PHILIPS

DATA HANDBOOK

PHILIPS ELECTRONIC COMPONENTS AND MATERIALS

ELECTRON TUBES

PART 4 APRIL 1971

Receiving tubes

ELECTRON TUBES

Part 4 **April 1971**

General section

Receiving tubes

DATA HANDBOOK SYSTEM

To provide you with a comprehensive source of information on electronic components, subassemblies and materials, our Data Handbook System is made up of three series of handbooks, each comprising several parts.
The three series, identified by the colours noted, are:

ELECTRON TUBES	(9 parts)	BLUE
SEMICONDUCTORS AND INTEGRATED CIRCUITS	(5 parts)	RED
COMPONENTS AND MATERIALS	(5 parts)	GREEN

The several parts contain all pertinent data available at the time of publication, and each is revised and reissued annually; the contents of each series are summarized on the following pages.
We have made every effort to ensure that each series is as accurate, comprehensive and up-to-date as possible, and we hope you will find it to be a valuable source of reference. Where ratings or specifications quoted differ from those published in the preceding edition they will be pointed out by arrows. You will understand that we can not guarantee that all products listed in any one edition of the handbook will remain available, or that their specifications will not be changed, before the next edition is published. If you need confirmation that the pusblished data about any of our products are the latest available, may we ask that you contact our representative. He is at your service and will be glad to answer your inquiries.

ELECTRON TUBES (BLUE SERIES)

This series consists of the following parts, issued on the dates indicated.

Part 1 — **January 1971**
Transmitting tubes (Tetrodes, Pentodes)
Associated accessories

Part 2 — **March 1971**
Tubes for microwave equipment

Part 3 — **March 1970**
Special Quality tubes
Miscellaneous devices

Part 4 — **April 1971**
Receiving tubes

Part 5 — **May 1971**
Cathode-ray tubes
Photo tubes
Camera tubes
Photoconductive devices
Associated accessories

Part 6 — **June 1970**
Photomultiplier tubes
Scintillators
Photoscintillators
Radiation counter tubes
Semiconductor radiation detectors
Neutron generator tubes
Associated accessories

Part 7 — **July 1970**
Voltage stabilizing and reference tubes
Counter, selector, and indicator tubes
Trigger tubes
Switching diodes
Thyratrons
Ignitrons
Industrial rectifying tubes
High-voltage rectifying tubes

Part 8 — **August 1970**
T.V. Picture tubes

Part 9 — **January 1971**
Transmitting tubes (Triodes)
Tubes for R.F. heating (Triodes)
Associated accessories

SEMICONDUCTORS AND INTEGRATED CIRCUITS (RED SERIES)

This series consists of the following parts, issued on the dates indicated.

Part 1 Diodes and Thyristors **September 1970**

General
Signal diodes
Tunnel diodes
Variable capacitance diodes
Voltage regulator diodes
Rectifier diodes
Thyristors, diacs, triacs
Rectifier stacks
Accessories
Heatsinks

Part 2 Low frequency; Deflection **October 1970**

General
Low frequency transistors (low power)
Low frequency power transistors
Deflection transistors
Accessories

Part 3 High frequency; Switching **November 1970**

General
High frequency transistors
Switching transistors
Accessories

Part 4 Special types **December 1970**

General
Transmitting transistors
Microwave devices
Field effect transistors
Dual transistors
Microminiature devices for thick- and thin-film circuits
Beam lead devices for thick- and thin-film circuits
Photo devices
Accessories

Part 5 Integrated Circuits **March 1971**

General
Digital integrated circuits
  DTL (FC family)
  TTL (FJ family)
  MOS (FD family)
Linear integrated circuits

COMPONENTS AND MATERIALS (GREEN SERIES)

This series consists of the following parts, issued on the dates indicated.

Part 1 Circuit Blocks, Input/Output Devices — September 1970

- Circuit blocks 100 kHz Series
- Circuit blocks 1-Series
- Circuit blocks 10-Series
- Circuit blocks 20-Series
- Circuit blocks 40-Series
- Counter modules 50-Series
- Norbits 60-Series, 61-Series
- Circuit blocks 90-Series
- Circuit blocks for ferrite core memory drive
- Input/output devices

Part 2 Resistors, Capacitors — December 1970

- Fixed resistors
- Variable resistors
- Non-linear resistors
- Ceramic capacitors
- Polyester, polycarbonate, polystyrene, paper capacitors
- Electrolytic capacitors
- Variable capacitors

Part 3 Radio, Audio, Television — February 1971

- FM tuners
- Coils
- Piezoelectric ceramic resonators and filters
- Loudspeakers
- Audio and mains transformers
- Television tuners
- Components for black and white television
- Components for colour television
- Deflection assemblies for camera tubes

Part 4 Magnetic Materials, White Ceramics — April 1971

- Ferrites for radio, audio and television
- Ferroxcube potcores and square cores
- Small coils, assemblies and assembling parts
- Ferroxcube transformer cores
- Piezoxide
- Permanent magnet materials

Part 5 Memory Products, Magnetic Heads, Quartz Crystals, Microwave Devices, Variable Transformers, Electro-mechanical Components — June 1970

- Ferrite memory cores
- Matrix planes, matrix stacks
- Complete memories
- Magnetic heads
- Quartz crystal units, crystal filters
- Isolators, circulators
- Variable mains transformers
- Electro-mechanical components

April 1971

Technology relating to the products described in this publication is shared by the following companies.

Argentina
FAPESA I.y.C.
Melincué 2594
Tel. 50-9941/8155
BUENOS AIRES

Australia
Philips Industries Ltd.
Miniwatt Electronics Division
20, Herbert St.
Tel. 43-2171
ARTARMON, N.S.W.

Austria
WIVEG
Zieglergasse 6
Tel. 93 26 22
A1072 VIENNA

Belgium
M.B.L.E.
80, rue des Deux Gares
Tel. 23 00 00
1070 BRUSSELS

Brazil
IBRAPE S.A.
Av. Paulista 2073-S/Loja
Tel. 278-1111
SAO PAULO

Canada
Philips Electron Devices
116, Vanderhoof Ave.
Tel. 425-5161
TORONTO 17, Ontario

Chile
Philips Chilena S.A.
Av. Santa Maria 0760
Tel. 39-40 01
SANTIAGO

Colombia
SADAPE S.A.
Calle 19, No.5-51
Tel. 422-175
BOGOTA D.E. 1

Denmark
Miniwatt A/S
Emdrupvej 115A
Tel. (01) 69 16 22
DK-2400 KØBENHAVN NV

Finland
Oy Philips A.B.
Elcoma Division
Kaivokatu 8
Tel. 10 915
HELSINKI 10

France
R.T.C.
La Radiotechnique-Compelec
Avenue Ledru Rollin 130
Tel. 797-99-30
PARIS 11

Germany
VALVO G.m.b.H.
Valvo Haus
Burchardstrasse 1,
Tel. (0411) 33 91 31
2 HAMBURG 1

Greece
Philips S.A. Hellénique
Elcoma Division
52, Av. Syngrou
Tel. 915.311
ATHENS

Hong Kong
Philips Hong Kong Ltd.
Components Dept.
St. George's Building 21st Fl.
Tel. K-42 82 05
HONG KONG

India
INBELEC Div. of
Philips India Ltd.
Band Box House
254-D, Dr. Annie Besant Road
Tel. 45 33 86, 45 64 20, 45 29 86
Worli, Bombay 18 (WB)

Indonesia
P.T. Philips-Ralin Electronics
Elcoma Division
Djalan Gadjah Mada 18
Tel. 44 163
DJAKARTA

Ireland
Philips Electrical (Ireland) Ltd.
Newstead, Clonskeagh
Tel. 69 33 55
DUBLIN 14

Italy
Philips S.p.A.
Sezione Elcoma
Piazza IV Novembre 3
Tel. 69 94
MILANO

Japan
NIHON PHILIPS
32nd Fl., World Trade Center Bldg.
5, 3-chome, Shiba Hamamatsu-cho
Minato-ku,
Tel. (435) 5204-5
TOKYO

Mexico
Electrónica S.A. de C.V.
Varsovia No.36
Tel. 5-33-11-80
MEXICO 6, D.F.

Netherlands
Philips Nederland N.V.
Afd. Elonco
Boschdijk, VB
Tel. (040) 43 33 33
EINDHOVEN

New Zealand
EDAC Ltd.
70-72 Kingsford Smith Street
Tel. 873 159
WELLINGTON

Norway
Electronica A/S
Middelthunsgate 27
Tel. 46 39 70
OSLO 3

Peru
CADESA
Ir. Jlo, No.216
Appartado 10132
Tel. 7 73 17
LIMA

Portugal
Philips Portuguesa S.A.R.L.
Rua Joaquim Antonio de Aguiar 66
Tel. 68 31 21/9
LISBOA

South Africa
EDAC (PTY) Ltd.
South Park Lane
New Doornfontein
Tel. 24/6701-2
JOHANNESBURG

Spain
COPRESA S.A.
Balmes 22
Tel. 2 32 03 00
BARCELONA 7

Sweden
ELCOMA A.B.
Lidingövägen 50
Tel. 08/67 97 80
10250 STOCKHOLM 27

Switzerland
Philips A.G.
Edenstrasse 20
Tel. 051/44 22 11
CH-8027 ZUERICH

Taiwan
Philips Taiwan Ltd.
San Min Building, 3rd Fl.
57-1, Chung Shan N. Road
Section 2
Tel. 559742, 512281
TAIPEI

Turkey
Turk Philips Ticaret A.S.
EMET Department
Gümüssuyu Cad. 78-80
Tel. 45.32.50
Beyoglu, ISTANBUL

United Kingdom
Mullard Ltd.
Mullard House
Torrington Place
Tel. 01-580 6633
LONDON WC1E 7HD

United States
Amperex Electronic Corp.
Electron Tubes Div.
Tel. 516 WE 1-6200
HICKVILLE N.Y.
Sem. and Microcircuits Div.
Tel. 401-762-9000
SLATERSVILLE R.I. 02876
Electronic Components Div.
Tel. 516-234-7000
HAUPPAGE N.Y.
Ferroxcube Corp.
(Memory Products)
P.O. Box 359
Tel. (914) 246-2811
SAUGERTIES, N.Y. 12477

Uruguay
Luzilectron S.A.
Rondeau 1567, piso 5
Tel. 9 43 21
MONTEVIDEO

Venezuela
C.A. Philips Venezolana
Elcoma Department
Colinas de Bello Monte
Tel. 72.01.51
CARACAS

January 1971

LIST OF SYMBOLS

Symbols denoting electrodes and electrode/element connections

Heater or filament	f
Heater or filament tap	f_c
Cathode	k
Input cathode lead	k_i
Output cathode lead	k_o
Grid	g
Electrostatic deflection plate or rod	D
Fluorescent screen	ℓ
Anode	a
Anode of a detection diode	d
Tube pin which must not be connected externally	i.c.
Tube pin which may be connected externally	n.c.
External conductive coating	m
Internal shield	s

Remarks

Equivalent electrodes of a multiple unit tube are distinguished by means of accents; e.g. the anodes of a double-anode rectifying tube are indicated by a and a'.

Similar electrodes of the same electrode system are distinguished by means of an additional numeral; the electrode nearest to the cathode has the lowest number.

The electrodes of multiple-unit tubes, in which the units are different, are distinguished by means of the following indices:

diode	D
triode	T
tetrode	Q
pentode	P
hexode or heptode	H

Symbols denoting voltages (average values unless otherwise stated)

Symbol for voltage, followed by an index denoting the relevant electrode/element	V
Heater or filament voltage	V_f
Peak value of a voltage	V_p
Peak to peak value of a voltage	V_{pp}
Supply voltage of tube electrodes	V_b
Anode voltage of a detection diode	V_d
RMS value of a voltage	V_{RMS}
Heater starting voltage	V_{fo}
Grid voltage	V_g
A.C. input voltage	V_i
Voltage between cathode and heater	V_{kf}
D.C. voltage supplied by a rectifying tube	V_o
A.C. output voltage	V_o
Voltage for gain control	V_R
Transformer voltage (secondary)	V_{tr}
Anode voltage under cold condition or cut-off condition (I_k approx.0)	V_{a_o}
Screen grid voltage under cold condition or cut-off condition (I_k approx.0)	$V_{g_{2o}}$

Remarks

In the case of indirectly heated tubes the electrode voltages are specified with respect to the cathode.
In the case of directly heated tubes the electrode voltages are specified with respect to the negative terminal of the filament, unless otherwise stated.

Symbols denoting currents

Remarks

The positive electrical current is directed opposite to the direction of the electron current.

The symbols quoted represent average values unless otherwise stated.

Symbol for current followed by an index denoting the relevant electrode	I
Heater or filament current	I_f
Anode current	I_a
Current of a detection diode	I_d
RMS value of a current	I_{RMS}
Grid current	I_g
Cathode current	I_k
Current to fluorescent screen	I_ℓ
D.C. current supplied by a rectifying tube	I_o
Peak value of a current	I_p

Symbols denoting powers

Symbol for power followed by an index denoting the relevant electrode	W
Anode dissipation	W_a
Grid dissipation	W_g
Input power	W_i
Anode supply D.C. power	W_{i_a}
Dissipation of a fluorescent screen	W_ℓ
Output power	W_o

Symbols denoting capacitances

See IEC Publication 100

Symbols denoting resistance and impedance

When for one of the following symbols Z is used instead of an R the word "resistance" should read "impedance"

External resistance in an anode lead	R_a
External A.C. resistance or load resistance in an anode lead	$R_{a\sim}$
Load resistance of a push-pull amplifier (anode to anode)	$R_{aa\sim}$
Equivalent noise resistance	R_{eq}
External resistor in a grid lead or grid circuit resistance	R_g
Input resistance	r_g
Internal resistance	R_i
Resistor in a cathode lead	R_k
External resistance between cathode and heater	R_{kf}
Protecting resistance in the anode lead of a rectifying tube	R_t

Symbols denoting various quantities

Brightness	B
Bandwidth	B
Distortion factor	d
n-th harmonic distortion	d_n
Noise factor	F
Frequency	f
Pulse repetition rate	f_{imp}
Power gain	G
Voltage gain	$V_o/V_{i,g}$
Height above sea level	h
Magnetic field strength	H
Cross modulation factor	K
Hum modulation factor	m_b
Transformer ratio	n
Transconductance	S
Conversion conductance	S_c
Effective transconductance of an oscillator	S_{eff}
Temperature	t
Ambient temperature	t_{amb}
Time	T
Averaging time of current or voltages	T_{av}
Cathode heating time	T_h
Pulse duration	T_{imp}
Shadow section on a fluorescent screen	α
Light sector on a fluorescent screen	β
Duty factor	δ
Phase angle	φ
Efficiency	η
Wavelength	λ
Amplification factor	μ
Amplification factor of grid No. 2 with respect to grid No. 1	$\mu_{g_2g_1}$

GENERAL OPERATIONAL RECOMMENDATIONS RECEIVING TUBES

CONTENTS

GENERAL OPERATIONAL RECOMMENDATIONS RECEIVING TUBES

1. GENERAL

Where deviations from these directives are permissible or necessary, statements to that effect will be made on the relevant data sheets. If applications are considered not referred to in the data sheet of the relevant tube type extra care should be taken with circuit design to avoid that the tube is overloaded due to unfavourable operating conditions.
Users are warned for applying a tube in circuits where use is made of tube characteristics not controlled by the manufacturer. When at a later date batches of tubes are delivered which show different values for these characteristics this may result in unsatisfactory performance of the equipment.

2. SPREAD IN TUBE CHARACTERISTICS

Equipment design should be based on the characteristics as stated in the data sheets.
Tube data not stated as maximum or minimum values apply to a nominal tube. When measurements are carried out on a small number of tubes, and in particular on new tube types it should be taken into account that average values and the spread figures may differ from those obtained for larger quantities.
No guarantee is given for values of characteristics in settings substantially differing from those specified in the data sheets.

3. SPREAD AND VARIATION IN OPERATING CONDITIONS

The operating conditions of the tube in the equipment are expressed as a number of parameter values each of which is subject to spread and/or variation.

3.1 Spread. Spread in a parameter value will result in individual values deviating permanently from the average value; spread is due to e.g. component value deviations. The average value is the average of such a number of individual values taken at random that an increase of the number will have a negligible influence on the average value.

3.2 Variation. Variation of a parameter value is the change of value occurring as a function of time, e.g. due to supply voltage fluctuations.
The average value is calculated over a period such that a prolongation of that period will have a negligible influence on the average value.

4. LIMITING VALUES

4.1 Limiting values are in accordance with the applicable rating system as defined by I.E.C. publication 134.
Reference may be made to one of the following 3 rating systems.

4.1.1 Absolute maximum rating system. Absolute maximum ratings are limiting values of operating and environmental conditions applicable to any electronic device of a specified type as defined by its published data, and should not be exceeded under the worst probable conditions.

These values are chosen by the device manufacturer to provide acceptable serviceability of the device, taking no responsibility for equipment variations, environmental variations, and the effects of changes in operating conditions due to variations in the characteristics of the device under consideration and of all other electronic devices in the equipment.

The equipment manufacturer should design so that, initially and throughout life, no absolute maximum value for the intended service is exceeded with any device under the worst probable operating conditions with respect to supply voltage variation, equipment components spread and variation, equipment control adjustment, load variations, signal variation, environmental conditions, and spread or variations in characteristics of the device under consideration and of all other electronic devices in the equipment.

4.1.2 Design-maximum rating system. Design-maximum ratings are limiting values of operating and environmental conditions applicable to a bogey electronic device* of a specified type as defined by its published data, and should not be exceeded under the worst probable conditions.

These values are chosen by the device manufacturer to provide acceptable serviceability of the device, taking responsibility for the effects of changes in operating conditions due to variations in the characteristics of the electronic device under consideration.

The equipment manufacturer should design so that, initially and throughout life, no design-maximum value for the intended service is exceeded with a bogey device under the worst probable operating conditions with respect to supply-voltage variation, equipment component variation, variation in characteristics of all other devices in the equipment, equipment control adjustment, load variation, signal variation and environmental conditions.

4.1.3 Design-centre rating system. Design-centre ratings are limiting values of operating and environmental conditions applicable to a bogey electronic device* of a specified type as defined by its published data, and should not be exceeded under average conditions.

Note*. A bogey tube is a tube whose characteristics have the published nominal values for the type. A bogey tube for any particular application can be obtained by considering only those characteristics which are directly related to the application.

These values are chosen by the device manufacturer to provide acceptable serviceability of the device in average applications, taking responsibility for normal changes in operating conditions due to rated supply-voltage variation, equipment component spread and variation, equipment control adjustment, load variation, signal variation, environmental conditions, and variations or spread in the characteristics of all electronic devices.

The equipment manufacturer should design so that, initially, no design-centre value for the intended service is exceeded with a bogey electronic device * in equipment operating at the stated normal supply-voltage.

4.2 If the tube data specify limiting values according to more than one rating system the circuit has to be designed so that none of these limiting values is exceeded under the relevant conditions.

4.3 In addition to the limiting values given in the individual data sheets the directives in the following paragraphs should be observed.

5. ELECTRODE VOLTAGES

5.1 All electrode voltages are given with respect to cathode.

5.2 Two limiting values of electrode voltage are given

a) V_{ao}, V_{g2o} etc.

These values are continuously permitted with cold cathode. They are also permitted as peak voltage during operation when a D.C. voltage in combination with a superimposed A.C. voltage is present at the electrode provided that the peak value coincides with approx. zero electrode current.

b) V_a, V_{g2} etc.

These values are D.C. components of the electrode voltages and are continuously permitted.

In circuits with automatic gain control the D.C. component may exceed the published limiting value with 20% provided that the increase of voltage results solely from the a.g.c. action and that maximum voltage coincides with approximately zero electrode current.

Proper functioning of the tubes at supply voltages lower than 50 volts cannot be guaranteed if these values are not quoted under the operating characteristics. Unless otherwise stated all values refer to positive voltages.

Floating electrodes. All tube electrodes should have a D.C. connection to the cathode (no floating electrodes).

6. ELECTRODE CURRENT

The limiting values I_a, I_{g2}, I_k etc. are the D.C. components of the electrode currents averaged over any 50 ms period.

If no specific pulse ratings apply, a peak value of three times I_a, I_{g2}, I_k etc. is permitted for maximum 25 ms.

---

* See note on previous page.

Spread and variation in electrode currents should be restricted so that with nominal tubes the specified design centre limiting values are not exceeded by more than 10% under the worst probable conditions.

7. ELECTRODE DISSIPATION

The limiting values W_a, W_{g_2} etc. are the average values, obtained by averaging over any 1 s period.

7.1 If not otherwise indicated the quoted operating conditions for audio output tubes are permitted only with speech and music signals.
When for power output tubes a limiting value W_{g2p} is stated this value applies only in the case of speech and music drive and it should not be exceeded when measured with a sinusoidal signal and at maximum output.
With class B operation and speech and music excitation the quoted limiting value of anode dissipation is allowed to be exceeded by max. 10% if measured with a sinusoidal signal at 2/3 of maximum drive.
When the operating conditions differ from those stated a non-decoupled series resistor of 0.5 to 1 kΩ may be required to avoid exceeding the limiting values of screen grid dissipation.
When load values vary during operation care should be taken that the limiting values of W_a or W_{g_2} are not exceeded.
Spread and variation in the electrode dissipation of audio output tubes should be restricted so that with bogey tubes the specified design centre limiting values are not exceeded by more than 20% under the worst probable conditions.

7.2 For all other types the quoted design centre limits for the electrode dissipations should not be exceeded by more than 15% with bogey tubes under the worst probable conditions unless otherwise stated in the relevant data sheets.

8. HEATER CIRCUIT

Any deviation from the nominal heater voltage (in case of parallel connection) or from the nominal heater current (in case of series connection) has a detrimental effect on tube performance and life, and should therefore be kept at a minimum.
Such deviations may be caused by:
a) Mains voltage fluctuations.
b) Spread in the characteristics of components such as transformers, resistors, capacitors etc.
Designers of heater circuits are strongly recommended to bear this in mind when dealing with equipment to be used in areas where the actual mains voltage is likely to differ from the nominal value.

8.1 Parallel connection

The maximum deviation of the heater voltage should not exceed ± 15% (design max. value).

This condition will be fulfilled when the mains voltage fluctuates by ± 10% and a ordinary transformer (see below) is used.

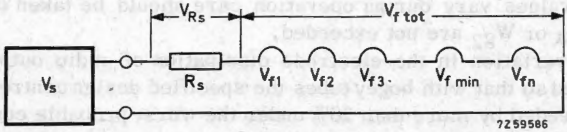
8.2 Series connection

The maximum deviation of the heater current should not exceed ± 8% (design max. value).

When a small number of tubes with large differences in the heater voltage is used in series connection combined with a series resistor or a series capacitor, the maximum permitted deviation of the heater current may be exceeded.

To avoid this, certain restrictions must be imposed on the composition of the heater chain; the maximum part of the supply voltage that can be eliminated, and the tolerances of the voltage dropper in series with the heaters.

A number of circuits for If = 300 mA will be described in detail below.



V_s = source voltage (mains voltage or mains voltage stepped down via a transformer)

V_{Rs} = voltage drop over series resistor

$V_{ftot.}$ = $V_{f1} + V_{f2} + V_{f3} \ldots\ldots\ldots + V_{fmin.} + \ldots\ldots\ldots V_{fn}$.

$V_{fmin.}$ = lowest individual heater voltage of all tubes in the chain

R_s = series resistor

Voltage source

The following spreads have been taken into account for the source voltage:

- Mains voltage spread ± 10% either or not combined with the voltage spread caused by a transformer with a permanent deviation from the nominal value of ± 1% and with a spread of ± 2% (ordinary, well made tranformer).

The following circuits are allowed:

8.2.1 Supply directly from a voltage source ($V_s = V_{ftot.}$)

- No restrictions.

8.2.2 Supply from a voltage source via a 5% series resistor ($V_s = V_{Rs} + V_{ftot.}$)

a. One single tube: permitted if $\frac{V_{Rs}}{V_{ftot.}} \leq 2$

b. Heater chain consisting of 2 or more tubes:

the maximum permitted ratio $\frac{V_{Rs}}{V_{ftot.}}$ can be read from diagram number 1 as follows:

Determine $\frac{V_{f\,min.}}{V_{ftot.}}$ of the heater chain. Draw a vertical line through the corresponding point in the diagram. Draw a horizontal line through the point of intersection of this vertical line with the line which indicates the total number of tubes in the chain. The point of intersection of this horizontal line with the vertical axis gives the maximum permitted ratio between the series resistor and the sum of the heater voltages of all tubes in the chain.

8.2.3 Supply from a voltage source via a series diode ($\frac{V_s}{\sqrt{2}} = V_{ftot.}$)

- No restrictions.

8.2.4 Supply from a voltage source via a series diode and a series resistor ($\frac{V_s}{\sqrt{2}} = V_{ftot.} + V_{Rs}$)

In the above formula $V_{ftot.}$ and V_{Rs} are RMS values and the maximum permitted ratio $\frac{V_{Rs}}{V_{ftot.}}$ can be read from diagram number 1 (see 8.2.2).

For calculation of R_s divide the required V_{Rs} (RMS) by the nominal heater current: $R_s = \frac{V_{Rs}}{0.3}$

Remark to 8.2.3 and 8.2.4:

When series diodes are applied, the D.C. component of the resulting heater voltage should preferably be negative with respect to the cathodes of the tubes.

8.2.5 Supply from a voltage source via a series capacitor

a. One single 300 mA tube; permitted if

$\frac{V_{f\,tot.}}{V_s} \geq 0.50$ when 5% paper capacitors are applied.

b. $\frac{V_{f\,tot.}}{V_s} \geq 0.70$ when 10% metalized polycarbonate capacitors are applied.

c. Heater chain consisting of 2 tubes or more; permitted if $\frac{V_{f\,tot.}}{V_s}$

$\frac{V_{f\,tot.}}{V_s} \geq 0.6$ when 5% paper capacitors are applied.

$\frac{V_{f\,tot.}}{V_s} \geq 0.8$ when 10% metallized polycarbonate capacitors are applied.

8.3 Stand-by (instant-on circuits)

In order to maintain reliability during life, it is recommended to reduce the heater voltage of the tubes during stand-by operation to 75% of the nominal value.

Note

If other designs for the heater supply circuit are wanted than the configurations described above it is strongly recommended to contact the tube manufacturer.

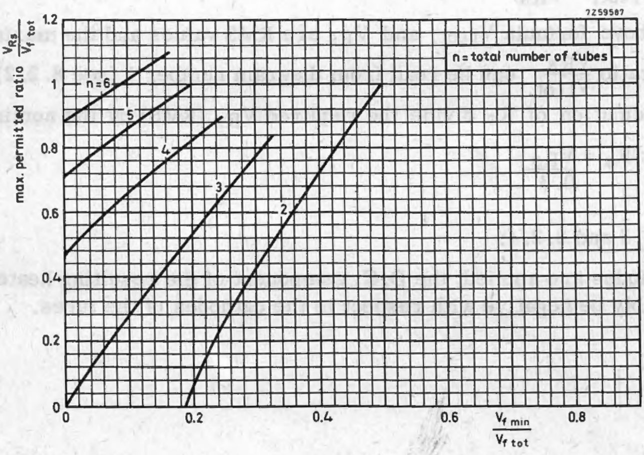


Diagram No. 1

9. HEATER-TO-CATHODE CIRCUIT

The published limiting values of V_{kf} apply to the positive and negative D.C. component of the voltage between the cathode and any of the heater terminals.
The limiting peak value is twice the rated D.C. value with a maximum of 315 V.

In stating these values figures only the risk of breakdown has been considered. No conclusions with respect to hum should be drawn from them.
To minimize the influence of variation and spread in the leakage current between heater and cathode the resistance of the external heater to cathode circuit should not exceed 20 kΩ.
However, when the D.C. value of V_{kf} never drops below three times the RMS value of the heater voltage a resistor of maximum 220 kΩ may be connected between heater and cathode provided that the hum voltage which may develop across the cathode resistor is acceptable for the application considered.
An interruption of the D.C. connection between cathode and earth or heater and earth may introduce heater-cathode breakdown and should be avoided.

10. SUPPRESSOR GRID CIRCUIT

The suppressor grid should normally be connected to the cathode; any series resistance in the suppressor grid lead should not exceed a value of 50 kΩ. The suppressor grid should not be used as a control grid unless specific recommendations are made in the data sheets. Where the suppressor grid is so used, care should be taken not to exceed the maximum screen-grid dissipation. When a tube is connected as a triode, the suppressor grid should be connected directly to the cathode, except where other recommendations are given in the data sheets. If the circuit is such that the suppressor grid is liable to be driven positive, it is recommended to consult the tube manufacturer.

11. CONTROL GRID CIRCUIT

In the interest of low hum and noise the resistance in the control grid circuit should be as low as possible.
The limiting value of the grid resistance given in the data sheets is so chosen that during the tube life the negative grid current which may occur will not result in unacceptable tube operation.
If only the limiting value of the resistance for fixed bias operation is given and stabilizing elements are used in the circuit, this limiting value may be multiplied by the D.C. feedback factor obtained by these stabilizing elements; the maximum limiting value should not exceed 20 MΩ.

12. CAPACITANCES

All data have been measured according to I.E.C. Publication 100

13. PROTECTIVE RESISTORS FOR MAINS RECTIFYING TUBES

To restrict the peak value of cathode current in a mains rectifying tube the ohmic resistance (R_t) in series with the anode should not be less than that specified in the data sheet.

When the anode supply voltage is obtained from a transformer the value of the resistance to be added in each anode lead should be calculated from the following formula:

$$R_t = R_s + n^2 R_p + R_1 .$$

In case of half-wave rectification

R_t = the required protective resistance
R_s = the ohmic resistance of the secondary coil
n = the transformer ratio
R_p = the ohmic resistance of the primary coil
R_1 = resistance that must be added

In case of full-wave rectification

R_t = the required protective resistance per anode
R_s = ohmic resistance of half the secondary coil
n = transformer ratio between primary and half the secondary coil
R_p = ohmic resistance of the primary coil
R_1 = resistance to be added in each anode lead.

When an auto transformer is applied it should be taken into account that the transformer winding is partly short-circuited by the mains.

When a filter input capacitor is applied the power dissipation in R_t is supplemented by the contribution of the ripple current up to three times the value produced by the D.C. component of current.

14. LIFE

Optimum life performance is ensured if the tube is operated according to the published "Operating conditions". Spread and variation of operating conditions should be limited as much as possible.

15. HUM

15.1 When the heater supply is obtained from the mains voltage the cathode current may be modulated by the A.C. mains frequency.
This modulation, resulting in hum, may be caused by capacitive or leakage currents between the heater and the tube electrodes, by the magnetic field of the heater or by external fields.

15.2 The following measures can be taken to reduce hum.

Cathode hum

Keep the A.C. voltage between cathode and heater as small as possible; with series operation insert the most critical tube at the earthed side of the heater chain and with parallel operation connect the electrical centre of the heater to earth.

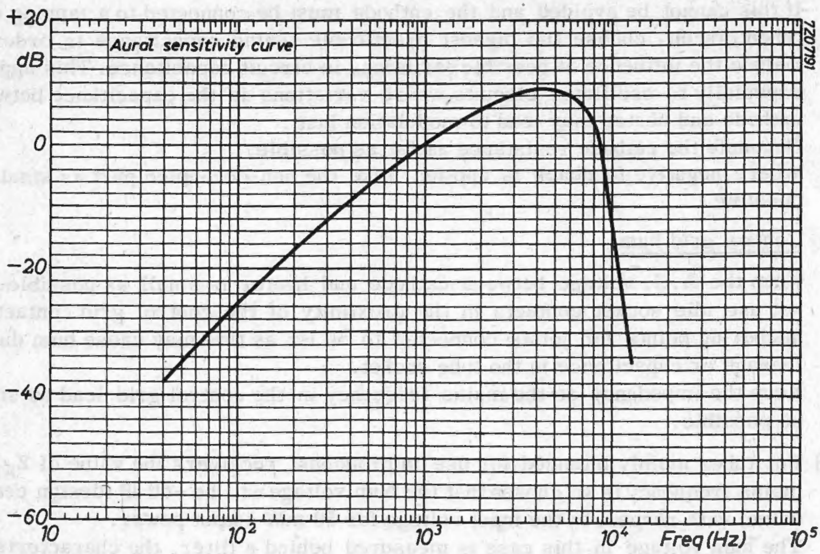
Do not include the impedance between cathode and heater in an R.F. circuit. If this cannot be avoided and the cathode must be connected to a tapping of a tuned circuit, choose the highest practicable tuning capacitance in order to reduce the influence of possible variations in circuit capacitance. This applies especially to oscillator circuits where variations in the capacitance between cathode and heater may lead to modulation hum.
Decouple the cathode resistance as far as possible.
Where negative feedback is applied, take the non-decoupled part as small as possible.

Control grid hum

Keep the A.C. voltage between cathode and heater as small as possible. Do not use idle socket contacts in the proximity of the control grid contact as anchoring points for joints connected to 50 Hz as this may cause hum due to leakage or capacitance in the tube socket.
Keep the impedance at the mains frequency in the control grid lead as small as possible.

15.3 For tubes mainly intended for use in broadcast receivers the value of Z_{g_1} at mains frequency is so chosen that the hum voltage will be −60 dB (design centre value) with respect to the input voltage for 50 mW output power.
The hum voltage in this case is measured behind a filter, the characteristic, of which agrees with the C.C.I.R. aurai sensitivity curve (see graph on next page).
For tubes mainly intended for use in audio equipment the value of Z_{g_1} is so chosen that the level of hum voltage, measured with a filter linear up to 500 Hz, is − 60 dB with respect to the input voltage for maximum output power.
To obtain these values the centre of parallel-connected heaters should be earthed whereas with series-connected heaters the value of V_{kf}, permitted in connection with hum, should not be exceeded; when a cathode resistor is used, it should be decoupled by a capacitor of at least 100 μF.
It should be realized that, although the tubes may meet the requirement of a −60 dB hum level, the total hum level of the circuitry stage under consideration may be higher owing to imperfect circuitry (magnetic hum induced by transformers and smoothing chokes; unsatisfactory smoothing of the rectified voltage, etc.).
For several R.F. and I.F. types a curve has been published which shows, as a function of the transconductance, the hum voltage (V_i) on the control-grid which causes a modulation hum of 1%.

The published limiting value of V_{kf} is the maximum permissible value up to which there will be no danger of breakdown between cathode and heater, and it does not give information about the resulting hum level.



16. MICROPHONY

Whenever a tube is subjected to vibration, caused by e.g. a loudspeaker, motor, switch etc., some disturbance in the output of the tube occurs. The effect of this disturbance will depend on the individual application. The published data of various tube types make reference to the microphonic sensitivity and this should be noted when a tube is chosen for a specific application.

Where the effects of microphony are found to be objectionable, special steps may have to be taken to reduce the vibration reaching the tube. The chassis itself may show wide variations in amplitude of vibration over its area, due to resonances; therefore favourable location of the tube, or local strengthening of the chassis, may appreciably reduce microphony.

The maximum peak acceleration to which the tube may be subjected under the most unfavourable conditions is 1.5 g at frequencies < 600 Hz and 0.2 g at frequencies > 600 Hz. However, tubes should not be subjected to the maximum acceleration at a given frequency for a long period of time. In case the actual acceleration is higher than these values, difficulties with regard to microphony may be expected.

Warning: It should be noted that excessive mechanical vibration may result in the destruction of the internal tube structure.

17. ENVIRONMENTAL CONDITIONS

1. Atmospheric pressure. Ratings apply to operation at normal atmospheric pressure at altitudes below 3000 m.
   It is advised to consult the tube manufacturer if tubes have to be operated at lower pressures.

2. Thermal considerations. The bulb and the base temperature are defined as the highest temperature at any place on the bulb or the base. The base temperature should not exceed 165 °C.
   Used in practical circuits and under design centre conditions the bulb temperature of a tube should not exceed by more than 30 °C that temperature which would be attained if the tube were operated at its maximum ratings in free air at a room temperature of 20 °C.
   If, for instance, the bulb temperature of a certain type of tube operating in free air at maximum ratings is shown to be 200 °C, it is permissible to use this tube in equipment where the bulb attains a temperature of 230 °C (thus at an excess of 30 °C). In practice this means that the "ambient" temperature in the equipment may rise above room temperature by about twice 30 °C and thus may attain a value of 80 °C.
   When a tube runs particularly hot this increase of 30 °C is not permissible; the design maximum should then be 250 °C unless otherwise stated in the relevant data sheets.
   When the maximum permitted base or bulb temperature is exceeded, the tube reliability during life may deteriorate. Cooling should therefore always be adequate; it may be obtained by convection, radiation or conduction. To make it most efficient a free circulation of air should be assured around the tube and the temperature of neighbouring bodies should be low. These neighbouring bodies should preferably approach a perfect black body.
   The design of screening or retaining devices should also be such that the reflection of heat back to the bulb must be minimized. In some cases it may be necessary to reduce the electrode dissipation.
   Heat dissipating shields have the property to reduce the hot-spot temperature at the tube envelope. However, this is generally accompanied by a rise in base temperature whereas also the normal sublimation pattern inside the tube may be drastically disturbed. For this reason extreme care should be exercised when applying these devices.

3. High Voltage insulation. To avoid insulation breakdown due to ionization or tracking at high electrode voltages adequate ventilation is required.
   High voltage terminals should not have sharp or pointed edges.

18. MOUNTING AND WIRING

1. Mounting position. Unless otherwise specified, a tube may be mounted in any position.

2. Pins and sockets. Many tube types employ semi-rigid pins.

   To ensure that these pins are straight before insertion into the tube socket use may be made of a pin straightening tool. It is recommended both in wired and in printed circuits to use sockets in which the contact springs are reasonably flexible. Too stiff wiring may hold the contacts out of position in such a way that the tube base is damaged upon insertion. To avoid this the use of a wiring jig is recommended. The dimensions of the wiring jig shall be in conformity with the nominal base dimensions specified in this Handbook.

   No connections should be made to a pin marked i.c.

   The sockets used shall comply with the following:
   The insertion and withdrawal forces of sockets shall be checked before any previous gauging or sizing. The sockets shall be capable of accepting and having withdrawn from them the insertion and withdrawal force gauge* within the force limits specified below. These tests shall be made with a test jig.

   Socket compatible with small button miniature 7 pin base (IEC 67-I-10a)

max. insertion force	72 N (7.2 kgf)
min. withdrawal force	12 N (1.2 kgf)

   Socket compatible with small button noval 9 pin base (IEC 67-I-12a)

max. insertion force	91 N (9.1 kgf)
min. withdrawal force	13.5 N (1.35 kgf)

   Socket compatible with small button decal 10 pin base (IEC 67-I-41a)

max. insertion force	91 N (9.1 kgf)
min. withdrawal force	13.5 N (1.35 kgf)

   Socket compatible with magnoval base (IEC 67-I-36a)

max. insertion force	91 N (9.1 kgf)
min. withdrawal force	13.5 N (1.35 kgf)

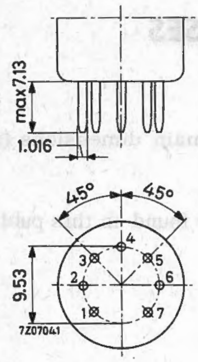
3. Retaining devices. When measures are required to prevent a tube from being shaken out of the socket a retaining device may be used.
   Care should then be taken to avoid the maximum permitted bulb temperature being exceeded.

* Described in I.E.C. Publication 149.

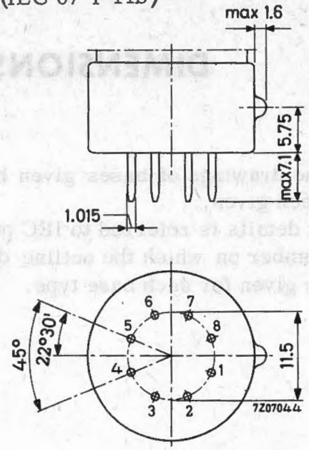
DIMENSIONS OF BASES

In the outline drawings of bases given below, some main dimensions (in mm) only have been given.
For further details is referred to IEC publication 67.
The page number on which the outline drawing can be found in this publication is therefore given for each base type.

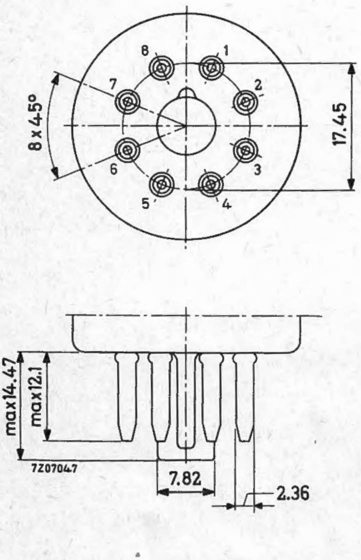
MINIATURE 7-PIN BASE
(IEC 67-I-10a)



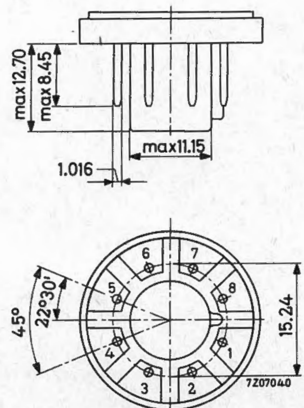
RIMLOCK BASE
(IEC 67-I-11b)



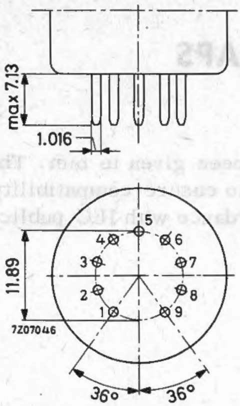
OCTAL BASE
(IEC 67-I-5a)



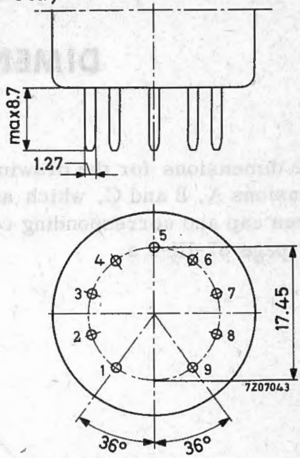
NEO EIGHTAR BASE
(IEC 67-I-31a)



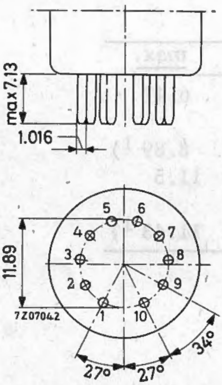
NOVAL BASE
(IEC 67-I-12a)



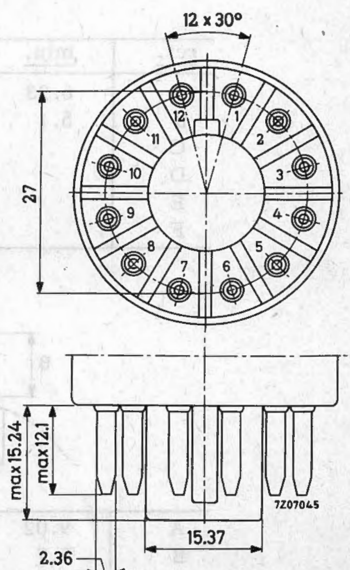
MAGNOVAL BASE
(IEC 67-I-36a)



DECAL BASE
(IEC 67-I-41a)

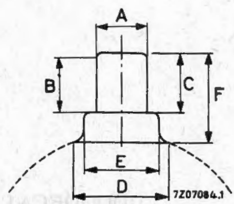


DUODECAL BASE
(IEC 67-I-17a)



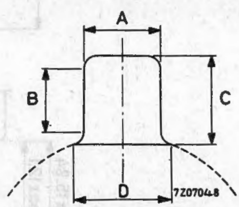
DIMENSIONS OF CAPS

The dimensions for the drawings of top caps have been given in mm. The dimensions A, B and C, which are those necessary to ensure compatibility between cap and corresponding connector are in accordance with IEC publication 67, page 67-III-1 a.



Type 1

ref.	min.	nom.	max.
A	6.23	6.35	6.47
B	5.1		
C		7.14	8.89 1)
D			11.5
E		9.15	
F		10.31	11.43 1)



Type 2

A	9.02	9.14	9.27
B	7.7		
C		10.31	11.43 1)
D			11.5

1) Without solder. On finished article an increase of 0,5 mm is allowed on this dimension for solder.

Receiving Tubes

DOUBLE ANODE RECTIFYING TUBE

Double anode high vacuum rectifying tube.

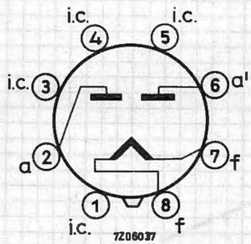
QUICK REFERENCE DATA			
Transformer voltage	V_{tr}	2 x 500	V_{RMS}
D.C. output current	I_o	max. 60	mA

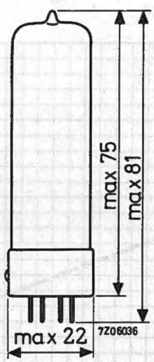
HEATING: Direct by A.C.

Filament voltage	V_f	4.0	V
Filament current	I_f	0.72	A

DIMENSIONS AND CONNECTIONS Dimensions in mm

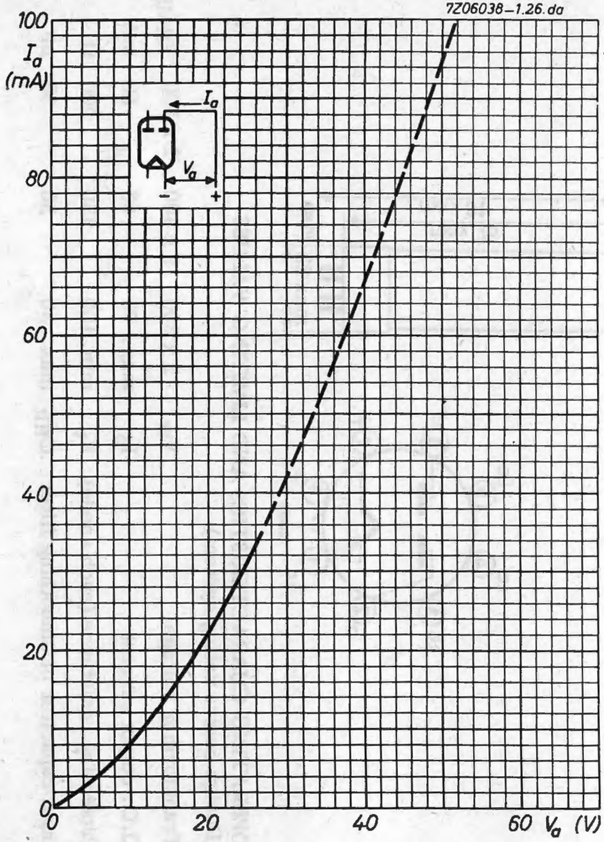
Base: Rimlock

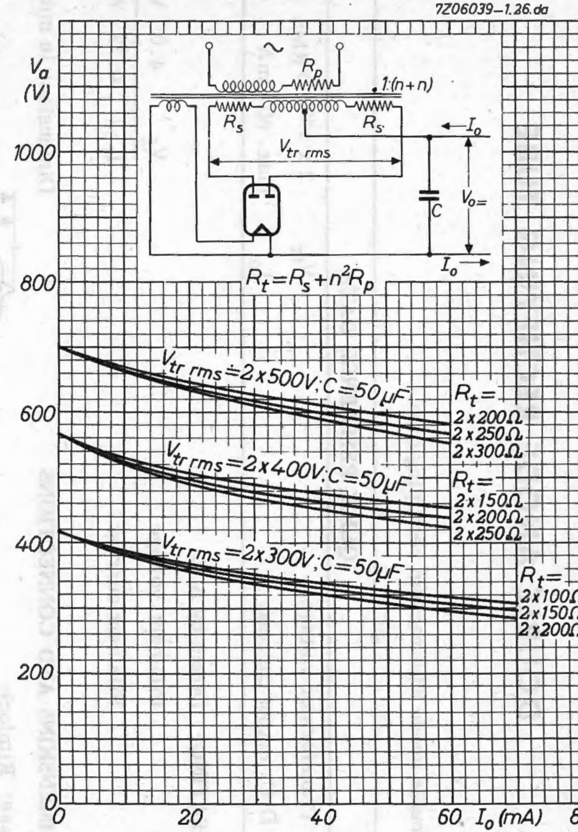




OPERATING CHARACTERISTICS AND LIMITING VALUES
(Design centre rating system)

Transformer voltage	V_{tr}	2 x 300	2 x 400	2 x 500	V_{RMS}
D.C. output current	I_o	max. 70	60	60	mA
Protecting resistance (each anode)	R_t	min. 100	150	200	Ω
Input capacitor of smoothing filter	C_{filt}	max. 50	50	50	μF


7Z06038-1.26.da
I_a (mA)
I_a
V_a
\-
\+
100
80
60
40
20
0
0
20
40
60
V_a (V)


7Z06039-1.26.da
V_a (V)
~
R_p
1:(n+n)
R_s
R_s
I_o
$V_{tr\ rms}$
C
$V_{o=}$
I_o
$R_t = R_s + n^2 R_p$
$V_{tr\ rms} = 2 \times 500V; C = 50\mu F$
$R_t =$
$2 \times 200\Omega$
$2 \times 250\Omega$
$2 \times 300\Omega$
$V_{tr\ rms} = 2 \times 400V; C = 50\mu F$
$R_t =$
$2 \times 150\Omega$
$2 \times 200\Omega$
$2 \times 250\Omega$
$V_{tr\ rms} = 2 \times 300V; C = 50\mu F$
$R_t =$
$2 \times 100\Omega$
$2 \times 150\Omega$
$2 \times 200\Omega$
1000
800
600
400
200
0
0
20
40
60
I_o (mA)
80

TUNING INDICATOR

Subminiature tuning indicator.

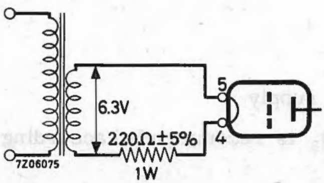
HEATING: Direct by D.C. or A.C.; series or parallel supply

A. In battery receivers

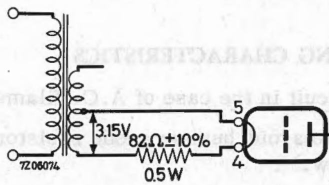
Filament voltage	V_f	1,4	V
Filament current	I_f	25	mA

One of the pins 4 and 5 should be connected to the earthed point of the detector circuit.

B. In A.C. receivers



With 6.3 V transformer winding



With 6.3 V winding with mid tap

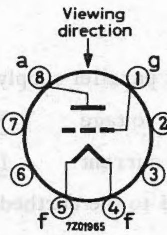
Pin 5 should be connected to the earthed point of the detector circuit.

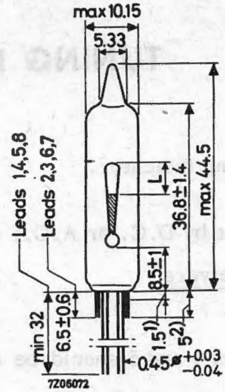
C. In A.C./D.C. receivers

Filament voltage	V_f	1.3	V

The filament of the DM70 with a suitable shunt resistor can be connected in a normal heater chain, provided an N.T.C. resistor is present.
Pin 5 should be connected to the earthed point of the detector circuit.

DIMENSIONS AND CONNECTIONS Dimensions in mm





Base: Submin. 8 p

L = length of the light bar = max. 14 mm

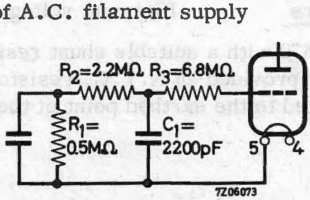
OPERATING CHARACTERISTICS

Anode circuit in the case of A.C. filament supply

In order to avoid hum an anode resistor R_a is recommended according to the table below.

Supply voltage	V_b	250	V	R_a	1.8	MΩ
	V_b	170	V	R_a	1.0	MΩ
	V_b	110	V	R_a	0.47	MΩ

Grid circuit in the case of A.C. filament supply



In order to avoid hum a filter is recommended in the grid circuit according to the above diagram.
R_1 is the detector resistor. In the case of non-delayed A.G.C. the resistor R_2 and the capacitor C_1 are already present.

---

1) This part of the leads should not be bent.
2) This part of the leads should not be soldered.

OPERATING CHARACTERISTICS (continued)

A. Battery supply

Filament voltage	V_f	1.4[1]	1.4[2]	V
Supply voltage	V_b	67.5	90	V
Anode voltage	V_a[3]	60	85	V
Grid voltage	V_g	0	0	V
Anode current	I_a	105	170	μA
Length of light bar	L	10	11	mm
Grid voltage at L = 0	$V_g(L = 0)$	-7	-10	V

B. Mains supply

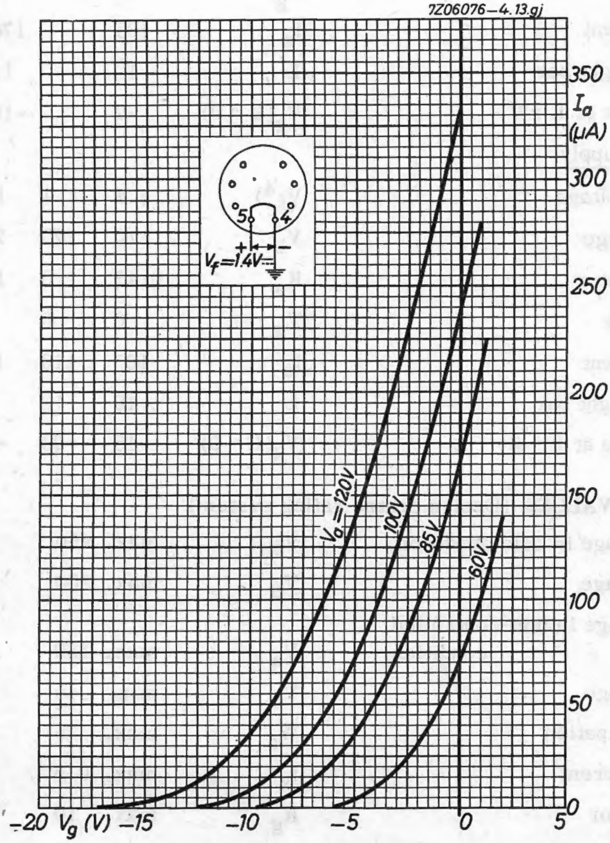
Filament voltage	V_f[4]	1.4	1.4	1.4	V_{RMS}
Supply voltage	V_b	110	170	250	V
Anode resistor	R_a	0.47	1.0	1.8	MΩ
Grid voltage	V_g	0	0	0	V
Anode current	I_a	105	110	105	μA
Length of light bar	L	10	10	10	mm
Grid voltage at L = 0	$V_g(L = 0)$	-15	-23	-34	V

LIMITING VALUES (Design centre rating system)

Supply voltage in cold condition	V_{b_o}	max. 450	V
Supply voltage	V_b	max. 300	V
Anode voltage in non-controlled condition	V_a	max. 150	V
Anode voltage	V_a	min. 45	V
Anode dissipation	W_a	max. 75	mW
Cathode current	I_k	max. 0.6	mA
Grid resistor	R_g	max. 10	MΩ

---

1) D.C.; pin 5 grounded
2) D.C.; pin 4 grounded
3) $V_a = V_b$ reduced by the bias for the output valve
4) A.C.; pin 5 connected to earth. When V_f is adjusted according to page 1, I_a will be 1-2 μA lower. The other data remain unchanged.


7Z06076–4.13.gj
350
300
250
200
150
100
50
0
I_a (μA)
5
4
V_f=1.4V
V_a=120V
100V
85V
60V
–20
V_g (V)
–15
–10
–5
0
5

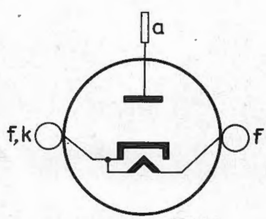
SINGLE ANODE E.H.T. RECTIFYING TUBE

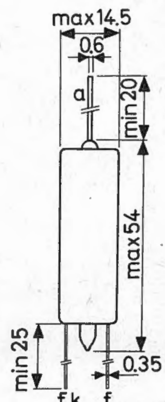
Single anode high vacuum rectifying tube intended for use in portable T.V. receivers.

HEATING: Indirect; parallel supply

Heater voltage	V_f	1.4	V
Heater current	I_f	550	mA

DIMENSIONS AND CONNECTIONS Dimensions in mm





The tube has flexible leads, which must not be bent nearer than 10 mm to the tube bottom.
The leads should not be soldered nearer than 1.5 mm to the seal.

CAPACITANCE

Anode to all	C_a	0.8	pF

TYPICAL CHARACTERISTICS

Anode voltage	V_a	100	V
Anode current	I_a	13	mA

LIMITING VALUES (Design centre rating system, unless otherwise specified)

Anode voltage, negative peak	$-V_{ap}$	max.	15	kV
Anode voltage, negative peak (abs. max.)	$-V_{ap}$	max.	18	kV
Anode current, average	I_a	max.	350	μA
Anode current, peak	I_{ap}	max.	40	mA [1])
Filter input capacitance	C_{filt}	max.	2000	pF
Heater voltage ($I_a < 200\ \mu$A) (abs. max.)	V_f	max.	1.6	V
Heater voltage ($I_a > 200\ \mu$A) (abs. max.)	V_f	min.	1.3	V

[1]) Max. duration is 10 % of a line-scanning cycle, but max. 10 μsec.

SINGLE ANODE E.H.T. RECTIFYING TUBES

High-vacuum single-anode rectifying tubes for high tension in television receivers (E.H.T. supply from the line time base).

The DY86 and DY87 are equivalent except for the DY87 having a chemically treated envelope which avoids flash-over under conditions of high humidity and low atmospheric pressure (45 cm Hg).

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage	V_f	1.4	V
Heater current	I_f	550	mA

When the heater is to be operated on R.F. or flyback pulses, the heater voltage can be adjusted to 1.4 V e.g. by measurement with a thermocouple.

Tolerances of V_f

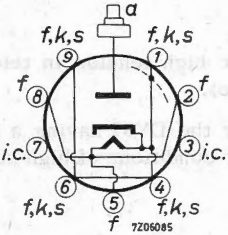
a. As E.H.T. rectifier in television receivers

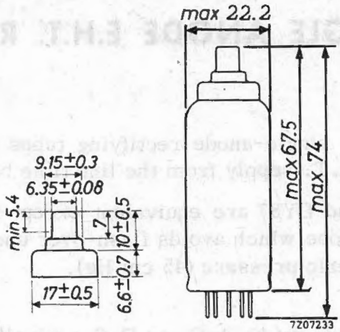
The heater voltage should be adjusted to its nominal value at a D.C. output current of 200 μA. At an increase of the D.C. output current to 400 to 600 μA which can incidentically occur during operation the decrease of the heater voltage may amount to max. 15 %. These requirements hold for nominal mains voltage and full horizontal scanning of the picture tube. If the picture width control is such that also the heater voltage of the E.H.T. diode is influenced, the influence of this control must be kept within the 15 % limit indicated above.

b. For all other applications the limits for the heater voltage are as given in the application directions in front of this section.

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: NOVAL





REMARKS

a. Pins 1, 4, 6 and 9 can be used for fixing an anti-corona ring.

b. Circuit elements having the same potential as the heater (e.g. a series resistor) may be connected to pins 3 and 7. These pins must never be earthed.

c. If the tube operates at high values of $V_{a\ invp}$ and/or under conditions of high relative humidity or low pressure the metal top-cap should get an insulating cover to avoid corona phenomena.

CAPACITANCES (without external shield)

Anode to all	C_a	1.55	pF

OPERATING CHARACTERISTICS

Output current	I_o	0.15	mA
Output voltage	V_o	18	kV

LIMITING VALUES (Design centre rating system unless otherwise stated)

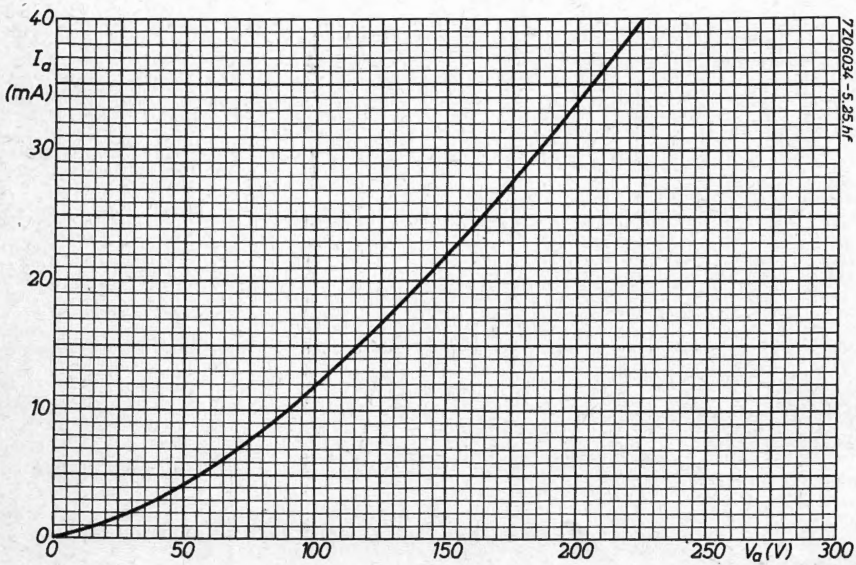
Output voltage	V_o	max.	18	kV	
Peak inverse voltage	$V_{a\,inv_p}$	max.	22	kV	1)
Peak inverse voltage (Absolute max.)	$V_{a\,inv_p}$	max.	27	kV	1)
Peak inverse voltage without current	$V_{a\,inv_p}(I_o = 0)$	max.	24	kV	1)
Output current	I_o	max.	0.5	mA	2)
Peak output current	I_{a_p}	max.	40	mA	3)
Filter input capacitance	C_{filt}	max.	2000	pF	

1) Maximum pulse duration 22 % of a line scanning cycle with a maximum of 18 μsec.

The negative peak anode voltage due to ringing in the line-output transformer must be taken into account. The ratio between this negative peak value and the positive D.C. voltage can be about 1 : 4.5.

2) During short periods as in television service I_o = max. 0.8 mA.

3) Maximum pulse duration 10 % of a line scanning cycle with a maximum of 10 μsec.


40
I_a
(mA)
30
20
10
0
0
50
100
150
200
250
V_a (V)
300
7Z06034-5.25.hf

E.H.T. RECTIFYING TUBE

High-vacuum single-anode rectifying tube for high tension in television receivers (E.H.T. supply from the line time base)

The DY802 has a chemically treated envelope which avoids flash-over under conditions of high humidity and low atmospheric pressure (45 cm Hg).

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage	V_f	1.4	V
Heater current	I_f	600	mA

Tolerances of V_f

a. As E.H.T. rectifier in television receivers

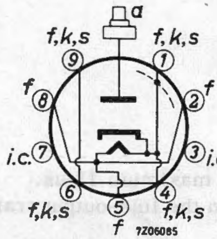
The heater voltage should be adjusted to its nominal value at a D.C. output current of 200 μA. At an increase of the D.C. output current to 400-800 μA which can incidentically occur during operation the decrease of the heater voltage may amount to max. 15%. These requirements hold for nominal mains voltage and full horizontal scanning of the picture tube. If the picture width control is such that also the heater voltage of the E.H.T. diode is influenced, the influence of this control must be kept within the 15% limit indicated above.

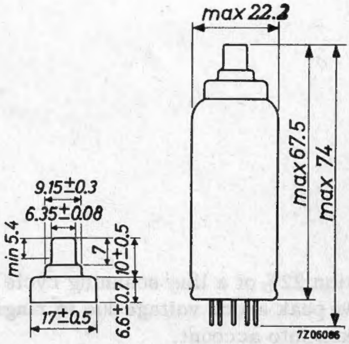
b. For all other applications the limits for the heater voltage are as given in the application directions.

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





REMARKS

a. Pins 1, 4, 6 and 9 can be used for fixing an anti-corona ring.

b. Circuit elements having the same potential as the heater (e.g. a series resistor) may be connected to pins 3 and 7. These pins must never be earthed.

c. If the tube operates a high values of V_{ainvp} and/or under conditions of high relative humidity or low pressure the metal top-cap should get an insulating cover to avoid corona phenomena.

CAPACITANCE

Anode to all	C_a	1.0	pF

OPERATING CHARACTERISTICS

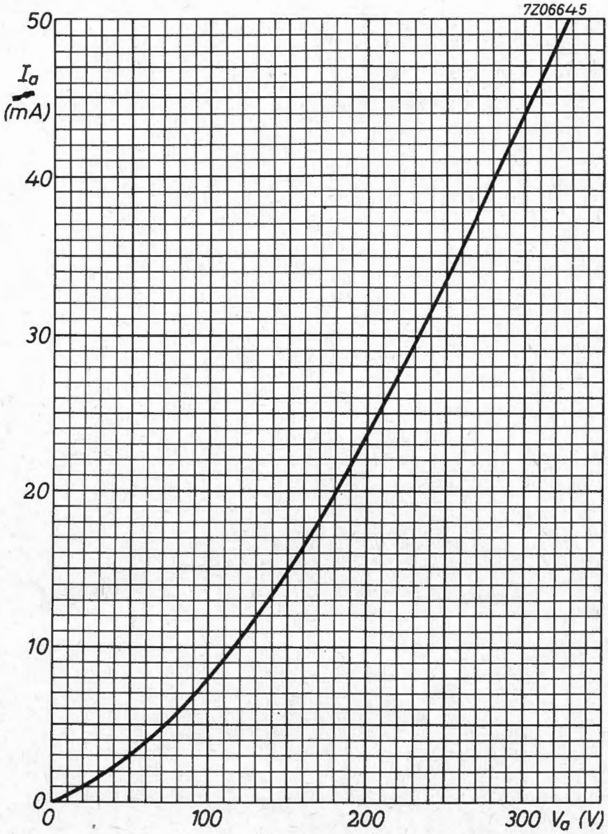
Output current	I_o	200	μA
Output voltage	V_o	20	kV

LIMITING VALUES (Design centre rating system unless otherwise stated)

Output voltage	V_o	max.	20	kV
Peak inverse voltage	V_{ainvp}	max.	25	kV [1])
Peak inverse voltage (Abs. max.)	V_{ainvp}	max.	30	kV [1])
Output current, average	I_o	max.	500	μA [2])
peak	I_{op}	max.	50	mA
Filter input capacitance	C_{filt}	max.	3000	pF

[1]) Max. duration 22% of a line scanning cycle and maximum 18 μs. The negative peak anode voltage due to ringing in the line-output transformer must be taken into account.

[2]) During short periods as in TV operation I_o = max. 800 μA.


7Z06645
50
I_a
(mA)
40
30
20
10
0
0
100
200
300 V_a (V)

DOUBLE DIODE

Double diode with separate cathodes.

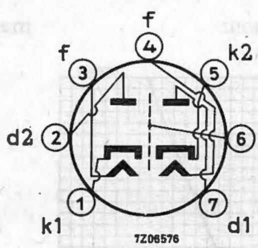
QUICK REFERENCE DATA			
A.C. supply voltage	V_{tr}	150	V_{RMS}
D.C. current per system	I_o	9	mA

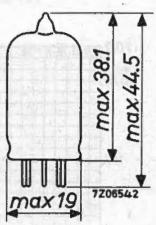
HEATING: Indirect by A.C. or D.C.; series or parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	300	mA

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Miniature





CAPACITANCES

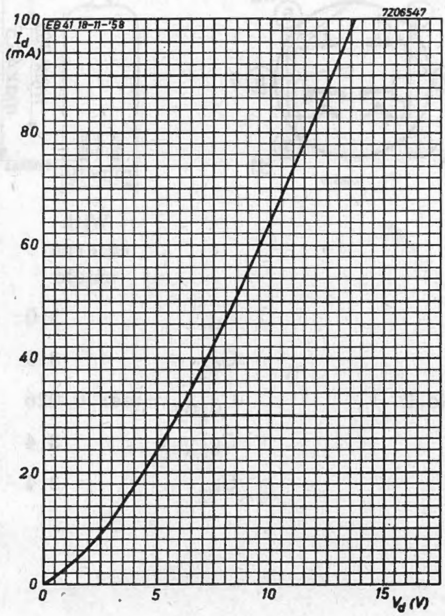
		With external shield	Without external shield	
Diode No. 1 to all	C_{d_1}	3.0	2.5	pF
Diode No. 2 to all	C_{d_2}	3.0	2.5	pF
Diode No. 1 to diode No. 2	$C_{d_1d_2}$	max. 0.026	max. 0.068	pF
Cathode No. 1 to all	C_{k_1}	3.4	3.4	pF
Cathode No. 2 to all	C_{k_2}	3.4	3.4	pF

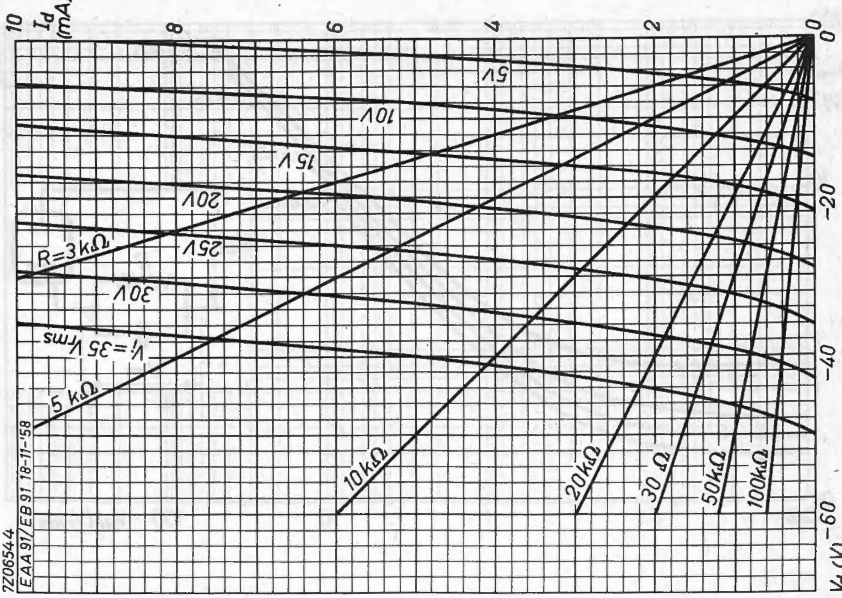
LIMITING VALUES Design centre rating system. (Each system)

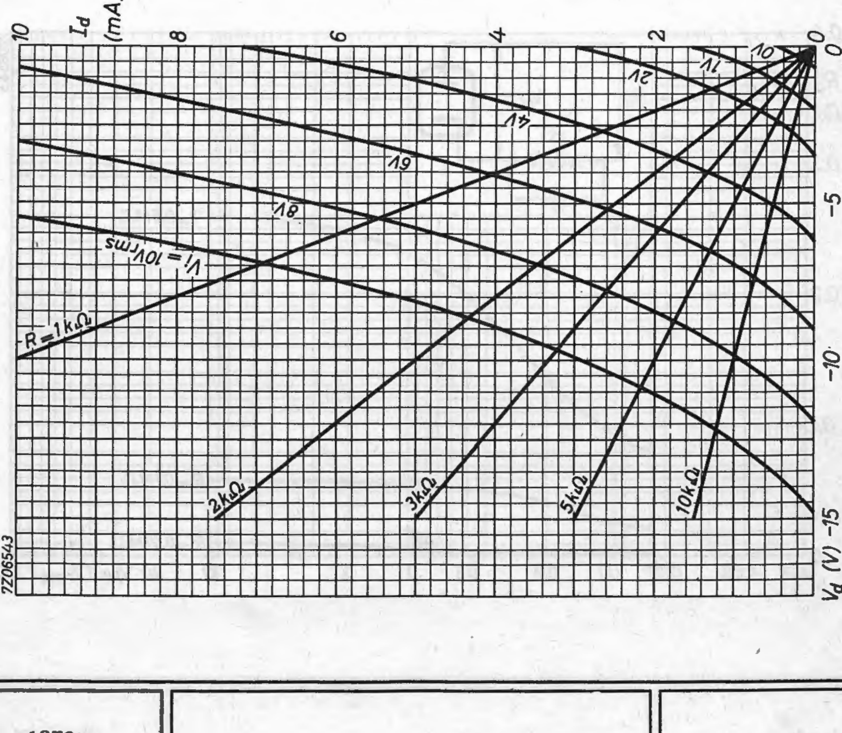
Diode voltage, negative peak	$-V_{dp}$	max.	420	V
Diode current	I_d	max.	9	mA
Diode current, peak	I_{dp}	max.	54	mA
Cathode to heater voltage peak (k neg)	V_{kf_p} (k neg)	max.	150	V
Cathode to heater voltage, peak (k pos)	V_{kf_p} (k pos)	max.	330	V
D.C. component		max.	200	V
A.C. component		max.	165	V_{RMS}

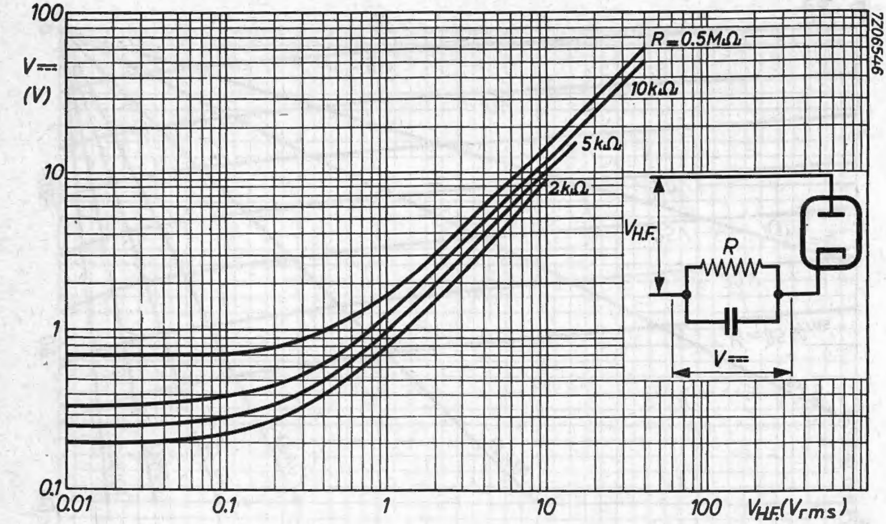
As half wave rectifier

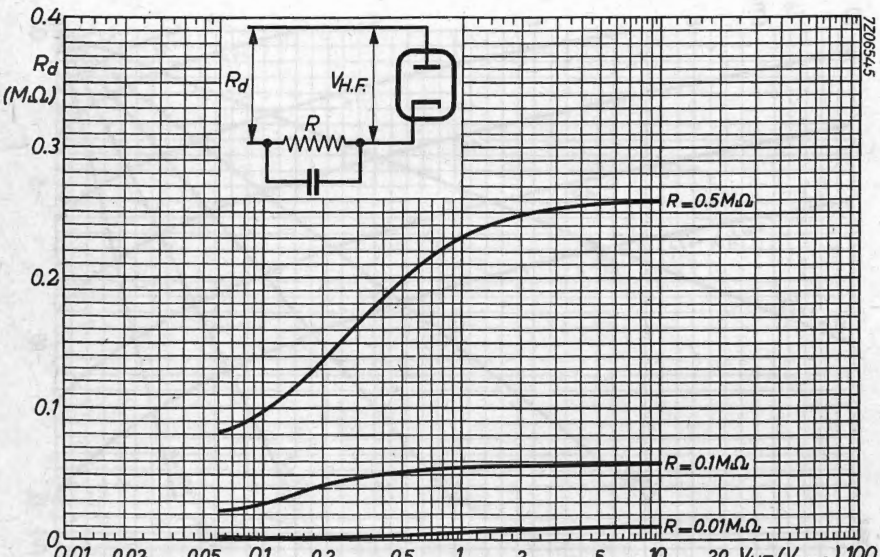
A.C. supply voltage	V_{tr}	max.	150	V_{RMS}
D.C. current	I_o	max.	9	mA
Input capacitor of smoothing filter	C_{filt}	max.	8	μF
Protecting resistance	R_t	min.	300	Ω
Cathode to heater voltage, peak (k pos)	V_{kf_p} (k pos)	max.	330	V
D.C. component		max.	200	V
A.C. component		max.	165	V_{RMS}




7Z06544
EAA91/EB91 18-11-'58
I_d (mA)
V_d (V)
10
8
6
4
2
0
0
-20
-40
-60
5V
10V
15V
20V
25V
30V
V_i = 35 V_{rms}
R=3kΩ
5 kΩ
10kΩ
20kΩ
30 Ω
50kΩ
100kΩ


7Z06543
I_d (mA)
V_d (V)
10
8
6
4
2
0
0
-5
-10
-15
0V
1V
2V
4V
6V
8V
V_i = 10V_{rms}
R=1kΩ
2kΩ
3kΩ
5kΩ
10kΩ


100
V=
(V)
10
1
0.1
0.01
0.1
1
10
100
$V_{H.F.}(V_{rms})$
R=0.5MΩ
10kΩ
5kΩ
2kΩ
$V_{H.F.}$
R
V=
7Z06546


0.4
R_d
(MΩ)
0.3
0.2
0.1
0
0.01
0.02
0.05
0.1
0.2
0.5
1
2
5
10
20
$V_{HF}(V_{rms})$
100
R_d
$V_{H.F.}$
R
R=0.5MΩ
R=0.1MΩ
R=0.01MΩ
7Z06545

TRIPLE DIODE-TRIODE

Triple diode-triode intended for F.M. and A.M. signal detection and A.F. signal amplification.

QUICK REFERENCE DATA			
Triode section			
Anode current	I_a	0.8	mA
Transconductance	S	1.45	mA/V
Amplification factor	μ	70	-

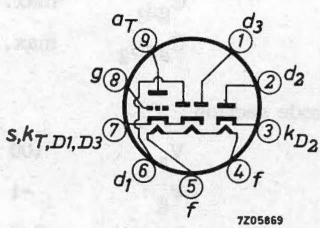
HEATING: Indirect by A.C. or D.C.; parallel supply

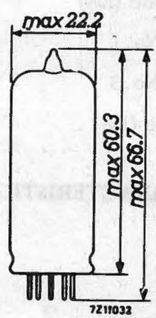
Heater voltage	V_f	6.3	V
Heater current	I_f	480	mA

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





CAPACITANCES

Triode section

Grid to all except anode	$C_{g(a)}$		1.9	pF
Anode to all except grid	$C_{a(g)}$		1.4	pF
Anode to grid	C_{ag}		2.0	pF
Grid to heater	C_{gf}	max.	0.04	pF

Diode sections

Diode No.1 to all	C_{d_1}		0.8	pF
Diode No.2 to all	C_{d_2}		4.8	pF
Diode No.3 to all	C_{d_3}		4.8	pF
Cathode (D_2) to all	C_{kD_2}		4.9	pF
Diode No.1 to heater	C_{d_1f}	max.	0.25	pF
Diode No.3 to heater	C_{d_3f}	max.	0.2	pF
Cathode (D_2) to heater	C_{kD_2f}		2.5	pF

Between triode and diode sections

Anode to diode No.1	C_{ad_1}	max.	0.12	pF
Anode to diode No.3	C_{ad_3}	max.	0.1	pF
Anode to cathode (D_2)	C_{akD_2}	max.	0.01	pF
Grid to diode No.1	C_{gd_1}	max.	0.07	pF
Grid to diode No.3	C_{gd_3}	max.	0.02	pF
Grid to cathode (D_2)	C_{gkD_2}	max.	0.005	pF

TYPICAL CHARACTERISTICS Triode section

Anode voltage	V_a	100	250	V
Grid voltage	V_g	-1	-3	V
Anode current	I_a	0.8	1.0	mA
Transconductance	S	1.45	1.4	mA/V
Amplification factor	μ	70	70	-
Internal resistance	R_i	48	50	kΩ

OPERATING CHARACTERISTICS

Triode section as RC coupled A.F. amplifier

Grid resistor R_g = 10 MΩ

Supply voltage	V_b	250	250	250	200	200	200	V
Anode resistor	R_a	220	100	47	220	100	47	kΩ
Grid resistor next stage	R_g'	0.68	0.33	0.15	0.68	0.33	0.15	MΩ
Anode current	I_a	0.76	1.40	2.20	0.56	1.00	1.60	mA
Voltage gain	V_o/V_i	54	47	36	53	44	34	-
Distortion:								
at output voltage $V_o = 3\ V_{RMS}$	d_{tot}	0.2	0.25	0.3	0.3	0.4	0.5	%
at output voltage $V_o = 5\ V_{RMS}$	d_{tot}	0.25	0.5	0.6	0.4	0.6	0.9	%
at output voltage $V_o = 8\ V_{RMS}$	d_{tot}	0.6	0.8	1.0	0.9	1.0	1.5	%

Supply voltage	V_b	170	170	170	100	100	100	V
Anode resistor	R_a	220	100	47	220	100	47	kΩ
Grid resistor next stage	R_g'	0.68	0.33	0.15	0.68	0.33	0.15	MΩ
Anode current	I_a	0.46	0.82	1.25	0.21	0.35	0.52	mA
Voltage gain	V_o/V_i	51	42	32	44	35	26	-
Distortion:								
at output voltage $V_o = 3\ V_{RMS}$	d_{tot}	0.4	0.5	0.6	1.0	1.3	2.0	%
at output voltage $V_o = 5\ V_{RMS}$	d_{tot}	0.5	0.8	1.1	1.7	2.3	4.3	%
at output voltage $V_o = 8\ V_{RMS}$	d_{tot}	1.1	1.3	2.0	–	–	–	%

TYPICAL CHARACTERISTICS Diode sections

Internal resistance diode No.1 Diode voltage V_{d_1} = +10 V	R_{iD_1}	5 kΩ
Internal resistance diode No.2 Diode voltage V_{d_2} = +5 V	R_{iD_2}	200 Ω
Internal resistance diode No.3 Diode voltage V_{d_3} = +5 V	R_{iD_3}	200 Ω
Ratio between R_{iD_2} and R_{iD_3}	R_{iD_2}/R_{iD_3}	min. 0.67 max. 1.5

MICROPHONY Triode section

No special precautions against microphony are required in circuits where the input voltage is min. 10 mV for 50 mW output of the output tube at frequencies higher than 800 Hz. At lower frequencies the sensitivity may be increased according to figure 1.

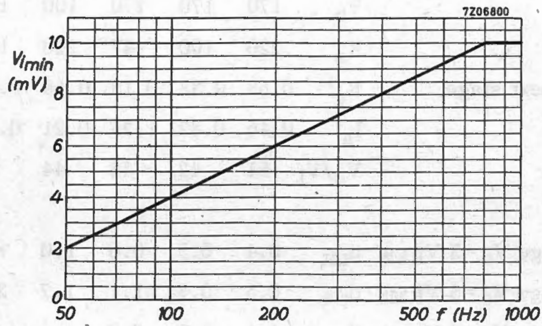


fig.1

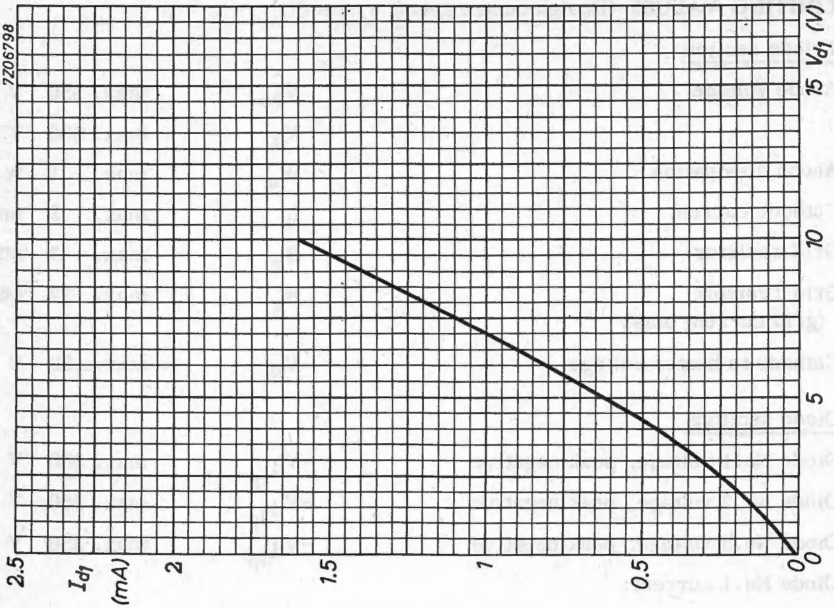
LIMITING VALUES (Design centre rating system)

Triode section

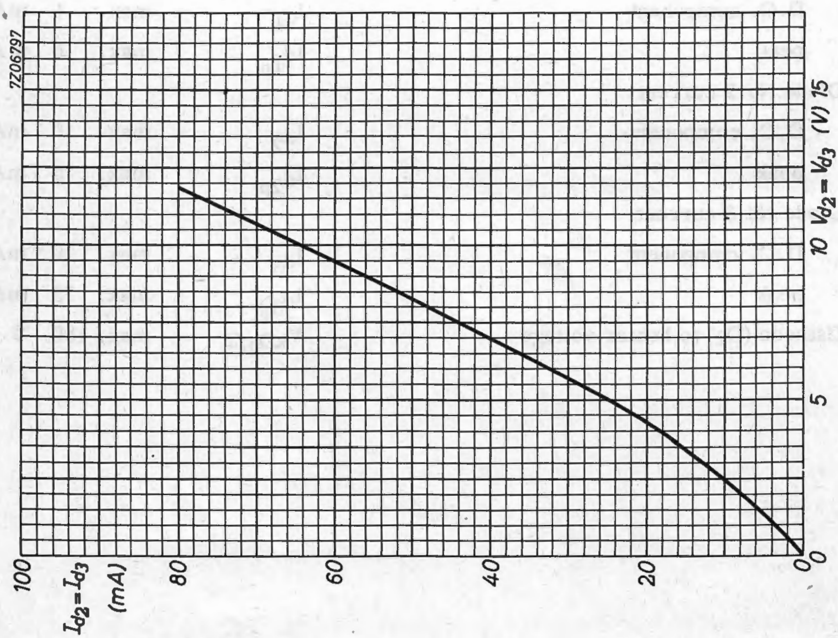
Anode voltage	V_{a_0}	max. 550	V
	V_a	max. 300	V
Anode dissipation	W_a	max. 1	W
Cathode current	I_k	max. 5	mA
Grid resistor	R_g	max. 3	MΩ
Grid resistor (grid current bias)	R_g	max. 22	MΩ
Cathode to heater voltage	V_{kf}	max. 150	V

Diode sections

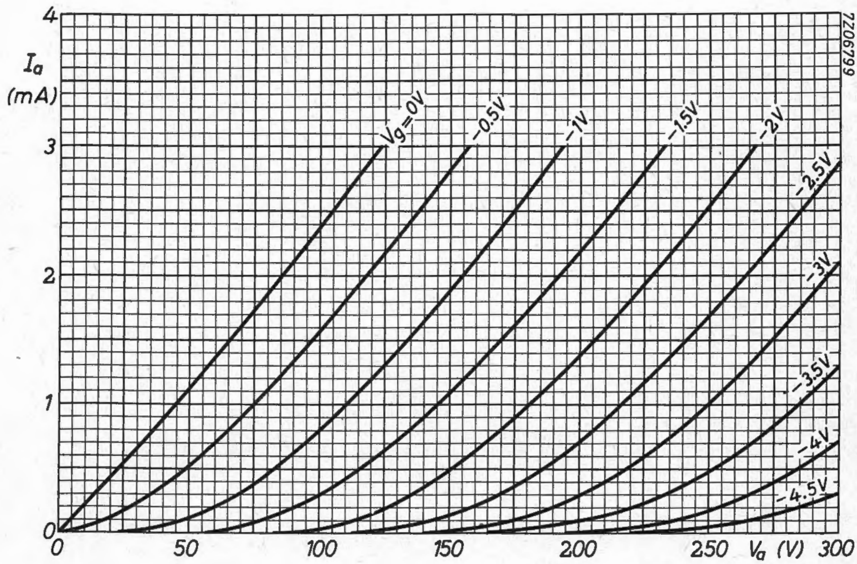
Diode No.1 voltage, peak negative	$-V_{d_{1p}}$	max. 350	V
Diode No.2 voltage, peak negative	$-V_{d_{2p}}$	max. 350	V
Diode No.3 voltage, peak negative	$-V_{d_{3p}}$	max. 350	V
Diode No.1 current:			
D.C. component	I_{d_1}	max. 1	mA
peak	$I_{d_{1p}}$	max. 6	mA
Diode No.2 current:			
D.C. component	I_{d_2}	max. 10	mA
peak	$I_{d_{2p}}$	max. 75	mA
Diode No.3 current:			
D.C. component	I_{d_3}	max. 10	mA
peak	$I_{d_{3p}}$	max. 75	mA
Cathode (D_2) to heater voltage	$V_{kD_2/f}$	max. 150	V



7Z06798
I_{d1} (mA)
2.5
2
1.5
1
0.5
0
0
5
10
15 V_{d1} (V)



7Z06797
$I_{d2} = I_{d3}$ (mA)
100
80
60
40
20
0
0
5
10
$V_{d2} = V_{d3}$ (V) 15


4
I_a
(mA)
3
2
1
0
V_g=0V
−0.5V
−1V
−1.5V
−2V
−2.5V
−3V
−3.5V
−4V
−4.5V
0
50
100
150
200
250
V_a (V)
300
7Z06799

DIODE-PENTODE

Diode-pentode. Pentode intended for use as R.F., I.F. or A.F. amplifier.

QUICK REFERENCE DATA			
Pentode section			
Variable transconductance			
Anode current	I_a	5	mA
Transconductance	S	2	mA/V
Amplification factor	$\mu_{g_2g_1}$	16	-

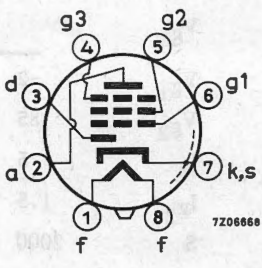
HEATING: Indirect by A.C. or D.C.; parallel supply

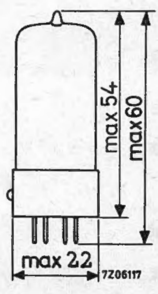
Heater voltage	V_f	6.3	V
Heater current	I_f	200	mA

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Rimlock





CAPACITANCES

Pentode section

Anode to all except grid No.1	$C_{a(g_1)}$		5.2	pF
Grid No.1 to all except anode	$C_{g_1(a)}$		4.1	pF
Anode to grid No.1	C_{ag_1}	max.	0.002	pF
Grid No.1 to heater	C_{g_1f}	max.	0.05	pF

Diode section

Diode to all	C_d		3.3	pF
Diode to heater	C_{df}	max.	0.02	pF

Between diode and pentode sections

Diode to grid No.1	C_{dg_1}	max.	0.0015	pF
Diode to anode	C_{da}	max.	0.15	pF

OPERATING CHARACTERISTICS

Pentode as R.F. or I.F. amplifier

Supply voltage	V_b	250		V
Anode resistor	R_a	0		Ω
Grid No.2 resistor	R_{g_2}	110		kΩ
Cathode resistor	R_k	310		Ω
Grid No.3 voltage	V_{g_3}	0		V
Grid No.1 voltage	V_{g_1}	−2	−43	V
Grid No.2 voltage	V_{g_2}	85	–	V
Anode current	I_a	5	–	mA
Grid No.2 current	I_{g_2}	1.5	–	mA
Transconductance	S	2000	20	μA/V
Internal resistance	R_i	1.4	min.10	MΩ
Amplification factor	$\mu_{g_2g_1}$	16	–	-
Equivalent noise resistance	R_{eq}	7.5	–	kΩ

OPERATING CHARACTERISTICS (continued)

Pentode as resistance coupled A.F. amplifier. Circuit fig.1

Supply voltage	V_b	250	250	250	250	250	V
Anode resistor	R_a	0.22	0.22	0.22	0.22	0.22	MΩ
Grid No.2 resistor	R_{g_2}	0.82	0.82	0.82	0.82	0.82	MΩ
Cathode resistor	R_k	1.5	1.5	1.5	1.5	1.5	kΩ
Grid No.1 supply voltage	V_R	0	−5	−10	−15	−20	V
Anode current	I_a	0.8	0.65	0.52	0.41	0.31	mA
Grid No.2 current	I_{g_2}	0.26	0.20	0.17	0.14	0.11	mA
Voltage gain	V_o/V_i	120	40	23	16	11	-
Distortion:							
at output voltage V_o = 3 V_{RMS}	d_{tot}	0.9	1.3	1.3	1.5	1.8	%
at output voltage V_o = 5 V_{RMS}	d_{tot}	1.0	1.5	1.6	2.0	2.7	%
at output voltage V_o = 8 V_{RMS}	d_{tot}	1.2	2.5	2.7	3.2	5.5	%

Supply voltage	V_b	250	250	250	250	250	V
Anode resistor	R_a	0.1	0.1	0.1	0.1	0.1	MΩ
Grid No.2 resistor	R_{g_2}	0.39	0.39	0.39	0.39	0.39	MΩ
Cathode resistor	R_k	680	680	680	680	680	Ω
Grid No.1 supply voltage	V_R	0	−5	−10	−15	−20	V
Anode current	I_a	1.52	1.2	0.94	0.7	0.52	mA
Grid No.2 current	I_{g_2}	0.53	0.4	0.3	0.23	0.17	mA
Voltage gain	V_o/V_i	100	35	20	13	9	-
Distortion:							
at output voltage V_o = 3 V_{RMS}	d_{tot}	0.8	1.0	1.2	1.4	1.8	%
at output voltage V_o = 5 V_{RMS}	d_{tot}	0.9	1.4	2.0	2.3	3.0	%
at output voltage V_o = 8 V_{RMS}	d_{tot}	1.0	2.4	3.2	3.7	6.0	%

MICROPHONY

No special precautions against microphony are required in circuits where the input voltage is min. 10 mV for 50 mW output of the output tube.

LIMITING VALUES (Design centre rating system)

Pentode section

Anode voltage	V_{a_o}	max. 550 V
	V_a	max. 300 V
Anode dissipation	W_a	max. 2 W
Grid No.2 voltage	V_{g_2}	max. 550 V
Grid No.2 voltage at anode current I_a = max. 2.5 mA	V_{g_2}	max. 300 V
Grid No.2 voltage at anode current I_a = 5 mA	V_{g_2}	max. 125 V
Grid No.2 dissipation	W_{g_2}	max. 0.3 W
Cathode current	I_k	max. 10 mA
Grid No.1 resistor	R_{g_1}	max. 3 MΩ
Grid No.3 resistor	R_{g_3}	max. 3 MΩ
Cathode to heater voltage	V_{kf}	max. 100 V

Diode section

Diode voltage, negative peak	$-V_{dp}$	max. 350 V
Diode current	I_d	max. 0.8 mA
Diode current, peak	I_{dp}	max. 5 mA
Cathode to heater voltage	V_{kf}	max. 100 V

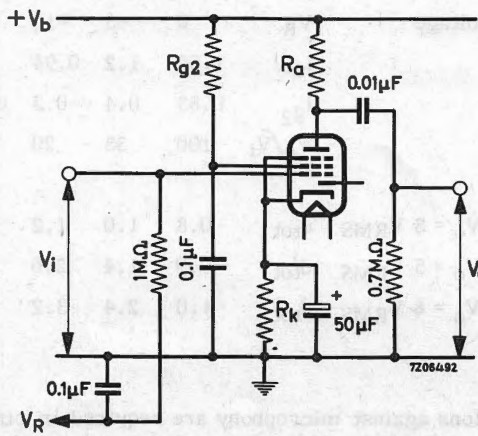


fig. 1

DOUBLE DIODE

Double diode with separate cathodes.

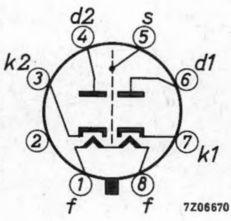
QUICK REFERENCE DATA			
A.C. supply voltage	V_{tr}	150	V_{RMS}
D.C. current per system	I_o	9	mA

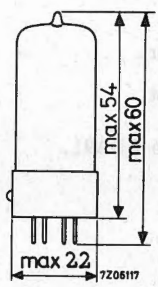
HEATING: Indirect by A.C. or D.C.; series or parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	300	mA

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Rimlock





CAPACITANCES

Diode No.1 to all	C_{d_1}	3.6	pF
Diode No.2 to all	C_{d_2}	3.6	pF
Diode No.1 to diode No.2	$C_{d_1d_2}$	max. 0.03	pF
Cathode No.1 to all	C_{k_1}	4.5	pF
Cathode No.2 to all	C_{k_2}	4.5	pF

LIMITING VALUES (Design centre rating system)(Each system)

Diode voltage, negative peak	$-V_{d_p}$	max.	420	V
Diode current	I_d	max.	9	mA
Diode current, peak	I_{d_p}	max.	54	mA
Cathode to heater voltage, peak (k neg)	V_{kf_p}	max.	150	V
Cathode to heater voltage:				
peak (k pos)	V_{kf_p}	max.	330	V
D.C. component		max.	200	V
A.C. component		max.	165	V_{RMS}

As half wave rectifier (each system)

A.C. supply voltage	V_{tr}	max.	150	V_{RMS}
D.C. current	I_o	max.	9	mA
Input capacitor of smoothing filter	C_{filt}	max.	8	μF
Protecting resistance	R_t	min.	300	Ω
Cathode to heater voltage:				
peak	V_{kf_p}	max.	330	V
D.C. component		max.	200	V
A.C. component		max.	165	V_{RMS}

For curves refer to EAA91.

DOUBLE DIODE

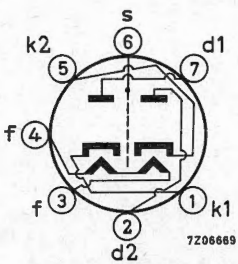
Double diode with separate cathodes.

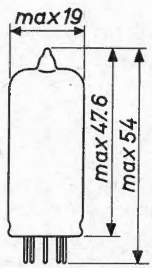
HEATING: Indirect by A.C. or D.C.; series or parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	300	mA

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Miniature





For further data
please refer to type EAA91

DOUBLE DIODE-TRIODE

Double diode-triode. Triode intended for use as A.F. amplifier.

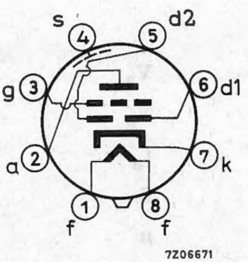
QUICK REFERENCE DATA			
Triode section			
Anode current	I_a	1.0	mA
Transconductance	S	1.2	mA/V
Amplification factor	μ	70	-

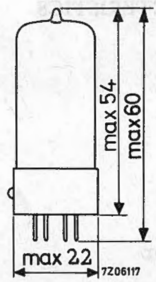
HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	230	mA

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Rimlock





CAPACITANCES

Triode section

Grid to all except anode	$C_{g(a)}$		2.7	pF
Anode to all except grid	$C_{a(g)}$		1.7	pF
Anode to grid	C_{ag}		1.5	pF
Grid to heater	C_{gf}	max.	0.05	pF

Diode sections

Diode No.1 to all	C_{d_1}		0.8	pF
Diode No.2 to all	C_{d_2}		0.7	pF
Diode No.1 to diode No.2	$C_{d_1d_2}$	max.	0.3	pF
Diode No.1 to heater	C_{d_1f}	max.	0.1	pF
Diode No.2 to heater	C_{d_2f}	max.	0.05	pF

Between triode and diode sections

Diode No.1 to grid	C_{d_1g}	max.	0.007	pF
Diode No.2 to grid	C_{d_2g}	max.	0.03	pF
Diode No.1 to anode	C_{d_1a}	max.	0.01	pF
Diode No.2 to anode	C_{d_2a}	max.	0.01	pF

TYPICAL CHARACTERISTICS

Triode section

Anode voltage	V_a		250	V
Grid voltage	V_g		-3	V
Anode current	I_a		1.0	mA
Transconductance	S		1.2	mA/V
Amplification factor	μ		70	-
Internal resistance	R_i		58	kΩ
Equivalent noise resistance (A.F.)	R_{eq}	max.	150	kΩ

OPERATING CHARACTERISTICS

Triode section as A.F. amplifier, circuit fig.1

Supply voltage	V_b	250	250	250	250	V
Anode resistor	R_a	0.22	0.1	0.22	0.1	MΩ
Cathode resistor	R_k	1.8	1.2	0	0	kΩ
Grid resistor	R_g	1	1	22	22	MΩ
Grid resistor next stage	$R_{g'}$	0.68	0.33	0.68	0.33	MΩ
Anode current	I_a	0.70	1.15	0.76	1.40	mA
Voltage gain	V_o/V_i	51	43	52	44	-
Distortion:						
at output voltage V_o = 5 V_{RMS}	d_{tot}	0.55	0.6	0.5	0.7	%
at output voltage V_o = 10 V_{RMS}	d_{tot}	0.9	1.1	0.8	0.9	%

MICROPHONY

No special precautions against microphony are required in circuits where the input voltage is min. 10 mV for 50 mW output of the output tube.

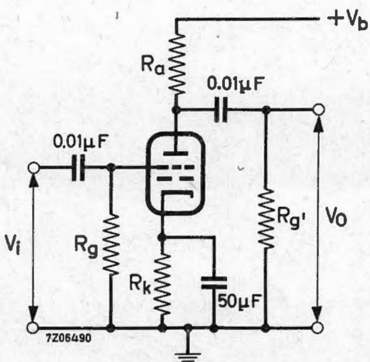


fig.1

LIMITING VALUES (Design centre rating system)

Triode section

Anode voltage	V_{a_o}	max. 550	V
	V_a	max. 300	V
Anode dissipation	W_a	max. 0.5	W
Cathode current	I_k	max. 5	mA
Grid resistor	R_g	max. 3	MΩ

Diode sections (Each diode)

Diode voltage, negative peak	$-V_{d_p}$	max. 350	V
Diode current,			
average	I_d	max. 0.8	mA
peak	I_{d_p}	max. 5	mA
Cathode to heater voltage	V_{kf}	max. 100	V

For curves refer to type EBC81.

DOUBLE DIODE-TRIODE

Double diode-triode. Triode intended for use as A.F. amplifier.

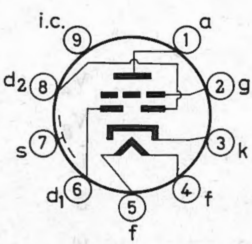
QUICK REFERENCE DATA			
<u>Triode section</u>			
Anode current	I_a	1.0	mA
Transconductance	S	1.2	mA/V
Amplification factor	μ	70	-

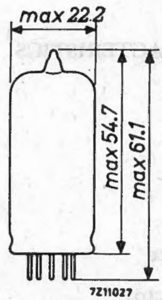
HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	230	mA

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Noval





CAPACITANCES

Triode section

Grid to all except anode	$C_{g(a)}$	2.3 pF
Anode to all except grid	$C_{a(g)}$	2.3 pF
Anode to grid	C_{ag}	1.2 pF
Grid to heater	C_{gf}	max. 0.05 pF

Diode sections

Diode No. 1 to all	C_{d_1}	0.9 pF
Diode No. 2 to all	C_{d_2}	0.9 pF
Diode No. 1 to diode No. 2	$C_{d_1d_2}$	max. 0.2 pF
Diode No. 1 to heater	C_{d_1f}	max. 0.25 pF
Diode No. 2 to heater	C_{d_2f}	max. 0.05 pF

Between diode and triode sections

Diode No. 1 to grid	C_{d_1g}	max. 0.007 pF
Diode No. 2 to grid	C_{d_2g}	max. 0.007 pF
Diode No. 1 to anode	C_{d_1a}	max. 0.005 pF
Diode No. 2 to anode	C_{d_2a}	max. 0.010 pF

TYPICAL CHARACTERISTICS

Triode section

Anode voltage	V_a	250	V
Grid voltage	V_g	-3	V
Anode current	I_a	1.0	mA
Transconductance	S	1.2	mA/V
Amplification factor	μ	70	–
Internal resistance	R_i	58	kΩ
Equivalent noise resistance (A.F.)	R_{eq}	max. 150	kΩ

OPERATING CHARACTERISTICS

Triode section as A.F. amplifier, circuit Fig.1

Supply voltage	V_b	250	250	250	250	V
Anode resistor	R_a	0.22	0.1	0.22	0.1	MΩ
Cathode resistor	R_k	1.8	1.2	0	0	kΩ
Grid resistor	R_g	1	1	22	22	MΩ
Grid resistor next stage	$R_{g'}$	0.68	0.33	0.68	0.33	MΩ
Anode current	I_a	0.70	1.15	0.76	1.40	mA
Voltage gain	V_o/V_i	51	43	52	44	-
Distortion:						
at output voltage V_o = 5 V_{RMS}	d_{tot}	0.55	0.6	0.5	0.7	%
at output voltage V_o = 10 V_{RMS}	d_{tot}	0.9	1.1	0.8	0.9	%

Microphony

No special precautions against microphony are required in circuits where the input voltage is min. 10 mV for 50 mW output of the output tube.

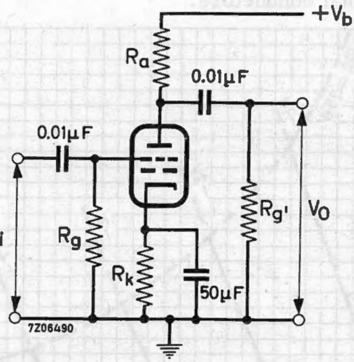


fig.1

LIMITING VALUES (Design centre rating system)

Triode section

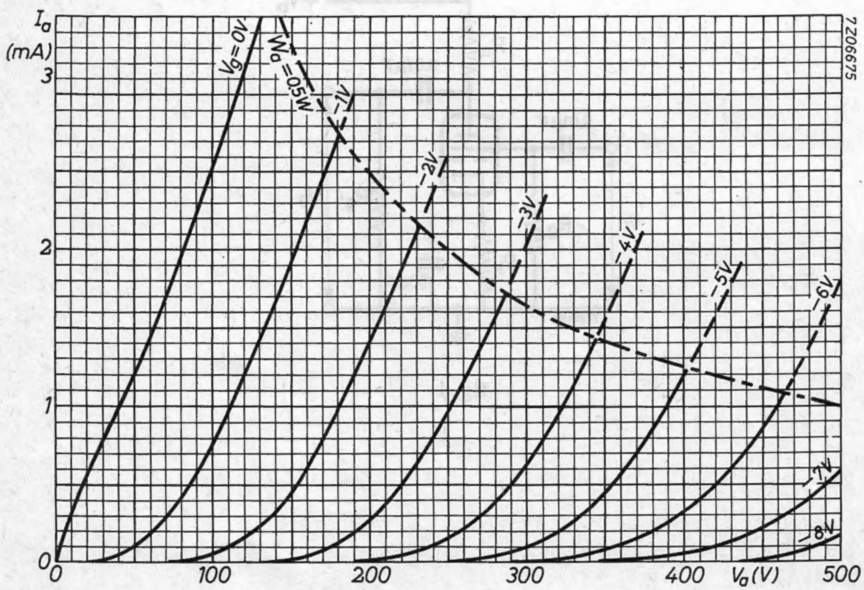
Anode voltage	V_{a_o}	max. 550 V
	V_a	max. 300 V
Anode dissipation	W_a	max. 0.5 W
Cathode current	I_k	max. 5 mA
Grid resistor	R_g	max. 3 MΩ
Cathode to heater voltage	V_{kf}	max. 100 V

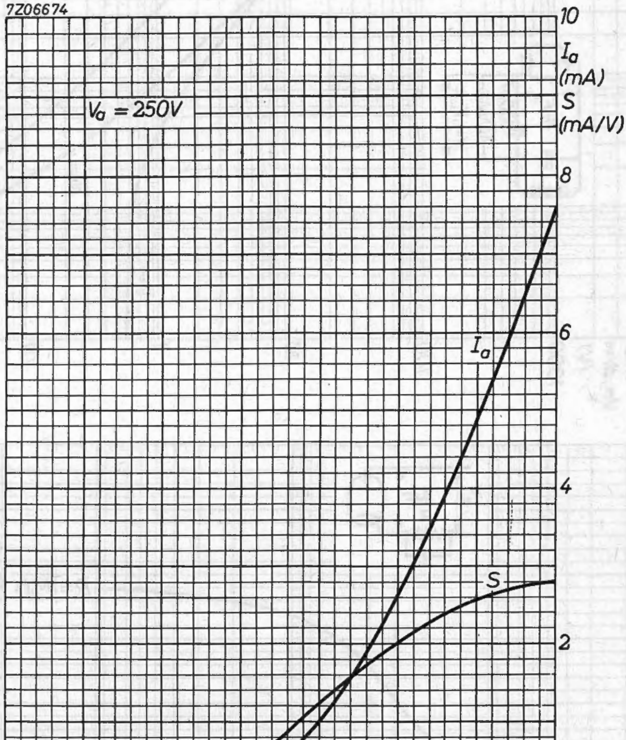
Diode sections (each diode)

Diode voltage, negative peak	$-V_{d_p}$	max. 350 V
Diode current, average	I_d	max. 0.8 mA
peak	I_{d_p}	max. 5 mA
Cathode to heater voltage	V_{kf}	max. 100 V

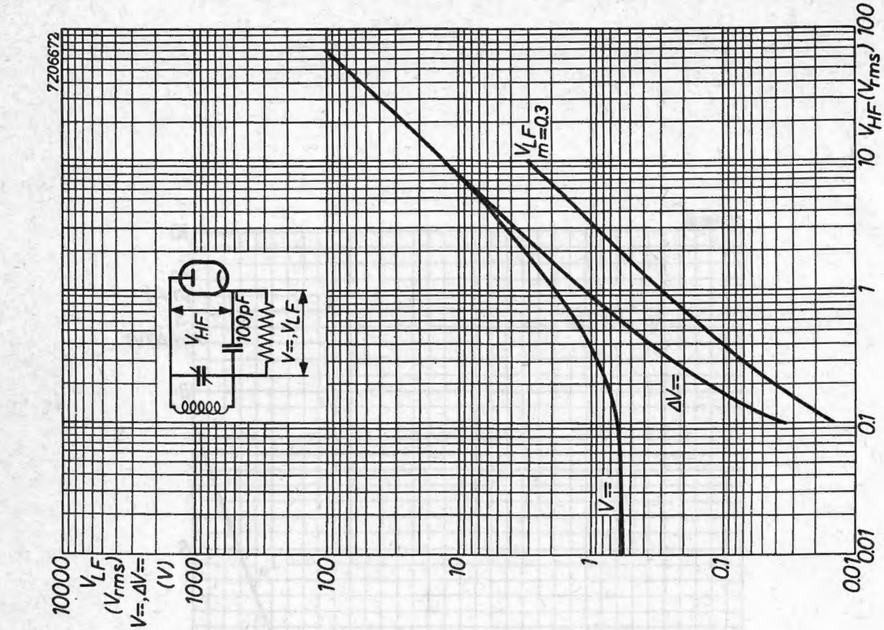
Note

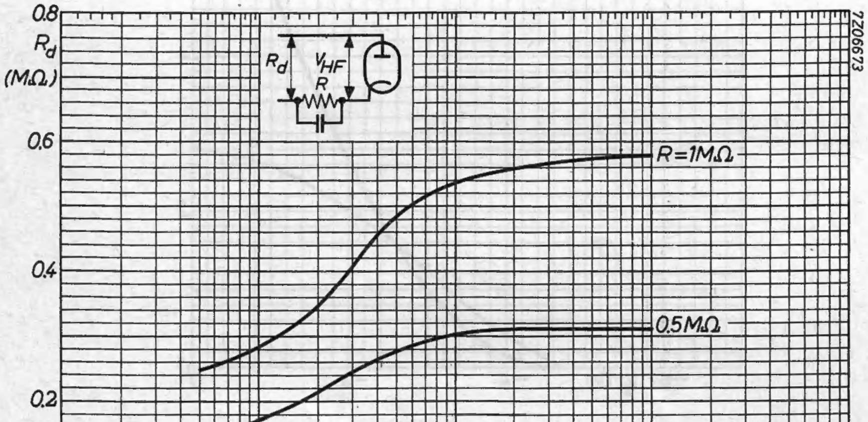
The use of a socket with skirt is advisable to reduce the capacitances between tube elements and external conductors.





7Z06674
$V_a = 250V$
10
I_a
(mA)
S
(mA/V)
8
6
I_a
4
S
2
0
−6
V_g (V)
−4
−2
0


7206672
V_{LF} m=0.3
V_{HF} (V_{rms})
100
10
1
0.1
0.01
ΔV=
V=
V_{HF}
100pF
V=, V_{LF}
10000
V_{LF} (V_{rms})
V=, ΔV= (V)
1000
100
10
1
0.1
0.01


7206673
R_d (MΩ)
0.8
0.6
0.4
0.2
0
R_d
V_{HF}
R
R=1MΩ
0.5MΩ
0.2MΩ
0.01
0.1
1
10
100
V_{HF} (V_{rms})

DOUBLE DIODE-PENTODE

Double diode-pentode. Pentode intended for use as R.F., I.F., or A.F. amplifier.

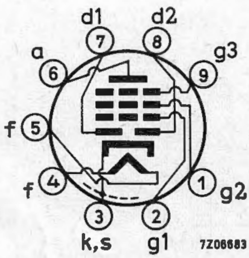
QUICK REFERENCE DATA			
Pentode section			
Variable transconductance			
Anode current	I_a	5	mA
Transconductance	S	2.2	mA/V
Amplification	$\mu_{g_2 g_1}$	18	-

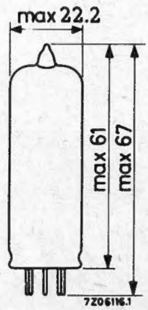
HEATING: Indirect by A.C. or D.C.; parallel or series supply.

Heater voltage	V_f	6.3	V
Heater current	I_f	300	mA

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Noval





CAPACITANCES

Pentode section

Anode to all except grid No.1	$C_{a(g_1)}$		4.9	pF
Grid No.1 to all except anode	$C_{g_1(a)}$		4.2	pF
Anode to grid No.1	C_{ag_1}	max.	0.0025	pF
Grid No.1 to heater	C_{g_1f}	max.	0.07	pF

Diode section

Diode No.1 to all	C_{d_1}		2.2	pF
Diode No.2 to all	C_{d_2}		2.35	pF
Diode No.1 to diode No.2	$C_{d_1d_2}$	max.	0.35	pF
Diode No.1 to heater	C_{d_1f}	max.	0.02	pF
Diode No.2 to heater	C_{d_2f}	max.	0.005	pF

Between diode and pentode sections

Diode No.1 to grid No.1	$C_{d_1g_1}$	max.	0.0008	pF
Diode No.2 to grid No.1	$C_{d_2d_1}$	max.	0.001	pF
Diode No.1 to anode	C_{d_1a}	max.	0.2	pF
Diode No.2 to anode	C_{d_2a}	max.	0.05	pF

OPERATING CHARACTERISTICS

Pentode section as R.F. or I.F. amplifier

Supply voltage	V_b	250		V
Anode resistor	R_a	0		Ω
Grid No.3 voltage	V_{g3}	0		V
Grid No.2 resistor	R_{g2}	95		kΩ
Cathode resistor	R_k	300		Ω
Grid No.1 voltage	V_g	−2	−41.5	V
Grid No.2 voltage	V_{g2}	85	250	V
Anode current	I_a	5	–	mA
Grid No.2 current	I_{g2}	1.75	–	mA
Transconductance	S	2200	22	μA/V
Internal resistance	R_i	1.4	min.10	MΩ
Amplification factor	μ_{g2g1}	18	–	–
Equivalent noise resistance	R_{eq}	6.8	–	kΩ

Pentode section as resistance coupled A.F. amplifier, circuit fig.1.

Supply voltage	V_b	250	250	250	250	V
Anode resistor	R_a	0.22	0.1	0.22	0.1	MΩ
Grid No.2 resistor	R_{g2}	0.82	0.39	1.0	0.47	MΩ
Grid No.1 resistor	R_{g1}	1	1	10	10	MΩ
Cathode resistor	R_k	1800	1000	0	0	Ω
Grid No.1 resistor next stage	$R_{g'}$	0.68	0.33	0.68	0.33	MΩ
Anode current	I_a	0.75	1.5	0.75	1.5	mA
Grid No.2 current	I_{g2}	0.30	0.53	0.25	0.50	mA
Voltage gain	V_o/V_i	110	80	160	110	–
Distortion:						
at output voltage V_o = 3 V_{RMS}	d_{tot}	0.8	0.9	0.8	0.8	%
at output voltage V_o = 5 V_{RMS}	d_{tot}	1.3	1.5	1.4	1.4	%
at output voltage V_o = 8 V_{RMS}	d_{tot}	2.0	2.2	2.1	2.1	%

OPERATING CHARACTERISTICS (continued)

Pentode section, triode connected (g_2 connected to anode) as resistance coupled A.F. amplifier.

Supply voltage	V_b	250	250	250	250	V
Anode resistor	R_a	0.1	0.047	0.1	0.047	MΩ
Grid No.1 resistor	R_{g_1}	1	1	10	10	MΩ
Cathode resistor	R_k	820	560	0	0	Ω
Grid No.1 resistor next stage	$R_{g'}$	0.33	0.15	0.33	0.15	MΩ
Anode current	I_a	2.08	4.10	2.16	4.50	mA
Voltage gain	V_o/V_i	14	13	15	15	–
Distortion:						
at output voltage V_o = 3 V_{RMS}	d_{tot}	1.6	1.3	2.0	1.7	%
at output voltage V_o = 5 V_{RMS}	d_{tot}	2.5	2.0	3.1	2.7	%
at output voltage V_o = 8 V_{RMS}	d_{tot}	4.3	2.9	4.8	4.1	%

LIMITING VALUES (Design centre rating system)

Pentode section

Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	300	V
Anode dissipation	W_a	max.	1.5	W
Grid No.2 voltage	V_{g2_o}	max.	550	V
at anode current I_a = max. 2.5 mA	V_{g_2}	max.	300	V
at anode current I_a = 5 mA	V_{g_2}	max.	125	V
Grid No.2 dissipation	W_{g2}	max.	0.3	W
Cathode current	I_k	max.	10	mA
Grid resistor, automatic bias	R_{g_1}	max.	3	MΩ
Grid resistor, grid current bias	R_{g_1}	max.	22	MΩ
Cathode to heater voltage	V_{kf}	max.	100	V

Microphony

No special precautions against microphony are required in circuits where the input voltage is min. 25 mV for an output of 50 mW of the output tube.

LIMITING VALUES (continued)

Diode section

Diode No.1 voltage, negative peak	$-V_{d_p}$	max.	350	V
Diode No.2 voltage, negative peak	$-V_{d_p}$	max.	350	V
Diode No.1 current	I_{d_1}	max.	0.8	mA
Diode No.2 current	I_{d_2}	max.	0.8	mA
Diode No.1 current, peak	$I_{d_{1p}}$	max.	5	mA
Diode No.2 current, peak	$I_{d_{2p}}$	max.	5	mA
Cathode to heater voltage	V_{kf}	max.	100	V

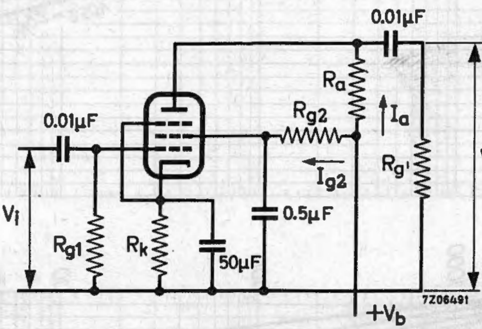
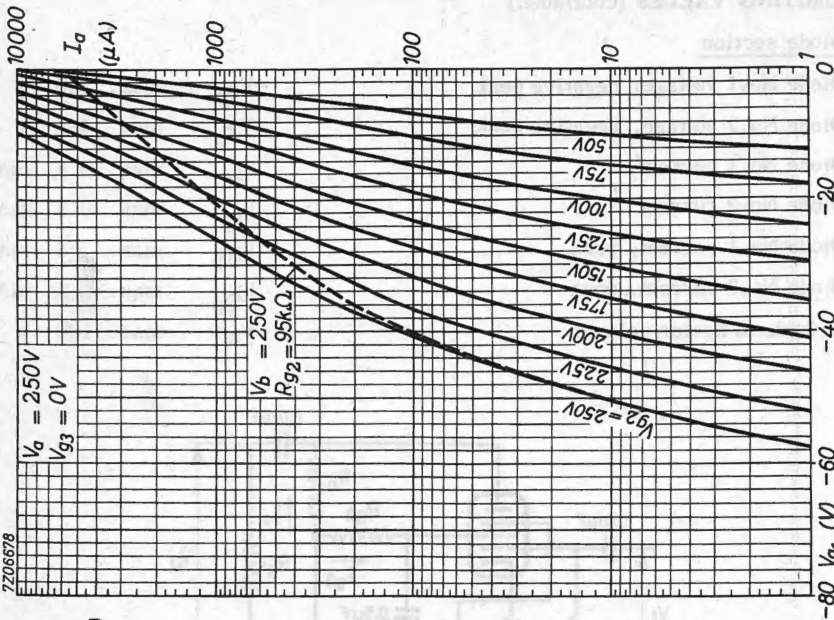
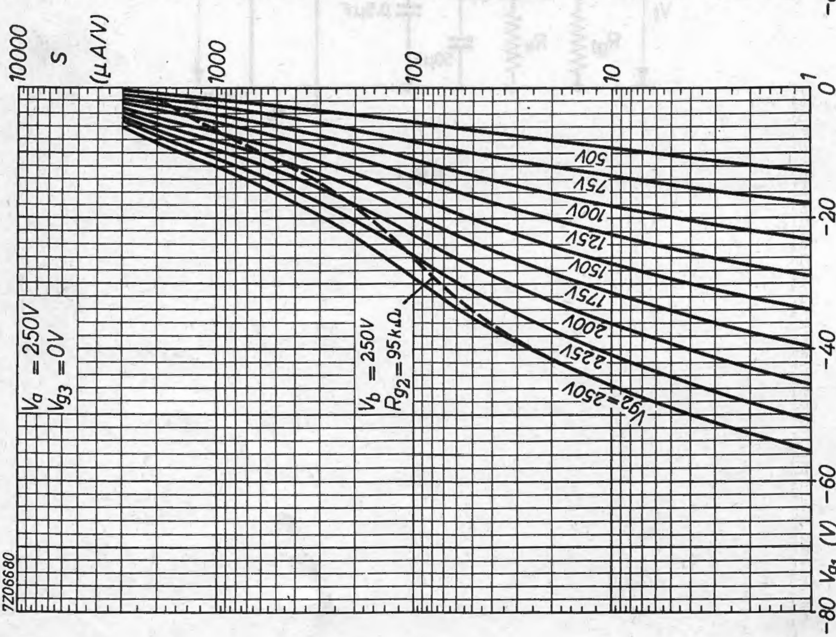
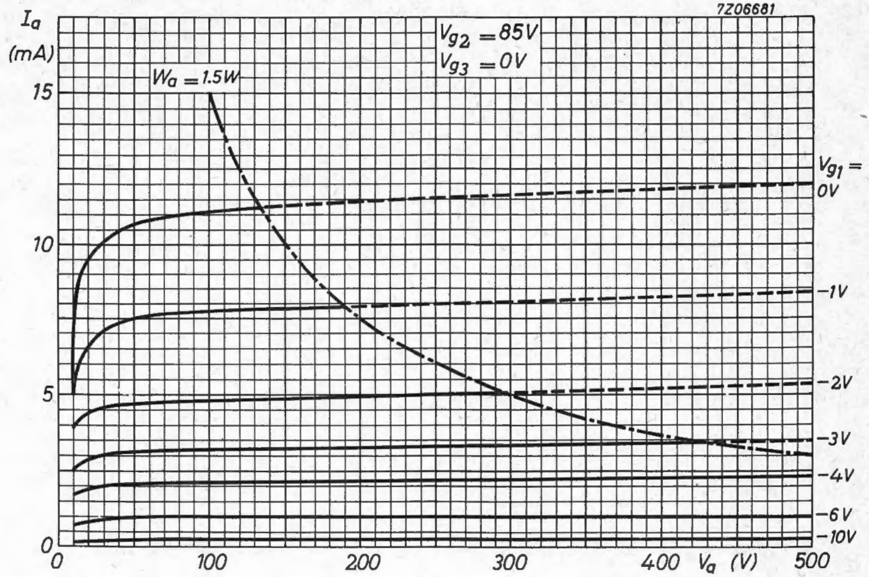
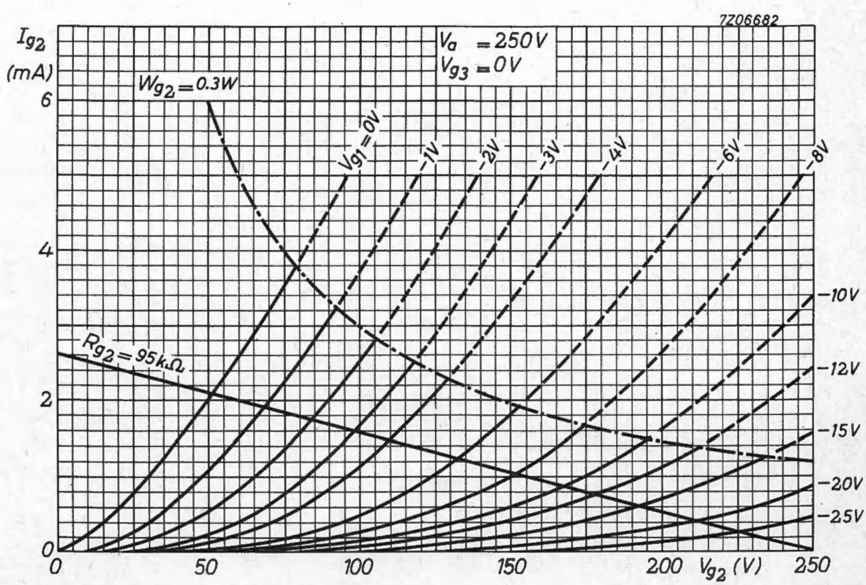


fig.1


7Z06678
I_a (μA)
10000
1000
100
10
1
V_a = 250V
V_{g3} = 0V
V_b = 250V
R_{g2} = 95kΩ
V_{g2} = 250V
225V
200V
175V
150V
125V
100V
75V
50V
0
−20
−40
−60
−80 V_{g1} (V)


7Z06680
S (μA/V)
10000
1000
100
10
1
V_a = 250V
V_{g3} = 0V
V_b = 250V
R_{g2} = 95kΩ
V_{g2} = 250V
225V
200V
175V
150V
125V
100V
75V
50V
0
−20
−40
−60
−80 V_{g1} (V)


7Z06681
I_a (mA)
$V_{g2} = 85V$
$V_{g3} = 0V$
$W_a = 1.5W$
$V_{g1} =$ 0V
-1V
-2V
-3V
-4V
-6V
-10V
V_a (V)
0
100
200
300
400
500
5
10
15


7Z06682
I_{g2} (mA)
$V_a = 250V$
$V_{g3} = 0V$
$W_{g2} = 0.3W$
$V_{g1} = 0V$
-1V
-2V
-3V
-4V
-6V
-8V
-10V
-12V
-15V
-20V
-25V
$R_{g2} = 95k\Omega$
V_{g2} (V)
0
50
100
150
200
250
2
4
6

DOUBLE DIODE – PENTODE

Double diode-pentode. Pentode intended for use as R.F. or I.F. amplifier.

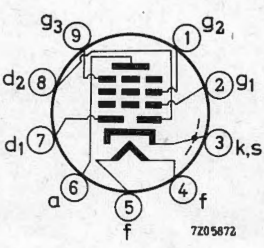
QUICK REFERENCE DATA			
Pentode section			
Variable transconductance			
Anode current	I_a	9	mA
Transconductance	S	4.5	mA/V
Amplification factor	$\mu_{g_2g_1}$	20	–

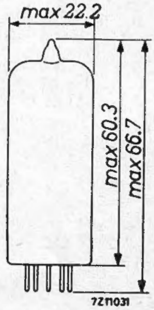
HEATING: Indirect by A.C. or D.C.; parallel or series supply

Heater voltage	V_f	6.3	V
Heater current	I_f	300	mA

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Noval





CAPACITANCES

Pentode section

Anode to all except grid No.1	$C_{a(g_1)}$		5.2 pF
Grid No.1 to all except anode	$C_{g_1(a)}$		5.0 pF
Anode to grid No.1	C_{ag_1}	max.	0.0025 pF
Grid No.1 to heater	C_{g_1f}	max.	0.05 pF

Diode sections

Diode No.1 to all	C_{d_1}		2.5 pF
Diode No.2 to all	C_{d_2}		2.5 pF
Diode No.1 to diode No.2	$C_{d_1d_2}$	max.	0.25 pF
Diode No.1 to heater	C_{d_1f}	max.	0.015 pF
Diode No.2 to heater	C_{d_2f}	max.	0.003 pF

Between diode and pentode sections

Diode No.1 to grid No.1	$C_{d_1g_1}$	max.	0.0008 pF
Diode No.2 to grid No.1	$C_{d_2g_1}$	max.	0.001 pF
Diode No.1 to anode	C_{d_1a}	max.	0.15 pF
Diode No.2 to anode	C_{d_2a}	max.	0.025 pF

TYPICAL CHARACTERISTICS

Pentode section

Anode voltage	V_a	250	250	200	170	V
Grid No. 2 voltage	V_{g_2}	100	80	100	100	V
Grid No. 3 voltage	V_{g_3}	0	0	0	0	V
Grid No. 1 voltage	V_{g_1}	-2	-1 [1]	-1.5	-1 [1]	V
Anode current	I_a	9	9	11	12	mA
Grid No. 2 current	I_{g_2}	2.7	2.7	3.3	4	mA
Transconductance	S	3.8	4.5	4.5	5	mA/V
Amplification factor	$\mu_{g_2g_1}$	20	20	20	20	–
Internal resistance	R_i	1.0	0.9	0.6	0.4	MΩ

OPERATING CHARACTERISTICS

Pentode section as R.F. or I.F. amplifier

Supply voltage	V_b	250		200		250		V
Anode resistor	R_a	0		0		0		Ω
Grid No. 3 voltage	V_{g_3}	0		0		0		V
Grid No. 2 resistor	R_{g_2}	56		30		62		kΩ
Grid No. 1 voltage	V_{g_1}	-2.0	-20	-1.5	-20	-1 [1]	-20	V
Anode current	I_a	9	-	11	-	9	-	mA
Grid No. 2 current	I_{g_2}	2.7	-	3.3	-	2.7	-	mA
Transconductance	S	3.8	0.2	4.5	0.12	4.5	0.2	mA/V
Internal resistance	R_i	1.0	-	0.6	-	0.9	-	MΩ

[1]) To avoid grid No. 1 current the negative grid No. 1 voltage should be min. 1.5 V.

LIMITING VALUES (Design centre rating system)

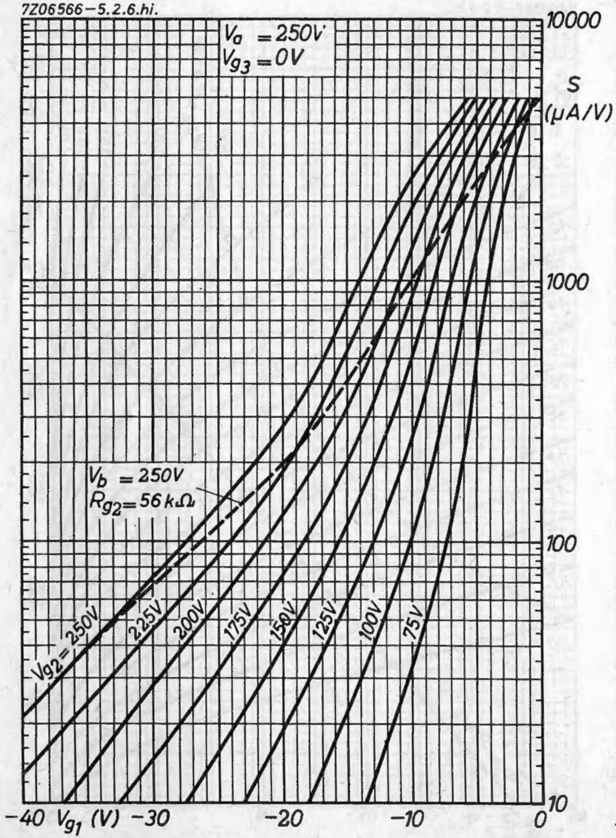
Pentode section

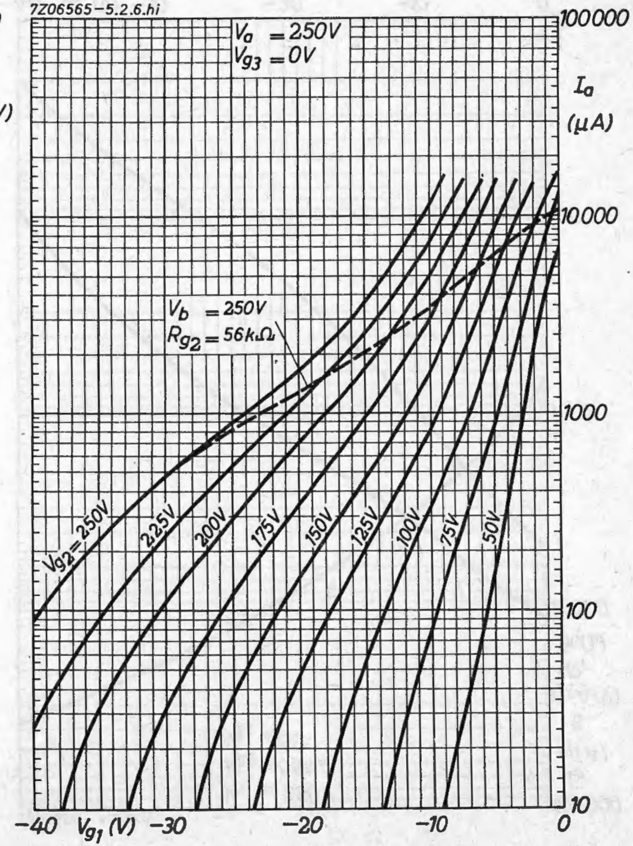
Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	300	V [1])
Anode dissipation	W_a	max.	2.25	W
Grid No. 2 voltage	$V_{g_{2o}}$	max.	550	V
Grid No. 2 voltage				
at anode current I_a max. 4 mA	V_{g_2}	max.	300	V [1])
at anode current I_a min. 8 mA	V_{g_2}	max.	125	V
Grid No. 2 dissipation	W_{g_2}	max.	0.45	W
Cathode current	I_k	max.	16.5	mA
Grid No. 1 resistor	R_{g_1}	max.	3	MΩ
Grid No. 3 resistor	R_{g_3}	max.	10	kΩ
Cathode to heater voltage	V_{kf}	max.	100	V

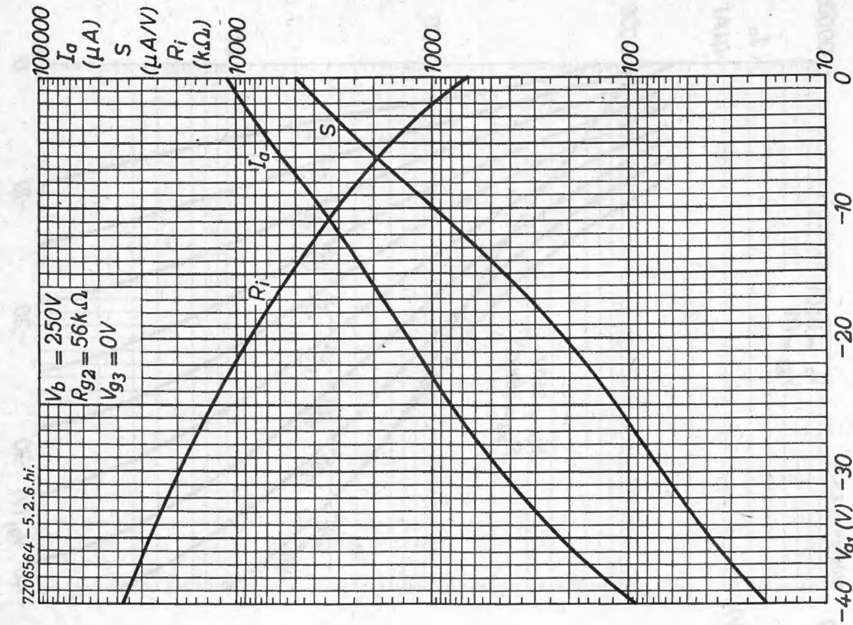
Diode sections (each diode)

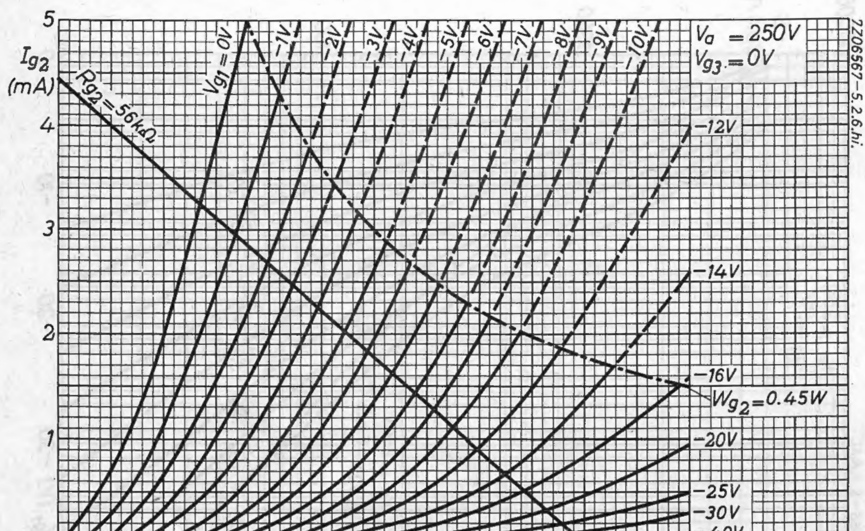
Diode voltage, negative peak	$-V_{d_p}$	max.	200	V
Diode current, average	I_d	max.	0.8	mA
peak	I_{d_p}	max.	5	mA
Cathode to heater voltage	V_{kf}	max.	100	V

[1]) With supply from a storage battery and vibrator the max. voltage is 250 V.


7Z06566-5.2.6.hi.
V_a = 250V
V_{g3} = 0V
S
(μA/V)
10000
1000
100
10
V_b = 250V
R_{g2} = 56 kΩ
V_{g2} = 250V
225V
200V
175V
150V
125V
100V
75V
−40 V_{g1} (V) −30
−20
−10
0


7Z06565-5.2.6.hi
V_a = 250V
V_{g3} = 0V
I_a
(μA)
100000
10000
1000
100
10
V_b = 250V
R_{g2} = 56 kΩ
V_{g2} = 250V
225V
200V
175V
150V
125V
100V
75V
50V
−40 V_{g1} (V) −30
−20
−10
0


7Z06564-5.2.6.hi.
$V_b = 250V$
$R_{g2} = 56k\Omega$
$V_{g3} = 0V$
I_a (μA)
S ($\mu A/V$)
R_i ($k\Omega$)
V_{g1} (V)


7Z06567-5.2.6.hi.
$V_a = 250V$
$V_{g3} = 0V$
I_{g2} (mA)
V_{g2} (V)
$R_{g2} = 56k\Omega$
$V_{g1} = 0V$
$W_{g2} = 0.45W$

U.H.F. TRIODE

Triode intended for use as grounded grid U.H.F. amplifier, oscillator or mixer for bands IV and V.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	200	mA

LIMITING VALUES (Design centre rating system)

Cathode to heater voltage, (k pos)	$V_{kf\ (k\ pos)}$	max.	100	V
(k neg)	$V_{kf\ (k\ neg)}$	max.	50	V

For further data and curves of this type please refer to PC86

U.H.F. TRIODE

Triode intended for use as grounded grid U.H.F. amplifier for bands IV and V.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	165	mA

For further data and curves of this type please refer to PC88

R.F. TRIODE

Triode intended for use as oscillator, mixer or amplifier in F.M.- and television receivers.

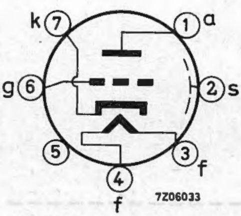
QUICK REFERENCE DATA			
Anode current	I_a	10	mA
Transconductance	S	5.5	mA/V
Amplification factor	μ	60	

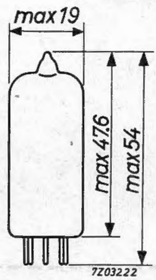
HEATING: Indirect by A.C. or D.C.; series or parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	150	mA

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Miniature





CAPACITANCES

Grid to all except anode	$C_{g(a)}$	2.6	pF
Anode to all except grid	$C_{a(g)}$	0.55	pF
Anode to grid	C_{ag}	1.6	pF
Anode to cathode	C_{ak}	0.24	pF
Cathode to heater	C_{kf}	2.2	pF
Grid to heater	C_{gf}	max. 0.15	pF
Anode to grid + heater	$C_{a/gf}$	1.8	pF
Cathode to grid + heater	$C_{k/gf}$	4.5	pF

TYPICAL CHARACTERISTICS AND OPERATING CONDITIONS

Anode voltage	V_a	100	170	200	250	V
Grid voltage	V_g	−1.0	−1.0	−1.0	−2.0	V
Anode current	I_a	3.0	8.5	11.5	10	mA
Transconductance	S	3.75	5.9	6.7	5.5	mA/V
Amplification factor	μ	62	66	70	60	
Internal resistance	R_i	16.5	11	10.5	11	kΩ

LIMITING VALUES (Design centre rating system)

Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	300	V
Anode dissipation	W_a	max.	2.5	W
Cathode current	I_k	max.	15	mA
Grid voltage	$-V_g$	max.	50	V
Grid resistor (automatic bias)	R_g	max.	1	MΩ
Cathode to heater voltage	V_{kf}	max.	100	V

For curves please refer to type ECC81

V.H.F. TRIODE

Triode intended for use as R.F. amplifier in V.H.F. television tuners.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	180	mA

For further data and curves of this type please refer to type PC900

A.F. DOUBLE TRIODE

Double triode intended for use as A.F. amplifier, phase inverter or output tube.

QUICK REFERENCE DATA
(Each unit)

Anode current	I_a	6	mA
Transconductance	S	2.9	mA/V
Amplification factor	μ	32	–

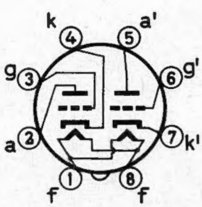
HEATING: Indirect by A.C. or D.C.; parallel supply

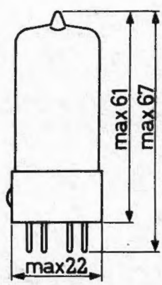
Heater voltage	V_f	6,3	V
Heater current	I_f	0.6	A

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Rimlock





TYPICAL CHARACTERISTICS

Anode voltage	V_a	250	V
Anode current	I_a	6	mA
Grid voltage	V_g	-5.6	V
Transconductance	S	2.9	mA/V
Amplification factor	μ	32	–
Internal resistance	R_i	11	kΩ

OPERATING CHARACTERISTICS as class A output amplifier (one unit)

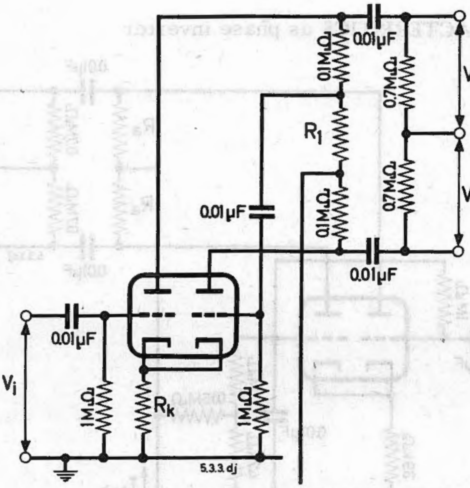
Anode voltage	V_a	250	V
Anode current	I_a	6	mA
Grid voltage	V_g	-5.6	V
Load resistance	$R_{a\sim}$	15	kΩ
Input voltage	V_i	3.9	V_{RMS}
Output power	W_o	280	mW
Total distortion	d_{tot}	8.5	%

OPERATING CHARACTERISTICS as class A output amplifier (two units in push-pull)

Anode voltage	V_a	250		V
Cathode resistor	R_k	560		Ω
Load resistance	$R_{aa\sim}$	30		kΩ
Input voltage	V_i	0	4.1	V_{RMS}
Anode current	I_a	2x5.2	2x5.6	mA
Output power	W_o	0	520	mW
Total distortion	d_{tot}	-	1.0	%

OPERATING CHARACTERISTICS as phase inverter

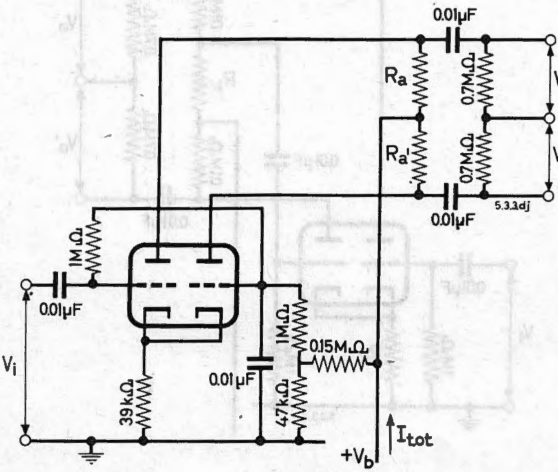
Supply voltage	V_b	350	250 V
Resistor R_1	R_1	3.8	3.9 kΩ
Cathode resistor	R_k	750	1000 Ω
Total current	I_{tot}	4.3	3.0 mA
Voltage gain	V_o/V_i	27.5	26
Output voltage	$V_o = V_o'$	30	30 V_{RMS}
Total distortion 1st unit	d_{tot}	1.1	1.5 %
2nd unit	d'_{tot}	0.3	0.5 %



OPERATING CHARACTERISTICS as A.F. amplifier (one unit)

Supply voltage	V_b	400	350	300	250	200	V
Anode resistor	R_a	100	100	100	100	100	kΩ
Grid resistor	R_g	1	1	1	1	1	MΩ
Grid resistor next stage	R_g'	0.33	0.33	0.33	0.33	0.33	MΩ
Cathode resistor	R_k	2.2	2.2	2.2	2.2	2.2	kΩ
Anode current	I_a	2.2	1.9	1.6	1.4	1.1	mA
Voltage gain	V_o/V_i	24	24	24	24	24	–
Output voltage, max.	$V_{o\,max}$	76	65	54	44	33	V_{RMS}
Total distortion	d_{tot}	3.9	3.9	3.8	3.7	3.6	%

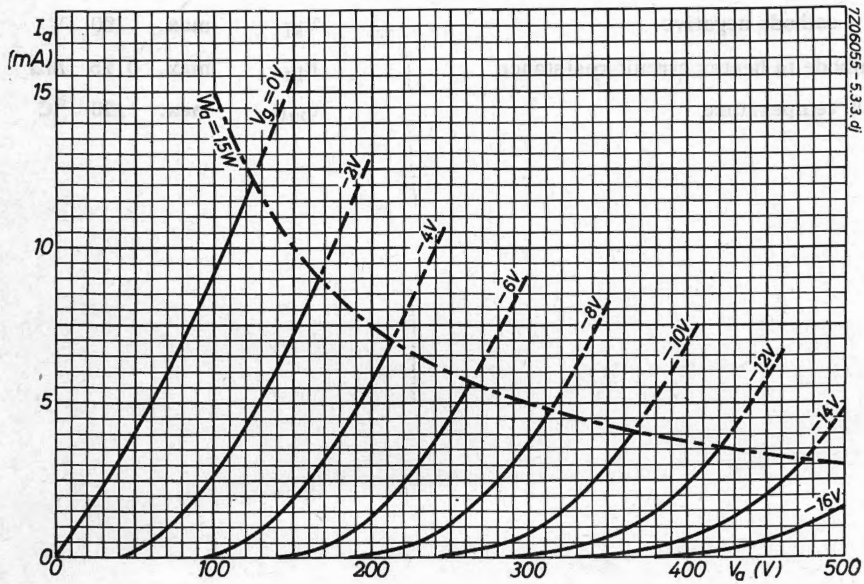
OPERATING CHARACTERISTICS as phase inverter



Supply voltage	V_b	250	350	V
Anode resistor	R_a	0.11	0.11	MΩ
	R_a'	0.12	0.12	MΩ
Total current	I_{tot}	3.0	4.5	mA
Voltage gain	V_o/V_i	11.5	12	–
Output voltage	V_o	30	30	V_{RMS}
Total distortion	d_{tot}	0.6	0.4	%

LIMITING VALUES (Design centre rating system) (each unit)

Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	300	V
Anode dissipation	W_a	max.	1.5	W
Grid dissipation	W_g	max.	0.1	W
Grid resistor	R_g	max.	1	MΩ
Cathode current	I_k	max.	10	mA
Cathode to heater voltage				
cathode positive	V_{kf}	max.	175	V
cathode negative	V_{kf}	max.	100	V
Cathode to heater circuit resistance	R_{kf}	max.	0.15	MΩ
Bulb temperature	t_{bulb}	max.	120	°C



I_a
(mA)
15
10
5
0
$W_a = 1.5W$
$V_g = 0V$
−2V
−4V
−6V
−8V
−10V
−12V
−14V
−16V
0
100
200
300
400
V_a (V)
500
7Z06055-5.3.3.dj

R.F. DOUBLE TRIODE

Double triode intended for use as oscillator, mixer or amplifier in television receivers.

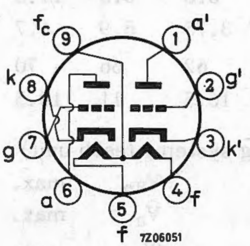
QUICK REFERENCE DATA (each unit)			
Anode current	I_a	10	mA
Transconductance	S	5.5	mA/V
Amplification factor	μ	60	-

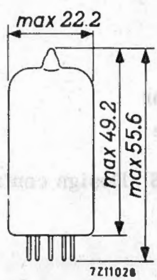
HEATING: Indirect by A.C. or D.C.; series or parallel supply

Heater voltage	V_f	6.3	12.6 V
Heater current	I_f	300 [1])	150 [1]) mA
		pins 9-(4+5)	pins 4-5

DIMENSIONS AND CONNECTIONS — Dimensions in mm

Base: Noval





1) In case of series supply a current limiting device must be inserted in the heater circuit for limiting the current when switching on.

CAPACITANCES

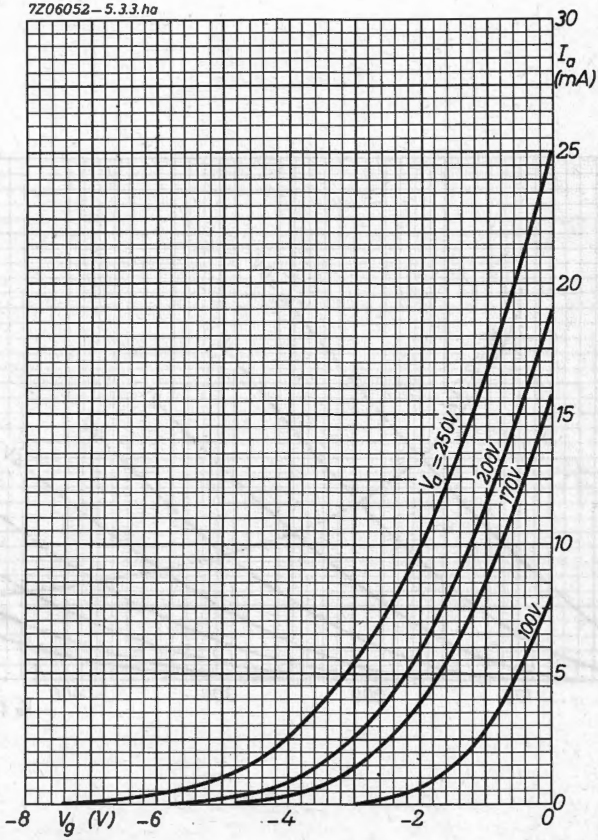
Grid to all except anode	$C_{g(a)}$		2.3	pF
	$C_{g'(a')}$		2.3	pF
Anode to all except grid	$C_{a(g)}$		0.45	pF
	$C_{a'(g')}$		0.35	pF
Anode to grid	C_{ag}		1.6	pF
	$C_{a'g'}$		1.6	pF
Anode to cathode	C_{ak}		0.20	pF
	$C_{a'k'}$		0.20	pF
Cathode to heater	C_{kf}		2.5	pF
	$C_{k'f}$		2.5	pF
Cathode to grid + heater	$C_{k/g+f}$		4.7	pF
	$C_{k'/g'+f}$		4.7	pF
Anode to grid + heater	$C_{a/g+f}$		1.9	pF
	$C_{a'/g'+f}$		1.8	pF
Grid to heater	C_{gf}	max.	0.17	pF
	$C_{g'f}$	max.	0.17	pF
Anode to anode	$C_{aa'}$	max.	0.4	pF
Grid to grid	$C_{gg'}$	max.	0.005	pF
Anode to grid other unit	$C_{ag'}$	max.	0.07	pF
Grid to anode other unit	$C_{ga'}$	max.	0.04	pF

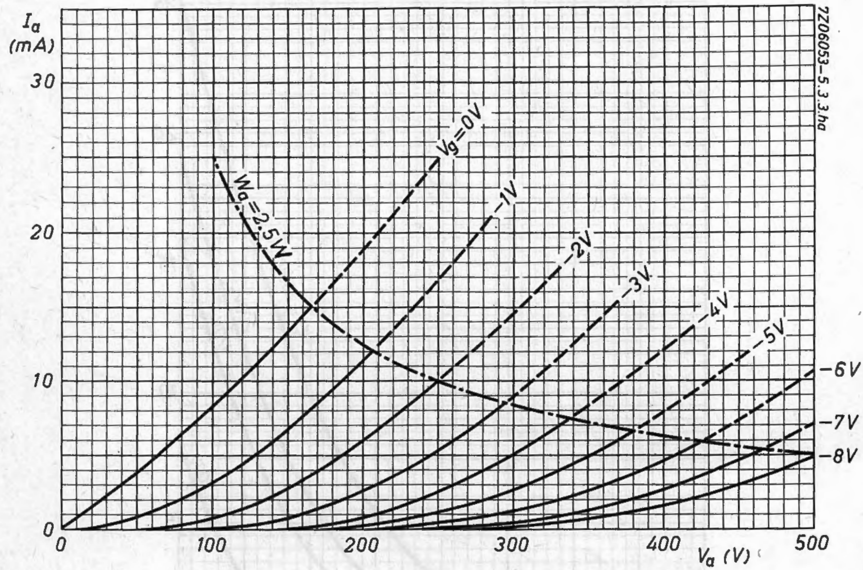
TYPICAL CHARACTERISTICS AND OPERATING CONDITIONS (each unit)

Anode voltage	V_a	100	170	200	250	V
Grid voltage	V_g	-1.0	-1.0	-1.0	-2.0	V
Anode current	I_a	3.0	8.5	11.5	10	mA
Transconductance	S	3.75	5.9	6.7	5.5	mA/V
Amplification factor	μ	62	66	70	60	
Internal resistance	R_i	16.5	11	10.5	11	kΩ

LIMITING VALUES (Design centre rating system) (each unit)

Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	300	V
Anode dissipation	W_a	max.	2.5	W
Cathode current	I_k	max.	15	mA
Grid voltage	$-V_g$	max.	50	V
Grid resistor (automatic bias)	R_g	max.	1	MΩ
Cathode to heater voltage	V_{kf}	max.	90	V


7Z06052-5.3.3.ha
30
I_a
(mA)
25
20
15
10
5
0
V_a = 250V
200V
170V
100V
-8
V_g (V)
-6
-4
-2
0



I_a (mA)
30
20
10
0
0
100
200
300
400
500
V_a (V)
V_g=0V
-1V
-2V
-3V
-4V
-5V
-6V
-7V
-8V
W_a=2.5W
7Z06053-5.3.3ha

A.F. DOUBLE TRIODE

Double triode intended for use as A.F. amplifier.

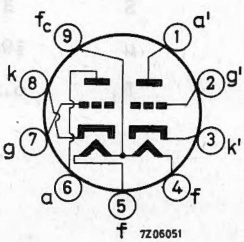
QUICK REFERENCE DATA (each unit)			
Anode current	I_a	10.5	mA
Transconductance	S	2.2	mA/V
Amplification factor	μ	17	–

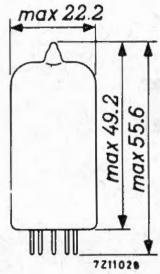
HEATING: Indirect by A.C. or D.C.; series or parallel supply

Heater voltage	V_f	6.3	12.6	V
Heater current	I_f	300	150	mA
		pins 9-(4+5)	pins 4-5	

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Noval





REMARK

With V_f applied to pins 4+5 and 9 and the centre tap of the heater transformer connected to earth, the more favourable triode section of the tube with regard to hum is the section connected to pins 6, 7 and 8.

CAPACITANCES

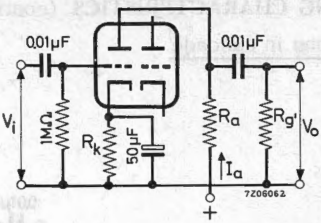
Grid to all except anode	$C_{g(a)}$		1.8	pF
	$C_{g'(a')}$		1.8	pF
Anode to all except grid	$C_{a(g)}$		0.37	pF
	$C_{a'(g')}$		0.25	pF
Anode to grid	C_{ag}		1.5	pF
	$C_{a'g'}$		1.5	pF
Grid to heater	C_{gf}	max.	0.135	pF
	$C_{g'f}$	max.	0.135	pF
Anode to anode	$C_{aa'}$	max.	1.1	pF
Anode to grid other unit	$C_{ag'}$	max.	0.11	pF
Grid to anode other unit	$C_{ga'}$	max.	0.06	pF
Grid to grid	$C_{gg'}$	max.	0.010	pF

TYPICAL CHARACTERISTICS

Anode voltage	V_a	100	250	V
Grid voltage	V_g	0	-8.5	V
Anode current	I_a	11.8	10.5	mA
Transconductance	S	3.1	2.2	mA/V
Amplification factor	μ	19.5	17	-
Internal resistance	R_i	6.25	7.7	kΩ

OPERATING CHARACTERISTICS

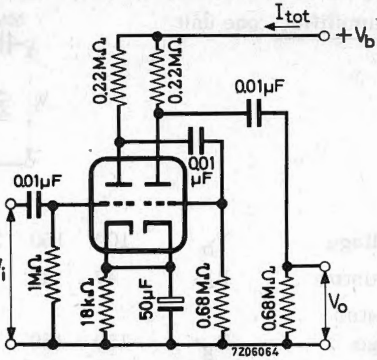
As A.F. amplifier, one unit



Supply voltage	V_b	100	150	200	250	300	350	400	V
Anode resistor	R_a	47	47	47	47	47	47	47	kΩ
Grid resistor next stage	$R_{g'}$	150	150	150	150	150	150	150	kΩ
Cathode resistor	R_k	1.2	1.2	1.2	1.2	1.2	1.2	1.2	kΩ
Anode current	I_a	1.20	1.82	2.41	3.02	3.65	4.30	5.00	mA
Voltage gain	V_o/V_i	13.5	13.5	13.5	13.5	13.5	13.5	13.5	–
Output voltage ($I_g = 0.3\ \mu A$)	V_o	11	18	26	34	43	51	59	V_{RMS}
Total distortion	d_{tot}	5.6	6.1	6.3	6.4	6.5	6.6	6.7	%
Supply voltage	V_b	100	150	200	250	300	350	400	V
Anode resistor	R_a	100	100	100	100	100	100	100	kΩ
Grid resistor next stage	$R_{g'}$	330	330	330	330	330	330	330	kΩ
Cathode resistor	R_k	2.2	2.2	2.2	2.2	2.2	2.2	2.2	kΩ
Anode current	I_a	0.66	0.98	1.30	1.63	1.97	2.30	2.62	mA
Voltage gain	V_o/V_i	14	14	14	14	14	14	14	–
Output voltage ($I_g = 0.3\ \mu A$)	V_o	10	17	25	32	41	49	57	V_{RMS}
Total distortion	d_{tot}	4.8	5.6	5.8	5.9	6.0	6.1	6.2	%
Supply voltage	V_b	100	150	200	250	300	350	400	V
Anode resistor	R_a	220	220	220	220	220	220	220	kΩ
Grid resistor next stage	$R_{g'}$	680	680	680	680	680	680	680	kΩ
Cathode resistor	R_k	3.9	3.9	3.9	3.9	3.9	3.9	3.9	kΩ
Anode current	I_a	0.33	0.50	0.66	0.82	0.98	1.16	1.31	mA
Voltage gain	V_o/V_i	14.5	14.5	14.5	14.5	14.5	14.5	14.5	–
Output voltage ($I_g = 0.3\ \mu A$)	V_o	8	15	22	28	36	43	50	V_{RMS}
Total distortion	d_{tot}	4.0	4.4	4.7	4.8	4.9	5.0	5.1	%

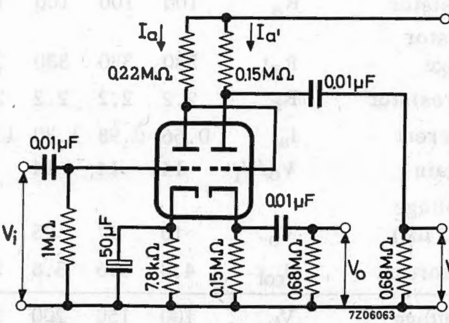
OPERATING CHARACTERISTICS (continued)

Two sections in cascade



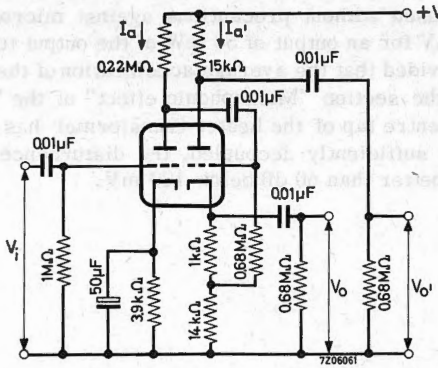
Supply voltage	V_b	250	350 V
Total current	I_{tot}	1.66	2.33 mA
Voltage gain	V_o/V_i	178	178 -
Output voltage (I_g = 0.3 μA)	V_o	15	25 V_{RMS}
Total distortion	d_{tot}	2	2 %

As phase inverter



Supply voltage	V_b	250	350 V
Anode current	I_a	0.70	1.00 mA
Anode current	I_a'	0.68	0.93 mA
Voltage gain	V_o/V_i	11	11 -
Output voltage (I_g = 0.3 μA)	V_o	15	24 V_{RMS}
Total distortion	d_{tot}	1	1 %

OPERATING CHARACTERISTICS (continued)



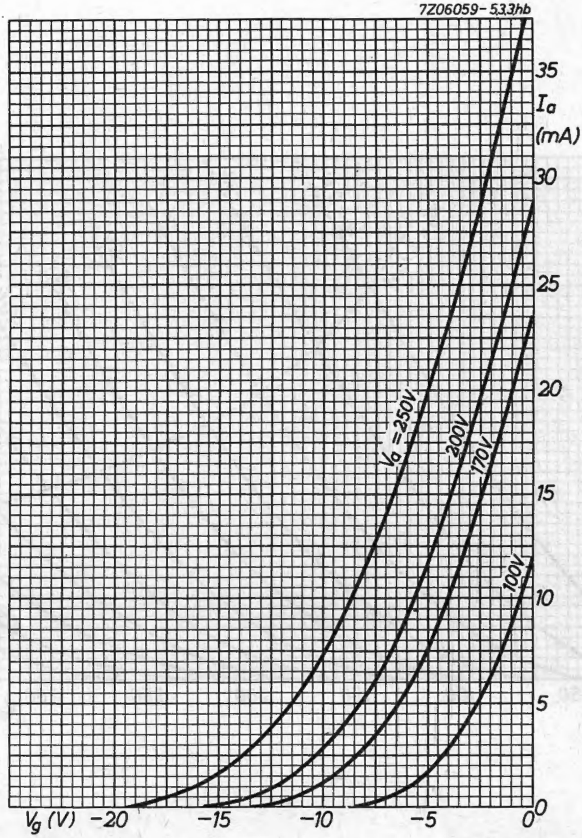
Supply voltage	V_b	250	350	V
Anode current	I_a	0.82	1.16	mA
Anode current	I_a'	4.5	6.3	mA
Voltage gain	V_o/V_i	11	11	-
Output voltage (I_g = 0.3 μA)	V_o	13	20	V_{RMS}
Total distortion	d_{tot}	1.5	1.5	%

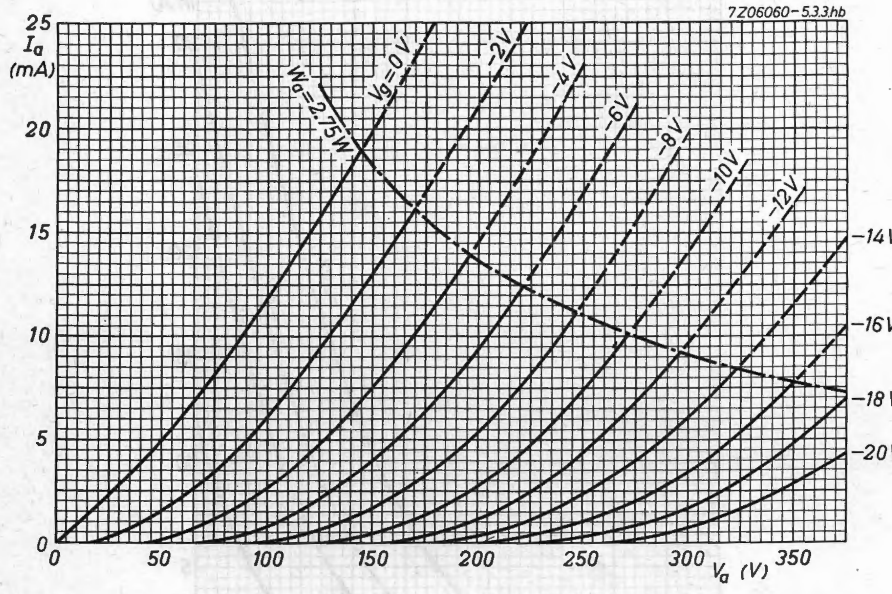
LIMITING VALUES (Design centre rating system) (each unit)

Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	300	V
Anode dissipation	W_a	max.	2.75	W
Cathode current	I_k	max.	20	mA
Grid voltage	$-V_g$	max.	100	V
, peak	$-V_{gp}$	max.	250	V
Grid resistor (automatic bias)	R_g	max.	1	MΩ
Cathode to heater voltage	V_{kf}	max.	180	V
Cathode to heater circuit resistance in phase splitting circuits	R_{kf}	max.	150	kΩ

REMARK

This tube can be used without precautions against microphony in equipment in which $V_i \geqq 10$ mV for an output of 50 mW of the output tube (or $V_i \geqq 100$ mV for 5 W output) provided that the average acceleration of the tube is not greater than indicated in the section "Microphonic effect" of the "Application Directions". When the centre tap of the heater transformer has been earthed, $R_g \leqq$ 0.3 MΩ and R_k is sufficiently decoupled, the disturbance level for hum and noise will then be better than 60 dB below 100 mV.


7Z06059-5.3.3hb
35
30
25
20
15
10
5
0
I_a (mA)
V_a = 250V
200V
170V
100V
V_g (V)
−20
−15
−10
−5
0


7Z06060-5.3.3.hb
25
I_a
(mA)
20
15
10
5
0
0
50
100
150
200
250
300
350
V_a (V)
$W_a = 2.75W$
$V_g = 0V$
−2V
−4V
−6V
−8V
−10V
−12V
−14V
−16V
−18V
−20V

A.F. DOUBLE TRIODE

Double triode intended for use as A.F. amplifier.

QUICK REFERENCE DATA (each unit)			
Anode current	I_a	1.2	mA
Transconductance	S	1.6	mA/V
Amplification factor	μ	100	–

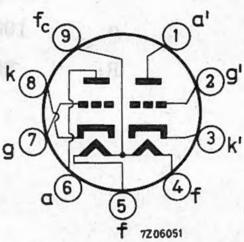
HEATING: Indirect by A.C. or D.C.; series or parallel supply

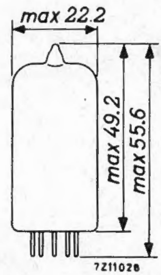
Heater voltage	V_f	6.3	12.6 V
Heater current	I_f	300	150 mA
		pins 9-(4+5)	pins 4-5

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





REMARK

With V_f applied to pins 9 and 4+5 and the centre tap of the heater transformer connected to earth, the triode section connected to pins 6, 7 and 8 is the more favourable section of the tube with respect to hum.

CAPACITANCES

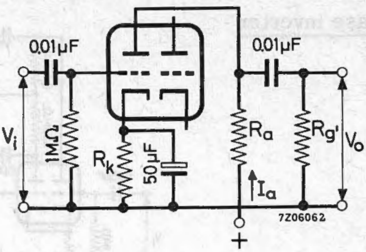
Grid to all except anode	$C_{g(a)}$	1.6 pF
	$C_{g'(a')}$	1.6 pF
Anode to all except grid	$C_{a(g)}$	0.33 pF
	$C_{a'(g')}$	0.23 pF
Anode to grid	C_{ag}	1.6 pF
	$C_{a'g'}$	1.6 pF
Grid to heater	C_{gf}	max. 0.15 pF
	$C_{g'f}$	max. 0.15 pF
Anode to anode	$C_{aa'}$	max. 1.2 pF
Anode to grid other unit	$C_{ag'}$	max. 0.11 pF
Grid to anode other unit	$C_{ga'}$	max. 0.1 pF
Grid to grid	$C_{gg'}$	max. 0.01 pF

TYPICAL CHARACTERISTICS

Anode voltage	V_a	100	250	V
Grid voltage	V_g	-1.0	-2.0	V
Anode current	I_a	0.5	1.2	mA
Transconductance	S	1.25	1.6	mA/V
Amplification factor	μ	100	100	-
Internal resistance	R_i	80	62.5	kΩ

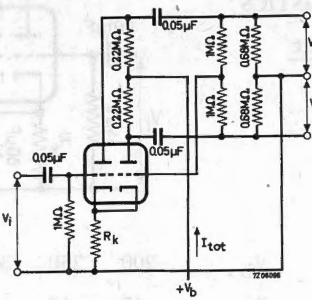
OPERATING CHARACTERISTICS

As A.F. amplifier, one unit

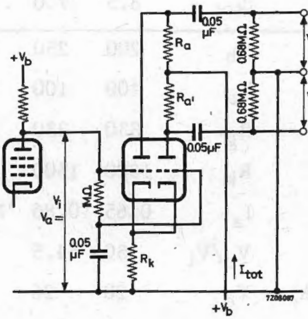


Supply voltage	V_b	200	250	300	350	400	V
Anode resistor	R_a	47	47	47	47	47	kΩ
Grid resistor next stage	$R_{g'}$	150	150	150	150	150	kΩ
Cathode resistor	R_k	1500	1200	1000	820	680	Ω
Anode current	I_a	0.86	1.18	1.55	1.98	2.45	mA
Voltage gain	V_o/V_i	34	37.5	40	42.5	44	–
Output voltage (I_g = 0.3 μA)	V_o	18	23	26	33	37	V_{RMS}
Total distortion	d_{tot}	8.5	7.0	5.0	4.4	3.6	%
Supply voltage	V_b	200	250	300	350	400	V
Anode resistor	R_a	100	100	100	100	100	kΩ
Grid resistor next stage	$R_{g'}$	330	330	330	330	330	kΩ
Cathode resistor	R_k	1800	1500	1200	1000	820	Ω
Anode current	I_a	0.65	0.86	1.11	1.40	1.72	mA
Voltage gain	V_o/V_i	50	54.5	57	61	63	–
Output voltage (I_g = 0.3 μA)	V_o	20	26	30	36	38	V_{RMS}
Total distortion	d_{tot}	4.8	3.9	2.7	2.2	1.7	%
Supply voltage	V_b	200	250	300	350	400	V
Anode resistor	R_a	220	220	220	220	220	kΩ
Grid resistor next stage	$R_{g'}$	680	680	680	680	680	kΩ
Cathode resistor	R_k	3.3	2.7	2.2	1.5	1.2	kΩ
Anode current	I_a	0.36	0.48	0.63	0.85	1.02	mA
Voltage gain	V_o/V_i	56	66.5	72	75.5	76.5	–
Output voltage (I_g = 0.3 μA)	V_o	24	28	36	37	38	V_{RMS}
Total distortion	d_{tot}	4.6	3.4	2.6	1.6	1.1	%

As phase inverter



Supply voltage	V_b	250	350	V
Cathode resistor	R_k	1200	820	Ω
Total current	I_{tot}	1.08	1.70	mA
Voltage gain	V_o/V_i	58	62	–
Output voltage (I_g = 0.3 µA)	V_o	35	45	V_{RMS}
Total distortion	d_{tot}	5.5	3.5	%



Supply voltage	V_b	250	350	V
Anode voltage	V_a	65	90	V
Total current	I_{tot}	1	1.2	mA
Cathode resistor	R_k	68	82	kΩ
Anode resistor	R_a	100	150	kΩ
Anode resistor	$R_{a'}$	100	150	kΩ
Voltage gain	V_o/V_i	25	27	–
Output voltage (I_g = 0.3 µA)	V_o	20	35	V_{RMS}
Total distortion	d_{tot}	1.8	1.8	%

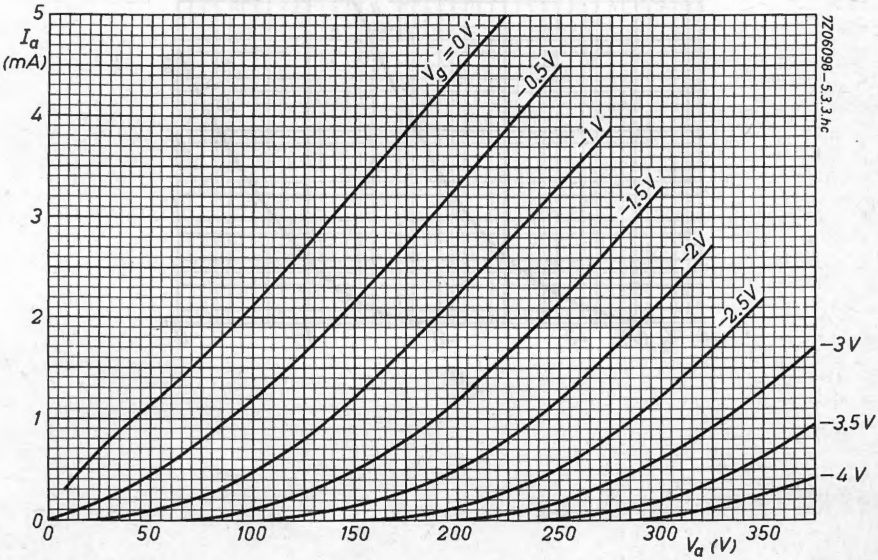
LIMITING VALUES (Design centre rating system)

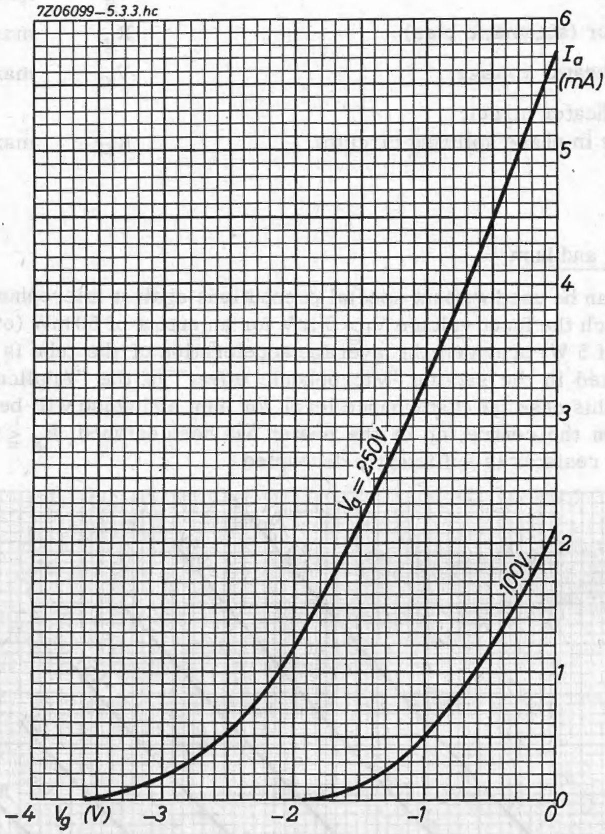
Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	300	V
Anode dissipation	W_a	max.	1	W
Cathode current	I_k	max.	8	mA
Grid voltage	$-V_g$	max.	50	V
Grid resistor (automatic bias)	R_g	max.	2	MΩ
Cathode to heater voltage	V_{kf}	max.	180	V
Cathode to heater circuit resistance in phase splitting circuits	R_{kf}	max.	150	kΩ

REMARK

Microphony and hum

This tube can be used without special precautions against microphony in equipment in which the input voltage $V_i \geq 5$ mV for an output of 50 mW (or 50 mV for an output of 5 W) provided the average acceleration of the tube is not greater than indicated in the section "Microphonic effect" of the "Application directions". In this case the disturbance level for hum and noise will be better than −60 dB when the centre tap of the heater has been earthed, $R_g \leqq 0.5$ MΩ and the cathode resistor is sufficiently decoupled.




7Z06099-5.3.3.hc
6
I_a (mA)
5
4
3
2
1
0
$V_a = 250V$
100V
−4
V_g (V)
−3
−2
−1
0

R.F. DOUBLE TRIODE

Double triode intended for use as R.F. and A.F. amplifier and self oscillating mixer.

QUICK REFERENCE DATA (each unit)			
Anode current	I_a	10	mA
Transconductance	S	6.1	mA/V
Amplification factor	μ	55	–

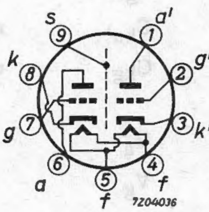
HEATING: Indirect by A.C. or D.C.; parallel supply

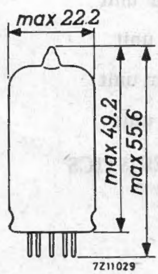
Heater voltage	V_f	6.3	V
Heater current	I_f	435	mA

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





CAPACITANCES

Anode to grid	C_{ag}		1.5	pF
	$C_{a'g'}$		1.5	pF
Anode to cathode	C_{ak}		0.17	pF
	$C_{a'k'}$		0.18	pF
Anode to cathode + heater + screen	$C_{a/kfs}$		1.2	pF
	$C_{a'/k'fs}$		1.2	pF
Grid to cathode + heater + screen	$C_{g/kfs}$		3.1	pF
	$C_{g'/k'fs}$		3.1	pF
Anode to cathode + heater + screen with external screen of 22.5 mm diam.	$C_{a/kfs}$		1.8	pF
	$C_{a'/k'fs}$		1.8	pF
Anode to anode	$C_{aa'}$	max.	0.04	pF
Grid to grid	$C_{gg'}$	max.	0.003	pF
Anode to grid other unit	$C_{ag'}$	max.	0.008	pF
Grid to anode other unit	$C_{ga'}$	max.	0.008	pF
Anode to anode with external screen of 22.5 mm diam.	$C_{aa'}$	max.	0.008	pF
Anode to cathode other unit	$C_{ak'}$	max.	0.008	pF
Grid to cathode other unit	$C_{gk'}$	max.	0.003	pF
Cathode to anode other unit	$C_{ka'}$	max.	0.008	pF
Cathode to grid other unit	$C_{kg'}$	max.	0.003	pF

TYPICAL CHARACTERISTICS

Anode voltage	V_a	250	V
Grid voltage	V_g	−2.7	V
Anode current	I_a	10	mA
Transconductance	S	6.1	mA/V
Amplification factor	μ	55	−

REMARK

Microphony

This tube can be used without special precautions against microphony in A.F. applications in which the input voltage $V_i \geq$ 5 mV for an output of 50 mW (or 50 mV for an output of 5 W) provided the peak acceleration of the tube is not greater than indicated in the section "Microphony" of the "General Operational Recommendations".

OPERATING CHARACTERISTICS

As R.F. amplifier

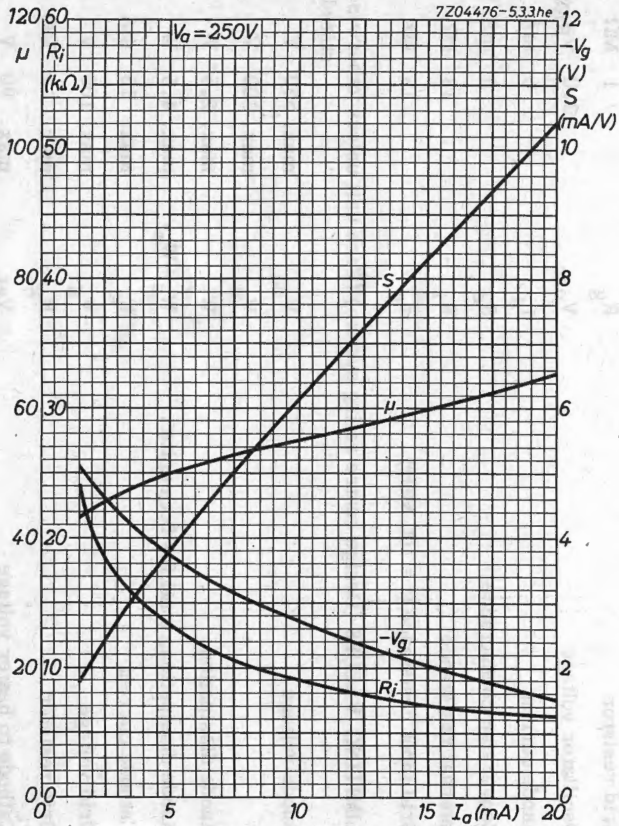
Supply voltage	V_b	250	V
Anode resistor	R_a	1.8	kΩ
Anode voltage	V_a	230	V
Cathode resistor	R_k	200	Ω
Grid voltage	V_g	-2.2	V
Anode current	I_a	10.8	mA
Transconductance	S	6.8	mA/V
Internal resistance	R_i	8.3	kΩ
Grid input resistance (f = 100 MHz)	r_g	4.7	kΩ
Equivalent noise resistance	R_{eq}	580	Ω

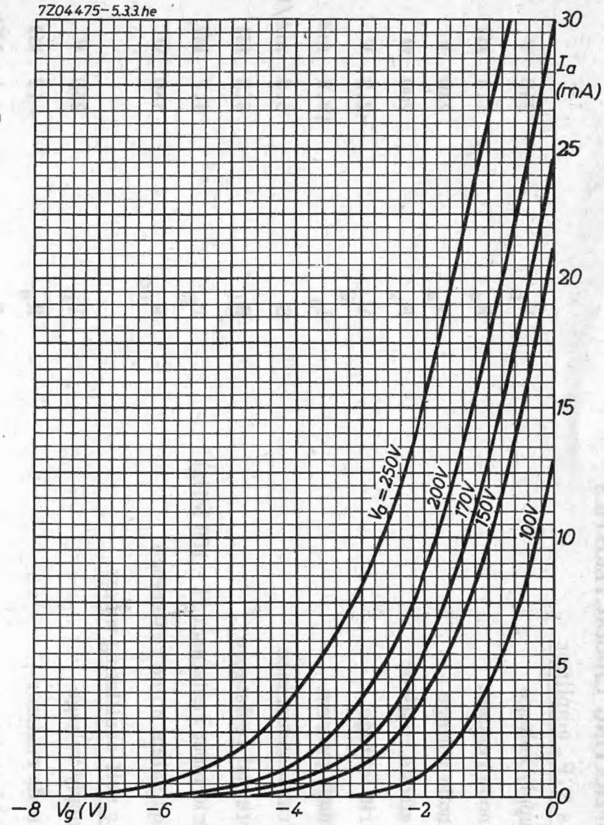
As self-oscillating mixer

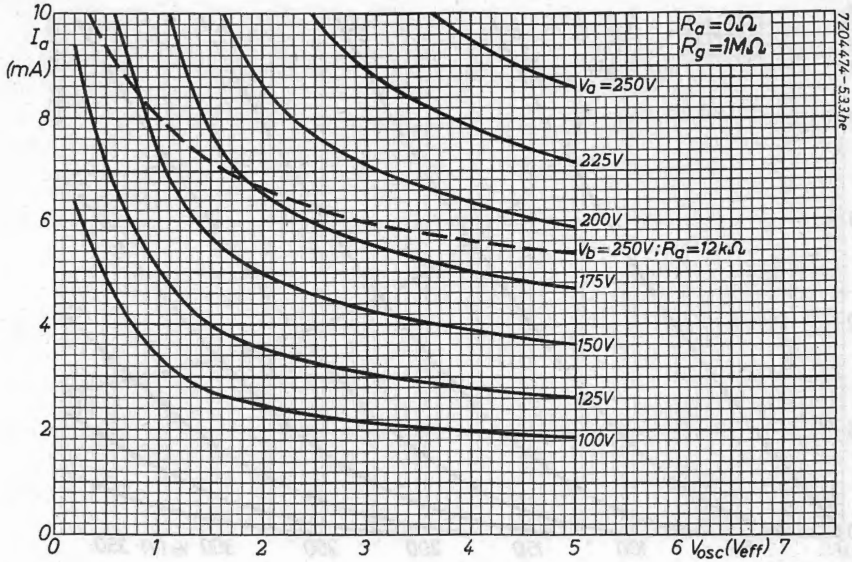
Supply voltage	V_b	250	V
Anode resistor	R_a	12	kΩ
Grid resistor	R_g	1	MΩ
Oscillator voltage	V_{osc}	3.0	V_{RMS}
Anode current	I_a	6	mA
Conversion conductance	S_c	3	mA/V
Internal resistance	R_i	18	kΩ
Grid input resistance (f = 100 MHz)	r_g	15	kΩ

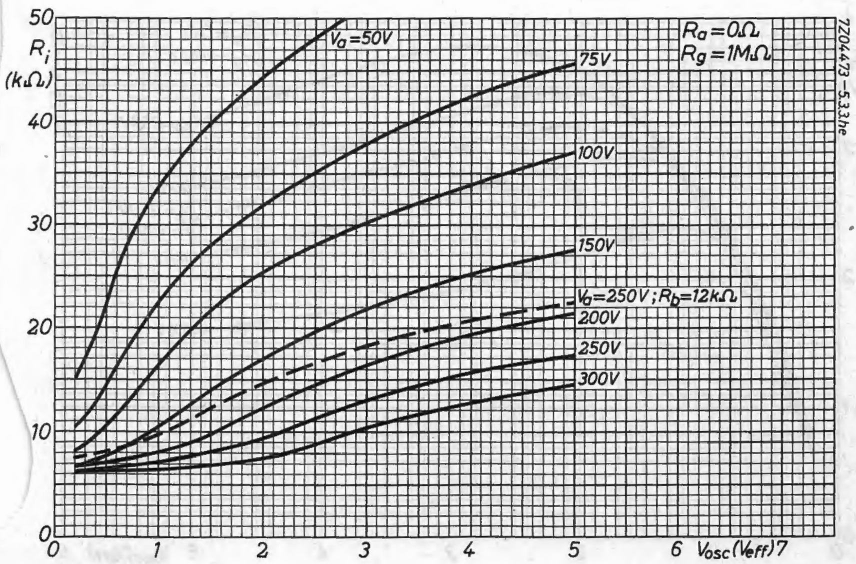
LIMITING VALUES (Design centre rating system) (Each unit unless otherwise stated)

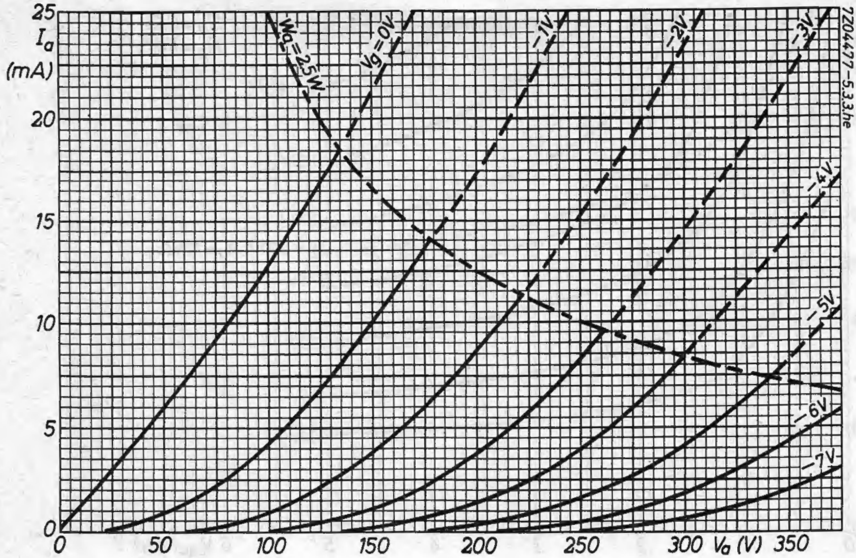
Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	300	V
Anode dissipation	W_a	max.	2.5	W
Anode dissipation, total for both units	$W_a + W_{a'}$	max.	4.5	W
Cathode current	I_k	max.	15	mA
Grid voltage	$-V_g$	max.	100	V
Grid resistor	R_g	max.	1	MΩ
Cathode to heater voltage	V_{kf}	max.	90	V

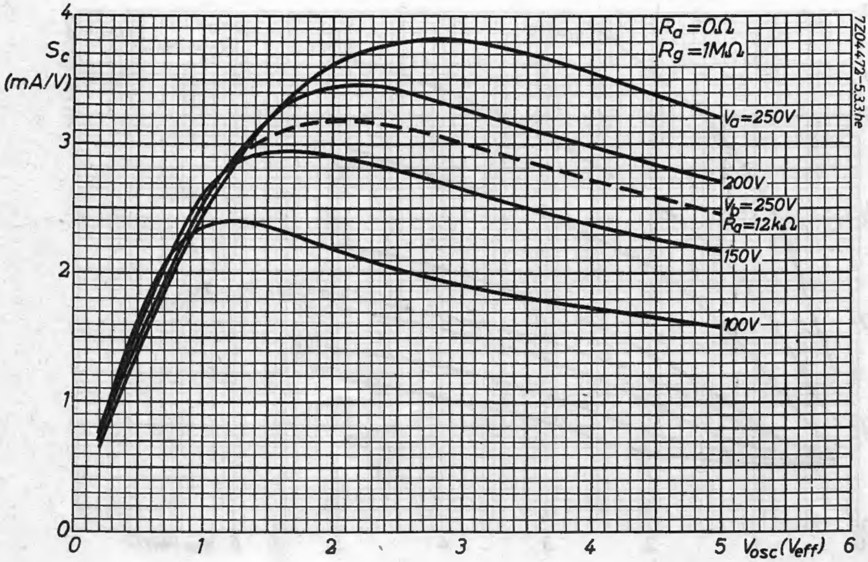

7Z04476-5.3.3.he
$V_a = 250V$
μ
R_i
(kΩ)
$-V_g$
(V)
S
(mA/V)
S
μ
$-V_g$
R_i
120 60 12
100 50 10
80 40 8
60 30 6
40 20 4
20 10 2
0 0 0
0 5 10 15 20
I_a(mA)


7Z04475-5.3.3.he
I_a
(mA)
30
25
20
15
10
5
0
$V_a = 250V$
200V
170V
150V
100V
−8 −6 −4 −2 0
V_g(V)


10
I_a
(mA)
8
6
4
2
0
0 1 2 3 4 5 6 $V_{osc}(V_{eff})$ 7
$R_a=0\Omega$
$R_g=1M\Omega$
$V_a=250V$
225V
200V
$V_b=250V;R_a=12k\Omega$
175V
150V
125V
100V
7Z04474-5.3.he


50
R_i
(kΩ)
40
30
20
10
0
0 1 2 3 4 5 6 $V_{osc}(V_{eff})$ 7
$R_a=0\Omega$
$R_g=1M\Omega$
$V_a=50V$
75V
100V
150V
$V_a=250V;R_b=12k\Omega$
200V
250V
300V
7Z04473-5.3.he


25
I_a
(mA)
20
15
10
5
0
0
50
100
150
200
250
300
V_a (V)
350
Wa=2,5W
Vg=0V
−1V
−2V
−3V
−4V
−5V
−6V
−7V
7Z04477-5.3.he


4
S_c
(mA/V)
3
2
1
0
0
1
2
3
4
5
V_{osc}(V_{eff})
6
R_a=0Ω
R_g=1MΩ
V_a=250V
200V
V_b=250V
R_a=12kΩ
150V
100V
7Z04478-5.3.he

R.F. DOUBLE TRIODE

Double triode intended for use as cascode amplifier in tuners for television receivers.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	365	mA

For further data and curves please refer to PCC88

R.F. DOUBLE TRIODE

Double triode with variable transconductance intended for use as V.H.F. cascode amplifier in television receivers.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	365	mA

LIMITING VALUES (Design centre rating system)

Cathode to heater voltage	V_{kf}	max.	50	V
	$V_{k'f}$ (k pos)	max.	150	V [1]

For further data and curves of this type
please refer to type PCC189

---

[1]) D.C. component max. 130 V.

TRIODE-PENTODE

Triode-pentode with separate cathodes intended for use as frequency changer in television receivers.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	430	mA

LIMITING VALUES (Design centre rating system)

Triode section

Cathode to heater voltage	V_{kf}	max.	100	V

Pentode section

Cathode to heater voltage	V_{kf}	max.	100	V

For further data and curves
please refer to PCF80

TRIODE-PENTODE

Triode-pentode intended for use as frequency changer in V.H.F. television tuners.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	390	mA

LIMITING VALUES (Design centre rating system)

Triode section

Cathode to heater voltage	V_{kf}	max.	100	V

Pentode section

Cathode to heater voltage	V_{kf}	max.	100	V

For further data and curves
please refer to PCF86

TRIODE-PENTODE

Triode-pentode intended for use in television receivers; triode section as limiter, noise detector, A.G.C. amplifier, sync. separator and pulse-amplifier; pentode section as sound I.F. amplifier and video I.F. amplifier.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	410	mA

For further data and curves
please refer to type PCF200

TRIODE-PENTODE

Triode-pentode intended for use in T.V. receivers; triode section as line-blocking oscillator, part of a multivibrator, sync separator, pulse amplifier or A.G.C. delay diode; pentode section with remote cut-off as video I.F. amplifier.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	410	mA

For further data and curves of this type
please refer to type PCF201

TRIODE-PENTODE

High transconductance triode and R.F. pentode intended for use as frequency changer in V.H.F. T.V. tuners.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	0.41	A

For further data and curves of this type please refer to type PCF801

TRIODE-PENTODE

Triode-pentode; triode section intended for use as reactance tube, pentode section intended for use as sine wave oscillator or pulse shaper in television receivers.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	430	mA

LIMITING VALUES

Pentode section

Cathode to heater voltage	V_{kf}	max. 100	V

Triode section

Cathode to heater voltage	V_{kf}	max. 100	V

For further data and curves
please refer to type PCF802

TRIODE-HEXODE

Triode-hexode intended for use as frequency changer and phase inverter.

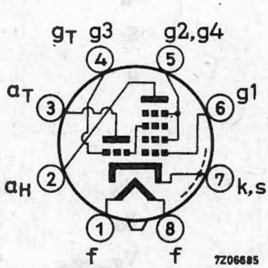
QUICK REFERENCE DATA			
Triode section			
Anode current	I_a	10	mA
Transconductance	S	2.8	mA/V
Hexode section			
Anode current	I_a	3	mA
Conversion conductance	S_c	0.75	mA/V

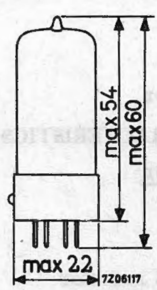
HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	230	mA

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Rimlock





CAPACITANCES

Triode section

Anode to all except grid and grid No. 3	$C_{a_T(g_Tg_3)}$	2.4 pF
Grid and grid No. 3 to all except anode	$C_{g_Tg_3/(a_T)}$	5.9 pF
Grid and grid No. 3 to anode	$C_{g_Tg_3/a_T}$	1.3 pF

Hexode section

Anode to all	C_a	9.4 pF
Grid No. 1 to all	C_{g_1}	4.0 pF
Anode to grid No. 1	C_{ag_1}	max. 0.1 pF
Grid No. 1 to heater	C_{g_1f}	max. 0.15 pF

Between triode and hexode sections

Grid triode and grid No. 3 to grid No. 1 hexode	$C_{g_Tg_3/g_{1H}}$	max. 0.35 pF
Grid triode and grid No. 3 to anode hexode	$C_{g_Tg_3/a_H}$	max. 0.2 pF
Anode triode to grid No. 1 hexode	$C_{a_Tg_{1H}}$	max. 0.06 pF
Anode triode to anode hexode	$C_{a_Ta_H}$	max. 0.5 pF

TYPICAL CHARACTERISTICS

Triode section

Anode voltage	V_a	100	V
Grid voltage	V_g	0	V
Anode current	I_a	10	mA
Transconductance	S	2.8	mA/V
Amplification factor	μ	22	-

OPERATING CHARACTERISTICS

Triode as oscillator

Supply voltage	V_b	250	250	V
Anode resistor	R_a	33	33	kΩ
Grid and grid No. 3 resistor	$V_{g_T+g_3}$	47	22	kΩ
Grid and grid No. 3 current	$I_{g_T+g_3}$	200	350	µA
Anode current	I_a	4.8	5.1	mA
Oscillator voltage	V_{osc}	8.0	8.0	V_{RMS}
Effective transconductance	S_{eff}	0.55	0.6	mA/V

OPERATING CHARACTERISTICS (continued)

Hexode as frequency changer; circuit fig. 1

Supply voltage	V_b	250		V
Anode resistor	R_a	0		Ω
Resistor 1	R_1	27		kΩ
Resistor 2	R_2	27		kΩ
Cathode resistor	R_k	180		Ω
Grid triode and grid No. 3 resistor	$R_{g_T+g_3}$	22		kΩ
Grid triode and grid No. 3 current	$I_{g_T+g_3}$	350 [1]		μA
Grid No. 1 voltage	V_{g_1}	-2	-29	V
Grid No. 2 and 4 voltage	$V_{g_{2+4}}$	85	124	V
Anode current	I_a	3.0	-	mA
Grid No. 2 and 4 current	$I_{g_{2+4}}$	3.0	-	mA
Conversion conductance	S_c	750	7.5	μA/V
Internal resistance	R_i	min. 1	min. 5	MΩ
Equivalent noise resistance	R_{eq}	100	-	kΩ

LIMITING VALUES (Design centre rating system)

Triode section

Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	175	V
Anode dissipation	W_a	max.	0.8	W
Cathode current	I_k	max.	6	mA
Grid resistor	R_g	max.	3	MΩ
Cathode to heater voltage	V_{kf}	max.	100	V

[1]) If R_{gt+g_3} is 47 kΩ, $I_{g_T+g_3}$ should be adjusted to 200 μA.

LIMITING VALUES (continued)

Hexode section

Anode voltage	V_{a_o}	max. 550 V
	V_a	max. 300 V
Anode dissipation	W_a	max. 1.5 W
Cathode current	I_k	max. 10 mA
Grid No. 2 and 4 voltage	$V_{(g2+4)o}$	max. 550 V
Grid No. 2 and 4 voltage (anode current 3 mA)	$V_{g_{2+4}}$	max. 125 V
Grid No. 2 and 4 voltage (anode current max. 1 mA)	$V_{g_{2+4}}$	max. 300 V
Grid No. 2 and 4 dissipation	$W_{g_{2+4}}$	max. 0.3 W
Grid No. 1 resistor	R_{g_1}	max. 3 MΩ
Grid No. 3 resistor	R_{g_3}	max. 3 MΩ
Cathode to heater voltage	V_{kf}	max. 100 V

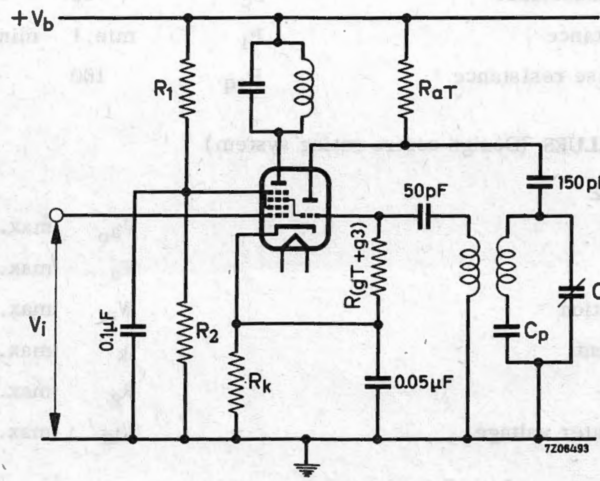


fig. 1

TRIODE-HEPTODE

Triode-heptode. Heptode section intended for use as mixer, R.F.-or I.F.amplifier. Triode section intented for use as oscillator in A.M./F.M. receivers.

QUICK REFERENCE DATA			
Triode section			
Anode current	I_a	13.5	mA
Transconductance	S	3.7	mA/V
Amplification factor	μ	22	-
Heptode section			
Anode current	I_a	11	mA
Transconductance	S	4.5	mA/V
Amplification factor	$\mu_{g_2g_1}$	25	-

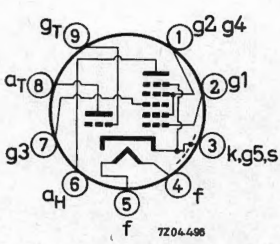
HEATING: Indirect by A.C. or D.C.; series or parallel supply

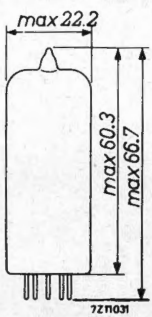
Heater voltage	V_f	6.3	V
Heater current	I_f	300	mA

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





CAPACITANCES

Triode section

Grid to all except anode	$C_{g(a)}$	2.6 pF
Anode to all except grid	$C_{a(g)}$	2.1 pF
Anode to grid	C_{ag}	1.0 pF
Grid to heater	C_{gf}	max. 0.02 pF

Heptode section

Grid No.1 to all except anode	$C_{g_1(a)}$	4.8 pF
Anode to all except grid No.1	$C_{a(g_1)}$	7.9 pF
Anode to grid No.1	C_{ag_1}	max.0.006 pF
Grid No.1 to heater	C_{g_1f}	max. 0.17 pF
Grid No.3 to all	C_{g_3}	6 pF
Grid No.1 to grid No.3	$C_{g_1g_3}$	max. 0.3 pF
Grid No.3 to heater	C_{g_3f}	max. 0.06 pF

Between heptode and triode sections

Anode heptode to anode triode	$C_{a_Ha_T}$	0.20 pF
Anode heptode to grid triode	$C_{a_Hg_T}$	max. 0.09 pF
Grid No.1 heptode to anode triode	$C_{g_{1H}a_T}$	max. 0.06 pF
Grid No.1 heptode to grid triode	$C_{g_{1H}g_T}$	max. 0.17 pF
Grid No.1 heptode to grid triode + grid No.3	C_{g_{1H}/g_Tg_3}	max. 0.45 pF
Anode heptode to grid triode + grid No.3	C_{a_H/g_Tg_3}	max. 0.35 pF

TYPICAL CHARACTERISTICS

Triode section

Anode voltage	V_a	100	V
Grid voltage	V_g	0	V
Anode current	I_a	13.5	mA
Transconductance	S	3.7	mA/V
Amplification factor	μ	22	-

Heptode section

Anode voltage	V_a	160	V
Grid No.3 voltage	V_{g_3}	0	V
Grids No.2 and 4 voltage	$V_{g_{2+4}}$	100	V
Grid No.1 current	I_{g_1}	0.5	μA
Grid No.1 voltage	V_{g_1}	−0.5	V
Anode current	I_a	11	mA
Grids No.2 and 4 current	$I_{g_{2+4}}$	7	mA
Transconductance	S	4.5	mA/V
Amplification factor	$\mu_{g_2g_1}$	25	-

OPERATING CHARACTERISTICS

Heptode section as mixer [1]

Supply voltage	V_b	250		V
Anode resistor	R_a	8.2		kΩ
Grids No.2 and 4 resistor	R_{g_2+4}	22		kΩ
Grid triode + grid No.3 resistor	$R_{g_T+g_3}$	47		kΩ
Grid triode + grid No.3 current	$I_{g_T+g_3}$	200		µA
Grid No.1 current	I_{g_1}	0.5	–	µA [2]
Grid No.1 voltage	V_{g_1}	–	–28	V
Anode voltage	V_a	225	240	V
Grids No.2 and 4 voltage	V_{g_2+4}	78	235	V
Anode current	I_a	3.3	–	mA
Grids No.2 and 4 current	I_{g_2+4}	7.8	–	mA
Conversion conductance	S_c	1100	11	µA/V
Internal resistance	R_i	0.8	min. 3	MΩ
Equivalent noise resistance	R_{eq}	30	–	kΩ

1) Triode operating with V_b = 250 V, R_a = 33 kΩ, V_{osc} = 8 V_{RMS}.

2) Grid current bias obtained with R_{g_1} = 1 MΩ and with zero volts a.g.c. voltage; resulting grid one voltage: −0.5 V.

OPERATING CHARACTERISTICS (continued)

Heptode section as R.F. or I.F. amplifier

Supply voltage	V_b	250		V	
Anode resistor	R_a	8.2		kΩ	
Grid No.3 voltage	V_{g_3}	0		V	
Grids No.2 and 4 resistor	$R_{g_{2+4}}$	22		kΩ	
Grid No.1 current	I_{g_1}	0.5	–	μA	
Grid No.1 voltage	V_{g_1}	–	–35	V	[1]
Anode voltage	V_a	160	248	V	
Grids No.2 and 4 voltage	$V_{g_{2+4}}$	96	245	V	
Anode current	I_a	11	–	mA	
Grids No.2 and 4 current	$I_{g_{2+4}}$	7	–	mA	
Transconductance	S	4500	45	μA/V	
Internal resistance	R_i	0.24	min. 10	MΩ	
Amplification factor	$\mu_{g_2g_1}$	25	-	-	
Equivalent noise resistance	R_{eq}	4.5	–	kΩ	

Triode section as oscillator

Supply voltage	V_b	250	V
Anode resistor	R_a	33	kΩ
Grid triode + grid No.3 resistor	R_{gT+g_3}	47	kΩ
Grid triode + grid No.3 current	I_{gT+g_3}	200	μA
Anode current	I_a	4.5	mA
Effective transconductance	S_{eff}	0.65	mA/V

[1] Grid current bias obtained with R_{g_1} = 1 MΩ and with zero volts a.g.c. voltage; resulting grid No.1 voltage: –0.5 V.

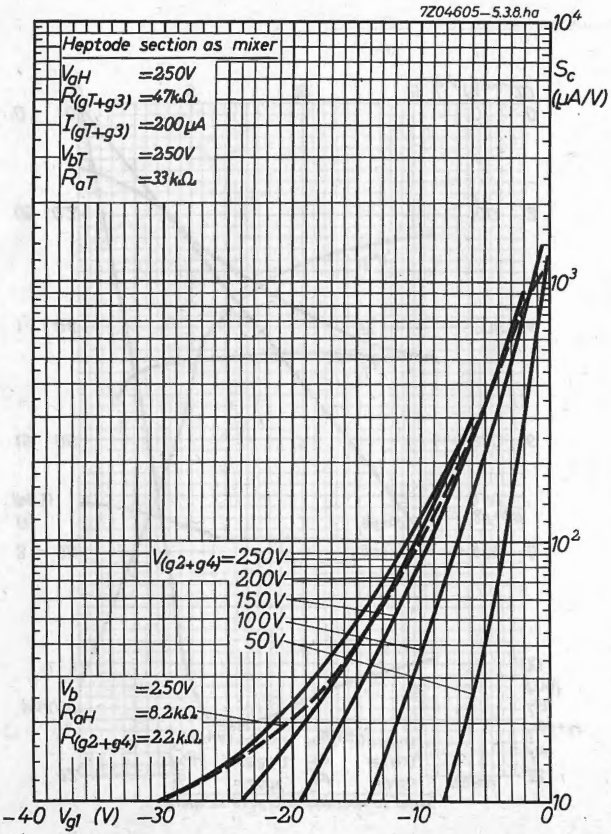
LIMITING VALUES (Design centre rating system)

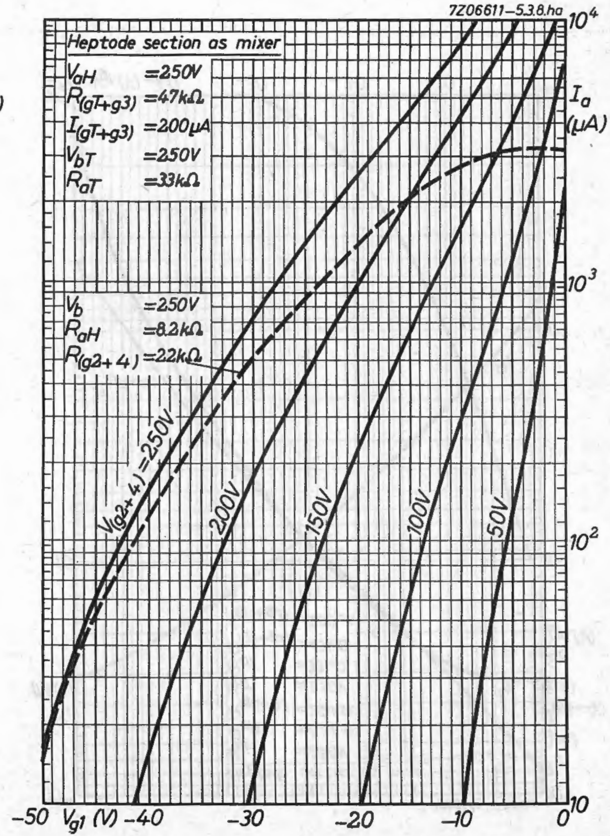
Heptode section

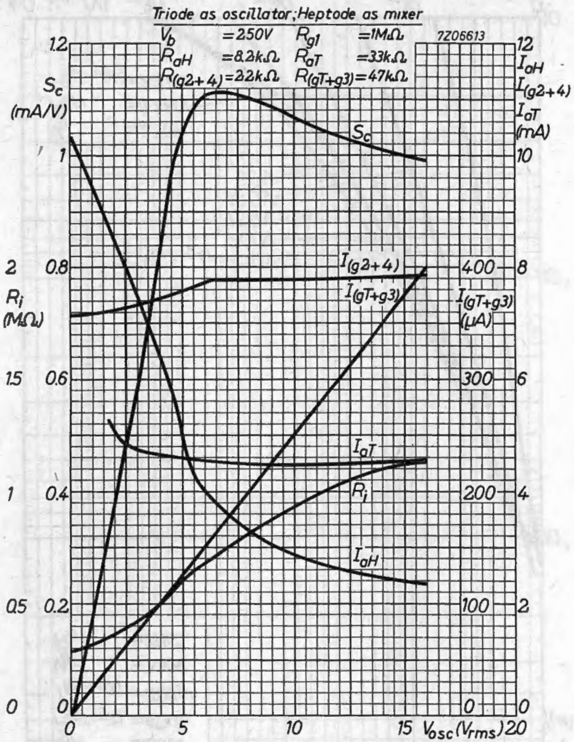
Anode voltage	V_{a_o}	max. 550 V
	V_a	max. 300 V
Anode dissipation	W_a	max. 2.0 W
Grids No.2 and 4 voltage	$V_{g_{2+4_o}}$	max. 550 V
	$V_{g_{2+4}}$	max. 125 V
Grids No.2 and 4 voltage (I_a max. 1 mA)	$V_{g_{2+4}}$	max. 300 V
Grids No.2 and 4 dissipation	$W_{g_{2+4}}$	max. 0.8 W
Cathode current	I_k	max. 18 mA
Grid No.1 resistor	R_{g_1}	max. 3 MΩ
Grid No.3 resistor	R_{g_3}	max. 20 kΩ
Grid No.3 resistor grid No.3 directly connected to grid triode	R_{g_3}	max. 3 MΩ
Cathode to heater voltage	V_{kf}	max. 100 V

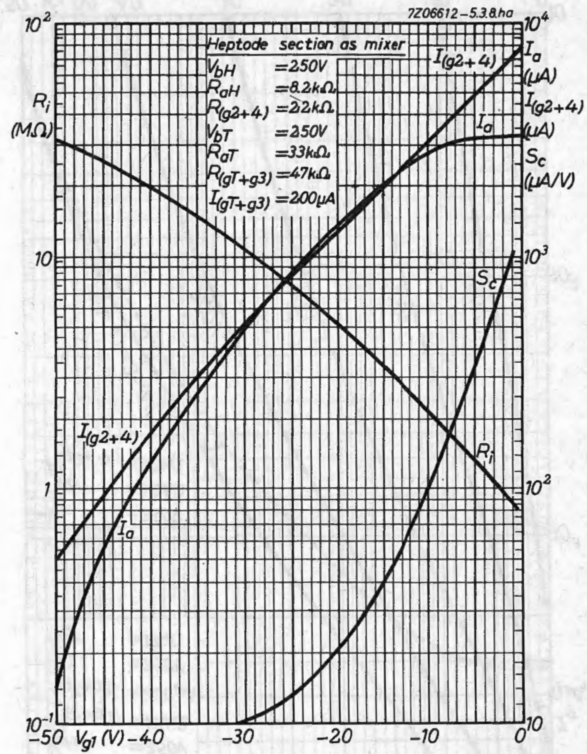
Triode section

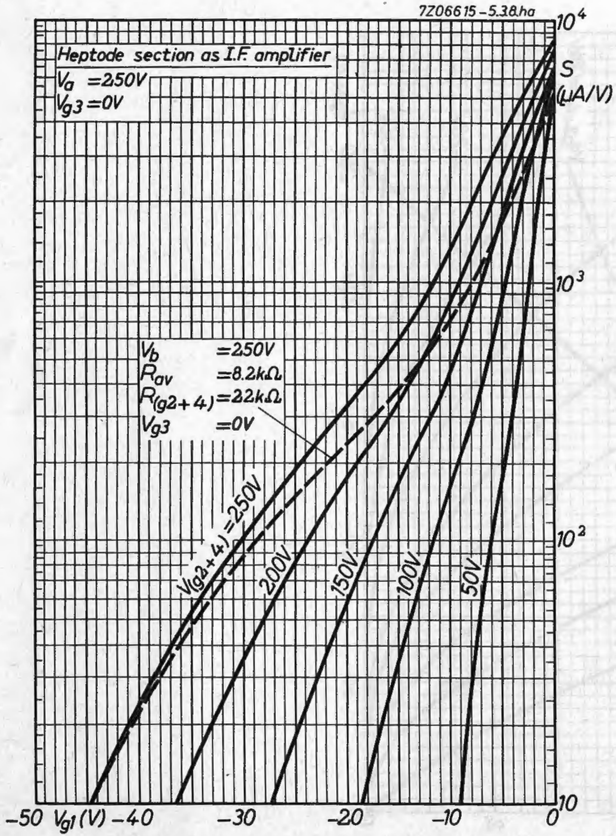
Anode voltage	V_{a_o}	max. 550 V
	V_a	max. 250 V
Anode dissipation	W_a	max. 0.8 W
Cathode current	I_k	max. 6.5 mA
Grid resistor	R_g	max. 3 MΩ
Cathode to heater voltage	V_{kf}	max. 100 V

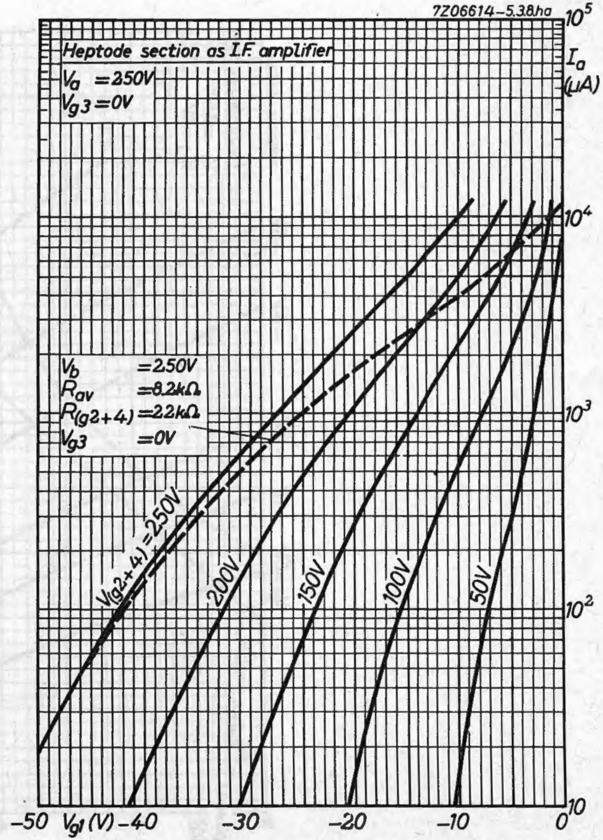

7Z04605–5.3.8.ha
Heptode section as mixer
V_{aH} =250V
$R_{(gT+g3)}$ =47kΩ
$I_{(gT+g3)}$ =200μA
V_{bT} =250V
R_{aT} =33kΩ
S_c (μA/V)
$V_{(g2+g4)}$=250V
200V
150V
100V
50V
V_b =250V
R_{aH} =8.2kΩ
$R_{(g2+g4)}$=2.2kΩ
V_{g1} (V)
−40 −30 −20 −10 0
10 10^2 10^3 10^4

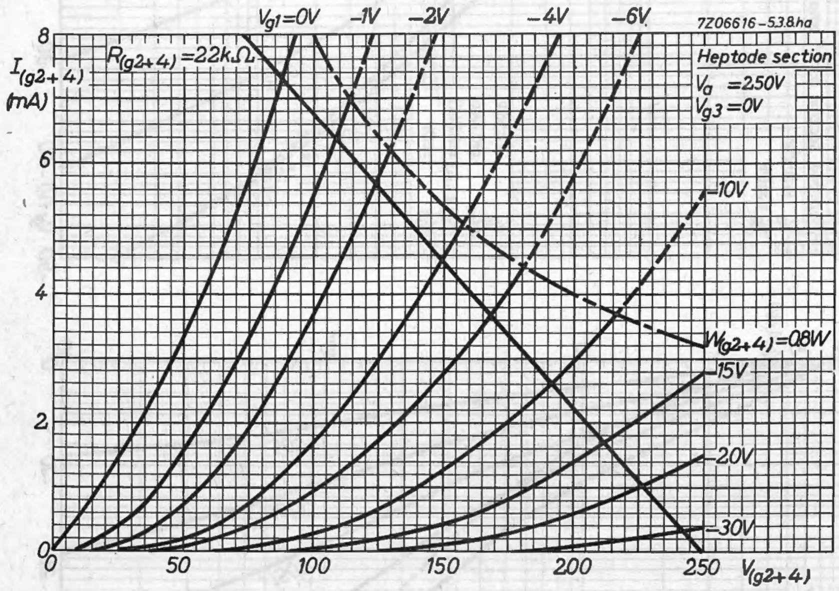

7Z06611–5.3.8.ha
Heptode section as mixer
V_{aH} =250V
$R_{(gT+g3)}$ =47kΩ
$I_{(gT+g3)}$ =200μA
V_{bT} =250V
R_{aT} =33kΩ
I_a (μA)
V_b =250V
R_{aH} =8.2kΩ
$R_{(g2+4)}$ =22kΩ
$V_{(g2+4)}$ =250V
200V
150V
100V
50V
V_{g1} (V)
−50 −40 −30 −20 −10 0
10 10^2 10^3 10^4


Triode as oscillator; Heptode as mixer
V_b = 250V R_g1 = 1MΩ
R_aH = 8.2kΩ R_aT = 33kΩ
R_(g2+4) = 22kΩ R_(gT+g3) = 47kΩ
7Z06613
S_c (mA/V)
R_i (MΩ)
I_aH I_(g2+4) I_aT (mA)
I_(gT+g3) (μA)
S_c
I_(g2+4)
I_(gT+g3)
I_aT
R_i
I_aH
V_osc (V_rms)

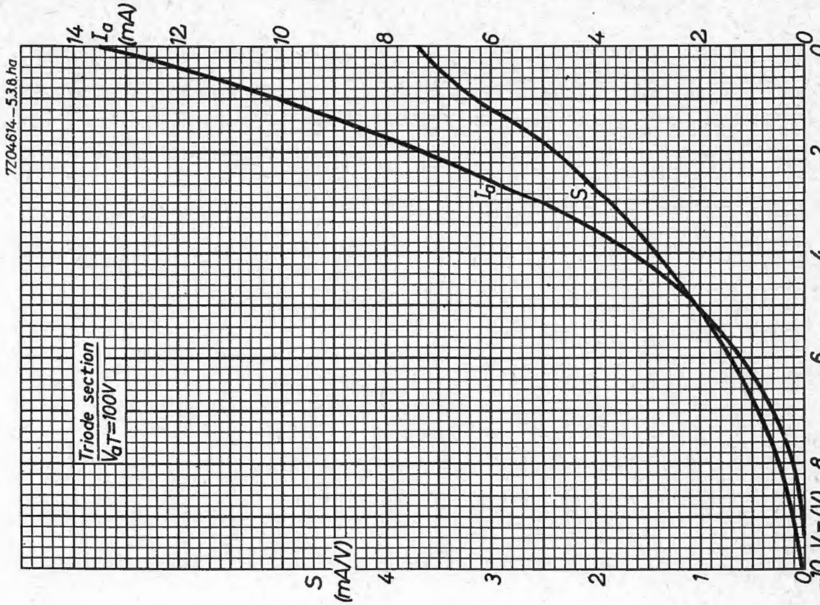

7Z06612-5.3.8.ha
Heptode section as mixer
V_bH = 250V
R_aH = 8.2kΩ
R_(g2+4) = 22kΩ
V_bT = 250V
R_aT = 33kΩ
R_(gT+g3) = 47kΩ
I_(gT+g3) = 200μA
R_i (MΩ)
I_a (μA)
I_(g2+4) (μA)
S_c (μA/V)
I_(g2+4)
I_a
S_c
R_i
V_g1 (V)

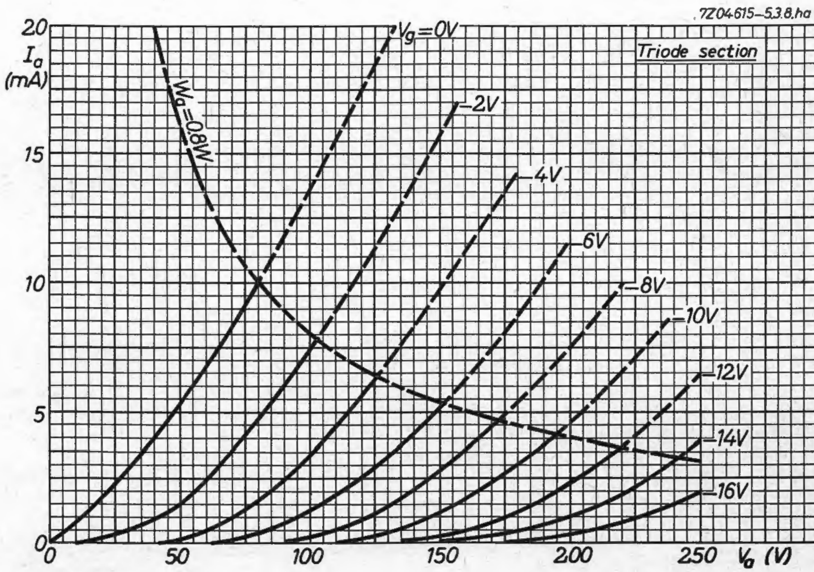

7Z06615-5.38.ha
Heptode section as I.F. amplifier
V_a =250V
V_g3 =0V
S (μA/V)
10^4
10^3
10^2
10
V_b =250V
R_av =8.2kΩ
R_(g2+4) =2.2kΩ
V_g3 =0V
V_(g2+4) =250V
200V
150V
100V
50V
-50
V_g1 (V)
-40
-30
-20
-10
0


7Z06614-5.38.ha
Heptode section as I.F. amplifier
V_a =250V
V_g3 =0V
I_a (μA)
10^5
10^4
10^3
10^2
10
V_b =250V
R_av =8.2kΩ
R_(g2+4) =2.2kΩ
V_g3 =0V
V_(g2+4) =250V
200V
150V
100V
50V
-50
V_g1 (V)
-40
-30
-20
-10
0



7Z06616-5.3.8.ha
Heptode section
V_a =250V
V_{g3} =0V
V_{g1}=0V
–1V
–2V
–4V
–6V
–10V
–15V
–20V
–30V
$R_{(g2+4)}$=22kΩ
$W_{(g2+4)}$=0.8W
$I_{(g2+4)}$ (mA)
8
6
4
2
0
0
50
100
150
200
250
$V_{(g2+4)}$


7Z04614–5.3.8.ha
Triode section
VaT=100V
Ia (mA)
Ia
S
S (mA/V)
VgT (V)


7Z04615–5.3.8.ha
Triode section
Ia (mA)
Wa=0.8W
Vg=0V
–2V
–4V
–6V
–8V
–10V
–12V
–14V
–16V
Va (V)

TRIODE-HEPTODE

Triode-heptode intended for use as mixer in car radio sets and as sync separator in TV receivers.

QUICK REFERENCE DATA					
Triode					
Anode voltage	V_a	25	12.6	6.3	V
Anode current	I_a	2	0.75	0.3	mA
Transconductance	S	2.2	1.4	0.8	mA/V
Amplification factor	μ	20	18.3	14.6	-
Heptode as mixer					
Anode voltage	V_a	25	12.6	6.3	V
Grids No.2 and 4 voltage	V_{g2+4}	25	12.6	6.3	V
Conversion conductance	S_c	450	220	90	μA/V
Heptode as R.F. or I.F. amplifier					
Anode voltage	V_a	25	12.6	6.3	V
Grids No.2 and 4 voltage	V_{g2+4}	25	12.6	6.3	V
Transconductance	S	1.5	0.75	0.35	mA/V

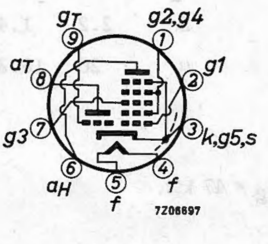
HEATING: Indirect by A.C. or D.C.; parallel or series supply

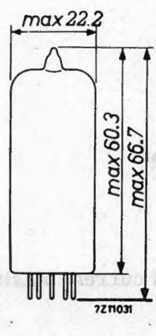
Heater voltage	V_f	6.3	V
Heater current	I_f	300	mA

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





CAPACITANCES

Triode section

Anode to all except grid	$C_{a(g)}$	2.1	pF
Grid to all except anode	$C_{g(a)}$	2.6	pF
Anode to grid	C_{ag}	1.0	pF

Heptode section

Anode to all	C_a	7.9	pF
Grid No.1 to all	C_{g_1}	4.8	pF
Anode to grid No.1	C_{ag_1}	max. 0.012	pF
Grid No.3 to all	C_{g_3}	6.0	pF
Grid No.1 to grid No.3	$C_{g_1g_3}$	max. 0.3	pF

Between heptode and triode sections

Anode heptode to anode triode	C_{aHaT}	0.20	pF
Anode heptode to grid triode	C_{aHgT}	max. 0.09	pF
Grid No.1 heptode to anode triode	C_{g_1HaT}	max. 0.06	pF
Grid No.1 heptode to grid triode	C_{g_1HgT}	max. 0.17	pF
Grid No.1 heptode to grid triode and grid No.3	C_{g_1H/gTg_3}	max. 0.45	pF
Anode heptode to grid triode and grid No.3	C_{aH/gTg_3}	max. 0.35	pF

TYPICAL CHARACTERISTICS

Triode section

Anode voltage	V_a	25	12.6	6.3	V
Grid voltage	V_g	[1]	[1]	[1]	-
Anode current	I_a	2	0.75	0.3	mA
Transconductance	S	2.2	1.4	0.8	mA/V
Amplification factor	μ	20	18.3	14.6	-

[1] Obtained by grid current biasing: R_g = 47 kΩ.

OPERATING CHARACTERISTICS

Heptode as mixer, circuit fig.1.

Anode voltage	V_a	25	12.6	6.3	V
Grids No.2 and 4 voltage	V_{g2+4}	25	12.6	6.3	V
Grid No.1 voltage	V_{g1}	1)	1)	1)	
Oscillator voltage	V_{osc}	3.5	1.7	1.1	V_{RMS}
Grid No.3 resistor	R_{g3}	47	47	47	kΩ
Grid No.3 current	I_{g3}	40	18	7	μA
Anode current	I_a	550	170	50	μA
Grids No.2 and 4 current	I_{g2+4}	1000	300	80	μA
Conversion conductance	S_c	450	220	90	μA/V
Internal resistance	R_i	0.5	1.5	1.3	MΩ

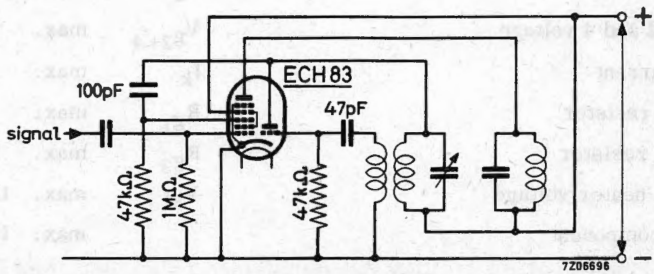


fig.1

Heptode as R.F. or I.F. amplifier

Anode voltage	V_a	25	12.6	6.3	V
Grids No.2, No.3 and No.4 voltage	V_{g2+3+4}	25	12.6	6.3	V
Grid No.1 voltage	V_{g1}	1)	1)	1)	
Anode current	I_a	1.25	0.4	0.11	mA
Grids No.2, No.3 and 4 current	I_{g2+3+4}	0.85	0.25	0.08	mA
Transconductance	S	1.5	0.75	0.35	mA/V
Internal resistance	R_i	0.2	0.85	0.6	MΩ
Equivalent noise resistance	R_{eq}	5	6.5	8.5	kΩ

1) Obtained by grid current biasing: $R_{g1} = 1$ MΩ.

LIMITING VALUES (Design centre rating system)

Triode section

Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	250	V
Anode dissipation	W_a	max.	0.8	W
Cathode current	I_k	max.	6.5	mA
Grid resistor	R_g	max.	3	MΩ
Cathode to heater voltage	V_{kf}	max.	150	V
D.C. component		max.	100	V

Heptode section

Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	50	V
Grids No.2 and 4 voltage	$V_{g_{2+4}}$	max.	50	V
Cathode current	I_k	max.	5	mA
Grid No.1 resistor	R_{g_1}	max.	3	MΩ
Grid No.3 resistor	R_{g_3}	max.	50	kΩ
Cathode to heater voltage	V_{kf}	max.	150	V
D.C. component		max.	100	V

TRIODE-HEPTODE

Triode-heptode intended for use as pulse separator, noise inverter and sync. amplifier.

QUICK REFERENCE DATA

Triode section			
Anode voltage	V_a	50	V
Anode current	I_a	3	mA
Transconductance	S	3.7	mA/V
Amplification factor	μ	50	-
Heptode section			
Anode voltage	V_a	135	V
Grids No.2 and 4 voltage	V_{g2+4}	14	V
Anode current	I_a	1.7	mA
Grids No.2 and 4 current	I_{g2+4}	0.9	mA
Transconductance	S	2.2	mA/V

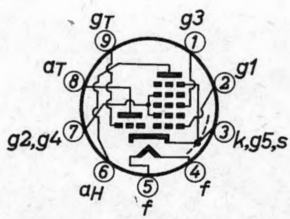
HEATING: Indirect by A.C. or D.C.; series or parallel supply

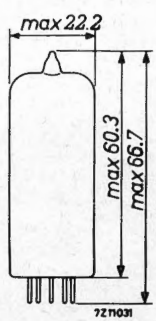
Heater voltage	V_f	6.3	V
Heater current	I_f	300	mA

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





CAPACITANCES

Triode section

Grid to all except anode	$C_{g(a)}$		3.0	pF
Anode to grid	C_{ag}		1.1	pF

Heptode section

Anode to grid No. 1	C_{ag_1}	max.	0.009	pF

Between triode and heptode sections

Grid triode to grid No. 1 heptode	$C_{g_T g_{1H}}$	max.	0.10	pF
Anode triode to grid No. 1 heptode	$C_{a_T g_{1H}}$	max.	0.08	pF
Anode triode to grid No. 3 heptode	$C_{a_T g_{3H}}$	max.	0.13	pF
Grid triode to anode heptode	$C_{g_T a_H}$	max.	0.09	pF
Anode triode to anode heptode	$C_{a_T a_H}$	max.	0.25	pF

TYPICAL CHARACTERISTICS

Triode section

Anode voltage	V_a		50	V
Grid voltage	V_g		0	V
Anode current	I_a		3	mA
Transconductance	S		3.7	mA/V
Amplification factor	μ		50	–
Anode voltage	V_a		200	V
Grid voltage	V_g		-11	V
Anode current	I_a	max.	0.1	mA

TYPICAL CHARACTERISTICS (continued)

Heptode section

Anode voltage	V_a	135	V
Grid No. 3 voltage	V_{g_3}	0	V
Grids No. 2 and 4 voltage	$V_{g_{2+4}}$	14	V
Grid No. 1 voltage	V_{g_1}	0	V
Anode current	I_a	1.7	mA
Grids No. 2 and 4 current	$I_{g_{2+4}}$	0.9	mA
Transconductance	S	2.2	mA/V
Grid No. 3 voltage	V_{g_3}	-2	V
Grid No. 1 voltage	V_{g_1}	0	V
Anode current	I_a	20	μA
Grid No. 1 voltage	V_{g_1}	-1.9	V
Grid No. 3 voltage	V_{g_3}	0	V
Anode current	I_a	20	μA.

LIMITING VALUES (Design centre rating system)

Heptode section

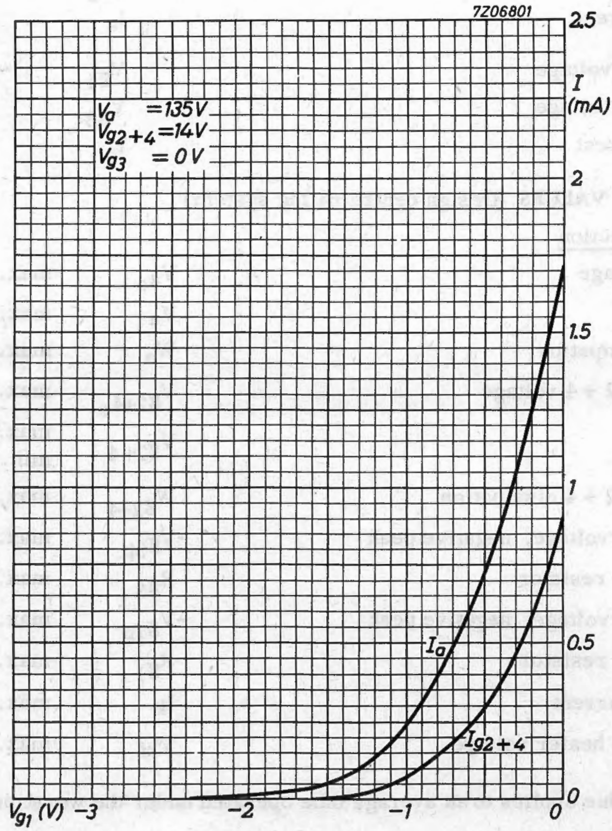
Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	250	V
Anode dissipation	W_a	max.	1.7	W
Grids No. 2 + 4 voltage	$V_{g_{2+4_o}}$	max.	550	V
	$V_{g_{2+4}}$	max.	250	V
		min.	10	V [1])
Grids No. 2 + 4 dissipation	$W_{g_{2+4}}$	max.	0.8	W
Grid No. 3 voltage, negative peak	$-V_{g_{3p}}$	max.	150	V
Grid No. 3 resistor	R_{g_3}	max.	3	MΩ
Grid No. 1 voltage, negative peak	$-V_{g_{1p}}$	max.	150	V
Grid No. 1 resistor	R_{g_1}	max.	3	MΩ
Cathode current	I_k	max.	12.5	mA
Cathode to heater voltage	V_{kf}	max.	100	V

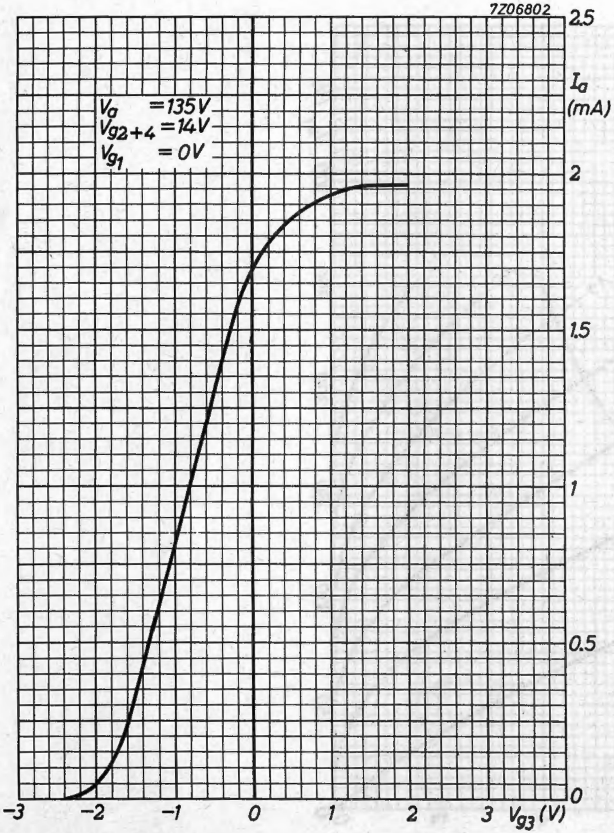
[1]) This value applies to an average tube operated under the worst probable conditions.

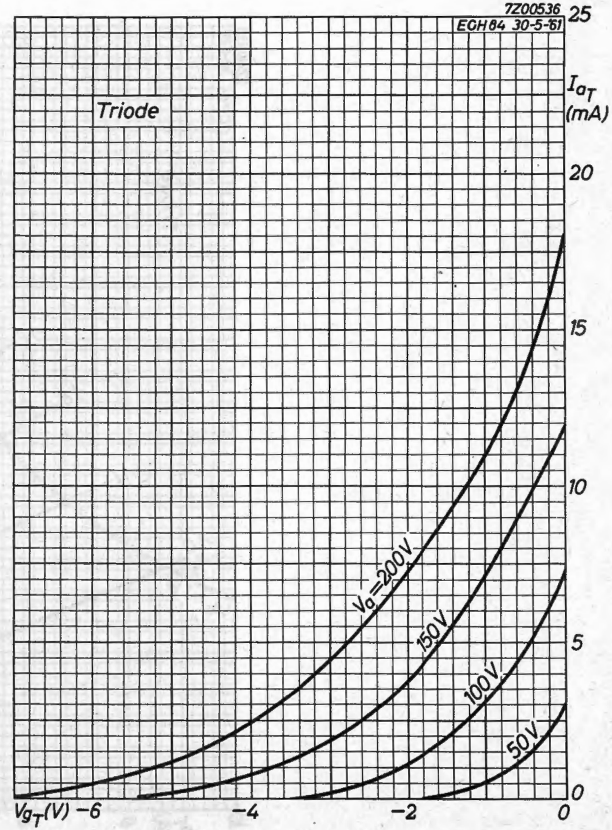
LIMITING VALUES (continued)

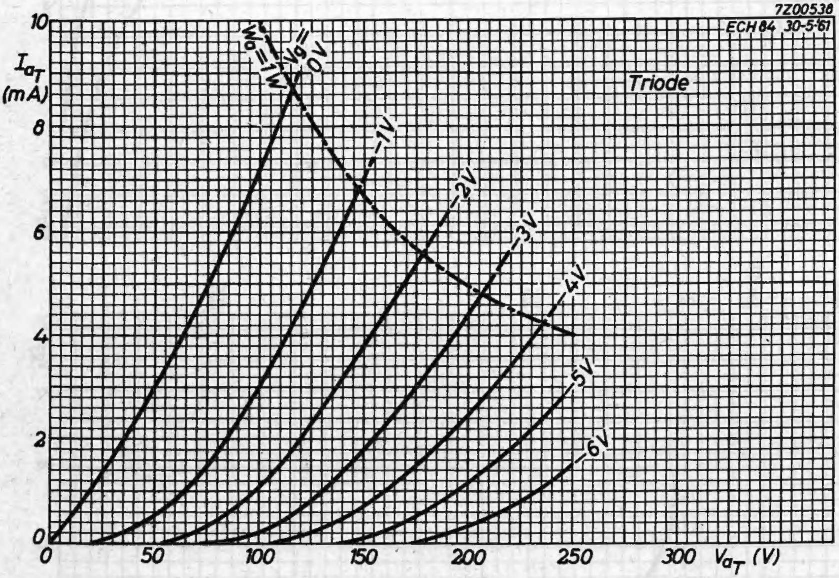
Triode section

Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	250	V
Anode dissipation	W_a	max.	1.3	W
Grid voltage, negative peak	$-V_{g_p}$	max.	200	V
Grid resistor	R_g	max.	3	MΩ
Cathode current	I_k	max.	10	mA
Cathode to heater voltage	V_{kf}	max.	100	V




7Z06802
I_a (mA)
V_a = 135 V
V_{g2+4} = 14 V
V_{g1} = 0 V
0
0.5
1
1.5
2
2.5
−3
−2
−1
0
1
2
3
V_{g3} (V)


7Z00536
ECH84 30-5-'61
I_{aT} (mA)
Triode
V_a=200V
150V
100V
50V
0
5
10
15
20
25
V_{gT} (V)
−6
−4
−2
0


7Z00538
ECH84 30-5-'61
Triode
I_{a_T} (mA)
10
8
6
4
2
0
0
50
100
150
200
250
300
V_{a_T} (V)
$W_a = 1W$
$V_g = 0V$
−1V
−2V
−3V
−4V
−5V
−6V

TRIODE-HEPTODE

Triode-heptode; triode section intended for use as pulse amplifier and heptode section for use as noise gated sync. separator.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	435	mA

LIMITING VALUES (Design centre rating system)

Triode section

Cathode to heater voltage	V_{kf}	max.	100	V

Heptode section

Cathode to heater voltage	V_{kf}	max.	100	V

For further data and curves of this type
please refer to type PCH200

TRIODE-OUTPUT PENTODE

The triode section is intended for use as A.F. pre-amplifier and oscillator. The pentode section is intended for use as synchronizing pulse separator, frame output tube and A.F. power amplifier.

QUICK REFERENCE DATA				
Triode section				
Anode current	I_a		8	mA
Transconductance	S		1.9	mA/V
Amplification factor	μ		20	-
Pentode section				
Anode peak voltage	V_{a_p}	max.	1.2	kV
Anode current	I_a		17.5	mA
Transconductance	S		3.3	mA/V
Amplification factor	$\mu_{g_2g_1}$		14	-
Output power	W_o		1.75	W

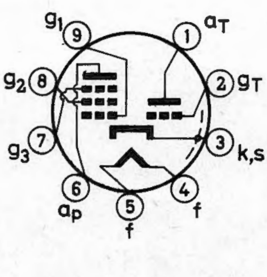
HEATING: Indirect by A.C. or D.C.; parallel or series supply

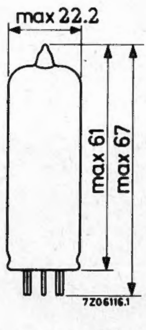
Heater voltage	V_f	6.3	V
Heater current	I_f	300	mA

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





CAPACITANCES

Triode section

Anode to all except grid	$C_{a(g)}$	0.8 pF
Grid to all except anode	$C_{g(a)}$	2.1 pF
Anode to grid	C_{ag}	0.9 pF
Grid to heater	C_{gf}	max. 0.05 pF
Cathode to heater	C_{kf}	3.7 pF

Pentode section

Anode to all except grid No.1	$C_{a(g_1)}$	4.8 pF
Grid No.1 to all except anode	$C_{g_1(a)}$	4.3 pF
Anode to grid No.1	C_{ag_1}	max. 0.2 pF
Grid No.1 to heater	C_{g_1f}	max. 0.25 pF
Cathode to heater	C_{kf}	3.7 pF

Between triode and pentode sections

Anode triode to grid No.1 pentode	C_{aTg_1P}	max. 0.2 pF
Grid triode to anode pentode	C_{gTaP}	max. 0.12 pF
Grid triode to grid No.1 pentode	C_{gTg_1P}	max. 0.2 pF
Anode triode to anode pentode	C_{aTaP}	max. 1.2 pF

TYPICAL CHARACTERISTICS

Triode section

Anode voltage	V_a	100 V
Grid voltage	V_g	0 V
Anode current	I_a	8 mA
Transconductance	S	1.9 mA/V
Amplification factor	μ	20 -

OPERATING CHARACTERISTICS

Triode section

A.F. amplifier

V_b (V)	V_g (V)	R_a (kΩ)	R_{g_1} (kΩ) 1)	I_a (mA)	V_o 2) (V_{RMS})	g	d_{tot} 2) (%)
170	−3.5	47	150	1.8	22	9.5	8.7
170	−3.5	100	330	1.0	24	10	7.6
170	−3.5	220	680	0.5	24	11	6.5
200	−4.2	47	150	2.2	27	9.5	9.0
200	−4.2	100	330	1.2	29	10	8.0
200	−4.2	220	680	0.6	30	11	6.5
250	−5.5	47	150	2.8	36	9.5	9.2
250	−5.5	100	330	1.5	39	10	8.3
250	−5.5	220	680	0.75	40	11	7.0

The triode section can be used without special precautions against microphonic effect in circuits in which the input voltage $V_i \geq 50$ mV for an output of 50 mW of the output tube.

1) Grid leak resistor of the output tube.

2) Output voltage and distortion at start of $+I_g$; at lower output voltages the distortion is reduced proportionally.

OPERATING CHARACTERISTICS (continued)

Pentode section

A.F. power amplifier, class A

Supply voltage	$V_{ba} = V_{bg_2}$	170	200	250	V
Anode voltage	V_a	170	200	250	V
Grid No.3 voltage	V_{g_3}	0	0	0	V
Grid No.2 voltage	V_{g_2}	170	200	-	V
Grid No.2 series resistor	R_{g_2}	0	0	4.7	kΩ
Grid No.1 voltage	V_{g_1}	−6.7	−8	−12.2	V
Anode current	I_a	15	17.5	14	mA
Grid No.2 current	I_{g_2}	2.8	3.3	2.6	mA
Transconductance	S	3.2	3.3	2.6	mA/V
Amplification factor	$\mu_{g_2g_1}$	14	14	14	-
Internal resistance	R_i	0.15	0.15	0.2	MΩ
Load resistance	$R_{a\sim}$	11	11	17.5	kΩ
at d_{tot} = 10 %:					
Grid No.1 driving voltage	V_i	3.7	4.1	5.3	V_{RMS}
Output power	W_o	1.0	1.4	1.55	W
at η = 50 %:					
Grid No.1 driving voltage	V_i	4.4	5.1	5.9	V_{RMS}
Output power	W_o	1.27	1.75	1.75	W
Grid No.1 driving voltage for W_o = 50 mW	V_i	0.7	0.7	0.75	V_{RMS}

OPERATING CHARACTERISTICS (continued)

Synchronizing pulse separator

Anode voltage	V_a		20	V
Grid No.3 voltage	V_{g_3}		0	V
Grid No.2 voltage	V_{g_2}		12	V
Grid No.1 voltage	V_{g_1}	0	−1.45	V
Anode current	I_a	2	0.1	mA

Frame output application

To allow for tube spread and deterioration during life, the circuit should be designed around an anode peak current not exceeding

26 mA at V_a = 50 V, V_{g_2} = 170 V
31 mA at V_a = 60 V, V_{g_2} = 200 V
42 mA at V_a = 70 V, V_{g_2} = 250 V

The anode peak current of a nominal new tube is:

38 mA at V_a = 50 V, V_{g_2} = 170 V, V_{g_1} = −1 V
47 mA at V_a = 60 V, V_{g_2} = 200 V, V_{g_1} = −1 V
62 mA at V_a = 70 V, V_{g_2} = 250 V, V_{g_1} = −1 V

LIMITING VALUES (Design centre rating system)

Triode section

Anode voltage	V_{a_o}	max.	550	V	
	V_a	max.	200	V	
Anode dissipation	W_a	max.	1	W	
Cathode current					
average	I_k	max.	8	mA	
peak	I_{k_p}	max.	200	mA	1)
Grid resistor					
for fixed bias	R_g	max.	1	MΩ	
for automatic bias	R_g	max.	3	MΩ	
Cathode to heater voltage	V_{kf}	max.	150	V	

Pentode section

Anode voltage	V_{a_o}	max.	550	V	
	V_a	max.	400	V	
Anode peak voltage					
positive	V_{a_p}	max.	1200	V	1)
negative	$-V_{a_p}$	max.	500	V	
Grid No.2 voltage	$V_{g_{2o}}$	max.	550	V	
	V_{g_2}	max.	250	V	
Anode dissipation	W_a	max.	3.5	W	
Grid No.2 dissipation	W_{g_2}	max.	1.2	W	
Cathode current					
average	I_k	max.	25	mA	
peak	I_{k_p}	max.	350	mA	1)
Grid No.1 resistor					
for fixed bias	R_{g_1}	max.	1	MΩ	
for automatic bias	R_{g_1}	max.	2	MΩ	
Cathode to heater voltage	V_{kf}	max.	150	V	

1) Valid for application in frame output circuits where the max. pulse duration is 10% of a cycle with a max. of 2 ms.

TRIODE-OUTPUT PENTODE

The triode section is intended for use as frame oscillator and A.F. amplifier. The pentode section is intended for use as frame output tube and A.F. power amplifier.

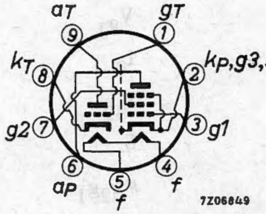
QUICK REFERENCE DATA				
Triode section				
Anode current	I_a		3.5	mA
Transconductance	S		2.2	mA/V
Amplification factor	μ		70	–
Pentode section				
Anode peak voltage	V_{a_p}	max.	2.5	kV
Anode current	I_a		41	mA
Transconductance	S		7.5	mA/V
Amplification factor	$\mu_{g_2g_1}$		9.5	–
Output power	W_o		3.5	W

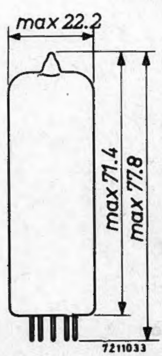
HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	780	mA

DIMENSIONS AND CONNECTIONS — Dimensions in mm

Base: Noval





CAPACITANCES

Triode section

Anode to all except grid	$C_{a(g)}$		4.3	pF
Grid to all except anode	$C_{g(a)}$		2.7	pF
Anode to grid	C_{ag}		4.4	pF
Grid to heater	C_{gf}	max.	0.1	pF

Pentode section

Anode to all except grid No.1	$C_{a(g_1)}$		8.0	pF
Grid No.1 to all except anode	$C_{g_1(a)}$		9.3	pF
Anode to grid No.1	C_{ag_1}	max.	0.3	pF
Grid No.1 to heater	C_{g_1f}	max.	0.3	pF

Between triode and pentode sections

Anode triode to grid No.1 pentode	C_{aTg_1P}	max.	0.02	pF
Grid triode to anode pentode	C_{gTaP}	max.	0.02	pF
Grid triode to grid No.1 pentode	C_{gTg_1P}	max.	0.025	pF
Anode triode to anode pentode	C_{aTaP}	max.	0.25	pF

TYPICAL CHARACTERISTICS

Triode section

Anode voltage	V_a	100	V
Grid voltage	V_g	0	V
Anode current	I_a	3.5	mA
Transconductance	S	2.2	mA/V
Amplification factor	μ	70	-

Pentode section

Anode voltage	V_a	170	V
Grid No.2 voltage	V_{g2}	170	V
Grid No.1 voltage	V_{g1}	-11.5	V
Anode current	I_a	41	mA
Grid No.2 current	I_{g2}	9	mA
Transconductance	S	7.5	mA/V
Amplification factor	$\mu_{g_2g_1}$	9.5	-
Internal resistance	R_i	16	kΩ

OPERATING CHARACTERISTICS

Triode section as A.F. amplifier

A. Signal source resistance	R_s	0.22			MΩ
Grid resistor	R_g	3			MΩ
Grid resistor of next stage	R_g	0.68			MΩ
Supply voltage	V_b	200	170		V
Cathode resistor	R_k	2.2	2.7		kΩ
Anode resistor	R_a	220	220		kΩ
Anode current	I_a	0.52	0.43		mA
Voltage gain	V_o/V_i 1)	52	51		-
Max. output voltage	$V_{o\,max}$	26	25		V_{RMS}
Distortion	d_{tot} 2)	1.6	2.3		%

B. Signal source resistance	R_s	0.22				MΩ
Grid resistor	R_g	22				MΩ
Grid resistor of next stage	R_g'	0.68				MΩ
Supply voltage	V_b	200	200	170	170	V
Cathode resistor	R_k	0	0	0	0	Ω
Anode resistor	R_a	100	220	100	220	kΩ
Anode current	I_a	1.05	0.61	0.86	0.50	MΩ
Voltage gain	V_o/V_i 1)	50	55	49	53	-
Max. output voltage	$V_{o\,max}$	24	25	19	20	V_{RMS}
Distortion	d_{tot} 3)	1.5	1.4	1.4	1.4	%

MICROPHONY AND HUM

The triode section can be used without special precautions against microphony and hum in circuits in which an input voltage of minimum 10 mV_{RMS} is required for an output of 50 mW of the output stage. Z_g(50 Hz) = 0.25 MΩ.

1) Measured at small input voltage.
2) At lower output voltages the distortion is proportionnally lower.
3) At lower output voltages down to 5 V_{RMS} the distortion is approximately constant. At values below 5 V_{RMS} the distortion is approximately proportional to V_o.

OPERATING CHARACTERISTICS

Pentode section

A.F. power amplifier, class A (measured with V_k constant)

Supply voltage	$V_{ba} = V_{bg2}$		200			272		V
Grid No.2 series resistor (non-decoupled)	R_{g2}		470			2200		Ω
Cathode resistor	R_k		330			650		Ω
Load resistance	$R_{a\sim}$		4.5			8		kΩ
Grid No.1 driving voltage	V_i	0	0.66	6.7	0	0.9	9.5	V_{RMS}
Anode current	I_a	35		37	28		27	mA
Grid No.2 current	I_{g2}	7.8		13.3	6.5		10.8	mA
Output power	W_o	0	0.05	3.3	0	0.05	3.5	W
Distortion	d_{tot}	-	-	10	-	-	10	%

A.F. power amplifier, class AB, two tubes in push-pull

Anode supply voltage	V_{ba}	200		250		V
Grid No.2 supply voltage	V_{bg2}	200		200		V
Common cathode resistor	R_k	170		220		Ω
Load resistance	$R_{aa'\sim}$	4.5		10		kΩ
Grid No.1 driving voltage	V_i	0	14.2	0	12.5	V_{RMS}
Anode current	I_a	2x35	2x42.5	2x28	2x31	mA
Grid No.2 current	I_{g2}	2x8	2x16.5	2x5.8	2x13	mA
Output power	W_o	0	9.3	0	10.5	W
Distortion	d_{tot}	-	6.3	-	4.8	%

Frame output application

The circuit should operate satisfactorily with a peak anode current I_{ap} = 85 mA at V_a = 50 V, V_{g2} = 170 V, V_f = 6.3 V. The minimum available I_{ap} at end of life is;

70 mA at V_a = 50 V, V_{g2} = 170 V, V_f = 5.5 V
80 mA at V_a = 50 V, V_{g2} = 190 V. V_f = 5.5 V.

LIMITING VALUES (Design centre rating system)

Triode section

Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	300	V
Anode peak voltage	V_{a_p}	max.	600	V 1)
Anode dissipation	W_a	max.	1	W
Cathode current, average	I_k	max.	15	mA
peak	I_{k_p}	max.	100	mA 1)
Grid resistor for fixed bias	R_g	max.	1	MΩ
for automatic bias	R_g	max.	3	MΩ
Grid impedance at 50 Hz	Z_g	max.	0.5	MΩ
Cathode to heater voltage	V_{kf}	max.	100	V

Pentode section

Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	300	V
Anode peak voltage, positive	V_{a_p}	max.	2.5	kV 1)
negative	$-V_{a_p}$	max.	500	V
Anode dissipation for frame ouput application	W_a	max.	5	W
for A.F. output application	W_a	max.	7	W
Grid No.2 voltage	$V_{g_{2o}}$	max.	550	V
	V_{g_2}	max.	300	V
Grid No.2 dissipation, average	W_{g_2}	max.	2	W
peak	$W_{g_{2p}}$	max.	3.2	W
Cathode current	I_k	max.	50	mA
Grid No.1 resistor for fixed bias	R_{g_1}	max.	1	MΩ
for automatic bias	R_{g_1}	max.	2	MΩ
Cathode to heater voltage	V_{kf}	max.	150	V

For curves of the ECL82 please refer to PCL82

1) Max. pulse duration 4% of a cycle with a maximum of 0.8 msec.

TRIODE-OUTPUT PENTODE

Triode-pentode with separate cathodes
The triode section is intended for use in circuits for keyed AGC, sync separation, sync amplification and noise suppression.
The pentode section is intended for use as video output tube.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	720	mA

LIMITING VALUES (Design centre rating system)

Triode section

Cathode to heater voltage	V_{kf}	max.	200	V

For further data and curves
please refer to PCL84

TRIODE-OUTPUT PENTODE

Triode pentode with separate cathodes.
Triode intended for use as frame oscillator or pulse amplifier.
Pentode intended for use as frame output tube.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	875	mA

OPERATING CHARACTERISTICS OF THE PENTODE SECTION

Hum

The equivalent pentode grid hum voltage without negative feedback and without A.C. voltage between heater and cathode is max. 10 mV_{RMS} when Z_{g_1} (at f = 50 Hz) $\leq$ 0.5 MΩ and C_{g_1-f} = 0.2 pF.

LIMITING VALUES (Design centre rating system)

Triode section

Cathode to heater voltage	V_{kf}	max.	100	V
D.C. component during warming up	V_{kf} (k pos)	max.	315	V

Pentode section

Cathode to heater voltage	V_{kf}	max.	100	V

For further data and curves
please refer to PCL85/PCL805

TRIODE–OUTPUT PENTODE

Triode pentode with separate cathodes.
The triode section is intended for use as A.F. amplifier.
The pentode section is intended for use as A.F. power amplifier.

QUICK REFERENCE DATA			
Triode section			
Anode current	I_a	1.2	mA
Transconductance	S	1.6	mA/V
Amplification factor	μ	100	-
Pentode section			
Anode current	I_a	36	mA
Transconductance	S	10	mA/V
Amplification factor	$\mu_{g_2 g_1}$	21	-
Output power	W_o	4.0	W

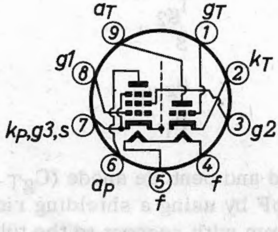
HEATING: Indirect by A.C. or D.C.; parallel supply

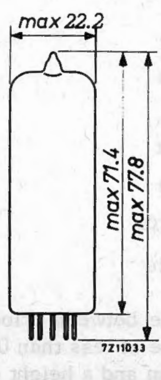
Heater voltage	V_f	6.3	V
Heater current	I_f	660	mA

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





CAPACITANCES

Triode section			
Anode to all except grid	$C_{a(g)}$	2.5	pF
Grid to all except anode	$C_{g(a)}$	2.3	pF
Anode to grid	C_{ag}	1.4	pF
Grid to heater	C_{gf}	max. 0.006	pF
Pentode section			
Grid No.1 to all except anode	$C_{g_1(a)}$	10	pF
Anode to grid No.1	C_{ag_1}	max. 0.4	pF
Grid No.1 to heater	C_{g_1f}	max. 0.24	pF
Between triode and pentode sections			
Anode triode to grid No.1 pentode	C_{aTg_1P}	max. 0.2	pF
Grid triode to grid No.1 pentode	C_{gTg_1P}	max. 0.02	pF
Anode triode to anode pentode	C_{aTaP}	max. 0.15	pF
Grid triode to anode pentode	C_{gTaP}	max. 0.006	pF [1])

TYPICAL CHARACTERISTICS

Triode section			
Anode voltage	V_a	250	V
Grid voltage	V_g	-1.9	V
Anode current	I_a	1.2	mA
Transconductance	S	1.6	mA/V
Amplification factor	μ	100	-
Pentode section			
Anode voltage	V_a	250	V
Grid No.2 voltage	V_{g_2}	250	V
Grid No.1 voltage	V_{g_1}	-7	V
Anode current	I_a	36	mA
Grid No.2 current	I_{g_2}	6	mA
Transconductance	S	10	mA/V
Amplification factor	$\mu_{g_2g_1}$	21	-
Internal resistance	R_i	48	kΩ

[1]) The capacitance between triode grid and pentode anode (C_{gT-aP}) can be reduced to a value of less than 0.002 pF by using a shielding ring with a diameter of 22.5 mm and a height of 15 mm with respect to the tube base.

OPERATING CHARACTERISTICS

Triode section

as A.F. amplifier

Supply voltage	V_b	200	250	250	300	V
Cathode resistor	R_k	2.6	1.75	1.75	1.2	kΩ
Anode resistor	R_a	220	220	220	220	kΩ
Grid resistor of following stage	$R_{g'}$	0.68	0.68	10	10	MΩ
Anode current	I_a	0.42	0.6	0.6	0.8	mA
Output voltage	V_o	3.2	3.2	5	9	V_{RMS}
Voltage gain	V_o/V_i	66	70	75	80	-
Distortion	d_{tot}	0.6	0.4	0.4	0.4	%

A.F. amplifier with grid current biasing

Supply voltage	V_b	200	250	250	300	V
Cathode resistor	R_k	0	0	0	0	Ω
Anode resistor	R_a	220	220	220	220	kΩ
Grid resistor	R_g	10	10	10	10	MΩ
Grid resistor of following stage	$R_{g'}$	0.68	0.68	10	10	MΩ
Signal source resistance	R_s	47	47	47	47	kΩ
Anode current	I_a	0.42	0.6	0.6	0.8	mA
Output voltage	V_o	3.2	3.2	5	9	V_{RMS}
Voltage gain	V_o/V_i	66	70	75	80	-
Distortion	d_{tot}	0.6	0.4	0.4	0.4	%

MICROPHONY

The triode section can be used without special precautions against microphonic effect in circuits in which an output of 50 mW is obtained at an input voltage of not less than 4 mV_{RMS}.

HUM

The hum level will be better than 60 dB under the following conditions:
Input voltage minimum 10 mV_{RMS} for 50 mW output.
Grid circuit impedance max. 0.5 MΩ at 50 Hz.
Cathode decoupling capacitor minimum 100 μF.
Pin 4 connected to earth.

OPERATING CHARACTERISTICS (continued)

Pentode section

Class A (Measured with V_k constant)

Anode voltage	V_a		250			250		V
Grid No.2 voltage	V_{g2}		250			250		V
Cathode resistor	R_k		170			270		Ω
Load resistance	$R_{a\sim}$		7			10		kΩ
Grid No.1 driving voltage	V_i	0	0.3	3.2	0	0.28	2.7	V_{RMS}
Anode current	I_a	36	-	37	26	-	27	mA
Grid No.2 current	I_{g2}	6	-	10.2	4.4	-	8.0	mA
Output power	W_o	0	0.05	4.0	0	0.05	2.8	W
Distortion	d_{tot}	-	0.95	10	-	1.1	10	%

Class AB, two tubes in push-pull

Supply voltage	V_b		250			300		V
Common cathode resistor	R_k		90			130		Ω
Load resistance	$R_{aa\sim}$		8.2			9.1		kΩ
Grid No.1 driving voltage	V_i	0	0.24	5.5	0	0.26	8.4	V_{RMS}
Anode current	I_a	2x32.5	-	2x35.5	2x31	-	2x36.5	mA
Grid No.2 current	I_{g2}	2x5.6	-	2x8.9	2x5.5	-	2x11	mA
Output power	W_o	0	0.05	10	0	0.05	13.6	W
Distortion	d_{tot}	-	<0.4	5.0	-	<0.4	4.0	%

LIMITING VALUES (Design centre rating system)

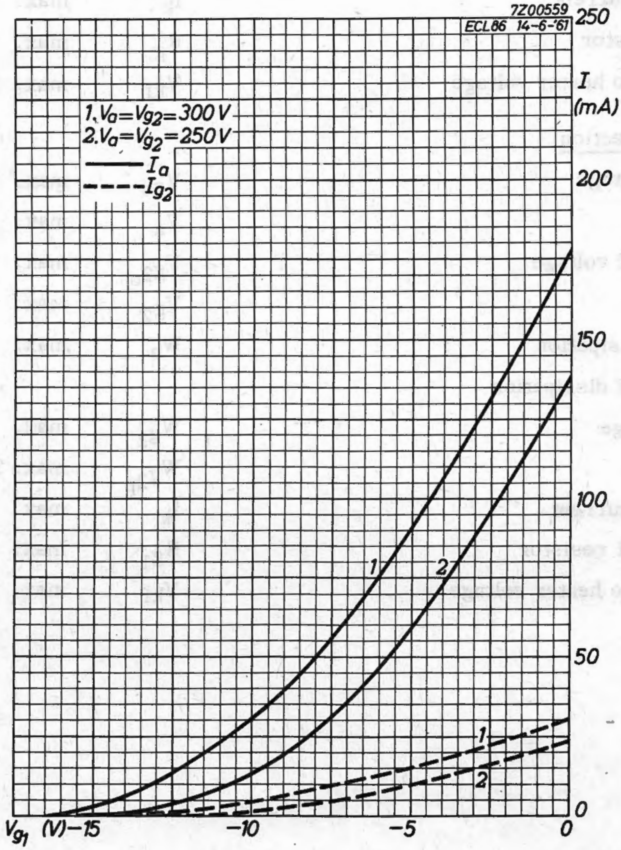
Triode section

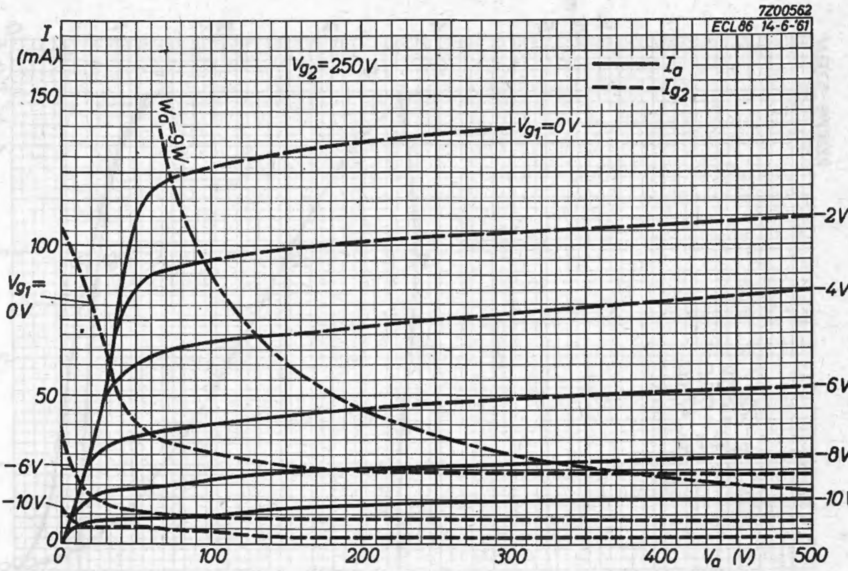
Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	300	V
Anode dissipation	W_a	max.	0.5	W
Cathode current	I_k	max.	4	mA
Grid resistor	R_g	max.	1	MΩ [1]
Cathode to heater voltage	V_{kf}	max.	100	V

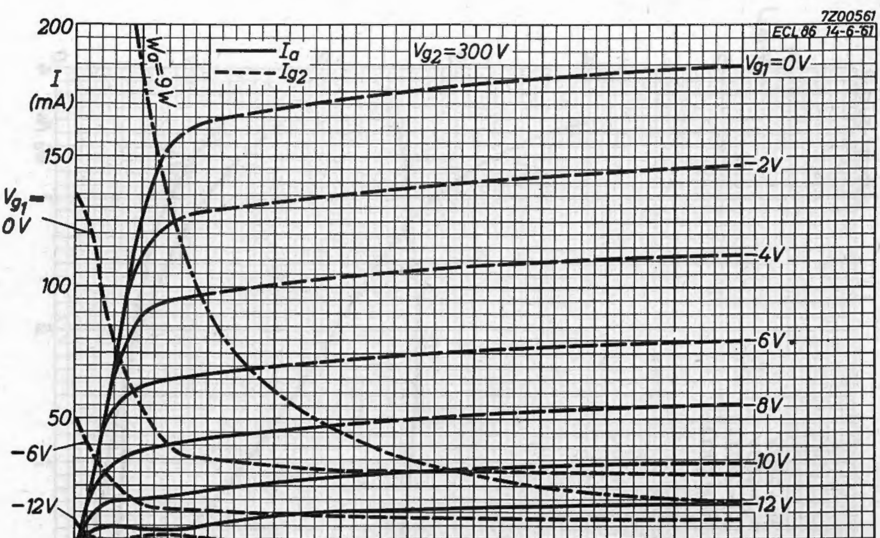
Pentode section

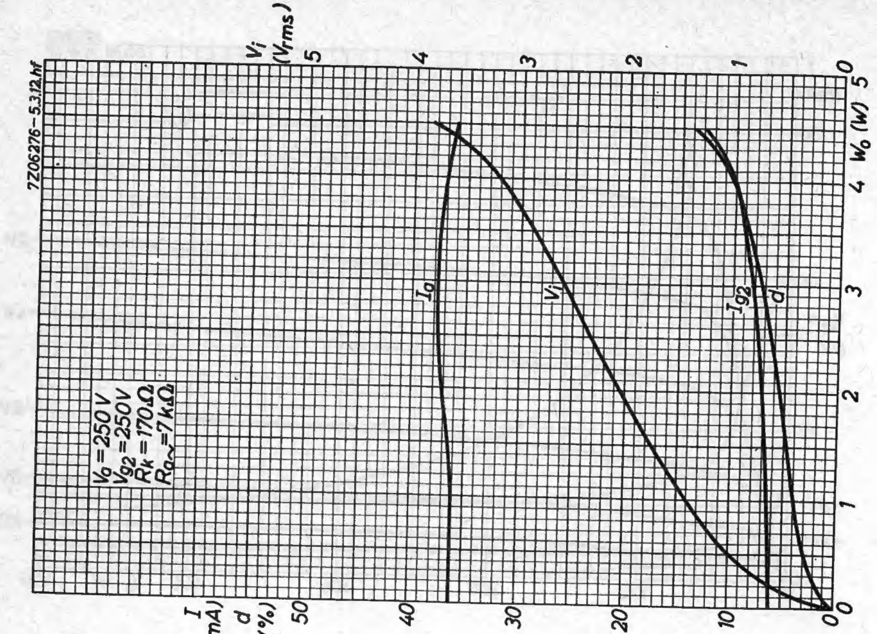
Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	300	V
Grid No.2 voltage	$V_{g_{2o}}$	max.	550	V
	V_{g_2}	max.	300	V
Anode dissipation	W_a	max.	9	W
Grid No.2 dissipation				
average	W_{g_2}	max.	1.8	W
peak	$W_{g_{2p}}$	max.	3.25	W
Cathode current	I_k	max.	55	mA
Grid No.1 resistor	R_{g_1}	max.	0.5	MΩ [1]
Cathode to heater voltage	V_{kf}	max.	100	V

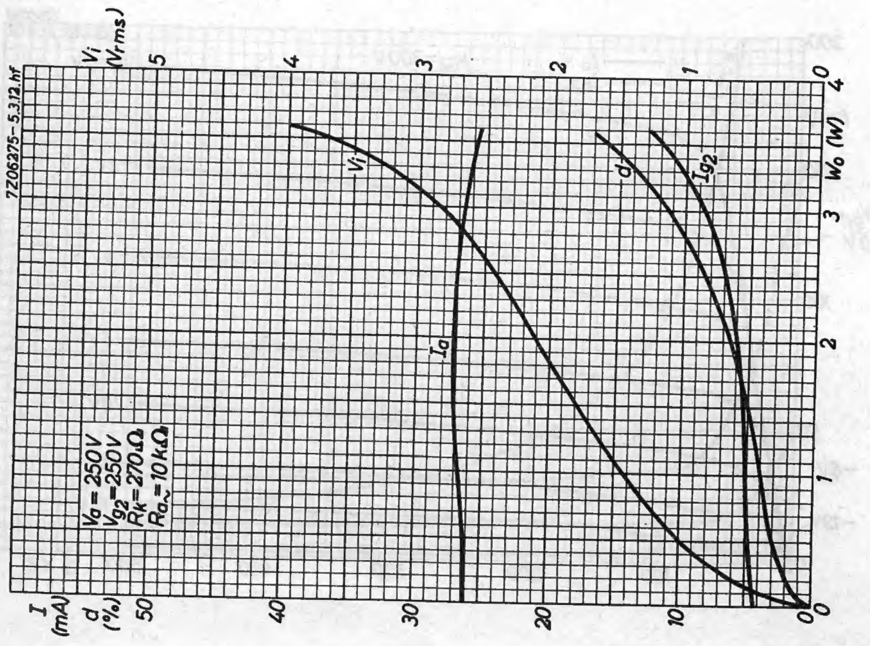
[1]) This value applies to operation with fixed bias. It may be multiplied by the D.C. inverse feedback factor resulting from e.g. cathode, screen grid or anode resistors, to a maximum of 10 MΩ.

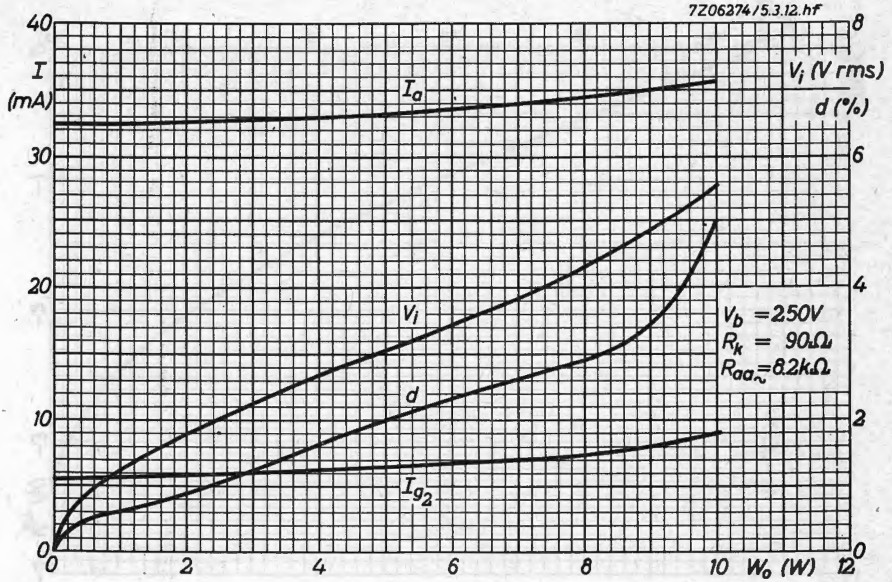

7Z00559
ECL86 14-6-'61
1. $V_a = V_{g2} = 300$ V
2. $V_a = V_{g2} = 250$ V
I_a
I_{g2}
I
(mA)
250
200
150
100
50
0
1
2
1
2
V_{g1} (V) −15
−10
−5
0

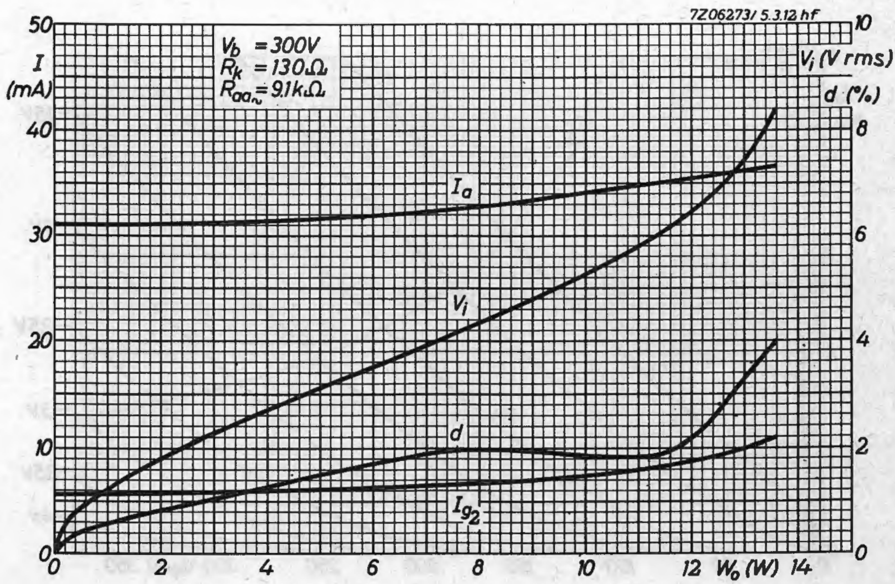

7Z00562
ECL86 14-6-'61
I
(mA)
V_{g2}=250V
I_a
I_{g2}
W_a=9W
V_{g1}=0V
-2V
-4V
-6V
-8V
-10V
V_{g1}=
0V
-6V
-10V
150
100
50
0
100
200
300
400
V_a (V)
500

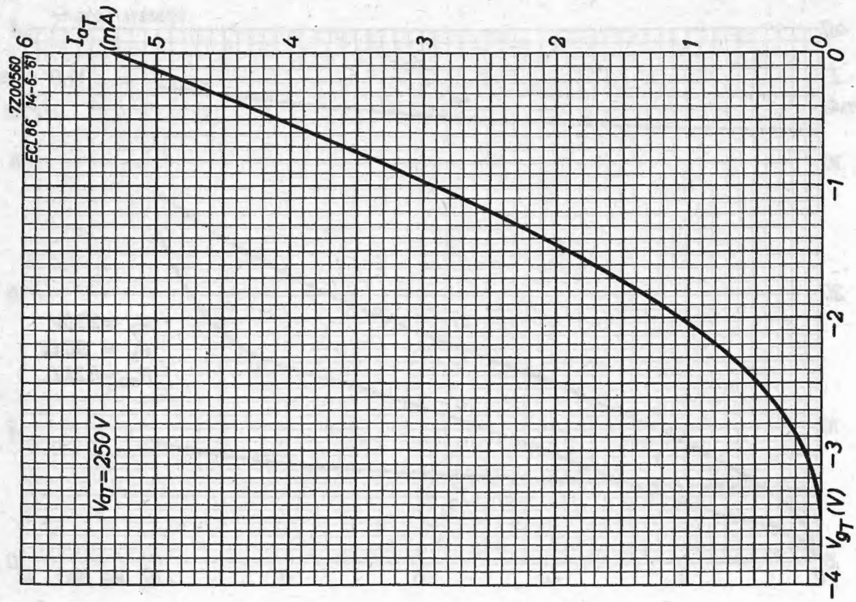

7Z00561
ECL86 14-6-'61
200
I
(mA)
I_a
I_{g2}
W_a=9W
V_{g2}=300V
V_{g1}=0V
-2V
-4V
-6V
-8V
-10V
-12V
V_{g1}=
0V
-6V
-12V
150
100
50
0
100
200
300
400
500
V_a (V)

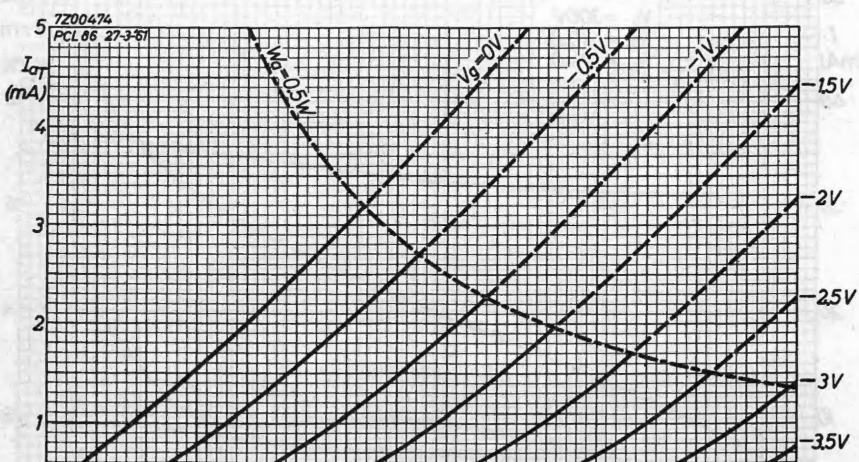

7Z06276-5.3.12.hf
$V_a = 250\,V$
$V_{g2} = 250\,V$
$R_k = 170\,\Omega$
$R_{a\sim} = 7\,k\Omega$
I (mA)
d (%)
V_i (V_{rms})
W_o (W)
I_a
V_i
I_{g2}
d


7Z06275-5.3.12.hf
$V_a = 250\,V$
$V_{g2} = 250\,V$
$R_k = 270\,\Omega$
$R_{a\sim} = 10\,k\Omega$
I (mA)
d (%)
V_i (V_{rms})
W_o (W)
I_a
V_i
I_{g2}
d


7Z06274/5.3.12.hf
I
(mA)
V_i (V rms)
d (%)
I_a
V_i
d
I_{g_2}
V_b = 250V
R_k = 90Ω
$R_{aa\sim}$ = 8.2kΩ
W_o (W)


7Z06273/5.3.12.hf
I
(mA)
V_b = 300V
R_k = 130Ω
$R_{aa\sim}$ = 9.1kΩ
V_i (V rms)
d (%)
I_a
V_i
d
I_{g_2}
W_o (W)


7Z00560
ECL86 14-6-'61
I_{aT} (mA)
V_{aT} = 250 V
V_{gT} (V)
6 5 4 3 2 1 0
0 −1 −2 −3 −4


7Z00474
PCL86 27-3-'61
I_{aT} (mA)
W_a=0.5W
V_g=0V
−0.5V
−1V
−1.5V
−2V
−2.5V
−3V
−3.5V
−4V
0 1 2 3 4 5
0 50 100 150 200 250 300 350
V_{aT}(V)

SHUNT STABILIZER TRIODE

Shunt stabilizer triode intended for use as in colour TV receivers.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	350	mA

For further data and curve of this type please refer to type PD500

A.F. PENTODE

Pentode intended for use as A.F. amplifier.

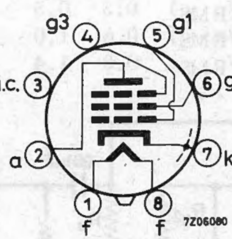
QUICK REFERENCE DATA			
Anode current	I_a	3.0	mA
Transconductance	S	1.85	mA/V
Amplification factor	$\mu_{g_2g_1}$	38	-
Internal resistance	R_i	2.5	MΩ

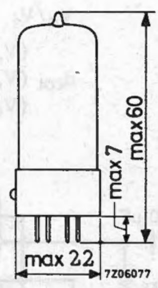
HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	200	mA

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Rimlock





CAPACITANCES

Grid No.1 to all except anode	$C_{g_1(a)}$		4.5	pF
Anode to all except grid No.1	$C_{a(g_1)}$		5.2	pF
Anode to grid No.1	C_{ag_1}	max.	0.04	pF
Grid No.1 to heater	C_{g_1f}	max.	0.002	pF

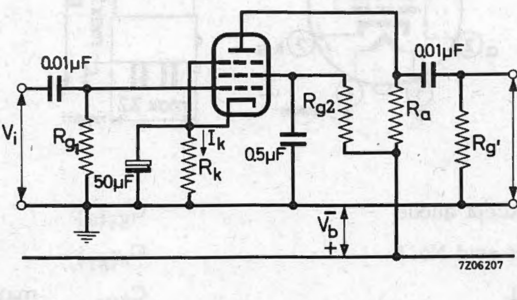
TYPICAL CHARACTERISTICS

Anode voltage	V_a	250	V
Grid No.3 voltage	V_{g3}	0	V
Grid No.2 voltage	V_{g2}	140	V
Grid No.1 voltage	V_{g1}	-2	V
Anode current	I_a	3.0	mA
Grid No.2 current	I_{g2}	0.55	mA
Transconductance	S	1.85	mA/V
Amplification factor	$\mu_{g_2g_1}$	38	-
Internal resistance	R_i	2.5	MΩ
Equivalent noise resistance (A.F.)	$R_{eq(A.F.)}$	40	kΩ

OPERATING CHARACTERISTICS

As A.F. amplifier

Supply voltage	V_b	250	250	250	100	V
Anode resistor	R_a	0.1	0.22	0.22	0.22	MΩ
Grid No.2 resistor	R_{g2}	0.39	1.0	1.2	1.2	MΩ
Grid No.1 resistor	R_{g1}	1	1	10	10	MΩ
Grid resistor next stage	$R_{g'}$	0.33	0.68	0.68	0.68	MΩ
Cathode resistor	R_k	1000	2200	0	0	Ω
Cathode current	I_k	2.05	0.95	1.07	0.36	mA
Voltage gain	V_o/V_i	112	180	200	130	-
	(V_o= 4 V_{RMS})	0.3	0.5	<1	1.2	%
Total distortion	d_{tot} (V_o= 8 V_{RMS})	0.6	1.0	<1	1.8	%
	(V_o=12 V_{RMS})	0.8	1.4	<1	3.0	%



This tube can be used without special precautions against microphonic effect in amplifiers in which the input voltage $V_i \geq 5$ mV for maximum output of the output tube and in receivers in which $V_i \geq 0.5$ mV for an output of 50 mW.

LIMITING VALUES (Design centre rating system)

Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	300	V
Anode dissipation	W_a	max.	1	W
Grid No.2 voltage	$V_{g_{2o}}$	max.	550	V
	V_{g_2}	max.	200	V
Grid No.2 dissipation	W_{g_2}	max.	0.2	W
Cathode current	I_k	max.	6	mA
Grid No.1 resistor	R_{g_1} ($W_a < 0.2$ W)	max.	10	MΩ
	R_{g_1} ($W_a > 0.2$ W)	max.	3	MΩ

R.F. PENTODE

Pentode with variable transconductance intended for use as R.F. and I.F. amplifier.

QUICK REFERENCE DATA			
Anode current	I_a	6.0	mA
Transconductance	S	2.2	mA/V
Amplification factor	$\mu_{g_2g_1}$	18	
Internal resistance	R_i	1.1	MΩ

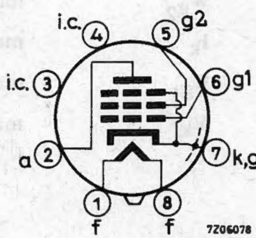
HEATING: Indirect by A.C. or D.C.; parallel supply

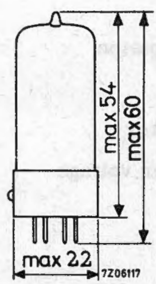
Heater voltage	V_f	6.3	V
Heater current	I_f	200	mA

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Rimlock





CAPACITANCES

Anode to all except grid No.1	$C_{a(g_1)}$		5.9	pF
Grid No.1 to all except anode	$C_{g_1(a)}$		5.3	pF
Anode to grid No.1	C_{ag_1}	max.	0.002	pF
Grid No.1 to heater	C_{g_1f}	max.	0.05	pF

TYPICAL CHARACTERISTICS AND OPERATING CONDITIONS

Anode voltage; supply voltage	V_a, V_b		250	V
Grid No.2 resistor	R_{g_2}		90	kΩ
Cathode resistor	R_k		325	Ω
Grid No.1 voltage	V_{g_1}	-2.5	-39	V
Anode current	I_a	6.0	-	mA
Grid No.2 current	I_{g_2}	1.7	-	mA
Transconductance	S	2200	22	μA/V
Internal resistance	R_i	1.1	min. 10	MΩ
Amplification factor	$\mu_{g_2g_1}$	18	-	
Equivalent noise resistance	R_{eq}	6.5	-	kΩ

LIMITING VALUES (Design centre rating system)

Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	300	V
Anode dissipation	W_a	max.	2	W
Grid No.2 voltage	$V_{g_{2o}}$	max.	550	V
	V_{g_2} ($I_a < 3$ mA)	max.	300	V
	V_{g_2} ($I_a = 6$ mA)	max.	125	V
Grid No.2 dissipation	W_{g_2}	max.	0.3	W
Cathode current	I_k	max.	10	mA
Grid No.1 resistor	R_{g_1}	max.	3	MΩ
Cathode to heater voltage	V_{kf}	max.	100	V

R.F. PENTODE

Pentode intended for use as wide-band amplifier.

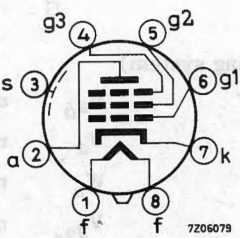
QUICK REFERENCE DATA			
Anode current	I_a	10	mA
Transconductance	S	9	mA/V
Amplification factor	μ_{g2g1}	83	
Internal resistance	R_i	500	kΩ

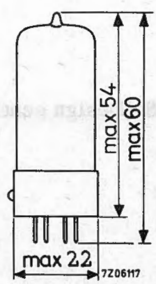
HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	330	mA

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Rimlock





CAPACITANCES

Anode to all except grid No.1	$C_{a(g_1)}$	4.3	pF
Grid No.1 to all except anode	$C_{g_1(a)}$	8.5	pF
Anode to grid No.1	C_{ag_1}	max. 0.006	pF
Grid No.1 to heater	C_{g_1f}	max. 0.2	pF

TYPICAL CHARACTERISTICS

Anode voltage	V_a	250	V
Grid No.3 voltage	V_{g3}	0	V
Grid No.2 voltage	V_{g2}	250	V
Grid No.1 voltage	V_{g1}	-2	V
Anode current	I_a	10	mA
Grid No.2 current	I_{g2}	2.4	mA
Transconductance	S	9	mA/V
Amplification factor	μ_{g2g1}	83	
Internal resistance	R_i	500	kΩ
Equivalent noise resistance	R_{eq}	840	Ω

OPERATING CHARACTERISTICS

Anode voltage	V_a	250	V
Grid No.3 voltage	V_{g3}	0	V
Grid No.2 voltage	V_{g2}	250	V
Anode current	I_a	10	mA
Frequency	f	100	MHz
Bandwidth	B	0.8	MHz
Gain	G	1100	

LIMITING VALUES (Design centre rating system)

Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	300	V
Anode dissipation	W_a	max.	3.5	W
Grid No.2 voltage	V_{g2_o}	max.	550	V
	V_{g2}	max.	300	V
Grid No.2 dissipation	W_{g2}	max.	0.7	W
Cathode current	I_k	max.	25	mA
Grid No.1 voltage	$-V_{g1}$	max.	100	V
Grid No.1 resistor (automatic bias)	R_{g1}	max.	1	MΩ
Cathode to heater voltage	V_{kf}	max.	100	V

R.F. PENTODE

Pentode with variable transconductance intended for use as wide-band amplifier.

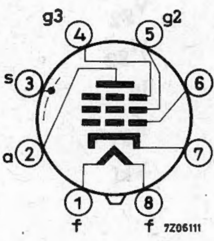
QUICK REFERENCE DATA			
Anode current	I_a	15	mA
Transconductance	S	6.4	mA/V
Internal resistance	R_i	500	kΩ

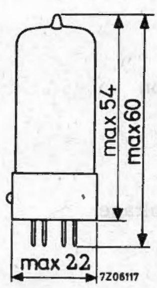
HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	330	mA

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Rimlock





CAPACITANCES

Anode to all except grid No.1	$C_{a(g_1)}$	4.5	pF
Grid No.1 to all except anode	$C_{g_1(a)}$	9.5	pF
Anode to grid No.1	C_{ag_1}	max. 0.006	pF
Grid No.1 to heater	C_{g_1f}	max. 0.2	pF

TYPICAL CHARACTERISTICS AND OPERATING CHARACTERISTICS

Anode voltage, supply voltage	V_a, V_b	250		V
Grid No. 3 voltage	V_{g3}	0		V
Grid No. 2 resistor	R_{g2}	33		kΩ
Cathode resistor	R_k	105		Ω
Grid No. 1 voltage	V_{g1}	-2	-28	V
Grid No. 2 voltage	V_{g2}	135	-	V_g
Anode current	I_a	15	-	mA
Grid No. 2 current	I_{g2}	3.5	-	mA
Transconductance	S	6400	64	μA/V
Internal resistance	R_i	500	-	kΩ
Equivalent noise resistance	R_{eq}	1.7	-	kΩ

LIMITING VALUES (Design centre rating system)

Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	300	V
Anode dissipation	W_a	max.	3.75	W
Grid No. 2 voltage	V_{g2_o}	max.	550	V
	V_{g2}	max.	250	V
Grid No. 2 dissipation	W_{g2}	max.	0.7	W
Cathode current	I_k	max.	20	mA
Grid resistor	R_{g1}	max.	1	MΩ
Cathode to heater voltage	V_{kf}	max.	100	V

R.F. PENTODE

Pentode intended for use as R.F., I.F. or video amplifying tube or as mixing tube in television receivers.

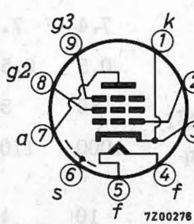
QUICK REFERENCE DATA			
Anode current	I_a	10	mA
Transconductance	S	7.4	mA/V
Amplification factor	$\mu_{g_2g_1}$	50	-
Internal resistance	R_i	500	kΩ

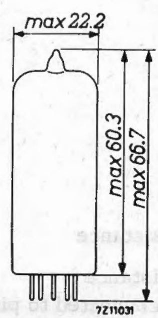
HEATING: Indirect by A.C. or D.C.; series or parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	300	mA

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Noval





CAPACITANCES

Grid No.1 to all except anode	$C_{g_1(a)}$	6.9	pF
Anode to all except grid No.1	$C_{a(g_1)}$	3.1	pF
Anode to grid No.1	C_{ag_1}	max. 0.007	pF
Anode to cathode	C_{ak}	max. 0.012	pF
Grid No.2 to all	C_{g_2}	5.4	pF
Grid No.1 to grid No.2	$C_{g_1g_2}$	2.6	pF
Grid No.1 to heater	C_{g_1f}	max. 0.15	pF
Cathode to heater	C_{kf}	5.0	pF

REMARK

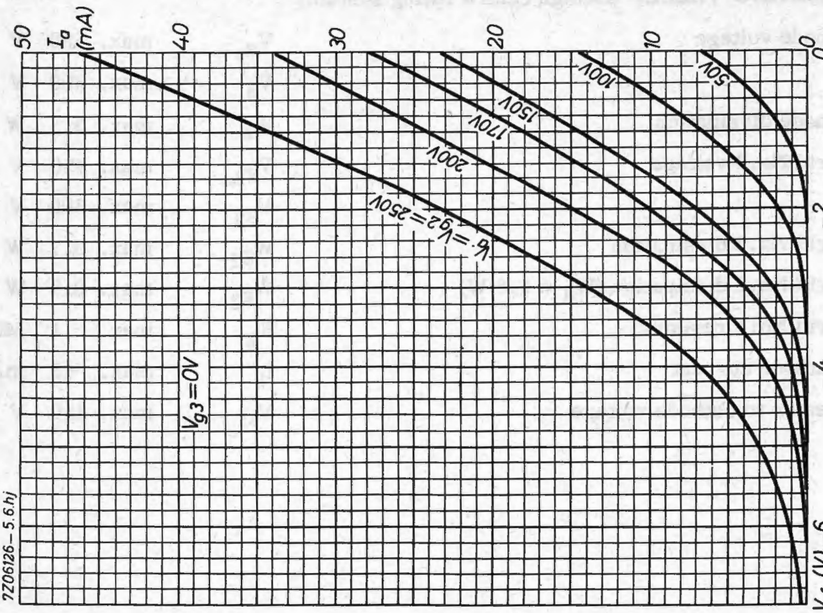
When using the EF80 as video amplifier the amplification between the input grid of the EF80 and the input of the cathode ray tube should not exceed a value of 25, in order to prevent microphonic effect.

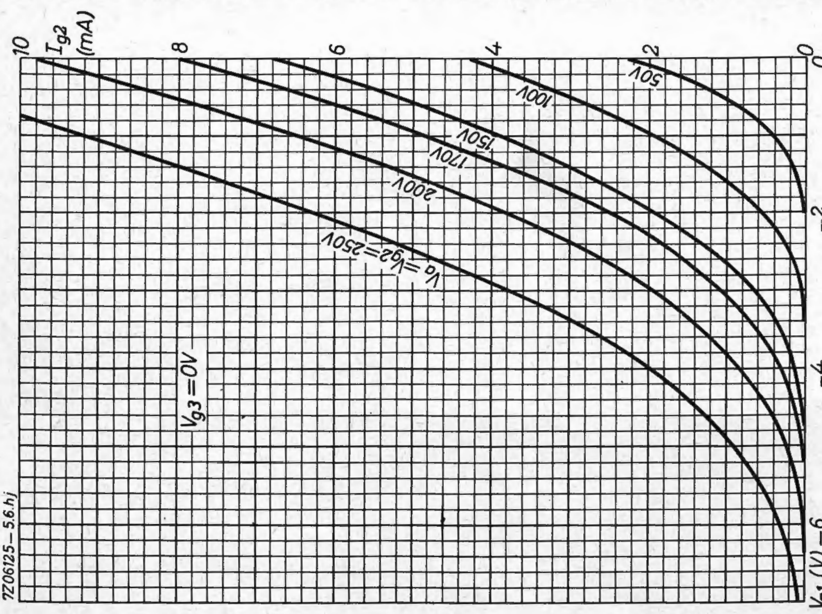
TYPICAL CHARACTERISTICS AND OPERATING CHARACTERISTICS

Anode voltage	V_a	170	200	250	V
Grid No.3 voltage	V_{g_3}	0	0	0	V
Grid No.2 voltage	V_{g_2}	170	200	250	V
Grid No.1 voltage	V_{g_1}	-2.0	-2.55	-3.5	V
Anode current	I_a	10	10	10	mA
Grid No.2 current	I_{g_2}	2.5	2.6	2.8	mA
Transconductance	S	7.4	7.1	6.8	mA/V
Internal resistance	R_i	0.5	0.55	0.65	MΩ
Amplification factor	$\mu_{g_2g_1}$	50	50	50	-
Equivalent noise resistance	R_{eq}	1000	1100	1200	Ω
Grid No.1 input resistance f = 50 MHz, pin 1 connected to pin 3	r_{g_1}	10	12	15	kΩ

LIMITING VALUES (Design centre rating system)

Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	300	V
Anode dissipation	W_a	max.	2.5	W
Grid No.2 voltage	$V_{g_{2o}}$	max.	550	V
	V_{g_2}	max.	300	V
Grid No.2 dissipation	W_{g_2}	max.	0.7	W
Grid No.2 dissipation (W_a < 1.8 W)	W_{g_2}	max.	0.9	W
Grid No.1 resistor	R_{g_1}	max.	1	MΩ
Cathode current	I_k	max.	15	mA
Heater to cathode voltage	V_{kf}	max.	150	V


7Z06126 – 5.6.hj
I_a (mA)
50
40
30
20
10
0
$V_a = V_{g2} = 250V$
200V
170V
150V
100V
50V
$V_{g3} = 0V$
V_{g1} (V)
0
−2
−4
−6


7Z06125 – 5.6.hj
I_{g2} (mA)
10
8
6
4
2
0
$V_a = V_{g2} = 250V$
200V
170V
150V
100V
50V
$V_{g3} = 0V$
V_{g1} (V)
0
−2
−4
−6

R.F. PENTODE

R.F. pentode with variable transconductance intended for use as wide-band amplifier.

QUICK REFERENCE DATA			
Anode current	I_a	10	mA
Transconductance	S	6.0	mA/V
Amplification factor	$\mu_{g_2g_1}$	26	-
Internal resistance	R_i	600	kΩ

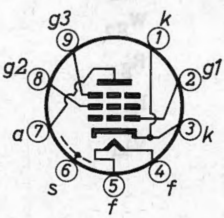
HEATING: Indirect by A.C. or D.C.; series or parallel supply

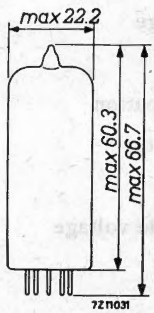
Heater voltage	V_f	6.3	V
Heater current	I_f	300	mA

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





CAPACITANCES

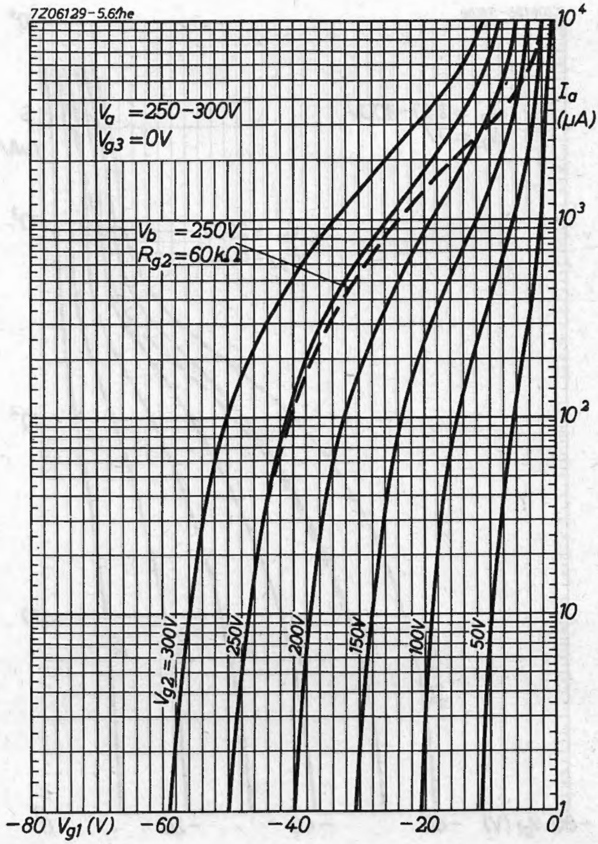
Anode to all except grid No.1	$C_{a(g_1)}$	3.2	pF
Grid No.1 to all except anode	$C_{g_1(a)}$	6.9	pF
Anode to grid No.1	C_{ag_1}	max. 0.007	pF
Grid No.1 to heater	C_{g_1f}	max. 0.15	pF

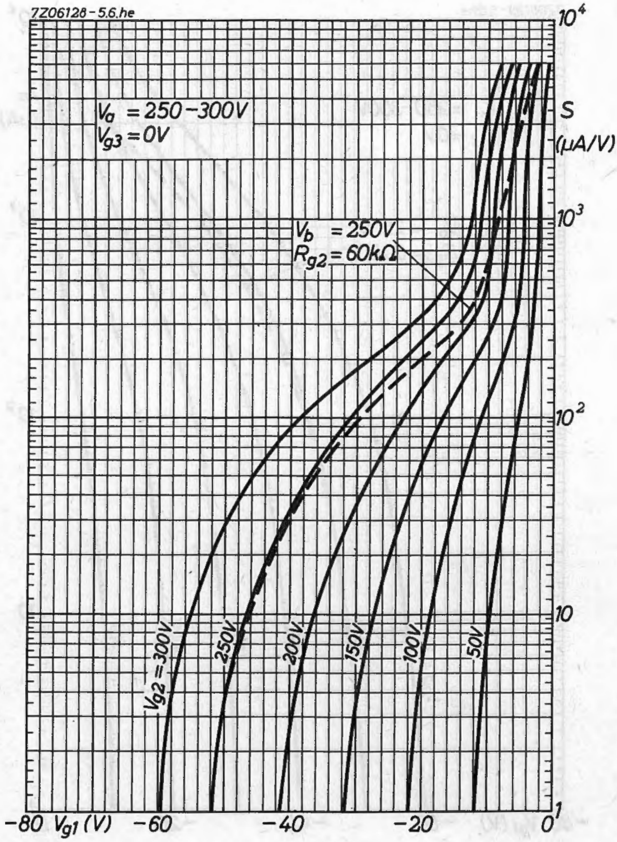
TYPICAL CHARACTERISTICS AND OPERATING CHARACTERISTICS

Anode and supply voltage	$V_a = V_b$	250		V
Grid No.3 voltage	V_{g3}	0		V
Grid No.2 resistor	R_{g2}	60		kΩ
Grid No.1 voltage	V_{g1}	−2	−35	V
Grid No.2 voltage	V_{g2}	100	-	V
Anode current	I_a	10	-	mA
Grid No.2 current	I_{g2}	2.5	-	mA
Transconductance	S	6.0	0.06	mA/V
Internal resistance	R_i	0.6	>5	MΩ
Amplification factor	μ_{g2g1}	26	-	
Equivalent noise resistance	R_{eq}	1.4	-	kΩ
Grid No.1 input resistance, f = 50 MHz	r_{g1}	9	-	kΩ

LIMITING VALUES (Design centre rating system)

Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	250	V
Anode dissipation	W_a	max.	2.5	W
Grid No.2 voltage	V_{g2_o}	max.	550	V
	V_{g2}	max.	250	V
Grid No.2 dissipation	W_{g2}	max.	0.65	W
Grid No.1 resistor	R_{g1}	max.	3	MΩ
Cathode current	I_k	max.	15	mA
Heater to cathode voltage	V_{kf}	max.	150	V


7Z06129-5.6/he
V_a =250-300V
V_{g3} =0V
V_b =250V
R_{g2}=60kΩ
V_{g2}=300V
250V
200V
150V
100V
50V
10^4
I_a
(μA)
10^3
10^2
10
1
-80
V_{g1} (V)
-60
-40
-20
0


7Z06128-5.6.he
V_a = 250-300V
V_{g3} = 0V
V_b = 250V
R_{g2} = 60kΩ
S
(μA/V)
10^4
10^3
10^2
10
1
V_{g2} = 300V
250V
200V
150V
100V
50V
-80
V_{g1} (V)
-60
-40
-20
0

A.F. PENTODE

Pentode intended for use as A.F. amplifier

QUICK REFERENCE DATA			
Anode current	I_a	3.0	mA
Transconductance	S	2.2	mA/V
Amplification factor	μ_{g2g1}	38	-
Internal resistance	R_i	2.5	MΩ

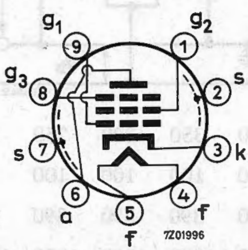
HEATING: Indirect by A.C. or D.C.; series or parallel supply

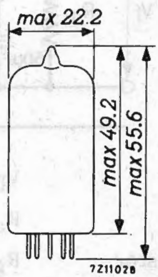
Heater voltage	V_f	6.3	V
Heater current	I_f	200	mA

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





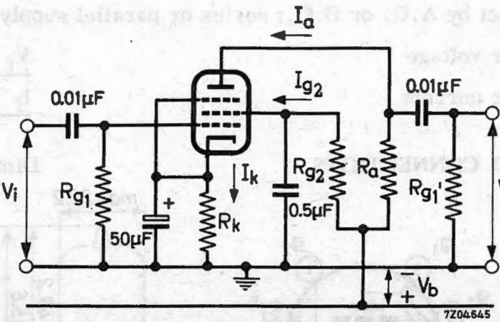
CAPACITANCES

Grid No.1 to all except anode	$C_{g1(a)}$		3.8	pF
Anode to all except grid No.1	$C_{a(g1)}$		5.1	pF
Anode to grid No.1	C_{ag1}	max.	0.05	pF
Grid No.1 to heater	C_{g1f}	max.	0.0025	pF

TYPICAL CHARACTERISTICS

Anode voltage	V_a	250	V
Grid No.3 voltage	V_{g3}	0	V
Grid No.2 voltage	V_{g2}	140	V
Grid No.1 voltage	V_{g1}	-2.2	V
Anode current	I_a	3.0	mA
Grid No.2 current	I_{g2}	0.6	mA
Transconductance	S	2.2	mA/V
Amplification factor	μ_{g2g1}	38	-
Internal resistance	R_i	2.5	MΩ

OPERATING CHARACTERISTICS as A.F. amplifier



Supply voltage	V_b	400	350	300	250	200	150	V
Anode resistor	R_a	100	100	100	100	100	100	kΩ
Grid No.2 resistor	R_{g2}	390	390	390	390	390	390	kΩ
Cathode resistor	R_k	1000	1000	1000	1000	1000	1000	Ω
Grid resistor next stage	R_{g1}'	330	330	330	330	330	330	kΩ
Cathode current	I_k	3.2	2.75	2.4	2.0	1.55	1.05	mA
Voltage gain 1)	V_o/V_i	140	134	129	123	117	110	-
Output voltage	V_o	85	74	62	50	38	27	V_{RMS}
Total distortion	d_{tot}	5	5	5	5	5	5	%

1) Measured at small input voltages

OPERATING CHARACTERISTICS (continued)

Supply voltage	V_b	400	350	300	250	200	150	V
Anode resistor	R_a	220	220	220	220	220	220	kΩ
Grid No.2 resistor	R_{g2}	1	1	1	1	1	1	MΩ
Cathode resistor	R_k	2200	2200	2200	2200	2200	2200	Ω
Grid resistor next stage	$R_{g'1}$	680	680	680	680	680	680	kΩ
Cathode current	I_k	1.45	1.3	1.1	0.9	0.75	0.5	mA
Voltage gain 1)	V_o/V_i	210	205	194	185	173	147	-
Output voltage	V_o	72	62	53	44	35	22	V_{RMS}
Total distortion	d_{tot}	5	5	5	5	5	5	%

As triode connected A.F. amplifier (g_2 connected to anode, g_3 to cathode)

Supply voltage	V_b	400	350	300	250	200	V
Anode resistor	R_a	47	47	47	47	47	kΩ
Cathode resistor	R_k	1200	1200	1200	1200	1200	Ω
Grid resistor next stage	$R_{g'1}$	150	150	150	150	150	kΩ
Anode current	I_a	3.6	3.15	2.7	2.25	1.8	mA
Voltage gain	V_o/V_i	26	25	25	25	24	-
Output voltage ($I_g = 0.3\mu A$)	V_o	68	58	46	36	24	V_{RMS}
Total distortion	d_{tot}	5	5	5	5	5	%

Supply voltage	V_b	400	350	300	250	200	V
Anode resistor	R_a	100	100	100	100	100	kΩ
Cathode resistor	R_k	2200	2200	2200	2200	2200	Ω
Grid resistor next stage	$R_{g'1}$	330	330	330	330	330	kΩ
Anode current	I_a	2.0	1.8	1.5	1.25	1.0	mA
Voltage gain	V_o/V_i	28	28	27.5	27.5	27	-
Output voltage ($I_g = 0.3\mu A$)	V_o	75	63	51	42	30	V_{RMS}
Total distortion	d_{tot}	5	5	5	5	5	%

Supply voltage	V_b	400	350	300	250	200	V
Anode resistor	R_a	220	220	220	220	220	kΩ
Cathode resistor	R_k	3900	3900	3900	3900	3900	Ω
Grid resistor next stage	R_{g1}'	680	680	680	680	680	kΩ
Anode current	I_a	1.1	0.95	0.8	0.7	0.55	mA
Voltage gain	V_o/V_i	29	29	29	28	28	-
Output voltage ($I_g = 0.3\mu A$)	V_o	71	60	52	42	30	V_{RMS}
Total distortion	d_{tot}	5	5	5	5	5	%

OPERATING CHARACTERISTICS (continued)

Microphonic effect

A sensitivity of 0.5 mV for an output of 50 mW (or 5 mV for an output of 5 W) is permissible in those equipments where an output of 50 mW in the loudspeaker does not produce an average acceleration on the tube higher than 0.015 g at any frequency higher than 500 Hz or higher than 0.06 g at any frequency lower than 500 Hz.

Hum level

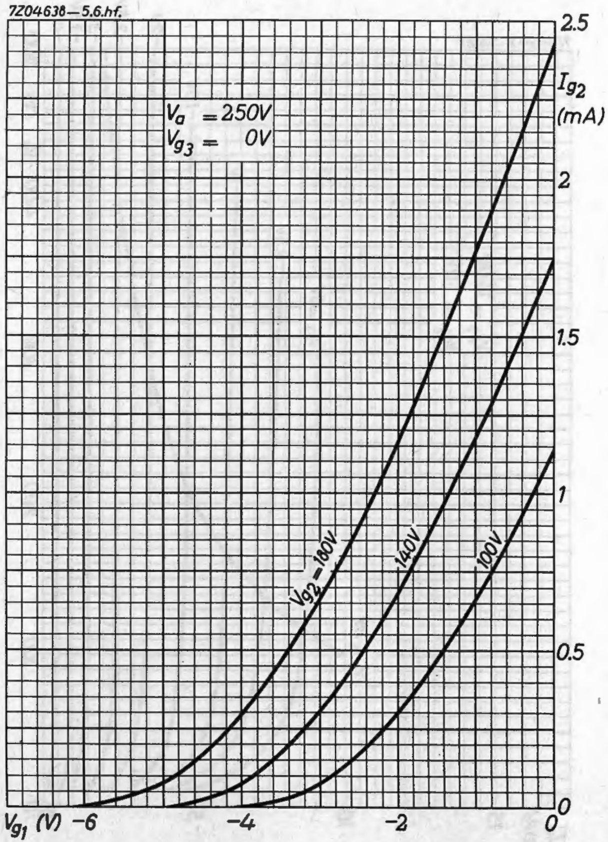
The hum disturbance level will be 3 μV (max. 5 μV) when Z_{g_1} is smaller than 0.5 MΩ at f = 50 Hz, the cathode resistor is decoupled by a capacitor of at least 100 μF and pin 4 is earthed. With the centre tap of the heater supply earthed this value will be 1 μV (max. 2 μV).

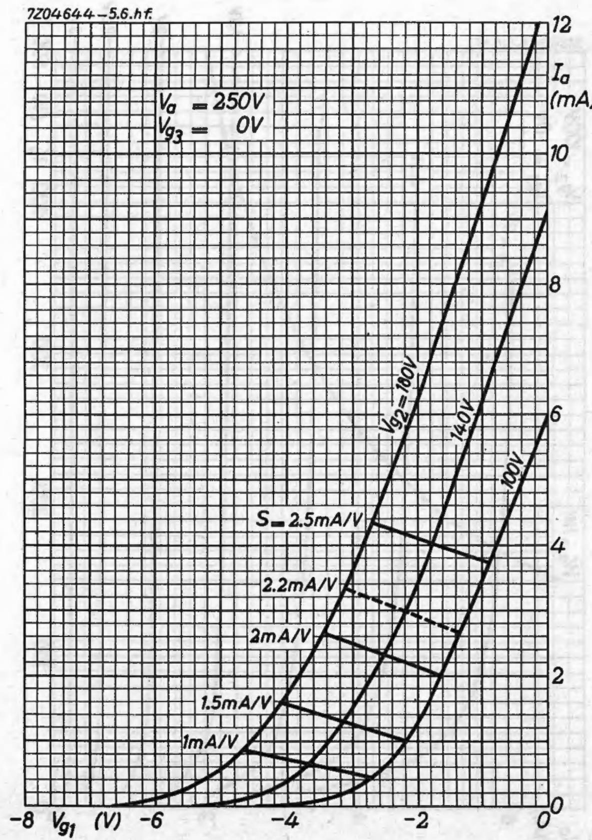
Noise voltage

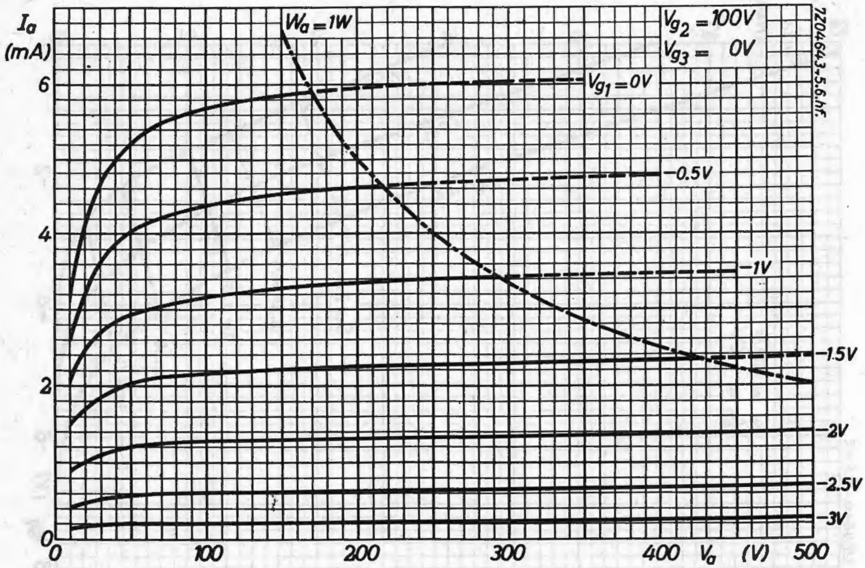
The equivalent noise voltage on g_1 is approximately 2 μV for the frequency range from 25 to 10 000 Hz at V_b = 250 V and R_a = 100 kΩ.

LIMITING VALUES (Design centre rating system)

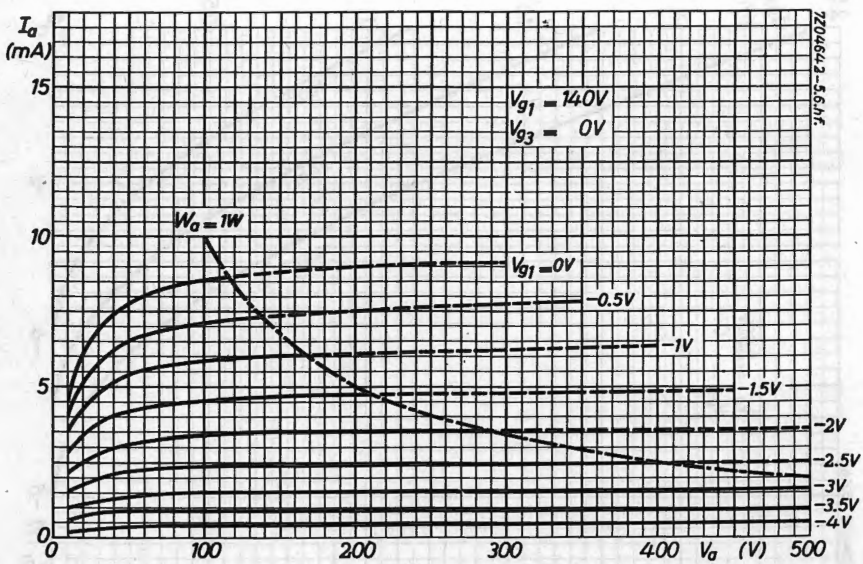
Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	300	V
Anode dissipation	W_a	max.	1.0	W
Grid No.2 voltage	$V_{g_{2o}}$	max.	550	V
	V_{g_2}	max.	200	V
Grid No.2 dissipation	W_{g_2}	max.	0.2	W
Grid No.1 circuit resistor				
if W_a < 0.2 W	R_{g_1}	max.	10	MΩ
if W_a > 0.2 W	R_{g_1}	max.	3	MΩ
with grid current biasing	R_{g_1}	max.	22	MΩ
Cathode current	I_k	max.	6	mA
Cathode to heater voltage				
cathode positive	V_{kf}	max.	100	V
cathode negative	V_{kf}	max.	50	V


7Z04638—5.6.hf.
V_a = 250V
V_{g3} = 0V
I_{g2} (mA)
V_{g2} = 180V
140V
100V
2.5
2
1.5
1
0.5
0
V_{g1} (V) −6
−4
−2
0

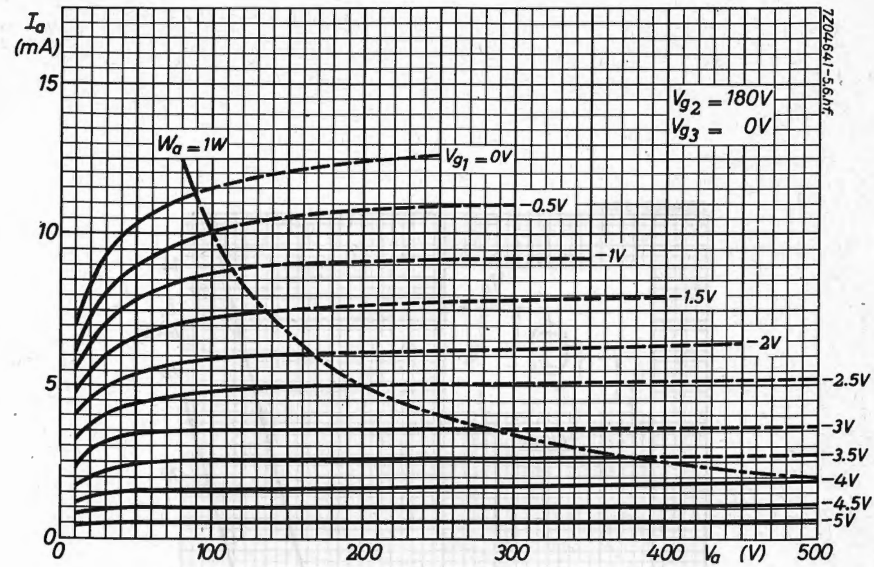

7Z04644—5.6.hf.
V_a = 250V
V_{g3} = 0V
I_a (mA)
V_{g2} = 180V
140V
100V
S = 2.5mA/V
2.2mA/V
2mA/V
1.5mA/V
1mA/V
12
10
8
6
4
2
0
−8 V_{g1} (V) −6
−4
−2
0



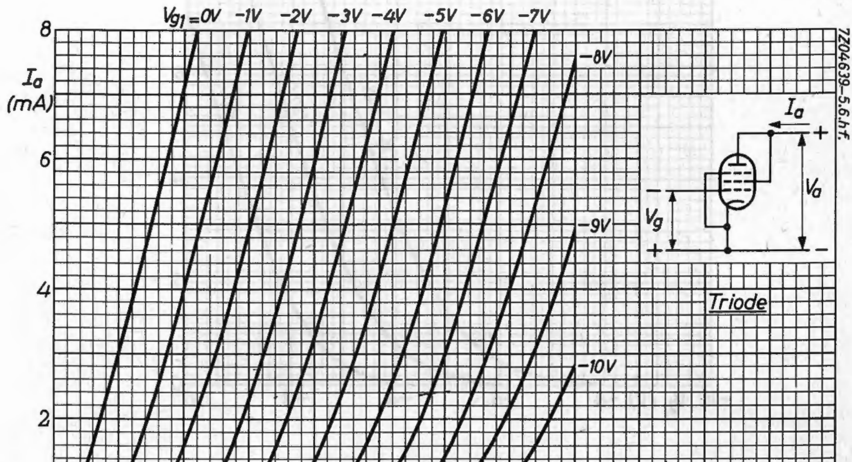
I_a (mA)
$W_a = 1W$
$V_{g_2} = 100V$
$V_{g_3} = 0V$
$V_{g_1} = 0V$
−0.5V
−1V
−1.5V
−2V
−2.5V
−3V
0
2
4
6
0
100
200
300
400
V_a (V)
500
7Z04643-5.6.hf.



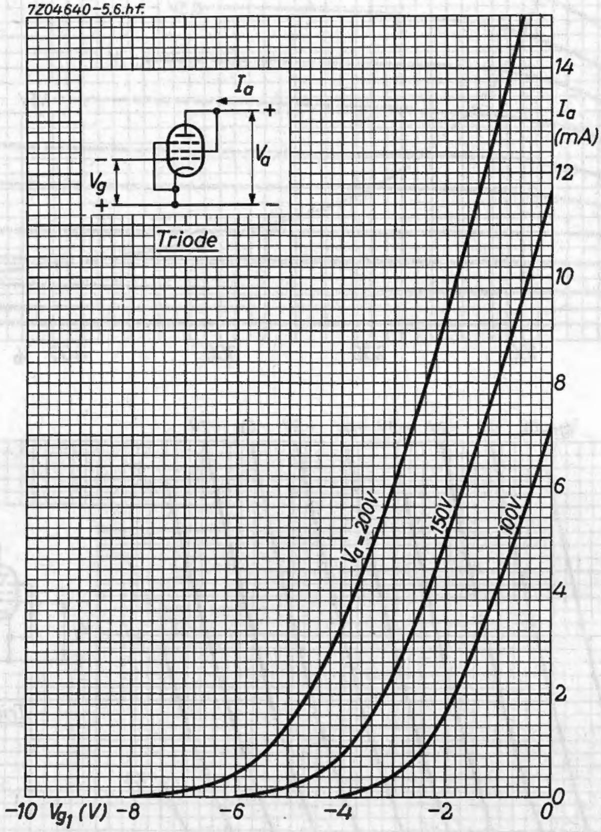
I_a (mA)
$V_{g_1} = 140V$
$V_{g_3} = 0V$
$W_a = 1W$
$V_{g_1} = 0V$
−0.5V
−1V
−1.5V
−2V
−2.5V
−3V
−3.5V
−4V
0
5
10
15
0
100
200
300
400
V_a (V)
500
7Z04642-5.6.hf.



I_a (mA)
15
10
5
0
0
100
200
300
400
V_a (V)
500
$W_a = 1W$
$V_{g_1} = 0V$
−0.5V
−1V
−1.5V
−2V
−2.5V
−3V
−3.5V
−4V
−4.5V
−5V
$V_{g_2} = 180V$
$V_{g_3} = 0V$
7Z04641-5.6.h.f.



$V_{g_1} = 0V$ −1V −2V −3V −4V −5V −6V −7V
−8V
−9V
−10V
I_a (mA)
8
6
4
2
0
0
100
200
300
400
500
V_a (V)
I_a
V_a
V_g
Triode
7Z04639-5.6.h.f.


7Z04640-5.6.h.f.
I_a
+
V_a
V_g
−
+
−
Triode
14
I_a
(mA)
12
10
8
6
4
2
0
$V_a = 200V$
150V
100V
−10
V_{g_1} (V)
−8
−6
−4
−2
0

R.F. PENTODE

Pentode with variable transconductance intended for use as R.F. or I.F. amplifier.

QUICK REFERENCE DATA			
Anode current	I_a	9	mA
Transconductance	S	4.0	mA/V
Amplification factor	$\mu_{g_2g_1}$	21	-
Internal resistance	R_i	750	kΩ

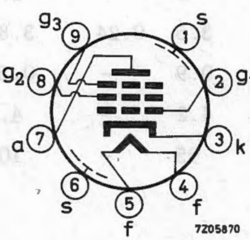
HEATING: Indirect by A.C. or D.C.; parallel supply

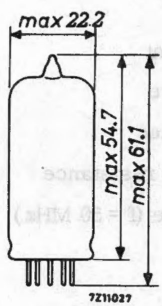
Heater voltage	V_f	6.3	V
Heater current	I_f	200	mA

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





CAPACITANCES

Anode to all except grid No.1	$C_{a(g_1)}$	5.1	pF
Grid No.1 to all except anode	$C_{g_1(a)}$	5.5	pF
Anode to grid No.1	C_{ag_1}	max. 0.002	pF
Grid No.1 to heater	C_{g_1f}	0.05	pF

TYPICAL CHARACTERISTICS

Anode voltage	V_a	250	250	170	V
Grid No.2 voltage	V_{g2}	100	85	100	V
Grid No.3 voltage	V_{g3}	0	0	0	V
Anode current	I_a	9	9	12	mA
Grid No.1 voltage	V_{g1}	−2	−1.2 [1]	−1.2 [1]	V
Grid No.2 current	I_{g2}	3	3.2	4.4	mA
Transconductance	S	3.6	4.0	4.4	mA/V
Internal resistance	R_i	0.9	0.75	0.4	MΩ
Amplification factor	μ_{g2g1}	−	21	−	−

OPERATING CHARACTERISTICS

Anode voltage, supply voltage	$V_a = V_b$	250		200		V
Grid No.3 voltage	V_{g3}	0		0		V
Grid No.2 resistor	R_{g2}	51		24		kΩ
Cathode resistor	R_k	160		130		Ω
Grid No.1 voltage	V_{g1}	−1.95	−20	−1.95	−20	V
Anode current	I_a	9	−	11.1	−	mA
Grid No.2 current	I_{g2}	3	−	3.8	−	mA
Transconductance	S	3.5	0.24	3.85	0.16	mA/V
Internal resistance	R_i	0.9	−	0.55	−	MΩ
Equivalent noise resistance	R_{eq}	4.2	−	4.2	−	kΩ
Input conductance (f = 50 MHz)	g	95	−	102	−	μA/V

[1]) In this case control grid current may occur. If this is not permissible, the negative grid bias should be increased to a value of 1.5 V at least.

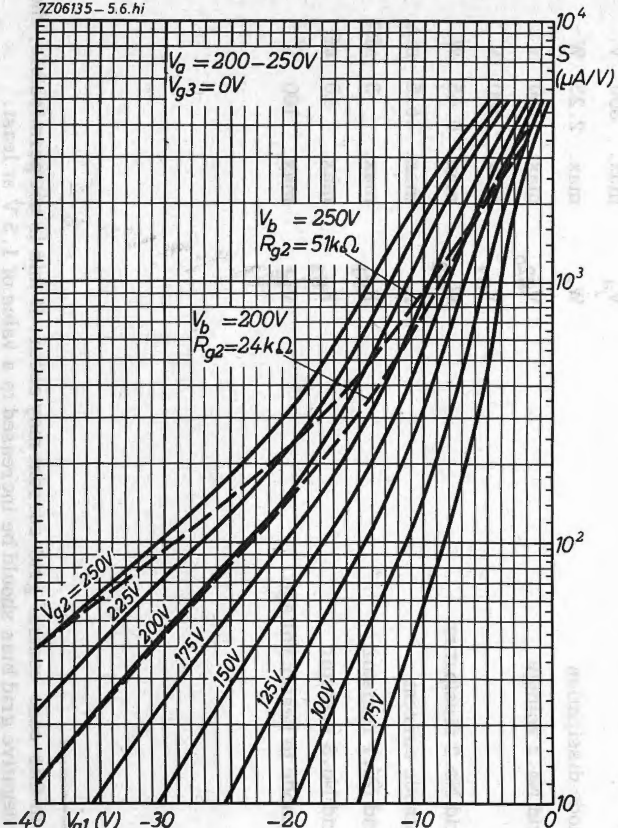
OPERATING CHARACTERISTICS (continued)

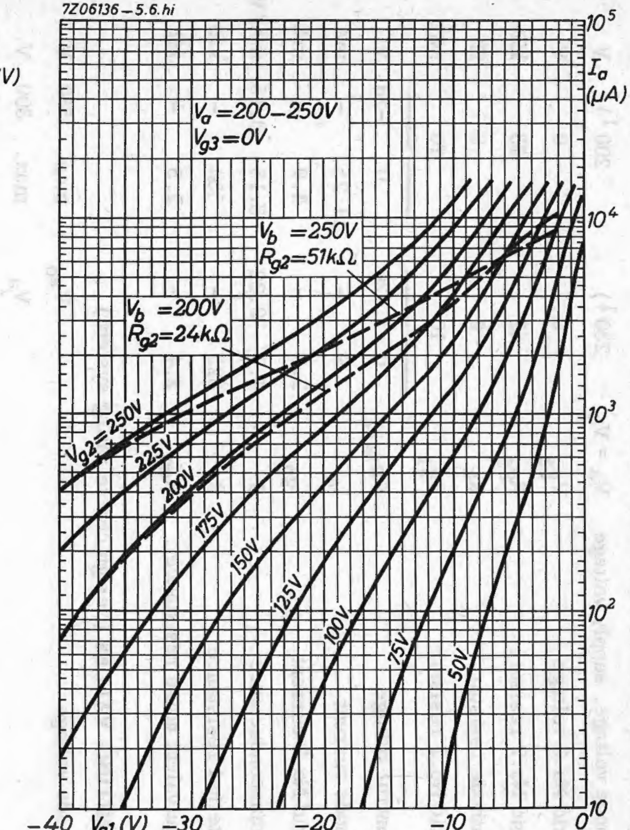
Anode voltage, supply voltage	$V_a = V_b$	250 [1]		200 [1]		V
Grid No.3 voltage	V_{g_3}	0		0		V
Grid No.2 resistor	R_{g_2}	62		33		kΩ
Cathode resistor	R_k	0		0		Ω
Grid No.1 resistor	R_{g_1}	10		10		MΩ
Control voltage	$V_{R(g_1)}$	0	-20	0	-20	V
Anode current	I_a	9	-	11.25	-	mA
Grid No.2 current	I_{g_2}	2.9	-	3.9	-	mA
Transconductance	S	4.7	0.22	5.15	0.15	mA/V
Internal resistance	R_i	825	-	550	-	kΩ
Equivalent noise resistance	R_{eq}	2.4	-	2.5	-	kΩ

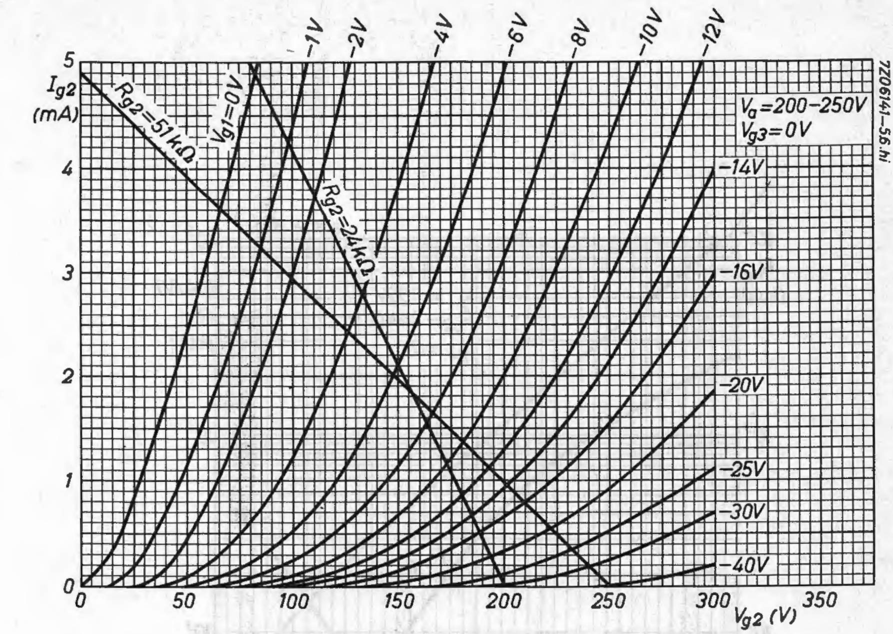
LIMITING VALUES (Design centre rating system)

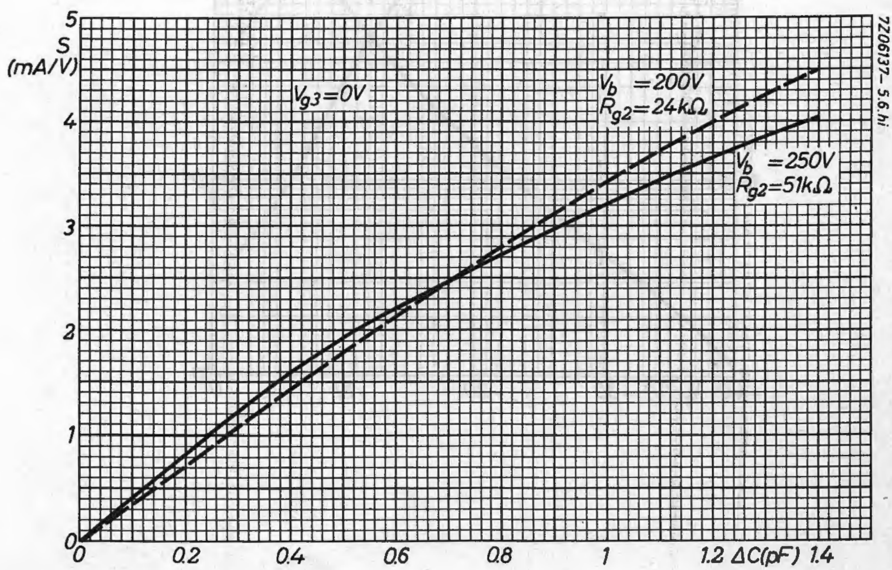
Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	300	V
Anode dissipation	W_a	max.	2.25	W
Grid No.2 voltage	V_{g2_o}	max.	550	V
	V_{g_2}	max.	300	V
Grid No.2 dissipation	W_{g_2}	max.	0.45	W
Cathode current	I_k	max.	16.5	mA
Grid No.1 resistor	R_{g_1}	max.	3	MΩ
Grid No.3 resistor	R_{g_3}	max.	10	kΩ
Cathode to heater voltage	V_{kf}	max.	100	V

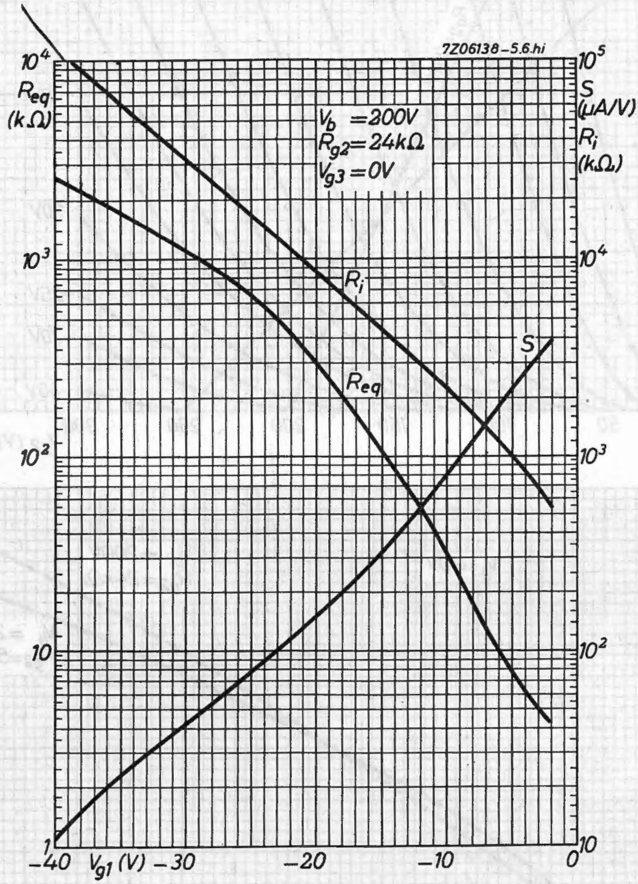
[1]) In this case control grid current may occur. If this is not permissible, the negative grid bias should be increased to a value of 1.5 V at least.


7Z06135 – 5.6.hi
V_a = 200–250V
V_{g3} = 0V
S (μA/V)
V_b = 250V
R_{g2} = 51kΩ
V_b = 200V
R_{g2} = 24kΩ
V_{g2} = 250V
225V
200V
175V
150V
125V
100V
75V
10^4
10^3
10^2
10
–40
V_{g1} (V)
–30
–20
–10
0


7Z06136 – 5.6.hi
I_a (μA)
V_a = 200–250V
V_{g3} = 0V
V_b = 250V
R_{g2} = 51kΩ
V_b = 200V
R_{g2} = 24kΩ
V_{g2} = 250V
225V
200V
175V
150V
125V
100V
75V
50V
10^5
10^4
10^3
10^2
10
–40
V_{g1} (V)
–30
–20
–10
0


5
I_{g2} (mA)
4
3
2
1
0
0
50
100
150
200
250
300
350
V_{g2} (V)
$R_{g2}=51k\Omega$
$V_{g1}=0V$
$R_{g2}=24k\Omega$
−1V
−2V
−4V
−6V
−8V
−10V
−12V
−14V
−16V
−20V
−25V
−30V
−40V
$V_a=200-250V$
$V_{g3}=0V$
7Z06141−5.6.hi


5
S (mA/V)
4
3
2
1
0
0
0.2
0.4
0.6
0.8
1
1.2
ΔC(pF)
1.4
$V_{g3}=0V$
$V_b=200V$
$R_{g2}=24k\Omega$
$V_b=250V$
$R_{g2}=51k\Omega$
7Z06137−5.6.hi



7Z06138-5.6.hi
10^4
R_{eq} (kΩ)
10^3
10^2
10
1
10^5
S (μA/V)
R_i (kΩ)
10^4
10^3
10^2
10
V_b = 200V
R_{g2} = 24kΩ
V_{g3} = 0V
R_i
R_{eq}
S
−40
V_{g1} (V)
−30
−20
−10
0

R.F. PENTODE

Pentode intended for use as R.F. amplifier.

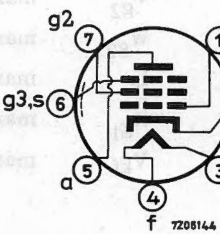
QUICK REFERENCE DATA			
Anode current	I_a	10	mA
Transconductance	S	7.65	mA/V
Amplification factor	$\mu_{g_2g_1}$	70	
Internal resistance	R_i	1	MΩ

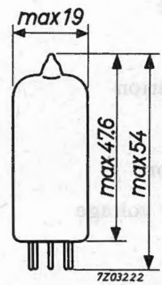
HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	300	mA

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Miniature 7 pin





CAPACITANCES (with external shield)

Grid No.1 to all except anode	$C_{g_1(a)}$	7.3	pF
Anode to all except grid No.1	$C_{a(g_1)}$	3.4	pF
Anode to grid No.1	C_{ag_1}	max. 0.01	pF

TYPICAL CHARACTERISTICS AND OPERATING CHARACTERISTICS

Anode voltage	V_a	250	V
Grid No.2 voltage	V_{g_2}	250	V
Grid No.3 voltage	V_{g_3}	0	V
Grid No.1 voltage	V_{g_1}	-2.0	V
Anode current	I_a	10	mA
Grid No.2 current	I_{g_2}	2.55	mA
Transconductance	S	7.65	mA/V
Internal resistance	R_i	1	MΩ
Amplification factor	$\mu_{g_2g_1}$	70	
Equivalent noise resistance	R_{eq}	1200	Ω
Input resistance grid No.1 (f = 50 MHz)	r_{g_1}	7500	Ω

LIMITING VALUES (Design centre rating system)

Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	300	V
Anode dissipation	W_a	max.	2.5	W
Grid No.2 voltage	$V_{g_{2o}}$	max.	550	V
	V_{g2}	max.	300	V
Grid No.2 dissipation	W_{g2}	max.	0.65	W
Cathode current	I_k	max.	15	mA
Grid No.1 resistor	R_{g_1}	max.	1	MΩ
Cathode to heater voltage	V_{kf}	max.	150	V

R.F. PENTODE

Pentode with variable transconductance intended for use as R.F. amplifier up to 160 MHz.

QUICK REFERENCE DATA			
Anode current	I_a	8.0	mA
Transconductance	S	2.5	mA/V
Amplification factor	$\mu_{g_2g_1}$	30	

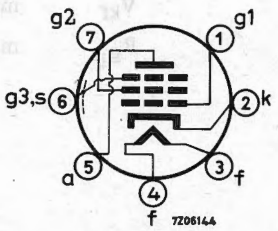
HEATING: Indirect by A.C. or D.C.; parallel supply

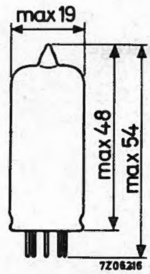
Heater voltage	V_f	6.3	V
Heater current	I_f	200	mA

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Miniature 7 pin





CAPACITANCES

Grid No.1 to all except anode	$C_{g_1(a)}$	4.5	pF
Anode to all except grid No.1	$C_{a(g_1)}$	6.5	pF
Anode to grid No.1	C_{ag_1}	0.007	pF

TYPICAL CHARACTERISTICS AND OPERATING CHARACTERISTICS

Anode voltage	V_a	250	250		V
Grid No.2 voltage	V_{g_2}	150	200		V
Grid No.3 voltage	V_{g_3}	0	0		V
Grid No.1 voltage	V_{g_1}	-0.65	-2.5	-28	V
Anode current	I_a	8.0	8.0	–	mA
Grid No.2 current	I_{g_2}	2.0	2.1	–	mA
Transconductance	S	2.5	2.5	0.005	mA/V
Amplification factor	$\mu_{g_2g_1}$	30	30	–	

LIMITING VALUES (Design centre rating system)

Anode voltage	V_{a_o}	max.	300	V
	V_a	max.	250	V
Anode dissipation	W_a	max.	2.5	W
Grid No.2 voltage	$V_{g_{2o}}$	max.	300	V
	V_{g_2}	max.	250	V
Grid No.2 dissipation	W_{g_2}	max.	0.6	W
Cathode current	I_k	max.	12	mA
Cathode to heater voltage	V_{kf}	max.	100	V
Grid No.1 resistor	R_{g_1}	max.	1	MΩ

R.F. PENTODE

Pentode intended for use as R.F. amplifier.

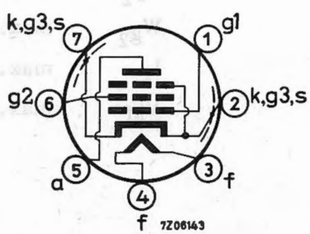
QUICK REFERENCE DATA			
Anode current	I_a	7.7	mA
Transconductance	S	5.1	mA/V
Internal resistance	R_i	690	kΩ

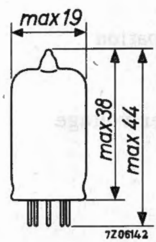
HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	175	mA

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Miniature 7-pin





CAPACITANCES (with external shield)

Grid No.1 to all except anode	$C_{g1(a)}$	4.0	pF
Anode to all except grid No.1	$C_{a(g1)}$	2.8	pF
Anode to grid No.1	C_{ag_1}	max. 0.02	pF

TYPICAL CHARACTERISTICS AND OPERATING CHARACTERISTICS

Anode voltage	V_a	120	180	V
Grid No.2 voltage	V_{g2}	120	120	V
Cathode resistor	R_k	200	200	Ω
Anode current	I_a	7.5	7.7	mA
Grid No.2 current	I_{g2}	2.5	2.4	mA
Transconductance	S	5.0	5.1	mA/V
Internal resistance	R_i	0.34	0.69	MΩ
Equivalent noise resistance	R_{eq}	2	2	kΩ
Input resistance grid No.1 f = 50 MHz	r_{g1}	25	25	kΩ

LIMITING VALUES (Design centre rating system)

Anode voltage	V_{a_o}	max.	300	V
	V_a	max.	180	V
Anode dissipation	W_a	max.	1.7	W
Grid No.2 voltage	V_{g2o}	max.	300	V
	V_{g2}	max.	140	V
Grid No.2 dissipation	W_{g2}	max.	0.5	W
Cathode current	I_k	max.	18	mA
Cathode to heater voltage	V_{kf}	max.	90	V

I.F. PENTODE

Pentode with variable transconductance intended for use as I.F. amplifier in television receivers.

QUICK REFERENCE DATA			
Anode current	I_a	12	mA
Transconductance	S	12.5	mA/V
Internal resistance	R_i	500	kΩ

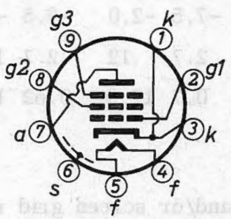
HEATING: Indirect by A.C. or D.C.; parallel or series supply

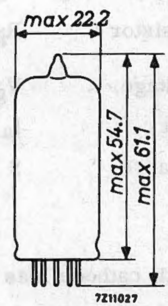
Heater voltage	V_f	6.3	V
Heater current	I_f	300	mA

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





CAPACITANCES

Anode to all except grid No.1	$C_{a(g_1)}$	3	pF
Grid No.1 to all except anode	$C_{g_1(a)}$	9.5	pF
Anode to grid No.1	C_{ag_1}	max. 0.005	pF
Grid No.1 to grid No.2	$C_{g_1g_2}$	2.8	pF

TYPICAL CHARACTERISTICS

Anode voltage	V_a	200	V
Grid No. 3 voltage	V_{g3}	0	V
Grid No. 2 voltage	V_{g2}	90	V
Grid No. 1 voltage	V_{g1}	-2	V
Anode current	I_a	12	mA
Grid No. 2 current	I_{g2}	4.5	mA
Transconductance	S	12.5	mA/V
Internal resistance	R_i	500	kΩ
Input resistance grid No. 1 (f = 40 MHz)	r_{g1}	13	kΩ
Equivalent noise resistance (f = 40 MHz)	R_{eq}	490	Ω

OPERATING CHARACTERISTICS

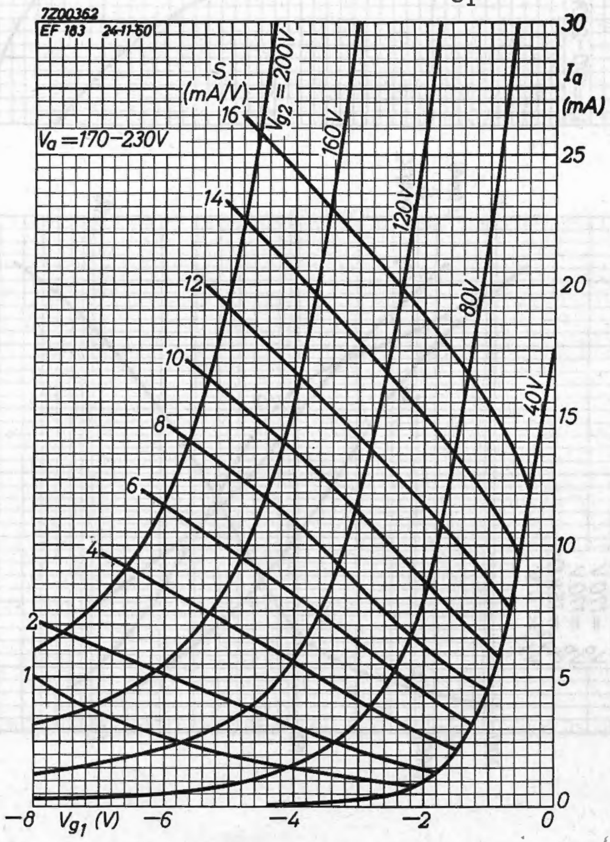
Anode voltage	V_a	170		200		230		V
Grid No. 3 voltage	V_{g3}	0		0		0		V
Grid No. 2 supply voltage	V_{bg2}	170		200		230		V
Grid No. 2 resistor	R_{g2}	15		24		39		kΩ
Grid No. 1 voltage	V_{g1}	-1.8	-7.5	-2.0	-9.5	-2.1	-12	V
Anode current	I_a	14	2.7	12	2.7	10.5	2.4	mA
Transconductance	S	14	0.7	12.5	0.62	10.6	0.5	mA/V

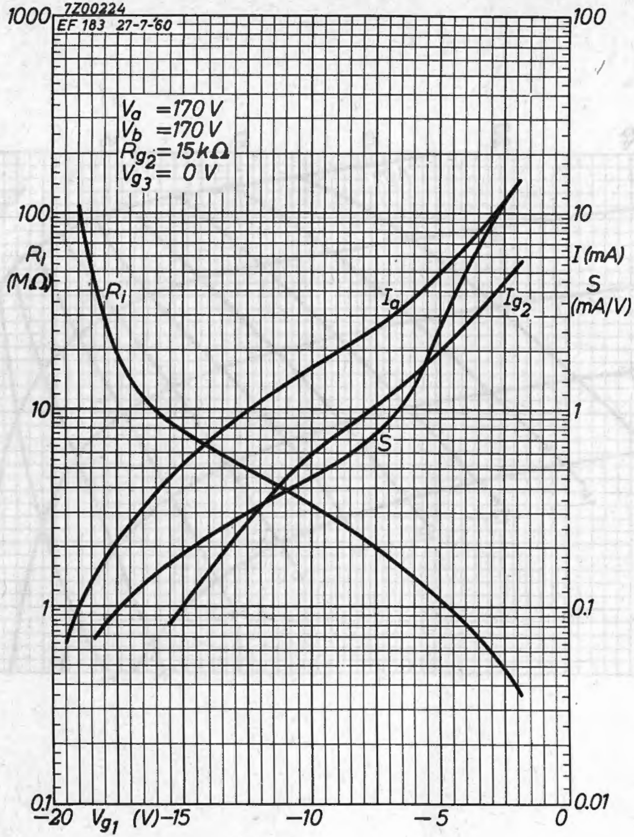
REMARK

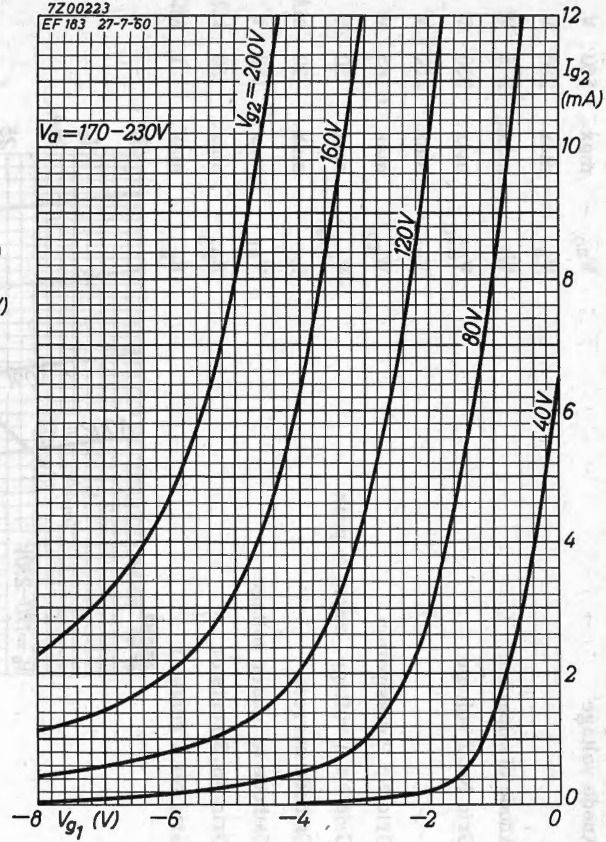
Operation with cathode bias resistor and/or screen grid resistor is recommended.

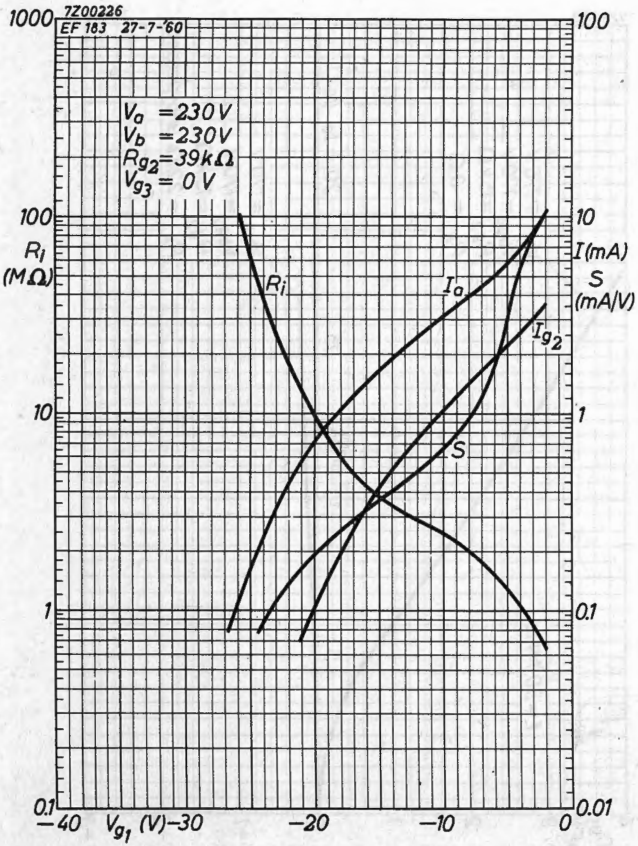
LIMITING VALUES (Design centre rating system)

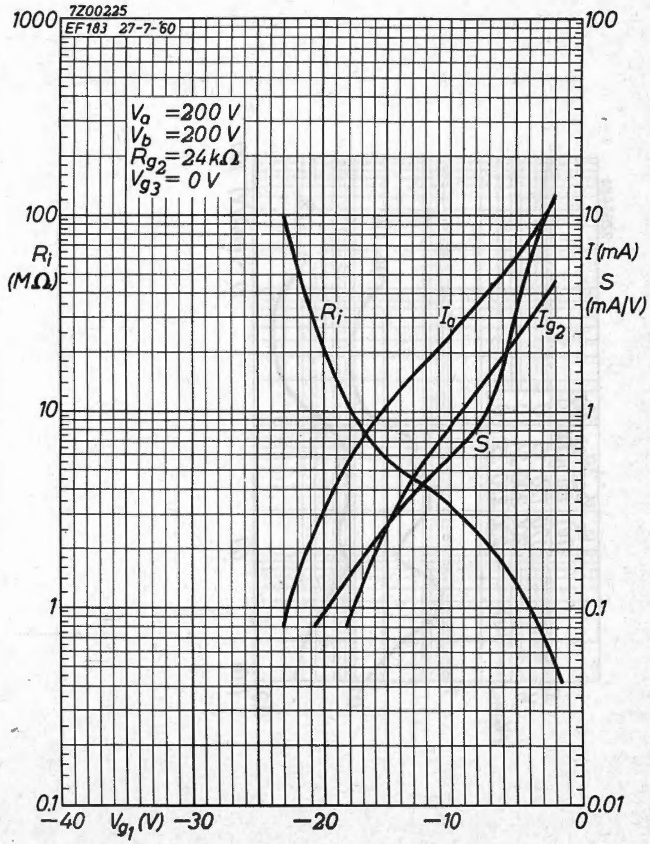
Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	250	V
Anode dissipation	W_a	max.	2.5	W
Grid No.2 voltage	V_{g2_o}	max.	550	V
	V_{g2}	max.	250	V
Grid No.2 dissipation	W_{g2}	max.	0.65	W
Grid No.1 voltage, negative peak	$-V_{g1p}$	max.	50	V
Cathode current	I_k	max.	20	mA
Cathode to heater voltage	V_{kf}	max.	150	V
Grid No.3 resistor	R_{g3}	max.	50	kΩ
Grid No.1 resistor	R_{g1}	max.	1	MΩ

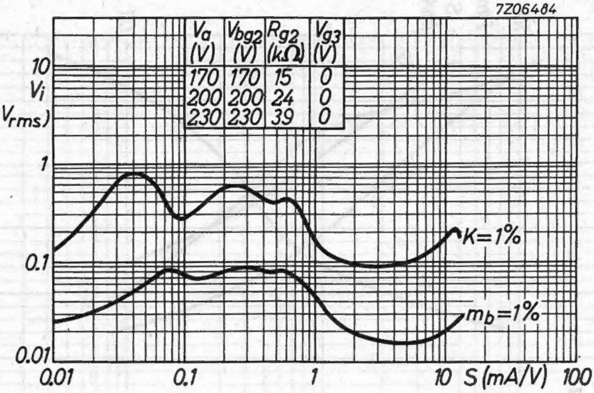


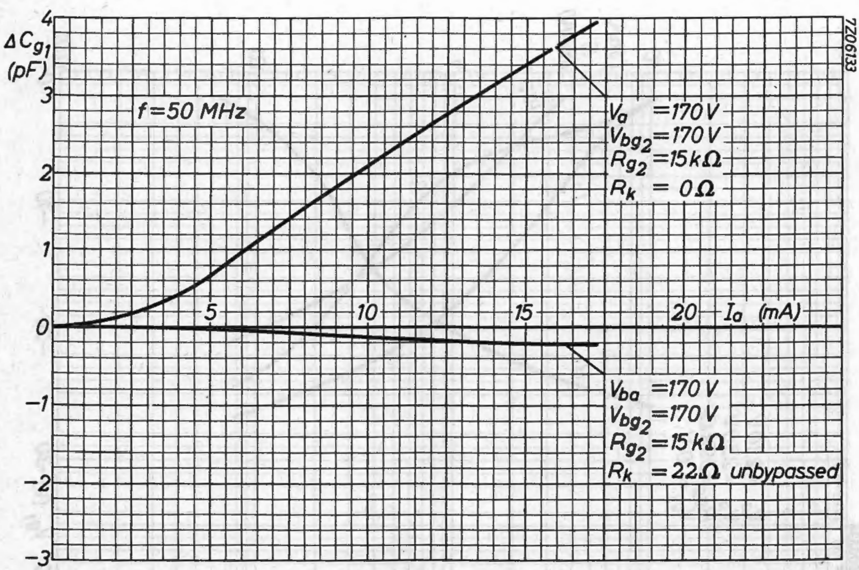

7Z00224
EF 183 27-7-'60
V_a = 170 V
V_b = 170 V
R_{g_2} = 15 kΩ
V_{g_3} = 0 V
R_i (MΩ)
R_i
I_a
I_{g_2}
S
I (mA)
S (mA/V)
1000
100
10
1
0.1
100
10
1
0.1
0.01
−20
V_{g_1} (V)
−15
−10
−5
0

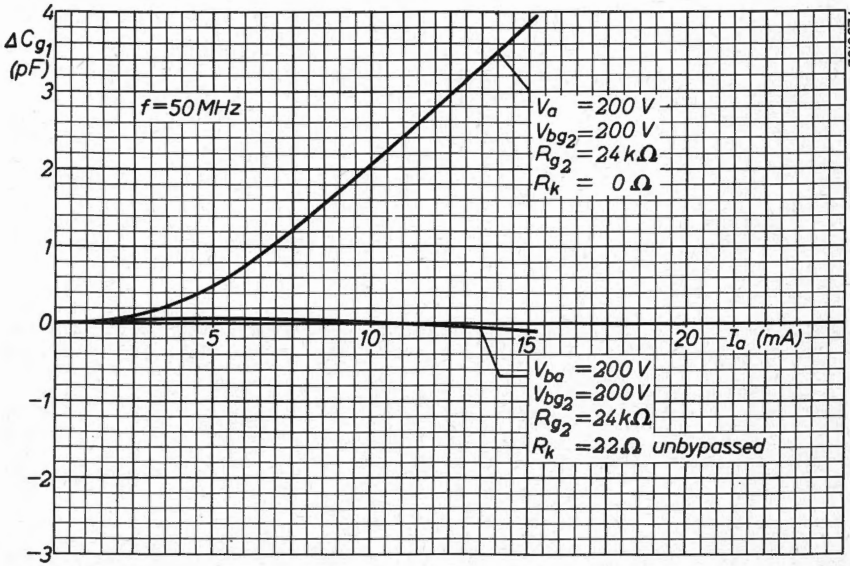

7Z00223
EF 183 27-7-'60
V_a = 170–230V
V_{g_2} = 200V
160V
120V
80V
40V
I_{g_2} (mA)
12
10
8
6
4
2
0
−8
V_{g_1} (V)
−6
−4
−2
0


7Z00226
EF 183 27-7-'60
V_a = 230 V
V_b = 230 V
R_{g2} = 39 kΩ
V_{g3} = 0 V
R_i (MΩ)
I (mA)
S (mA/V)
R_i
I_a
I_{g2}
S
1000
100
10
1
0.1
100
10
1
0.1
0.01
−40
V_{g1} (V) −30
−20
−10
0


7Z00225
EF 183 27-7-'60
V_a = 200 V
V_b = 200 V
R_{g2} = 24 kΩ
V_{g3} = 0 V
R_i (MΩ)
I (mA)
S (mA/V)
R_i
I_a
I_{g2}
S
1000
100
10
1
0.1
100
10
1
0.1
0.01
−40
V_{g1} (V) −30
−20
−10
0


7Z06484
Va (V)
Vbg2 (V)
Rg2 (kΩ)
Vg3 (V)
170 170 15 0
200 200 24 0
230 230 39 0
Vi (Vrms)
10
1
0.1
0.01
K=1%
mb=1%
0.01
0.1
1
10
S (mA/V)
100


7Z06133
ΔCg1 (pF)
4
3
2
1
0
−1
−2
−3
f=50 MHz
5
10
15
20
Ia (mA)
Va =170 V
Vbg2=170 V
Rg2=15 kΩ
Rk = 0Ω
Vba =170 V
Vbg2=170 V
Rg2=15 kΩ
Rk =22Ω unbypassed



4
ΔC_{g_1} (pF)
3
2
1
0
−1
−2
−3
5
10
15
20
I_a (mA)
f=50 MHz
V_a =200 V
V_{bg_2}=200 V
R_{g_2}=24 kΩ
R_k = 0 Ω
V_{ba} =200 V
V_{bg_2}=200 V
R_{g_2}=24 kΩ
R_k =22 Ω unbypassed
7206132

I.F. PENTODE

Pentode intended for use as I.F. amplifier in television receivers.

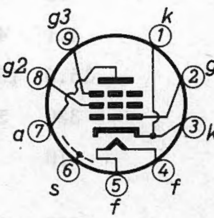
QUICK REFERENCE DATA			
Anode current	I_a	10	mA
Transconductance	S	15	mA/V
Amplification factor	$\mu_{g_2 g_1}$	60	-
Internal resistance	R_i	380	kΩ

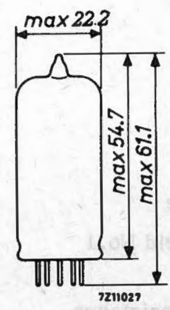
HEATING: Indirect by A.C. or D.C.; parallel or series supply

Heater voltage	V_f	6.3	V
Heater current	I_f	300	mA

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Noval





CAPACITANCES

Anode to all except grid No.1	$C_{a(g_1)}$	3	pF
Grid No.1 to all except anode	$C_{g_1(a)}$	10	pF
Anode to grid No.1	C_{ag_1}	max. 0.0055	pF
Grid No.1 to grid No.2	$C_{g_1 g_2}$	2.8	pF

TYPICAL CHARACTERISTICS

Anode voltage	V_a	200	V
Grid No.3 voltage	V_{g3}	0	V
Grid No.2 voltage	V_{g2}	200	V
Grid No.1 voltage	V_{g1}	-2.5	V
Anode current	I_a	10	mA
Grid No.2 current	I_{g2}	4.1	mA
Transconductance	S	15	mA/V
Internal resistance	R_i	380	kΩ
Amplification factor	μ_{g2g1}	60	-
Input resistance grid No.1 (f = 40 MHz)	r_{g1}	11	kΩ
Equivalent noise resistance (f = 40 MHz)	R_{eq}	330	Ω

OPERATING CHARACTERISTICS

Anode supply coltage	V_{ba}	170	200	230	V
Grid No.3 voltage	V_{g3}	0	0	0	V
Grid No.2 supply voltage	V_{bg2}	170	200	230	V
Grid No.2 resistor	R_{g2}	0	7.5	15	kΩ
Cathode resistor	R_k	140	140	140	Ω
Anode current	I_a	10	10	10	mA
Grid No.2 current	I_{g2}	4.1	4.1	4.1	mA
Transconductance	S	15.6	15.6	15.6	mA/V
Internal resistance	R_i	330	510	680	kΩ
Input resistance grid No.1 f = 40 MHz	r_{g1}	10	10	10	kΩ
Equivalent noise resistance f = 40 MHz	R_{eq}	300	300	300	Ω

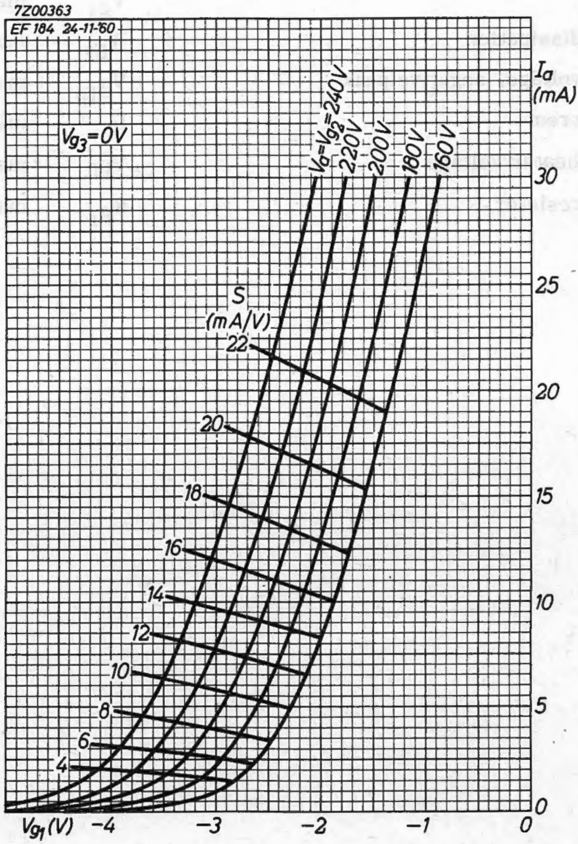
REMARKS

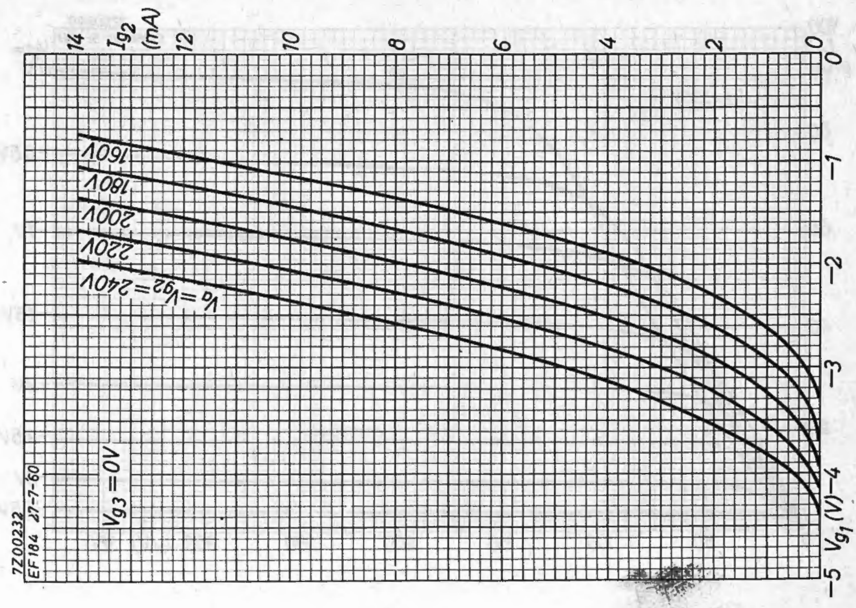
1. Operation with cathode bias resistor is recommended.
2. In order to ensure a good performance with respect to cross-modulation and microphony this tube should not be used in circuits with automatic gain control. For such applications a tube with variable transconductance is recommended.

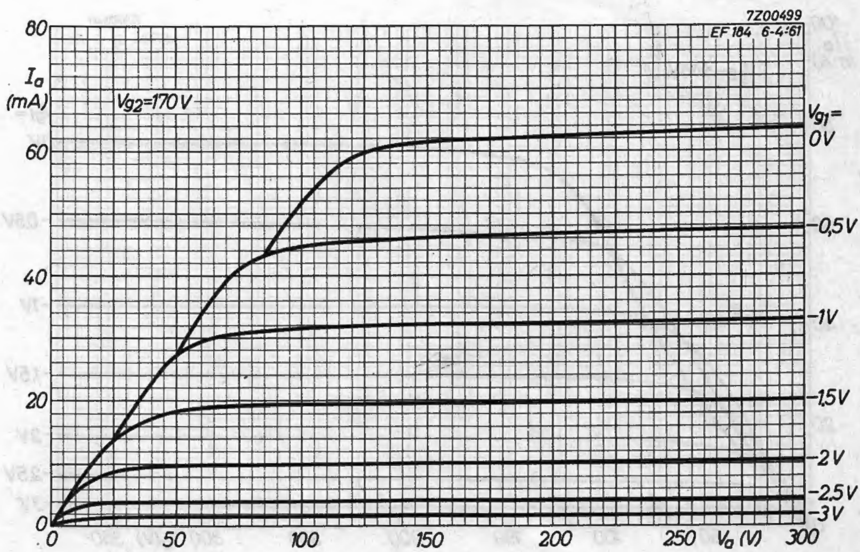
LIMITING VALUES (Design centre rating system)

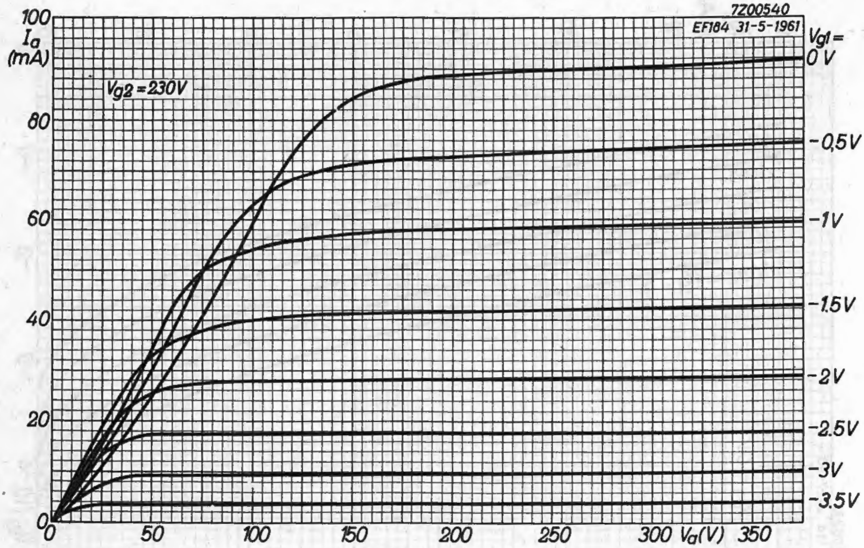
Anode voltage	V_{ao}	max.	550	V
	V_a	max.	250	V
Anode dissipation	W_a	max.	2.5	W
Grid No.2 voltage	V_{g2o}	max.	550	V
	V_{g2}	max.	250	V
Grid No.2 dissipation	W_{g2}	max.	0.9	W [1])
Grid No.1 voltage, negative peak	$-V_{g1p}$	max.	50	V
Cathode current	I_k	max.	25	mA
Cathode to heater voltage	V_{kf}	max.	150	V
Grid No.1 resistor	R_{g1}	max.	1	MΩ

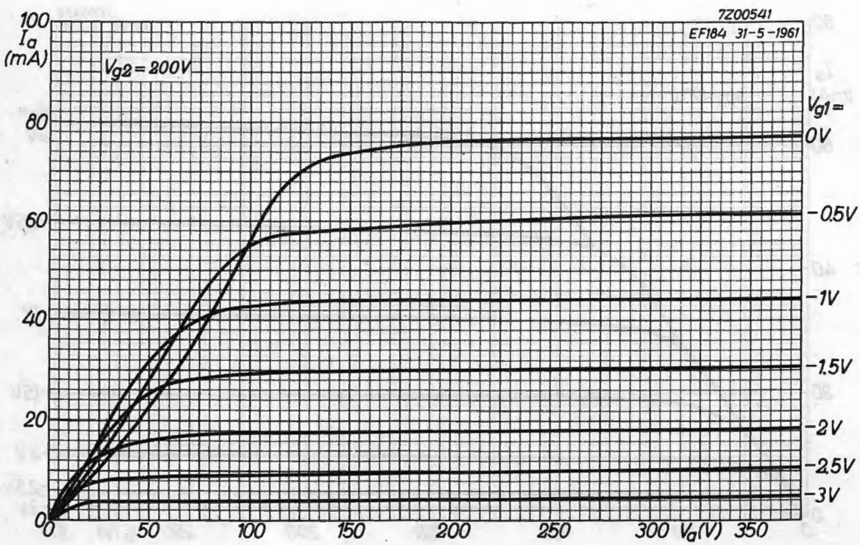
[1]) During a heating-up period not exceeding 15 seconds this value may be max. 1.5 W. At the values of R_{g2} specified under "Operating characteristics" there will be no risk of exceeding the maximum permissible value of W_{g2}.


7Z00363
EF 184 24-11-'60
V_{g_3}=0V
V_a=V_{g_2}=240V
220V
200V
180V
160V
S
(mA/V)
22
20
18
16
14
12
10
8
6
4
I_a
(mA)
30
25
20
15
10
5
0
V_{g_1}(V)
−4
−3
−2
−1
0


7Z00232
EF 184 27-7-60
$V_{g3} = 0V$
$V_a = V_{g2} = 240V$
220V
200V
180V
160V
I_{g2} (mA)
14
12
10
8
6
4
2
0
0
−1
−2
−3
−4
−5
V_{g1} (V)


7Z00499
EF 184 6-4-'61
I_a (mA)
V_{g2}=170V
V_{g1}= 0V
−0,5V
−1V
−1,5V
−2V
−2,5V
−3V
80
60
40
20
0
0
50
100
150
200
250
300
V_a (V)


7Z00540
EF184 31-5-1961
I_a (mA)
V_{g2} = 230V
V_{g1} =
0 V
-0,5V
-1V
-1.5V
-2V
-2.5V
-3V
-3.5V
V_a(V)
0
20
40
60
80
100
50
150
200
250
300
350


7Z00541
EF184 31-5-1961
I_a (mA)
V_{g2} = 200V
V_{g1} =
0V
-0.5V
-1V
-1.5V
-2V
-2.5V
-3V
V_a(V)
0
20
40
60
80
100
50
150
200
250
300
350

DOUBLE PENTODE

Double pentode intended for use as video output tube and as sync separator, A.G.C. amplifier or I.F. sound amplifier.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	810	mA

For further data and curves of this type please refer to type PFL200

A.F. OUTPUT PENTODE

Pentode intended for use as A.F. power amplifier.

QUICK REFERENCE DATA			
Anode current	I_a	100	mA
Transconductance	S	12.5	mA/V
Amplification factor	$\mu_{g_2g_1}$	11	
Output power, class B		100	W

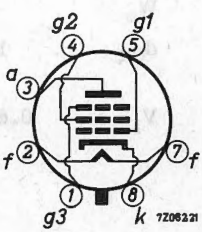
HEATING: Indirect by A.C. or D.C.; parallel supply

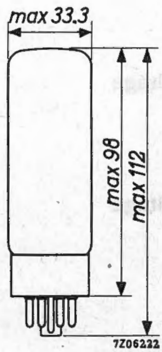
Heater voltage	V_f	6.3	V
Heater current	I_f	1.5	A

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Octal

Socket: 5903/13





CAPACITANCES

Anode to all except grid No.1	$C_{a(g_1)}$		8.4	pF
Grid No.1 to all except anode	$C_{g_1(a)}$		15.2	pF
Anode to grid No.1	C_{ag_1}	max.	1.1	pF
Grid No.1 to heater	C_{g_1f}	max.	1.0	pF
Cathode to heater	C_{kf}		10	pF

OPERATING CHARACTERISTICS

Class A

Supply voltage	V_b	265	265	V
Anode voltage	V_a	250	250	V
Grid No.2 series resistor	R_{g_2}	2	0	kΩ
Grid No.3 voltage	V_{g_3}	0	0	V
Grid No.1 voltage	V_{g_1}	−14.5	−13.5	V
Anode current	I_a	70	100	mA
Grid No.2 current	I_{g_2}	10	14.9	mA
Transconductance	S	11	12.5	mA/V
Amplification factor	$\mu_{g_2g_1}$	11	11	
Internal resistance	R_i	20	17	kΩ
Load resistance	$R_{a\sim}$	3.0	2.0	kΩ
Grid No.1 driving voltage	V_i	9.3	8.7	V_{RMS}
Output power	W_o	8	11	W
Distortion	d_{tot}	10	10	%
Grid No.1 driving voltage for W_o = 50 mW	V_i	0.65	0.5	V_{RMS}

OPERATING CHARACTERISTICS

Class B, two tubes in push-pull

Common grid No.2 series resistor (non decoupled)	R_{g2}		1000			470		Ω
Grid No.1 voltage	V_{g1}		−38			−32		V
Grid No.3 voltage	V_{g3}		0			0		V
Grid No.1 driving voltage	V_i	0	27	27	0	22.7	22.7	V_{RMS}
Load resistance	$R_{aa\sim}$	–	3.4	4.0	–	2.8	3.8	kΩ
Supply voltage	V_b	425	425	400	375	375	350	V
Anode voltage	V_a	420	400	375	370	350	325	V
Anode current	I_a	2x30	2x120	2x100	2x35	2x120	2x93	mA
Grid No.2 current	I_{g2}	2x4.4	2x25	2x25	2x4.7	2x25	2x25	mA
Output power	W_o	0	55	45	0	44	36	W
Distortion	d_{tot}	–	5	6	–	5	6	%

Common grid No.2 series resistor (non decoupled)	R_{g2}		750			750		Ω
Grid No.1 voltage	V_{g1}		−36			−39		V
Grid No.3 voltage	V_{g3}		0			0		V
Grid No.1 driving voltage	V_i	0	25.8	25.8	0	23.4	23.4	V_{RMS}
Load resistance	$R_{aa\sim}$	–	4	5	–	11	11	kΩ
Anode supply voltage	V_{ba}	500	500	475	800	800	750	V
Anode voltage	V_a	495	475	450	795	775	725	V
Grid No.2 supply voltage	V_{bg2}	400	400	375	400	400	375	V
Anode current	I_a	2x30	2x125	2x102	2x25	2x91	2x84	mA
Grid No.2 current	I_{g2}	2x4	2x25	2x25	2x3	2x19	2x19	mA
Output power	W_o	0	70	58	0	100	90	W
Distortion	d_{tot}	–	5	6	–	5	6	%

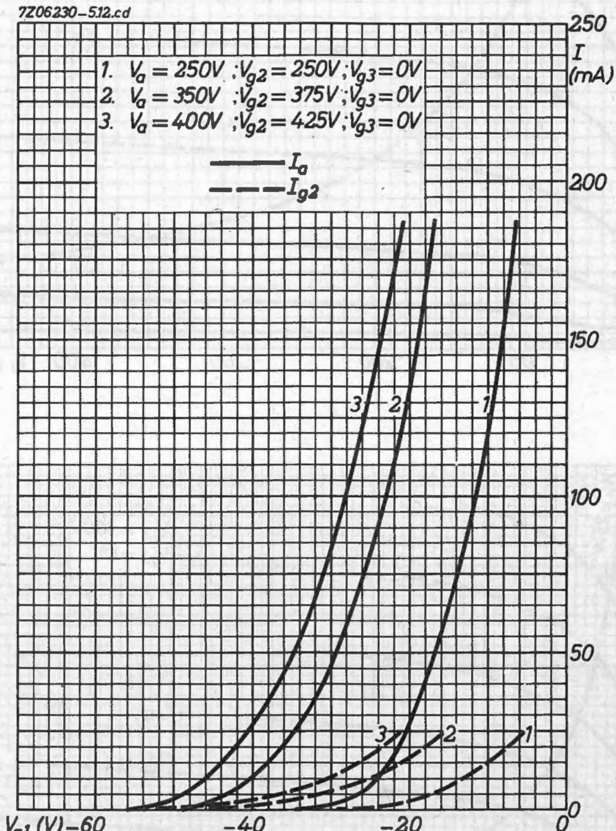
OPERATING CHARACTERISTICS

Class AB, two tubes in push-pull

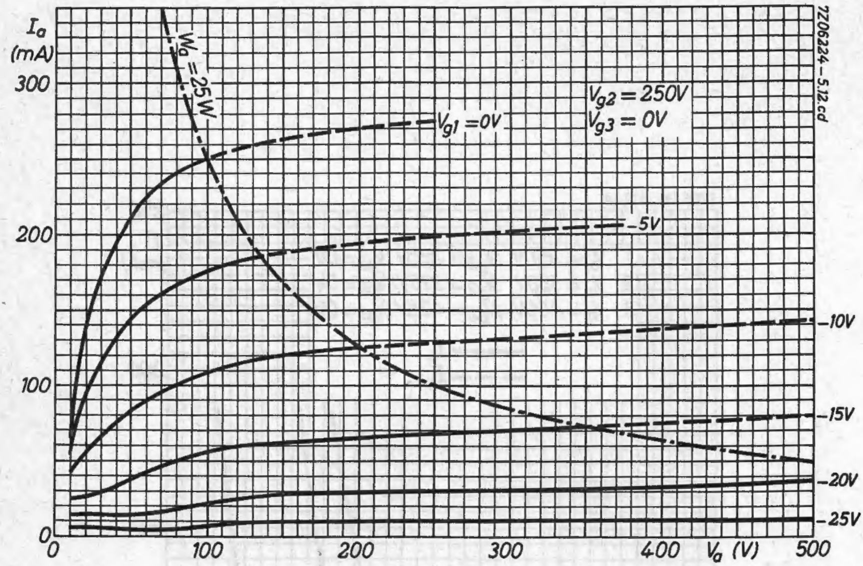
Load resistance	$R_{aa\sim}$		3.4	kΩ
Common grid No.2 series resistor (non decoupled)	R_{g2}		470	Ω
Common cathode resistor	R_k		130	Ω
Grid No.3 voltage	V_{g3}		0	V
Grid No.1 driving voltage	V_i	0	21	V_{RMS}
Supply voltage	V_b	375	375	V
Anode to earth voltage	V_a+V_{Rk}	355	350	V
Anode current	I_a	2x75	2x95	mA
Grid No.2 current	I_{g2}	2x11.5	2x22.5	mA
Output power	W_o	0	35	W
Distortion	d_{tot}	–	5	%

LIMITING VALUES (Design centre rating system)

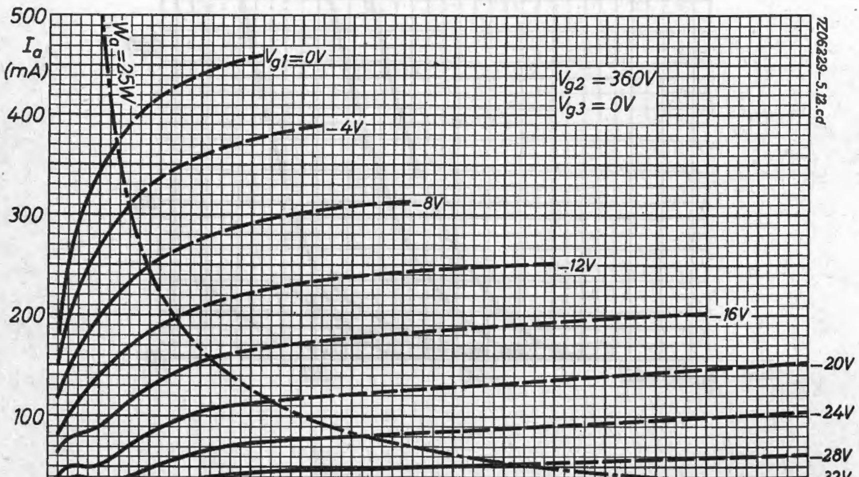
Anode voltage	V_{a_o}	max.	2000	V
	V_a	max.	800	V
Grid No.2 voltage	V_{g2_o}	max.	800	V
	V_{g2}	max.	500	V
Anode dissipation				
at $V_i = 0$	W_a	max.	25	W
at $V_i > 0$	W_a	max.	27.5	W
Grid No.2 dissipation	W_{g2}	max.	8	W
Cathode current	I_k	max.	150	mA
Grid No.1 resistor				
for class A and AB	R_{g1}	max.	0.7	MΩ
for class B	R_{g1}	max.	0.5	MΩ
Cathode to heater voltage	V_{kf}	max.	100	V



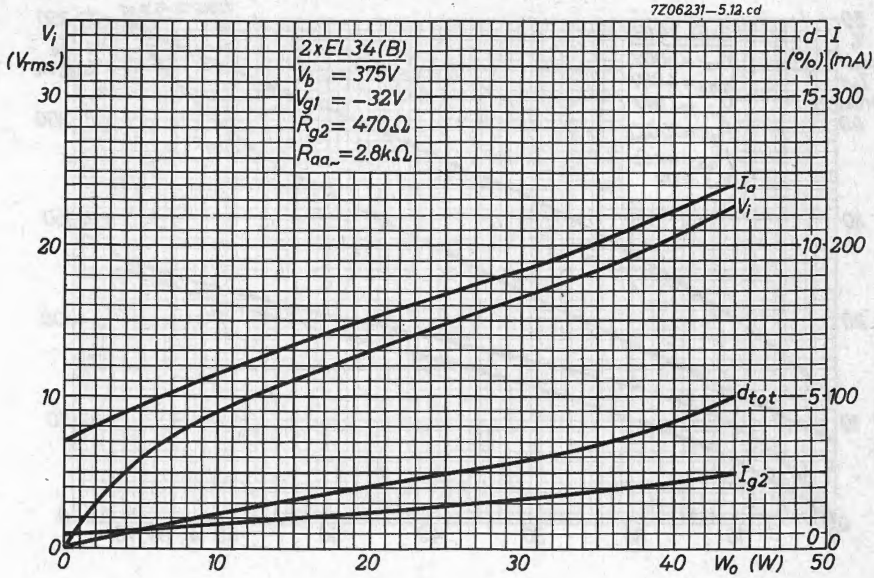
7Z06230-5.12.cd
1. $V_a = 250V$; $V_{g2} = 250V$; $V_{g3} = 0V$
2. $V_a = 350V$; $V_{g2} = 375V$; $V_{g3} = 0V$
3. $V_a = 400V$; $V_{g2} = 425V$; $V_{g3} = 0V$
I_a
I_{g2}
250
I (mA)
200
150
100
50
0
V_{g1} (V) −60
−40
−20
0
3
2
1
3
2
1

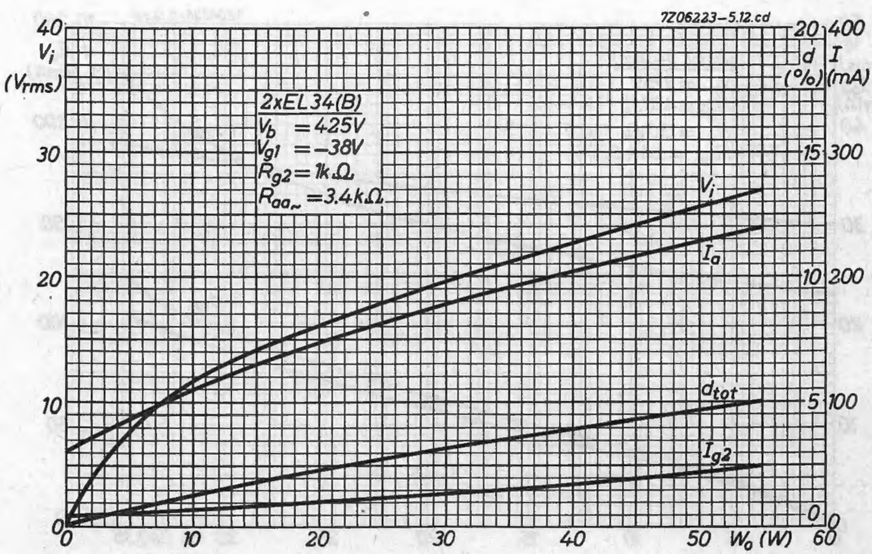


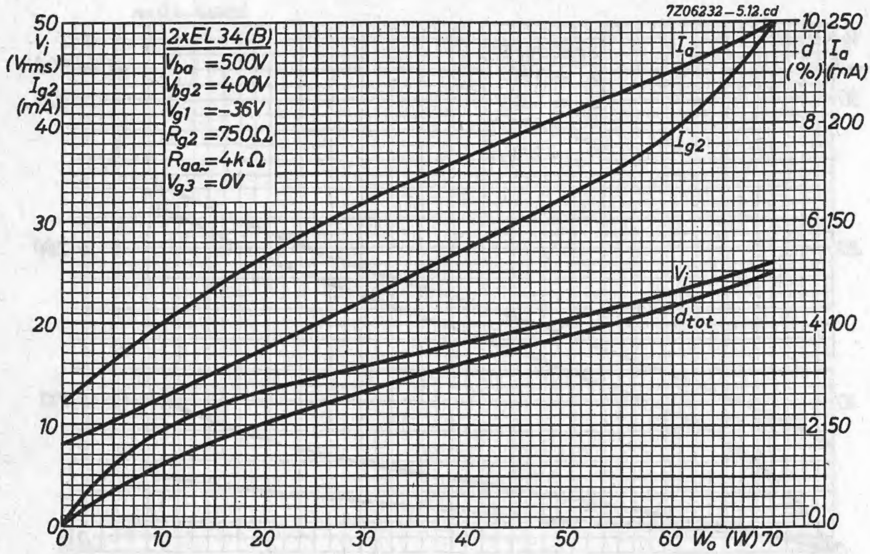
I_a (mA)
300
200
100
0
0
100
200
300
400
V_a (V)
500
$W_a = 25W$
$V_{g1} = 0V$
$-5V$
$-10V$
$-15V$
$-20V$
$-25V$
$V_{g2} = 250V$
$V_{g3} = 0V$
7Z06224-5.12.cd

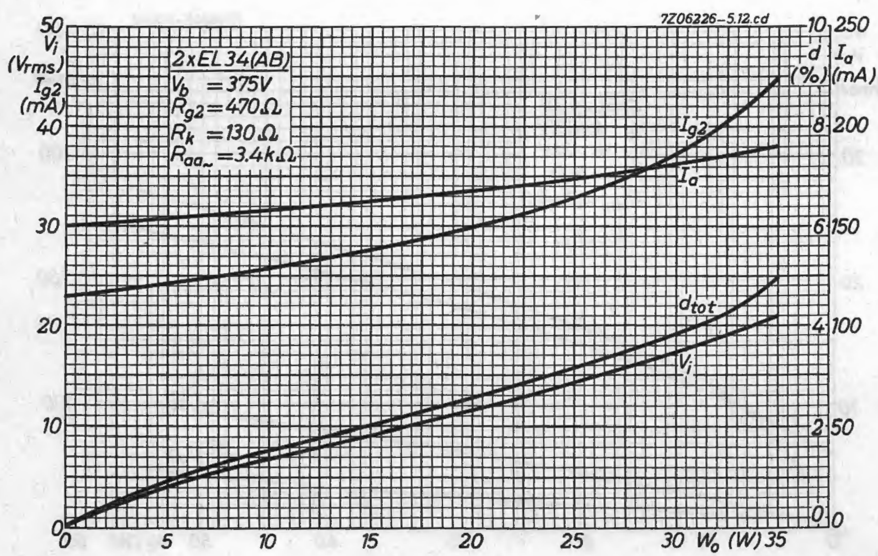


500
I_a (mA)
400
300
200
100
0
0
100
200
300
400
500
600
V_a (V)
700
$W_a = 25W$
$V_{g1} = 0V$
$-4V$
$-8V$
$-12V$
$-16V$
$-20V$
$-24V$
$-28V$
$-32V$
$V_{g2} = 360V$
$V_{g3} = 0V$
7Z06229-5.12.cd


7Z06231–5.12.cd
V_i (V_{rms})
2xEL34(B)
$V_b = 375V$
$V_{g1} = -32V$
$R_{g2} = 470\Omega$
$R_{aa\sim} = 2.8k\Omega$
I_a
V_i
d_{tot}
I_{g2}
d (%)
I (mA)
W_o (W)
0
10
20
30
40
50
5
15
100
200
300


7Z06223–5.12.cd
V_i (V_{rms})
2xEL34(B)
$V_b = 425V$
$V_{g1} = -38V$
$R_{g2} = 1k\Omega$
$R_{aa\sim} = 3.4k\Omega$
V_i
I_a
d_{tot}
I_{g2}
d (%)
I (mA)
W_o (W)
0
10
20
30
40
50
60
5
15
100
200
300
400


7Z06232-5.12.cd
2xEL34(B)
V_{ba} =500V
V_{bg2}=400V
V_{g1} =-36V
R_{g2} =750Ω
$R_{aa\sim}$=4kΩ
V_{g3} =0V
V_i (V_{rms})
I_{g2} (mA)
d (%)
I_a (mA)
I_a
I_{g2}
V_i
d_{tot}
W_o (W)


7Z06226-5.12.cd
2xEL34(AB)
V_b =375V
R_{g2}=470Ω
R_k =130Ω
$R_{aa\sim}$ =3.4kΩ
V_i (V_{rms})
I_{g2} (mA)
d (%)
I_a (mA)
I_{g2}
I_a
d_{tot}
V_i
W_o (W)

LINE AND A.F. OUTPUT PENTODE

Pentode intended for use as line output tube in television receivers and as A.F. power amplifier.

HEATING: Indirectly by A.C. or D.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	1.25	A

OPERATING CHARACTERISTICS

A.F. amplifier. Class B, two tubes in push pull

Anode voltage	V_a	300		V
Grid No.2 voltage	V_{g_2}	150		V
Grid No.1 voltage	V_{g_1}	-29		V
Load resistance	$R_{aa\sim}$	3.5		kΩ
Grid No.1 driving voltage	V_i	0	20	V_{RMS}
Anode current	I_a	2x18	2x100	mA
Grid No.2 current	I_{g_2}	2x0.5	2x19	mA
Output power	W_o	0	44.5	W
Distortion	d_{tot}	-	7.2	%

LIMITING VALUES (Design centre rating system)

Anode voltage	V_a	max.	250	V
Anode voltage for class B operation	V_a	max.	300	V
Cathode to heater voltage	V_{kf}	max.	100	V

For further data and curves of this type please refer to PL36

A.F. OUTPUT PENTODE

Pentode intended for use as A.F. power amplifier.

QUICK REFERENCE DATA			
Anode current	I_a	36	mA
Transconductance	S	10	mA/V
Amplification factor	$\mu_{g_2g_1}$	22	
Output power	W_o	4.8	W

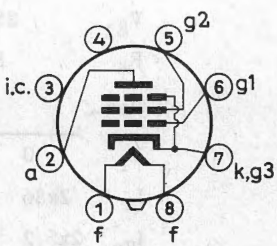
HEATING: Indirect by A.C. or D.C.; parallel supply

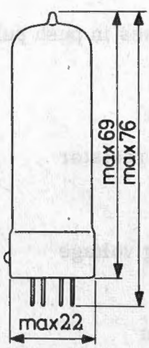
Heater voltage	V_f	6.3	V
Heater current	I_f	710	mA

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Rimlock





CAPACITANCES

Anode to all except grid No.1	$C_{a(g_1)}$		7.8	pF
Grid No.1 to all except anode	$C_{g_1(a)}$		10.2	pF
Anode to grid No.1	C_{ag_1}	max.	1	pF
Grid No.1 to heater	C_{g_1f}	max.	0.15	pF

OPERATING CHARACTERISTICS

Class A

Anode voltage	V_a	250	V
Grid No. 2 voltage	V_{g_2}	250	V
Cathode resistor	R_k	170	Ω
Anode current	I_a	36	mA
Grid No. 2 current	I_{g_2}	5.2	mA
Transconductance	S	10	mA/V
Amplification factor	$\mu_{g_2g_1}$	22	
Internal resistance	R_i	40	kΩ
Load resistance	$R_{a\sim}$	7	kΩ
Grid No. 1 driving voltage	V_i (d_{tot} = 10%)	3.8	V_{RMS}
Output power			
at d_{tot} = 10%	W_o	3.9	W
at I_{g_1} = +0.3 μA	W_o	4.8	W
Grid No. 1 driving voltage			
for W_o = 50 mW	V_i	0.32	V_{RMS}

Class AB, two tubes in push pull

Anode voltage	V_a	250		V
Grid No. 2 voltage	V_{g_2}	250		V
Common cathode resistor	R_k	85		Ω
Load resistance	$R_{aa\sim}$	7		kΩ
Grid No. 1 driving voltage	V_i	0	5.6	V_{RMS}
Anode current	I_a	2x36	2x39.5	mA
Grid No. 2 current	I_{g_2}	2x5.2	2x8	mA
Output power	W_o	0	9.4	W
Distortion	d_{tot}		4.6	%

OPERATING CHARACTERISTICS IN TRIODE CONNECTION
(g_2 connected to a)

Class A

Anode voltage	V_a	250	V
Cathode resistor	R_k	250	Ω
Load resistance	$R_{a\sim}$	3.5	kΩ
Anode current	I_a	33	mA
Grid No.1 driving voltage	V_i	6	V_{RMS}
Output power	W_o	1.55	W
Distortion	d_{tot}	8	%

LIMITING VALUES (Design centre rating system)

Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	300	V
Grid No.2 voltage	V_{g2_o}	max.	550	V
	V_{g2}	max.	300	V
Anode dissipation	W_a	max.	9	W
Grid No.2 dissipation				
at $V_i = 0$	W_{g2}	max.	1.4	W
at W_o = max.	W_{g2}	max.	3.3	W
Cathode current	I_k	max.	55	mA
Grid No.1 resistor	R_{g1}	max.	1	MΩ
Cathode to heater voltage	V_{kf}	max.	100	V

A.F. OUTPUT PENTODE

Pentode intended for use as A.F. power amplifier in car radio sets.

QUICK REFERENCE DATA			
Anode current	I_a	26	mA
Transconductance	S	3.2	mA/V
Amplification factor	$\mu_{g_2g_1}$	11	
Output power	W_o	2.8	W

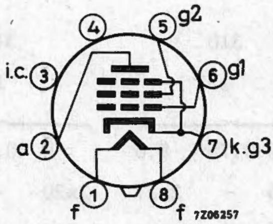
HEATING: Indirect by A.C. or D.C.; parallel supply

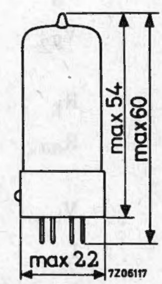
Heater voltage	V_f	6.3	V
Heater current	I_f	200	mA

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Rimlock





CAPACITANCES

Anode to all except grid No.1	$C_{a(g_1)}$	6.2	pF
Grid No.1 to all except anode	$C_{g_1(a)}$	4.3	pF
Anode to grid No.1	C_{ag_1}	max. 0.2	pF
Grid No.1 to heater	C_{g_1f}	max. 0.2	pF

OPERATING CHARACTERISTICS

Class A

Anode voltage	V_a	200	225	V
Grid No.2 voltage	V_{g2}	200	225	V
Cathode resistor	R_k	360	360	Ω
Anode current	I_a	22.5	26	mA
Grid No.2 current	I_{g2}	3.5	4.1	mA
Transconductance	S	3.2	3.2	mA/V
Amplification factor	μ_{g2g1}	11	11	
Internal resistance	R_i	90	90	kΩ
Load resistance	$R_{a\sim}$	9	9	kΩ
Grid No.1 driving voltage	V_i	6.8	8	V_{RMS}
Output power	W_o	2.1	2.8	W
Distortion	d_{tot}	11	12	%
Grid No.1 driving voltage for $W_o = 50$ mW	V_i	0.8	0.75	V_{RMS}

Class AB

Anode voltage	V_a		200			250		V
Grid No.2 voltage	V_{g2}		200			250		V
Common cathode resistor	R_k		310			310		Ω
Load resistance	$R_{aa\sim}$		15			15		kΩ
Grid No.1 driving voltage	V_i	0	0.75	9.6	0	0.7	12.5	V_{RMS}
Anode current	I_a	2x16	-	2x17	2x20	-	2x21.5	mA
Grid No.2 current	I_{g2}	2x2.6	-	2x5.6	2x3.2	-	2x6.7	mA
Output power	W_o	0	0.05	4.1	0	0.05	7	W
Distortion	d_{tot}	-	-	5.5	-	-	5.5	%

OPERATING CHARACTERISTICS (continued)

Class B

Anode voltage	V_a		200			250		V
Grid No.2 voltage	V_{g_2}		200			250		V
Grid No.1 voltage	V_{g_1}		−17			−22.5		V
Load resistance	$R_{aa\sim}$		16			16		kΩ
Grid No.1 driving voltage	V_i	0	1.5	12	0	1.7	16	V_{RMS}
Anode current	I_a	2x5	–	2x16	2x5	–	2x20	mA
Grid No.2 current	I_{g_2}	2x0.8	–	2x4.6	2x0.8	–	2x6.5	mA
Output power	W_o	0	0.05	4	0	0.05	6.5	W
Distortion	d_{tot}	–	–	3.5	–	–	5	%

LIMITING VALUES (Design centre rating system)

Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	300	V
Anode dissipation	W_a	max.	6	W
Grid No.2 voltage	$V_{g_{2o}}$	max.	550	V
	V_{g_2}	max.	300	V
Grid No.2 dissipation				
at $V_i = 0$	W_{g_2}	max.	1	W
at W_o = max.	W_{g_2}	max.	2	W
Cathode current	I_k	max.	35	mA
Grid No.1 resistor	R_{g_1}	max.	2	MΩ
Cathode to heater voltage	V_{kf}	max.	100	V

OUTPUT PENTODE FOR LINE DEFLECTION AND A.F. OUTPUT PENTODE

Output pentode intended for use as horizontal deflection amplifier in small screen television receivers and as A. F. power amplifier.

QUICK REFERENCE DATA				
Anode peak voltage	V_{ap}	max.	7	kV
Cathode current	I_k	max.	180	mA
Output power, class B two tubes	W_o		20	W

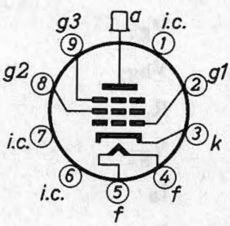
HEATING : Indirect by A. C. ot D. C. ; parallel supply

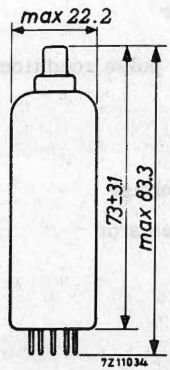
Heater voltage	V_f	6.3	V
Heater current	I_f	1.05	A

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





CAPACITANCES

Anode to all except grid No. 1	$C_{a(g1)}$		6	pF
Grid No. 1 to all except anode	$C_{g1(a)}$		14	pF
Anode to grid No. 1	C_{ag1}	max.	0.8	pF
Anode to cathode	C_{ak}	max.	0.1	pF
Grid No. 1 to heater	C_{g1f}	max.	0.2	pF

TYPICAL CHARACTERISTICS

A)

Anode voltage	V_a	170	V
Grid No. 3 voltage	V_{g3}	0	V
Grid No. 2 voltage	V_{g2}	170	V
Grid No. 1 voltage	V_{g1}	−24	V
Anode current	I_a	45	mA
Grid No. 2 current	I_{g2}	2.4	mA
Transconductance	S	6.3	mA/V
Internal resistance	R_i	11	kΩ
Amplification factor	μ_{g2g1}	5.0	

B) (Measured under pulse conditions)

Anode voltage	V_a	40	V
Grid No. 3 voltage	V_{g3}	0	V
Grid No. 2 supply voltage	V_{bg2}	190	V
Grid No. 2 series resistor	R_{g2}	4.7	kΩ
Grid No. 1 voltage	V_{g1}	0	V
Anode current	I_a	180	mA
Grid No. 2 current	I_{g2}	18	mA

OPERATING CONDITIONS

Stabilized circuits (D.C. feedback)

Cut-off voltage

The minimum required cut-off voltage ($-V_{g1}$) during flyback is 120 V at V_a = 6000 V, V_{g2} = 190 V, and Z_{g1} = 1 kΩ at line-frequency.

Supply-voltage: See page 5

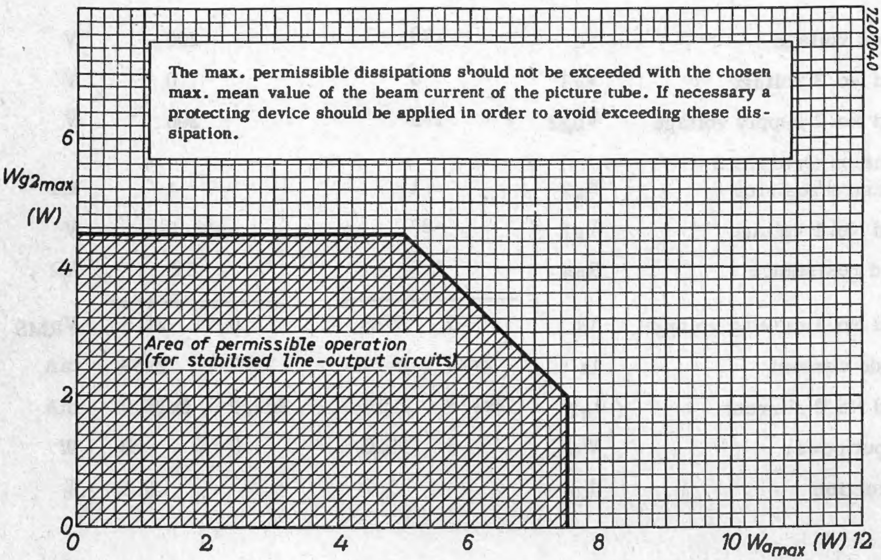
Minimum required value of the screengrid voltage and of the anode voltage, when the tube is used in a line output stage.
The graphs refer to nominal mains voltage provided the specified values of I_a at V_a min, will be available throughout life of the tube at supply voltage values 10% below nominal.
In order to prevent Barkhausen interferences and less of stabilisation, care should be taken that the anode voltage never drops below the specified V_a min. during the scanning period.

OPERATING CHARACTERISTICS as class B push-pull A.F. power amplifier, two tubes.

Anode voltage	V_a	170		200		V
Grid No. 3 voltage	V_{g3}	0		0		V
Grid No. 2 supply voltage	V_{bg2}	170		200		V
Common Grid No. 2 series resistor	R_{g2}	1		1		kΩ
Grid No. 1 voltage	V_{g1}	−27		−31.5		V
Load resistance	$R_{aa\sim}$	2.5		2.5		kΩ
Grid No. 1 driving voltage	V_i	0	16.5	0	21.5	V_{RMS}
Anode current	I_a	2x25	2x72	2x27	2x84	mA
Grid No. 2 current	I_{g2}	2x1.5	2x10	2x2.0	2x11.0	mA
Output power	W_o	0	13.0	0	20	W
Distortion	d_{tot}	–	5.2	–	6.5	%

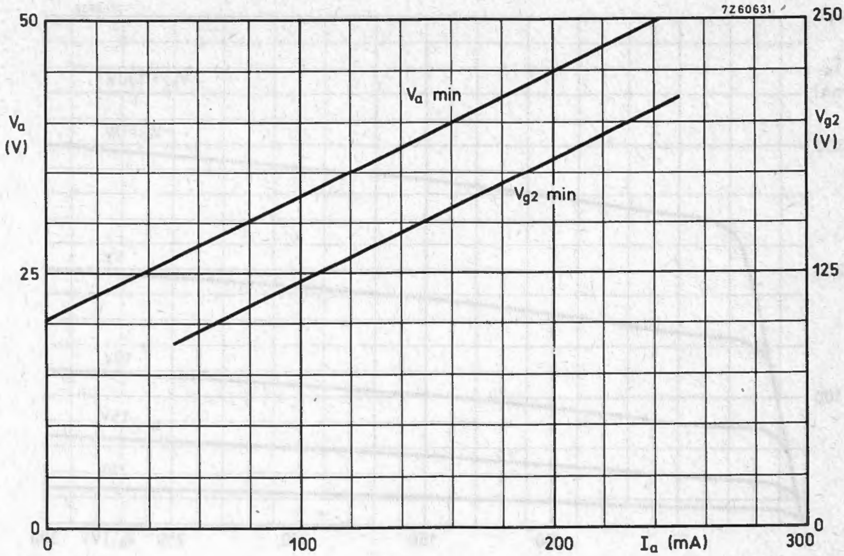
LIMITING VALUES (Design centre rating system)

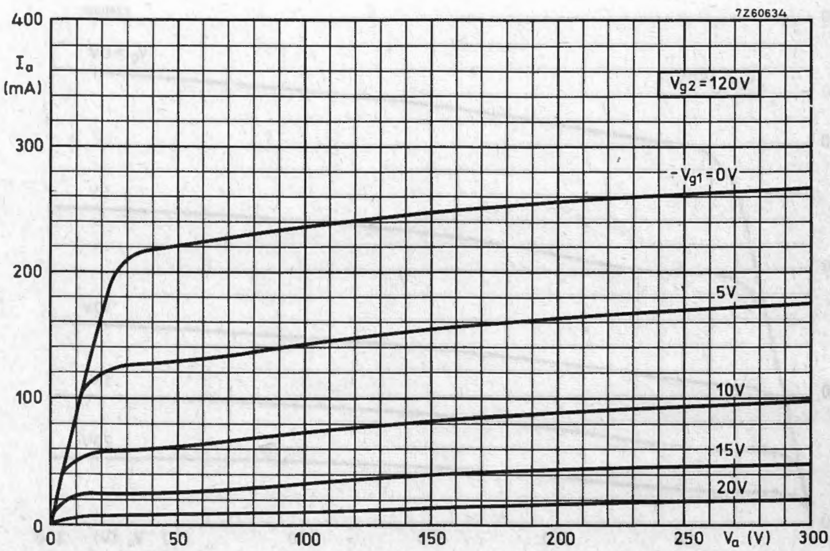
Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	250	V
Anode voltage, peak	V_{ap}	max.	7	kV [1]
negative peak	$-V_{ap}$	max.	7	kV [1]
Anode dissipation	W_a	See figure below		
Grid No. 2 dissipation	W_{g2} [2]	See figure below		
Anode + grid No. 2 dissipation	$W_a + W_{g2}$	See figure below		
Grid No. 2 voltage	V_{g2_o}	max.	550	V
	V_{g2}	max.	250	V
Cathode current	I_k	max.	180	mA
Cathode to heater voltage	V_{kf}	max.	100	V
Grid No. 1 resistor	R_{g1}	max.	0.5	MΩ

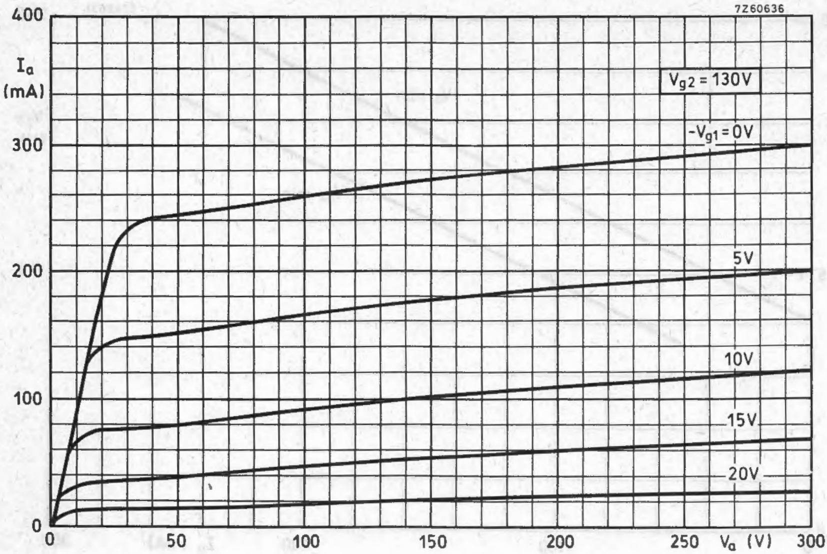


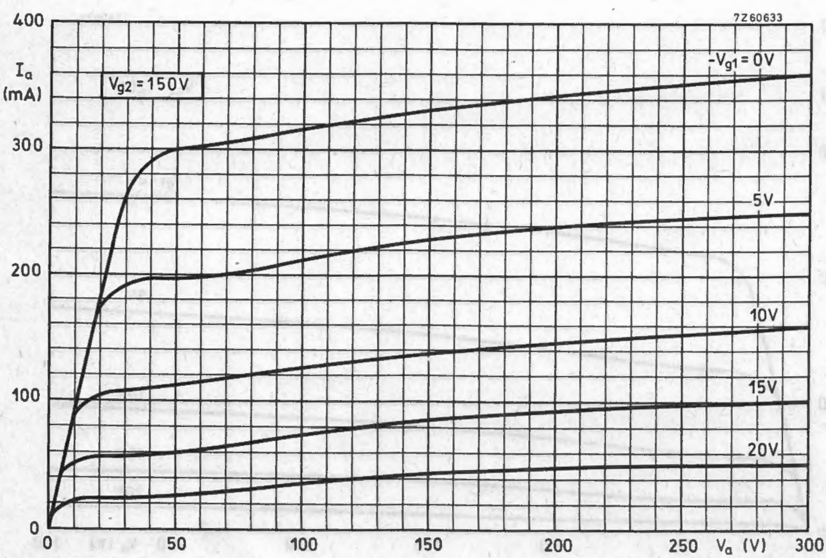
1) Maximum pulse duration 22 % of a cycle but maximum 18 μs.

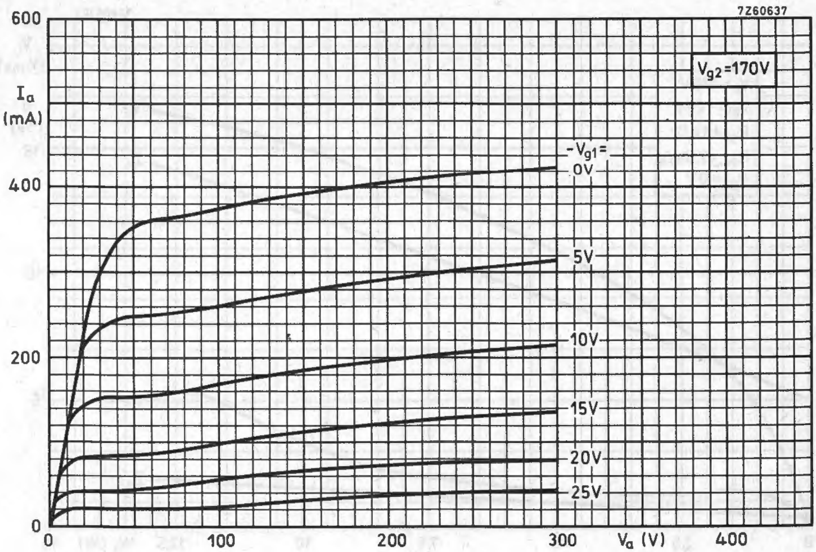
2) During the heating-up of the cathode W_{g2} = max. 6 W.

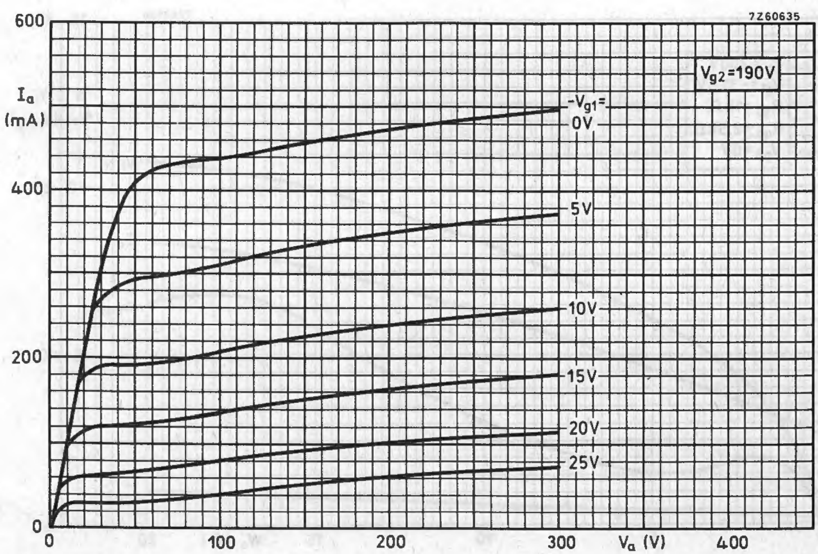

7Z60631
50
25
0
250
125
0
V_a (V)
V_{g2} (V)
V_a min
V_{g2} min
0
100
200
300
I_a (mA)

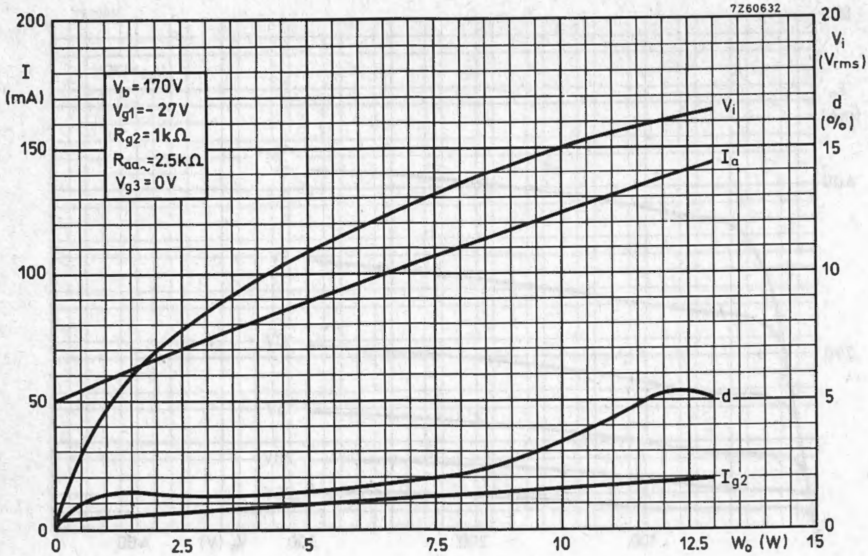

7Z60634
400
300
200
100
0
I_a (mA)
V_{g2} = 120 V
$-V_{g1}$ = 0 V
5V
10V
15V
20V
0
50
100
150
200
250
300
V_a (V)

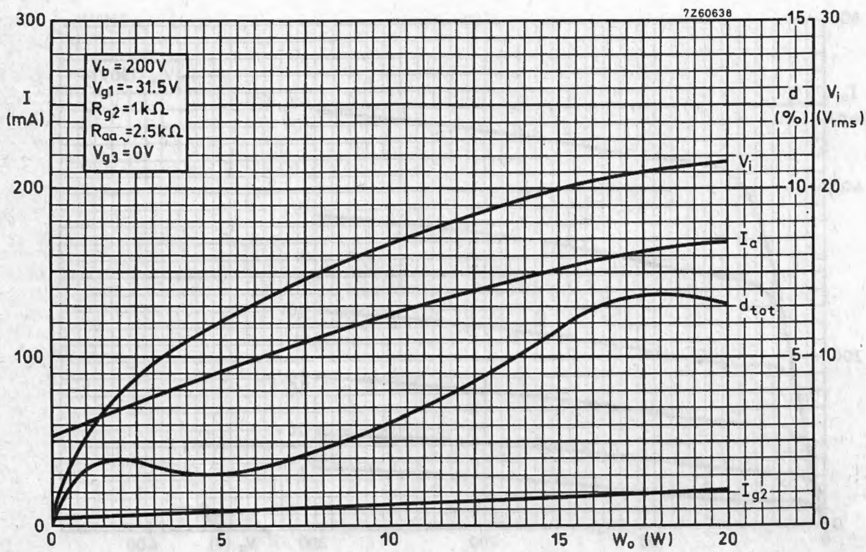

7Z60636
400
I_a
(mA)
300
200
100
0
V_{g2} = 130V
$-V_{g1}$ = 0V
5V
10V
15V
20V
0
50
100
150
200
250
V_a (V)
300


7Z60633
400
I_a
(mA)
300
200
100
0
V_{g2} = 150V
$-V_{g1}$ = 0V
5V
10V
15V
20V
0
50
100
150
200
250
V_a (V)
300


7Z60637
600
400
200
0
I_a (mA)
V_{g2}=170V
$-V_{g1}$=
0V
5V
10V
15V
20V
25V
0
100
200
300
V_a (V)
400


7Z60635
600
400
200
0
I_a (mA)
V_{g2}=190V
$-V_{g1}$=
0V
5V
10V
15V
20V
25V
0
100
200
300
V_a (V)
400


7Z60632
I (mA)
200
150
100
50
0
Vb = 170V
Vg1 = - 27V
Rg2 = 1kΩ
Raa~ = 2.5kΩ
Vg3 = 0V
Vi
Ia
d
Ig2
0
2.5
5
7.5
10
12.5
Wo (W)
15
20
Vi (Vrms)
d (%)
15
10
5
0


7Z60638
I (mA)
300
200
100
0
Vb = 200V
Vg1 = - 31.5V
Rg2 = 1kΩ
Raa~ = 2.5kΩ
Vg3 = 0V
Vi
Ia
dtot
Ig2
0
5
10
15
Wo (W)
20
d (%)
Vi (Vrms)
15
30
10
20
5
10
0

FRAME AND A.F. OUTPUT PENTODE

Pentode intended for use as frame output tube in television receivers and as A.F. power amplifier.

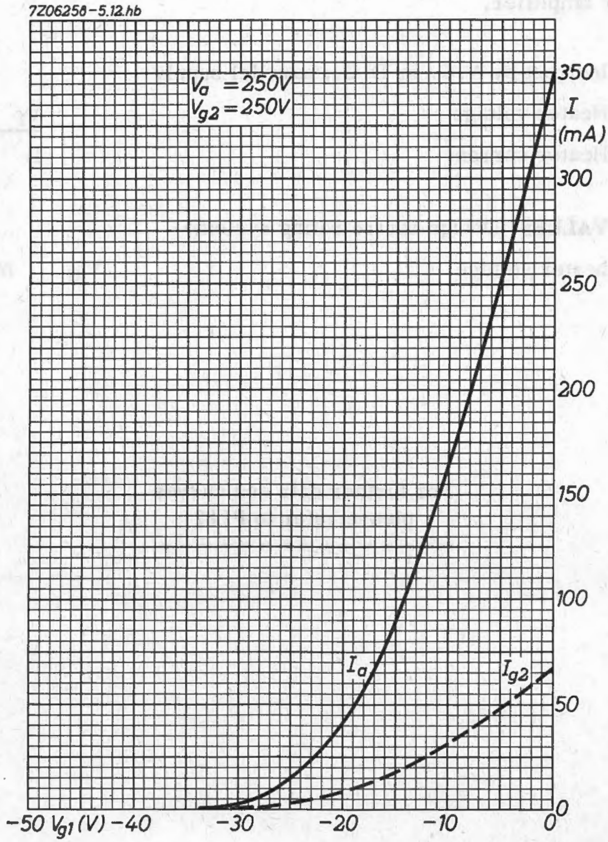
HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	800	mA

LIMITING VALUES (Design centre rating system)

Cathode to heater voltage	V_{kf}	max. 100	V

For further data and curves please refer to PL82


7Z06258-5.12.hb
V_a =250V
V_{g2}=250V
I
(mA)
350
300
250
200
150
100
50
0
I_a
I_{g2}
-50 V_{g1} (V) -40
-30
-20
-10
0

VIDEO OUTPUT PENTODE

Pentode intended for use as video output tube.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	710	mA

TYPICAL CHARACTERISTICS

Anode voltage	V_a	250	V
Grid No.3 voltage	V_{g_3}	0	V
Grid No.2 voltage	V_{g_2}	250	V
Grid No.1 voltage	V_{g_1}	-5.5	V
Anode current	I_a	36	mA
Grid No.2 current	I_{g_2}	5	mA
Transconductance	S	10	mA/V
Amplification factor	$\mu_{g_2g_1}$	24	-
Internal resistance	R_i	0.13	MΩ

LIMITING VALUES (Design centre rating system)

Anode voltage	V_a	max. 300	V
Grid No.2 voltage	V_{g_2}	max. 300	V
Cathode to heater voltage	V_{kf}	max. 100	V

For further data and curves refer to PL83

A.F. OUTPUT PENTODE

Pentode intended for use as A.F. power amplifier.

QUICK REFERENCE DATA			
Anode current	I_a	48	mA
Transconductance	S	11.3	mA/V
Amplification factor	$\mu_{g_2g_1}$	19	
Output power	W_o	6.0	W

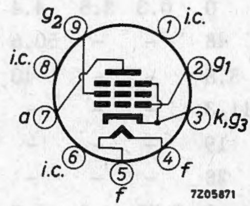
HEATING: Indirect by A.C. or D.C.; parallel supply

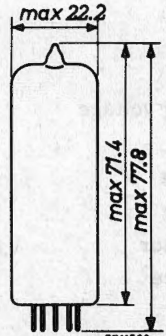
Heater voltage	V_f	6.3	V
Heater current	I_f	760	mA

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





CAPACITANCES

Anode to all except grid No.1	$C_{a(g_1)}$	6.5	pF
Grid No.1 to all except anode	$C_{g_1(a)}$	10.8	pF
Anode to grid No.1	C_{ag_1}	max. 0.5	pF
Grid No.1 to heater	C_{g_1f}	max. 0.25	pF

OPERATING CHARACTERISTICS

Class A

Anode voltage	V_a	250	V
Grid No.2 voltage	V_{g2}	250	V
Grid No.1 voltage	V_{g1}	-7.3	V
Cathode resistor	R_k	135	Ω
Load resistance	$R_{a\sim}$	5.2	kΩ

Grid No.1 driving voltage	V_i	0	0.3	3.4	4.3	4.7 [2]	V_{RMS}
Anode current	I_a	48	–	–	49.5	49.2	mA
Grid No.2 current	I_{g2}	5.5	–	–	10.8	11.6	mA
Transconductance	S	11.3	–	–	–	–	mA/V
Amplification factor	μ_{g2g1}	19	–	–	–	–	
Internal resistance	R_i	38	–	–	–	–	kΩ
Output power	W_o [1]	0	0.05	4.5	5.7	6.0	W
Distortion, total	d_{tot} [1]	–	–	6.8	10	–	%
second harmonic	d_2 [1]	–	–	3.0	2.0	–	%
third harmonic	d_3 [1]	–	–	5.8	9.5	–	%

Anode voltage	V_a	250	V
Grid No.2 voltage	V_{g2}	250	V
Grid No.1 voltage	V_{g1}	-7.3	V
Cathode resistor	R_k	135	Ω
Load resistance	$R_{a\sim}$	4.5	kΩ

Grid No.1 driving voltage	V_i	0	0.3	3.5	4.4	4.8 [2]	V_{RMS}
Anode current	I_a	48	–	–	50.6	50.5	mA
Grid No.2 current	I_{g2}	5.5	–	–	10	11	mA
Transconductance	S	11.3	–	–	–	–	mA/V
Amplification factor	μ_{g2g1}	19	–	–	–	–	
Internal resistance	R_i	38	–	–	–	–	kΩ
Output power	W_o [1]	0	0.05	4.5	5.7	6.0	W
Distortion, total	d_{tot} [1]	–	–	7.5	10	–	%
second harmonic	d_2 [1]	–	–	5.7	5.0	–	%
third harmonic	d_3 [1]	–	–	4.5	8	–	%

1) Measured with fixed bias

2) At I_{g1} = +0.3 μA

OPERATING CHARACTERISTICS (continued)

Class A (continued)

Anode voltage	V_a		250			V
Grid No.2 voltage	V_{g2}		250			V
Grid No.1 voltage	V_{g1}		-8.4			V
Cathode resistor	R_k		210			Ω
Load resistance	$R_{a\sim}$		7			kΩ
Grid No.1 driving voltage	V_i	0	0.3	3.5	5.5 2)	V_{RMS}
Anode current	I_a	36	-	36.8	36	mA
Grid No.2 current	I_{g2}	4.1	-	8.5	14.6	mA
Transconductance	S	10	-	-	-	mA/V
Amplification factor	μ_{g2g1}	19	-	-	-	
Internal resistance	R_i	40	-	-	-	kΩ
Output power	W_o 1)	0	0.05	4.2	5.6	W
Distortion, total	d_{tot} 1)	-	-	10	-	%
second harmonic	d_2 1)	-	-	1.7	-	%
third harmonic	d_3 1)	-	-	8.7	-	%

Anode voltage	V_a		250			V
Grid No.2 voltage	V_{g2}		210			V
Grid No.1 voltage	V_{g1}		-6.4			V
Cathode resistor	R_k		160			Ω
Load resistance	$R_{a\sim}$		7			kΩ
Grid No.1 driving voltage	V_i	0	0.3	3.4	3.8 2)	V_{RMS}
Anode current	I_a	36	-	36.6	36.5	mA
Grid No.2 current	I_{g2}	3.9	-	7.3	8.0	mA
Transconductance	S	10.4	-	-	-	mA/V
Amplification factor	μ_{g2g1}	19	-	-	-	
Internal resistance	R_i	40	-	-	-	kΩ
Output power	W_o 1)	0	0.05	4.3	4.7	W
Distortion, total	d_{tot} 1)	-	-	10	-	%
second harmonic	d_2 1)	-	-	1.8	-	%
third harmonic	d_3 1)	-	-	9.3	-	%

1) Measured with fixed bias

2) At $I_{g1} = +0.3\ \mu A$

OPERATING CHARACTERISTICS (continued)

Class B, two tubes in push-pull

Anode voltage	V_a	250		300		V
Grid No.2 voltage	V_{g_2}	250		300		V
Grid No.1 voltage	V_{g_1}	-11.6		-14.7		V
Load resistance	$R_{aa\sim}$	8		8		kΩ
Grid No.1 driving voltage	V_i	0	8	0	10	V_{RMS}
Anode current	I_a	2x10	2x37.5	2x7.5	2x46	mA
Grid No.2 current	I_{g_2}	2x1.1	2x7.5	2x0.8	2x11	mA
Output power	W_o	0	11	0	17	W
Distortion	d_{tot}	-	3	-	4	%

Class AB, two tubes in push-pull

Anode voltage	V_a	250		300		V
Grid No.2 voltage	V_{g_2}	250		300		V
Common cathode resistor	R_k	130		130		Ω
Load resistance	$R_{aa\sim}$	8		8		kΩ
Grid No.1 driving voltage	V_i	0	8	0	10	V_{RMS}
Anode current	I_a	2x31	2x37.5	2x36	2x46	mA
Grid No.2 current	I_{g_2}	2x3.5	2x7.5	2x4	2x11	mA
Output power	W_o	0	11	0	17	W
Distortion	d_{tot}	-	3	-	4	%

OPERATING CHARACTERISTICS IN TRIODE CONNECTION
(g_2 connected to a)

Class A

Anode voltage	V_a		250		V
Cathode resistor	R_k		270		Ω
Load resistance	$R_{a\sim}$		3.5		kΩ
Grid No.1 driving voltage	V_i	0	1.0	6.7	V_{RMS}
Anode current	I_a	34	-	36	mA
Output power	W_o	-	0.05	1.95	W
Distortion	d_{tot}	-	-	9	%

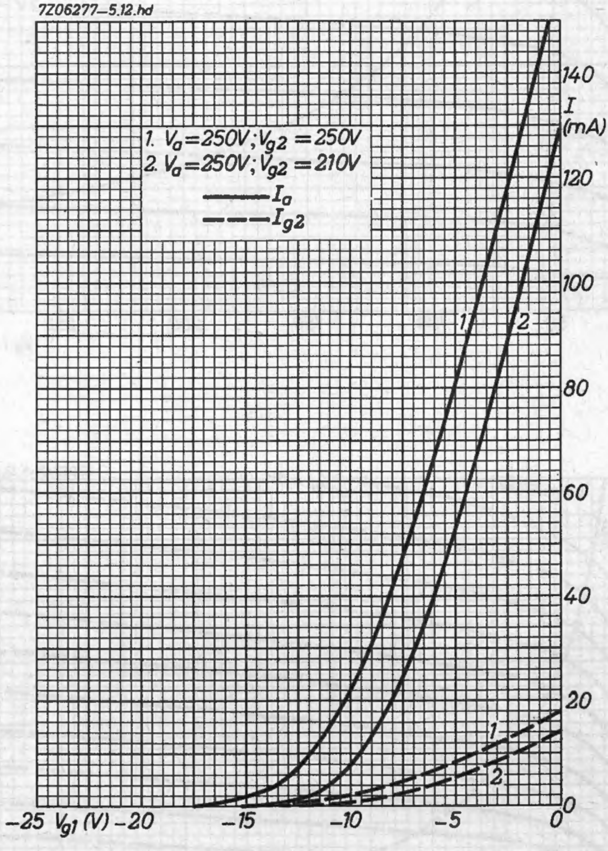
Class AB, two tubes in push-pull

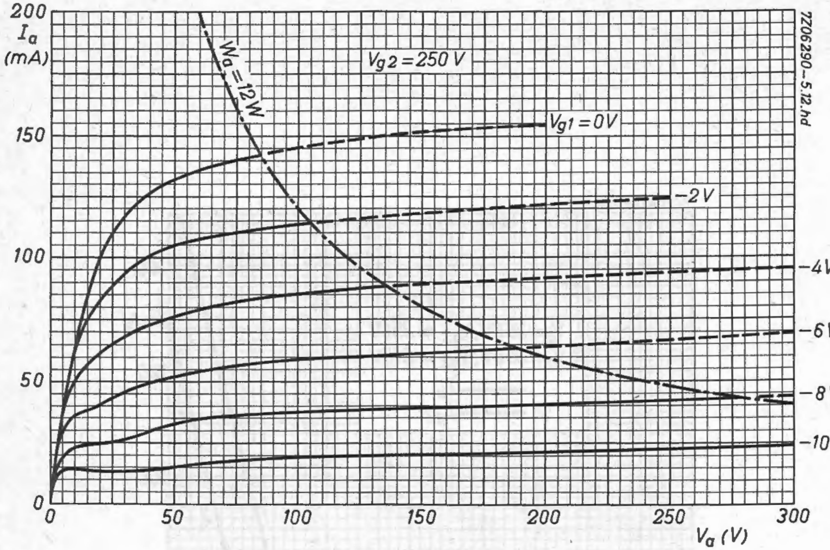
Anode voltage	V_a	250		300		V
Common cathode resistor	R_k	270		270		Ω
Load resistance	$R_{aa\sim}$	10		10		kΩ
Grid No.1 driving voltage	V_i	0	8.3	0	10	V_{RMS}
Anode current	I_a	2x20	2x21.7	2x24	2x26	mA
Output power	W_o	0	3.4	0	5.2	W
Distortion	d_{tot}	-	2.5	-	2.5	%
Grid No.1 driving voltage for W_o = 50 mW	V_i	0.95		0.9		V_{RMS}

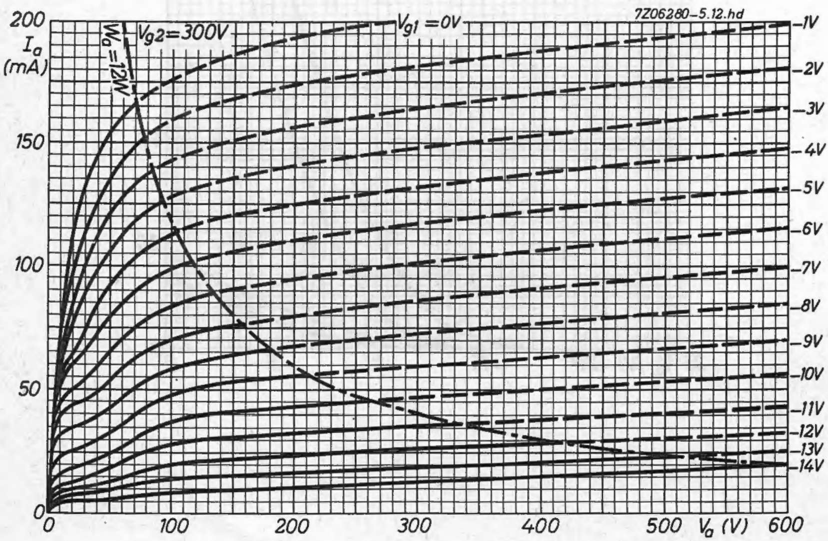
LIMITING VALUES (Design centre rating system)

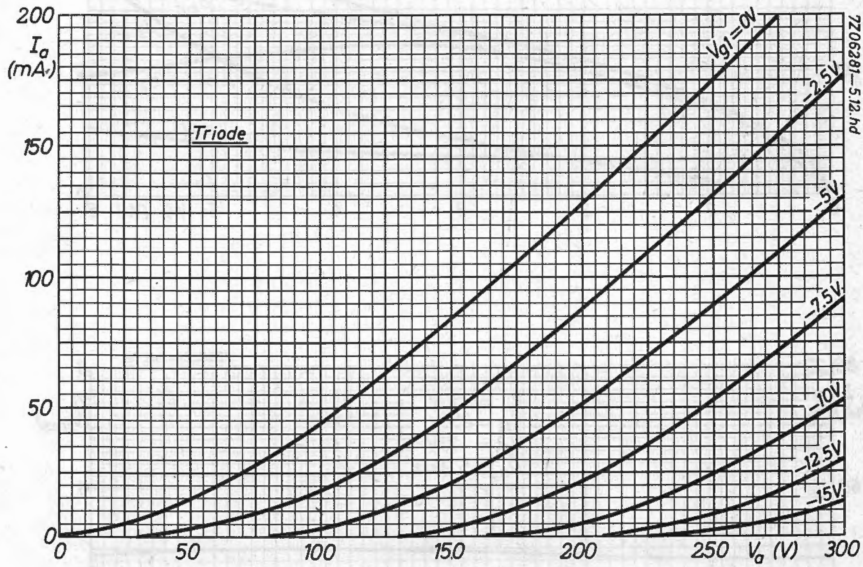
Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	300	V [1])
Anode dissipation	W_a	max.	12	W [1])
Grid No.2 voltage	$V_{g_{2o}}$	max.	550	V
	V_{g_2}	max.	300	V [1])
Grid No.2 dissipation	W_{g_2}	max.	2	W
	$W_{g_{2p}}$	max.	4	W
Grid No.1 voltage	$-V_{g_1}$	max.	100	V
Cathode current	I_k	max.	65	mA
Grid No.1 resistor				
for automatic bias	R_{g_1}	max.	1	MΩ
for fixed bias	R_{g_1}	max.	0.3	MΩ
Cathode to heater voltage	V_{kf}	max.	100	V

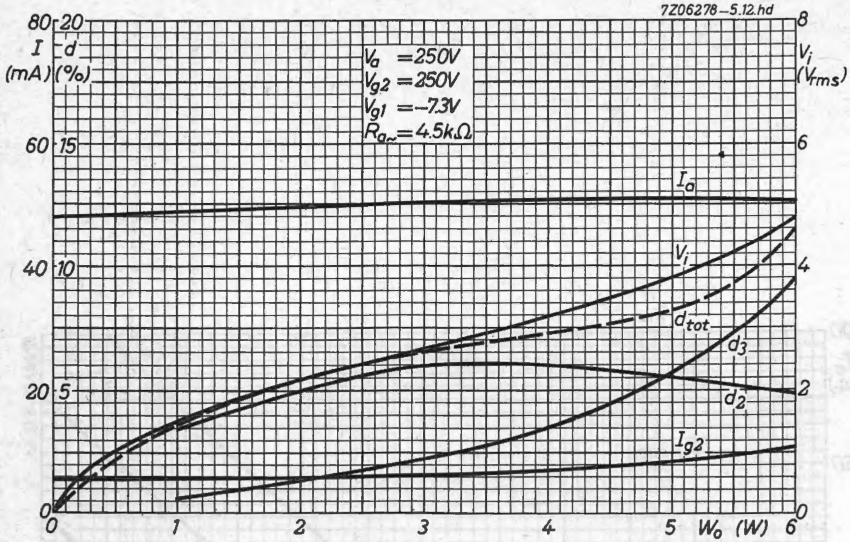
[1]) When the heater and positive voltages are obtained from a storage battery by means of a vibrator, the max. values of V_a and V_{g_2} are 250 V and that of W_a is 9 W.

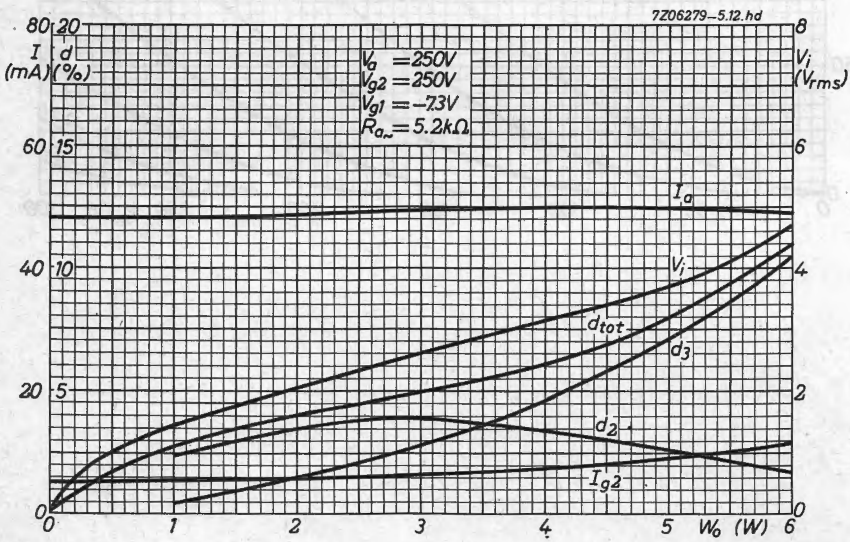

7Z06277–5.12.hd
1. V_a=250V; V_{g2}=250V
2. V_a=250V; V_{g2}=210V
I_a
I_{g2}
I (mA)
140
120
100
80
60
40
20
0
1
2
1
2
–25 V_{g1} (V) –20
–15
–10
–5
0

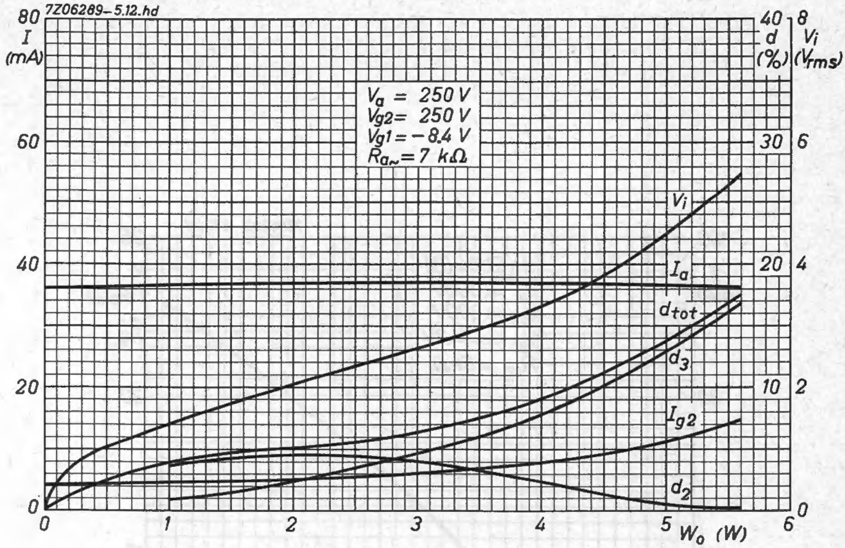

200
I_a
(mA)
150
100
50
0
$V_{g2} = 250\ V$
$W_a = 12W$
$V_{g1} = 0V$
−2 V
−4 V
−6 V
−8 V
−10 V
0
50
100
150
200
250
300
V_a (V)
7Z06290−5.12.hd

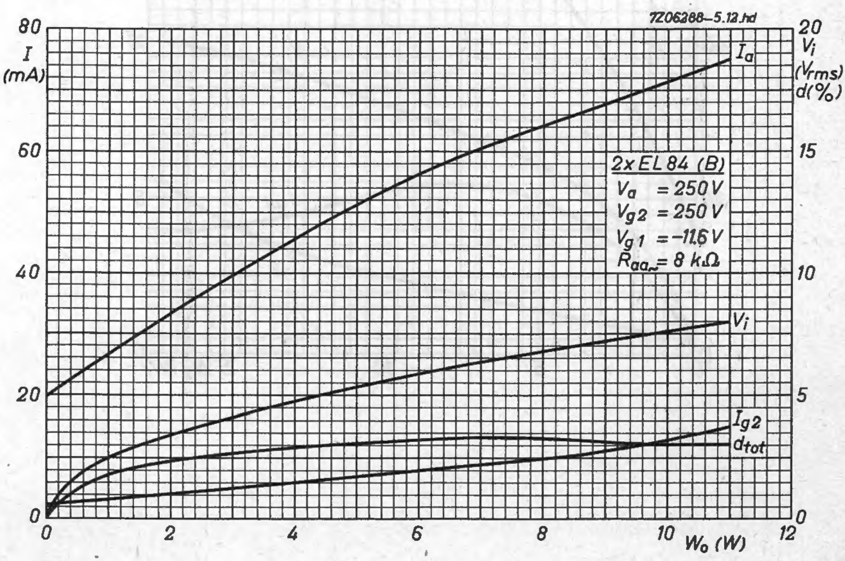

200
I_a
(mA)
150
100
50
0
V_{g2}=300V
W_a=12W
V_{g1} =0V
7Z06280−5.12.hd
−1V
−2V
−3V
−4V
−5V
−6V
−7V
−8V
−9V
−10V
−11V
−12V
−13V
−14V
0
100
200
300
400
500
V_a (V)
600

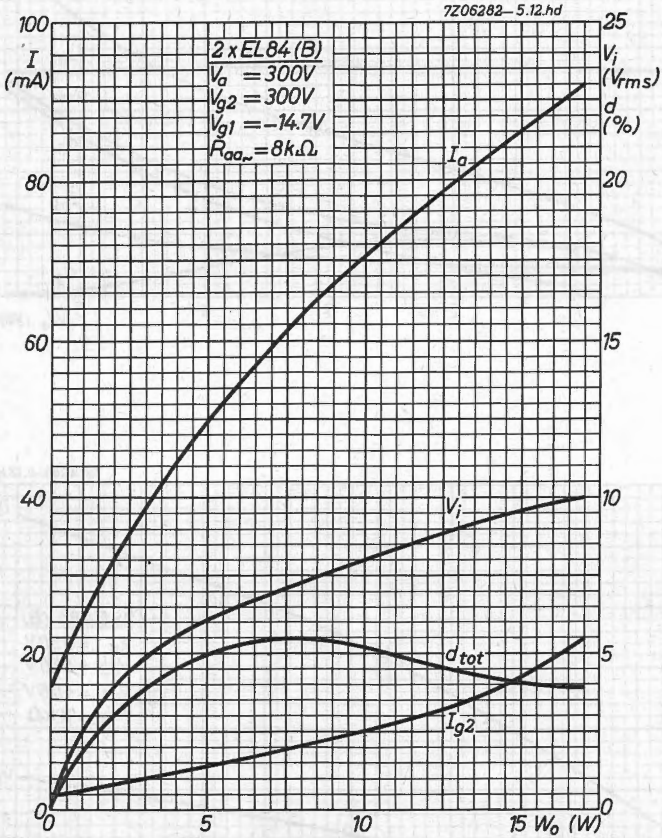

200
I_a (mA)
150
100
50
0
Triode
V_{g1}=0V
−2.5V
−5V
−7.5V
−10V
−12.5V
−15V
0
50
100
150
200
250
V_a (V)
300
7Z06281−5.12.hd

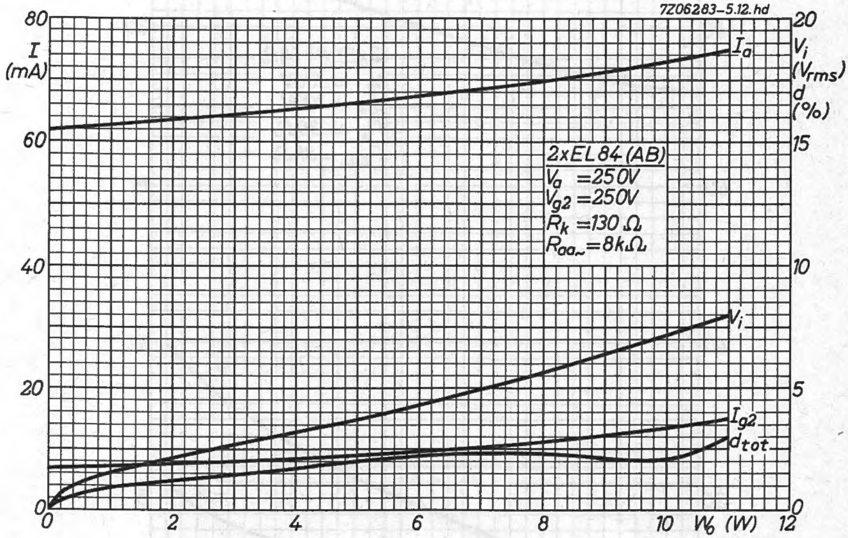

7Z06278-5.12.hd
80
20
I
d
(mA)
(%)
60
15
40
10
20
5
0
0
1
2
3
4
5
W_o (W)
6
8
V_i
(V_{rms})
6
4
2
0
V_a =250V
V_{g2} =250V
V_{g1} =−7.3V
$R_{a\sim}$=4.5kΩ
I_a
V_i
d_{tot}
d_3
d_2
I_{g2}

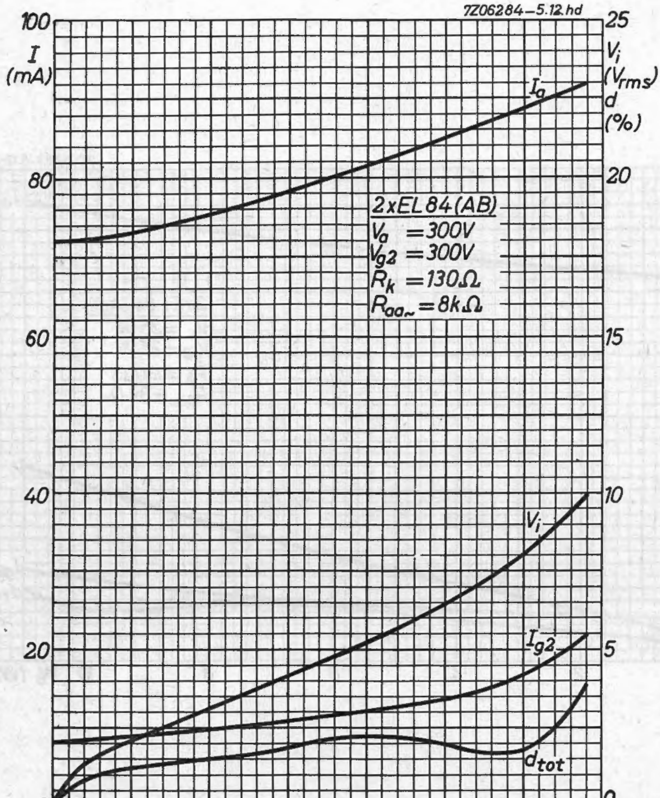

7Z06279-5.12.hd
80
20
I
d
(mA)
(%)
60
15
40
10
20
5
0
0
1
2
3
4
5
W_o (W)
6
8
V_i
(V_{rms})
6
4
2
0
V_a =250V
V_{g2} =250V
V_{g1} =−7.3V
$R_{a\sim}$=5.2kΩ
I_a
V_i
d_{tot}
d_3
d_2
I_{g2}

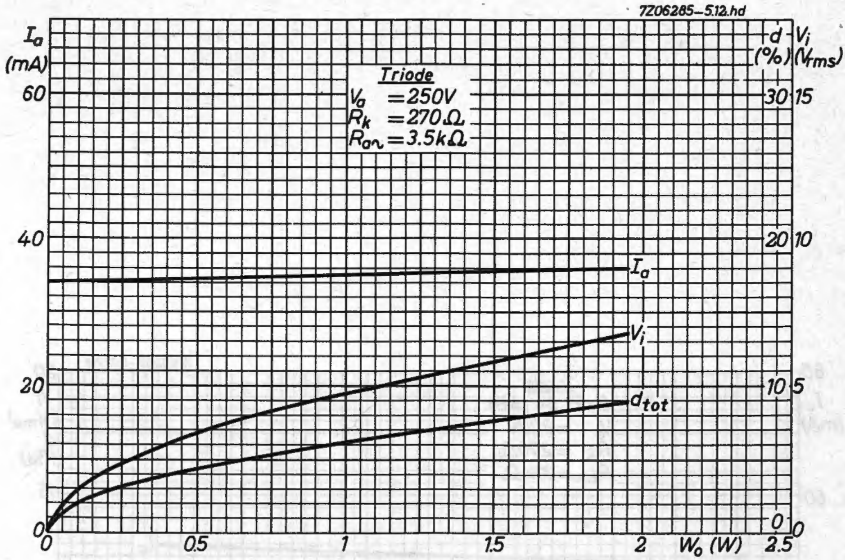

7Z06289-5.12.hd
I (mA)
d (%)
V_i (V_{rms})
V_a = 250 V
V_{g2} = 250 V
V_{g1} = −8.4 V
$R_{a\sim}$ = 7 kΩ
V_i
I_a
d_{tot}
d_3
I_{g2}
d_2
W_o (W)

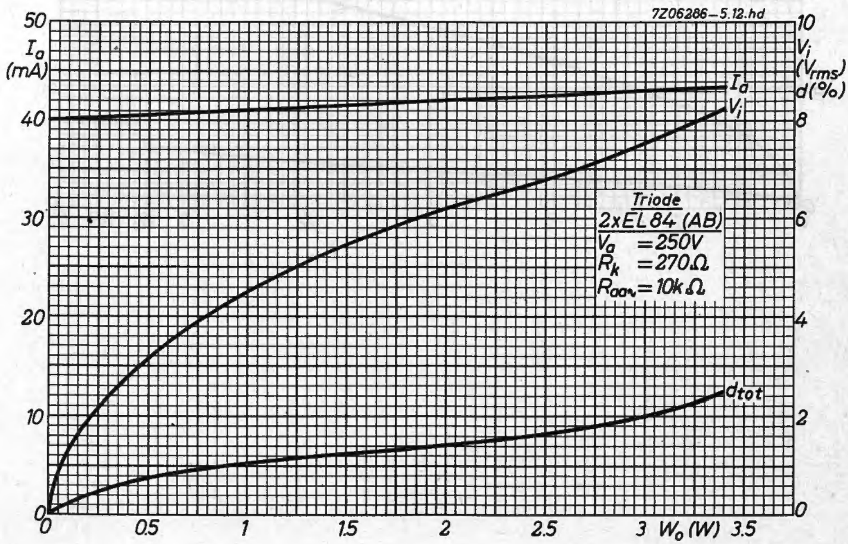

7Z06288-5.12.hd
I (mA)
V_i (V_{rms}) d(%)
2x EL 84 (B)
V_a = 250 V
V_{g2} = 250 V
V_{g1} = −11.6 V
$R_{aa\sim}$ = 8 kΩ
I_a
V_i
I_{g2}
d_{tot}
W_o (W)

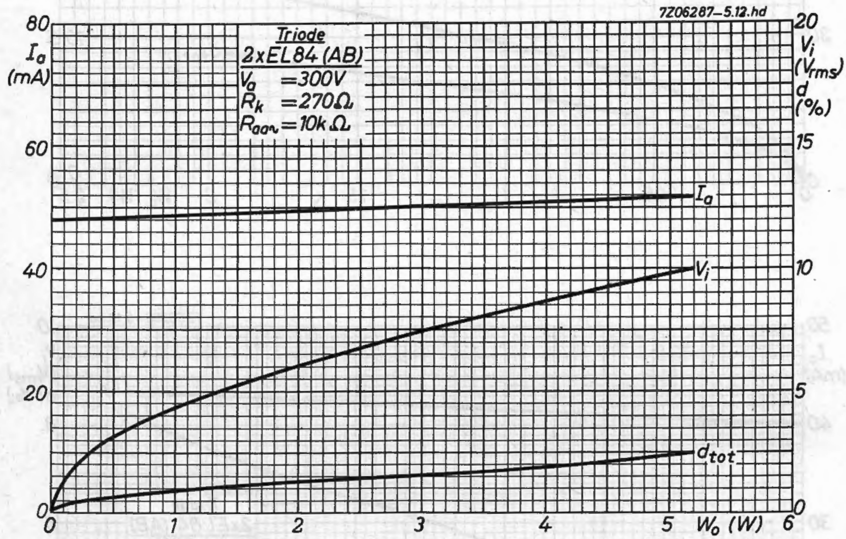

7Z06282—5.12.hd
2 x EL84 (B)
V_a = 300V
V_{g2} = 300V
V_{g1} = −14.7V
$R_{aa\sim}$ = 8kΩ
I
(mA)
100
80
60
40
20
0
V_i
(V_{rms})
d
(%)
25
20
15
10
5
0
0
5
10
15 W_o (W)
I_a
V_i
d_{tot}
I_{g2}


7Z06283-5.12.hd
I
(mA)
V_i
(V_{rms})
d
(%)
I_a
2xEL84 (AB)
V_a =250V
V_{g2} =250V
R_k =130 Ω
$R_{aa\sim}$ =8kΩ
V_i
I_{g2}
d_{tot}
W_o (W)
0
20
40
60
80
0
5
10
15
20
0
2
4
6
8
10
12


7Z06284-5.12.hd
100
I
(mA)
80
60
40
20
0
0
5
10
15 W_o (W)
25
V_i
(V_{rms})
d
(%)
20
15
10
5
0
I_a
2xEL84(AB)
V_a = 300V
V_{g2} = 300V
R_k = 130Ω
$R_{aa\sim}$ = 8kΩ
V_i
I_{g2}
d_{tot}


7Z06285-5.12.hd
I_a (mA)
d (%)
V_i (V_{rms})
Triode
V_a = 250V
R_k = 270 Ω
$R_{a\sim}$ = 3.5 kΩ
I_a
V_i
d_{tot}
W_o (W)
0
0.5
1
1.5
2
2.5
20
40
60
10
20
30
5
10
15


7Z06286-5.12.hd
I_a (mA)
V_i (V_{rms})
d(%)
Triode
2xEL84 (AB)
V_a = 250V
R_k = 270 Ω
$R_{aa\sim}$ = 10k Ω
I_a
V_i
d_{tot}
W_o (W)
0
0.5
1
1.5
2
2.5
3
3.5
10
20
30
40
50
2
4
6
8
10


7Z06287–5.12.hd
Triode
2xEL84 (AB)
V_a =300V
R_k =270Ω
$R_{aa\sim}$=10kΩ
I_a (mA)
V_i (V_{rms})
d (%)
I_a
V_i
d_{tot}
W_o (W)
80
60
40
20
0
20
15
10
5
0
0
1
2
3
4
5
6

FRAME AND A.F. OUTPUT PENTODE

Pentode intended for use as frame output tube in television receivers and as A.F. power amplifier.

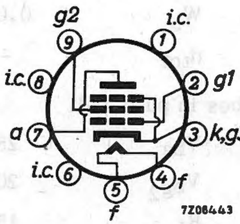
QUICK REFERENCE DATA				
Anode peak voltage	V_{a_p}	max.	2	kV
Cathode current	I_k	max.	100	mA
Output power	W_o		5.3	W

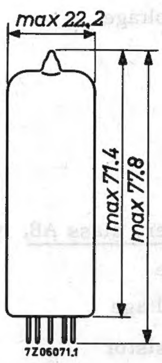
HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	760	mA

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Noval





CAPACITANCES

Anode to all except grid No.1	$C_{a(g_1)}$		6.8	pF
Grid No.1 to all except anode	$C_{g1(a)}$		13	pF
Anode to grid No.1	C_{ag_1}	max.	0.6	pF
Grid No.1 to heater	C_{g_1f}	max.	0.25	pF

OPTIMUM PEAK ANODE CURRENT IN FRAME OUTPUT OPERATION

The circuit should be designed so that the peak anode current does not exceed:

145 mA at V_a = 60 V, V_{g2} = 170 V, V_f = 6.3 V
190 mA at V_a = 70 V, V_{g2} = 200 V, V_f = 6.3 V
220 mA at V_a = 80 V, V_{g2} = 220 V, V_f = 6.3 V

The minimum available value of the peak anode current at end of life and V_f = 5.7 V is:

125 mA at V_a = 60 V, V_{g2} = 170 V
160 mA at V_a = 70 V, V_{g2} = 200 V
185 mA at V_a = 80 V, V_{g2} = 220 V

OPERATING CHARACTERISTICS

A.F. power amplifier, class A (Measured with V_k constant)

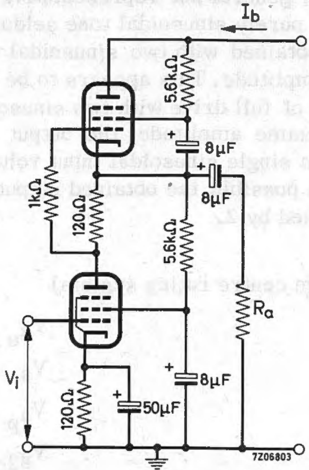
Supply voltage	V_b		200		V
Grid No.2 series resistor (non decoupled)	R_{g2}		470		Ω
Cathode resistor	R_k		215		Ω
Load resistance	$R_{a\sim}$		2.5		kΩ
Grid No.1 driving voltage	V_i	0	0.52	7.0	V_{RMS}
Anode current	I_a	65	-	64	mA
Grid No.2 current	I_{g2}	3.2	-	11.4	mA
Output power	W_o	0	0.05	5.3	W
Distortion	d_{tot}	-	-	10	%

A.F. power amplifier, class AB, two tubes in push-pull

Anode supply voltage	V_{ba}		250		V
Grid No.2 supply voltage	V_{bg2}		200		V
Common cathode resistor	R_k		150		Ω
Load resistance	$R_{aa\sim}$		5.5		kΩ
Grid No.1 driving voltage	V_i	0	0.37	13.0	V_{RMS}
Anode current	I_a	2x50	-	2x55	mA
Grid No.2 current	I_{g2}	2x2.0	-	2x13	mA
Output power	W_o	0	0.05	18.5	W
Distortion	d_{tot}	-	-	4.5	%

OPERATING CHARACTERISTICS (continued)

A.F. power amplifier, single ended push-pull



a) Single tone input signal

Supply voltage	V_b		300		V
Load resistance	$R_{a\sim}$		1		kΩ
Grid No.1 driving voltage	V_i	0	0.41	5.4	V_{RMS}
Supply current	I_b	66	–	64	mA
Output power	W_o	0	0.05	4.5	W
Distortion	d_{tot}	–	–	9.3	%

b) Double tone input signal

Supply voltage	V_b	300		V
Load resistance	$R_{a\sim}$	1		kΩ
Grid No.1 driving voltage	V_i	0	2.7	V_{RMS} [1])
Supply current	I_b	66	64	mA
Output power	W_o	0	5.5	W
Distortion	d_{tot}	–	8.5	%

[1]) Value of each tone separately.

REMARK

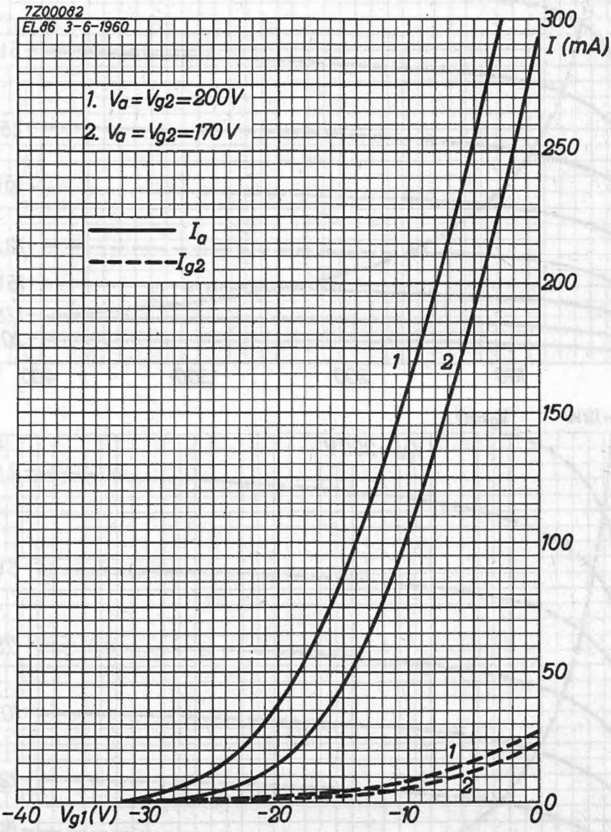
Single tone data are obtained with a pure sinusoidal input voltage. However such an input voltage is in general not representative for the reproduction of music and speech, since a purely sinusoidal tone seldom occurs.
The double tone data are obtained with two sinusoidal signals of different frequencies but of the same amplitude. This appears to be far better in agreement with practice. In the case of full drive with two sinusoidal signals different in frequency but having the same amplitude, the output power is half the value obtained at full drive with a single sinusoidal input voltage of twice this amplitude. To make comparison possible the obtained output power with double tone has therefore been multiplied by 2.

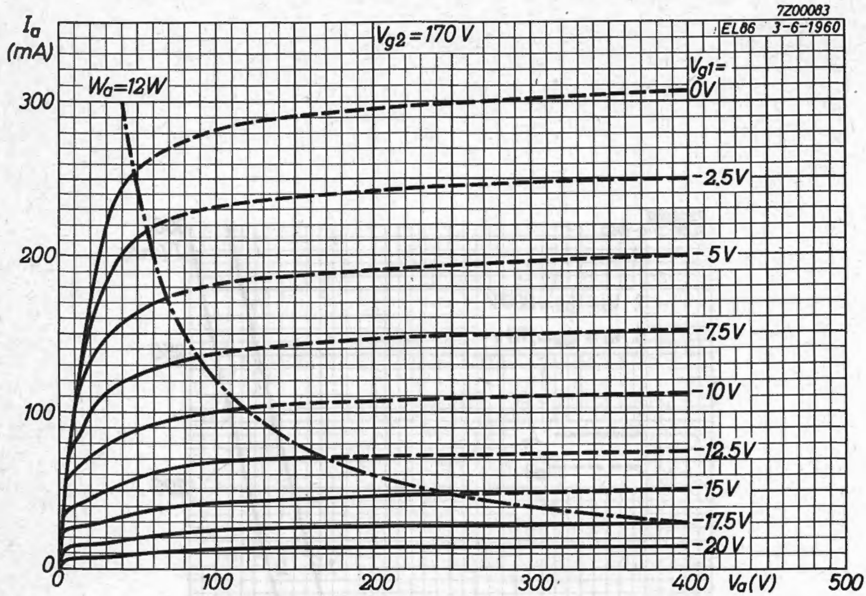
LIMITING VALUES (Design centre rating system)

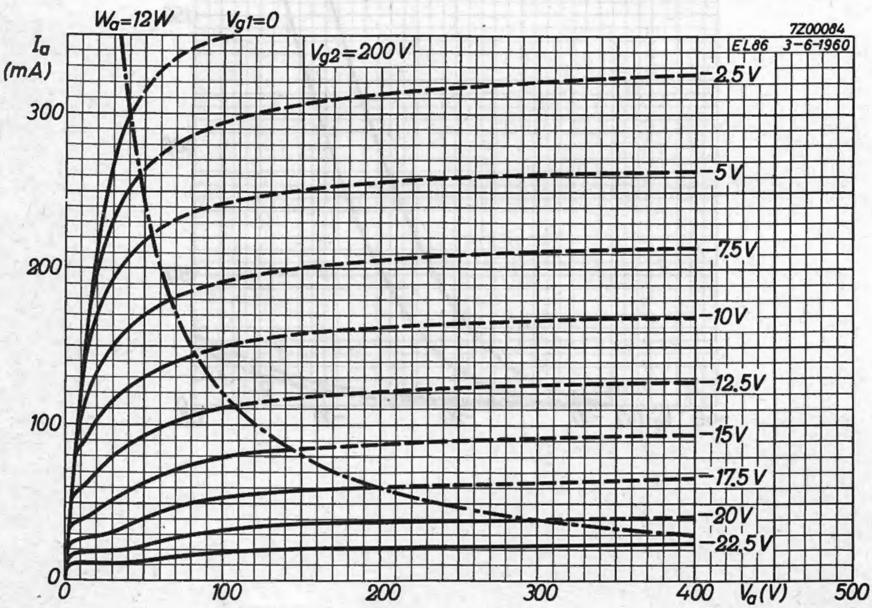
Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	250	V
Anode peak voltage	V_{a_p}	max.	2	kV [1])
Grid No.2 voltage	V_{g2_o}	max.	550	V
	V_{g_2}	max.	250	V
Anode dissipation	W_a	max.	12	W [2])
Grid No.2 dissipation:				
average	W_{g_2}	max.	1.75	W
peak	$W_{g_{2p}}$	max.	6	W
Cathode current	I_k	max.	100	mA
Grid No.1 resistor:				
automatic bias	R_{g_1}	max.	1	MΩ
frame output application with automatic bias	R_{g_1}	max.	2	MΩ
Cathode to heater voltage	V_{kf}	max.	200	V

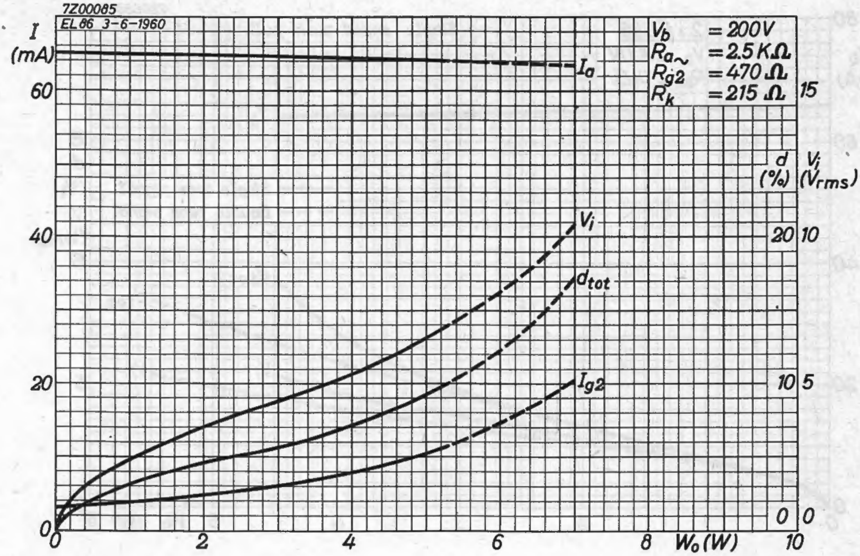
[1]) Valid for application in frame output circuits where the max. pulse duration is 4% of a cycle with a max. of 0.8 ms.

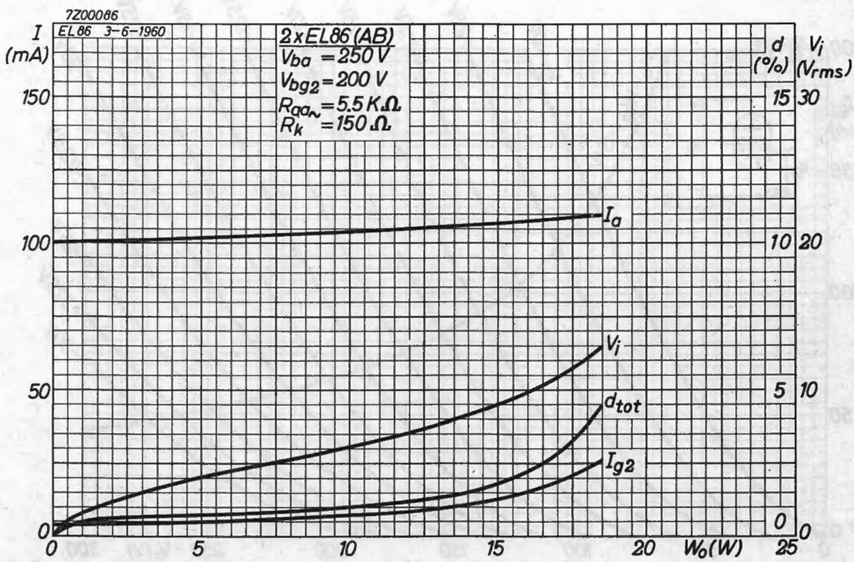
[2]) For frame output application W_a = max. 10 W.

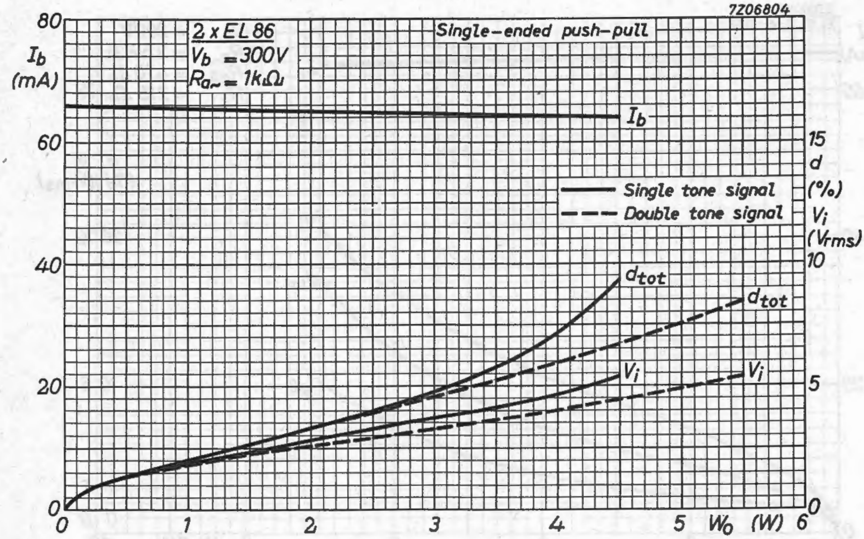

7Z00082
EL86 3-6-1960
1. $V_a = V_{g2} = 200V$
2. $V_a = V_{g2} = 170V$
I_a
I_{g2}
300
I (mA)
250
200
150
100
50
0
1
2
1
2
-40
V_{g1}(V)
-30
-20
-10
0

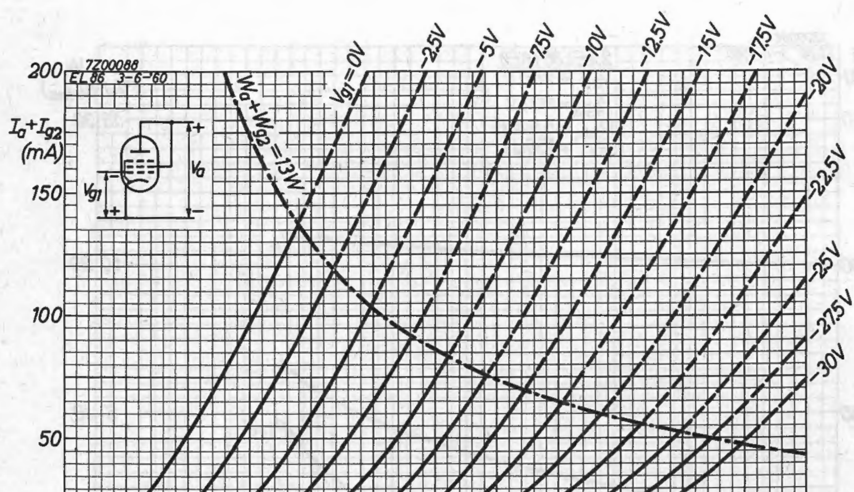

7Z00083
EL86 3-6-1960
I_a (mA)
V_{g2}=170 V
W_a=12W
V_{g1}=
0V
−2.5V
−5V
−7.5V
−10V
−12.5V
−15V
−17.5V
−20V
0
100
200
300
400
500
V_a(V)


7Z00084
EL86 3-6-1960
I_a (mA)
W_a=12W
V_{g1}=0
V_{g2}=200V
−2.5V
−5V
−7.5V
−10V
−12.5V
−15V
−17.5V
−20V
−22.5V
0
100
200
300
400
500
V_a(V)


7Z00085
EL86 3-6-1960
I (mA)
Vb = 200V
Ra~ = 2.5 KΩ
Rg2 = 470 Ω
Rk = 215 Ω
d (%)
Vi (Vrms)
Ia
Vi
dtot
Ig2
Wo (W)
0
2
4
6
8
10
20
40
60
15
5
10
20


7Z00086
EL86 3-6-1960
I (mA)
2xEL86 (AB)
Vba = 250 V
Vbg2 = 200 V
Raa~ = 5.5 KΩ
Rk = 150 Ω
d (%)
Vi (Vrms)
Ia
Vi
dtot
Ig2
Wo (W)
0
5
10
15
20
25
50
100
150
30


7Z06804
2 x EL86
V_b = 300V
$R_{a\sim}$ = 1kΩ
Single-ended push-pull
I_b (mA)
I_b
d (%)
V_i (V_{rms})
Single tone signal
Double tone signal
d_{tot}
d_{tot}
V_i
V_i
W_o (W)
0
1
2
3
4
5
6
20
40
60
80
5
10
15


7Z00088
EL86 3-6-'60
I_a+I_{g2} (mA)
V_{g1}
V_a
W_a+W_{g2}=13W
V_{g1}=0V
-2.5V
-5V
-7.5V
-10V
-12.5V
-15V
-17.5V
-20V
-22.5V
-25V
-27.5V
-30V
V_a(V)
0
50
100
150
200
250
300

A.F. OUTPUT PENTODE

Pentode intended for use as A.F. power amplifier in car radio sets.

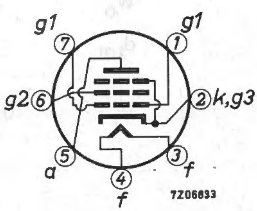
QUICK REFERENCE DATA			
Anode current	I_a	24	mA
Transconductance	S	5	mA/V
Amplification factor	$\mu_{g_2g_1}$	17	
Output power	W_o	3	W

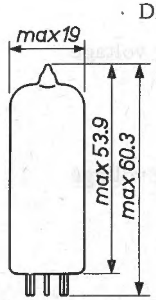
HEATING: Indirect by A.C. or D.C.; parallel supply or two tubes in series on 12 V battery

Heater voltage	V_f	6.3	V
Heater current	I_f	200	mA

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: miniature 7-pin





CAPACITANCES

Anode to all except grid No.1	$C_{a(g_1)}$		3.5	pF
Grid No.1 to all except anode	$C_{g_1(a)}$		5.3	pF
Anode to grid No.1	C_{ag_1}	max.	0.4	pF
Grid No.1 to heater	C_{g_1f}	max.	0.2	pF

TYPICAL CHARACTERISTICS

Anode voltage	V_a	250	V
Grid No.2 voltage	V_{g_2}	250	V
Grid No.1 voltage	V_{g_1}	-9.0	V
Anode current	I_a	24	mA
Grid No.2 current	I_{g_2}	4.5	mA
Transconductance	S	5	mA/V
Amplification factor	$\mu_{g_2g_1}$	17	
Internal resistance	R_i	80	kΩ

OPERATING CHARACTERISTICS

Class A

Anode voltage	V_a	200	250	V
Grid No.2 voltage	V_{g_2}	200	250	V
Cathode resistor	R_k	230	320	Ω
Anode current	I_a	23	24	mA
Grid No.2 current	I_{g_2}	4.2	4.5	mA
Load resistance	$R_{a\sim}$	8	10	kΩ
Grid No.1 driving voltage	V_i	4.5	5	V_{RMS}
Output power	W_o	2.3	3.0	W
Distortion	d_{tot}	12	12	%
Grid No.1 driving voltage for W_o = 50 mW	V_i	0.55	0.50	V_{RMS}

OPERATING CHARACTERISTICS (continued)

Class AB, two tubes in push-pull

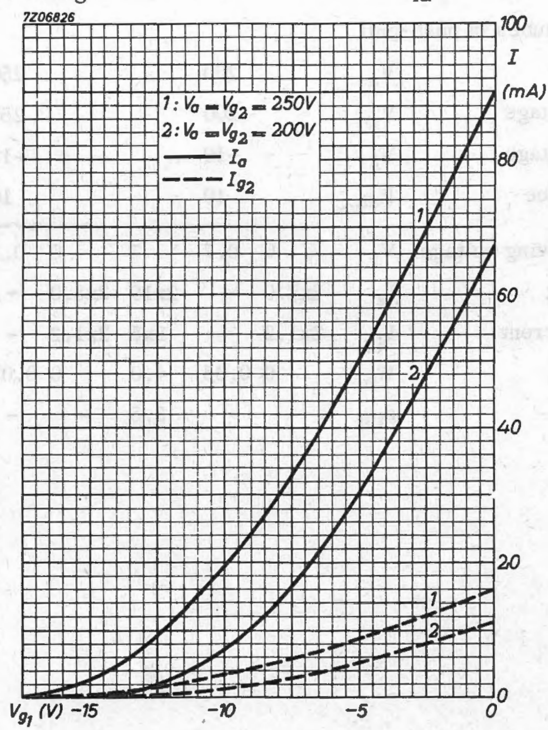
Anode voltage	V_a		200			250		V
Grid No.2 voltage	V_{g_2}		200			250		V
Common cathode resistor	R_k		180			180		Ω
Load resistance	$R_{aa\sim}$		10			10		kΩ
Grid No.1 driving voltage	V_i	0	0.5	7	0	0.5	9	V_{RMS}
Anode current	I_a	2x17.5	-	2x20	2x22	-	2x26	mA
Grid No.2 current	I_{g_2}	2x3.2	-	2x5.2	2x4.0	-	2x7.5	mA
Output power	W_o	0	0.05	4.1	0	0.05	7	W
Distortion	d_{tot}	-	-	4.5	-	-	5	%

Class B, two tubes in push-pull

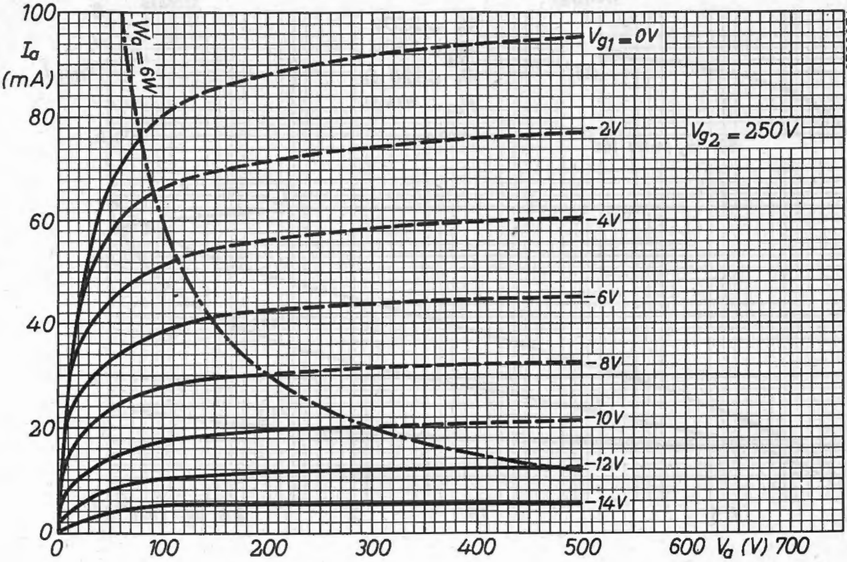
Anode voltage	V_a		200			250		V
Grid No.2 voltage	V_{g_2}		200			250		V
Grid No.1 voltage	V_{g_1}		-10			-13		V
Load resistance	$R_{aa\sim}$		10			10		kΩ
Grid No.1 driving voltage	V_i	0	0.7	7	0	0.7	9	V_{RMS}
Anode current	I_a	2x7.0	-	2x19	2x8.0	-	2x24	mA
Grid No.2 current	I_{g_2}	2x1.2	-	2x5	2x1.2	-	2x7.2	mA
Output power	W_o	0	0.05	4.0	0	0.05	6.5	W
Distortion	d_{tot}	-	-	3.5	-	-	3.5	%

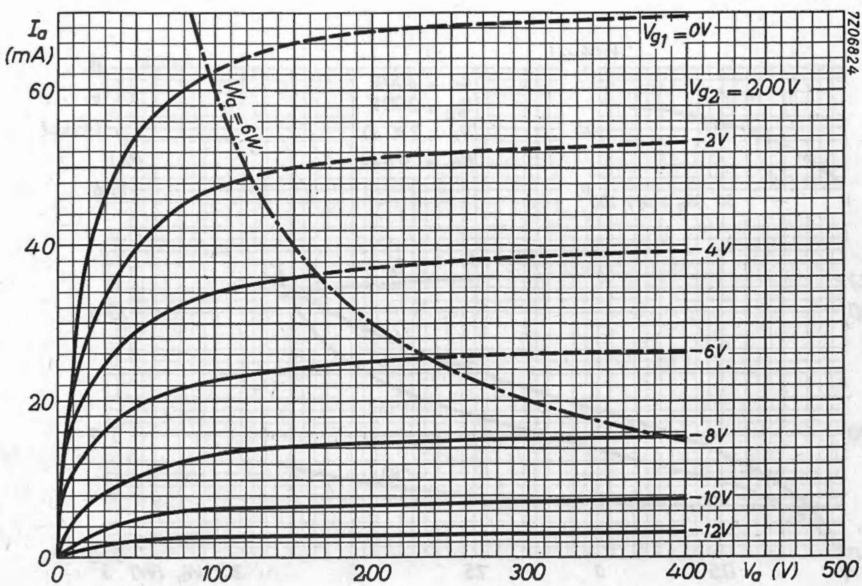
LIMITING VALUES (Design centre rating system)

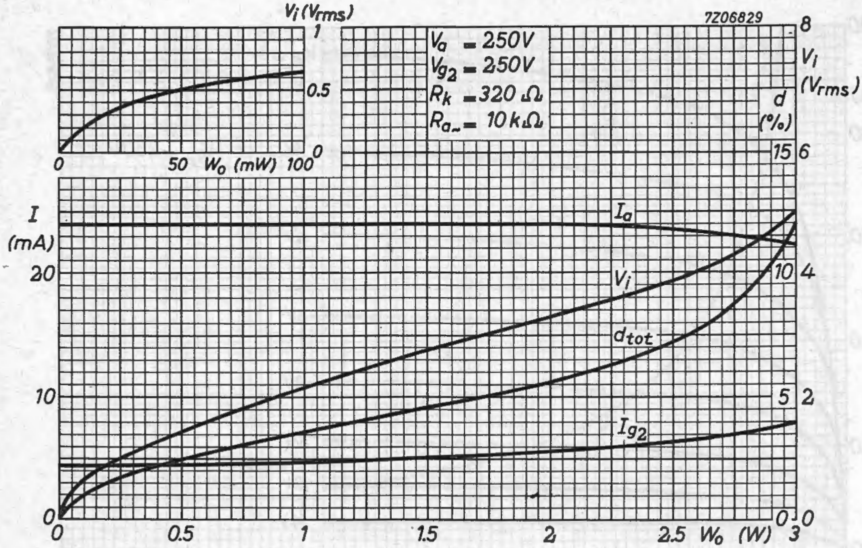
Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	300	V 1)
Grid No. 2 voltage	V_{g2_o}	max.	550	V
	V_{g2}	max.	300	V 1)
Anode dissipation	W_a	max.	6	W
Grid No. 2 dissipation				
average at $V_i = 0$	W_{g2}	max.	1.25	W
peak	W_{g2p}	max.	2.5	W
Cathode current	I_k	max.	35	mA
Grid No. 1 resistor, automatic bias	R_{g1}	max.	2	MΩ
Cathode to heater voltage	V_{kf}	max.	100	V



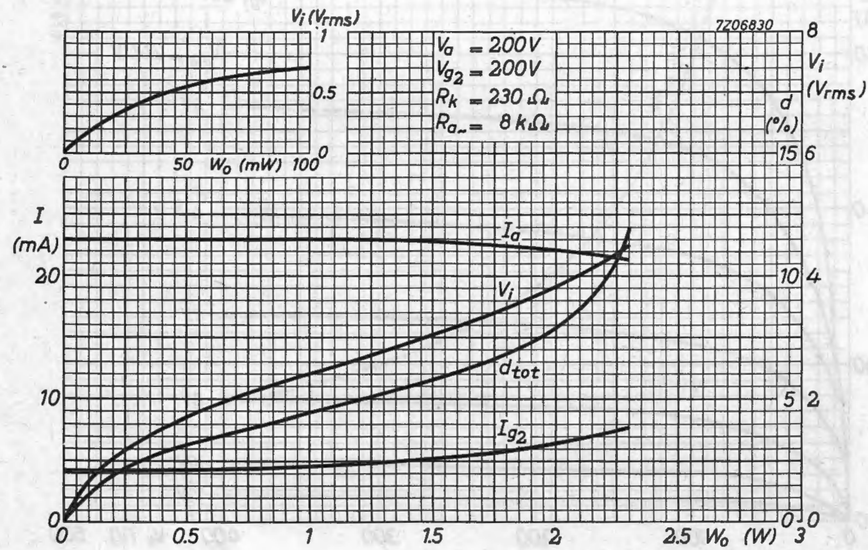
1) When the heater and positive voltages are obtained from a storage battery (pos. voltages by means of a vibrator), the max. values of V_a and V_{g2} are 250 V.


100
I_a
(mA)
80
60
40
20
0
0
100
200
300
400
500
600 V_a (V) 700
$W_a = 6W$
$V_{g1} = 0V$
−2V
−4V
−6V
−8V
−10V
−12V
−14V
$V_{g2} = 250V$
7Z06825

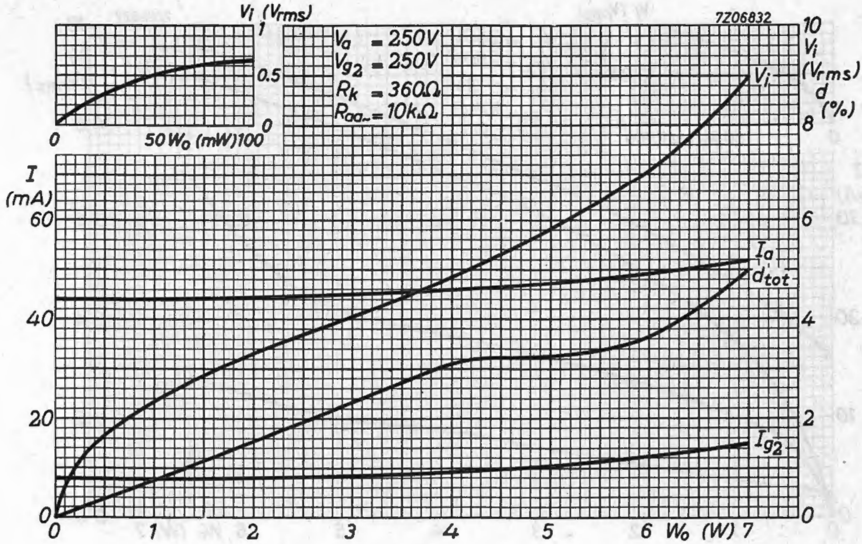

I_a
(mA)
60
40
20
0
0
100
200
300
400 V_a (V) 500
$W_a = 6W$
$V_{g1} = 0V$
$V_{g2} = 200V$
−2V
−4V
−6V
−8V
−10V
−12V
7Z06824

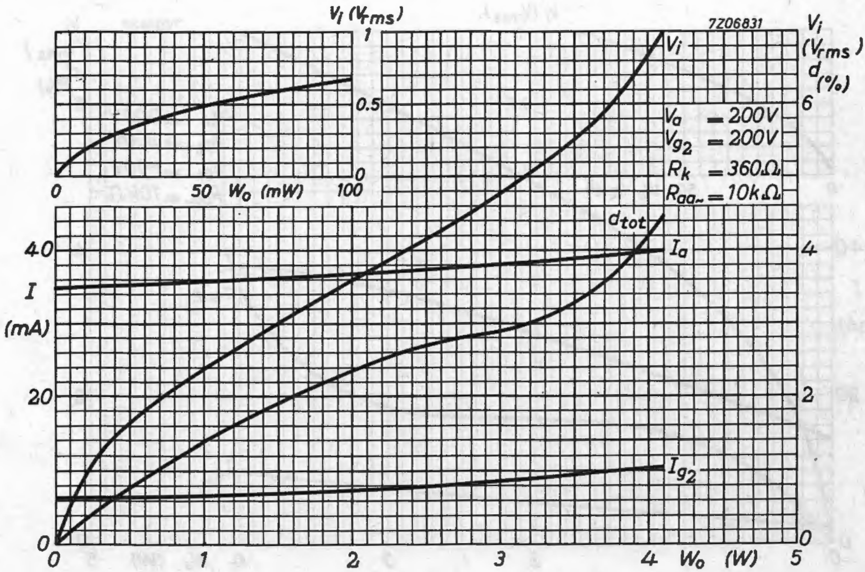


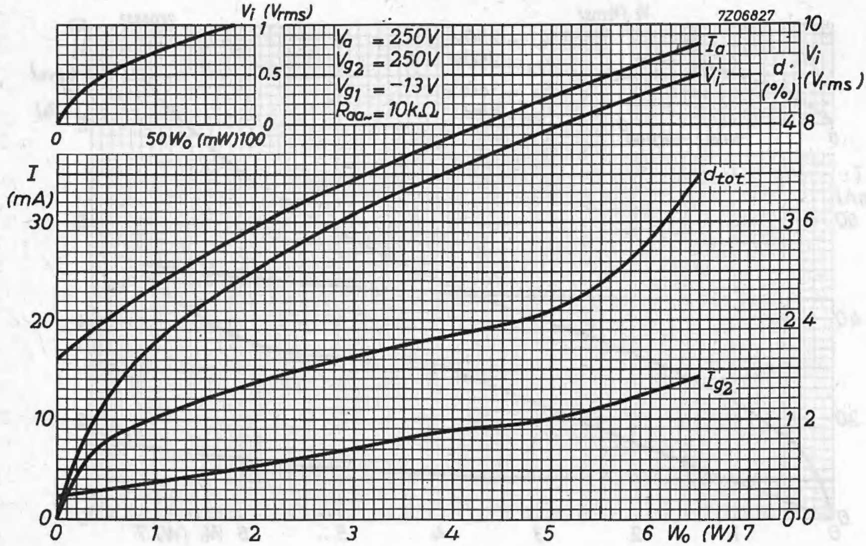
7Z06829
V_i (V_{rms})
1
0.5
0
0
50 W_o (mW) 100
V_a = 250V
V_{g2} = 250V
R_k = 320 Ω
$R_{a\sim}$ = 10 kΩ
I (mA)
I_a
V_i
d_{tot}
I_{g2}
V_i (V_{rms})
d (%)
0 0.5 1 1.5 2 2.5 W_o (W) 3

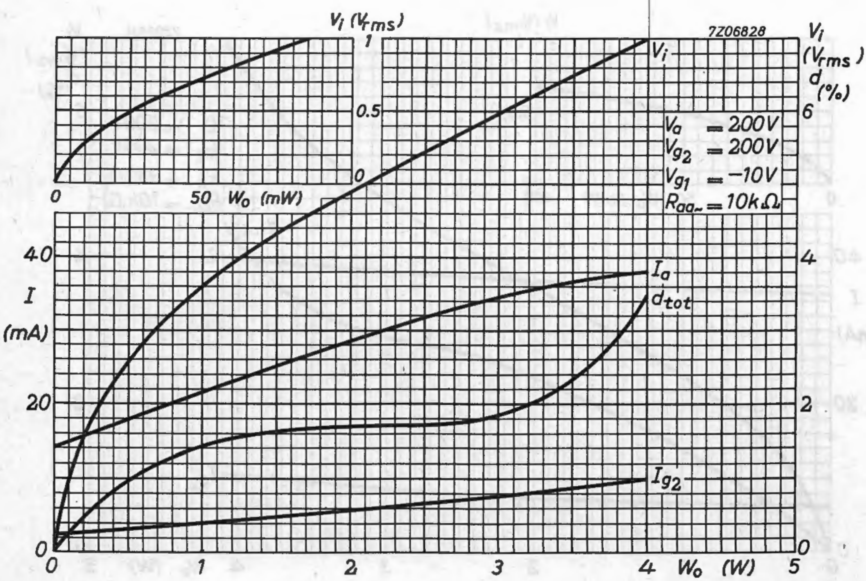


7Z06830
V_i (V_{rms})
1
0.5
0
0
50 W_o (mW) 100
V_a = 200V
V_{g2} = 200V
R_k = 230 Ω
$R_{a\sim}$ = 8 kΩ
I (mA)
I_a
V_i
d_{tot}
I_{g2}
V_i (V_{rms})
d (%)
0 0.5 1 1.5 2 2.5 W_o (W) 3


7Z06832
V_a = 250V
V_{g2} = 250V
R_k = 360Ω
$R_{aa\sim}$ = 10kΩ
V_i (V_{rms})
50 W_o (mW) 100
I (mA)
V_i (V_{rms})
d (%)
V_i
I_a
d_{tot}
I_{g2}
W_o (W)


7Z06831
V_a = 200V
V_{g2} = 200V
R_k = 360Ω
$R_{aa\sim}$ = 10kΩ
V_i (V_{rms})
50 W_o (mW) 100
I (mA)
V_i (V_{rms})
d (%)
V_i
d_{tot}
I_a
I_{g2}
W_o (W)


7Z06827
$V_a = 250V$
$V_{g2} = 250V$
$V_{g1} = -13V$
$R_{aa\sim} = 10k\Omega$
V_i (V_{rms})
W_o (mW)
I (mA)
I_a
V_i
d_{tot}
I_{g2}
d (%)
V_i (V_{rms})
W_o (W)


7Z06828
$V_a = 200V$
$V_{g2} = 200V$
$V_{g1} = -10V$
$R_{aa\sim} = 10k\Omega$
V_i (V_{rms})
W_o (mW)
I (mA)
V_i
I_a
d_{tot}
I_{g2}
V_i (V_{rms})
d (%)
W_o (W)

LINE OUTPUT PENTODE

Beam pentode intended for use as line output tube in television receivers.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	1.38	A

LIMITING VALUES (Design centre rating system)

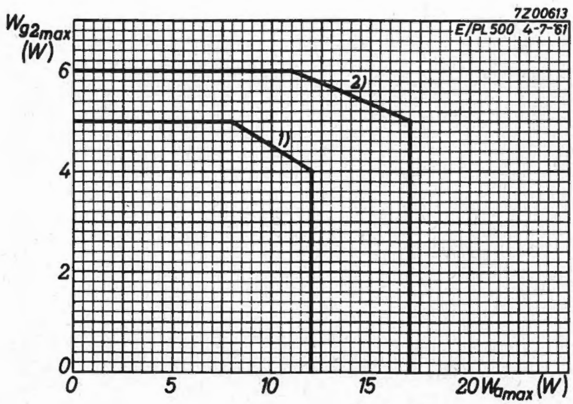
Cathode to heater voltage

DC + peak, k positive	V_{kf}	max.	200	V
k negative	$-V_{kf}$	max.	200	V 3)

Anode dissipation

Grid No.2 dissipation

See graph below



1) Design centre limits for W_a and W_{g_2}.
2) These limits for W_a and W_{g_2} should not be exceeded with a nominal tube operating in a normal line deflection circuit under the worst probable conditions.
3) D.C. component max. 100 V.

For further data and curves of this type please refer to type PL 504

A.F. OUTPUT PENTODE

Beam pentode intended for use as A.F. power amplifier.

QUICK REFERENCE DATA			
Anode current	I_a	110	mA
Transconductance	S	23	mA/V
Amplification factor	$\mu_{g_2g_1}$	13	
Output power (class AB)	W_o	40	W

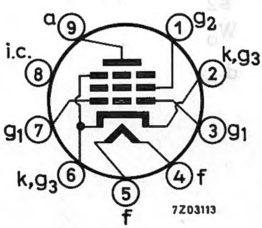
HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	1.05	A

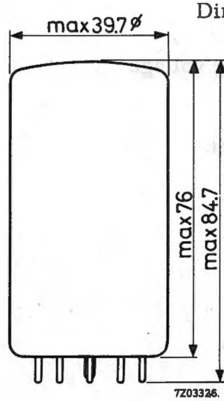
DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Magnoval



7Z03113



7Z03326

CAPACITANCES

Anode to all except grid No.1	$C_{a(g_1)}$	13.5	pF	←
Grid No.1 to all except anode	$C_{g_1(a)}$	22.5	pF	
Anode to grid No.1	C_{ag_1}	1.7	pF	←
Grid No.1 to heater	C_{g_1f}	0.325	pF	

TYPICAL CHARACTERISTICS

Anode voltage	V_a	250	V
Grid No.2 voltage	V_{g_2}	250	V
Grid No.1 voltage	V_{g_1}	14.0	V
Anode current	I_a	110	mA
Grid No.2 current	I_{g_2}	7.0	mA
Transconductance	S	23	mA/V
Amplification factor	$\mu_{g_2g_1}$	13	
Internal resistance	R_i	5.4	kΩ

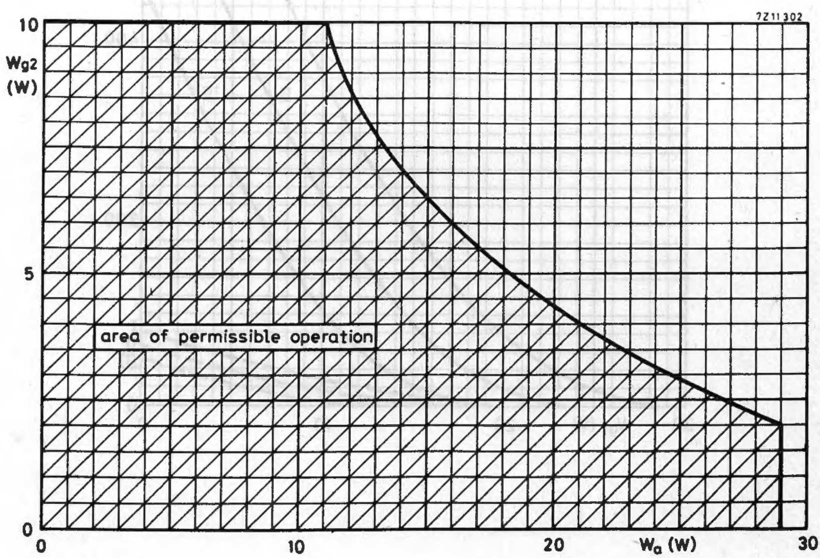
OPERATING CHARACTERISTICS

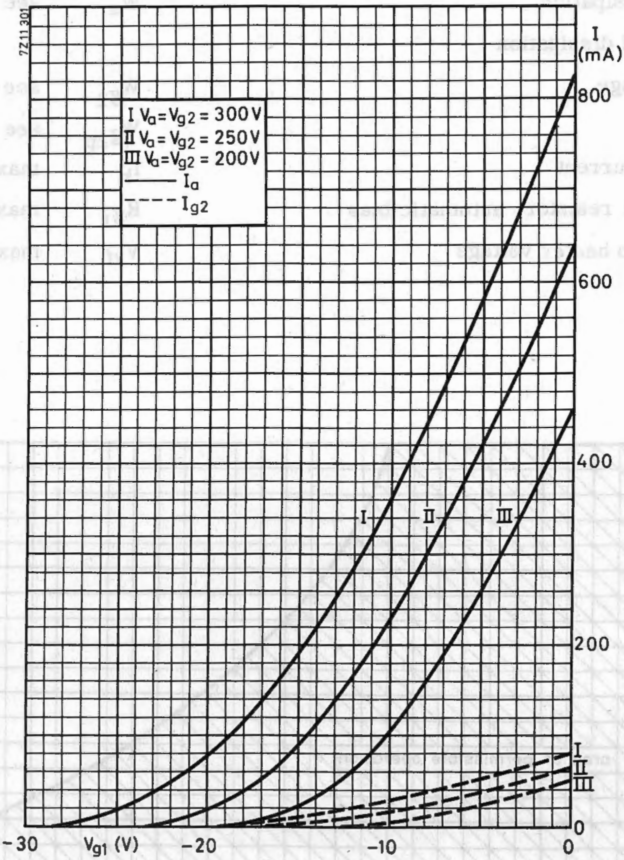
Class AB, two tubes in push-pull

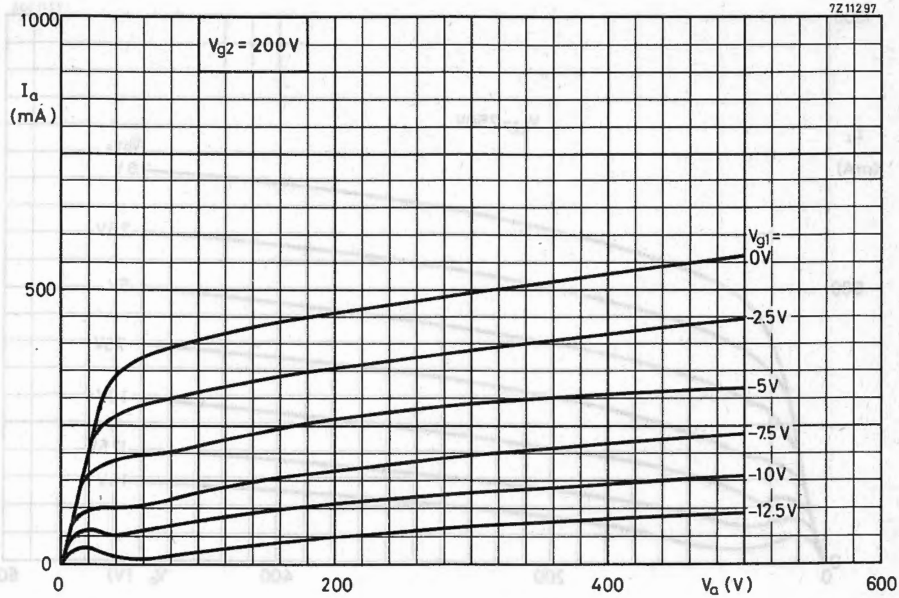
Anode supply voltage	V_{ba}	265		V
Grid No.2 supply voltage	V_{bg_2}	265		V
Common cathode resistor	R_k	56		Ω
Load resistance	$R_{aa\sim}$	2.4		kΩ
Grid No.1 driving voltage	V_i	0	12.2	V_{RMS}
Anode current	I_a	2x115	2x125	mA
Grid No.2 current	I_{g_2}	2x7.5	2x35.0	mA
Output power	W_o	0	40	W
Distortion	d_{tot}	-	5	%

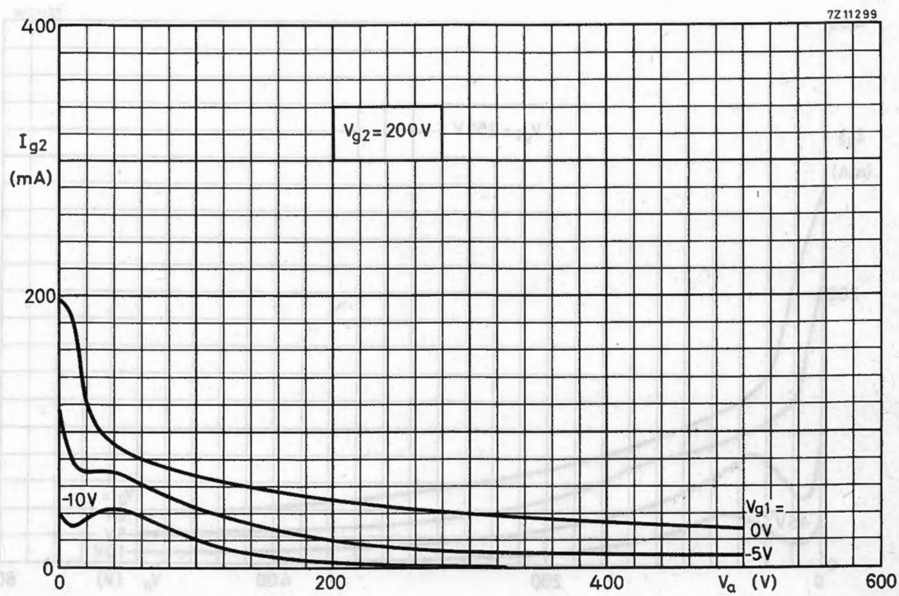
LIMITING VALUES (Design centre rating system)

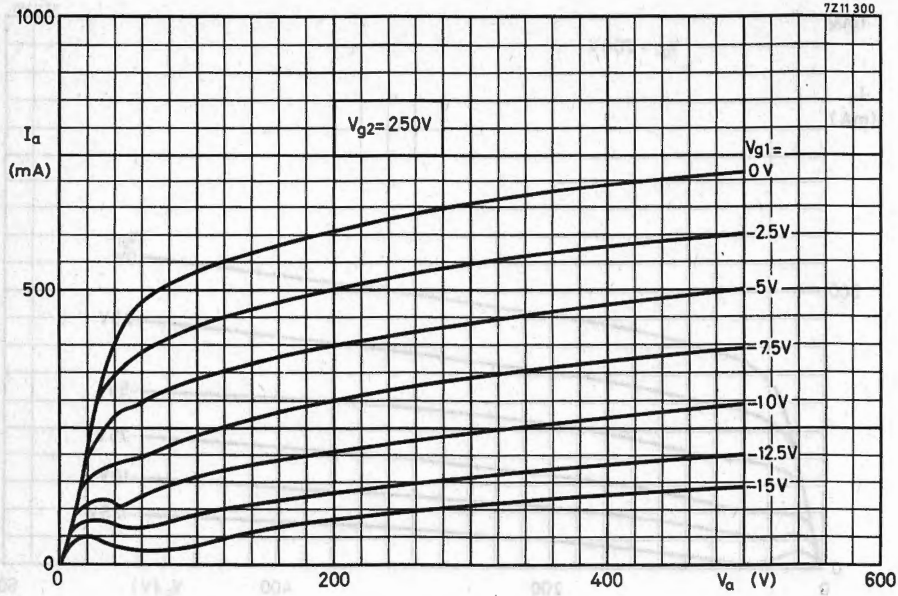
Anode voltage	V_{ao}	max.	550	V
	V_a	max.	300	V
Grid No. 2 voltage	V_{g2o}	max.	550	V
	V_{g2}	max.	300	V
Anode dissipation	W_a	see below		
Grid No. 2 dissipation				
average	W_{g2}	see below		
peak	W_{g2p}	see below		
Cathode current	I_k	max.	200	mA
Grid No. 1 resistor, automatic bias	R_{g1}	max.	0.5	MΩ
Cathode to heater voltage	V_{kf}	max.	100	V

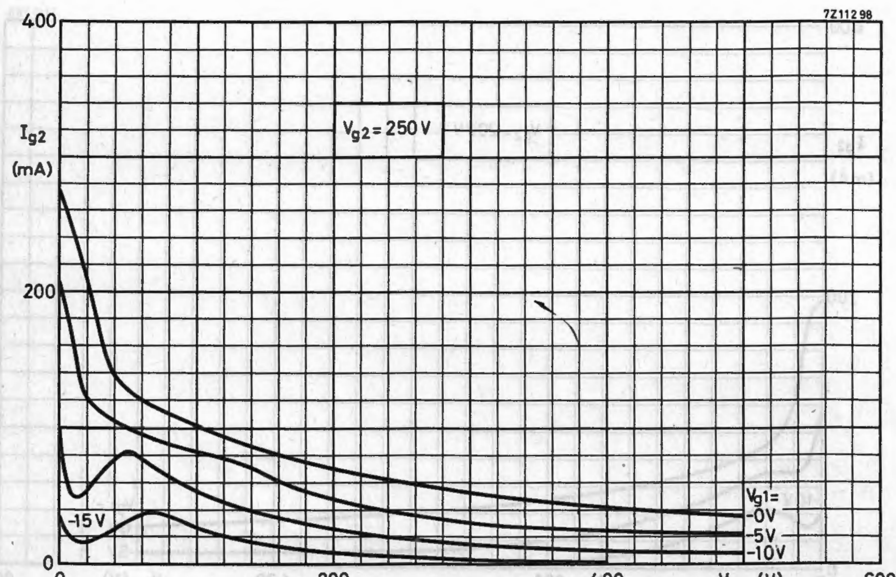


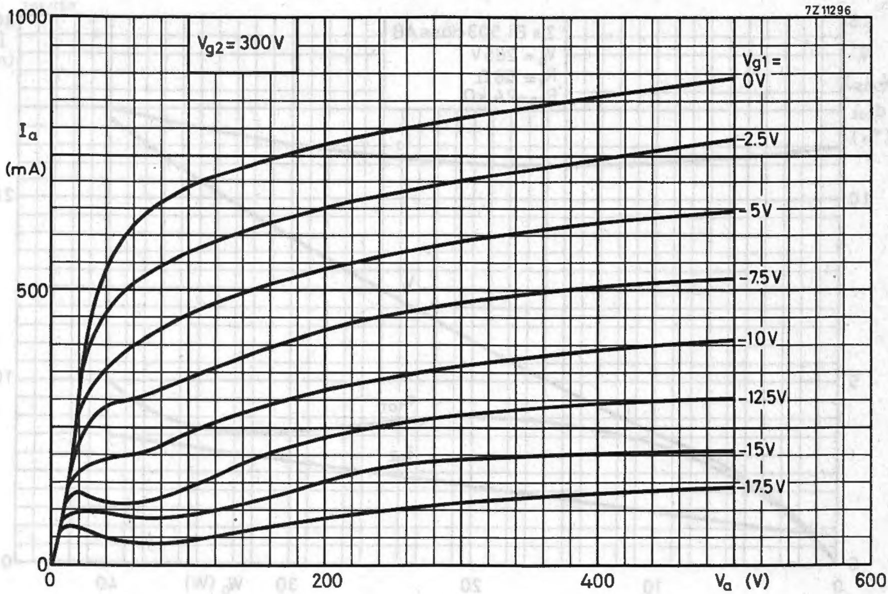

7Z11301
I
(mA)
800
600
400
200
0
I $V_a = V_{g2} = 300$ V
II $V_a = V_{g2} = 250$ V
III $V_a = V_{g2} = 200$ V
I_a
I_{g2}
I
II
III
I
II
III
−30
V_{g1} (V)
−20
−10
0

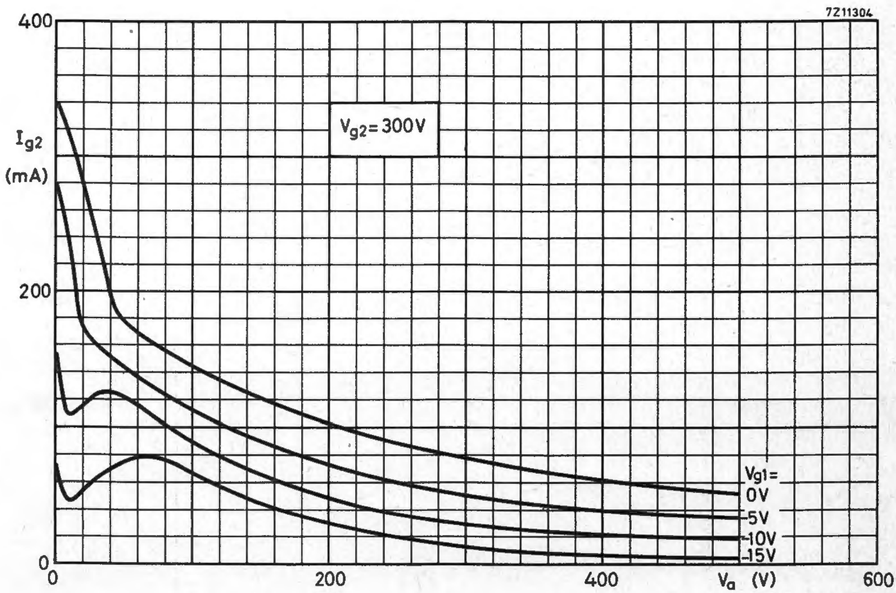

7Z11297
1000
500
0
I_a
(mA)
V_{g2} = 200 V
V_{g1} =
0V
-2.5V
-5V
-7.5 V
-10V
-12.5V
0
200
400
600
V_a (V)

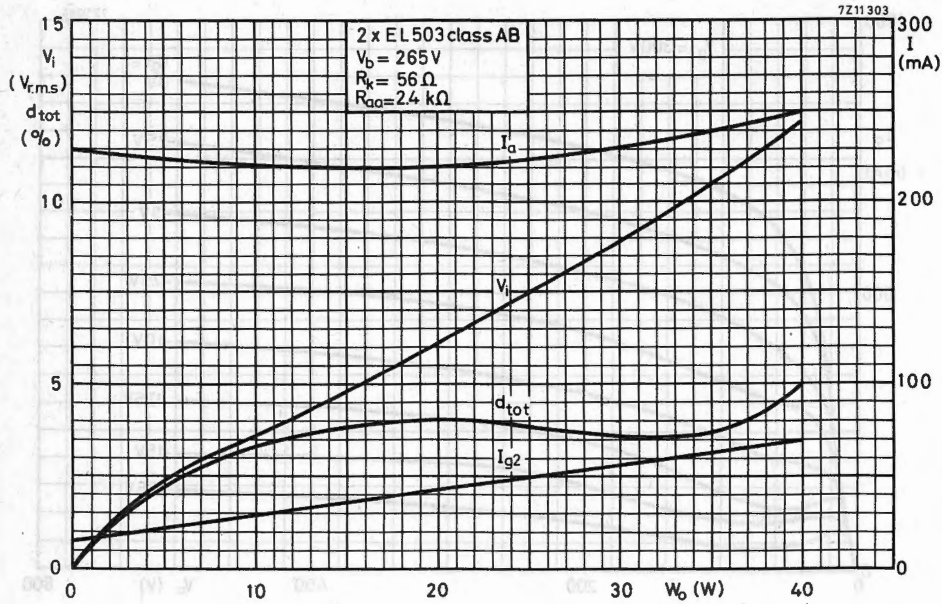

7Z11299
400
200
0
I_{g2}
(mA)
V_{g2} = 200 V
V_{g1} =
0V
-5V
-10V
0
200
400
600
V_a (V)


7Z11 300
1000
500
0
I_a
(mA)
V_{g2}= 250V
V_{g1}=
0 V
-2.5V
-5V
-7.5V
-10V
-12.5V
-15V
0
200
400
V_a (V)
600


7Z112 98
400
200
0
I_{g2}
(mA)
V_{g2} = 250 V
V_{g1}=
-0V
-5V
-10V
-15 V
0
200
400
V_a (V)
600


7Z 11296
1000
V_{g2} = 300 V
I_a
(mA)
500
0
V_{g1} =
0 V
-2.5 V
-5 V
-7.5 V
-10 V
-12.5 V
-15 V
-17.5 V
0
200
400
V_a (V)
600


7Z11304
400
V_{g2} = 300 V
I_{g2}
(mA)
200
0
V_{g1} =
0 V
-5 V
-10 V
-15 V
0
200
400
V_a (V)
600


7Z11303
2 x EL503 class AB
V_b = 265 V
R_k = 56 Ω
R_{aa} = 2.4 kΩ
V_i ($V_{r.m.s}$)
d_{tot} (%)
I (mA)
I_a
V_i
d_{tot}
I_{g2}
W_o (W)
15
10
5
0
300
200
100
0
10
20
30
40

LINE OUTPUT PENTODE

Beam pentode intended for use as line output tube in television receivers.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	1.38	A

LIMITING VALUES (Design centre rating system)

Cathode to heater voltage,

DC + peak, k positive	V_{kf}	max.	200	V
k negative	$-V_{kf}$		200	V [1])

For further data and curves of this type please refer to type PL 504

---

[1]) DC component max. 100 V.

LINE OUTPUT PENTODE

Output pentode intended for colour TV line deflection circuits.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	2	A

LIMITING VALUES (Design centre rating system)

Cathode to heater voltage,

DC + peak, k positive	V_{kf}	max.	200	V
k negative	$-V_{kf}$	max.	200	V [1]
Anode dissipation	W_a	max.	25	W
Anode + grid No. 2 dissipation (triode connected)	W_a+W_{g2}	max.	26	W
(Design max. rating system) [2]				
Anode dissipation	W_a	max.	34	W
Anode + grid No. 2 dissipation (triode connected)	W_a+W_{g2}	max.	35	W

For further data and curves of this type
please refer to type PL 509

---

[1]) DC component max. 100 V.

[2]) The design maximum limits should not be exceeded with a normal tube under the worst probable operating conditions at a normal picture width.

FRAME OUTPUT PENTODE

Pentode intended for use as frame output amplifier in colour television receivers.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	825	mA

LIMITING VALUES (Design centre rating system)

Cathode to heater voltage	V_{kf}	max.	100	V

For further data of this type please refer to type PL508

LINE OUTPUT PENTODE

Output pentode intended for colour TV line deflection circuits.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater voltage	I_f	2	A

LIMITING VALUES (Design centre rating system)

Cathode to heater voltage,

DC + peak, k positive	V_{kf}	max.	200	V
k negative	$-V_{kf}$	max.	200	V [1]

For further data and curves of this type please refer to type PL 509

[1]) DC component max. 100 V.

LINE OUTPUT PENTODE

Output pentode intended for colour TV line deflection circuits.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater voltage	I_f	2	A

LIMITING VALUES (Design centre rating system)

Cathode to heater voltage,

DC + peak, k positive	V_{kf}	max.	200	V	
k negative	$-V_{kf}$	max.	200	V	[1]

For further data and curves of this type please refer to type PL519

[1]) DC component max. 100 V.

Data based on pre-production tubes.

VIDEO OUTPUT PENTODE

Luminance output tube in colour TV receivers

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	800	mA

LIMITING VALUES (Design centre rating system)

Cathode to heater voltage	V_{kf}	max.	100	V

For further data of this type please refer to type PL802

TUNING INDICATOR

Tuning indicator intended for use in A.M. receivers.

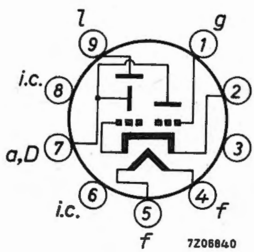
HEATING: Indirect by A.C. or D.C.; parallel supply

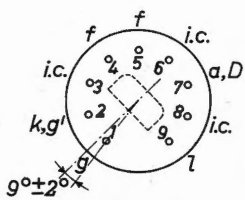
Heater voltage	V_f	6.3	V
Heater current	I_f	300	mA

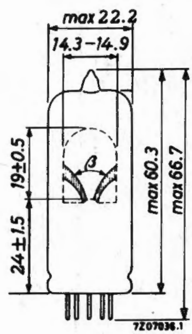
DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval







OPERATING CHARACTERISTICS

Supply voltage	V_b	250		V
Luminescent screen voltage	V_ℓ	250		V
Anode resistor	R_a	0.5		MΩ
Grid resistor	R_g	3		MΩ
Grid supply voltage	V_{b_g}	−1	−14	V
Light sector	β	5	50	o
Anode current	I_a	0.37	0.01	mA
Luminescent screen current	I_ℓ	2	2.3	mA

LIMITING VALUES (Design centre rating system)

Anode voltage	V_{a_o}	max. 550	V
	V_a	max. 300	V
Anode dissipation	W_a	max. 0.2	W
Luminescent screen voltage	$V_{\ell o}$	max. 550	V
	V_ℓ	max. 300	V
	V_ℓ	min. 165	V
Cathode current	I_k	max. 3	mA
Grid resistor	R_g	max. 3	MΩ
Cathode to heater voltage	V_{kf}	max. 100	V

TUNING INDICATOR

Tuning indicator tube.

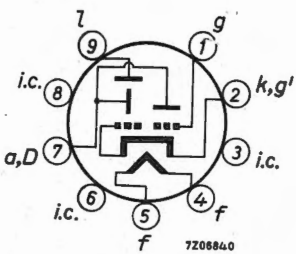
HEATING: Indirect by A.C. or D.C.; series or parallel supply

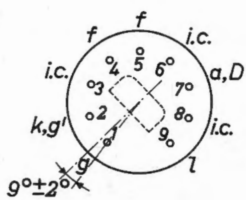
Heater voltage	V_f	6.3	V
Heater current	I_f	300	mA

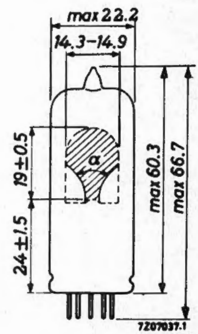
DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval







OPERATING CHARACTERISTICS

Supply voltage	V_b	250		V
Luminescent screen voltage	V_ℓ	250		V
Anode resistor	R_a	0.5		MΩ
Grid resistor	R_g	3		MΩ
Grid supply voltage	V_{bg}	−1	−10.5	V
Shadow sector	α	65	5	°
Anode current	I_a	0.37	0.02	mA
Luminescent screen current	I_ℓ	2.0	2.3	mA

LIMITING VALUES (Design centre rating system)

Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	300	V
Anode dissipation	W_a	max.	0.2	W
Luminescent screen voltage	V_{ℓ_o}	max.	550	V
	V_ℓ	max.	300	V
	V_ℓ	min.	165	V
Cathode current	I_k	max.	3	mA
Cathode to heater voltage	V_{kf}	max.	100	V
Grid resistor	R_g	max.	3	MΩ

TUNING INDICATOR

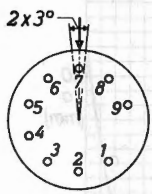
Indicator tube with triode amplifier intended for use as tuning indicator or for modulation control.

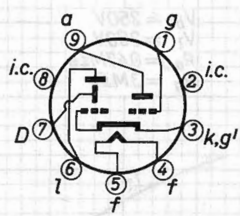
HEATING: Indirect by A.C. or D.C.; parallel supply

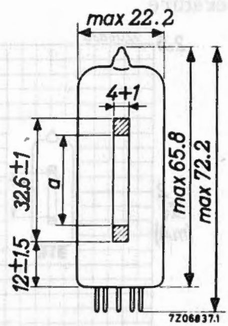
Heater voltage	V_f	6.3	V
Heater current	I_f	210	mA

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Noval







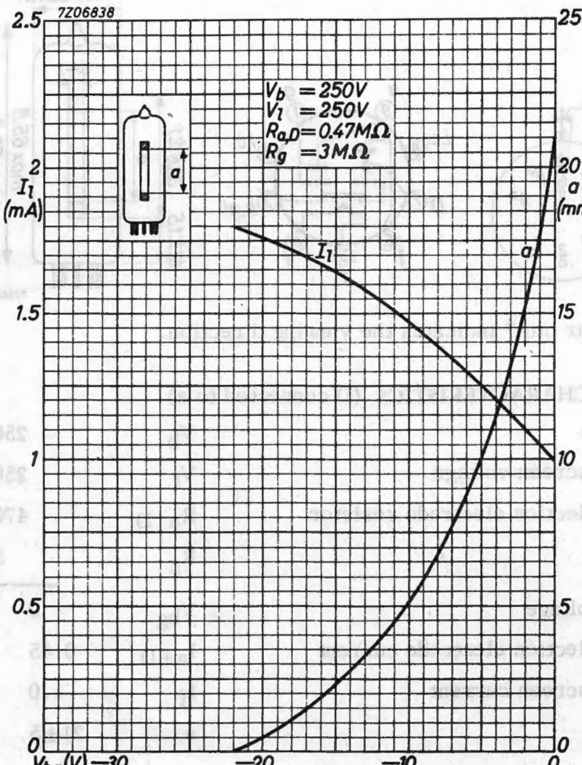
The arrow near pin 7 indicates the viewing direction.

OPERATING CHARACTERISTICS (D connected to a)

Supply voltage	V_b	250		V
Luminescent screen voltage	V_ℓ	250		V
Anode and deflection electrode resistor	$R_{a,D}$	470		kΩ
Grid resistor	R_g	3		MΩ
Grid supply voltage	V_{bg}	0	−22	V
Anode and deflection electrode current	I_{a+D}	0.45	0.06	mA
Luminescent screen current	I_ℓ	1.0	1.8	mA
Shadow length	a	21±5	0	mm

LIMITING VALUES (Design centre rating system)

Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	300	V
Anode dissipation	W_a	max.	0.5	W
Deflection electrode voltage	V_{D_o}	max.	550	V
	V_D	max.	300	V
Luminescent screen voltage	$V_{\ell o}$	max.	550	V
	V_ℓ	max.	300	V
	V_ℓ	min.	170	V
Cathode current	I_k	max.	3	mA
Grid resistor	R_g	max.	3	MΩ
Cathode to heater voltage	V_{kf}	max.	100	V
Bulb temperature	t_{bulb}	max.	120	°C



TUNING INDICATOR

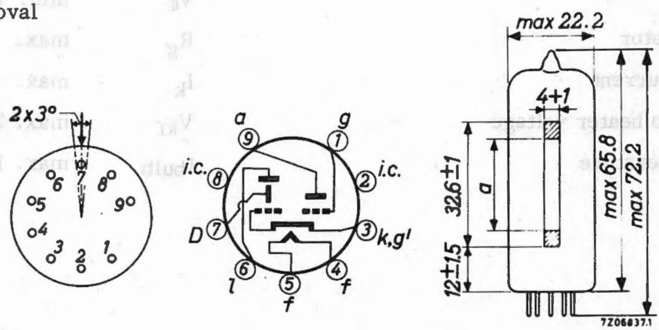
Tuning indicator tube.

HEATING: Indirect by A.C. or D.C.; series or parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	300	mA

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Noval



The arrow near pin 7 indicates the viewing direction.

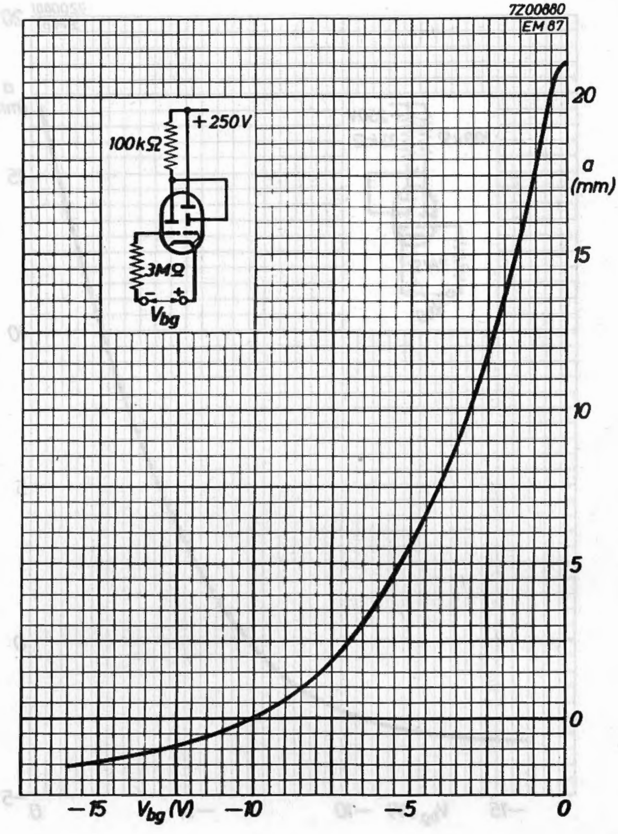
OPERATING CHARACTERISTICS (D connected to a)

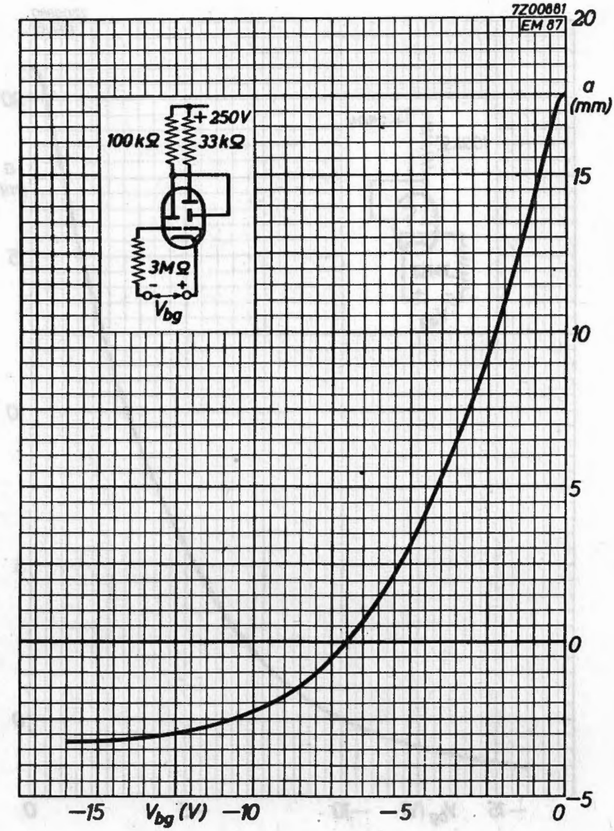
Supply voltage	V_b		250		V
Luminescent screen voltage	V_ℓ		250		V
Anode and deflection electrode resistor	$R_{a,D}$		100		kΩ
Grid resistor	R_g		3		MΩ
Grid supply voltage	V_{bg}	0	−10	−15	V
Anode and deflection electrode current	I_{a+D}	2.0	0.5	0.2	mA
Luminescent screen current	I_ℓ	1.0	1.8	2.0	mA
Shadow length	a	21	0	−1.5	mm[1])

[1]) A negative value of "a" means overlapping:
The grid bias for a = o is reduced by decreasing V_ℓ.
The measure of overlapping at V_g = −15 V will then increase (see page 4).

LIMITING VALUES (Design centre rating system)

Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	300	V
Anode dissipation	W_a	max.	0.6	W
Deflection electrode voltage	V_{D_o}	max.	550	V
	V_D	max.	300	V
Luminescent screen voltage	V_{ℓ_o}	max.	550	V
	V_ℓ	max.	300	V
	V_ℓ	min.	170	V
Grid resistor	R_g	max.	3	MΩ
Cathode current	I_k	max.	5	mA
Cathode to heater voltage	V_{kf}	max.	250	V
Bulb temperature	t_{bulb}	max.	120	^{o}C


7Z00880
EM 87
+250 V
100 kΩ
3 MΩ
V_{bg}
20
a (mm)
15
10
5
0
−15
V_{bg} (V)
−10
−5
0


7Z00881
EM 87
20
15
10
5
0
−5
a (mm)
+250V
100kΩ
33kΩ
3MΩ
V_{bg}
−15
V_{bg} (V)
−10
−5
0

BOOSTER DIODE

Booster diode intended for use in line time-base circuits of television receivers.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater current	V_f	6.3	V
Heater voltage	I_f	810	mA

For further data and curves
please refer to type PY81

SINGLE ANODE RECTIFYING TUBE

Single anode high vacuum rectifying tube.

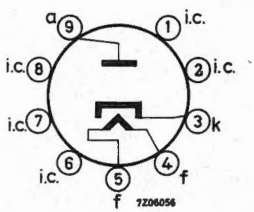
QUICK REFERENCE DATA (two tubes)			
Transformer voltage	V_{tr}	2x300	V_{RMS}
D.C. current	I_o	360	mA

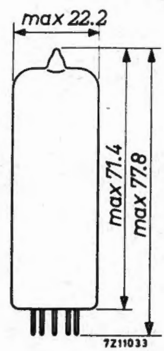
HEATING : Indirect by A.C. or D.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	900	mA

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Noval





OPERATING CHARACTERISTICS (two tubes in a two-phase half-wave circuit)

Transformer voltage	V_{tr}	=	2x250	2x280	2x300	V_{RMS}
D.C. output voltage	V_o	=	225	250	268	V
D.C. current	I_o	=	360	360	360	mA
Protecting resistance	R_t	=	2x75	2x95	2x110	Ω
Input capacitance of smoothing filter	C_{filt}	=	60	60	60	µF

LIMITING VALUES (Design centre rating system)
For two tubes in a two-phase half-wave circuit.

Transformer voltage	V_{tr}		max.		2x300	V_{RMS}
Anode voltage, peak inverse	$V_{a\ inv_p}$		max.		850	V
D.C. current	I_o		max.		360	mA
Anode peak current (each tube)	I_{ap}		max.		1.1	A
Cathode to heater voltage, peak	V_{kf_p}		max.		450	V
Input capacitor of smoothing filter	C_{filt}		max.		60	μF [1])
Protective resistance	R_t	min.	2x75	2x95	2x110	Ω
at transformer voltage	V_{tr}		2x250	2x280	2x300	V_{RMS}

[1]) When R_t is increased by 10 Ω, C_{filt} = max. 100 μF.

SINGLE ANODE E.H.T. RECTIFYING TUBES

High-vacuum single-anode rectifying tubes for high tension in television receivers (E.H.T. supply from the line time base).

The EY86 and the EY87 are equivalent except for the EY87 having a chemically treated envelope which avoids flash-over under conditions of high humidity and low atmospheric pressure (45 cm Hg).

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	90	mA

When the heater is to be operated on R.F. or flyback pulses, the heater voltage can be adjusted to 6.4 V e.g. by measurement with a thermocouple.

For further data and curve of these types
please refer to types DY86/DY87

BOOSTER DIODE

Booster diode intended for use in line time base circuits of television receivers.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	1.55	A

For further data and curves of this type
please refer to type PY88

BOOSTER DIODE

Booster diode intended for use in time base circuits of colour television receivers.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	2.1	A

For further data and curves of this type
please refer to type PY500

BOOSTER DIODE

Booster diode intended for use in time base circuits of colour television receivers.

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	2.1	A

For further data and curves of this type please refer to type PY500A

DOUBLE ANODE RECTIFYING TUBE

Double anode high vacuum rectifying tube

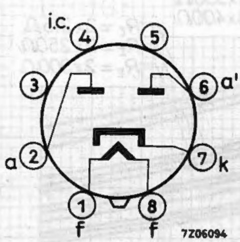
QUICK REFERENCE DATA			
Transformer voltage	V_{tr}	2x350	V
D.C. current	I_o	90	mA

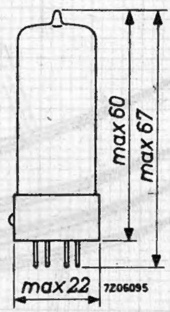
HEATING: Indirect by A.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	600	mA

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Rimlock



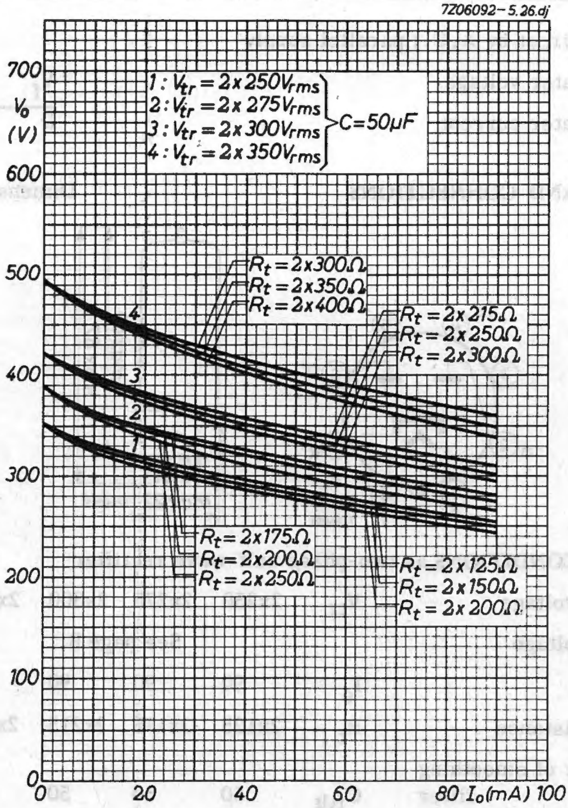


OPERATING CONDITIONS as two-phase half-wave rectifier

Transformer voltage	V_{tr}	2x250	2x275	2x300	2x350	V_{RMS}
D.C. output voltage		See page B				
D.C. current	I_o	90	90	90	90	mA
Protecting resistance	R_t	2x125	2x175	2x215	2x300	Ω
Input capacitor of smoothing filter	C_{filt}	50	50	50	50	μF

LIMITING VALUES (Design centre rating system)

Transformer voltage	V_{tr}	max.	2x350				V_{RMS}
D.C. current	I_o	max.	90				mA
Cathode to heater voltage, peak, k pos	V_{kf_p}	max.	500				V
Input capacitor of smoothing filter	C_{filt}	max.	50				μF
Protecting resistance	R_t	min.	2x125	2x175	2x215	2x300	Ω
at transformer voltage	V_{tr}		2x250	2x275	2x300	2x350	V_{RMS}



DOUBLE ANODE RECTIFYING TUBE

Double anode high vacuum rectifying tube

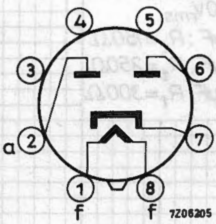
QUICK REFERENCE DATA			
Transformer voltage	V_{tr}	2x250	V_{RMS}
D.C. current	I_o	60	mA

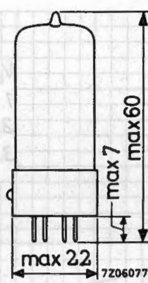
HEATING: Indirect by A.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	400	mA

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Rimlock



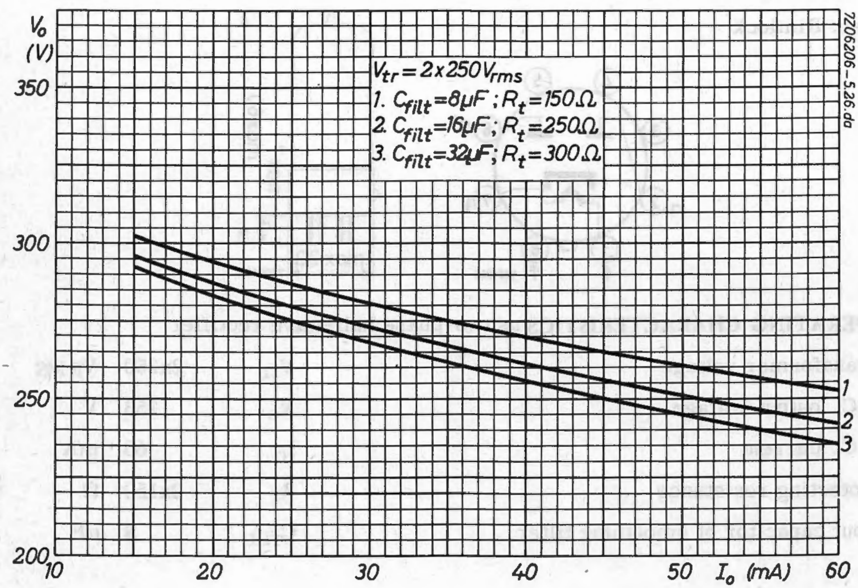


OPERATING CHARACTERISTICS as two-phase half-wave rectifier

Transformer voltage	V_{tr}	2x250	V_{RMS}
D.C. output voltage	V_o	253	V
D.C. current	I_o	60	mA
Protecting resistance	R_t	2x150	Ω
Input capacitor of smoothing filter	C_{filt}	8	μF

LIMITING VALUES (Design centre rating system)

Transformer voltage	V_{tr}	max.		2x250		V_{RMS}
D.C. current	I_o	max.		60		mA
Cathode to heater voltage, peak, k pos	V_{kf}	max.		350		V
Protecting resistance	R_t	min.	2x150	2x250	2x300	Ω
at	C_{filt}		8	16	32	μF



DOUBLE ANODE RECTIFYING TUBE

Double anode high vacuum rectifying tube

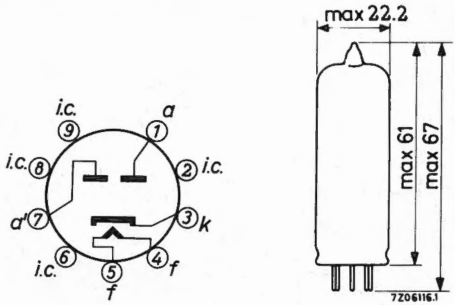
QUICK REFERENCE DATA			
Transformer voltage	V_{tr}	2x350	V_{RMS}
D.C. current	I_o	90	mA

HEATING: Indirect by A.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	600	mA

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Noval

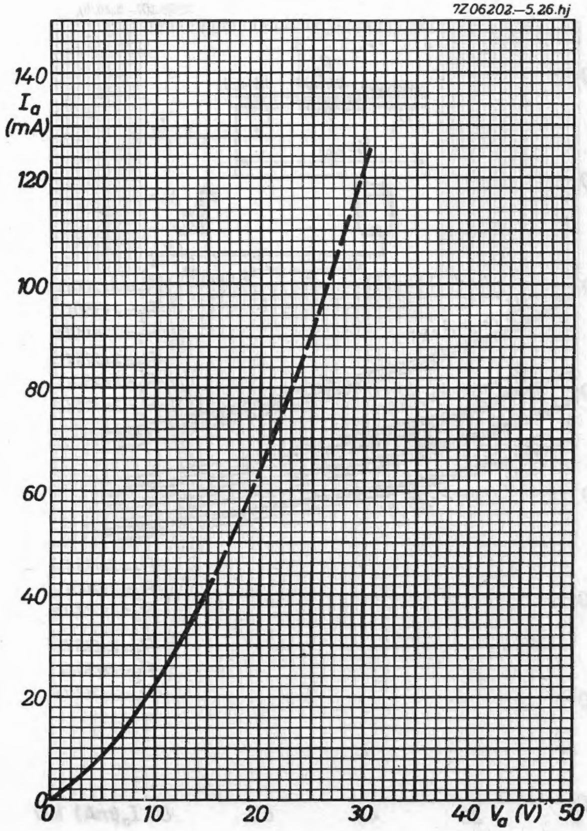


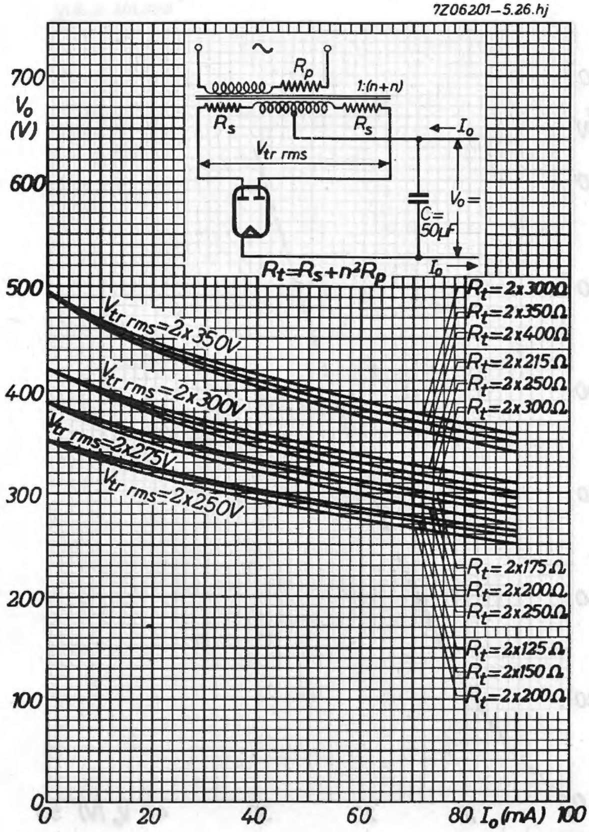
OPERATING CHARACTERISTICS as two-phase half-wave rectifier

Transformer voltage	V_{tr}	2x250	2x275	2x300	2x350	V_{RMS}
D.C. output voltage	V_o	260	285	310	360	V
D.C. current	I_o	90	90	90	90	mA
Protecting resistance	R_t	2x125	2x175	2x215	2x300	Ω
Input capacitor of smoothing filter	C_{filt}	50	50	50	50	μF

LIMITING VALUES (Design centre rating system)

Transformer voltage	V_{tr}	max.	2x350	V_{RMS}		
D.C. current	I_o	max.	90	mA		
Cathode to heater voltage, peak, k pos	V_{kf_p}	max.	500	V		
Input capacitor of smoothing filter	C_{filt}	max.	50	μF		
Protecting resistance	R_t min.	2x125	2x175	2x215	2x300	Ω
at transformer voltage	V_{tr}	2x250	2x275	2x300	2x350	V_{RMS}


7Z06202.–5.26.hj
140
I_a
(mA)
120
100
80
60
40
20
0
0
10
20
30
40 V_a (V) 50


7Z06201-5.26.hj
700
V_o
(V)
600
500
400
300
200
100
0
0
20
40
60
80 I_o(mA) 100
R_p
1:(n+n)
R_s
R_s
I_o
$V_{tr\ rms}$
V_o=
C=
50μF
$R_t=R_s+n^2R_p$
I_o
$V_{tr\ rms}$=2x350V
$V_{tr\ rms}$=2x300V
$V_{tr\ rms}$=2x275V
$V_{tr\ rms}$=2x250V
R_t=2x300Ω
R_t=2x350Ω
R_t=2x400Ω
R_t=2x215Ω
R_t=2x250Ω
R_t=2x300Ω
R_t=2x175Ω
R_t=2x200Ω
R_t=2x250Ω
R_t=2x125Ω
R_t=2x150Ω
R_t=2x200Ω

DOUBLE ANODE RECTIFYING TUBE

Double anode high vacuum rectifying tube.

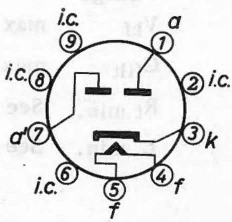
QUICK REFERENCE DATA			
Transformer voltage	V_{tr}	2x450	V_{RMS}
D.C. current	I_o	100	mA

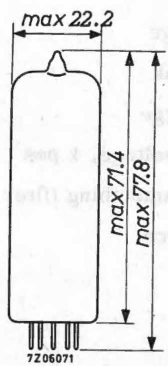
HEATING: Indirect by A.C.; parallel supply

Heater voltage	V_f	6.3	V
Heater current	I_f	1	A

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Noval





OPERATING CHARACTERISTICS

As two-phase half-wave rectifier with capacitor input filter See page 4 upper fig.

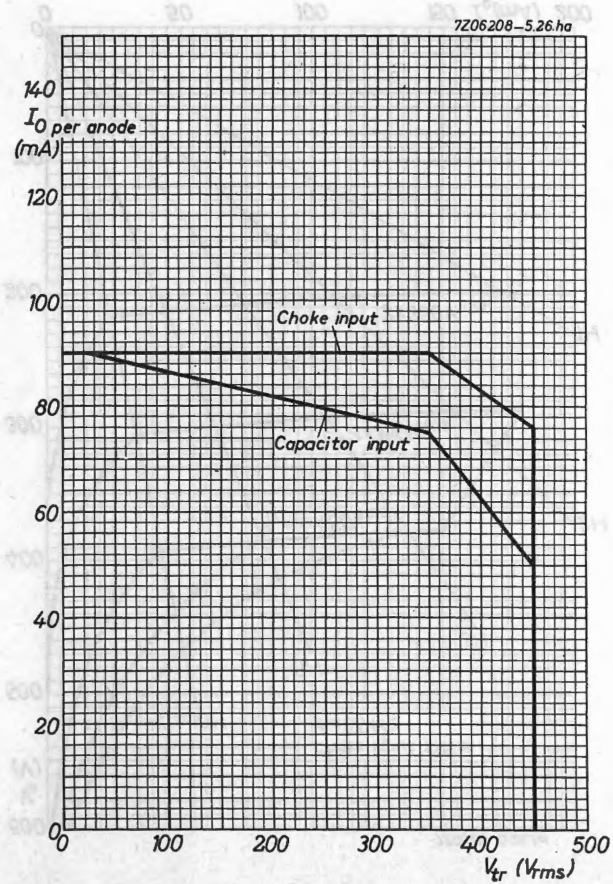
Transformer voltage	V_{tr}	2x250	2x350	2x450	V_{RMS}
D.C. output voltage	V_o	245	352	497	V
D.C. current	I_o	160	150	100	mA
Protecting resistance	R_t	2x150	2x230	2x310	Ω
Input capacitor of smoothing filter	C_{filt}	50	50	50	μF

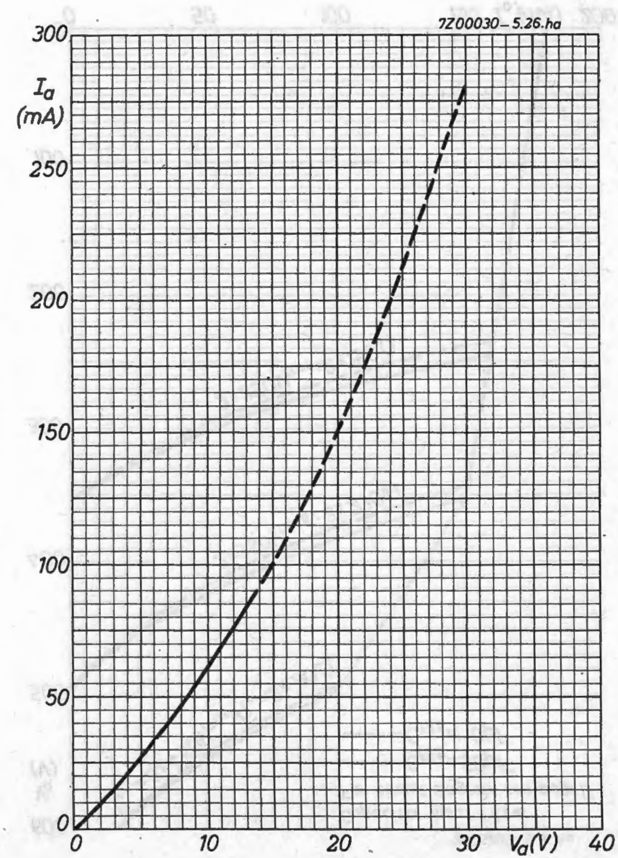
As two-phase half-wave rectifier with choke input filter See page 4 lower fig.

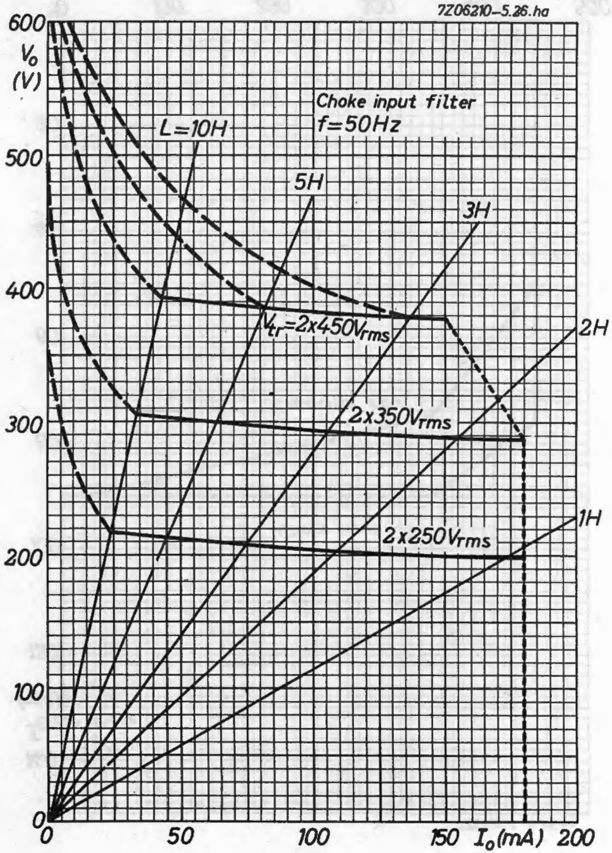
Transformer voltage	V_{tr}	2x250	2x350	2x450	V_{RMS}
D.C. output voltage	V_o	199	288	378	V
D.C. current	I_o	180	180	150	mA
Choke	L	10	10	10	H

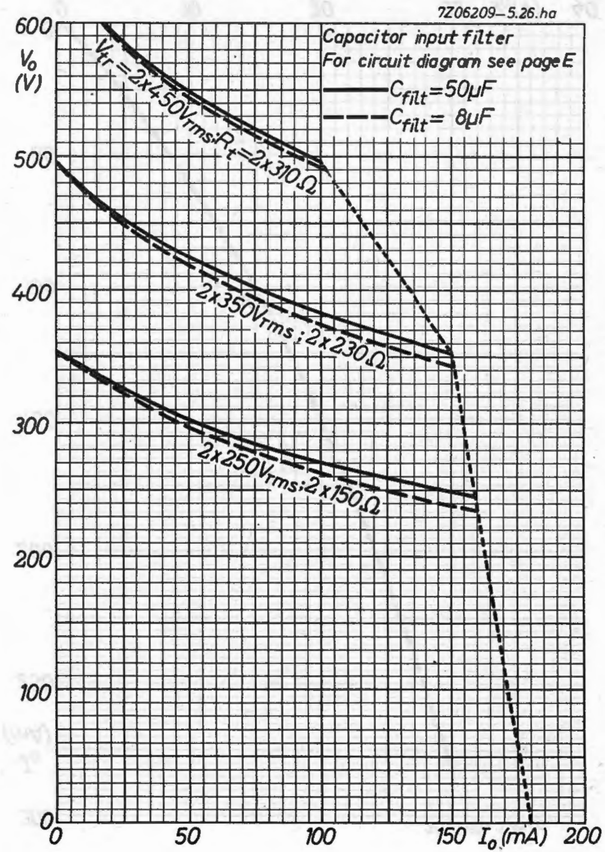
LIMITING VALUES (Design centre rating system)

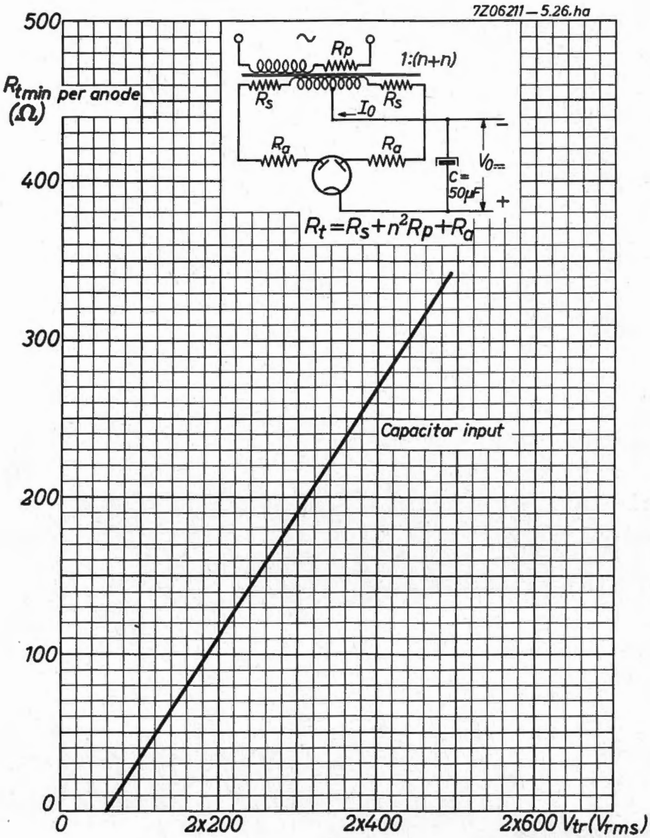
Anode voltage, peak inverse	$V_{a_{invp}}$	max.	1300	V
D.C. current	I_o	See page 3 lower figure		
Transformer voltage	V_{tr}			
Anode current, peak	I_{a_p}	max.	500	mA
surge	$I_{a_{surge}}$	max.	1.8	A
Cathode to heater voltage, k pos	V_{kf}	max.	500	V
Input capacitor of smoothing filter	C_{filt}	max.	50	μF
Protecting resistance	R_t min.	See page 5		
Choke	L min.	See page 4 lower fig.		


7Z06208-5.26.ha
I_O per anode (mA)
Choke input
Capacitor input
V_{tr} (V_{rms})
0
20
40
60
80
100
120
140
100
200
300
400
500


7Z00030-5.26.ha
I_a (mA)
V_a(V)
0
50
100
150
200
250
300
10
20
30
40


7Z06210-5.26.ha
Choke input filter
f=50Hz
L=10H
5H
3H
2H
1H
V_{tr}=2x450V_{rms}
2x350V_{rms}
2x250V_{rms}
V_o (V)
I_o (mA)
0
50
100
150
200
300
400
500
600


7Z06209-5.26.ha
Capacitor input filter
For circuit diagram see page E
C_{filt}=50µF
C_{filt}= 8µF
V_{tr}=2x450V_{rms};R_t=2x310Ω
2x350V_{rms};2x230Ω
2x250V_{rms};2x150Ω
V_o (V)
I_o (mA)
0
50
100
150
200
300
400
500
600


7Z06211—5.26.ha
500
400
300
200
100
0
$R_{t\,min}$ per anode
(Ω)
~
R_p
1:(n+n)
R_s
R_s
I_0
R_a
R_a
$V_{0=}$
C=
50µF
−
+
$R_t = R_s + n^2 R_p + R_a$
Capacitor input
0
2x200
2x400
2x600 V_{tr} (V_{rms})

SINGLE ANODE E.H.T. RECTIFYING TUBE

Single anode E.H.T. rectifying tube intended for use in colour television receivers.
The GY501 has a chemically treated envelope to avoid flash-over under conditions of high humidity and low atmospheric pressure (45 cm Hg).

QUICK REFERENCE DATA			
D.C. output voltage	V_o	25	kV
Anode current	I_a	1.5	mA

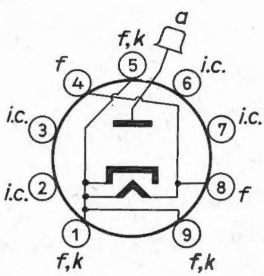
HEATING: Indirect by A.C. or D.C.; parallel supply

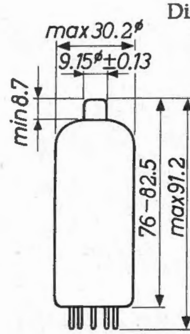
Heater voltage	V_f	3.15	V [1]
Heater current	I_f	400	mA

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Magnoval





Pins 1, 5 and 9 may be used to connect an anti-corona ring.

Circuit elements having the same potential as the heater (e.g. a series resistor) may be connected to pins 3 and 7. These pins must never be earthed.

Precaution: X-ray shielding may be required to give protection against excessive radiation.

[1]) Under nominal operating conditions and with the longterm average value of I_a to be expected in practice, $V_{f\,RMS}$ should be 3.15 V.
The heater voltage deviation resulting from spread or variation of operating conditions should be limited to the values indicated by the diagram in fig. A.

CAPACITANCES

Anode to cathode	C_{ak}		1.2	pF

OPERATING CHARACTERISTICS

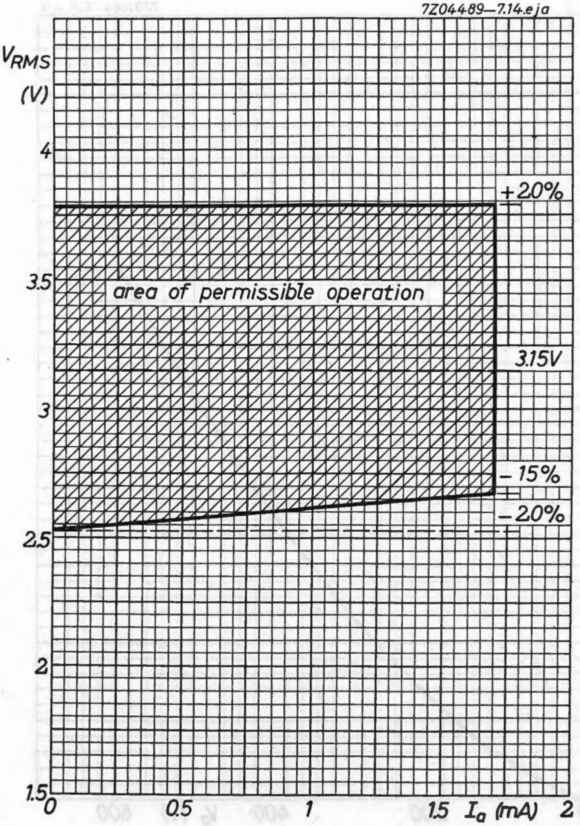
Output voltage	V_o		25	kV
Anode current	I_a		1.5	mA

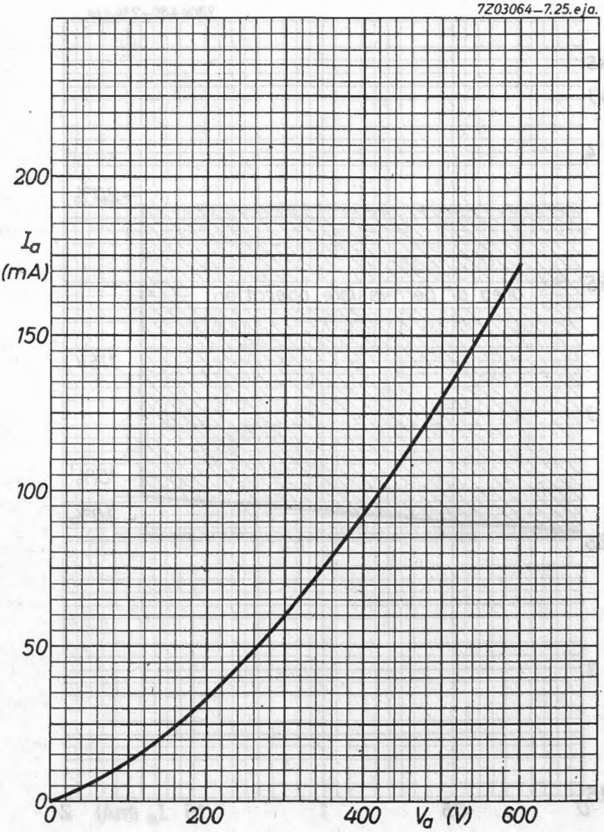
LIMITING VALUES (Design centre rating system)

Peak inverse voltage (absolute max.)	V_{ainv_p}	max.	35	kV [1])
Output voltage (absolute max.)	V_o	max.	27.5	kV
Output current, average	I_o	max.	1.7	mA
peak	I_{op}	max.	100	mA [2])

[1]) The negative peak due to ringing in the line output transformer should be taken into account.
Max. pulse duration 22% of a cycle and 18 μs.

[2]) Design max. rating system
Max. pulse duration 10% of a line scanning cycle with a max. of 10 μs.


7Z04489—7.14.eja
V_{RMS} (V)
4
3.5
3
2.5
2
1.5
+20%
3.15V
−15%
−20%
area of permissible operation
0
0.5
1
1.5
I_a (mA)
2


7Z03064–7.25.eja.
200
I_a
(mA)
150
100
50
0
0
200
400
V_a (V)
600

DOUBLE ANODE RECTIFYING TUBE

Double anode high vacuum rectifying tube.

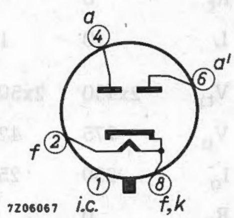
QUICK REFERENCE DATA			
Transformer voltage	V_{tr}	2x450	V_{RMS}
D.C. current	I_o	250	mA

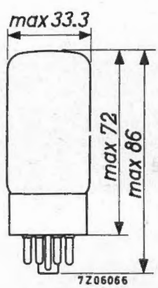
HEATING: Indirect by A.C.; parallel supply

Heater voltage	V_f	5	V
Heater current	I_f	1.9	A

DIMENSIONS AND CONNECTIONS — Dimensions in mm

Base: Octal





OPERATING CHARACTERISTICS

As two-phase half-wave rectifier with capacitor input

Transformer voltage	V_{tr}	2x300	2x350	2x400	V_{RMS}
D.C. output voltage	V_o	330	380	430	V
D.C. current	I_o	250	250	250	mA
Protecting resistance	R_t	2x75	2x100	2x125	Ω
Input capacitor of smoothing filter	C_{filt}	60	60	60	μF
Transformer voltage	V_{tr}	2x450	2x500	2x550	V_{RMS}
D.C. output voltage	V_o	480	560	640	V
D.C. current	I_o	250	200	160	mA
Protecting resistance	R_t	2x150	2x175	2x200	Ω
Input capacitor of smoothing filter	C_{filt}	60	60	60	μF

As two-phase half-wave rectifier with choke input

Transformer voltage	V_{tr}	2x300	2x350	2x400	V_{RMS}
D.C. output voltage	V_o	250	290	330	V
D.C. current	I_o	250	250	250	mA
Protecting resistor	R_t	0	0	0	Ω
Choke	L	10	10	10	H
Transformer voltage	V_{tr}	2x450	2x500	2x550	V_{RMS}
D.C. output voltage	V_o	375	420	465	V
D.C. current	I_o	250	250	225	mA
Protecting resistor	R_t	0	0	0	Ω
Choke	L	10	10	10	H

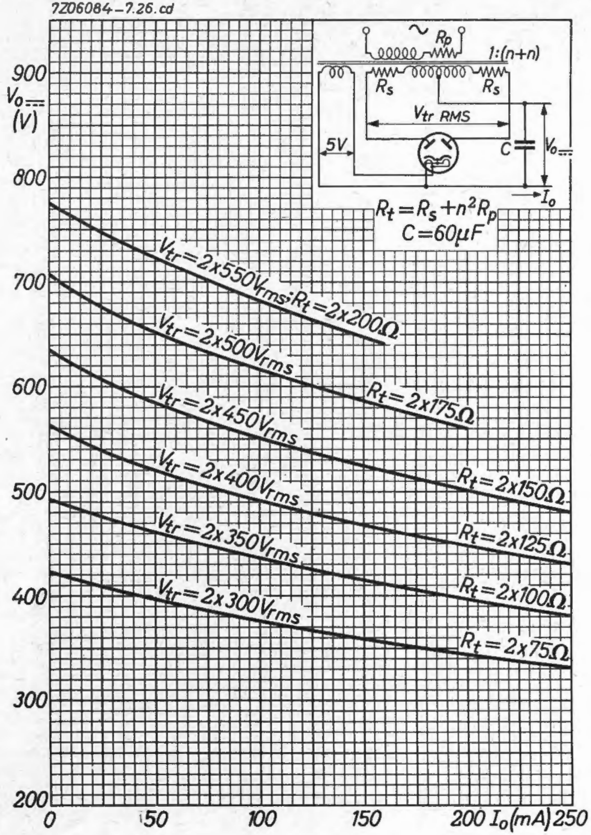
LIMITING VALUES (Design centre rating system)
See also page 5

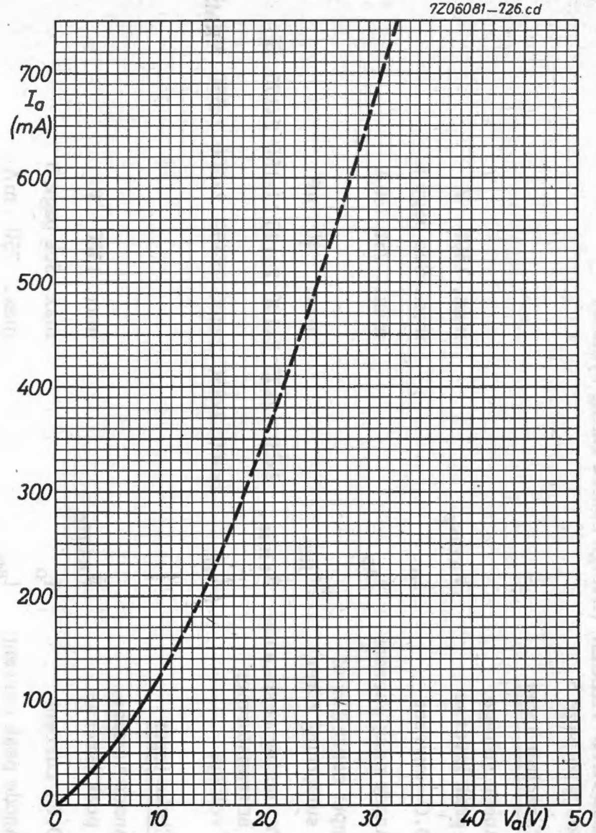
Capacitor input

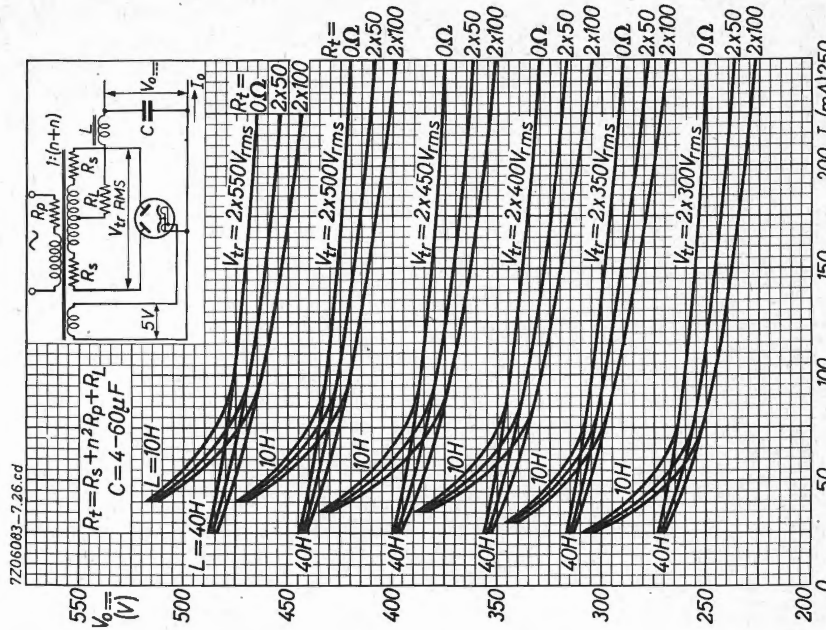
Anode voltage, peak inverse	$V_{a\,inv_p}$	max.	1500	V				
D.C. current	I_o	max.	See page 5					
Anode peak current	I_{ap}	max.	750	mA				
Input capacitor of smoothing filter	C_{filt}	max.	60	μF				
Protecting resistance	$R_{t\,min.}$	2x50	2x75	2x100	2x125	2x150	2x175	Ω
at transformer voltage	V_{tr}	2x300	2x350	2x400	2x450	2x500	2x550	V_{RMS}

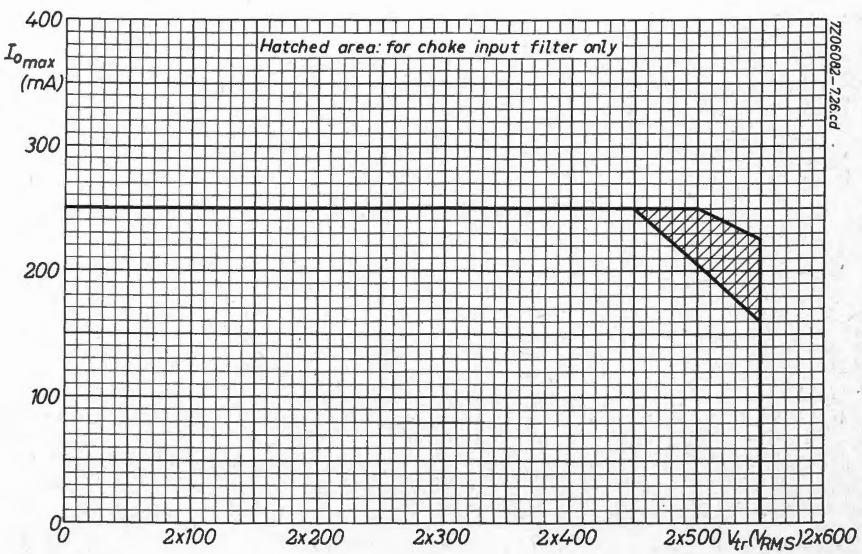
Choke input

Anode voltage, peak inverse	$V_{a\,inv_p}$	max.	1500	V
D.C. current	I_o	max.	See page 5	
Anode peak current	I_{ap}	max.	750	mA


7Z06084-7.26.cd
$R_t = R_s + n^2R_p$
$C = 60\mu F$
1:(n+n)
R_p
R_s
V_{tr} RMS
5V
C
V_o
I_o
V_o (V)
I_o(mA)
$V_{tr}=2x550V_{rms}$; $R_t=2x200\Omega$
$V_{tr}=2x500V_{rms}$ $R_t=2x175\Omega$
$V_{tr}=2x450V_{rms}$ $R_t=2x150\Omega$
$V_{tr}=2x400V_{rms}$ $R_t=2x125\Omega$
$V_{tr}=2x350V_{rms}$ $R_t=2x100\Omega$
$V_{tr}=2x300V_{rms}$ $R_t=2x75\Omega$
200 300 400 500 600 700 800 900
0 50 100 150 200 250


7Z06081-726.cd
I_a (mA)
V_a(V)
0 100 200 300 400 500 600 700
0 10 20 30 40 50


7Z06083-7.26.cd
$R_t = R_s + n^2 R_p + R_L$
$C = 4-60\mu F$
~ R_p
1:(n+n)
R_s
R_L
R_s
L
V_{tr} RMS
5V
C
V_o
I_o
L=10H
L=40H
10H
40H
$V_{tr}=2x550V_{rms}$
$V_{tr}=2x500V_{rms}$
$V_{tr}=2x450V_{rms}$
$V_{tr}=2x400V_{rms}$
$V_{tr}=2x350V_{rms}$
$V_{tr}=2x300V_{rms}$
R_t=
0Ω
2x50
2x100
V_o (V)
550
500
450
400
350
300
250
200
0
50
100
150
200
I_o(mA)
250


7Z06082-7.26.cd
Hatched area: for choke input filter only
$I_{o\,max}$ (mA)
400
300
200
100
0
0
2x100
2x200
2x300
2x400
2x500
V_{tr} (V_{RMS})
2x600

TRIPLE DIODE-TRIODE

Triple diode-triode, intended for video and FM and AM audio signal detection and A.F. signal amplification.

HEATING: Indirect by A.C. or D.C.; series supply

Heater current	I_f	300	mA
Heater voltage	V_f	9.5	V

For further data and curves
please refer to UABC80

U.H.F. TRIODE

Triode intended for use as grounded grid U.H.F. amplifier, oscillator or mixer for bands IV and V.

QUICK REFERENCE DATA			
Anode current	I_a	12	mA
Transconductance	S	14	mA/V
Amplification factor	μ	68	-

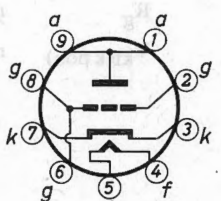
HEATING: Indirect by A.C. or D.C.; series supply

Heater current	I_f	300	mA
Heater voltage	V_f	3.8	V

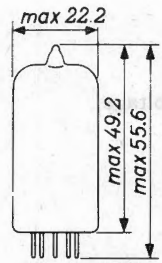
DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval



7Z06106



7Z11028

OPERATING CHARACTERISTICS

As grounded grid amplifier

Anode voltage	V_a	175	V
Cathode resistor	R_k	125	Ω
Anode current	I_a	12	mA
Transconductance	S	14	mA/V

As self-oscillating mixer

Supply voltage	V_{b_a}	220	V
Anode resistor	R_a	5.6	kΩ
Grid resistor	R_g	47	kΩ
Anode current	I_a	12	mA
Grid current	I_g	50	μA

LIMITING VALUES (Design centre rating system)

Anode voltage	V_{a_o}	max. 550	V	
	V_a	max. 220	V	
Anode dissipation	W_a	max. 2.2	W	
Cathode current	I_k	max. 20	mA	
Grid voltage	$-V_g$	max. 50	V	
Grid resistor	R_g	max. 1	MΩ	
Cathode to heater voltage	$V_{kf(k\,pos)}$	max. 100	V	1)

1) A.C. component max. 50 V_{RMS}.

CAPACITANCES

Without external shield

Anode to grid	C_{ag}	2.2	pF
Anode to cathode	C_{ak}	0.24	pF
Grid to cathode	C_{gk}	3.5	pF
Grid to heater	C_{gf}	0.27	pF
Cathode to grid + heater	$C_{k/gf}$	6.3	pF
Grid to cathode + heater	$C_{g/kf}$	3.8	pF
Anode to cathode + heater	$C_{a/kf}$	0.35	pF
Anode to grid + heater	$C_{a/gf}$	2.3	pF

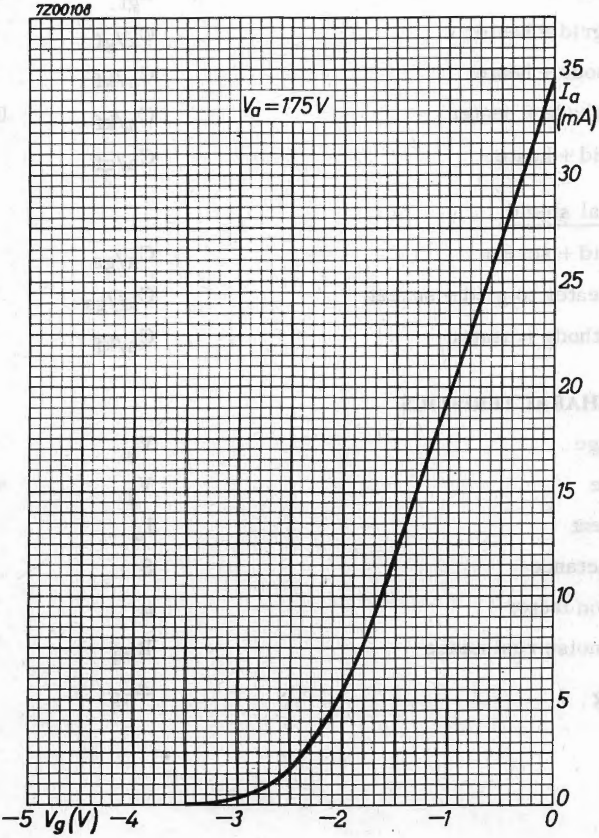
With external shield

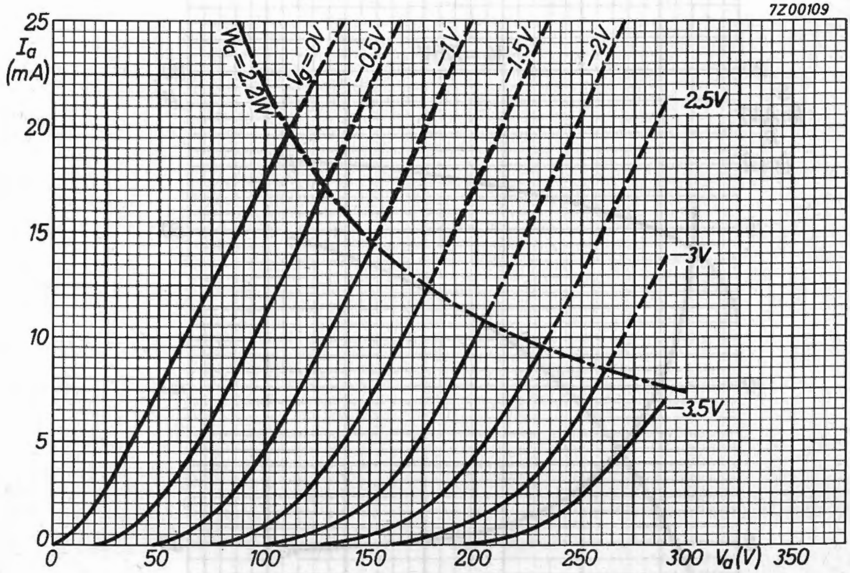
Anode to grid + screen	$C_{a/gs}$	3.3	pF
Cathode + heater to grid + screen	$C_{kf/gs}$	4.1	pF
Anode to cathode + heater	$C_{a/kf}$	0.3	pF

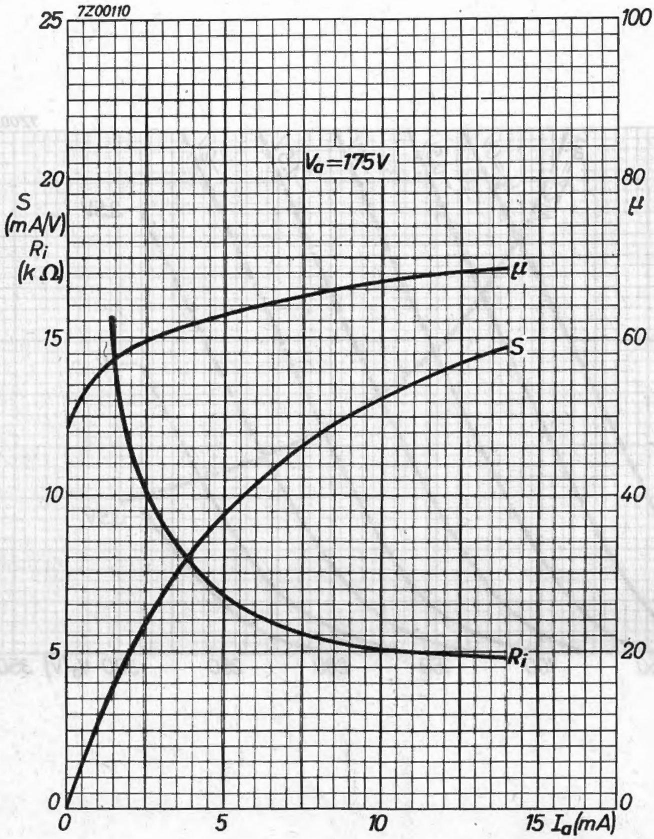
TYPICAL CHARACTERISTICS

Anode voltage	V_a	175	V
Grid voltage	V_g	-1.5	V
Anode current	I_a	12	mA
Transconductance	S	14	mA/V
Amplification factor	μ	68	-
Equivalent noise resistance	R_{eq}	230	Ω
Increase C_g	ΔC_g	2	pF [1]

[1] Difference between C_g of cold and hot tube.


7Z00108
$V_a = 175\,V$
35
I_a
(mA)
30
25
20
15
10
5
0
−5
V_g(V)
−4
−3
−2
−1
0


7Z00109
25
I_a
(mA)
20
15
10
5
0
0
50
100
150
200
250
300
V_a(V)
350
W_a=2.2W
V_g=0V
−0.5V
−1V
−1.5V
−2V
−2.5V
−3V
−3.5V


7Z00110
25
20
15
10
5
0
S
(mA/V)
R_i
(kΩ)
100
80
60
40
20
0
μ
V_a=175V
μ
S
R_i
0
5
10
15 I_a(mA)

U.H.F. TRIODE

Triode intended for use as grounded grid U.H.F. amplifier for bands IV and V.

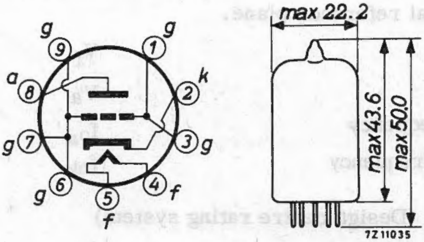
QUICK REFERENCE DATA			
Anode current	I_a	12.5	mA
Transconductance	S	13.5	mA/V
Amplification factor	μ	65	

HEATING: Indirect by A.C. or D.C.; series supply

Heater current	I_f	300	mA
Heater voltage	V_f	3.8	V

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Noval



CAPACITANCES

Without external screen

Anode to grid	C_{ag}	1.2	pF

With external screen (inside diameter 22.2 mm)

Anode to grid	C_{ag}	1.7	pF
Grid to anode + cathode	$C_{g/kf}$	3.8	pF
Anode to heater + cathode	$C_{a/kf}$	0.055	pF

TYPICAL CHARACTERISTICS

Anode voltage	V_a	160	V [1]
Cathode resistor	R_k	100	Ω [1]
Anode current	I_a	12.5	mA
Transconductance	S	13.5	mA/V
Amplification factor	μ	65	
Equivalent noise resistance	R_{eq}	240	Ω
Noise figure at f = 850 MHz	F	10	dB
Anode voltage	V_a	0	V
Grid current, positive	I_g	0.3	μA
Grid voltage	$-V_g$	max. 1.3	V

Series resonance frequencies

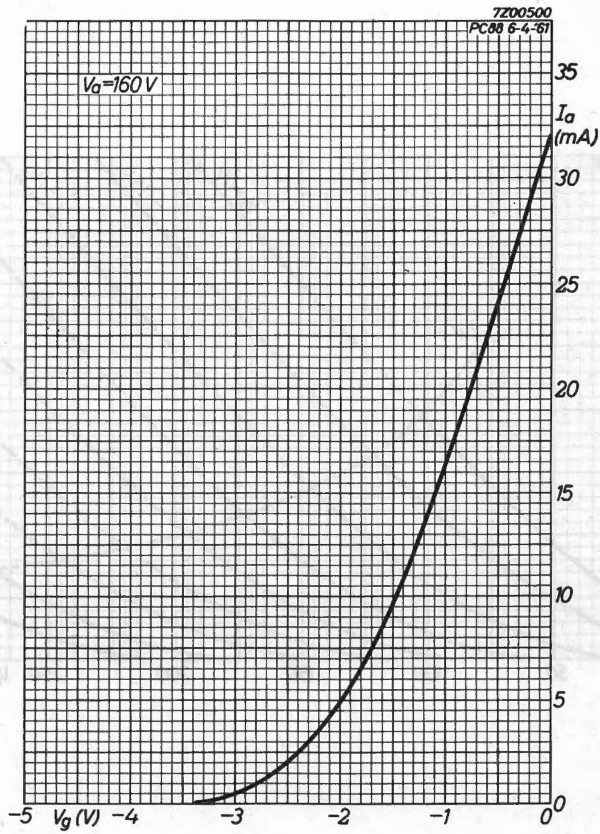
Measured between a point on the relevant tube pin close to the tube bottom and a point close to the relevant pin on a metal reference plane, placed against the tube bottom.
All the pins, except the relevant one, are connected to the reference plane with a negligible impedance.
The tube is screened by a metal screen with an inside diameter of 22.2 mm placed upon the metal reference plane.

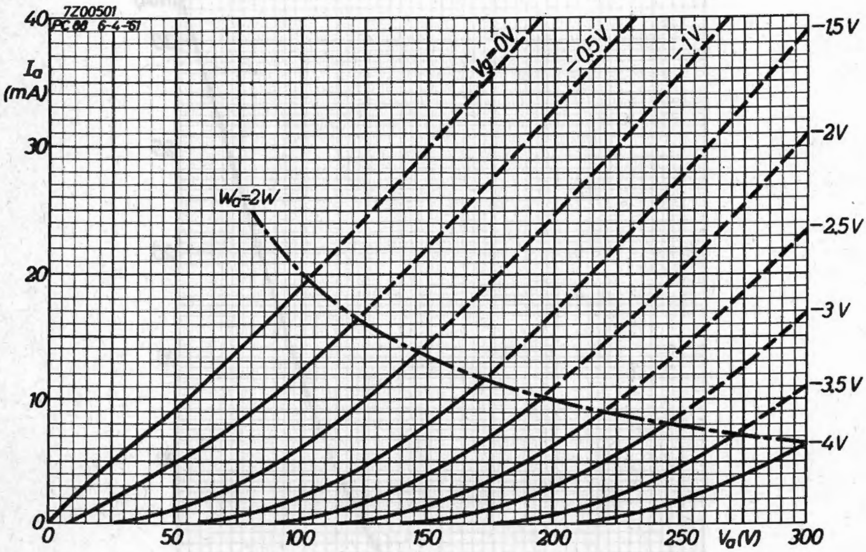
Heater voltage	V_f	0	V
Anode voltage	V_a	0	V
Anode resonance frequency	f_{oa}	1700	MHz
Cathode resonance frequency	f_{ok}	1000	MHz

LIMITING VALUES (Design centre rating system)

Anode voltage	V_{a_o}	max. 550	V
	V_a	max. 175	V
Anode dissipation	W_a	max. 2	W
Cathode current	I_k	max. 13	mA
Grid voltage	$-V_g$	max. 50	V
Grid resistor (R_k = 100 Ω)	R_g	max. 1	MΩ
Cathode to heater voltage	V_{kf}	max. 100	V [1]

[1]) To fulfil the modulation hum requirements, the A.C. component should not exceed 50 V_{RMS}.


7Z00500
PC88 6-4-'61
V_a=160 V
I_a (mA)
35
30
25
20
15
10
5
0
-5
V_g (V)
-4
-3
-2
-1
0


7Z00501
PC88 6-4-'61
40
I_a (mA)
30
20
10
0
0
50
100
150
200
250
V_a(V)
300
V_g=0V
-0.5V
-1V
-1.5 V
-2V
-2.5V
-3 V
-3.5 V
-4V
W_a=2W

H.F. TRIODE

Triode intended for use as H.F. amplifier, oscillator, mixer and in frame deflection circuits and line deflection circuits of TV receivers.

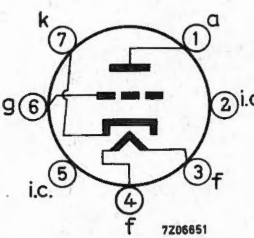
QUICK REFERENCE DATA			
Anode current	I_a	12	mA
Transconductance	S	7.2	mA/V
Amplification factor	μ	67	-

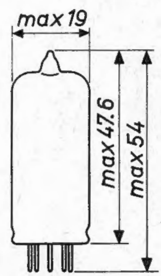
HEATING: Indirect by A.C. or D.C.; series supply

Heater current	I_f	300	mA
Heater voltage	V_f	3.1	V

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: 7 pin miniature





LIMITING VALUES (Design centre rating system)

Anode voltage	V_{a_o}	max.	550	V	
	V_a	max.	250	V	
Anode dissipation	W_a	max.	2.5	W	
Grid voltage	$-V_g$	max.	50	V	
Cathode current, average	I_k	max.	15	mA	
peak	I_{k_p}	max.	150	mA	[3]
Cathode to heater voltage (k pos.)	V_{kf}	max.	250	V	[1]
(k neg.)	V_{kf}	max.	250	V	
	(D.C. component max. 100 V)				
Grid resistor (automatic bias)	R_g	max.	1	MΩ	

OPERATING CONDITIONS AS BLOCKING OSCILLATOR

To take into account the tube tolerances, the decrease of the characteristics during life and the decrease of the emission at underheating, the circuit should be designed so that acceptable performance is obtained with a cathode peak current of 100 mA [2] (150 mA [3]). It is recommended to limit the peak current of new tubes by an automatic amplitude limiting circuit e.g. by the use of non by-passed grid and anode resistors.

1) During the warm-up period of the tubes V_{kf} (k pos.) (D.C. component) max. 315 V.

2) Pulse duration 4% of a cycle and max. 0.8 ms.

3) Pulse duration 1% of a cycle and max. 0.2 ms.

CAPACITANCES

Grounded cathode circuit

without external shield

Input	C_i	2.8	pF
Output	C_o	0.55	pF
Anode to grid	C_{ag}	1.8	pF

With external shield 19.5 mm diameter

Anode to cathode, heater and shield	$C_{a/kfs}$	1.4	pF
Cathode to grid, heater and shield	$C_{k/gfs}$	4.7	pF
Anode to grid, heater and shield	$C_{a/gfs}$	2.9	pF

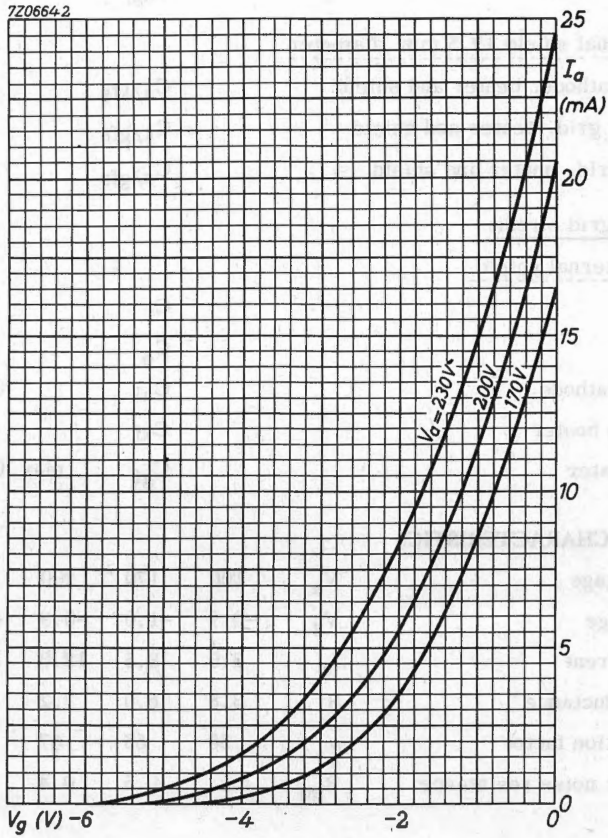
Grounded grid circuit

without external shield

Input	C_i	4.6	pF
Output	C_o	2.0	pF
Anode to cathode	C_{ak}	0.24	pF
Cathode to heater	C_{kf}	2.0	pF
Grid to heater	C_{gf}	max. 0.15	pF

TYPICAL CHARACTERISTICS

Anode voltage	V_a	100	170	200	230	V
Grid voltage	V_g	-0.9	-1.0	-0.9	-1.6	V
Anode current	I_a	3.0	8.5	12.0	10.5	mA
Transconductance	S	3.8	6.0	7.2	6.0	mA/V
Amplification factor	μ	58	65	67	62	-
Equivalent noise resistance	R_{eq}		0.5	0.4	0.5	kΩ


7Z06642
25
20
15
10
5
0
I_a (mA)
V_a=230V
200V
170V
V_g (V) −6
−4
−2
0

V.H.F. TRIODE

Triode intended for use as R.F. amplifier in V.H.F. television receivers.

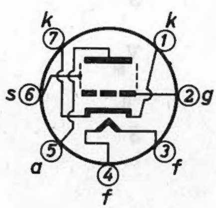
QUICK REFERENCE DATA			
Anode current	I_a	11	mA
Transconductance	S	13	mA/V
Amplification factor	μ	65	–

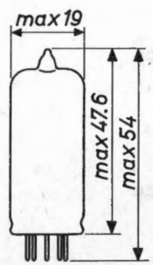
HEATING: Indirect by A.C. or D.C.; series supply

Heater current	I_f	300	mA
Heater voltage	V_f	4.5	V

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Miniature 7 pins





CAPACITANCES

		with external screen of 19.1 mm diam.	without external screen	
Anode to all	C_a	4.3	3.3	pF
Grid to all	C_g	5.0	5.0	pF
Anode to grid	C_{ag}	0.48	0.48	pF
Anode to cathode	C_{ak}	0.21	0.25	pF
Grid to cathode	C_{gk}	3.2	3.2	pF
Grid to heater	C_{gf}	max. 0.28	max. 0.28	pF
Cathode to heater	C_{kf}	2.5	2.5	pF

TYPICAL CHARACTERISTICS (pin 6 connected to cathode)

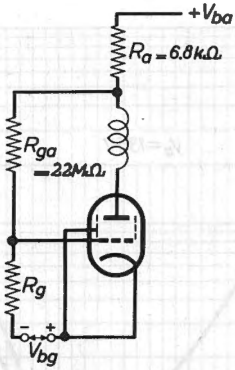
Anode voltage	V_a	135	V
Grid voltage	V_g	-1.0	V
Anode current	I_a	11	mA
Transconductance	S	13	mA/V
Amplification factor	μ	65	
Internal resistance	R_i	5	kΩ

Grid voltage	V_g	-3.1	V
Transconductance	S	0.65	mA/V

Grid voltage	V_g	-5.0	V
Anode current	I_a	0.1	mA
Transconductance	S	0.13	mA/V

OPERATING CHARACTERISTICS (pin 6 connected to cathode)

Anode supply voltage	V_{ba}	200[1]			200[2]			V
Anode resistor	R_a	5.6			5.6			kΩ
Cathode resistor	R_k	82			0			Ω
Grid resistor	R_g	0			1.0			MΩ
Grid supply voltage	V_{bg}	0	−4.4	−7.5	0	−4.2	−7.3	V
Anode current	I_a	12	–	–	13	–	–	mA
Transconductance	S	14	0.7	0.14	15.5	0.78	0.155	mA/V

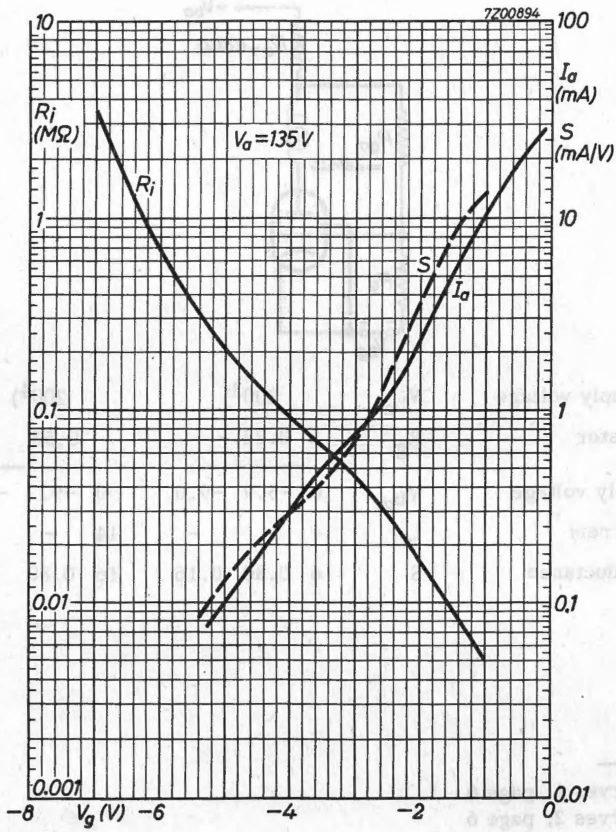


Anode supply voltage	V_{ba}	200[3]			200[4]			V
Grid resistor	R_g	0.22			0.56			MΩ
Grid supply voltage	V_{bg}	0	−5.9	−9.0	0	−9.2	−12.5	V
Anode current	I_a	14	–	–	14	–	–	mA
Transconductance	S	16	0.80	0.16	16	0.80	0.16	mA/V

1) See curves 1, page 6
2) See curves 2, page 6
3) See curves 3, page 6
4) See curves 4, page 6

LIMITING VALUES (Design centre rating system)

Anode voltage	V_{a_o}	max.	550 V
	V_a	max.	200 V
Anode dissipation	W_a	max.	2.2 W
Negative grid voltage	$-V_g$	max.	50 V
Grid circuit resistance	R_g	max.	1 MΩ
Cathode current	I_k	max.	20 mA
Cathode to heater voltage	V_{kf}	max.	100 V



V.H.F. TRIODE

Triode intended for use as R.F. amplifier in V.H.F. television receivers.

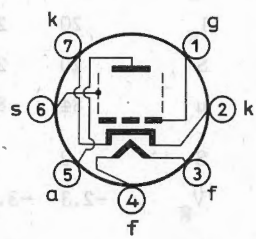
QUICK REFERENCE DATA				
Cathode current	I_k	max.	20	mA
Transconductance	S		20	mA/V
Amplification factor	μ		84	

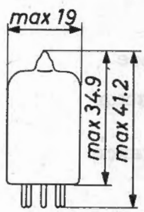
HEATING: Indirect by A.C. or D.C.; series supply

Heater current	I_f	300	mA
Heater voltage	V_f	3.9	V

DIMENSIONS AND CONNECTIONS — Dimensions in mm

Base: Miniature 7p





CAPACITANCES (with external shield, internal diameter 19.1 mm, connected to cathode)

Anode to all except grid	$C_{a(g)}$	3.0	pF
Grid to all except anode	$C_{g(a)}$	4.5	pF
Anode to grid	C_{ag}	0.365	pF
Anode to cathode	C_{ak}	0.08	pF
Grid to cathode	C_{gk}	3.3	pF
Grid to heater	C_{gf}	max. 0.07	pF
Cathode to heater	C_{kf}	2.3	pF

TYPICAL CHARACTERISTICS

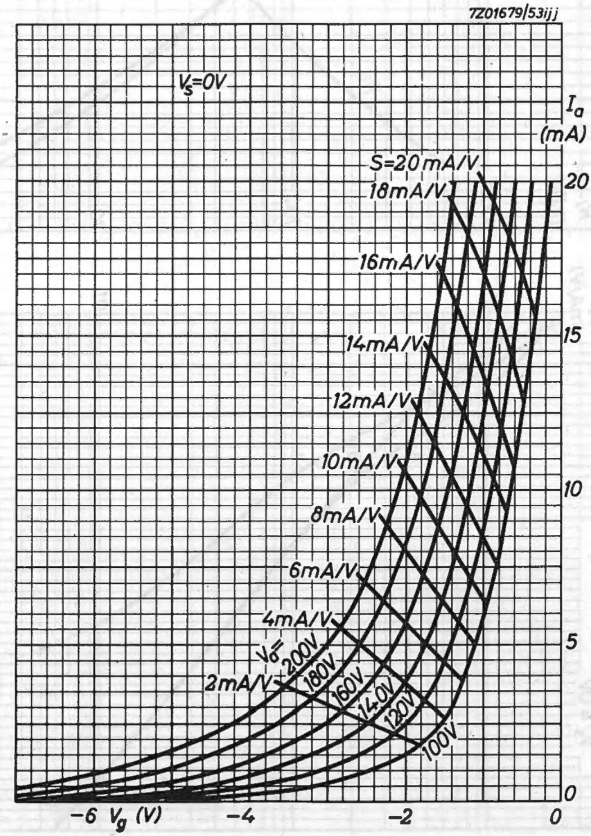
Anode voltage	V_a		135		V
Shield voltage	V_s		0		V
Grid voltage	V_g	-1	-2.8	-5.9	V
Anode current	I_a	11.5	–	–	mA
Transconductance	S	14.5	1.45	0.145	mA/V
Amplification factor	μ	76	–	–	

OPERATING CHARACTERISTICS

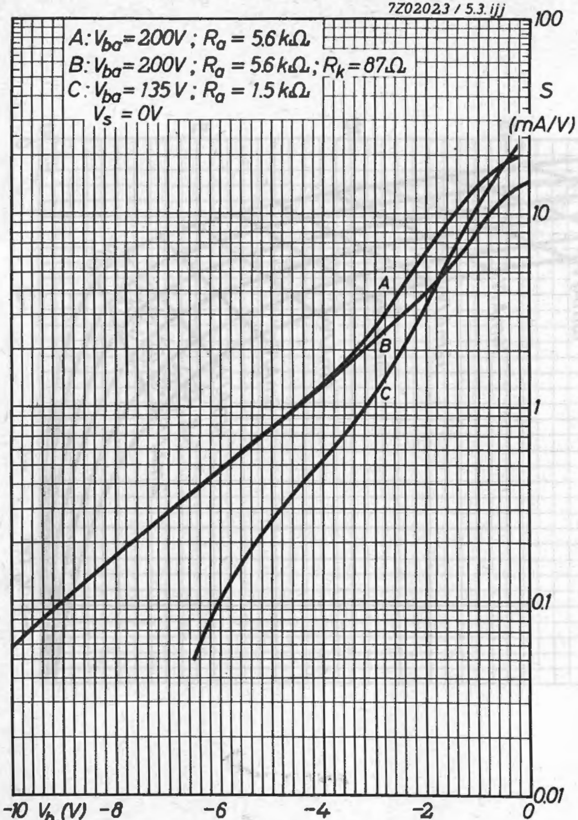
Anode supply voltage	V_{ba}	135	200	200	V
Anode resistor	R_a	1.5	5.6	5.6	kΩ
Shield voltage	V_s	0	0	0	V
Cathode resistor	R_k	0	0	87	Ω
Anode current	I_a	16.5	16.5	11.5	mA
Grid current	I_g	20	20	–	µA
Transconductance	S	20	20	14.5	mA/V
Amplification factor	μ	84	84	76	
Transconductance	S	2	2	1.45	mA/V
Grid voltage	V_g	-2.3	-3.2	-3.8	V
Transconductance	S	0.2	0.2	0.145	mA/V
Grid voltage	V_g	-5.3	-7.7	-8.3	V

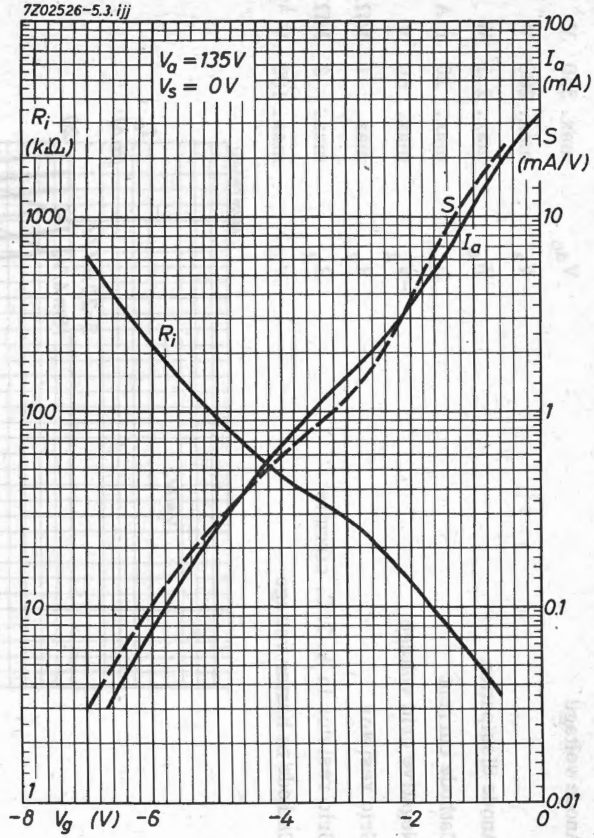
LIMITING VALUES (Design centre rating system)

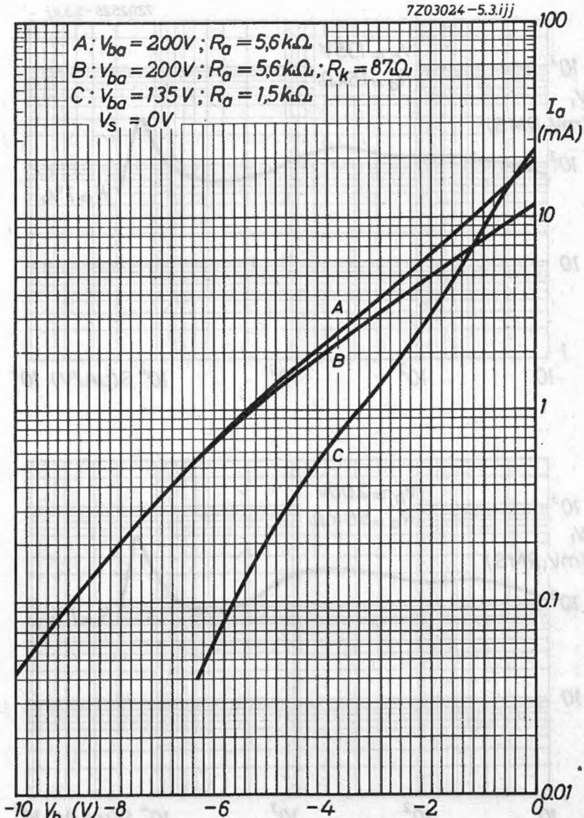
Anode voltage	V_{a_o}	max. 550	V
	V_a	max. 200	V
Anode dissipation	W_a	max. 2.2	W
Cathode current	I_k	max. 20	mA
Negative grid voltage	$-V_g$	max. 50	V
Grid resistor	R_g	max. 1	MΩ
Grid resistor in A.G.C. circuits	R_g	max. 3	MΩ
Cathode to heater voltage	V_{kf}	max. 100	V [1])

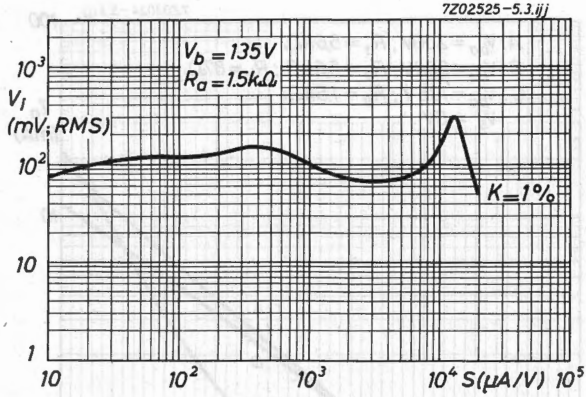


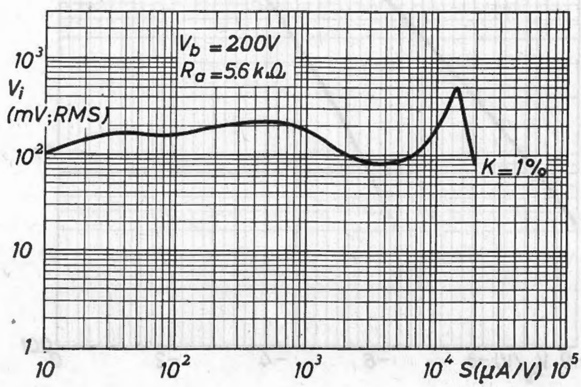
1) To fulfil the modulation hum requirements, V_{kf} should not exceed 55 V_{RMS}.


7Z02023 / 5.3.ijj
A: V_{ba} = 200V ; R_a = 5.6 kΩ
B: V_{ba} = 200V ; R_a = 5.6 kΩ ; R_k = 87 Ω
C: V_{ba} = 135 V ; R_a = 1.5 kΩ
V_s = 0V
S
(mA/V)
100
10
1
0.1
0.01
A
B
C
-10
V_{bg} (V)
-8
-6
-4
-2
0


7Z02526-5.3.ijj
V_a = 135V
V_s = 0V
R_i
(kΩ)
1000
100
10
1
I_a
(mA)
S
(mA/V)
100
10
1
0.1
0.01
S
I_a
R_i
-8
V_g (V)
-6
-4
-2
0


7Z03024-5.3.ijj
A: Vba = 200V ; Ra = 5,6 kΩ
B: Vba = 200V ; Ra = 5,6 kΩ ; Rk = 87Ω
C: Vba = 135 V ; Ra = 1,5 kΩ
Vs = 0V
Ia (mA)
100
10
1
0.1
0.01
A
B
C
-10
Vbg (V)
-8
-6
-4
-2
0


7Z02525-5.3.ijj
$V_b = 135V$
$R_a = 1.5k\Omega$
10^3
V_i
(mV; RMS)
10^2
10
1
K=1%
10
10^2
10^3
10^4
S(µA/V)
10^5


$V_b = 200V$
$R_a = 5.6k\Omega$
10^3
V_i
(mV; RMS)
10^2
10
1
K=1%
10
10^2
10^3
10^4
S(µA/V)
10^5

R.F. DOUBLE TRIODE

Double triode intended for various applications in television receivers.

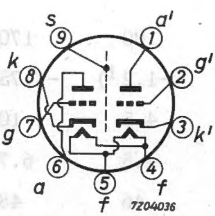
QUICK REFERENCE DATA			
Anode current	I_a	10	mA
Transconductance	S	6.7	mA/V
Amplification factor	μ	48	-

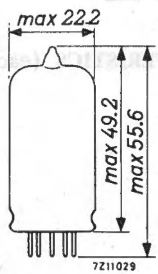
HEATING: Indirect by A.C. or D.C.; series supply

Heater current	I_f	300	mA
Heater voltage	V_f	9.0	V

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Noval





CAPACITANCES (each unit unless otherwise specified)

Anode to grid	C_{ag}		1.5	pF
Anode to cathode	C_{ak}		0.18	pF
Anode to cathode + heater + screen	$C_{a/kfs}$		1.2	pF
Grid to cathode + heater + screen	$C_{g/kfs}$		3.1	pF
Anode to cathode + heater + screen (measured with external screen of 22.5 mm diam.)	$C_{a/kfs}$		1.8	pF
Anode to anode other unit	$C_{aa'}$	max.	0.04	pF
Anode to anode other unit (measured with external screen of 22.5 mm diam.)	$C_{aa'}$	max.	0.008	pF
Grid to grid other unit	$C_{gg'}$	max.	0.003	pF
Anode to grid other unit	$C_{ag'}$	max.	0.008	pF
Anode to grid other unit	$C_{a'g}$	max.	0.008	pF
Anode to cathode other unit	$C_{ak'}$	max.	0.008	pF
Anode to cathode other unit	$C_{a'k}$	max.	0.008	pF
Grid to cathode other unit	$C_{gk'}$	max.	0.003	pF
Grid to cathode other unit	$C_{g'k}$	max.	0.003	pF

TYPICAL CHARACTERISTICS (each unit)

Anode voltage	V_a	100	170	200	V
Grid voltage	V_g	-1.2 [1]	-1.75	-2.4	V
Anode current	I_a	4.5	10	10	mA
Transconductance	S	4.8	6.7	6	mA/V
Amplification factor	μ	46	48	46	

REMARK

Microphony

This tube can be used without special precautions against microphony in A.F. applications in which the input voltage $V_i \geq 5$ mV for an output of 50 mW (or 50 mV for an output 5 W) provided the peak acceleration of the tube is not greater than indicated in the section "Microphony" of the "General Operational Recommendations".

[1]) In this case grid current may occur. If this is not permissible, a condition with a bias of −1.5 V should be chosen.

OPERATING CHARACTERISTICS (each unit)

As self-oscillating additive mixer

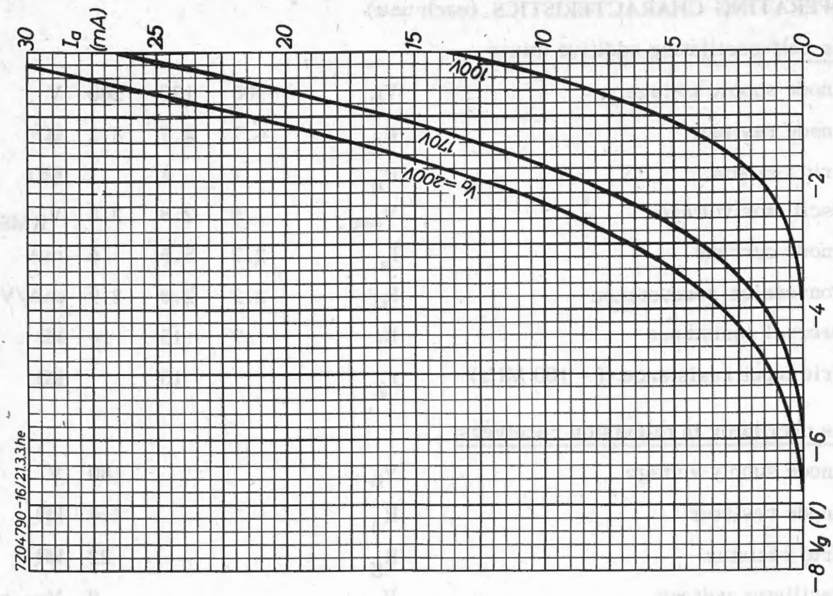
Anode supply voltage	V_b	100	170	200	V
Anode resistor	R_a	4.7	4.7	8.2	kΩ
Grid resistor	R_g	1	1	1	MΩ
Oscillator voltage	$V_{osc.}$	1.8	2.8	2.8	V_{RMS}
Anode current	I_a	2.7	5.5	6	mA
Conversion conductance	S_c	2.2	2.8	2.9	mA/V
Internal resistance	R_i	19	15	14	kΩ
Grid input resistance (f = 100 MHz)	r_g		15		kΩ

As oscillator in television receivers

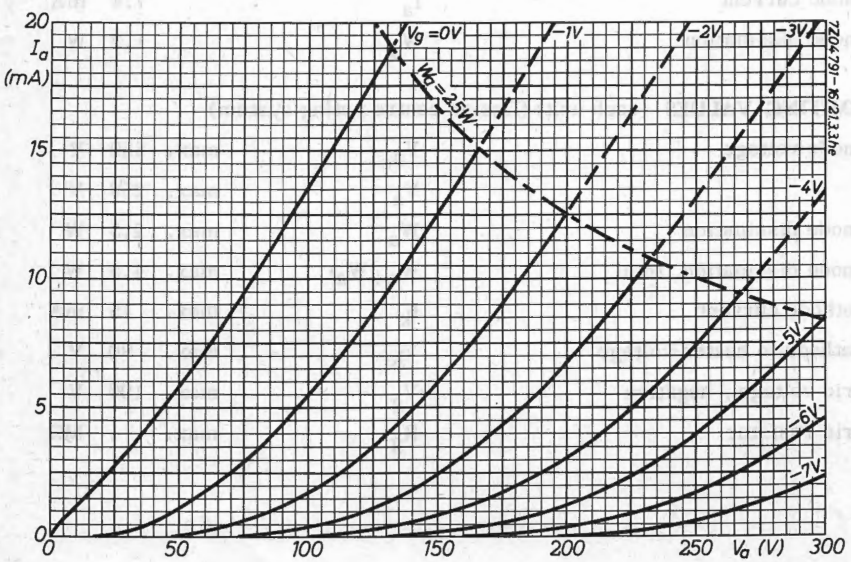
Anode supply voltage	V_b	180	V
Anode resistor	R_a	4.4	kΩ
Grid resistor	R_g	22	kΩ
Oscillator voltage	$V_{osc.}$	9	V_{RMS}
Anode current	I_a	7.4	mA
Anode dissipation	W_a	1.2	W

LIMITING VALUES (each unit) (Design centre rating system)

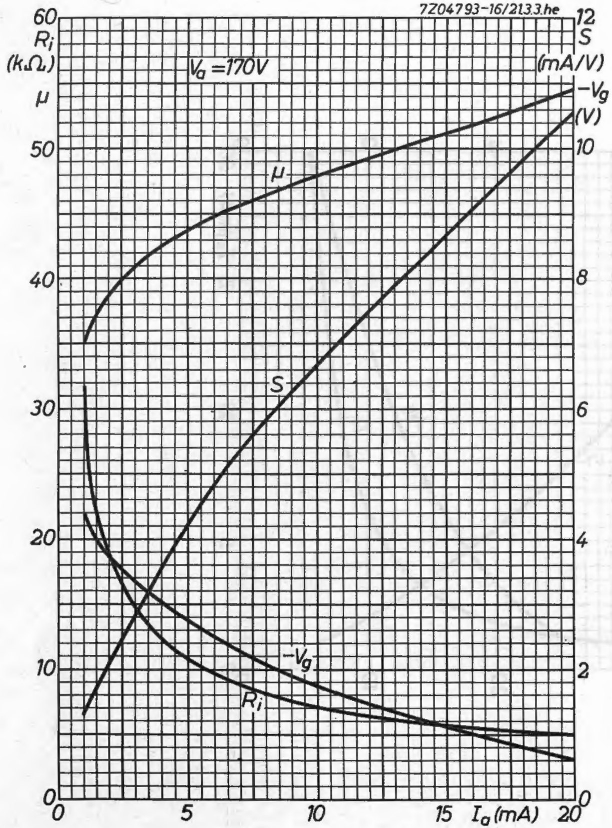
Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	250	V
Anode dissipation	W_a	max.	2.5	W
Anode dissipation, total	$W_a + W_{a'}$	max.	4.5	W
Cathode current	I_k	max.	15	mA
Cathode to heater voltage	V_{kf}	max.	90	V
Grid voltage, negative	$-V_g$	max.	100	V
Grid resistor	R_g	max.	1	MΩ

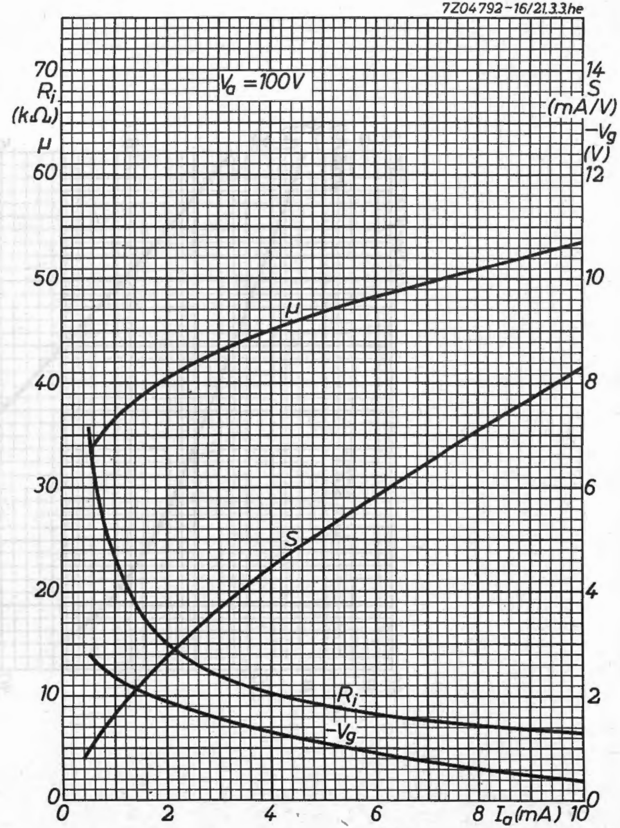


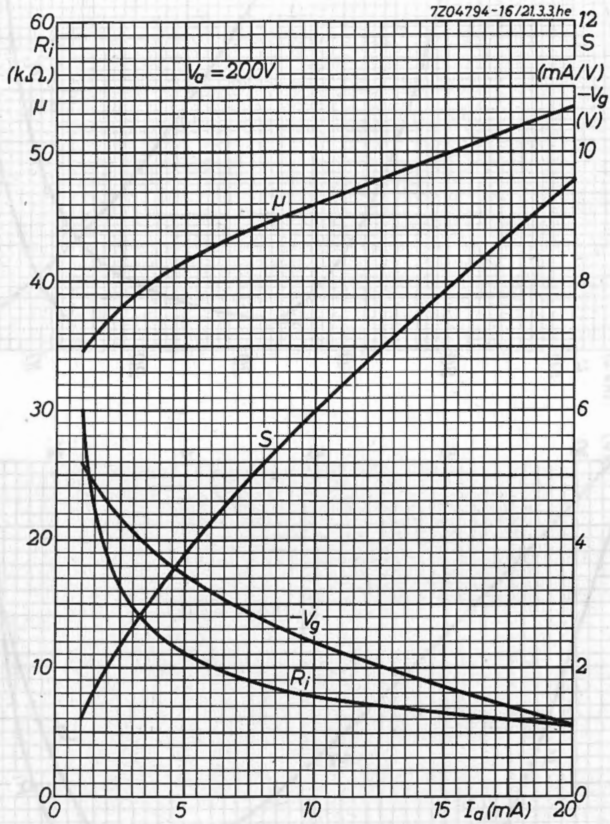
Ia (mA)
30
25
20
15
10
5
0
Va = 200V
170V
100V
0
−2
−4
−6
−8 Vg (V)
7Z04790-16/21.3.3.he

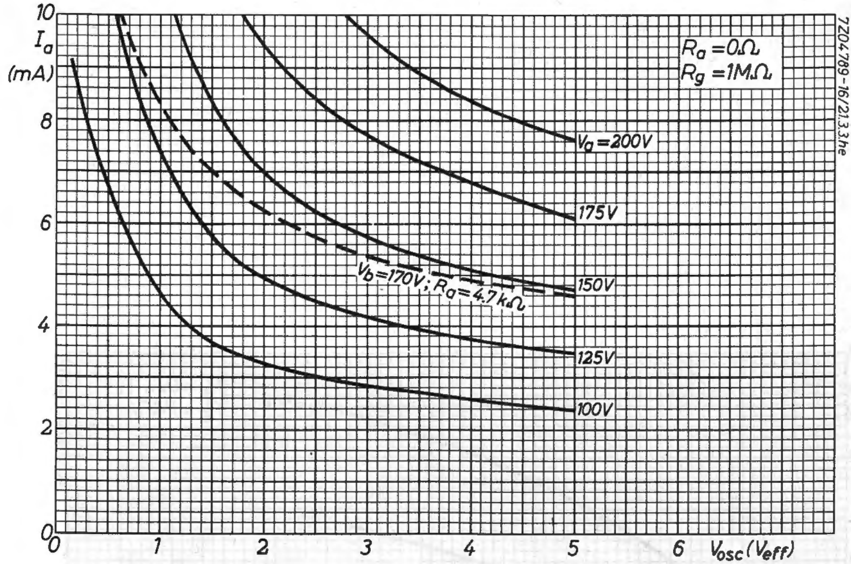


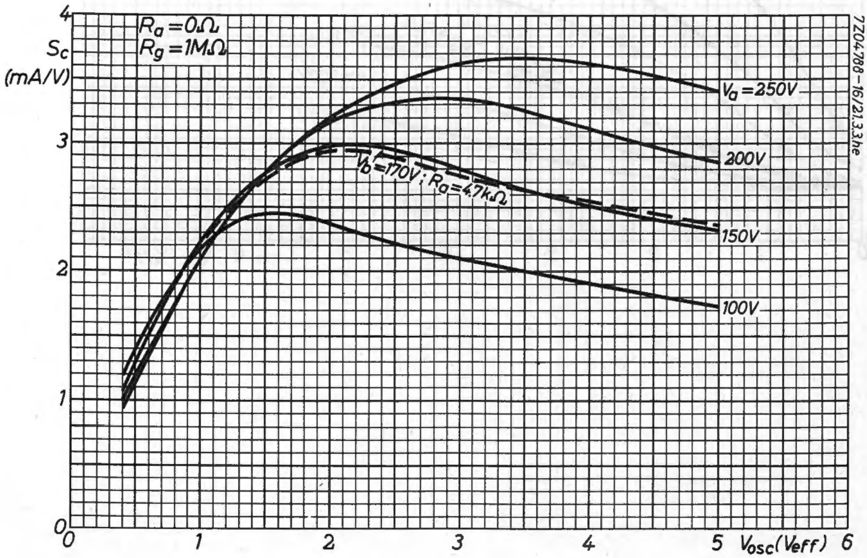
20
Ia (mA)
15
10
5
0
Vg = 0V
−1V
−2V
−3V
−4V
−5V
−6V
−7V
Wa = 2.5W
0
50
100
150
200
250
Va (V)
300
7Z04791-16/21.3.3.he

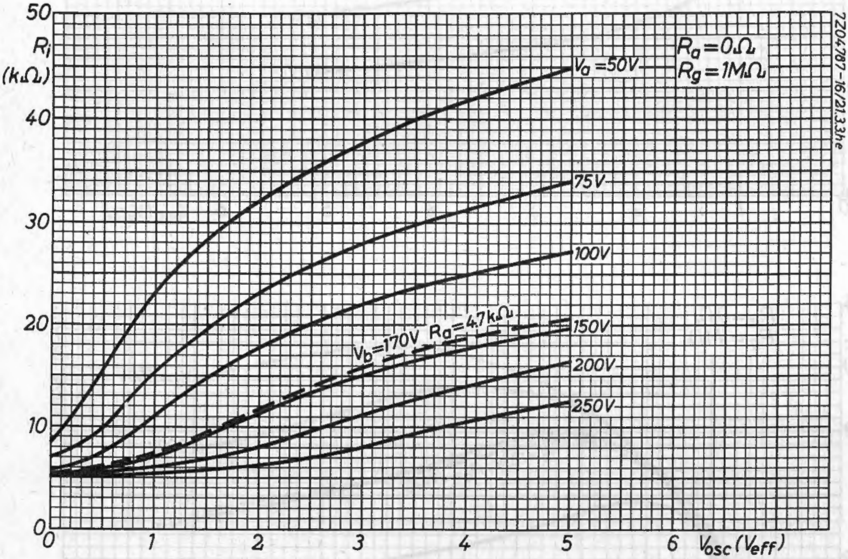

7Z04793-16/21.3.3.he
60
R_i
(kΩ)
μ
50
40
30
20
10
0
12
S
(mA/V)
$-V_g$
(V)
10
8
6
4
2
0
V_a =170V
μ
S
$-V_g$
R_i
0
5
10
15
I_a(mA)
20


7Z04792-16/21.3.3.he
70
R_i
(kΩ)
μ
60
50
40
30
20
10
0
14
S
(mA/V)
$-V_g$
(V)
12
10
8
6
4
2
0
V_a =100V
μ
S
R_i
$-V_g$
0
2
4
6
8
I_a(mA)
10


7Z04794-16/21.3.3.he
60
R_i
(kΩ)
μ
50
40
30
20
10
0
12
S
(mA/V)
$-V_g$
(V)
10
8
6
4
2
0
$V_a = 200V$
μ
S
$-V_g$
R_i
0
5
10
15
I_a (mA)
20


10
I_a
(mA)
8
6
4
2
0
0
1
2
3
4
5
6
$V_{osc}(V_{eff})$
$R_a = 0\Omega$
$R_g = 1M\Omega$
$V_a = 200V$
175V
150V
125V
100V
$V_b = 170V$; $R_a = 4.7k\Omega$
7Z04789-16/21.3.he


4
S_c
(mA/V)
3
2
1
0
0
1
2
3
4
5
$V_{osc}(V_{eff})$
6
$R_a = 0\Omega$
$R_g = 1M\Omega$
$V_a = 250V$
200V
150V
100V
$V_b = 170V$; $R_a = 4.7k\Omega$
7Z04788-16/21.3.he


50
R_i
$(k\Omega)$
40
30
20
10
0
0
1
2
3
4
5
6
V_{osc} (V_{eff})
$R_a = 0\Omega$
$R_g = 1M\Omega$
$V_a = 50V$
75V
100V
150V
200V
250V
$V_b = 170V$ $R_a = 4.7k\Omega$
7Z04787-16/21.3.3he

R.F. DOUBLE TRIODE

Double triode intended for use as cascode amplifier in television tuners.

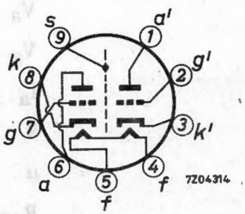
QUICK REFERENCE DATA (Each unit)			
Anode current	I_a	15	mA
Transconductance	S	12.5	mA/V
Amplification factor	μ	33	–

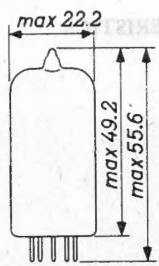
HEATING: Indirect by A.C. or D.C.; series supply

Heater current	I_f	300	mA
Heater voltage	V_f	7.6	V

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Noval





CAPACITANCES

		without external screen	with external screen	
Anode to grid	C_{ag}	1.4	1.4	pF
Grid to cathode + heater + screen	$C_{g/kfs}$	3.3	3.3	pF
Anode to cathode + heater + screen	$C_{a/kfs}$	1.8	2.5	pF
Grid to heater	C_{gf}	0.13	0.13	pF
Anode to grid	$C_{a'g'}$	1.4	1.4	pF
Cathode to grid + heater + screen	$C_{k'/g'fs}$	6	6	pF
Anode to grid + heater + screen	$C_{a'/g'fs}$	2.8	3.7	pF
Cathode to heater	$C_{k'f}$	2.7	2.7	pF
Anode to cathode	$C_{a'k'}$	0.18	0.16	pF
Anode to anode	$C_{aa'}$	max. 0.045	max. 0.015	pF
Grid to anode other unit	$C_{ga'}$	max. 0.005	max. 0.005	pF

REMARK

The unit a, g, k should be used as the grounded cathode input section and unit a', g', k' as the grounded grid output unit.

TYPICAL CHARACTERISTICS

Anode voltage	V_a	90	V
Grid voltage	V_g	-1.3	V
Anode current	I_a	15	mA
Transconductance	S	12.5	mA/V
Amplification factor	μ	33	-
Equivalent noise resistance	R_{eq}	300	Ω

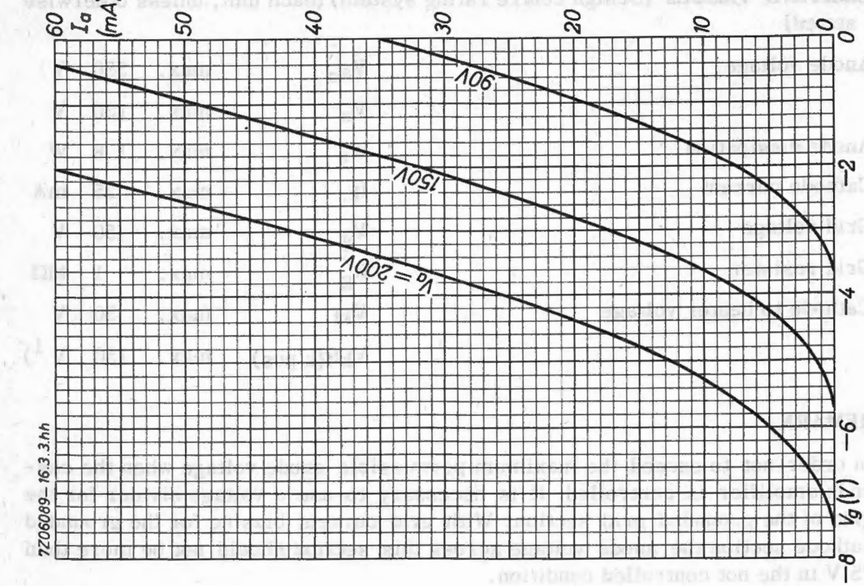
LIMITING VALUES (Design centre rating system) (each unit, unless otherwise stated)

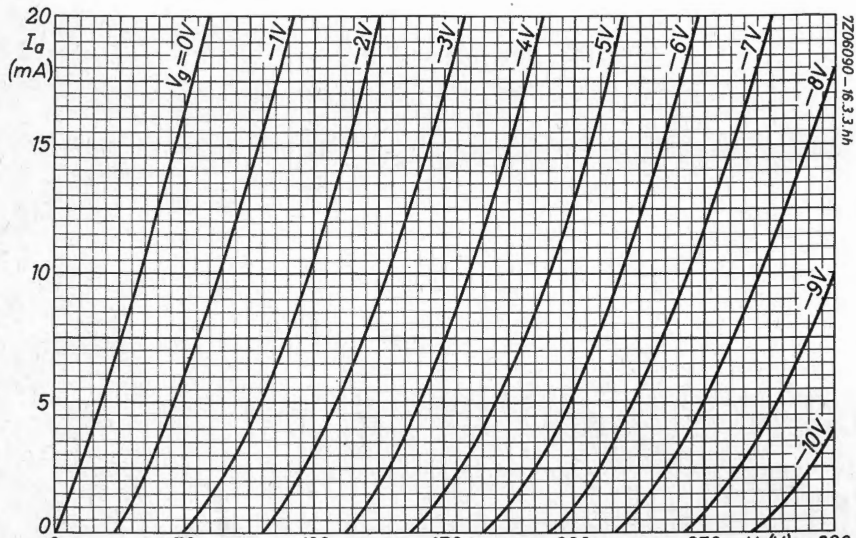
Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	130	V
Anode dissipation	W_a	max.	1.8	W
Cathode current	I_k	max.	25	mA
Grid voltage	$-V_g$	max.	50	V
Grid resistor	R_g	max.	1	MΩ
Cathode to heater voltage	V_{kf}	max.	50	V
	$V_{k'f(k'pos)}$	max.	150	V [1]

REMARK

In order not to exceed the maximum permissible anode voltage when the cascode amplifier is controlled, it is necessary to use a voltage divider for the grid of the grounded grid section. With grid current biasing for the grounded cathode section the anode voltage across this section should not be more than 75 V in the not controlled condition.

[1]) D.C. component max. 130 V.


I_a (mA)
60
50
40
30
20
10
0
0
−2
−4
−6
−8
V_g (V)
90V
150V
V_a = 200V
7Z06089 16.3.3.hh


20
I_a (mA)
15
10
5
0
0
50
100
150
200
250
V_a(V)
300
V_g=0V
−1V
−2V
−3V
−4V
−5V
−6V
−7V
−8V
−9V
−10V
7Z06090−16.3.3.hh

R.F. DOUBLE TRIODE

Double triode with variable transconductance intended for use as V.H.F. cascode amplifier in television receivers.

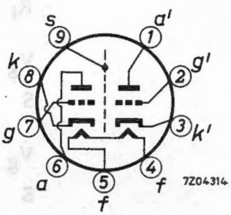
QUICK REFERENCE DATA			
Anode current	I_a	15	mA
Transconductance	S	12.5	mA/V
Amplification factor	μ	31	-

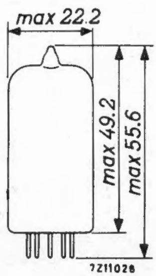
HEATING: Indirect by A.C. or D.C.; series supply

Heater current	I_f	300	mA
Heater voltage	V_f	7.6	V

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Noval





CAPACITANCES

		with external screen 22.2 mm diam.	without external screen	
Grid to cathode + heater + screen	$C_{g/kfs}$	3.5	3.5	pF
Anode to cathode + heater + screen	$C_{a/kfs}$	2.3	1.7	pF
Anode to grid	C_{ag}	1.9	1.9	pF
Grid to heater	C_{gf}	max. 0.28	max. 0.28	pF
Cathode to grid + heater + screen	$C_{k'/g'fs}$	6.0	6.0	pF
Anode to grid, heater + screen	$C_{a'/g'fs}$	4.0	3.4	pF
Anode to cathode	$C_{a'k'}$	0.17	0.18	pF
Cathode to heater	$C_{k'f}$	2.7	2.7	pF
Anode to grid	$C_{a'g'}$	1.9	1.9	pF
Anode to anode	$C_{aa'}$	max. 0.015	max. 0.045	pF
Grid to anode other unit	$C_{ga'}$	max. 0.004	max. 0.004	pF

TYPICAL CHARACTERISTICS (each unit)

Anode voltage	V_a	90	V
Grid voltage	V_g	-1.4	V
Anode current	I_a	15	mA
Transconductance	S	12.5	mA/V
Internal resistance	R_i	2.5	kΩ
Grid voltage	V_g	-5	V
Transconductance	S	0.625	mA/V
Grid voltage	V_g	-9	V
Transconductance	S	0.125	mA/V

LIMITING VALUES (Design centre rating system) (Each unit)

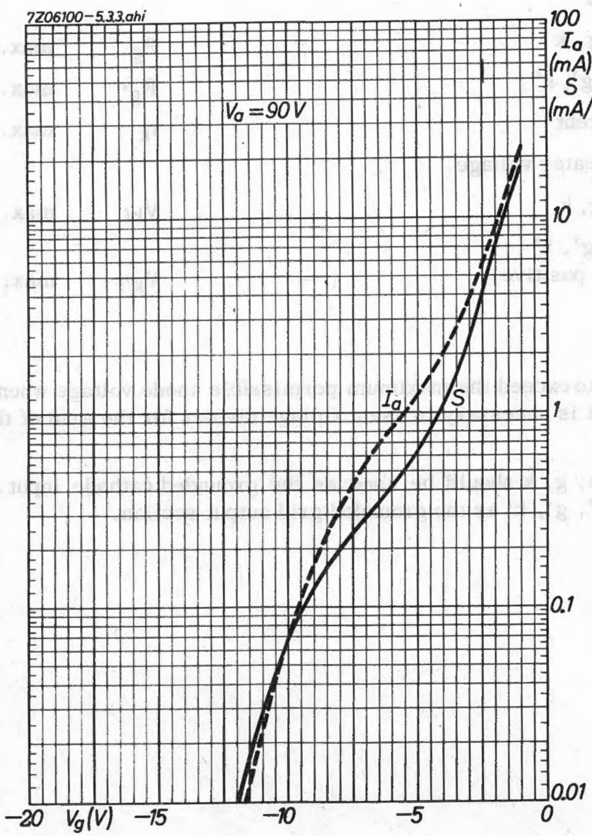
Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	130	V
Anode dissipation	W_a	max.	1.8	W
Grid voltage	$-V_g$	max.	50	V
Grid resistor				
unit a, g, k	R_g	max.	1	MΩ
unit a', g', k'	$R_{g'}$	max.	0.5	MΩ
Cathode current	I_k	max.	22	mA
Cathode to heater voltage				
unit a, g, k	V_{kf}	max.	80	V
unit a', g', k' (cathode positive)	$V_{k'f}$	max.	180	V [1]

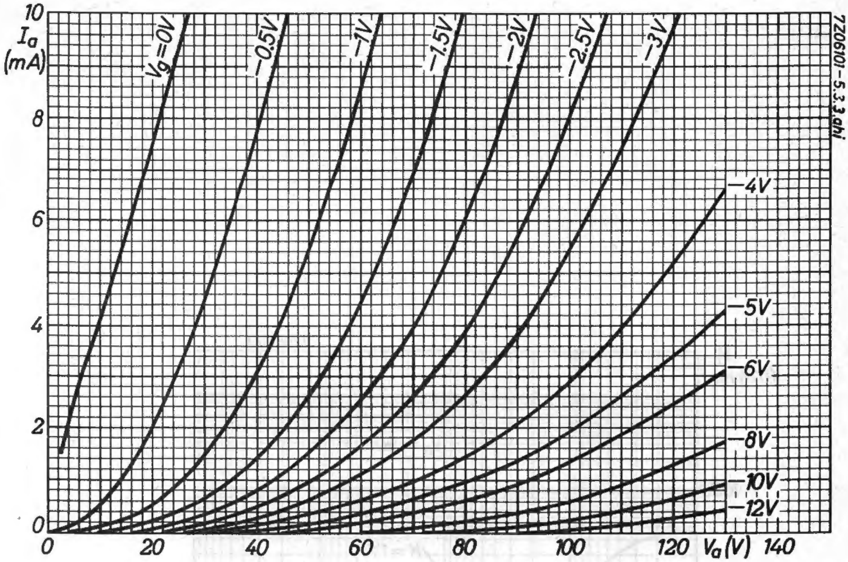
REMARKS

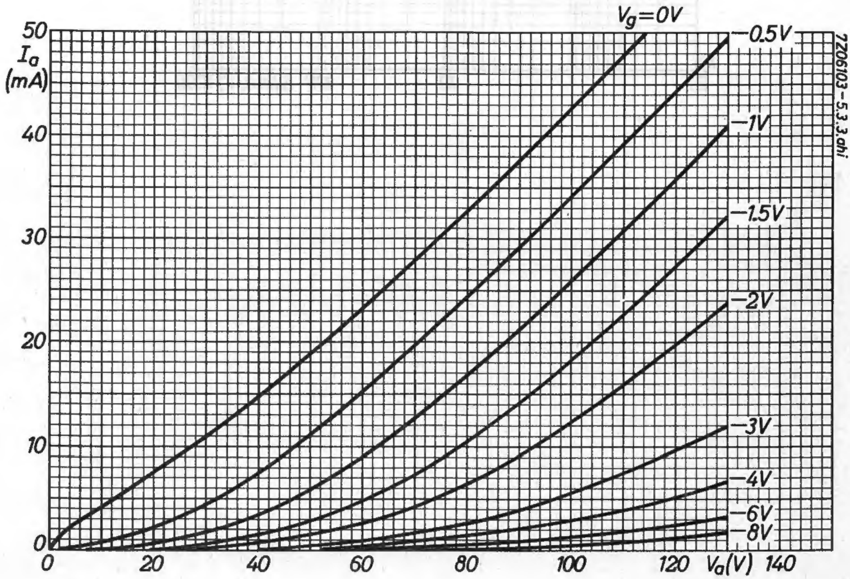
In order not to exceed the maximum permissible anode voltage when the tube is controlled, it is necessary to use a voltage divider for the grid of the grounded grid section.

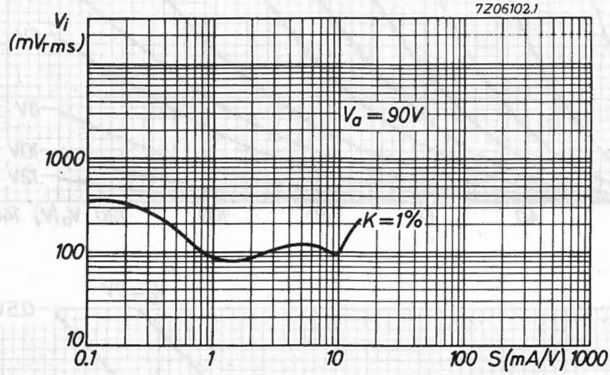
The system a, g, k should be used as the grounded cathode input section and the system a', g', k' as the grounded grid output section.

[1] D.C. component max. 130 V.


7Z06100-5.3.3.ahi
100
I_a
(mA)
S
(mA/V)
$V_a = 90\,V$
10
1
0.1
0.01
I_a
S
−20
V_g (V)
−15
−10
−5
0


10
I_a
(mA)
8
6
4
2
0
0
20
40
60
80
100
120
V_a(V)
140
V_g=0V
−0.5V
−1V
−1.5V
−2V
−2.5V
−3V
−4V
−5V
−6V
−8V
−10V
−12V
7Z06101-5.3.3ahi


50
I_a
(mA)
40
30
20
10
0
0
20
40
60
80
100
120
V_a(V)
140
V_g=0V
−0.5V
−1V
−1.5V
−2V
−3V
−4V
−6V
−8V
7Z06103-5.3.3ahi


7Z06102.1
V_i (mV$_{rms}$)
1000
100
10
0.1
1
10
100
S (mA/V)
1000
V_a = 90V
K = 1%

TRIODE PENTODE

Triode pentode with separate cathodes intended for use as frequency changer in television receivers.

QUICK REFERENCE DATA

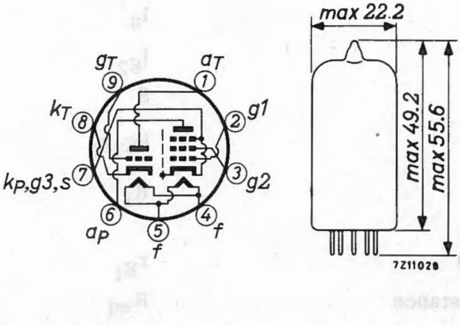
Triode section			
Anode current	I_a	14	mA
Transconductance	S	5	mA/V
Amplification factor	μ	20	–
Pentode section			
Anode current	I_a	10	mA
Transconductance	S	6.2	mA/V
Amplification factor	μ_{g2g1}	47	–

HEATING: Indirect by A.C. or D.C.; series supply

Heater current	I_f	300	mA
Heater voltage	V_f	9	V

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Noval



CAPACITANCES

Triode section (numbers denote pin number)			
Anode to all except grid (1-4+5+7+8)	$C_{a(g)}$	1.8	pF
Grid to all except anode (9-4+5+7+8)	$C_{g(a)}$	2.5	pF
Anode to grid	C_{ag}	1.5	pF
Pentode section			
Anode to all except grid No.1	$C_{a(g_1)}$	3.4	pF
Grid No.1 to all except anode	$C_{g_1(a)}$	5.2	pF
Anode to grid No.1	C_{ag_1}	max. 0.025	pF
Between triode and pentode sections			
Anode triode to grid No.1 pentode	$C_{a_T g_{1P}}$	max. 0.16	pF
Grid triode to anode pentode	$C_{g_T a_P}$	max. 0.02	pF
Anode triode to anode pentode	$C_{a_T a_P}$	max. 0.07	pF

TYPICAL CHARACTERISTICS

Triode section			
Anode voltage	V_a	100	V
Grid voltage	V_g	−2	V
Anode current	I_a	14	mA
Transconductance	S	5	mA/V
Amplification factor	μ	20	−
Pentode section			
Anode voltage	V_a	170	V
Grid No.2 voltage	V_{g_2}	170	V
Grid No.1 voltage	V_{g_1}	−2	V
Anode current	I_a	10	mA
Grid No.2 current	I_{g_2}	2.8	mA
Transconductance	S	6.2	mA/V
Amplification factor	$\mu_{g_2 g_1}$	47	−
Internal resistance	R_i	0.4	MΩ
Grid No.1 impedance (Frequency 50 MHz)	r_{g_1}	10	kΩ
Equivalent noise resistance	R_{eq}	1.5	kΩ

OPERATING CONDITIONS

As frequency changer (It is recommended to employ the triode in a Colpitts type of circuit and not in a Hartley type)

Anode voltage	V_a	170	170	V
Grid No.2 voltage	V_{g_2}	170	170	V
Grid No.1 resistor	R_{g_1}	0.1	0.1	MΩ
Cathode resistor	R_k	330	820	Ω
Oscillator voltage	V_{osc}	3.5	3.5	V_{RMS}
Anode current	I_a	6.5	5.2	mA
Grid No.2 current	I_{g_2}	2.0	1.5	mA
Grid No.1 current	I_{g_1}	20	0	μA
Conversion conductance	S_c	2.2	2.1	mA/V
Internal resistance	R_i	800	870	kΩ

Frame output application (Optimum peak cathode current of the triode section)

To allow for tube spread, for deterioration during life and for emission drop at underheating the equipment should be so designed that it still operates satisfactorily with a peak cathode current of 100 mA (max. pulse duration 4 % of a cycle, but maximum 0.8 ms). The amplitude of the peak current occurring with new tubes should be limited automatically to this max. value of 100 mA. (E.g. by non-bypassed resistances in the grid lead.)

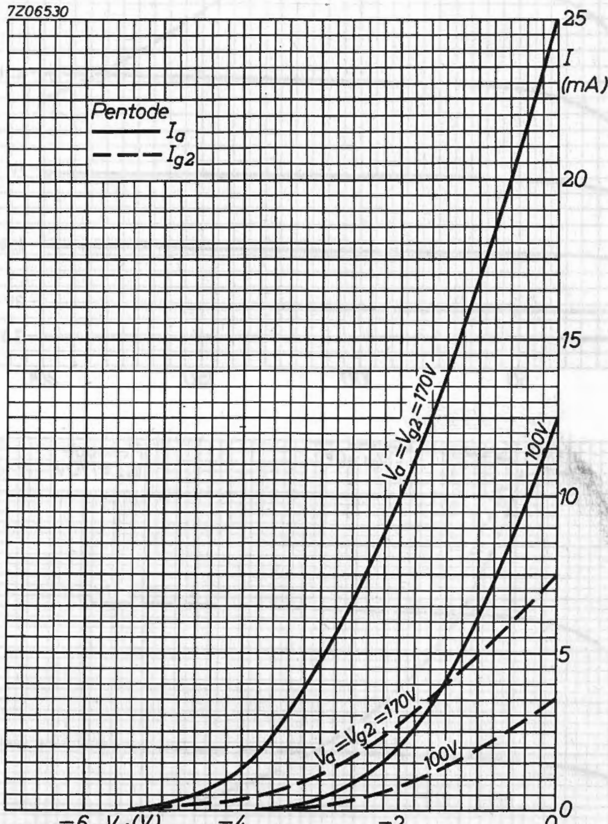
LIMITING VALUES (Design centre rating system)

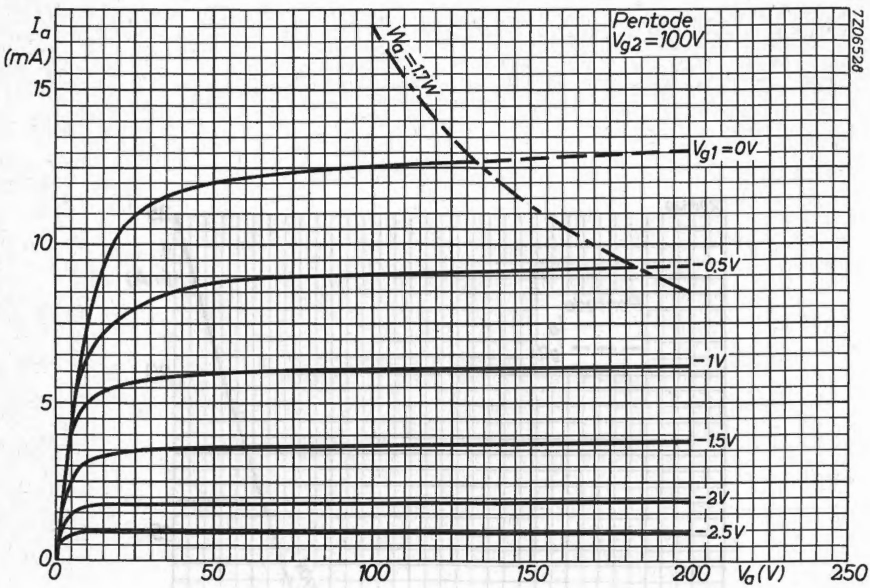
Triode section

Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	250	V
Anode dissipation	W_a	max.	1.5	W
Cathode current				
average	I_k	max.	14	mA
peak	I_{k_p}	see under "frame output applications"		
Grid resistor	R_g	max.	0.5	MΩ
Cathode to heater voltage				
cathode neg	V_{kf}	max.	100	V
cathode pos	V_{kf}	max.	200	V
	D.C. component	max.	120	V

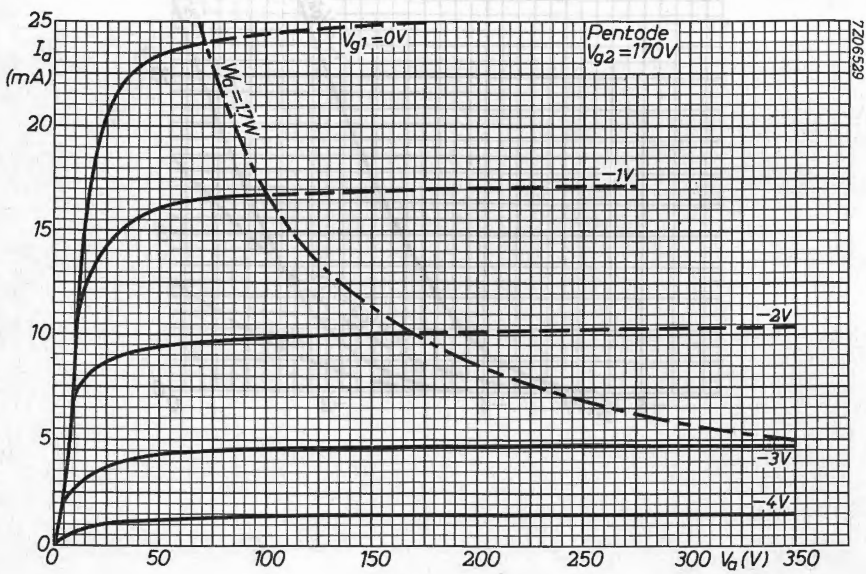
Pentode section

Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	250	V
Grid No.2 voltage	V_{g2_o}	max.	550	V
I_k = 14 mA	V_{g2}	max.	175	V
I_k = max. 10 mA	V_{g2}	max.	200	V
Anode dissipation	W_a	max.	1.7	W
Grid No.2 dissipation				
at W_a = min. 1.2 W	W_{g2}	max.	0.5	W
at W_a = max. 1.2 W	W_{g2}	max.	0.75	W
Cathode current	I_k	max.	14	mA
Grid resistor				
fixed bias	R_{g1}	max.	0.5	MΩ
automatic bias	R_{g1}	max.	1	MΩ
Cathode to heater voltage				
cathode neg	V_{kf}	max.	100	V
cathode pos	V_{kf}	max.	200	V
	D.C. component	max.	120	V

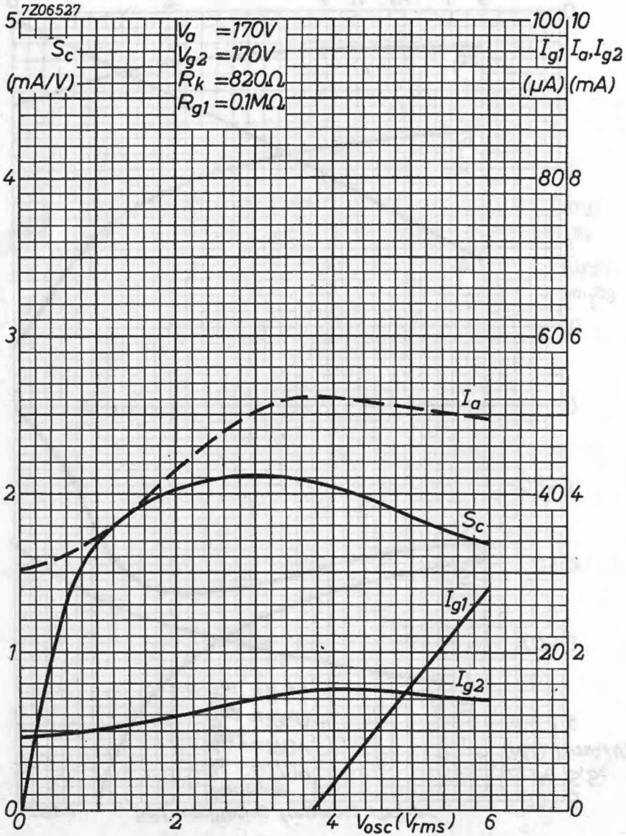

7Z06530
Pentode
I_a
I_{g2}
25
I
(mA)
20
15
10
5
0
$V_a = V_{g2} = 170V$
100V
$V_a = V_{g2} = 170V$
100V
−6
V_{g1}(V)
−4
−2
0

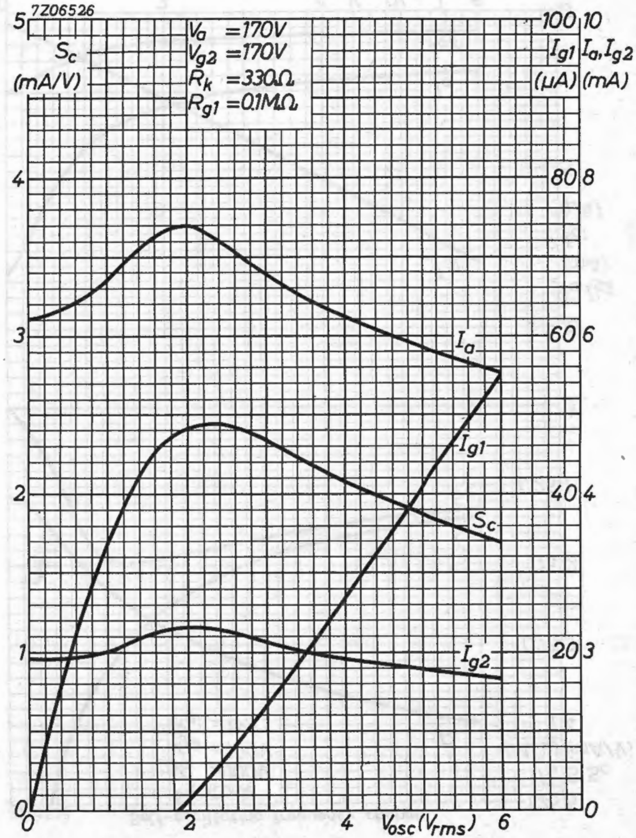


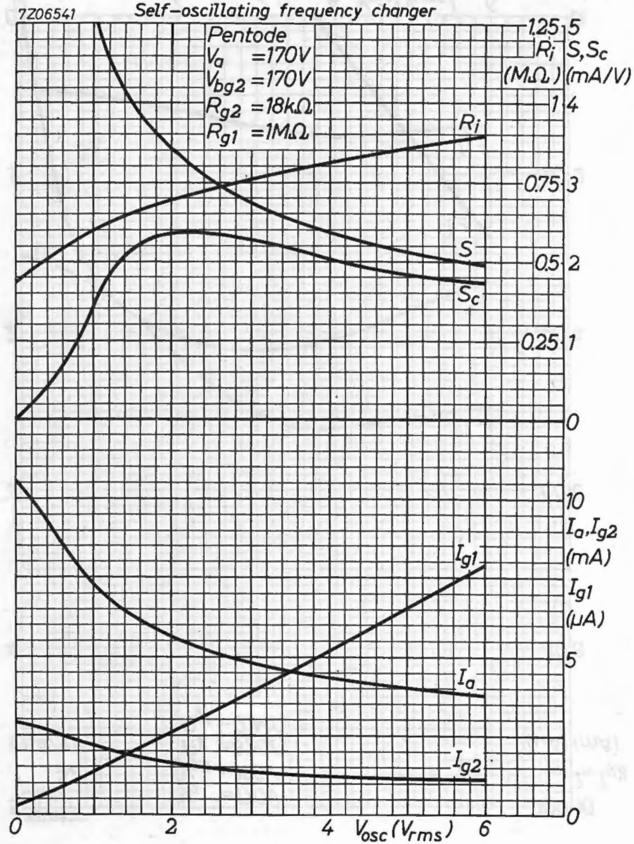
7Z06528
Pentode
V_{g2}=100V
I_a
(mA)
15
10
5
0
W_a=1.7W
V_{g1}=0V
−0.5V
−1V
−1.5V
−2V
−2.5V
0
50
100
150
200
V_a(V)
250

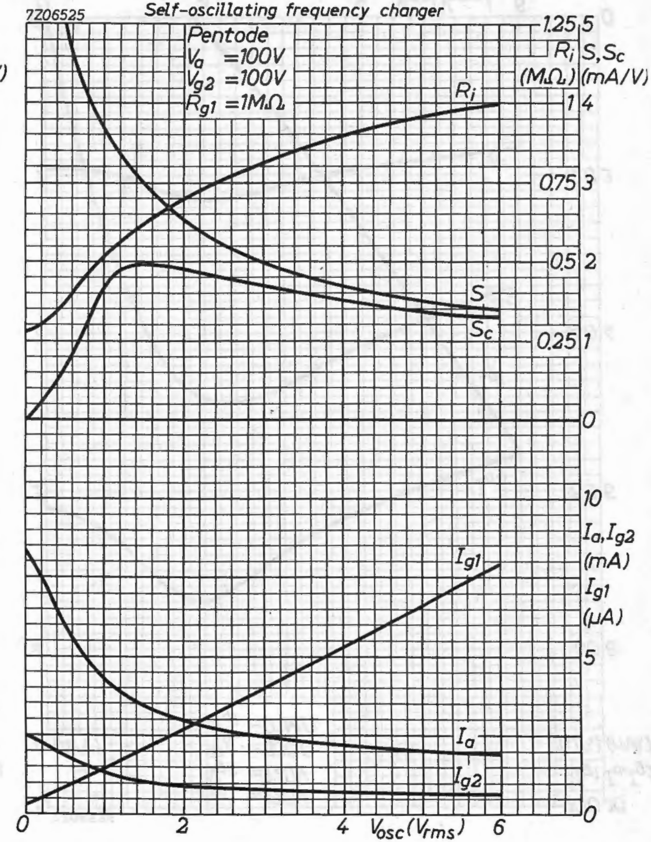


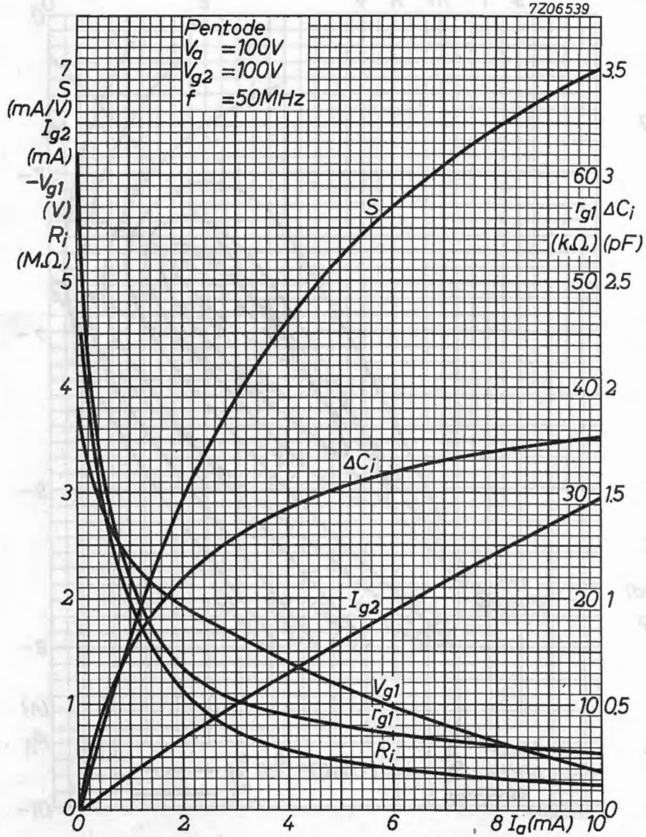
7Z06529
Pentode
V_{g2}=170V
25
I_a
(mA)
20
15
10
5
0
V_{g1}=0V
W_a=1.7W
−1V
−2V
−3V
−4V
0
50
100
150
200
250
300
V_a(V)
350

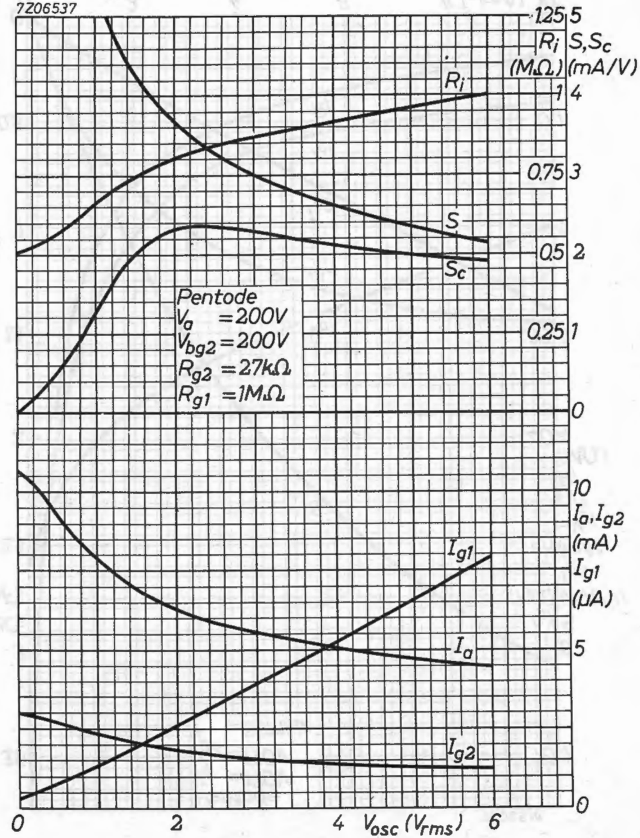

7Z06527
V_a = 170V
V_{g2} = 170V
R_k = 820Ω
R_{g1} = 0.1MΩ
S_c (mA/V)
I_{g1} (μA)
I_a, I_{g2} (mA)
I_a
S_c
I_{g1}
I_{g2}
V_{osc} (V_{rms})

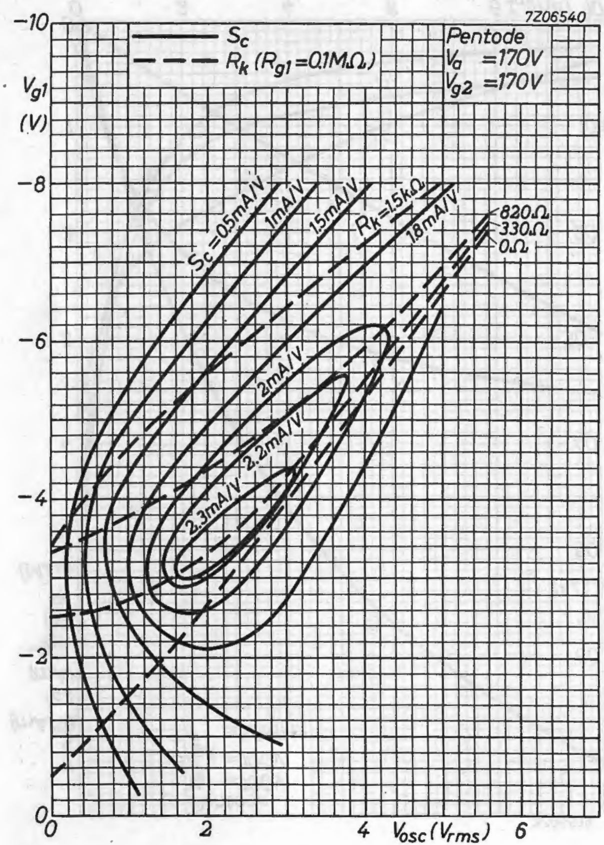

7Z06526
V_a = 170V
V_{g2} = 170V
R_k = 330Ω
R_{g1} = 0.1MΩ
S_c (mA/V)
I_{g1} (μA)
I_a, I_{g2} (mA)
I_a
I_{g1}
S_c
I_{g2}
V_{osc} (V_{rms})

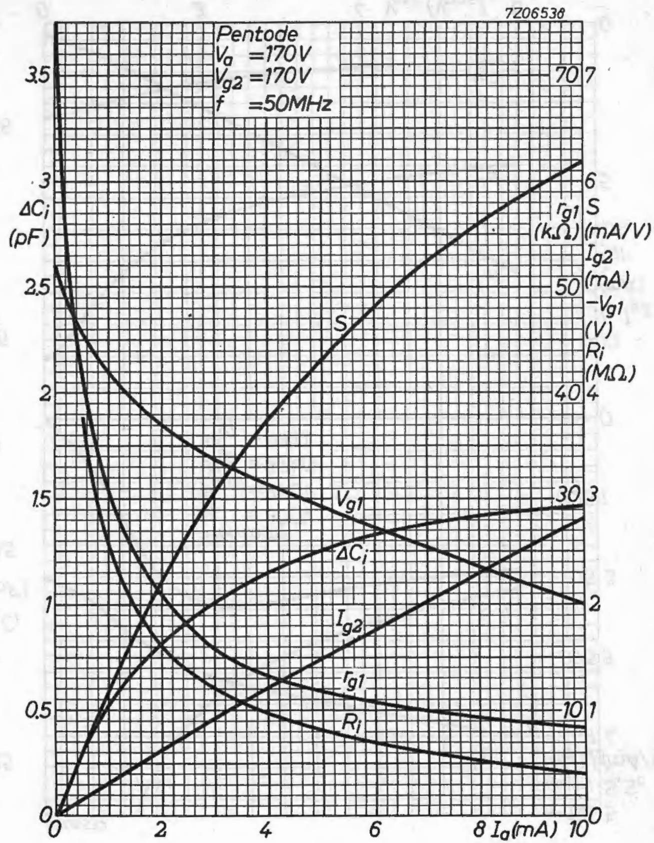

7Z06541
Self-oscillating frequency changer
Pentode
V_a = 170V
V_{bg2} = 170V
R_{g2} = 18kΩ
R_{g1} = 1MΩ
R_i (MΩ)
S, S_c (mA/V)
1.25 5
1 4
0.75 3
0.5 2
0.25 1
0
R_i
S
S_c
10
I_a, I_{g2} (mA)
I_{g1} (μA)
5
0
I_{g1}
I_a
I_{g2}
0
2
4
6
V_{osc} (V_{rms})

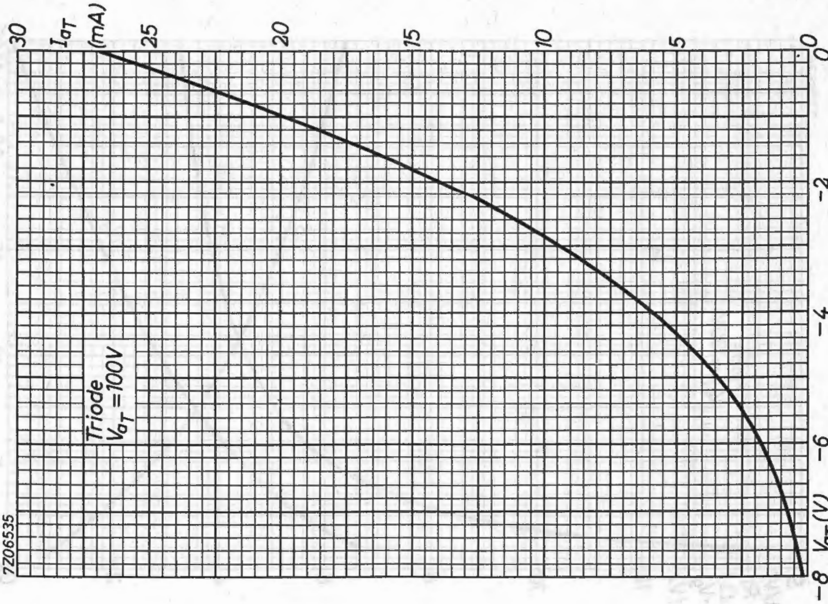

7Z06525
Self-oscillating frequency changer
Pentode
V_a = 100V
V_{g2} = 100V
R_{g1} = 1MΩ
R_i (MΩ)
S, S_c (mA/V)
1.25 5
1 4
0.75 3
0.5 2
0.25 1
0
R_i
S
S_c
10
I_a, I_{g2} (mA)
I_{g1} (μA)
5
0
I_{g1}
I_a
I_{g2}
0
2
4
6
V_{osc} (V_{rms})

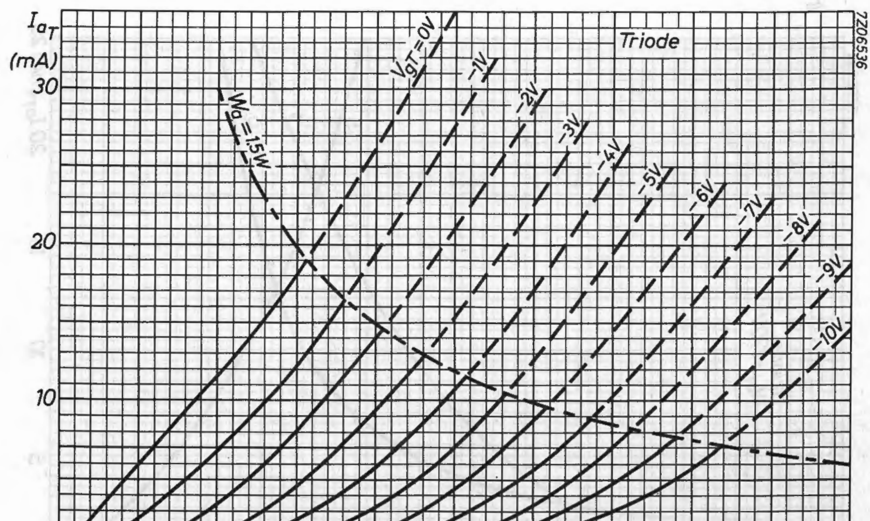

7Z06539
Pentode
Va =100V
Vg2 =100V
f =50MHz
S (mA/V)
Ig2 (mA)
−Vg1 (V)
Ri (MΩ)
rg1 (kΩ)
ΔCi (pF)
S
ΔCi
Ig2
Vg1
rg1
Ri
Ia(mA)

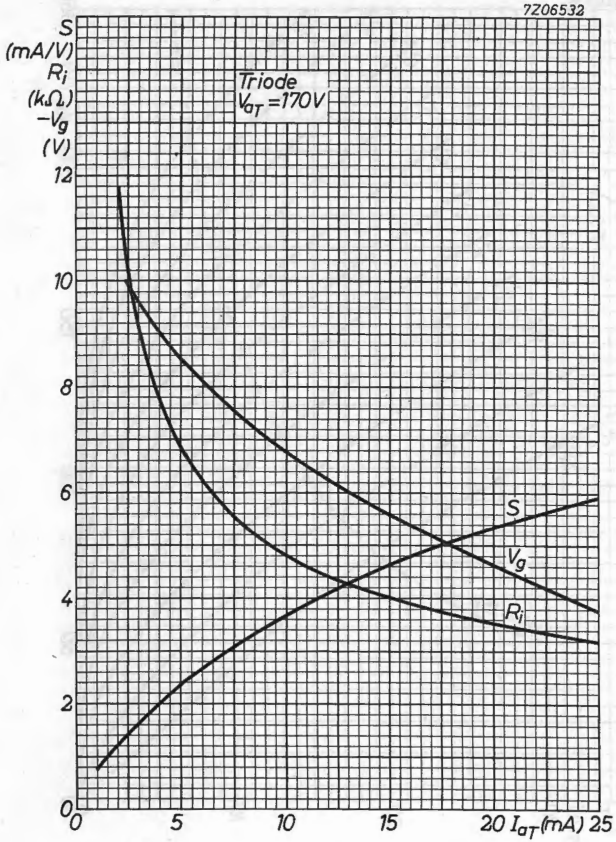

7Z06537
Ri (MΩ)
S,Sc (mA/V)
Ri
S
Sc
Pentode
Va =200V
Vbg2 =200V
Rg2 =27kΩ
Rg1 =1MΩ
Ia,Ig2 (mA)
Ig1 (µA)
Ig1
Ia
Ig2
Vosc (Vrms)

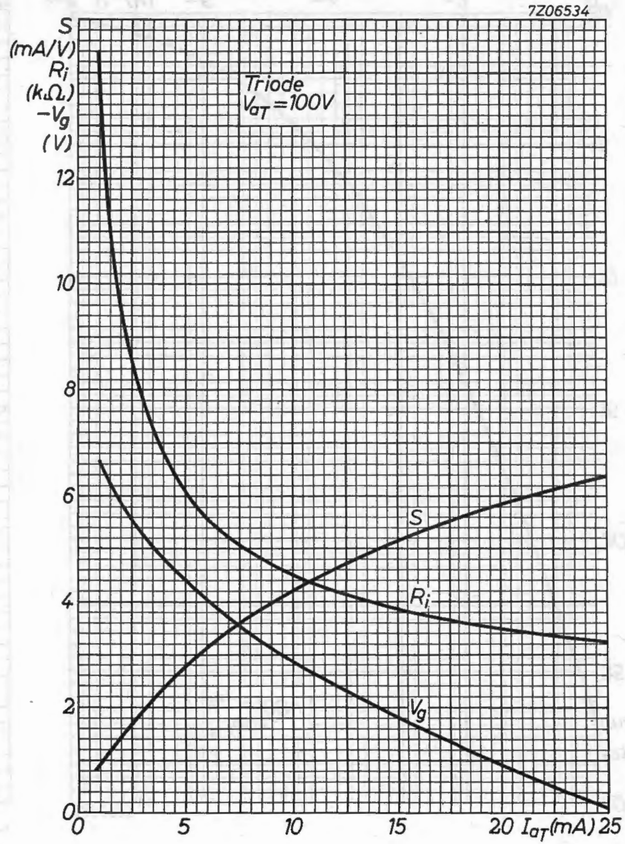

7Z06540
S_c
R_k (R_{g1}=0.1MΩ)
Pentode
V_a =170V
V_{g2} =170V
V_{g1} (V)
S_c=0.5mA/V
1mA/V
1.5mA/V
R_k=1.5kΩ
1.8mA/V
820Ω
330Ω
0Ω
2mA/V
2.2mA/V
2.3mA/V
V_{osc} (V_{rms})
-10
-8
-6
-4
-2
0
0
2
4
6

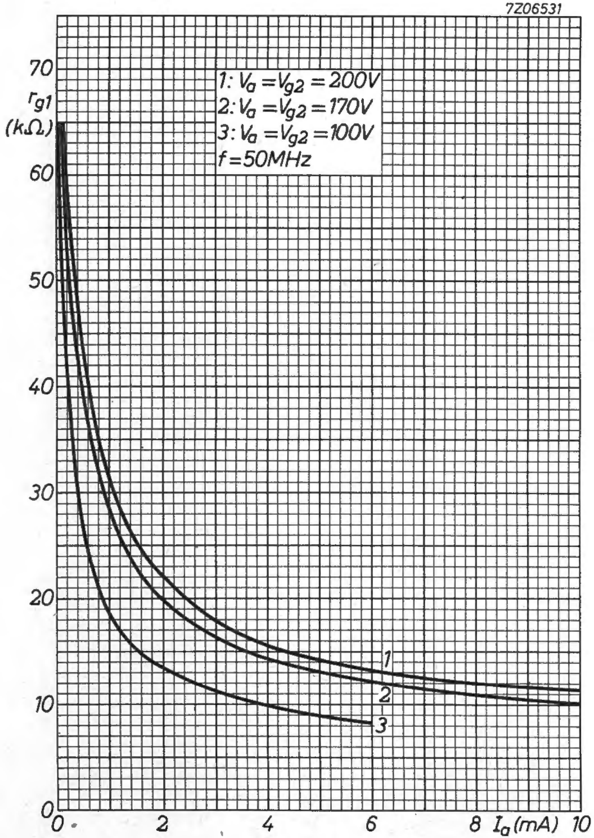

7Z06538
Pentode
V_a =170V
V_{g2} =170V
f =50MHz
ΔC_i (pF)
r_{g1} (kΩ)
S (mA/V)
I_{g2} (mA)
$-V_{g1}$ (V)
R_i (MΩ)
S
V_{g1}
$ΔC_i$
I_{g2}
r_{g1}
R_i
I_a(mA)
0
0.5
1
1.5
2
2.5
3
3.5
0
2
4
6
8
10
10
30
40
50
70
1
2
3
4
6
7

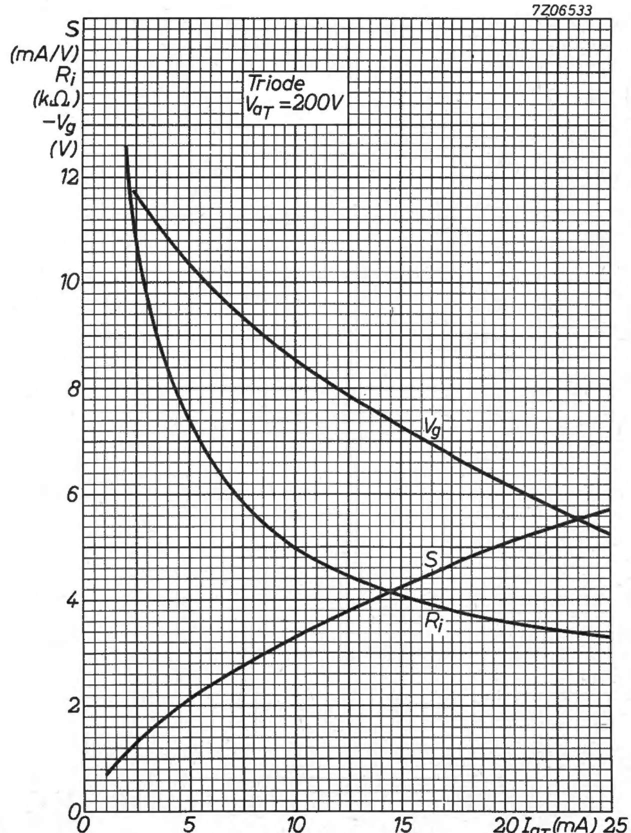

Triode
V_{aT} = 100V
I_{aT} (mA)
30
25
20
15
10
5
0
0
-2
-4
-6
-8
V_{gT} (V)
7Z06535


I_{aT} (mA)
Triode
7Z06536
W_a = 1.5W
V_{gT} = 0V
-1V
-2V
-3V
-4V
-5V
-6V
-7V
-8V
-9V
-10V
30
20
10
0
0
50
100
150
200
V_{aT} (V)
250


7Z06532
S
(mA/V)
R_i
(kΩ)
$-V_g$
(V)
Triode
V_{aT} = 170V
S
V_g
R_i
I_{aT} (mA)
0
2
4
6
8
10
12
5
15
20
25


7Z06534
S
(mA/V)
R_i
(kΩ)
$-V_g$
(V)
Triode
V_{aT} = 100V
S
R_i
V_g
I_{aT} (mA)
0
2
4
6
8
10
12
5
15
20
25


7Z06531
r_{g1} (kΩ)
1: $V_a = V_{g2} = 200V$
2: $V_a = V_{g2} = 170V$
3: $V_a = V_{g2} = 100V$
f = 50MHz
I_a (mA)
1
2
3


7Z06533
S (mA/V)
R_i (kΩ)
$-V_g$ (V)
Triode
$V_{aT} = 200V$
V_g
S
R_i
I_{aT} (mA)

TRIODE-PENTODE

Triode pentode intended for use as frequency changer in V.H.F. television tuners.

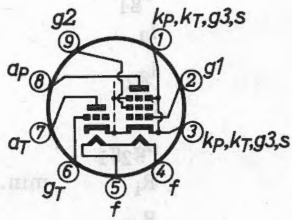
QUICK REFERENCE DATA			
Triode section			
Anode current	I_a	14	mA
Transconductance	S	5.7	mA/V
Amplification factor	μ	17	-
Pentode section			
Anode current	I_a	10	mA
Transconductance	S	12	mA/V
Amplification factor	$\mu_{g_2g_1}$	70	-

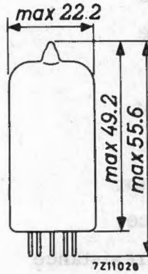
HEATING: Indirect by A.C. or D.C.; series supply

Heater current	I_f	300	mA
Heater voltage	V_f	8	V

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Noval





CAPACITANCES

Triode section

Anode to all except grid	$C_{a(g)}$	1.1	pF
Grid to all except anode	$C_{g(a)}$	2.4	pF
Anode to grid	C_{ag}	2.0	pF

Pentode section

Anode to all except grid No. 1	$C_{a(g_1)}$	3.5	pF
Grid No. 1 to all except anode	$C_{g_1(a)}$	5.8	pF
Anode to grid No. 1	C_{ag_1}	0.012	pF
Grid No. 1 to grid No. 2	$C_{g_1g_2}$	1.7	pF

Between triode and pentode sections

Anode triode to anode pentode	$C_{a_Ta_P}$	0.125	pF
Grid triode to anode pentode	$C_{g_Ta_P}$	0.014	pF
Anode triode to grid No. 1 pentode	$C_{a_Tg_{1P}}$	max. 0.010	pF
Grid triode to grid No. 1 pentode	$C_{g_Tg_{1P}}$	max. 0.010	pF

TYPICAL CHARACTERISTICS

Triode section

Anode voltage	V_a		100	V
Grid voltage	V_g		-3	V
Anode current	I_a		14	mA
Transconductance	S		5.7	mA/V
Amplification factor	μ		17	–

Pentode section

Anode voltage	V_a		170	V
Grid No. 2 voltage	V_{g_2}		150	V
Grid No. 1 voltage	V_{g_1}		-1.2	V
Anode current	I_a		10	mA
Grid No. 2 current	I_{g_2}		3.8	mA
Transconductance	S		12	mA/V
Amplification factor	$\mu_{g_2g_1}$		70	–
Internal resistance	R_i	min.	350	kΩ
Equivalent noise resistance	R_{eq}		1	kΩ

OPERATING CHARACTERISTICS

Triode section as oscillator

Anode supply voltage	V_{ba}	190	V
Anode resistor	R_a	8.2	kΩ
Grid resistor	R_g	10	kΩ
Oscillator voltage	V_{osc}	4.5	V_{RMS}
Anode current	I_a	12	mA
Effective transconductance	S_{eff}	3.5	mA/V

Pentode section as mixer

Anode supply voltage	V_{ba}	190	V
Grid No.2 supply voltage	V_{bg_2}	190	V
Grid No.2 resistor	R_{g_2}	18	kΩ
Grid No.1 resistor	R_{g_1}	100	kΩ
Oscillator voltage	V_{osc}	2.3	V_{RMS}
Anode current	I_a	8.5	mA
Grid No.2 current	I_{g_2}	3.0	mA
Grid No.1 current	I_{g_1}	30	μA
Conversion conductance	S_c	4.5	mA/V
Internal resistance	R_i	0.6	MΩ

LIMITING VALUES

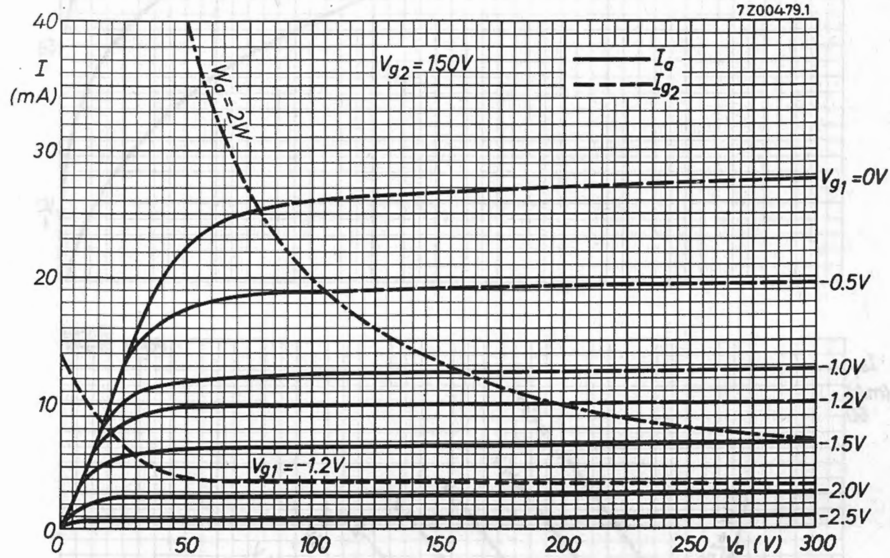
Triode section

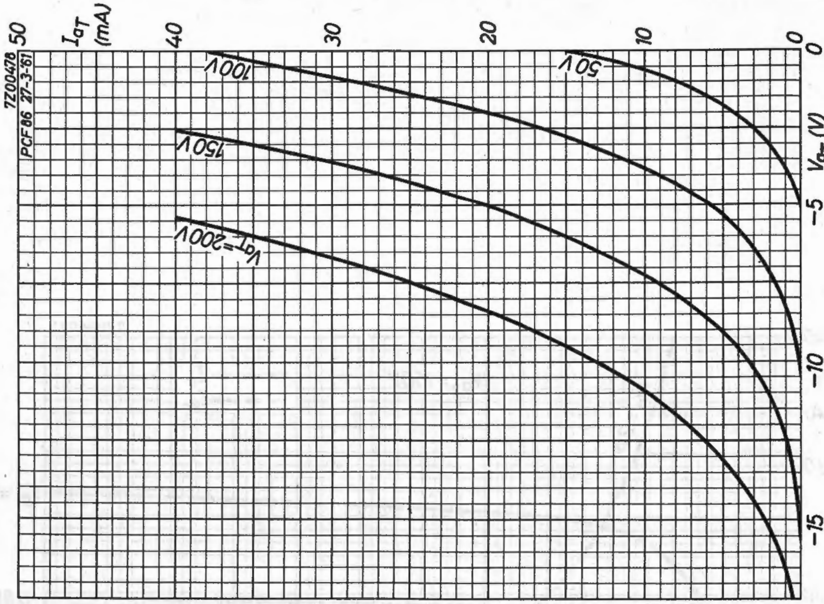
Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	250	V
Anode dissipation	W_a	max.	1.5	W
Cathode current	I_k	max.	15	mA
Grid resistor	R_g	max.	0.5	MΩ
Cathode to heater voltage	V_{kf}	max.	100	V [1]

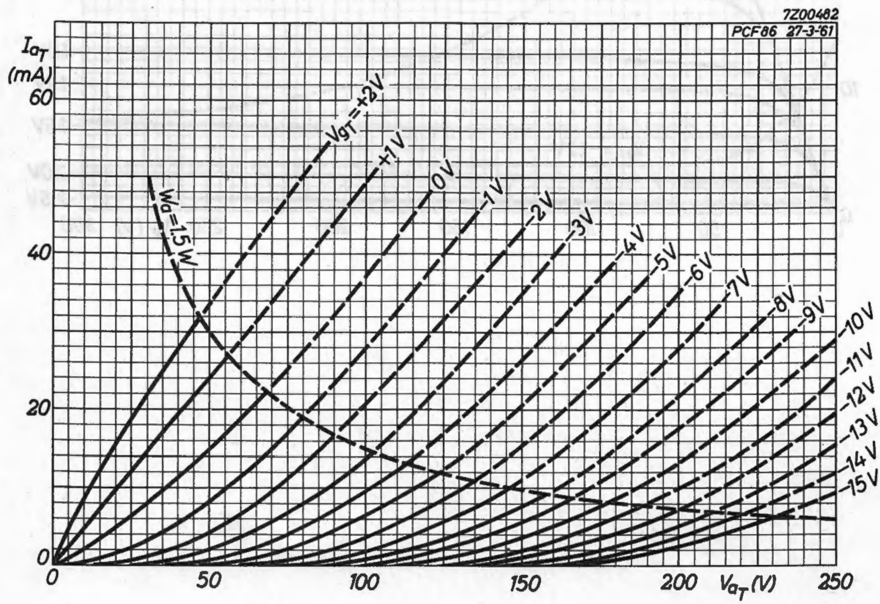
Pentode section

Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	250	V
Grid No.2 voltage	V_{g2_o}	max.	550	V
	V_{g_2}	max.	150	V
Anode dissipation	W_a	max.	2.0	W
Grid No.2 dissipation	W_{g_2}	max.	0.5	W
Cathode current	I_k	max.	18	mA
Grid No.1 resistor	R_{g_1}	max.	0.5	MΩ
Cathode to heater voltage	V_{kf}	max.	100	V [1]

[1]) To fulfil the modulation hum requirements in intercarrier receivers, V_{kf} should not exceed 75 V_{RMS}.
With respect to modulation hum in A.M. sound receivers, V_{kf} should not exceed 50 V_{RMS}.


7Z00479.1
40
I
(mA)
30
20
10
0
V_{g2} = 150V
W_a = 2W
I_a
I_{g2}
V_{g1} = 0V
-0.5V
-1.0V
-1.2V
-1.5V
-2.0V
-2.5V
V_{g1} = -1.2V
0
50
100
150
200
250
V_a (V)
300


7Z00478
PCF86 27-3-'61
I_{a_T} (mA)
50
40
30
20
10
0
100V
50V
150V
V_{a_T}=200V
V_{g_T} (V)
0
−5
−10
−15


7Z00482
PCF86 27-3-'61
I_{a_T} (mA)
60
40
20
0
W_a=1.5W
V_{g_T}=+2V
+1V
0V
−1V
−2V
−3V
−4V
−5V
−6V
−7V
−8V
−9V
−10V
−11V
−12V
−13V
−14V
−15V
0
50
100
150
200
250
V_{a_T} (V)

TRIODE-PENTODE

Triode-pentode intended for use in television receivers; triode section as limiter, noise detector, A.G.C. amplifier, sync. separator and pulse-amplifier; pentode section as sound I.F. amplifier and video I.F. amplifier.

QUICK REFERENCE DATA			
Pentode section			
Anode current	I_a	13	mA
Transconductance	S	14	mA/V
Amplification factor	$\mu_{g_2g_1}$	53	-
Triode section			
Anode current	I_a	8.5	mA
Transconductance	S	5.2	mA/V
Amplification factor	μ	57	-

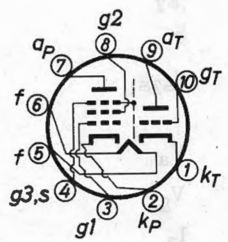
HEATING: Indirect by A.C. or D.C.; series supply

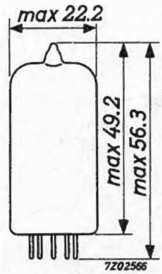
Heater current	I_f	300	mA
Heater voltage	V_f	8.5	V

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Decal





CAPACITANCES

Triode section			
Grid to all except anode	$C_{g(a)}$	2.1	pF
Anode to all except grid	$C_{a(g)}$	3.0	pF
Anode to grid	C_{ag}	2.2	pF
Pentode section			
Grid No.1 to all except anode	$C_{g_1(a)}$	6.0	pF
Anode to all except grid No.1	$C_{a(g_1)}$	3.3	pF
Anode to grid No.1	C_{ag_1}	0.0056	pF
	C_{ag_1} max.	0.008	pF
Grid No.1 to grid No.2	$C_{g_1g_2}$	1.7	pF
Grid No.1 to cathode	C_{g_1k}	3.7	pF
Between triode and pentode sections			
Pentode anode to triode anode	$C_{aP\text{-}aT}$	max. 0.015	pF
Pentode grid No.1 to triode anode	$C_{g_1P\text{-}aT}$	max. 0.0012	pF
Pentode grid No.1 to triode grid	$C_{g_1P\text{-}gT}$	max. 0.0015	pF

TYPICAL CHARACTERISTICS

Pentode section			
Anode voltage	V_a	160	V
Grid No.3 voltage	V_{g_3}	0	V
Grid No.2 voltage	V_{g_2}	135	V
Grid No.1 voltage	V_{g_1}	-1.7	V
Anode current	I_a	13	mA
Grid No.2 current	I_{g_2}	5.3	mA
Transconductance	S	14	mA/V
Amplification factor	$\mu_{g_2g_1}$	53	-
Triode section			
Anode voltage	V_a	170	V
Grid voltage	V_g	-1.0	V
Anode current	I_a	8.5	mA
Transconductance	S	5.2	mA/V
Amplification factor	μ	57	-

OPERATING CHARACTERISTICS

Pentode section as sound or video I.F. amplifier (g_3 connected to earth)

Supply voltage	V_b	210	230	V
Anode resistor	R_a	3.9	5.6	kΩ
Grid No.2 resistor	R_{g_2}	15	22	kΩ
Cathode resistor	R_k	91	83	Ω
Anode current	I_a	13.0	12.5	mA
Grid No.2 current	I_{g_2}	5.3	5.1	mA
Transconductance	S	14	14	mA/V
Input resistance at 40 MHz	r_{g_1}	6.6	6.6	kΩ

Triode section as sync separator

Anode supply voltage	V_b	130 to 150	V
Anode resistor	R_a	33	kΩ
Grid current	I_g	1	μA
Anode current	I_a	min. 2	mA

LIMITING VALUES (Design centre rating system)

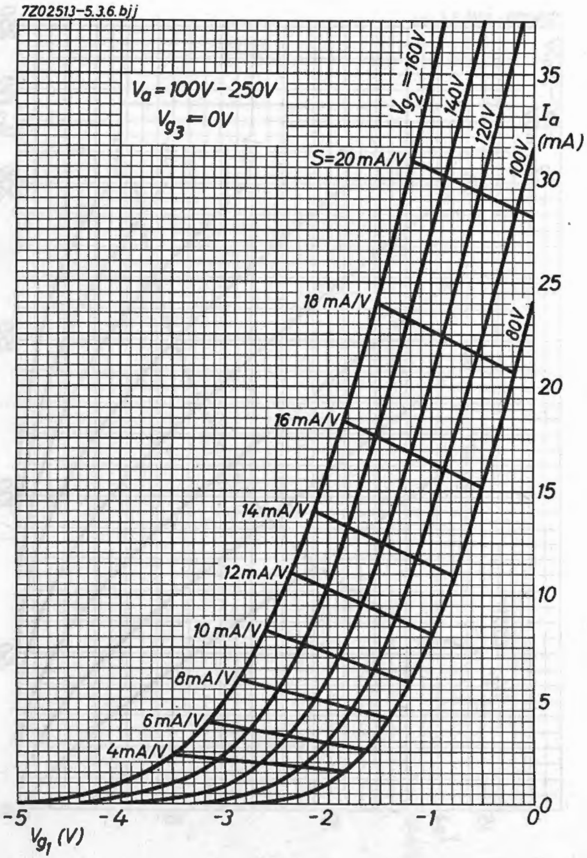
Pentode section

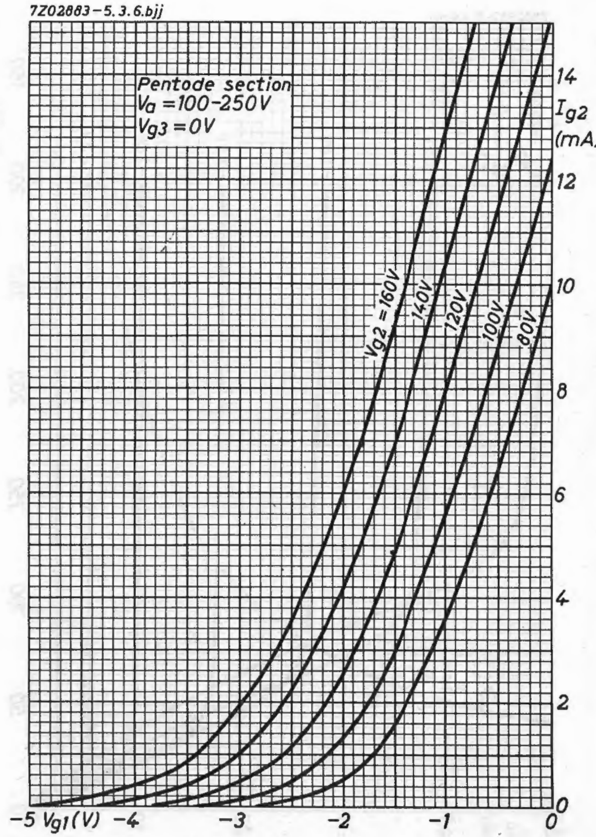
Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	250	V
Anode dissipation	W_a	max.	2.1	W
Cathode current	I_k	max.	20	mA
Grid No.2 voltage	V_{g2_o}	max.	550	V
	V_{g_2}	max.	250	V
Grid No.2 dissipation	W_{g_2}	max.	0.75	W
Cathode to heater voltage	V_{kf}	max.	150	V
Grid No.1 resistor	R_{g_1}	max.	1	MΩ

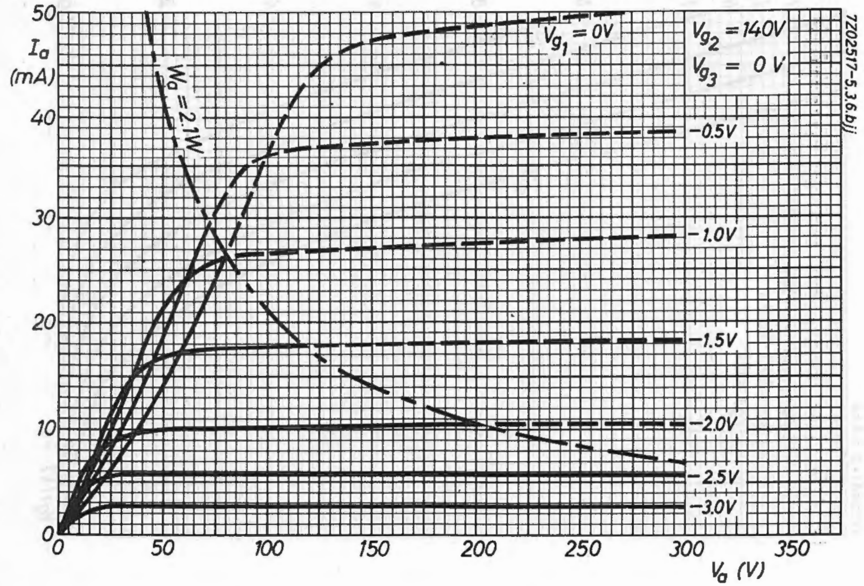
Triode section

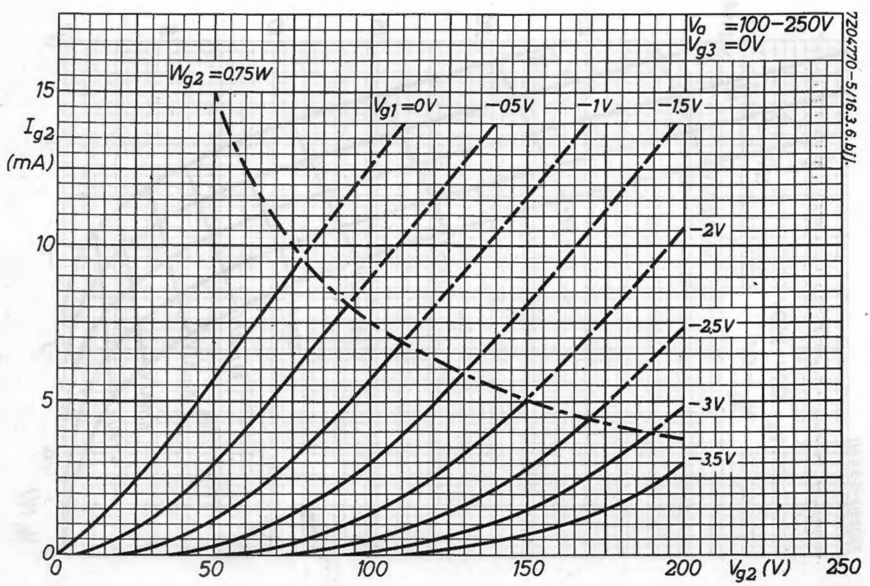
Peak anode voltage ($I_a < 0.1$ mA)	V_{a_p}	max.	600	V [1]
Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	250	V
Anode dissipation	W_a	max.	1.5	W
Cathode current	I_k	max.	18	mA
Grid resistor	R_g	max.	1	MΩ
Cathode to heater voltage:				
cathode negative with respect to heater	V_{kf}	max.	150	V
cathode positive with respect to heater	V_{kf}	max.	200	V
		+ max.	150	V_{RMS}

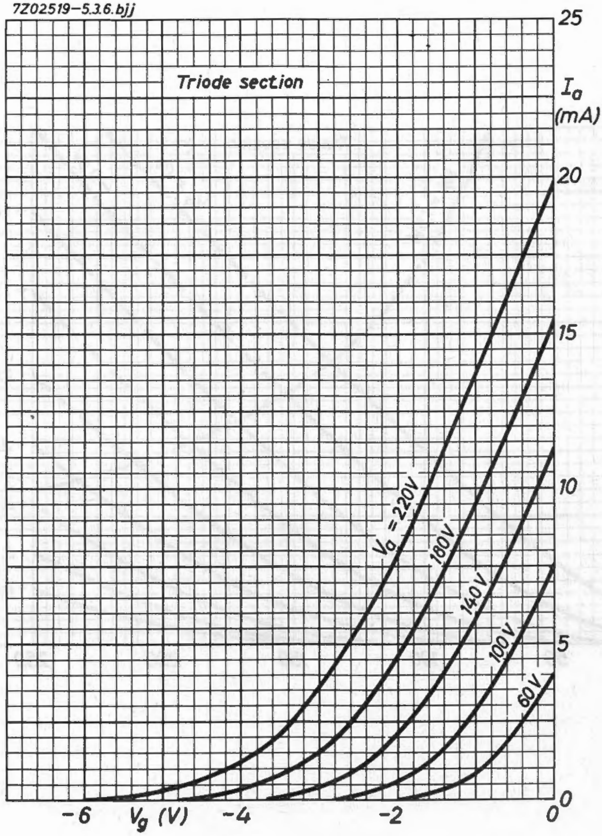
[1]) Max. pulse duration is 18 % of a cycle but max. 18 μsec.

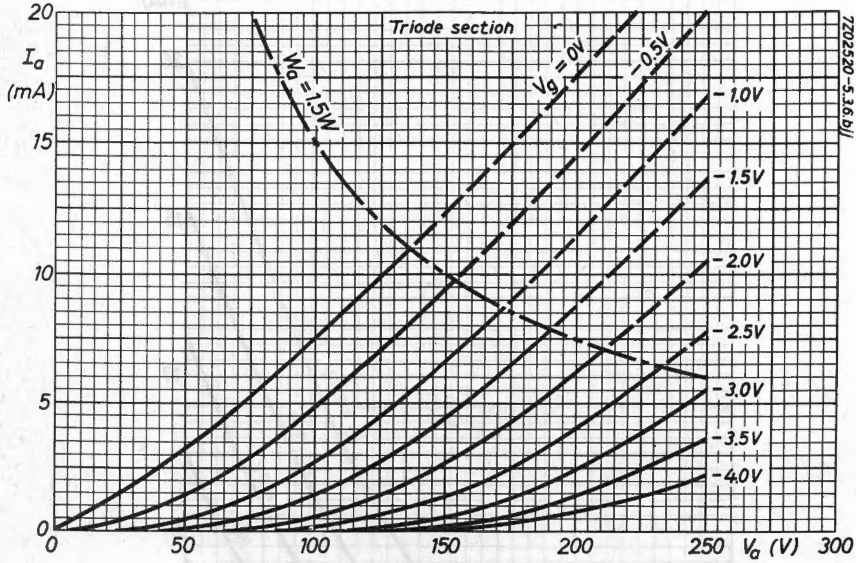

7Z02513-5.3.6.bjj
V_a = 100V - 250V
V_{g_3} = 0V
V_{g_2} = 160V
140V
120V
100V
80V
S=20 mA/V
18 mA/V
16 mA/V
14 mA/V
12 mA/V
10 mA/V
8mA/V
6mA/V
4mA/V
I_a (mA)
35
30
25
20
15
10
5
0
-5
-4
-3
-2
-1
0
V_{g_1} (V)


7Z02883-5.3.6.bjj
Pentode section
V_a = 100-250V
V_{g3} = 0V
V_{g2} = 160V
140V
120V
100V
80V
I_{g2} (mA)
14
12
10
8
6
4
2
0
-5 V_{g1} (V) -4
-3
-2
-1
0


7Z02517-5.3.6.b)).
V_{g2} =140V
V_{g3} = 0 V
V_{g1} = 0V
W_a = 2.1W
−0.5V
−1.0V
−1.5V
−2.0V
−2.5V
−3.0V
I_a
(mA)
50
40
30
20
10
0
0
50
100
150
200
250
300
350
V_a (V)


7Z04770-5/16.3.6.b)).
V_a =100−250V
V_{g3} =0V
W_{g2} =0.75W
V_{g1} =0V
−05V
−1V
−1.5V
−2V
−2.5V
−3V
−3.5V
I_{g2}
(mA)
15
10
5
0
0
50
100
150
200
250
V_{g2} (V)


7Z02519-5.3.6.bjj
Triode section
I_a (mA)
25
20
15
10
5
0
V_a = 220V
180V
140V
100V
60V
-6
V_g (V)
-4
-2
0


Triode section
I_a
(mA)
20
15
10
5
0
0
50
100
150
200
250
300
V_a (V)
W_a = 1.5W
V_g = 0V
−0.5V
−1.0V
−1.5V
−2.0V
−2.5V
−3.0V
−3.5V
−4.0V
7Z02520-5.3.6.b//

TRIODE-PENTODE

Triode pentode intended for use in T.V. receivers; triode section as line-blocking oscillator, part of a multivibrator, sync separator, pulse amplifier or A.G.C. delay diode; pentode section with remote cut-off as video I.F. amplifier.

QUICK REFERENCE DATA

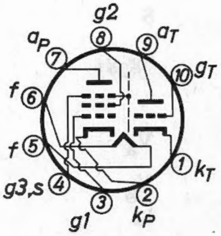
Pentode section				
Anode current	I_a		13	mA
Transconductance	S		12.6	mA/V
Amplification factor	$\mu_{g_2 g_1}$		45	-
Triode section				
Anode current	I_a		14	mA
Transconductance	S		4.8	mA/V
Amplification factor	μ		17.5	-
Cathode peak current	I_{k_p}	max.	50	mA

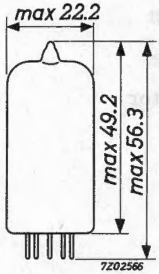
HEATING: Indirect by A.C. or D.C.; series supply

Heater current	I_f	300	mA
Heater voltage	V_f	8.5	V

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Decal





CAPACITANCES

Pentode section			
Anode to all except grid No.1	$C_{a(g_1)}$	3.3	pF
Grid No.1 to all except anode	$C_{g1(a)}$	6.0	pF
Grid No.1 to cathode	C_{kg_1}	3.7	pF
Anode to grid No.1	C_{ag_1}	0.0056	pF
	C_{ag_1}	max. 0.008	pF
Grid No.1 to grid No.2	C_{g1g2}	1.7	pF
Triode section			
Anode to all except grid	$C_{a(g)}$	3.0	pF
Grid to all except anode	$C_{g(a)}$	2.1	pF
Anode to grid	C_{ag}	2.0	pF
Between pentode and triode sections			
Pentode anode to triode anode	C_{aPaT}	max. 0.015	pF
Pentode grid No.1 to triode anode	C_{g_1PaT}	max. 0.0012	pF
Pentode grid No.1 to triode grid	C_{g_1PgT}	max. 0.0015	pF

TYPICAL CHARACTERISTICS

Pentode section			
Anode voltage	V_a	160	V
Grid No.3 voltage	V_{g3}	0	V
Grid No.2 voltage	V_{g2}	110	V
Grid No.1 voltage	V_{g1}	-1.4	V
Anode current	I_a	13	mA
Grid No.2 current	I_{g2}	5.3	mA
Transconductance	S	12.6	mA/V
Amplification factor	$\mu_{g_2g_1}$	45	–
Triode section			
Anode voltage	V_a	100	V
Grid voltage	V_g	-2	V
Anode current	Ia	14	mA
Transconductance	S	4.8	mA/V
Amplification factor	μ	17.5	–

OPERATING CHARACTERISTICS

Pentode section as video I.F. amplifier (g_3 connected to earth)

Supply voltage	V_b	210	230	250	V
Anode resistor	R_a	3.9	5.6	6.8	kΩ
Grid No.2 resistor	R_{g_2}	18	22	27	kΩ
Cathode resistor	R_k	79	79	76	Ω
Anode current	I_a	13.2	13.2	12.8	mA
Grid No.2 current	I_{g_2}	5.4	5.4	5.2	mA
Transconductance	S	12.6	12.6	12.6	mA/V
Grid No.1 voltage at 0.1 S	V_{g_1}	-5.1	-5.4	-5.7	V
Grid No.1 voltage at 0.01 S	V_{g_1}	-19	-20.5	-22	V
Grid No.1 input resistance at 40 MHz	r_{g_1}	7.4	7.4	7.4	kΩ

Triode section as line-blocking oscillator

Anode voltage	V_a	30	V
Peak cathode current	I_{k_p}	40	mA
Peak anode current	I_{a_p}	25	mA
Peak grid current	I_{g_p}	15	mA

Triode section as sync. separator

Anode supply voltage	V_{b_a}	130 to 150	V
Anode resistor	R_a	33	kΩ
Grid current	I_g	1	μA
Anode current	I_a	min. 2	mA

LIMITING VALUES (Design centre rating system)

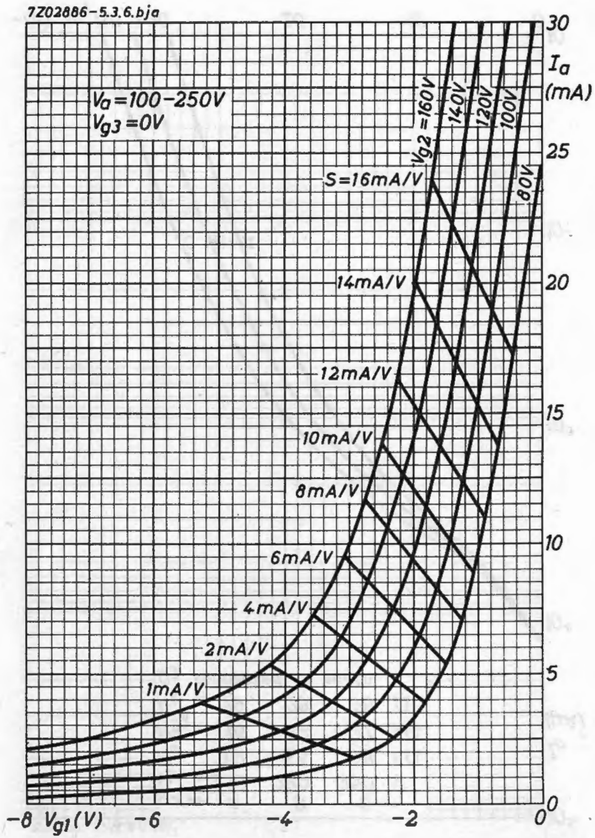
Pentode section

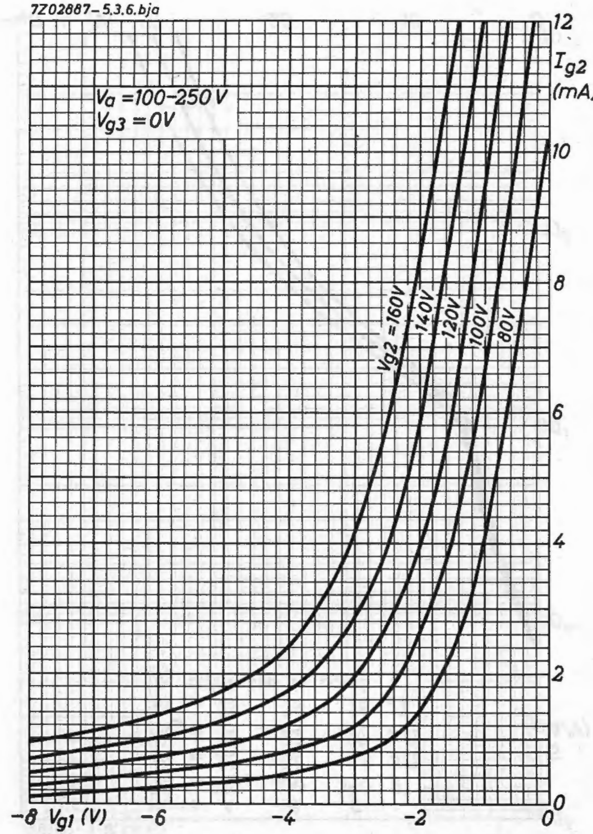
Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	250	V
Anode dissipation	W_a	max.	2.1	W
Grid No.2 voltage	$V_{g_{2o}}$	max.	550	V
	V_{g_2}	max.	250	V
Grid No.2 dissipation	W_{g_2}	max.	0.7	W
Grid No.1 resistor	R_{g_1}	max.	1	MΩ
Cathode current	I_k	max.	20	mA
Cathode to heater voltage	V_{kf}	max.	150	V

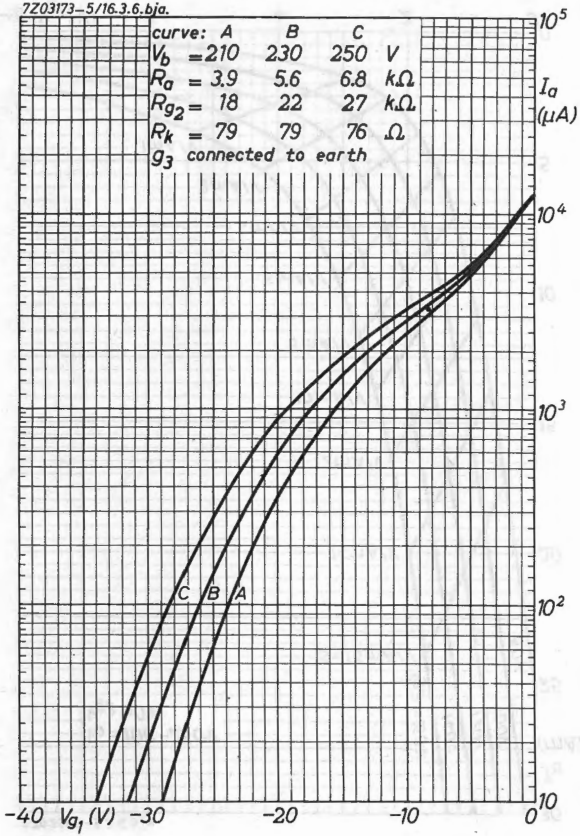
Triode section

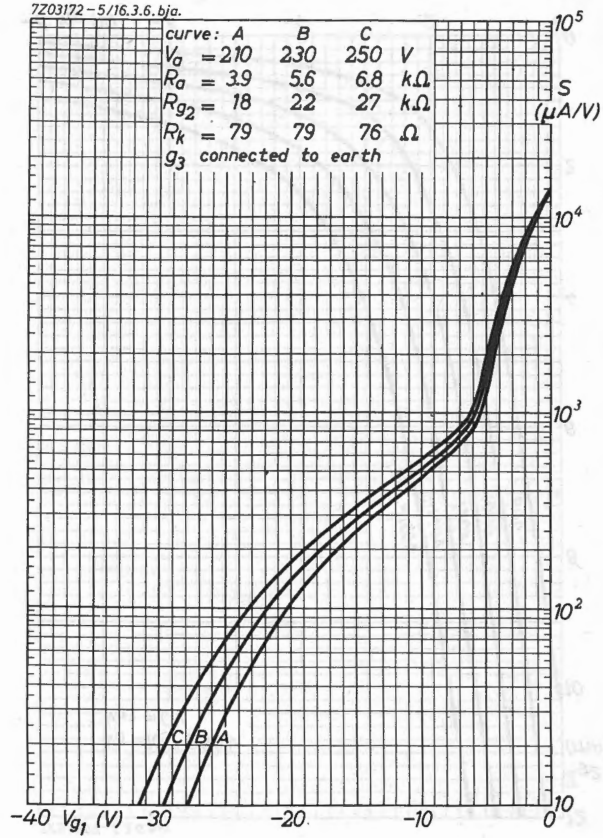
Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	250	V
Anode dissipation	W_a	max.	1.5	W
Grid resistor	R_g	max.	1	MΩ
Cathode current	I_k	max.	18	mA
Peak cathode current	I_{kp}	max.	50	mA[1])
Cathode to heater voltage	V_{kf}	max.	150	V

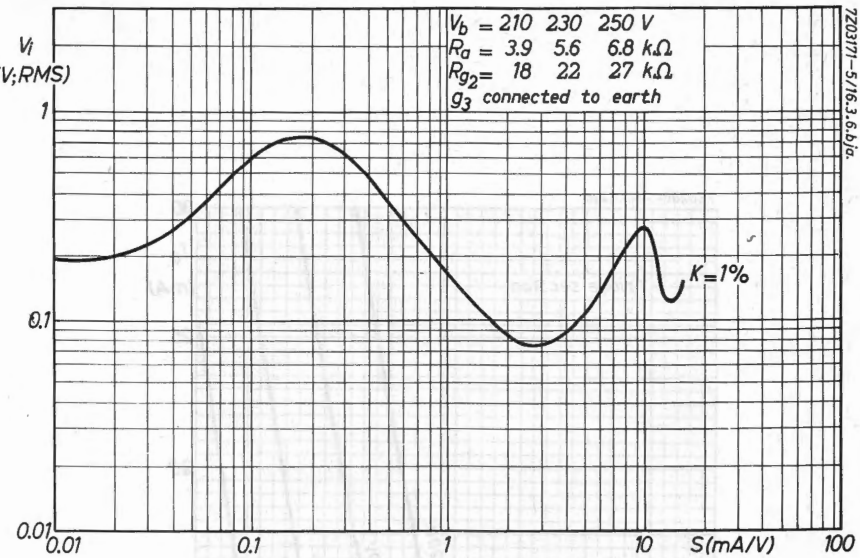
[1]) Maximum pulse duration 10% of a cycle but max. 10 μs.


7Z02886-5.3.6.bja
V_a=100-250V
V_{g3}=0V
I_a (mA)
V_{g2}=160V
140V
120V
100V
80V
S=16mA/V
14mA/V
12mA/V
10mA/V
8mA/V
6mA/V
4mA/V
2mA/V
1mA/V
30
25
20
15
10
5
0
−8 V_{g1}(V)
−6
−4
−2
0

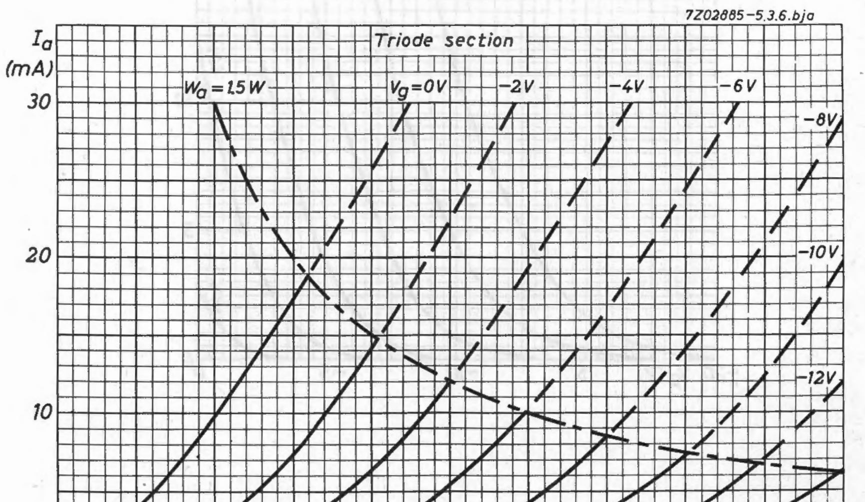

7Z02887-5.3.6.bja
V_a=100-250V
V_{g3}=0V
I_{g2} (mA)
V_{g2}=160V
140V
120V
100V
80V
12
10
8
6
4
2
0
−8 V_{g1}(V)
−6
−4
−2
0


7Z03173-5/16.3.6.bja.
curve: A B C
V_b = 210 230 250 V
R_a = 3.9 5.6 6.8 kΩ
R_{g_2} = 18 22 27 kΩ
R_k = 79 79 76 Ω
g_3 connected to earth
I_a (μA)
10^5
10^4
10^3
10^2
10
C B A
-40 V_{g_1} (V) -30 -20 -10 0

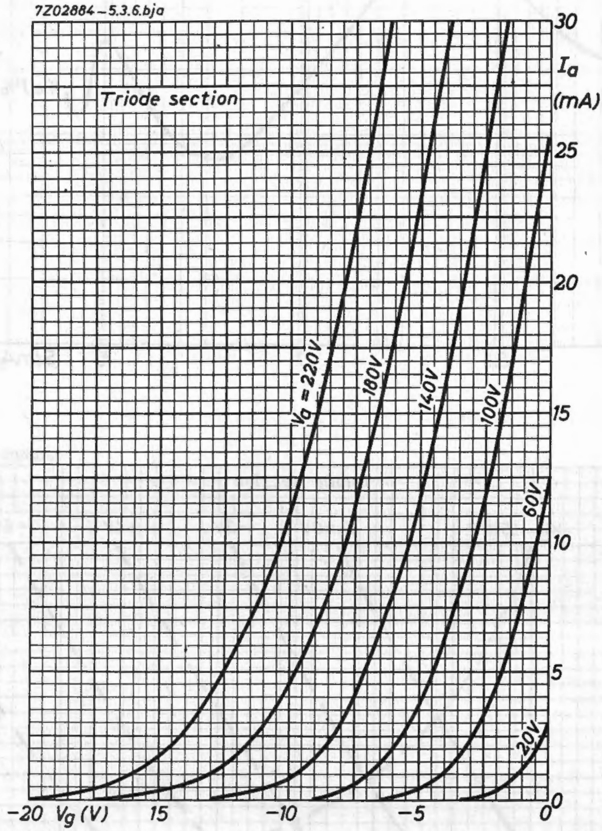

7Z03172-5/16.3.6.bja.
curve: A B C
V_a = 210 230 250 V
R_a = 3.9 5.6 6.8 kΩ
R_{g_2} = 18 22 27 kΩ
R_k = 79 79 76 Ω
g_3 connected to earth
S (μA/V)
10^5
10^4
10^3
10^2
10
C B A
-40 V_{g_1} (V) -30 -20 -10 0



V_i (V;RMS)
V_b = 210 230 250 V
R_a = 3.9 5.6 6.8 kΩ
R_{g_2} = 18 22 27 kΩ
g_3 connected to earth
K=1%
0.01
0.1
1
10
100
S(mA/V)
7Z03171-5/16.3.6.bja.



7Z02885-5.3.6.bja
Triode section
I_a (mA)
W_a=1.5 W
V_g=0V
−2V
−4V
−6V
−8V
−10V
−12V
−14V
−16V
0
10
20
30
50
100
150
200
250
V_a (V)


7Z02884-5.3.6.bja
Triode section
I_a (mA)
30
25
20
15
10
5
0
V_a = 220V
180V
140V
100V
60V
20V
−20
V_g (V)
15
−10
−5
0

TRIODE-PENTODE

High transconductance triode and R.F. pentode intended for use as frequency changer in V.H.F. T.V. tuners.

QUICK REFERENCE DATA				
Pentode section				
Anode current	I_a		10	mA
Transconductance	S		11	mA/V
Amplification factor	$\mu_{g_2g_1}$		55	-
Internal resistance	R_i	min.	350	kΩ
Triode section				
Anode current	I_a		15	mA
Transconductance	S		9	mA/V
Amplification factor	μ		20	-

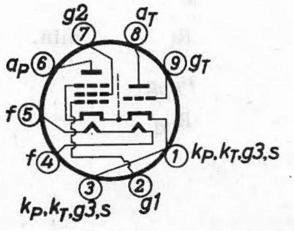
HEATING: Indirect by A.C. or D.C.; series supply

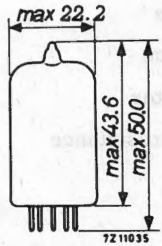
Heater current	I_f	0.3	A
Heater voltage	V_f	8.5	V

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





CAPACITANCES (with external shield)

Pentode section

Grid No. 1 to all except anode	$C_{g1(a)}$	5.9	pF
Anode to all except grid No. 1	$C_{a(g_1)}$	3.7	pF
Anode to grid No. 1	C_{ag_1}	0.009	pF
	C_{ag_1}	max. 0.012	pF
Grid No. 1 to grid No. 2	$C_{g_1g_2}$	1.6	pF

Triode section

Grid to all except anode	$C_{g(a)}$	3.3	pF
Anode to all except grid	$C_{a(g)}$	1.7	pF
Anode to grid	C_{ag}	1.8	pF

Between pentode and triode sections

Pentode anode to triode anode	C_{aPaT}	max. 0.025	pF
Pentode anode to triode grid	C_{aPgT}	max. 0.010	pF
Pentode grid No. 1 to triode anode	C_{g1PaT}	max. 0.010	pF
Pentode grid No. 1 to triode grid	C_{g1PgT}	max. 0.010	pF

TYPICAL CHARACTERISTICS

Pentode section

Anode voltage	V_a	170	V
Grid No. 2 voltage	V_{g2}	120	V
Grid No. 1 voltage	V_{g1}	-1.4	V
Anode current	I_a	10	mA
Grid No. 2 current	I_{g2}	3	mA
Transconductance	S	11	mA/V
Internal resistance	R_i	min. 350	kΩ
Amplification factor	μ_{g2g1}	55	
Equivalent noise resistance	R_{eq}	1.5	kΩ

TYPICAL CHARACTERISTICS (continued)

Triode section

Anode voltage	V_a	100	V
Grid voltage	V_g	-3	V
Anode current	I_a	15	mA
Transconductance	S	9	mA/V
Amplification factor	μ	20	-

OPERATING CHARACTERISTICS

Pentode section as I.F. amplifier

Anode supply voltage	V_{ba}	200		V
Grid No. 2 supply voltage	V_{bg_2}	200		V
Grid No. 2 resistor	R_{g_2}	27		kΩ
Anode resistor	R_a	2.7	4.7	kΩ
Grid No. 1 supply voltage	V_{bg_1}	-1.4	0	V
Grid No. 1 resistor	R_{g_1}	0.1	1	MΩ
Anode current	I_a	10	13	mA
Grid No. 2 current	I_{g_2}	3.0	3.9	mA
Transconductance	S	11	14.5	mA/V
Input resistance at 50 MHz	r_{g_1}	10	10	kΩ
Grid No. 1 voltage	V_{g_1}	-12	-	V
Transconductance	S	0.11	-	mA/V

OPERATING CHARACTERISTICS (continued)

Pentode section as mixer

Anode supply voltage	V_{ba}	200		V
Grid No. 2 supply voltage	V_{bg_2}	200		V
Grid No. 2 resistor	R_{g_2}	27		kΩ
Anode resistor	R_a	2.7	4.7	kΩ
Grid No. 1 supply voltage	V_{bg_1}	-1.4	0	V
Grid No. 1 resistor	R_{g_1}	0.1	1	MΩ
Oscillator voltage	V_{osc}	1.6	1.6	$V_{(RMS)}$
Anode current	I_a	10	9.3	mA
Grid No. 2 current	I_{g_2}	3.0	2.9	mA
Grid No. 1 current	I_{g_1}	8	2.3	μA
Conversion conductance	S_c	5	4.7	mA/V

OPERATING CHARACTERISTICS

Triode section as oscillator

Anode supply voltage	V_{ba}	200		V
Grid resistor	R_g	10		kΩ
Anode resistor	R_a	8.2	12	kΩ
Oscillator voltage	V_{osc}	4.5	3.3	$V_{(RMS)}$
Anode current	I_a	16	12	mA
Effective transconductance (without higher harmonics)	S_{eff}	3.7	3.7	mA/V

LIMITING VALUES (Design centre rating system)

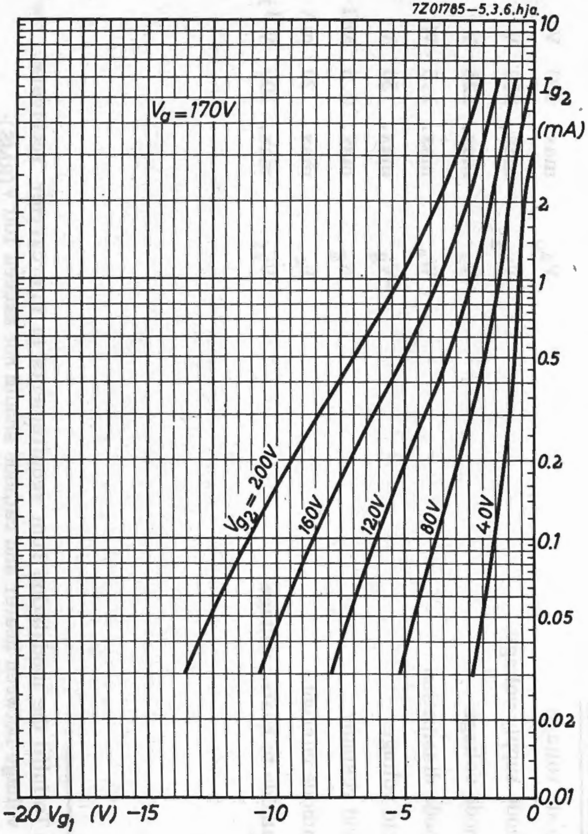
Pentode section

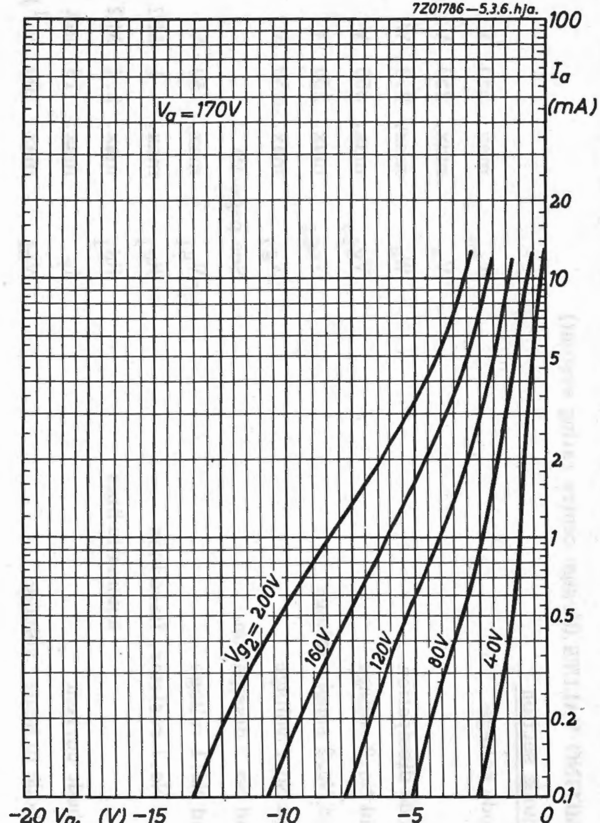
Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	250	V
Anode dissipation	W_a	max.	2.0	W
Grid No.2 voltage	$V_{g_{2o}}$	max.	550	V
Grid No.2 supply voltage	V_{bg_2}	max.	250	V
Grid No.2 voltage	V_{g_2}	max.	250	V
Grid No.2 dissipation	See page 10			
Grid No.1 voltage	$-V_{g_1}$	max.	50	V
Grid No.1 resistor, fixed bias	R_{g_1}	max.	1	MΩ
automatic bias	R_{g_1}	max.	2.2	MΩ
Cathode current	I_k	max.	18	mA
Cathode to heater voltage	V_{kf}	max.	100	V [1]

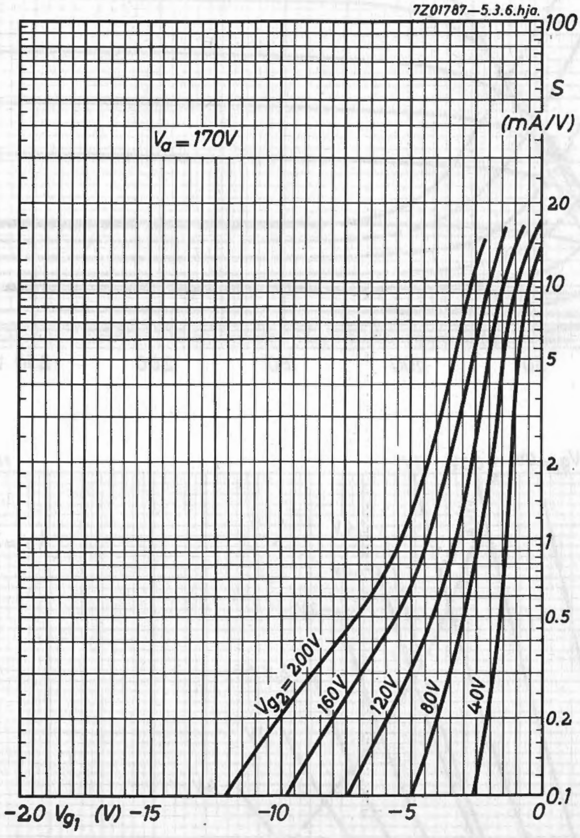
Triode section

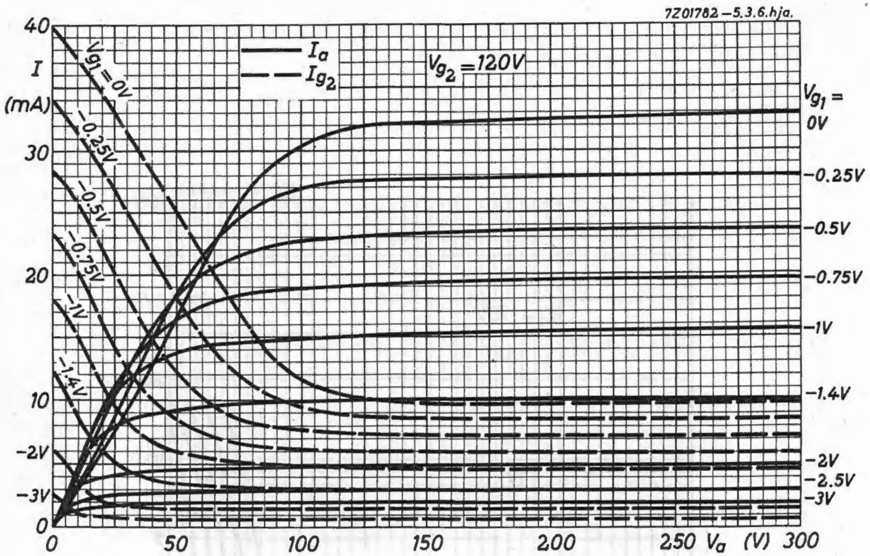
Anode voltage	V_{a_o}	max.	550	V
Anode supply voltage	V_{b_a}	max.	250	V
Anode voltage	V_a	max.	125	V
Anode dissipation	W_a	max.	1.5	W
Grid voltage	$-V_g$	max.	50	V
Grid resistor	R_g	max.	0.5	MΩ
Cathode current	I_k	max.	20	mA
Cathode to heater voltage	V_{kf}	max.	100	V [1]

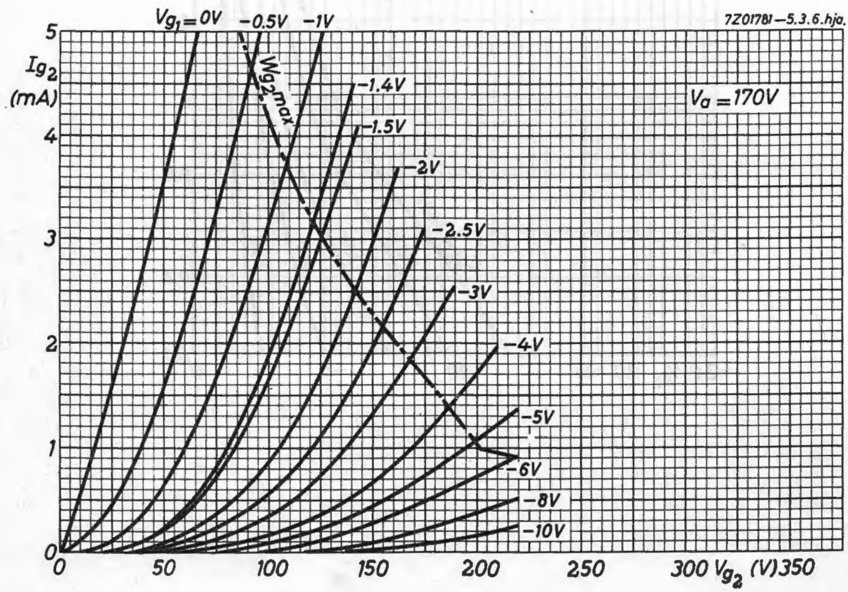
[1]) To fulfil the modulation hum requirements in intercarrier receivers, the voltage between heater and cathode should not exceed 100 $V_{(RMS)}$.
With respect to modulation hum in A.M. sound receivers the voltage between heater and cathode should not exceed 50 $V_{(RMS)}$.

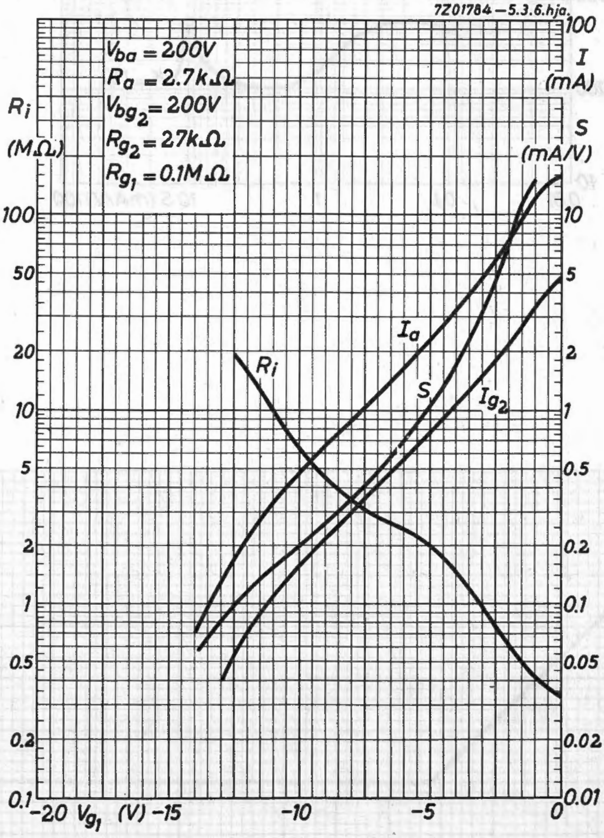

7Z01785—5.3.6.hja.
$V_a = 170V$
I_{g_2} (mA)
$V_{g_2} = 200V$
160V
120V
80V
40V
10
2
1
0.5
0.2
0.1
0.05
0.02
0.01
−20 V_{g_1} (V) −15
−10
−5
0

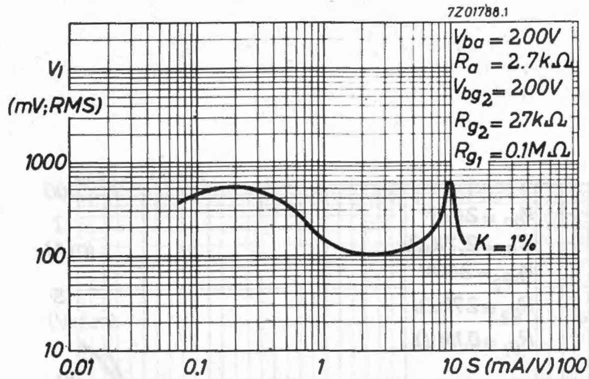

7Z01786—5.3.6.hja.
$V_a = 170V$
I_a (mA)
$V_{g_2} = 200V$
160V
120V
80V
40V
100
20
10
5
2
1
0.5
0.2
0.1
−20 V_{g_1} (V) −15
−10
−5
0

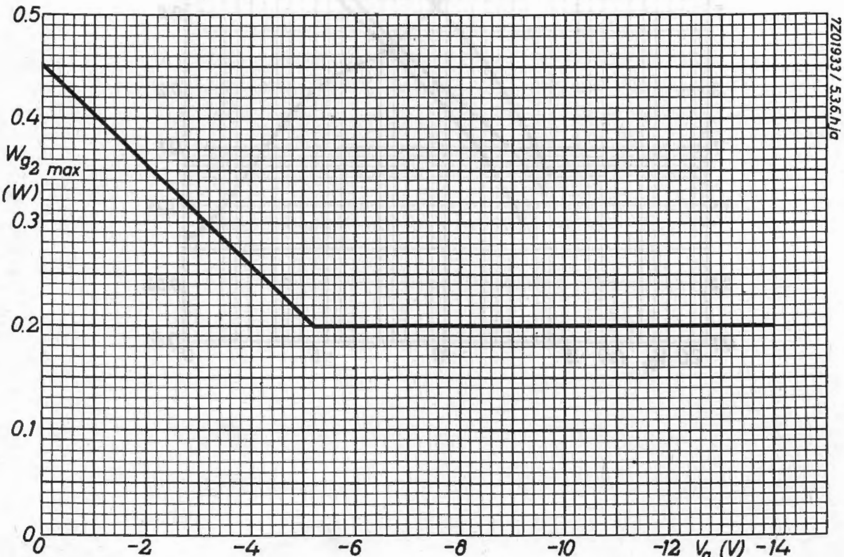

7Z01787—5.3.6.hja.
100
S
(mA/V)
$V_a = 170V$
20
10
5
2
1
0.5
0.2
0.1
$V_{g2} = 200V$
160V
120V
80V
40V
−20 V_{g1} (V) −15
−10
−5
0

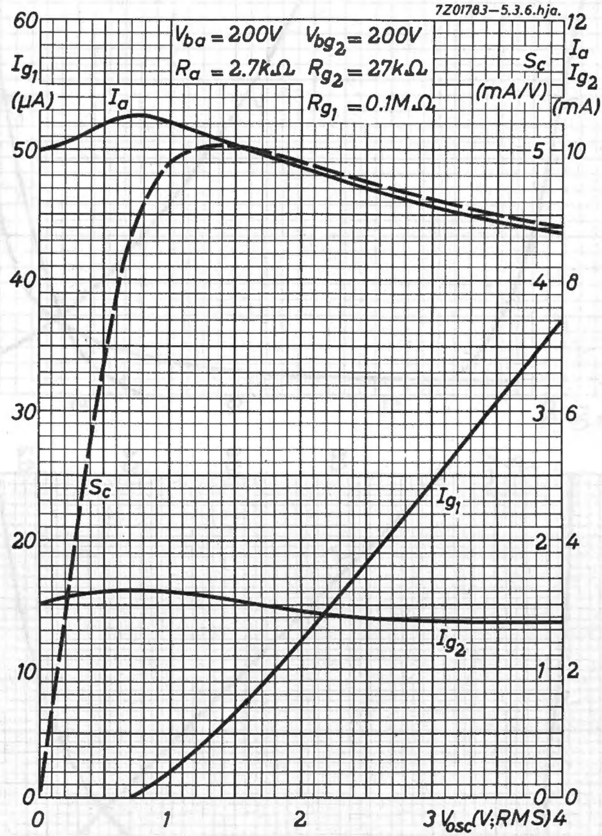

7Z01782-5.3.6.hja.
I_a
I_{g_2}
$V_{g_2}=120V$
I (mA)
$V_{g_1}=0V$
-0.25V
-0.5V
-0.75V
-1V
-1.4V
-2V
-3V
$V_{g_1}=$ 0V
-0.25V
-0.5V
-0.75V
-1V
-1.4V
-2V
-2.5V
-3V
V_a (V)

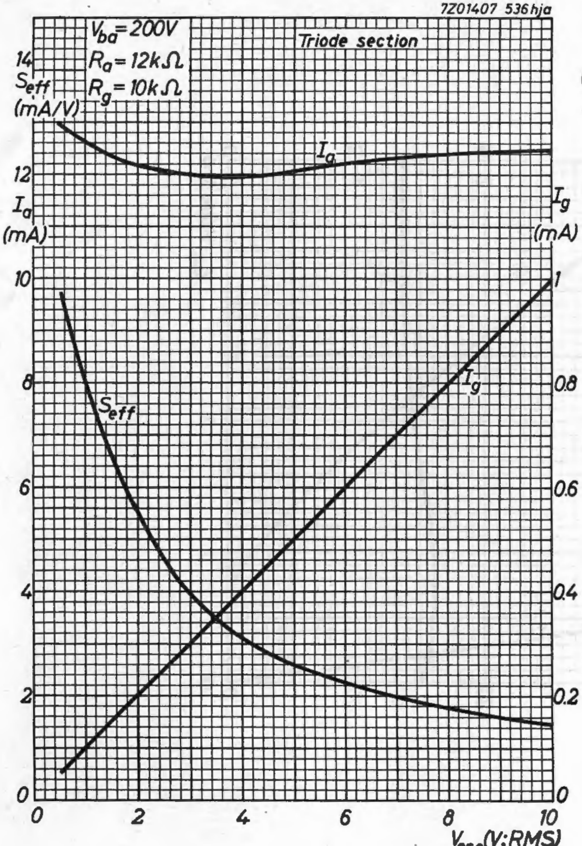

7Z01781-5.3.6.hja.
I_{g_2} (mA)
$V_{g_1}=0V$
-0.5V
-1V
W_{g_2} max
-1.4V
-1.5V
-2V
-2.5V
-3V
-4V
-5V
-6V
-8V
-10V
$V_a=170V$
V_{g_2} (V)

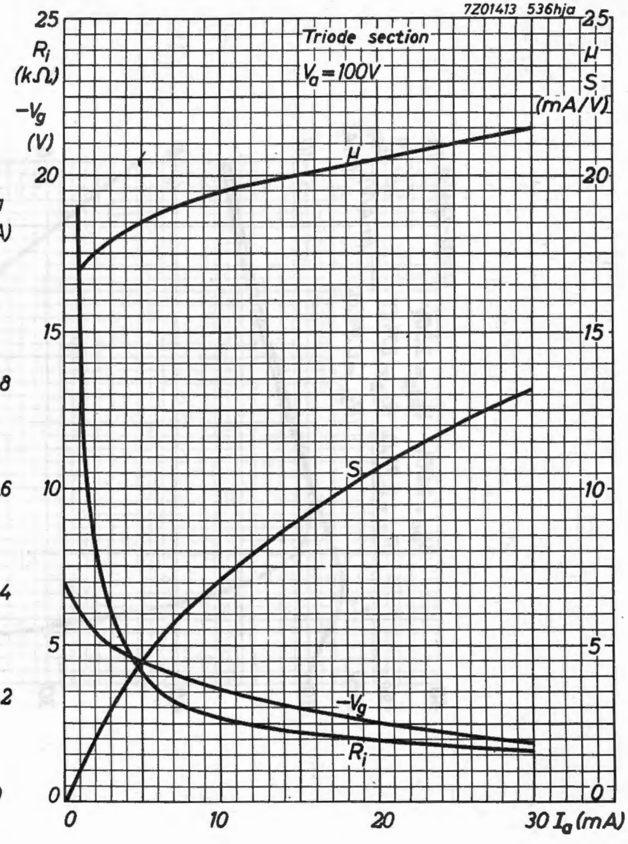

7Z01784—5.3.6.hja.
$V_{ba} = 200V$
$R_a = 2.7k\Omega$
$V_{bg_2} = 200V$
$R_{g_2} = 2.7k\Omega$
$R_{g_1} = 0.1M\Omega$
R_i
$(M\Omega)$
I
(mA)
S
(mA/V)
100
50
20
10
5
2
1
0.5
0.2
0.1
0.5
0.2
0.1
0.05
0.02
0.01
I_a
R_i
S
I_{g_2}
−20 V_{g_1} (V) −15
−10
−5
0


7Z01788.1
$V_{ba} = 200V$
$R_a = 2.7k\Omega$
$V_{bg_2} = 200V$
$R_{g_2} = 27k\Omega$
$R_{g_1} = 0.1M\Omega$
V_i
(mV;RMS)
1000
100
10
0.01
0.1
1
10
S (mA/V)
100
K = 1%


7Z01933 / 5.3.6.h/a
$W_{g_2\,max}$
(W)
0.5
0.4
0.3
0.2
0.1
0
0
-2
-4
-6
-8
-10
-12
V_{g_1} (V)
-14


7Z01783—5.3.6.hja.
$V_{ba} = 200V$ $V_{bg_2} = 200V$
$R_a = 2.7k\Omega$ $R_{g_2} = 27k\Omega$
$R_{g_1} = 0.1M\Omega$
I_{g_1} (μA)
S_c (mA/V)
I_a I_{g_2} (mA)
I_a
S_c
I_{g_1}
I_{g_2}
V_{osc} (V;RMS)
0
10
20
30
40
50
60
0
1
2
3
4
5
0
2
4
6
8
10
12
0
1
2
3
4


7Z01407 536hja
Triode section
V_{ba}=200V
R_a=12kΩ
R_g=10kΩ
S_{eff} (mA/V)
I_a (mA)
I_g (mA)
I_a
I_g
S_{eff}
V_{osc}(V;RMS)
0
2
4
6
8
10
12
14
0.2
0.4
0.6
0.8
1


7Z01413 536hja
Triode section
V_a=100V
R_i (kΩ)
$-V_g$ (V)
μ
S (mA/V)
μ
S
$-V_g$
R_i
I_a (mA)
0
5
10
15
20
25
30

TRIODE-PENTODE

Triode pentode; triode section intended for use as reactance tube, pentode section intended for use as sine wave oscillator or pulse shaper in television receivers.

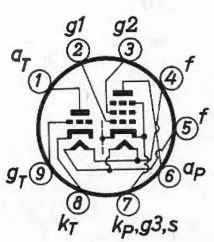
QUICK REFERENCE DATA			
Pentode section			
Anode current	I_a	6	mA
Transconductance	S	5.5	mA/V
Amplification factor	μ_{g2g1}	47	-
Internal resistance	R_i	400	kΩ
Triode section			
Anode current	I_a	3.5	mA
Transconductance	S	3.5	mA/V
Amplification factor	μ	70	-

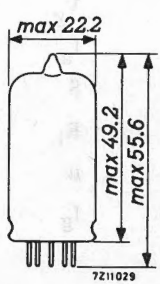
HEATING: Indirect by A.C. or D.C.; series supply

Heater current	I_f	300	mA
Heater voltage	V_f	9	V

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Noval





CAPACITANCES

Pentode section

Grid No.1 to all except anode	$C_{g_1(a)}$		5.4	pF
Anode to grid No.1	C_{ag_1}		0.06	pF
Grid No.1 to heater	C_{g_1f}	max.	0.1	pF

Triode section

Grid to all except anode	$C_{g(a)}$		2.4	pF
Anode to grid	C_{ag}		1.5	pF
Grid to heater	C_{gf}	max.	0.1	pF

TYPICAL CHARACTERISTICS

Pentode section

Anode voltage	V_a	100	100	200	100	V
Grid No.2 voltage	V_{g_2}	100	100	200	100	V
Grid No.1 voltage	V_{g_1}	−1	0	max.−16	max.−1.3	V
Anode current	I_a	6	12.5	0.01	–	mA
Grid No.2 current	I_{g_2}	1.7	3.5	–	–	mA
Transconductance	S	5.5	–	–	–	mA/V
Internal resistance	R_i	400	–	–	–	kΩ
Amplification factor	$\mu_{g_2g_1}$	47	–	–	–	–
Grid No.1 current	I_{g_1}	–	–	–	0.3	µA

Triode section

Anode voltage	V_a	200	200	200	V
Grid voltage	V_g	−2	–	max.−1.3	V
Anode current	I_a	3.5	10	–	mA
Transconductance	S	3.5	–	–	mA/V
Internal resistance	R_i	20	–	–	kΩ
Amplification factor	μ	70	–	–	–
Grid current	I_g	–	10	0.3	µA

LIMITING VALUES (Design centre rating system)

Pentode section

Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	250	V
Anode dissipation	W_a	max.	1.2	W
Grid No.2 voltage	V_{g2_o}	max.	550	V [1]
	V_{g2}	max.	250	V
Grid No.2 dissipation	W_{g2}	max.	0.8	W
Grid No.1 voltage	$-V_{g1}$	max.	220	V [1]
Grid resistor, fixed bias	R_{g1}	max.	0.56	MΩ
automatic bias	R_{g1}	max.	1	MΩ
Cathode current, average	I_k	max.	15	mA
peak	I_{kp}	max.	50	mA
T_{imp} = max. 30 µs, δ = max. 0.3				
Cathode to heater voltage	V_{kf}	max.	100	V [2]
Grid circuit impedance	Z_{g1} (f = 50 Hz)	max.	300	kΩ [2]

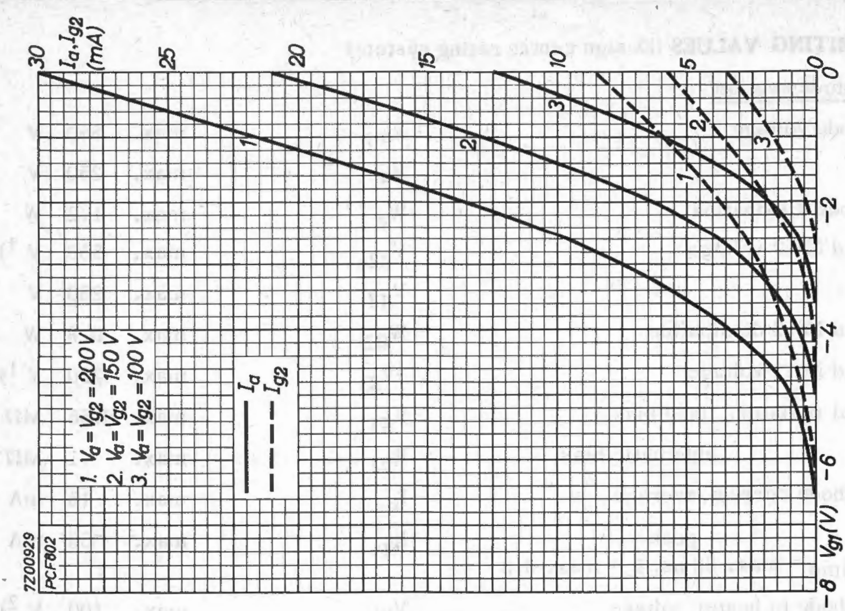
Triode section

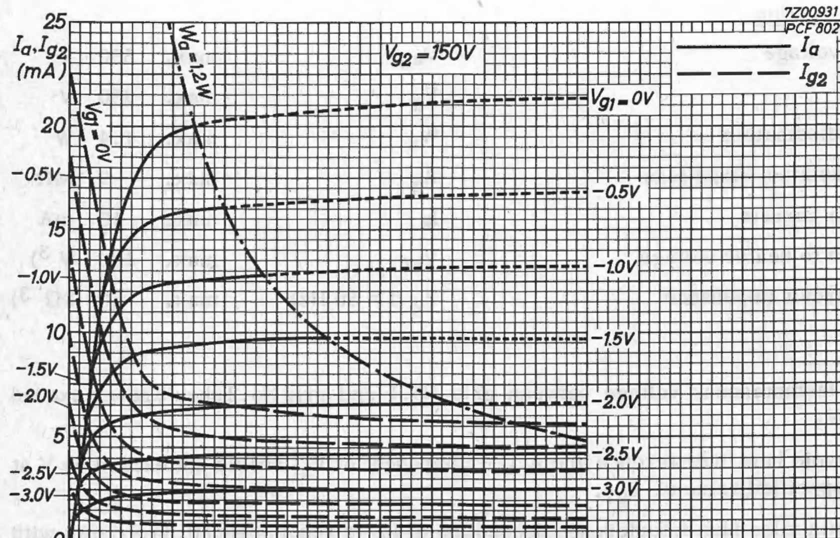
Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	250	V
Anode dissipation	W_a	max.	1.4	W
Grid resistor, fixed bias	R_g	max.	3	MΩ
Cathode current	I_k	max.	10	mA
Cathode to heater voltage	V_{kf}	max.	100	V [3]
Grid circuit impedance	Z_g (f = 50 Hz)	max.	50	kΩ [3]

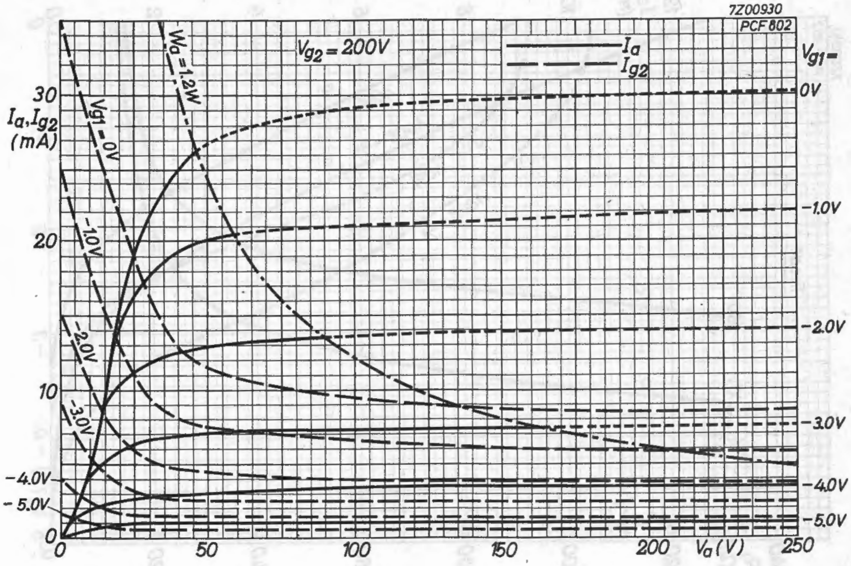
1) The instantaneous voltage between grid No.1 and grid No.2 should never exceed 550 V.

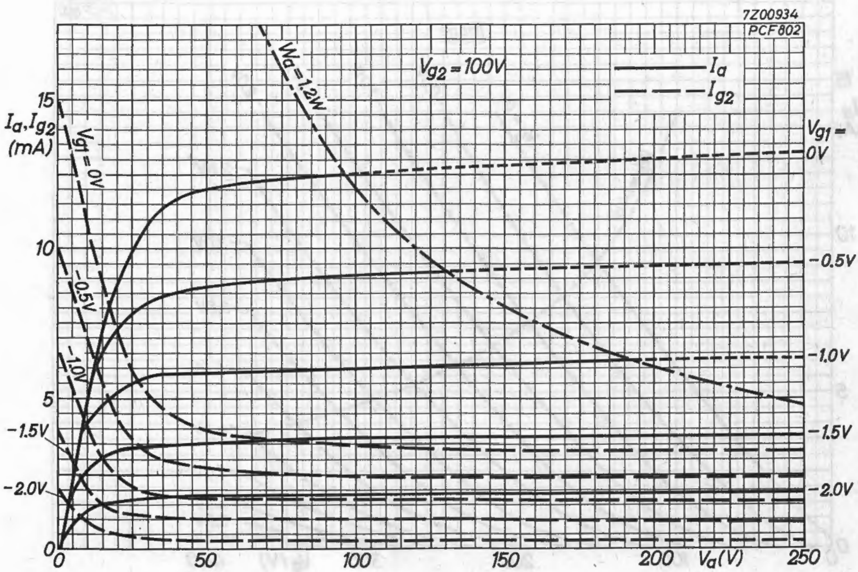
2) To avoid hum interference the A.C. component of V_{kf} should not exceed 65 V at the specified value of Z_{g1}.

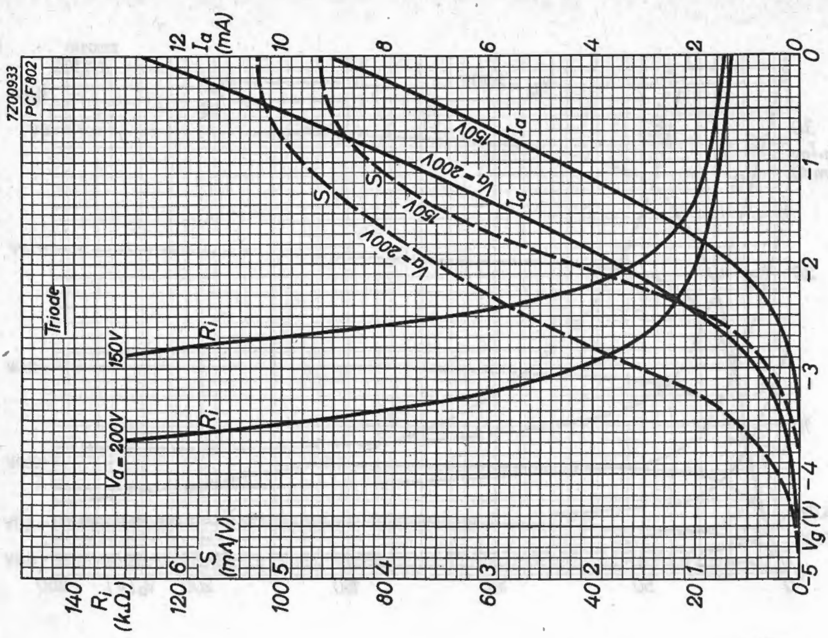
3) To minimise hum interference decoupling of R_k is recommended. In circuits with undecoupled R_k the hum interference between grid and cathode will remain below 1000 µV when the A.C. component of V_{kf} does not exceed 25 V and the R_k is not higher than 1.2 kΩ at the specified value of Z_g.

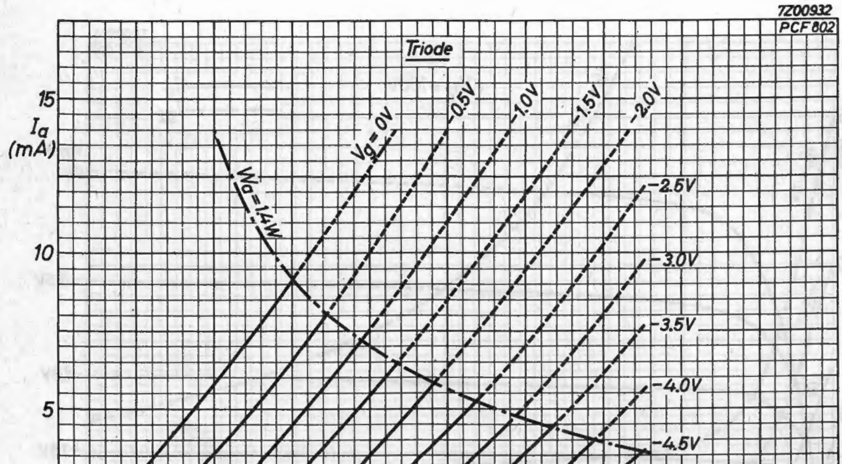

I_a, I_{g2} (mA)
30
25
20
15
10
5
0
0
−2
−4
−6
−8
V_{g1} (V)
1. $V_a = V_{g2} = 200\,V$
2. $V_a = V_{g2} = 150\,V$
3. $V_a = V_{g2} = 100\,V$
I_a
I_{g2}
7Z00929
PCF802


I_a, I_{g2} (mA)
25
20
15
10
5
0
$V_{g2} = 150V$
I_a
I_{g2}
7Z00931
PCF802
$W_a = 1.2W$
$V_{g1} = 0V$
$V_{g1} = 0V$
−0.5V
−1.0V
−1.5V
−2.0V
−2.5V
−3.0V
0
50
100
150
200
V_a (V)
250


7Z00930
PCF 802
$V_{g2} = 200V$
I_a
I_{g2}
$V_{g1} =$
0V
-1.0V
-2.0V
-3.0V
-4.0V
-5.0V
$W_a = 1.2W$
$V_{g1} = 0V$
I_a, I_{g2} (mA)
30
20
10
0
V_a (V)
50
100
150
200
250


7Z00934
PCF 802
$V_{g2} = 100V$
I_a
I_{g2}
$V_{g1} =$
0V
-0.5V
-1.0V
-1.5V
-2.0V
$W_a = 1.2W$
$V_{g1} = 0V$
I_a, I_{g2} (mA)
15
10
5
0
V_a (V)
50
100
150
200
250


7Z00933
PCF 802
Triode
I_a (mA)
12
10
8
6
4
2
0
S (mA/V)
6
5
4
3
2
1
R_i (kΩ)
140
120
100
80
60
40
20
0
V_g (V)
0
−1
−2
−3
−4
−5
V_a = 200V
150V
R_i
S
I_a


7Z00932
PCF 802
Triode
I_a (mA)
15
10
5
0
V_a (V)
0
100
200
300
400
W_a = 1 W
V_g = 0V
−0.5V
−1.0V
−1.5V
−2.0V
−2.5V
−3.0V
−3.5V
−4.0V
−4.5V
−5.0V
−5.5V
−6.0V
−6.5V

TRIODE-HEPTODE

Triode-heptode; triode section intended for use as pulse amplifier and heptode section for use as noise gated sync. separator.

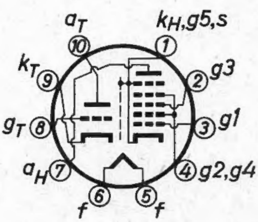
QUICK REFERENCE DATA					
Triode section					
Anode current	I_a		9		mA
Transconductance	S		8.8		mA/V
Amplification factor	μ		50		-
Heptode section					
Grid No.1 voltage	V_{g_1}	0	-1.8	0	V
Grid No.3 voltage	V_{g_3}	0	0	-1.8	V
Anode current	I_a	1500	20	20	μA

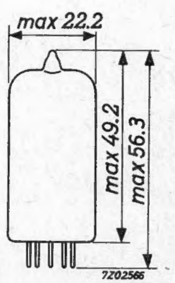
HEATING: Indirect by A.C. or D.C.; series supply

Heater current	I_f	300	mA
Heater voltage	V_f	8.5	V

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: decal





CAPACITANCES

Heptode section

Grid No.1 to all except anode	$C_{g_1(a)}$		4.4	pF
Anode to all except grid No.1	$C_{a(g_1)}$		5.4	pF
Anode to grid No.1	C_{ag_1}	max.	0.1	pF
Anode to grid No.3	C_{ag_3}	max.	0.25	pF
Grid No.1 to grid No.3	$C_{g_1g_3}$		0.3	pF

Triode section

Grid to all except anode	$C_{g(a)}$		3.3	pF
Anode to all except grid	$C_{a(g)}$		1.7	pF
Anode to grid	C_{ag}		1.8	pF

Between heptode and triode sections

Heptode grid No.1 to triode grid	C_{g_1HgT}	max.	0.005	pF
Heptode grid No.1 to triode anode	C_{g_1HaT}	max.	0.010	pF
Heptode grid No.3 to triode grid	C_{g_3HgT}	max.	0.020	pF
Heptode anode to triode anode	C_{aHaT}	max.	0.150	pF

TYPICAL CHARACTERISTICS

Triode section

Anode voltage	V_a	100	200	V
Anode current	I_a	9.0	0.1	mA
Grid voltage	V_g	−1	−7(<11)	V
Transconductance	S	8.8	–	mA/V
Amplification factor	μ	50		

Heptode section

Anode voltage	V_a	14	14	14	V
Grids No.2 and 4 voltage	V_{g_2,g_4}	14	14	14	V
Grid No.3 voltage	V_{g_3}	0	0	−1.8(<2.2)	V
Grid No.1 voltage	V_{g_1}	0	−1.8	0	V
Anode current	I_a	1500	20	20	µA
Grids No.2 and 4 current	$I_{g_2+g_4}$	1300	–	–	µA

OPERATING CHARACTERISTICS

Heptode section as sync. separator

Anode voltage	V_a	14	1	14	14	V
Grids No.2 and 4 voltage	V_{g_2,g_4}	14	14	14	14	V
Grid No.3 voltage	V_{g_3}	–	–	+25	−1.9(<2.3)	V
Grid No.1 voltage	V_{g_1}	–	–	−2	–	V
Anode current	I_a	750	>300	20	20	µA
Grid No.3 current	I_{g_3}	1	1	–	–	µA
Grid No.1 current	I_{g_1}	100	100	–	100	µA

LIMITING VALUES (Design centre rating system)

Triode section

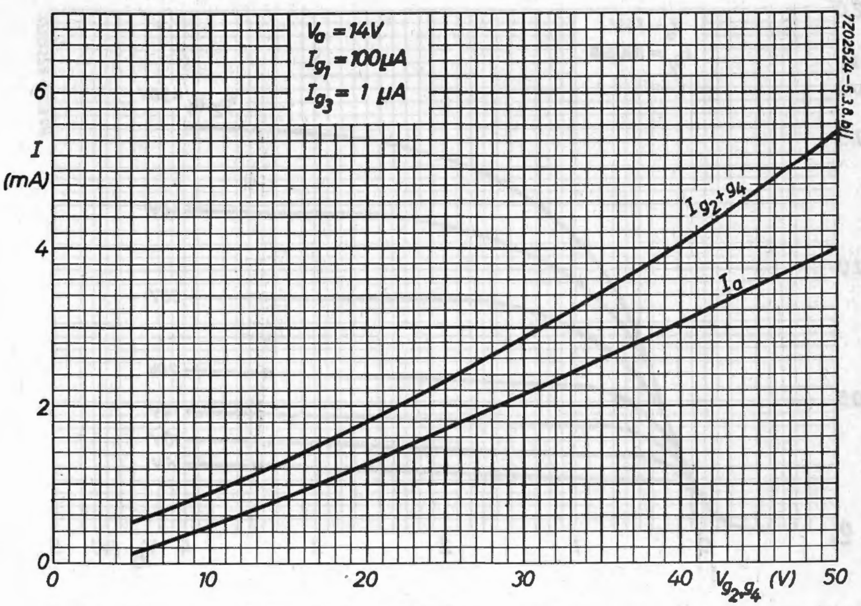
Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	250	V
Anode dissipation	W_a	max.	1.5	W
Cathode current	I_k	max.	20	mA
Grid resistor (fixed bias)	R_g	max.	2	MΩ
(automatic bias)	R_g	max.	3	MΩ
Grid voltage, negative peak	$-V_{g_p}$	max.	200	V
Cathode to heater voltage	V_{kf}	max.	70	V 1)
			+100	V_{RMS}

Heptode section

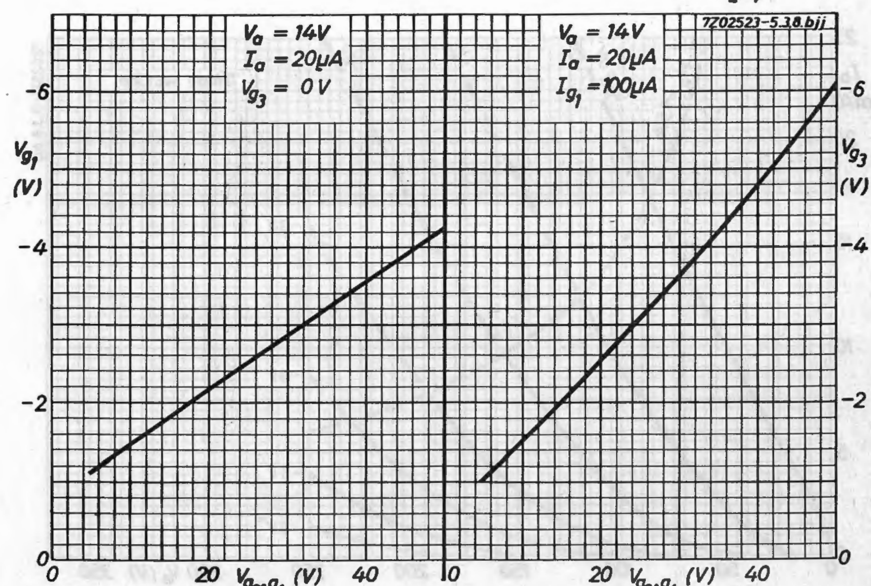
Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	100	V
Grids No.2 and 4 voltage	$V_{(g2,g4)_o}$	max.	550	V
	$V_{g2,g4}$	max.	50	V 2)
Anode dissipation	W_a	max.	0.5	W
Grids No.2 and 4 dissipation	W_{g2+g4}	max.	0.5	W
Cathode current	I_k	max.	8	mA
Grid No.1 resistor	R_{g1}	max.	3	MΩ
Grid No.3 resistor	R_{g3}	max.	3	MΩ
Grid No.1 voltage, negative peak	$-V_{g1_p}$	max.	100	V
Grid No.3 voltage, negative peak	$-V_{g3_p}$	max.	150	V
Cathode to heater voltage	V_{kf}	max.	100	V

1) Cathode positive with respect to heater.

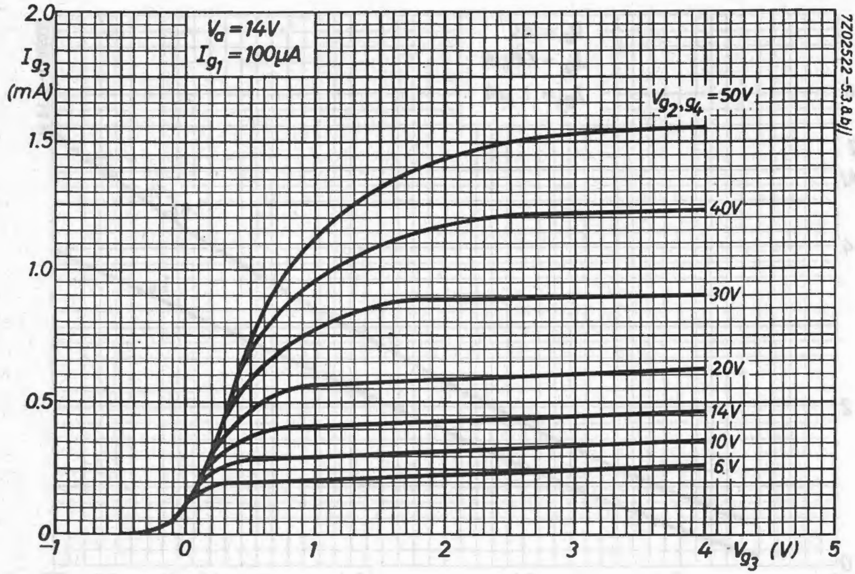
2) The grids No.2 and 4 voltage should not be less than 6 V with an average tube under the worst probable operating conditions.



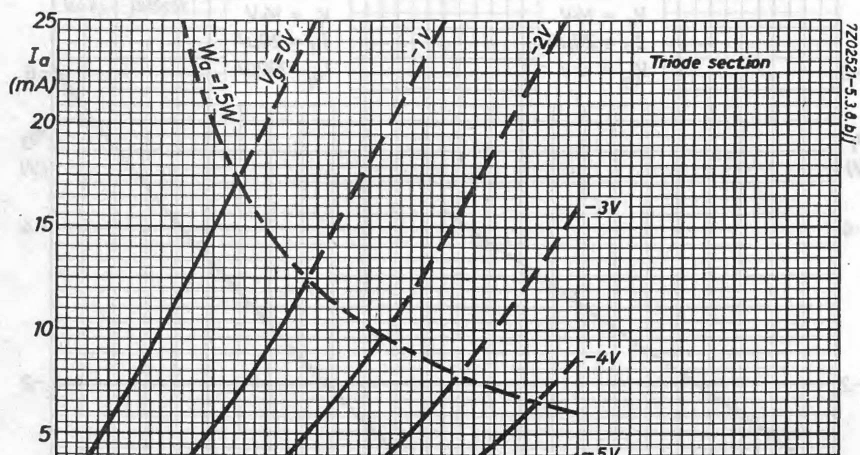
Va = 14V
Ig1 = 100μA
Ig3 = 1 μA
7Z02524-5.3.8.bjj
I (mA)
Ig2+g4
Ia
Vg2,g4 (V)
0
2
4
6
0
10
20
30
40
50



7Z02523-5.3.8.bjj
Va = 14V
Ia = 20μA
Vg3 = 0 V
Va = 14V
Ia = 20μA
Ig1 = 100μA
Vg1 (V)
Vg3 (V)
-6
-4
-2
0
0
20
Vg2,g4 (V)
40
0
20
Vg2,g4 (V)
40



7Z02522-5.3.8.b)
$V_a = 14V$
$I_{g_1} = 100\mu A$
I_{g_3} (mA)
$V_{g_2,g_4} = 50V$
40V
30V
20V
14V
10V
6V
V_{g_3} (V)
2.0
1.5
1.0
0.5
0
−1
0
1
2
3
4
5



7Z02521-5.3.8.b)
Triode section
I_a (mA)
$W_a = 1.5W$
$V_g = 0V$
−1V
−2V
−3V
−4V
−5V
−6V
V_a (V)
25
20
15
10
5
0
0
50
100
150
200
250
300
350

TRIODE-OUTPUT PENTODE

The triode section is intended for use as frame oscillator and A.F. amplifier. The pentode section is intended for use as frame output tube and A.F. power amplifier.

QUICK REFERENCE DATA

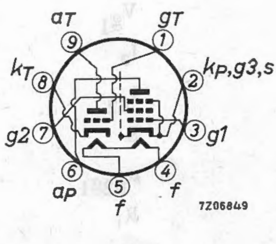
Triode section			
Anode current	I_a	3.5	mA
Transconductance	S	2.2	mA/V
Amplification factor	μ	70	-
Pentode section			
Anode peak voltage	V_{a_p}	max. 2.5	kV
Anode current	I_a	41	mA
Transconductance	S	7.5	mA/V
Amplification factor	$\mu_{g_2g_1}$	9.5	-
Output power	W_o	3.3	W

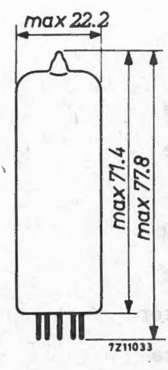
HEATING: Indirect by A.C. or D.C.; series supply

Heater current	I_f	300	mA
Heater voltage	V_f	16	V

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Noval





CAPACITANCES

Triode section			
Anode to all except grid	$C_{a(g)}$	4.3	pF
Grid to all except anode	$C_{g(a)}$	2.7	pF
Anode to grid	C_{ag}	4.4	pF
Grid to heater	C_{gf}	max. 0.02	pF
Pentode section			
Anode to all except grid No.1	$C_{a(g_1)}$	8.0	pF
Grid No.1 to all except anode	$C_{g_1(a)}$	9.3	pF
Anode to grid No.1	C_{ag_1}	max. 0.3	pF
Grid No.1 to heater	C_{g_1f}	max. 0.3	pF
Between triode and pentode sections			
Anode triode to grid No.1 pentode	C_{aTg_1P}	max. 0.02	pF
Grid triode to anode pentode	C_{gTaP}	max. 0.02	pF
Grid triode to grid No.1 pentode	C_{gTg_1P}	max. 0.025	pF
Anode triode to anode pentode	C_{aTaP}	max. 0.25	pF

TYPICAL CHARACTERISTICS

Triode section			
Anode voltage	V_a	100	V
Grid voltage	V_g	0	V
Anode current	I_a	3.5	mA
Transconductance	S	2.2	mA/V
Amplification factor	μ	70	–
Pentode section			
Anode voltage	V_a	170	V
Grid No.2 voltage	V_{g_2}	170	V
Grid No.1 voltage	V_{g_1}	-11.5	V
Anode current	I_a	41	mA
Grid No.2 current	I_{g2}	9	mA
Transconductance	S	7.5	mA/V
Amplification factor	μ_{g2g1}	9.5	–
Internal resistance	R_i	16	kΩ

OPERATING CHARACTERISTICS

Triode section as A.F. amplifier

A. Signal source resistance	R_s	0.22		MΩ
Grid resistor	R_g	3		MΩ
Grid resistor of next stage	$R_{g'}$	0.68		MΩ
Supply voltage	V_b	200	170	V
Cathode resistor	R_k	2.2	2.7	kΩ
Anode resistor	R_a	220	220	kΩ
Anode current	I_a	0.52	0.43	mA
Voltage gain	V_o/V_i 1)	52	51	-
Max. output voltage	$V_{o\,max}$	26	25	V_{RMS}
Distortion	d_{tot} 2)	1.6	2.3	%

B. Signal source resistance	R_s	0.22				MΩ
Grid resistor	R_g	22				MΩ
Grid resistor of next stage	$R_{g'}$	0.68				MΩ
Supply voltage	V_b	200	200	170	170	V
Cathode resistor	R_k	0	0	0	0	Ω
Anode resistor	R_a	100	220	100	220	kΩ
Anode current	I_a	1.05	0.61	0.86	0.50	mA
Voltage gain	V_o/V_i 1)	50	55	49	53	-
Max. output voltage	$V_{o\,max}$	24	25	19	20	V_{RMS}
Distortion	d_{tot} 3)	1.5	1.4	1.4	1.4	%

MICROPHONY AND HUM

The triode section can be used without special precautions against microphony and hum in circuits in which an input voltage $V_i \geqq 10$ mV_{RMS} gives an output of 50 mW of the output stage. Z_g (50 Hz) = 0.25 MΩ. The A.C. voltage between pin 4 and cathode should not exceed 6.3 V. If the tube is used in television circuits where the frequency of the heater supply is not synchronized with the frame frequency, this may cause interference due to hum. At page 8 the relation is shown between the permissible value of Z_{g1} of the pentode section and the A.C. voltage between pin 4 and the cathode. This curve applies to C_{g1f} is 0.8 pF (inclusive of wiring and tube socket).

1) Measured at small input voltage
2) At lower output voltages the distortion is proportionally lower.
3) At lower output voltages down to 5 V_{RMS} the distortion remains approximately constant. At values below 5 V_{RMS} the distortion is approximately proportional to V_o.

OPERATING CHARACTERISTICS

Pentode section

A.F. power amplifier, class A (measured with V_k constant)

Supply voltage	$V_{ba}=V_{bg2}$		170			200			230		V
Grid No.2 series resistor (non-decoupled)	R_{g2}		0			470			1200		Ω
Cathode resistor	R_k		200			330			490		Ω
Load resistance	$R_{a\sim}$		3.25			4.5			6		kΩ
Grid No.1 driving voltage	V_i	0	0.61	5.9	0	0.66	6.7	0	0.75	7.8	V_{RMS}
Anode current	I_a	42	–	44	35	–	37	30	–	31	mA
Grid No.2 current	I_{g2}	9.2	–	15.5	7.8	–	13.3	6.6	–	11.0	mA
Output power	W_o	0	0.05	3.2	0	0.05	3.3	0	0.05	3.25	W
Distortion	d_{tot}	–	–	10	–	–	10	–	–	10	%

A.F. power amplifier, class AB, two tubes in push-pull

Anode supply voltage	V_{ba}	200		230		V
Grid No.2 supply voltage	V_{bg2}	200		200		V
Common cathode resistor	R_k	170		200		Ω
Load resistance	$R_{aa\sim}$	4.5		7		kΩ
Grid No.1 driving voltage	V_i	0	14.2	0	13.0	V_{RMS}
Anode current	I_a	2x35	2x42.5	2x30	2x34.5	mA
Grid No.2 current	I_{g2}	2x8	2x16.5	2x6.2	2x13.5	mA
Output power	W_o	0	9.3	0	10	W
Distortion	d_{tot}	–	6.3	–	5.5	%

Frame output application

The circuit should operate satisfactorily with peak anode current I_{ap} = 85 mA at V_a = 50 V, V_{g2} = 170 V, I_f = 300 mA. The minimum available I_{ap} value at end of life is

70 mA at V_a = 50 V, V_{g2} = 170 V, I_f = 280 mA
80 mA at V_a = 50 V, V_{g2} = 190 V, I_f = 280 mA

LIMITING VALUES (Design centre rating system)

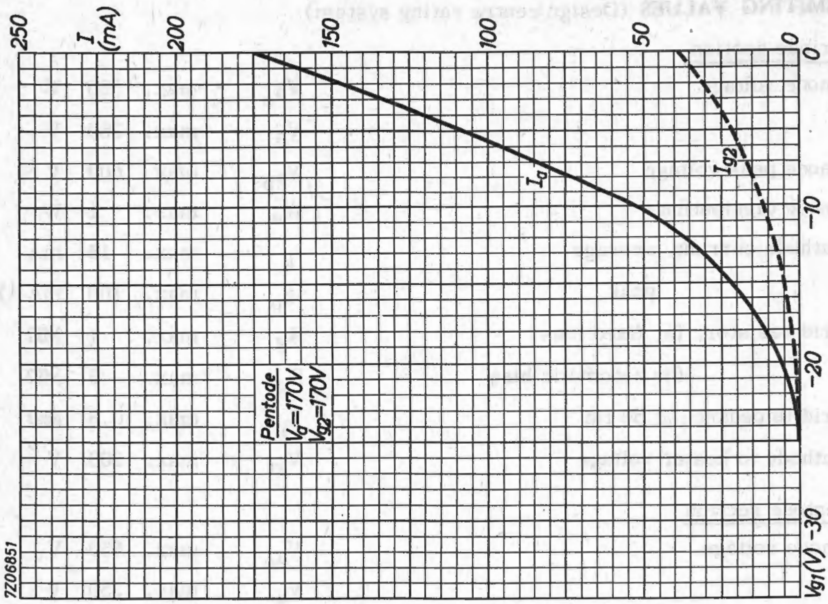
Triode section

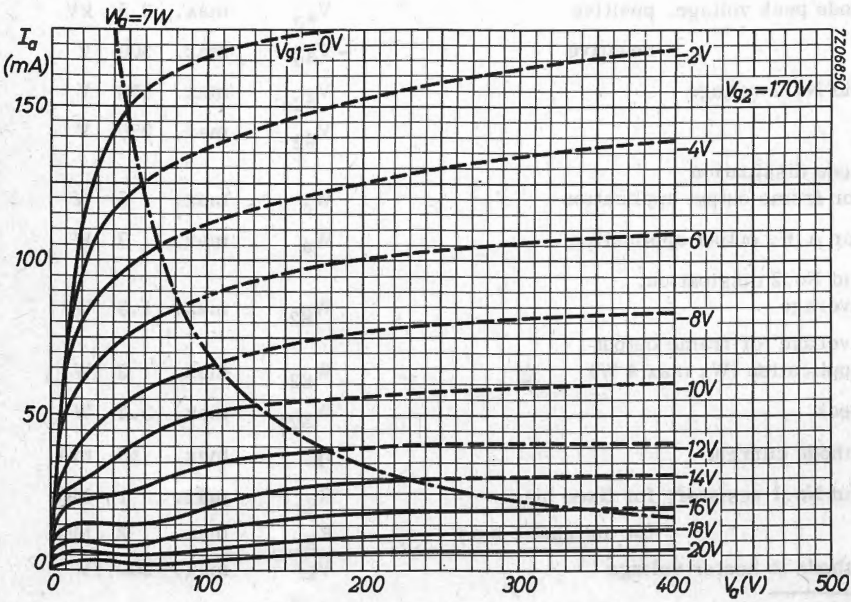
Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	250	V
Anode peak voltage	V_{a_p}	max.	600	V [1])
Anode dissipation	W_a	max.	1	W
Cathode current, average	I_k	max.	15	mA
peak	I_{k_p}	max.	100	mA [1])
Grid resistor, for fixed bias	R_g	max.	1	MΩ
for automatic bias	R_g	max.	3	MΩ
Grid impedance at 50 Hz	Z_g	max.	0.5	MΩ
Cathode to heater voltage	V_{kf}	max.	200	V

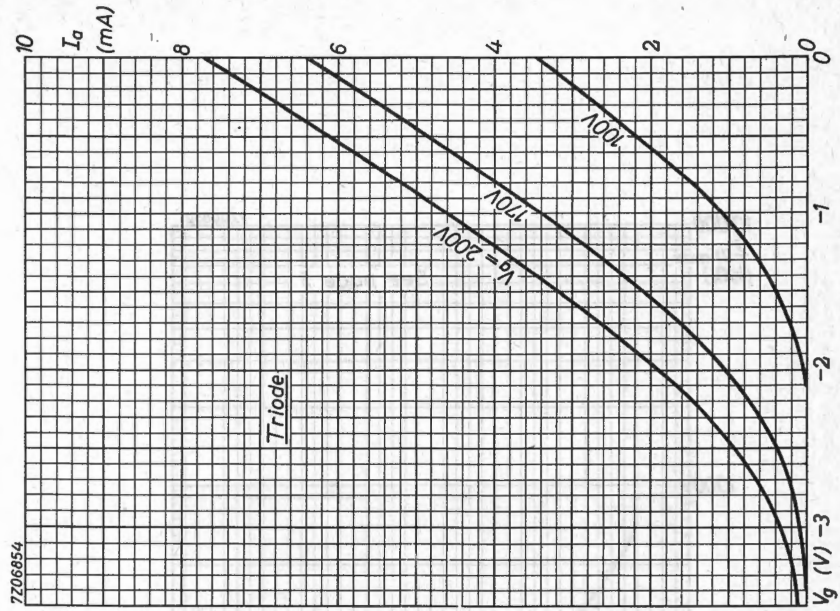
Pentode section

Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	250	V
Anode peak voltage, positive	V_{a_p}	max.	2.5	kV
negative	$-V_{a_p}$	max.	500	V
Grid No.2 voltage	$V_{g_{2o}}$	max.	550	V
	V_{g_2}	max.	250	V
Anode dissipation for frame output application	W_a	max.	5	W
for A.F. output application	W_a	max.	7	W
Grid No.2 dissipation, average	W_{g_2}	max.	1.8	W
average for frame output application (W_a max 4 W)	W_{g_2}	max.	2	W
peak	$W_{g_{2p}}$	max.	3.2	W
Cathode current	I_k	max.	50	mA
Grid No.1 resistor, for fixed bias	R_{g_1}	max.	1	MΩ
for automatic bias	R_{g_1}	max.	2	MΩ
Cathode to heater voltage	V_{kf}	max.	200	V

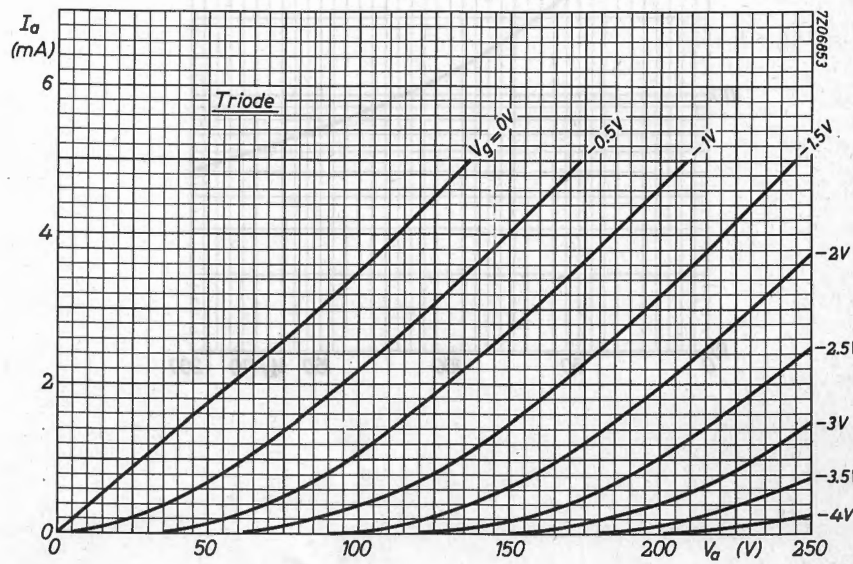
1) Max. pulse duration 4% of a cycle with a maximum of 0.8 msec.


250
I (mA)
200
150
100
50
0
0
−10
−20
V_{g1}(V) −30
I_a
I_{g2}
Pentode
V_a=170V
V_{g2}=170V
7206851

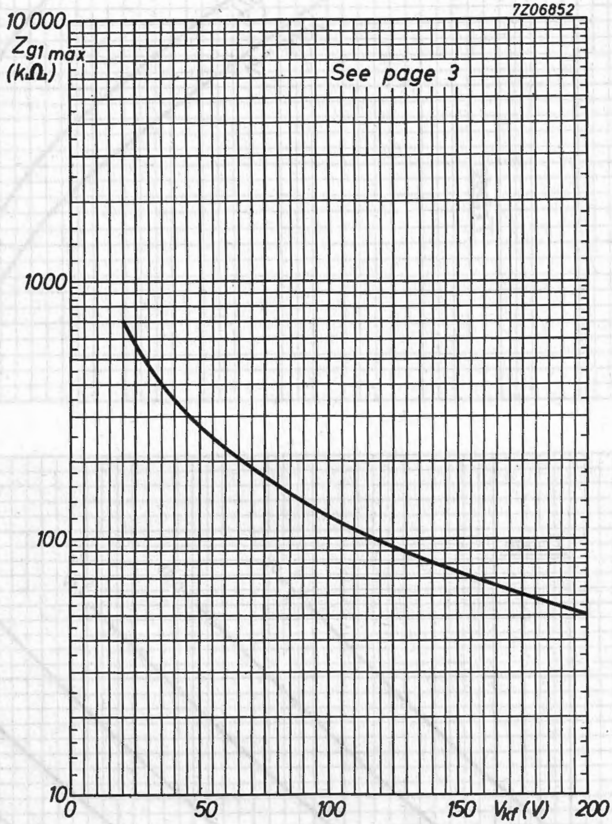

W_a=7W
V_{g1}=0V
I_a (mA)
150
100
50
0
−2V
−4V
−6V
−8V
−10V
−12V
−14V
−16V
−18V
−20V
V_{g2}=170V
7206850
0
100
200
300
400
V_a(V)
500



10
Ia (mA)
8
6
4
2
0
100V
170V
Vg = 200V
Triode
0
-1
-2
-3
Vg (V)
7Z06854



Ia (mA)
6
4
2
0
Triode
Vg = 0V
-0.5V
-1V
-1.5V
-2V
-2.5V
-3V
-3.5V
-4V
0
50
100
150
200
Va (V)
250
7Z06853


7Z06852
10 000
$Z_{g1\,max}$ (kΩ)
See page 3
1000
100
10
0
50
100
150
V_{kf} (V)
200

TRIODE-OUTPUT PENTODE

Triode-pentode with separate cathodes.
Triode section intended for use in circuits for keyed A.G.C., sync. separation, sync. amplification and noise suppression.
Pentode section is intended for use as video output tube.

QUICK REFERENCE DATA			
Triode section			
Anode current	I_a	3	mA
Transconductance	S	4	mA/V
Amplification factor	μ	65	-
Pentode section			
Anode current	I_a	18	mA
Transconductance	S	11	mA/V
Amplification factor	$\mu_{g_2g_1}$	36	-

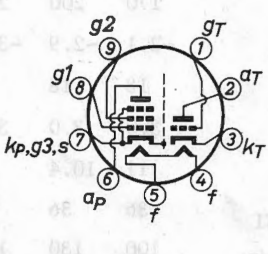
HEATING: Indirect by A.C. or D.C.; series supply

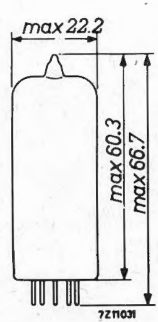
Heater current	I_f	300	mA
Heater voltage	V_f	15	V

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





CAPACITANCES

Triode section

Anode to all except grid	$C_{a(g)}$		2.3	pF
Grid to all except anode	$C_{g(a)}$		3.8	pF
Anode to grid	C_{ag}		2.7	pF
Grid to heater	C_{gf}	max.	0.1	pF

Pentode section

Anode to all except grid No.1	$C_{a(g_1)}$		4.2	pF
Grid No.1 to all except anode	$C_{g_1(a)}$		8.7	pF
Anode to grid No.1	C_{ag_1}	max.	0.1	pF
Grid No.1 to heater	C_{g_1f}	max.	0.1	pF

Between triode and pentode sections

Anode triode to grid No.1 pentode	$C_{a_T g_{1P}}$	max.	0.01	pF
Grid triode to grid No.1 pentode	$C_{g_T g_{1P}}$	max.	0.01	pF

TYPICAL CHARACTERISTICS

Triode section

Anode voltage	V_a	200	V
Grid voltage	V_g	−1.7	V
Anode current	I_a	3	mA
Transconductance	S	4	mA/V
Amplification factor	μ	65	−

Pentode section

Anode voltage	V_a	170	200	220	V
Grid No.2 voltage	V_{g_2}	170	200	220	V
Grid No.1 voltage	V_{g_1}	−2.1	−2.9	−3.4	V
Anode current	I_a	18	18	18	mA
Grid No.2 current	I_{g_2}	3.0	3.0	3.0	mA
Transconductance	S	11	10.4	10	mA/V
Amplification factor	$\mu_{g_2g_1}$	36	36	36	−
Internal resistance	$R_{i\,min}$	100	130	150	kΩ

OPERATING CHARACTERISTICS

Pentode section

Video output tube

Supply voltage	V_b	170	200	220	V
Grid No. 2 voltage	V_{g_2}	170	200	220	V
Anode series resistor	R_a	3	3	3	kΩ
Grid No. 1 voltage	V_{g_1}	-2	-2.8	-3.3	V
Anode current	I_a	18	18	18	mA
Grid No. 2 current	I_{g_2}	3.2	3.1	3.1	mA
Transconductance	S	10.4	10.0	9.7	mA/V

LIMITING VALUES (Design centre rating system)

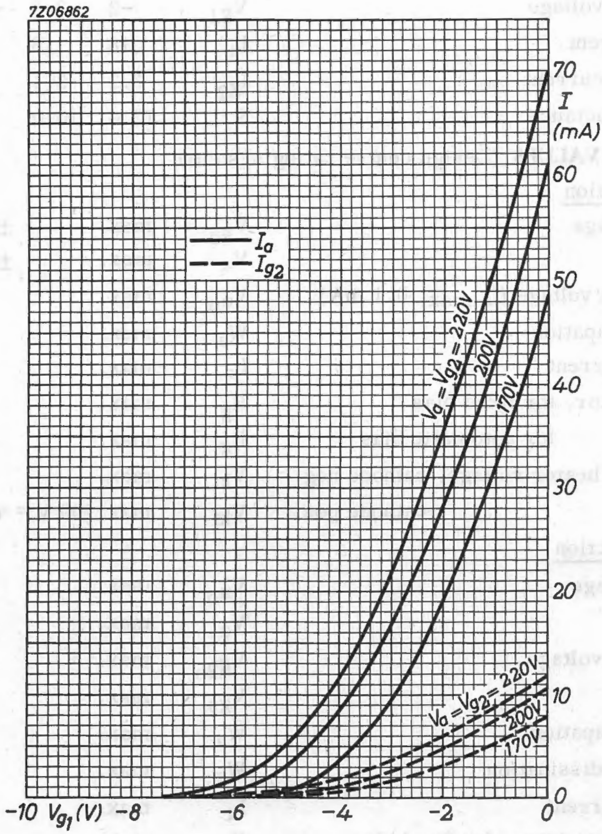
Triode section

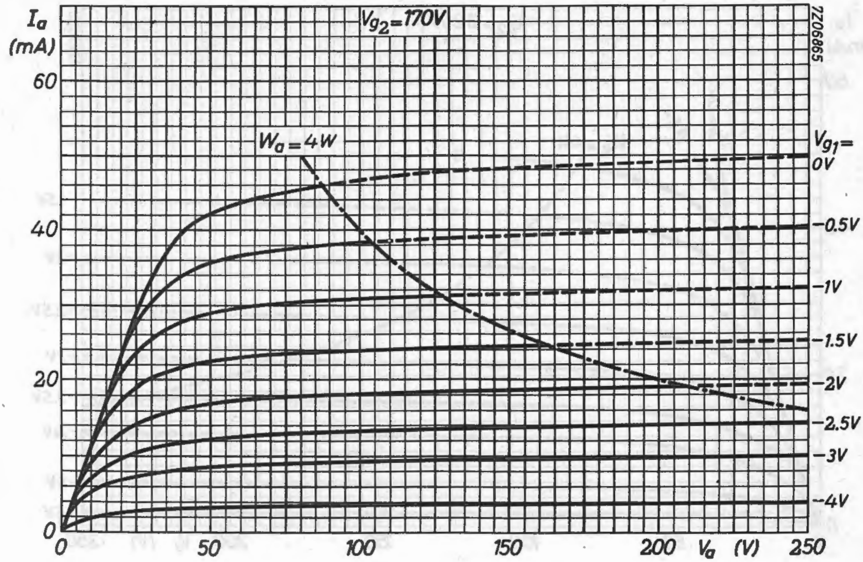
Anode voltage	V_{a_o}	max.	±550	V
	V_a	max.	±300	V
Anode peak voltage (I_a max. 0.1 mA)	V_{a_p}	max.	600	V [1])
Anode dissipation	W_a	max.	1	W
Cathode current	I_k	max.	12	mA
Grid resistor, for fixed bias	R_g	max.	1	MΩ
for automatic bias	R_g	max.	3	MΩ
Cathode to heater voltage, cathode neg.	V_{kf}	max.	150	V
cathode pos.	V_{kf}	max. 200 V =	+150	V_{RMS}

Pentode section

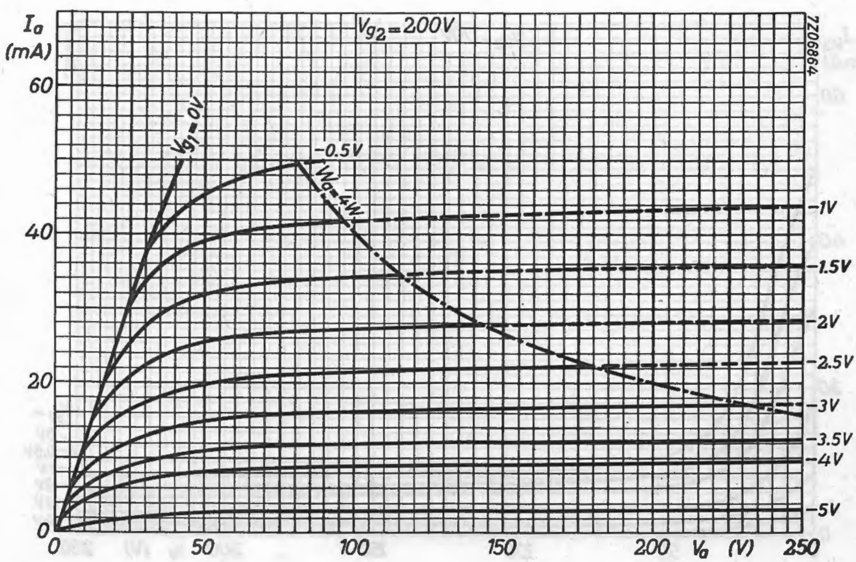
Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	300	V
Grid No. 2 voltage	$V_{g_{2o}}$	max.	550	V
	V_{g_2}	max.	250	V
Anode dissipation	W_a	max.	4	W
Grid No. 2 dissipation	W_{g_2}	max.	1.7	W
Cathode current	I_k	max.	40	mA
Grid No. 1 resistor, for fixed bias	R_{g_1}	max.	1	MΩ
for automatic bias	R_{g_1}	max.	2	MΩ
Cathode to heater voltage	V_{kf}	max.	200	V

[1]) Max. pulse duration 18% of a cycle with a maximum of 18 μsec.

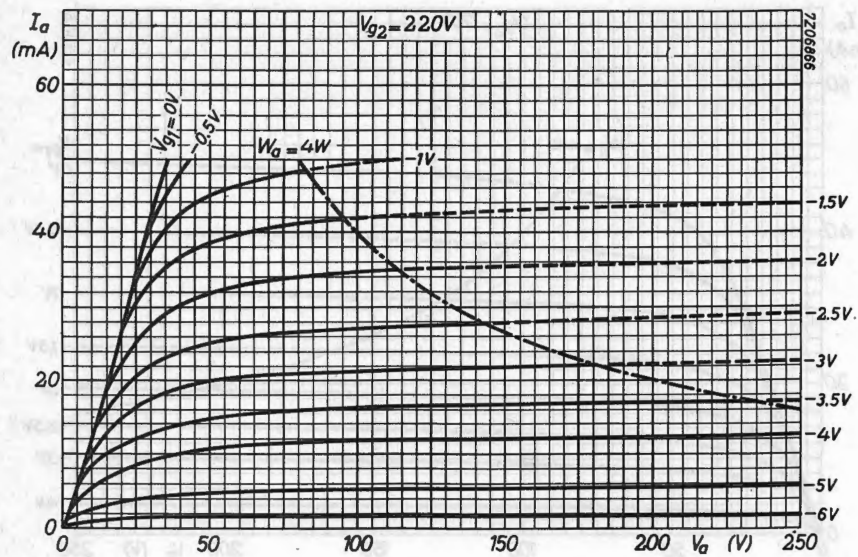

7Z06862
70
I
(mA)
60
50
40
30
20
10
0
I_a
I_{g2}
$V_a = V_{g2} = 220V$
200V
170V
$V_a = V_{g2} = 220V$
200V
170V
−10
V_{g1} (V)
−8
−6
−4
−2
0

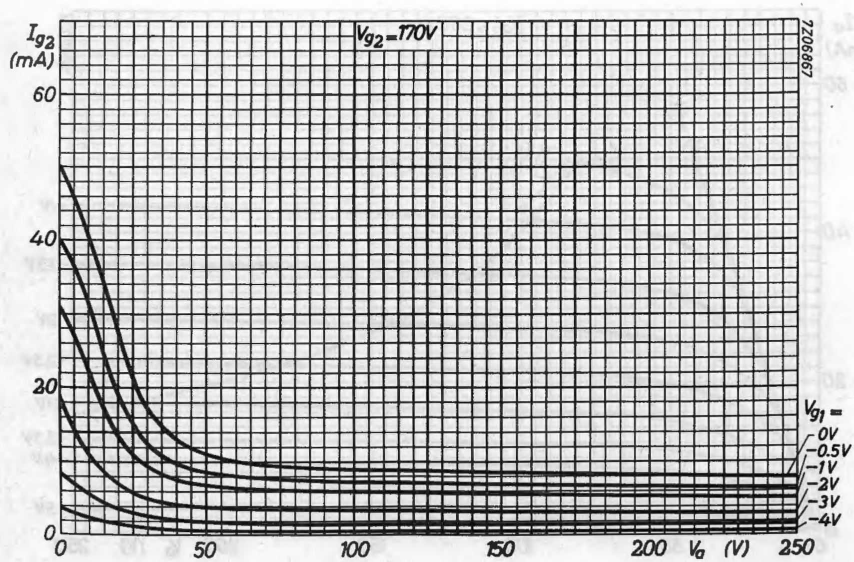


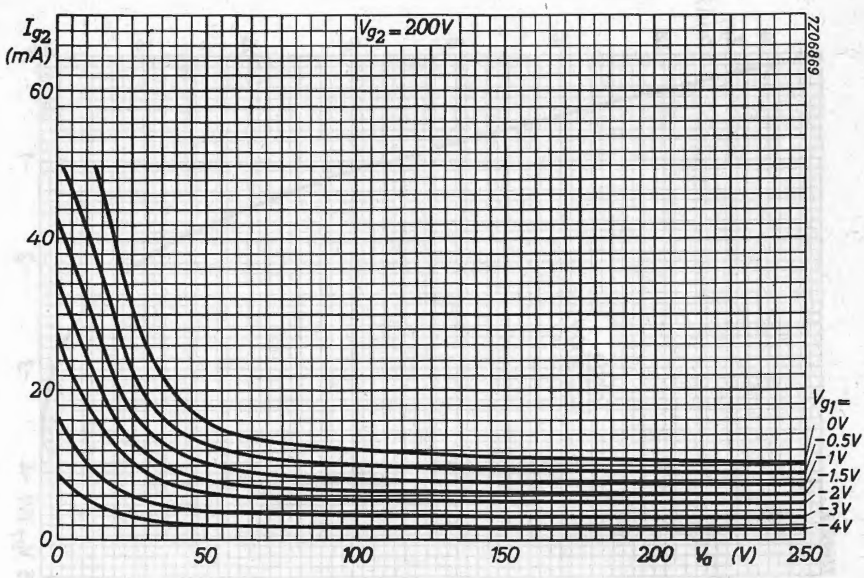
I_a (mA)
V_{g2}=170V
7Z06865
W_a=4W
V_{g1}= 0V
−0.5V
−1V
−1.5V
−2V
−2.5V
−3V
−4V
0
20
40
60
50
100
150
200
V_a (V)
250

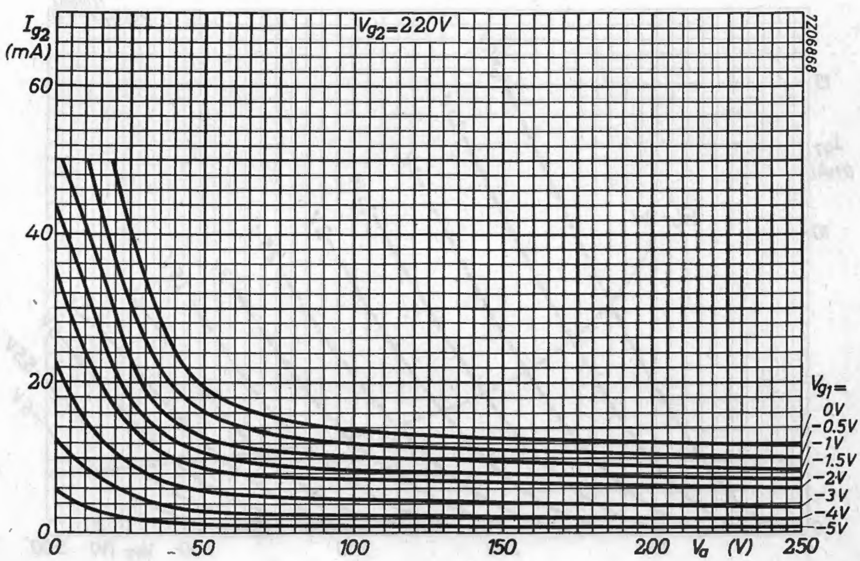


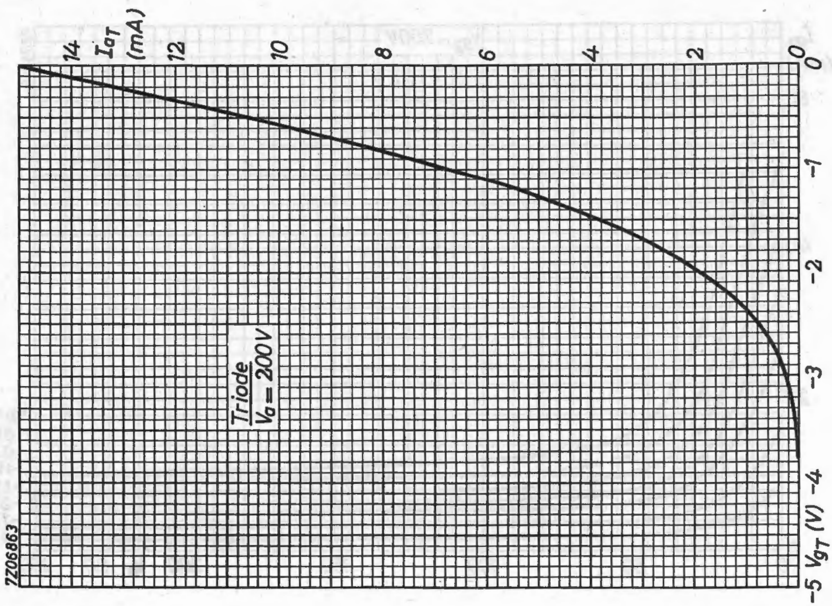
I_a (mA)
V_{g2}=200V
7Z06864
V_{g1}=0V
−0.5V
W_a=4W
−1V
−1.5V
−2V
−2.5V
−3V
−3.5V
−4V
−5V
0
20
40
60
50
100
150
200
V_a (V)
250

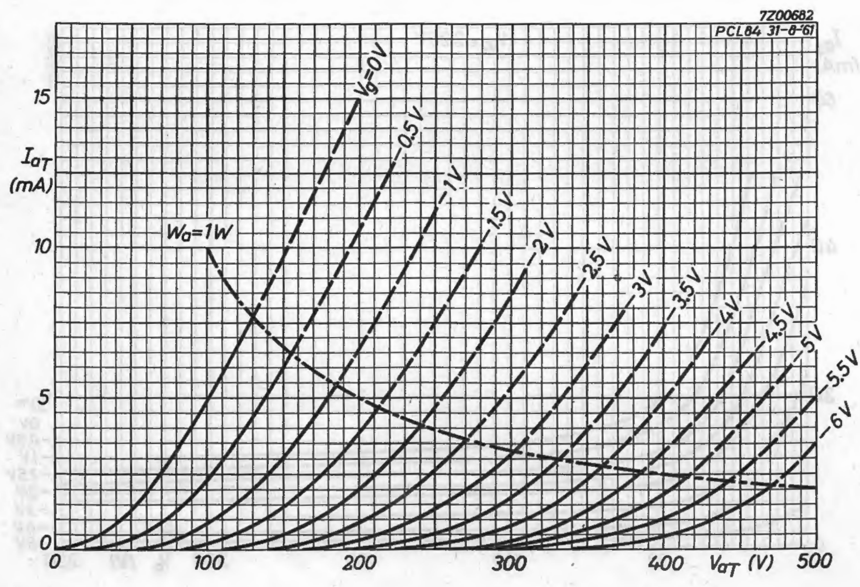

Ia (mA)
Vg2=220V
7206866
Vg1=0V
-0.5V
Wa=4W
-1V
-1.5V
-2V
-2.5V
-3V
-3.5V
-4V
-5V
-6V
60
40
20
0
0
50
100
150
200
Va (V)
250


Ig2 (mA)
Vg2=170V
7206867
Vg1 =
0V
-0.5V
-1V
-2V
-3V
-4V
60
40
20
0
0
50
100
150
200
Va (V)
250


I_{g2} (mA)
60
40
20
0
V_{g2} = 200V
7Z06869
V_{g1}=
0V
−0.5V
−1V
−1.5V
−2V
−3V
−4V
0
50
100
150
200
V_a (V)
250


I_{g2} (mA)
60
40
20
0
V_{g2} = 220V
7Z06868
V_{g1}=
0V
−0.5V
−1V
−1.5V
−2V
−3V
−4V
−5V
0
50
100
150
200
V_a (V)
250


14
I_{aT}
(mA)
12
10
8
6
4
2
0
0
-1
-2
-3
-4
-5 V_{gT} (V)
Triode
V_a = 200V
7Z06863


7Z00682
PCL84 31-8-'61
I_{aT}
(mA)
15
10
5
0
V_g=0V
-0.5V
-1V
-1.5V
-2V
-2.5V
-3V
-3.5V
-4V
-4.5V
-5V
-5.5V
-6V
W_a=1W
0
100
200
300
400
V_{aT} (V)
500

TRIODE-FRAME OUTPUT PENTODE

Triode-pentode with separate cathodes. Triode intended for use as frame oscillator or pulse amplifier.
Pentode intended for use as frame output tube.

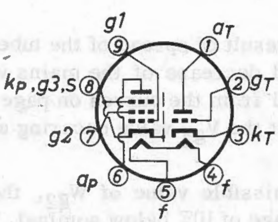
QUICK REFERENCE DATA				
Triode section				
Anode current	I_a		10.5	mA
Transconductance	S		7	mA/V
Amplification factor	μ		63	–
Cathode peak current	I_{kp}	max.	150	mA
Pentode section				
Anode peak voltage	V_{a_p}	max.	2	kV
Cathode current	I_k	max.	75	mA
Anode dissipation	W_a	max.	8	W

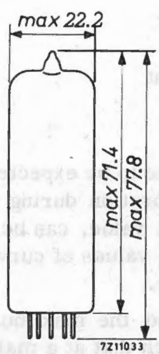
HEATING: Indirect by A.C. or D.C.; series supply

Heater current	I_f	300	mA
Heater voltage	V_f	17.5	V

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Noval





CAPACITANCES

Grid triode to anode pentode	$C_{g_Ta_p}$	max.	0.05	pF
Grid triode to heater	C_{g_Tf}	max.	0.15	pF
Grid No. 1 pentode to anode pentode	$C_{g_{1p}a_p}$	max.	1.0	pF
Grid No. 1 pentode to anode triode	$C_{g_{1p}a_T}$	max.	0.08	pF
Grid No. 1 pentode to heater	$C_{g_{1p}f}$	max.	0.20	pF

TYPICAL CHARACTERISTICS

Triode section

Anode voltage	V_a	100	100	V
Grid voltage	V_g	-0.85	0	V
Anode current	I_a	5	10.5	mA
Transconductance	S	5.5	7.0	mA/V
Amplification factor	μ	60	63	–
Internal resistance	R_i	11	9	kΩ

OPERATING CHARACTERISTICS

Pentode section

Frame output application

Anode voltage	V_a	50	65	V
Grid No. 2 voltage	V_{g_2}	170	210	V
Grid No. 1 voltage	V_{g_1}	-1	-1	V
Anode peak current	I_{a_p}	200	285	mA
Grid No. 2 peak current	$I_{g_{2p}}$	35	45	mA

Remarks

The minimum I_{a_p} value to be expected as a result of spread of the tube characteristics, tube deterioration during life and decrease of the mains voltage to 10% below the nominal value, can be derived from the curves on page 9 by decreasing by 40% the I_a values of curve A-B at the V_{g_2} value occuring at the decreased mains voltage.

In order not to exceed the maximum permissible value of W_{g2}, the circuit should be designed such that at a mains voltage of 10% below nominal, V_a at the end of scan will not be lower than the value determined by curve A-B at the relevant V_{g_2} value.

HUM

The equivalent pentode grid hum voltage without negative feedback is max. 10 mV when Z_{g_1} (at f = 50 Hz) ≤ 0.5 MΩ, C_{g_1-f} = 0.2 pF and V_{kf} = 150 V_{RMS}.

LIMITING VALUES (Design centre rating system)

Triode section

Anode voltage	V_{a_o}	max.	550	V	
	V_a	max.	300	V	
Anode dissipation	W_a	max.	0.5	W	
Cathode current					
average	I_k	max.	15	mA	
peak	I_{k_p}	max.	150	mA	1)
peak	I_{k_p}	max.	100	mA	2)
Grid resistor					
for fixed bias	R_g	max.	1	MΩ	
for automatic bias	R_g	max.	3.3	MΩ	
Cathode to heater voltage	V_{kf}	max.	200	V	3)

Remark

A cathode peak current of 100 mA will be available throughout life and at under-heating.

1) Max. pulse duration 2% of a cycle with a maximum of 400 μsec.

2) Max. pulse duration 4% of a cycle with a maximum of 800 μsec.

3) During warming up the D.C. component of V_{kf} = max. 315 V, k pos.

LIMITING VALUES (continued)

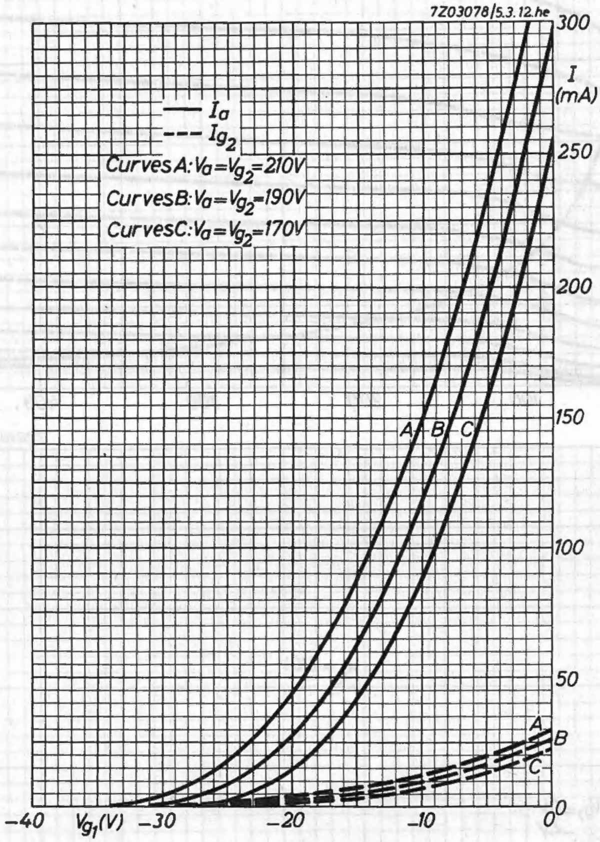
Pentode section

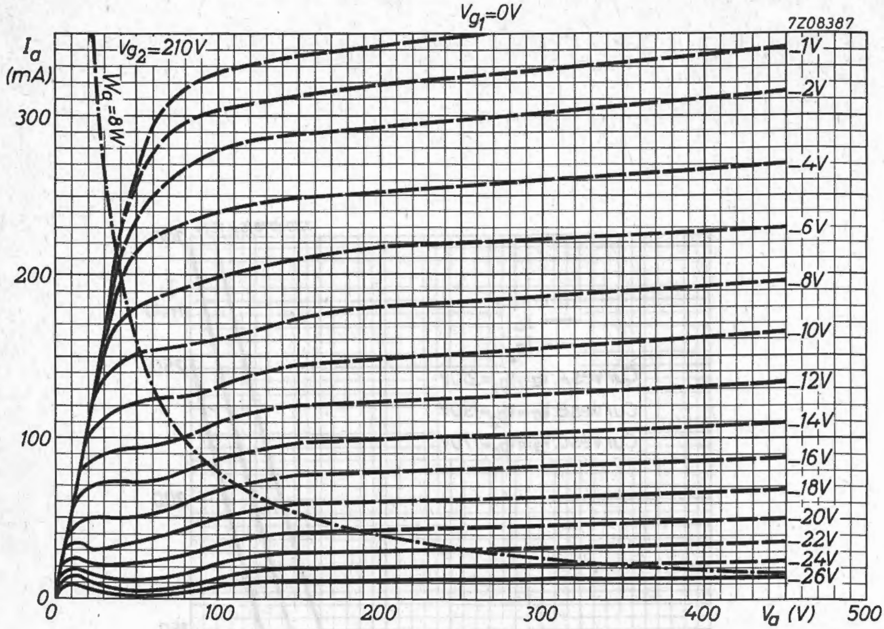
Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	300	V
Anode peak voltage	V_{a_p}	max.	2	kV[1]
Grid No. 2 voltage	$V_{g_{2o}}$	max.	550	V
	V_{g_2}	max.	250	V
Anode dissipation	W_a	max.	8	W [2]
Grid No. 2 dissipation	W_{g_2}	max.	1.5	W [3]
Cathode current	I_k	max.	75	mA
Grid No. 1 resistor				
for fixed bias	R_{g_1}	max.	1.0	MΩ
for automatic bias	R_{g_1}	max.	2.2	MΩ
Cathode to heater voltage	V_{kf}	max.	200	V

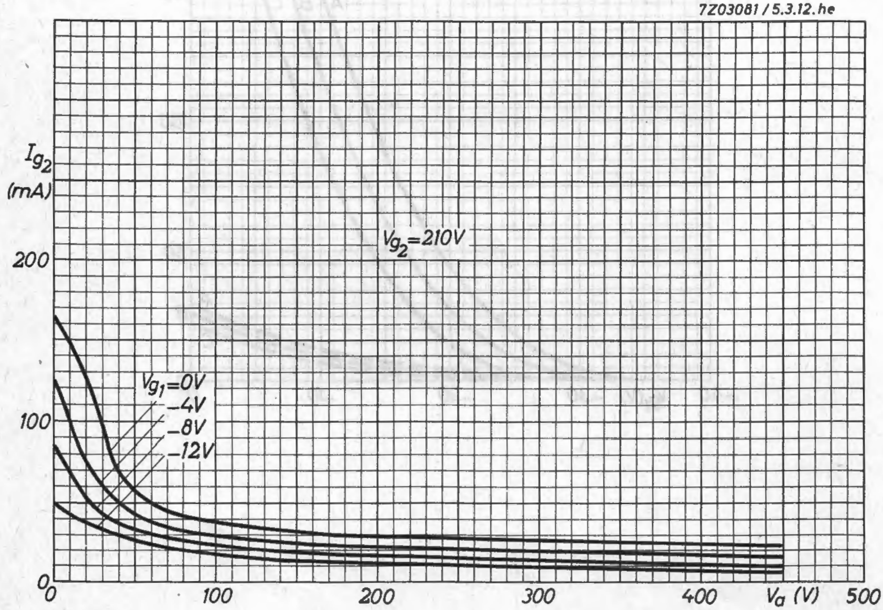
[1]) Max. pulse duration 5% of a cycle with a maximum of 1 ms.

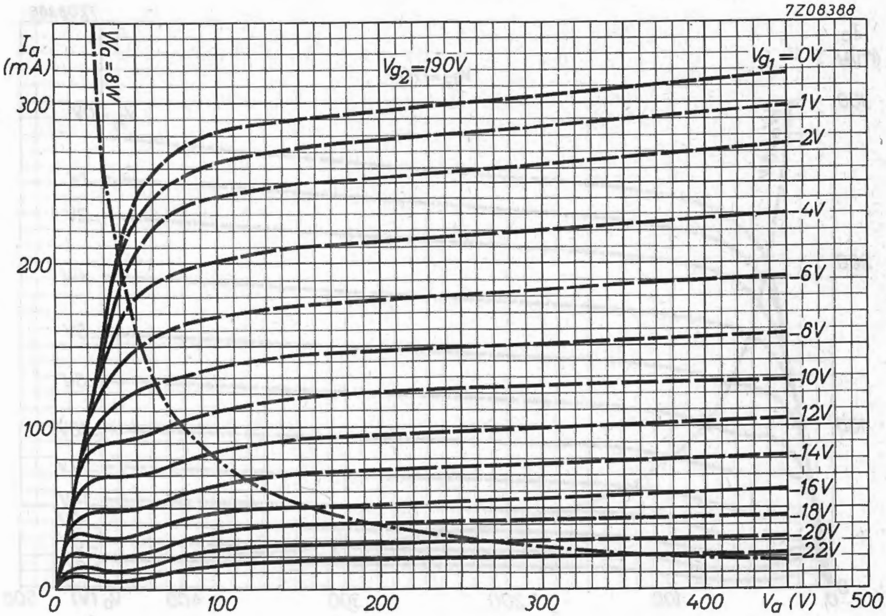
[2]) For a nominal tube at the worst probable operating conditions and at normal picture height W_a should not exceed 10.5 W.

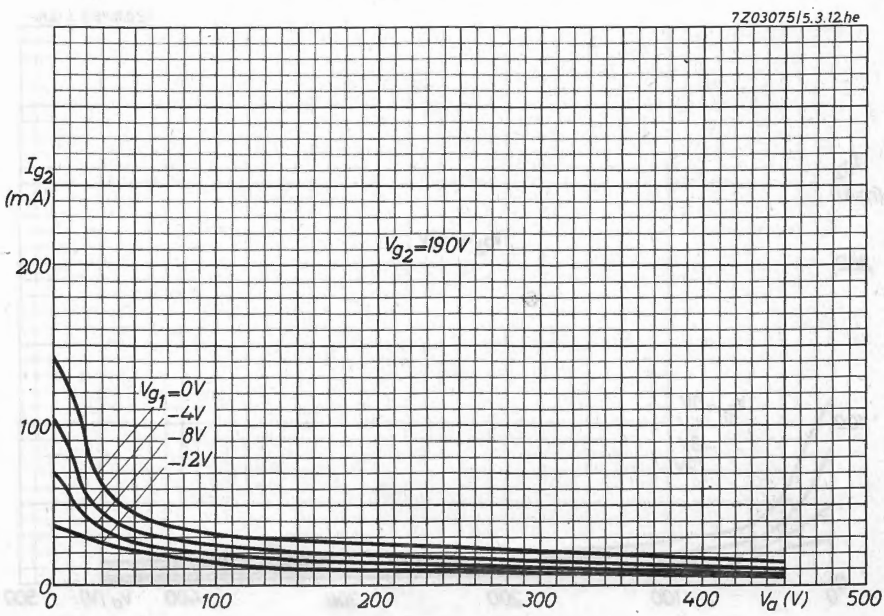
[3]) For a nominal tube at the worst probable operating conditions and at normal picture height W_{g_2} should not exceed 2 W.

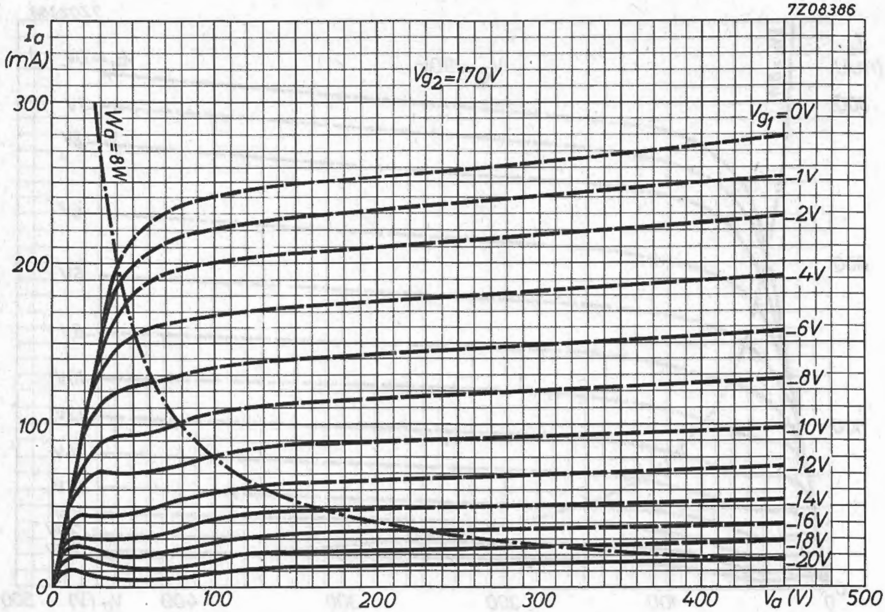

7Z03078/5.3.12.he
I (mA)
300
250
200
150
100
50
0
— I_a
--- I_{g_2}
Curves A: $V_a = V_{g_2} = 210V$
Curves B: $V_a = V_{g_2} = 190V$
Curves C: $V_a = V_{g_2} = 170V$
A B C
A
B
C
−40
V_{g_1}(V)
−30
−20
−10
0

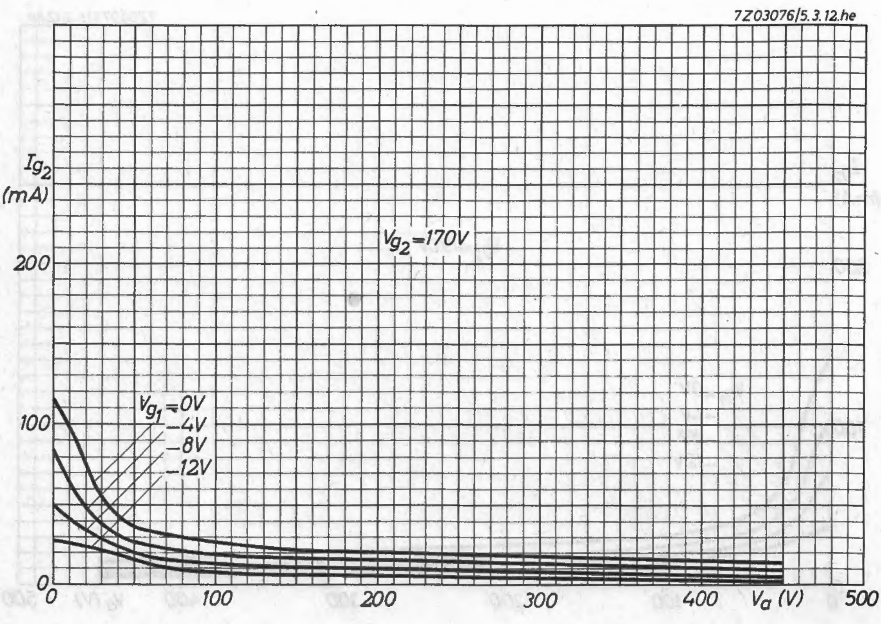

7Z08387
V_{g1}=0V
V_{g2}=210V
W_a=8W
I_a (mA)
-1V
-2V
-4V
-6V
-8V
-10V
-12V
-14V
-16V
-18V
-20V
-22V
-24V
-26V
0
100
200
300
400
500
V_a (V)
7Z03081 / 5.3.12.he

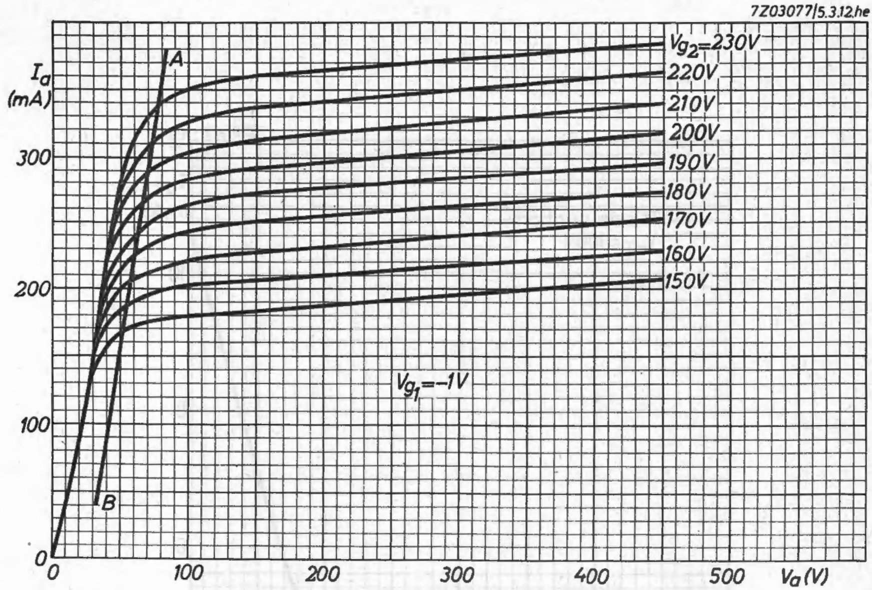

I_{g2} (mA)
V_{g2}=210V
V_{g1}=0V
-4V
-8V
-12V
0
100
200
300
400
500
V_a (V)

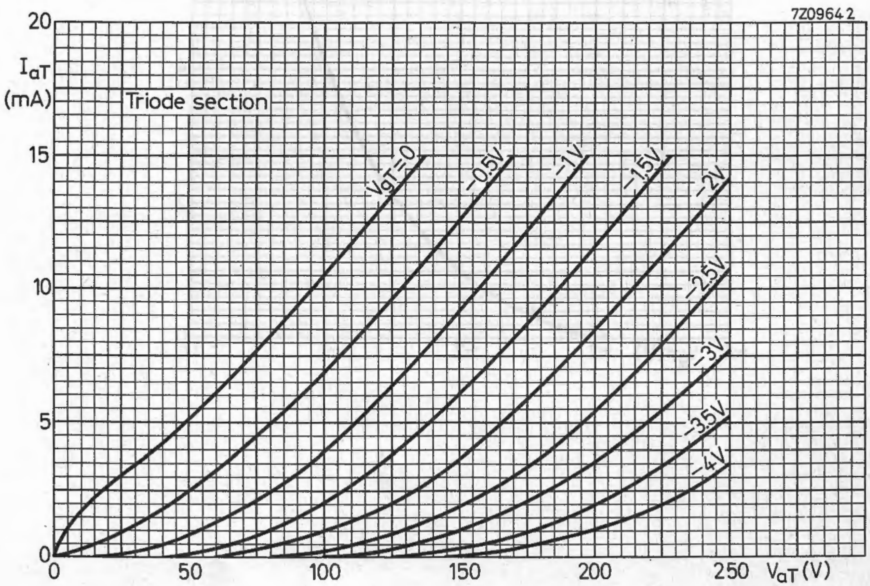

7Z08388
I_a (mA)
300
200
100
0
$W_a = 8W$
V_{g_2}=190V
V_{g_1}=0V
-1V
-2V
-4V
-6V
-8V
-10V
-12V
-14V
-16V
-18V
-20V
-22V
0
100
200
300
400
V_a (V)
500

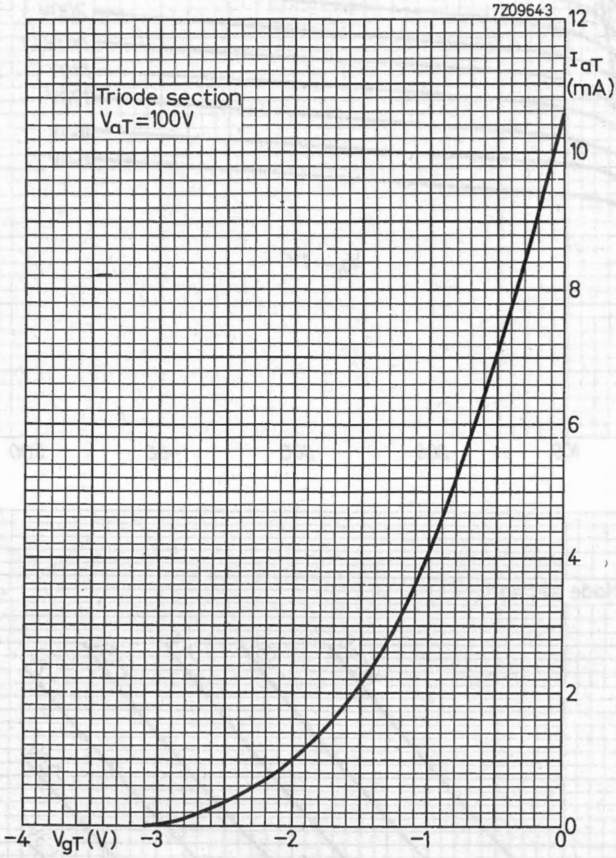

7Z03075/5.3.12.he
I_{g_2} (mA)
200
100
0
V_{g_2}=190V
V_{g_1}=0V
-4V
-8V
-12V
0
100
200
300
400
V_a (V)
500


7Z08386
I_a (mA)
V_{g_2}=170V
W_a=8W
V_{g_1}=0V
-1V
-2V
-4V
-6V
-8V
-10V
-12V
-14V
-16V
-18V
-20V
0
100
200
300
400
V_a (V)
500


7Z03076/5.3.12.he
I_{g_2} (mA)
V_{g_2}=170V
V_{g_1}=0V
-4V
-8V
-12V
0
100
200
300
400
V_a (V)
500


7Z03077/5.3.12.he
I_a (mA)
300
200
100
0
0
100
200
300
400
500
V_a (V)
A
B
V_{g_2}=230V
220V
210V
200V
190V
180V
170V
160V
150V
V_{g_1}=−1V


7Z09642
20
I_{aT} (mA)
Triode section
15
10
5
0
0
50
100
150
200
250
V_{aT} (V)
V_{gT}=0
−0.5V
−1V
−1.5V
−2V
−2.5V
−3V
−3.5V
−4V


7Z09643
Triode section
V_{aT}=100V
I_{aT}
(mA)
12
10
8
6
4
2
0
−4
V_{gT}(V)
−3
−2
−1
0

TRIODE-OUTPUT PENTODE

Triode-pentode with separate cathodes.
The triode section is intended for use as A.F. amplifier.
The pentode section is intended for use as A.F. power amplifier.

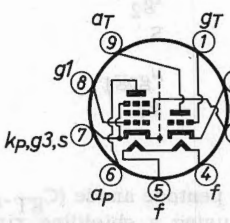
QUICK REFERENCE DATA			
Triode section			
Anode current	I_a	1.2	mA
Transconductance	S	1.6	mA/V
Amplification factor	μ	100	-
Pentode section			
Anode current	I_a	39	mA
Transconductance	S	10.5	mA/V
Amplification factor	μ_{g2g1}	21	-
Output power	W_o	4.1	W

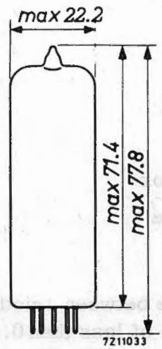
HEATING: Indirect by A.C. or D.C.; series supply

Heater current	I_f	300	mA
Heater voltage	V_f	13.3	V

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Noval





CAPACITANCES

Triode section				
Anode to all except grid	$C_{a(g)}$		2.5	pF
Grid to all except anode	$C_{g(a)}$		2.3	pF
Anode to grid	C_{ag}		1.4	pF
Grid to heater	C_{gf}	max.	0.006	pF
Pentode section				
Grid No. 1 to all except anode	$C_{g_1(a)}$		10	pF
Anode to grid No. 1	C_{ag_1}	max.	0.4	pF
Grid No. 1 to heater	C_{g_1f}	max.	0.24	pF
Between triode and pentode sections				
Anode triode to grid No. 1 pentode	$C_{a_Tg_{1P}}$	max.	0.2	pF
Grid triode to grid No. 1 pentode	$C_{g_Tg_{1P}}$	max.	0.02	pF
Anode triode to anode pentode	$C_{a_Ta_P}$	max.	0.15	pF
Grid triode to anode pentode	$C_{g_Ta_P}$	max.	0.006	pF [1]

TYPICAL CHARACTERISTICS

Triode section			
Anode voltage	V_a	230	V
Grid voltage	V_g	-1.7	V
Anode current	I_a	1.2	mA
Transconductance	S	1.6	mA/V
Amplification factor	μ	100	
Pentode section			
Anode voltage	V_a	230	V
Grid No. 2 voltage	V_{g_2}	230	V
Grid No. 1 voltage	V_{g_1}	-5.7	V
Anode current	I_a	39	mA
Grid No. 2 current	I_{g_2}	6.5	nA
Transconductance	S	10.5	mA/V
Amplification factor	$\mu_{g_2g_1}$	21	
Internal resistance	R_i	45	kΩ

[1]) The capacitance between triode grid and pentode anode (C_{g_T}-a_P) can be reduced to a value of less than 0.002 pF by using a shielding ring with a diameter of 22.5 mm and a height of 15 mm with respect to the tube base.

OPERATING CHARACTERISTICS

Triode section

A.F. amplifier

Supply voltage	V_b	200	230	200	230	V
Cathode resistor	R_k	0	0	2.6	2.1	kΩ
Anode resistor	R_a	220	220	220	220	kΩ
Grid resistor	R_g	10	10	-	-	MΩ
Grid resistor of following stage	R_g'	680	680	680	680	kΩ
Signal source resistance	R_s	47	47	-	-	kΩ
Anode current	I_a	0.42	0.52	0.42	0.52	mA
Output voltage	V_o	3.2	3.2	3.2	3.2	V_{RMS}
Voltage gain	V_o/V_i	66	68	66	68	
Distortion	d_{tot}	0.6	0.5	0.6	0.5	%

Microphony

The triode section can be used without special precautions against microphonic effect in circuits in which an output of 50 mW is obtained at an input voltage of not less than 10 mV_{RMS}.

Hum

The hum level will be better than 60 dB under the following conditions;
Input voltage minimum 10 mV_{RMS} for 50 mW output.
Grid circuit impedance max. 0.5 MΩ at 50 Hz.
Cathode decoupling capacitor minimum 100 μF.
Pin 4 connected to earth.
A.C. voltage between pin 4 and cathode max. 30 V_{RMS}.

OPERATING CHARACTERISTICS

Pentode section

Class A (Measured with V_k constant)

Anode voltage	V_a		200			230			V
Grid No. 2 voltage	V_{g2}		200			230			V
Cathode resistor	R_k		115			125			Ω
(Grid No. 1 voltage)	V_{g1}		-4.7			-5.7			V)
Load resistance	$R_{a\sim}$		5.6			5.1			kΩ
Grid No. 1 driving voltage	V_i	0	0.32	3.2	0	0.34	3.6		V_{RMS}
Anode current	I_a	35	-	34	39	-	40.7		mA
Grid No. 2 current	I_{g2}	6.0	-	9.0	6.5	-	10.5		mA
Output power	W_o	0	0.05	3.1	0	0.05	4.1		W
Distortion	d_{tot}	-	0.9	10	-	0.9	10		%

LIMITING VALUES (Design centre rating system)

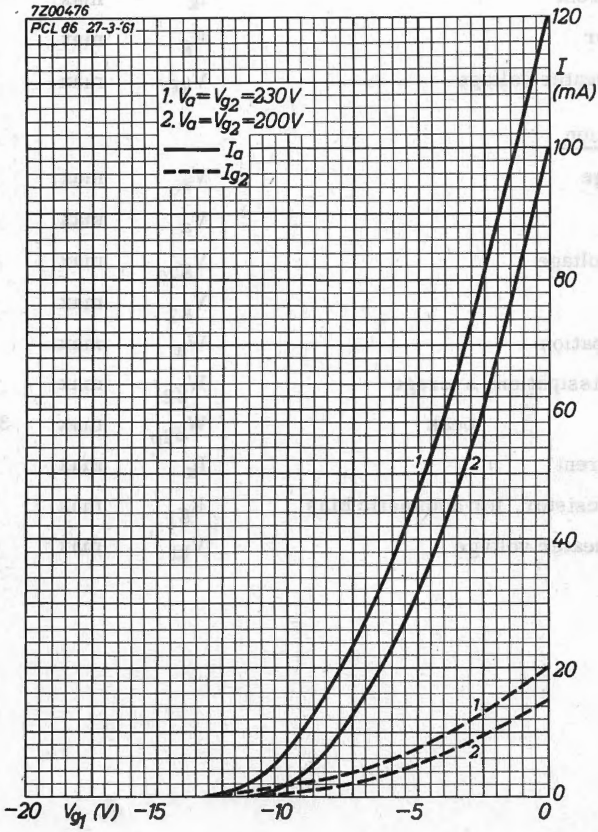
Triode section

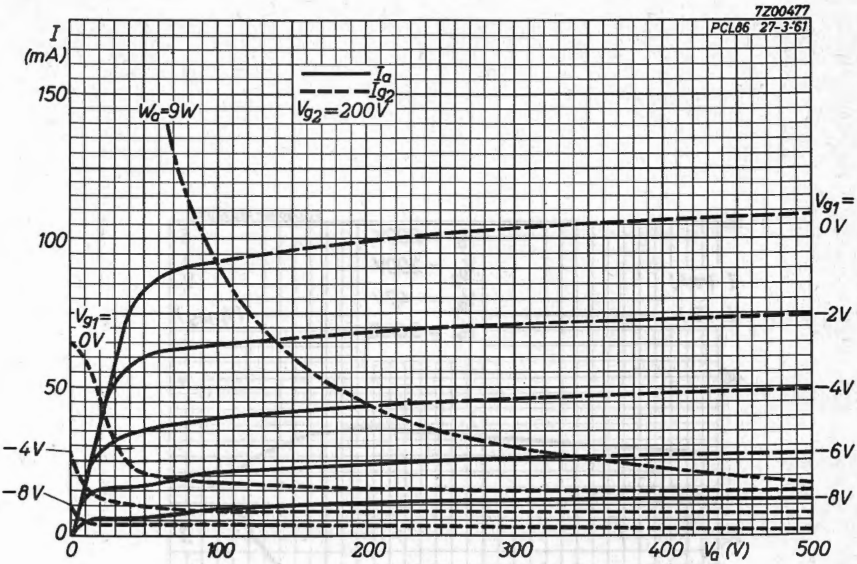
Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	300	V
Anode dissipation	W_a	max.	0.5	W
Cathode current	I_k	max.	4	mA
Grid resistor	R_g	max.	1	MΩ [1]
Cathode to heater voltage	V_{kf}	max.	100	V

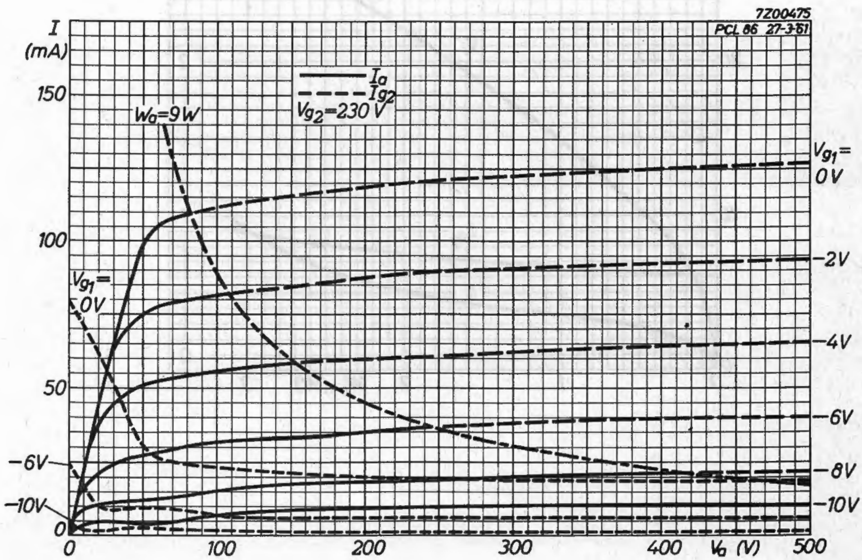
Pentode section

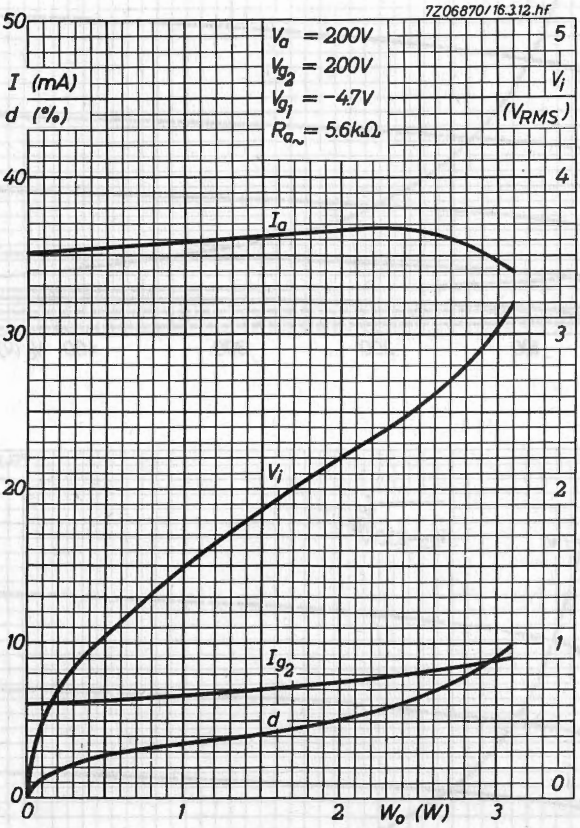
Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	300	V
Grid No. 2 voltage	$V_{g_{2o}}$	max.	550	V
	V_{g_2}	max.	300	V
Anode dissipation	W_a	max.	9	W
Grid No. 2 dissipation, average	W_{g_2}	max.	1.8	W
peak	$W_{g_{2p}}$	max.	3.25	W
Cathode current	I_k	max.	55	mA
Grid No. 1 resistor, for automatic bias	R_{g_1}	max.	1	MΩ
Cathode to heater voltage	V_{kf}	max.	100	V

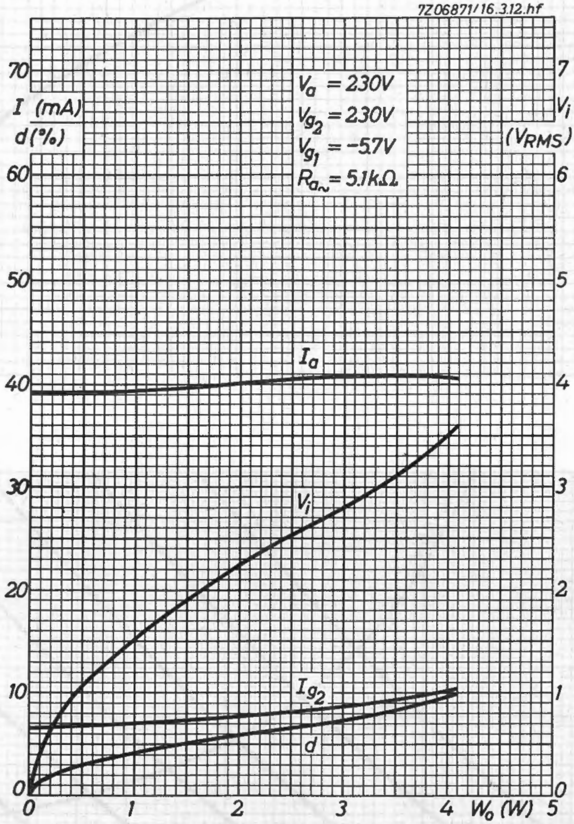
[1]) This value applies to operation with fixed bias. It may be multiplied by the D.C. inverse feedback factor resulting from e.g. cathode or anode resistors to a maximum of 10 MΩ.

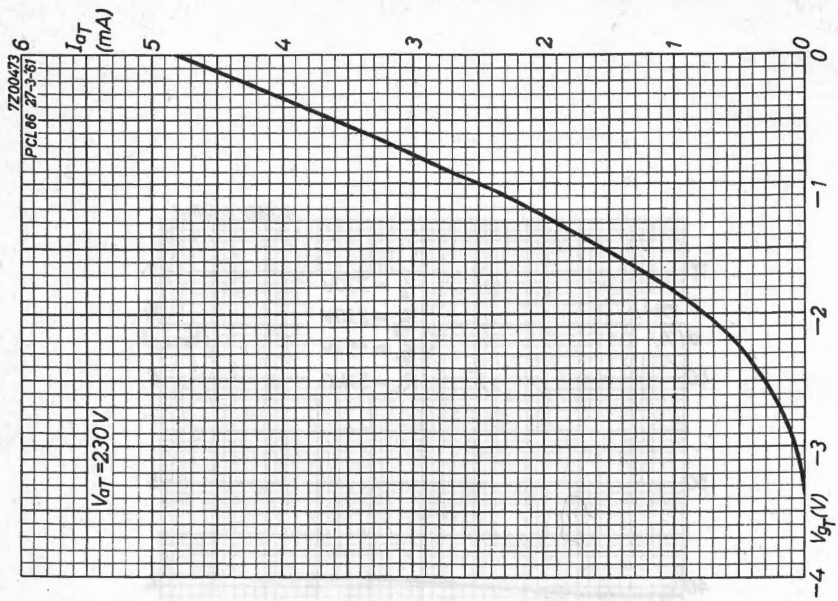

7Z00476
PCL 86 27-3-'61
1. Va=Vg2=230V
2. Va=Vg2=200V
Ia
Ig2
I
(mA)
120
100
80
60
40
20
0
1
2
1
2
-20
Vg1 (V)
-15
-10
-5
0

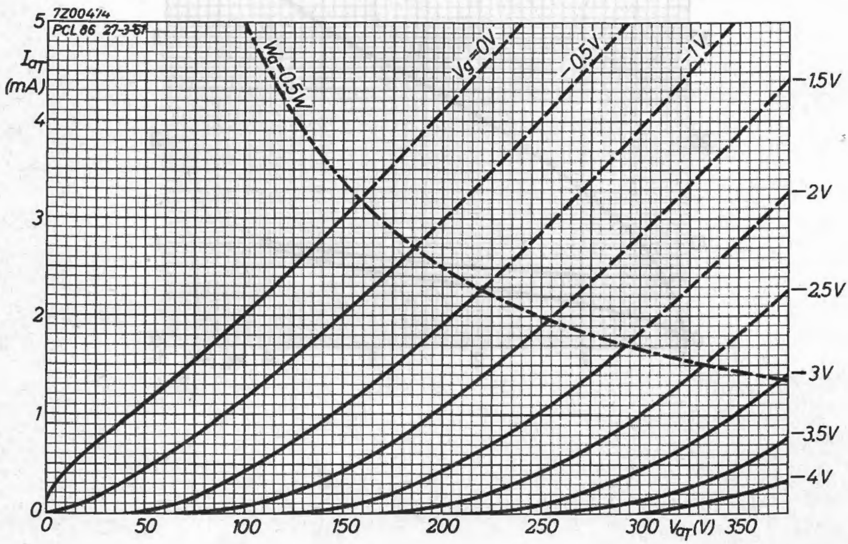

7Z00477
PCL86 27-3-'61
I (mA)
150
100
50
0
I_a
I_{g2}
V_{g2}=200V
W_a=9W
V_{g1}= 0V
-4V
-8V
V_{g1}= 0V
-2V
-4V
-6V
-8V
0
100
200
300
400
V_a (V)
500


7Z00475
PCL 86 27-3-'61
I (mA)
150
100
50
0
I_a
I_{g2}
V_{g2}=230 V
W_a=9W
V_{g1}= 0V
-6V
-10V
V_{g1}= 0V
-2V
-4V
-6V
-8V
-10V
0
100
200
300
400
V_a (V)
500


7Z06870/16.3.12.hf
$V_a = 200V$
$V_{g_2} = 200V$
$V_{g_1} = -4.7V$
$R_{a\sim} = 5.6k\Omega$
I (mA)
d (%)
V_i (V_{RMS})
I_a
V_i
I_{g_2}
d
W_o (W)
50
40
30
20
10
0
5
4
3
2
1
0
1
2
3


7Z06871/16.3.12.hf
I (mA)
d(%)
$V_a = 230V$
$V_{g_2} = 230V$
$V_{g_1} = -5.7V$
$R_{a\sim} = 5.1k\Omega$
V_i
(V_{RMS})
I_a
V_i
I_{g_2}
d
W_o (W)
0
10
20
30
40
50
60
70
1
2
3
4
5
6
7


7Z00473
PCL 86 27-3-'61
I_{a_T} (mA)
6
5
4
3
2
1
0
V_{a_T} = 230 V
0
−1
−2
−3
−4
V_{g_T} (V)


7Z00474
PCL 86 27-3-'61
I_{a_T} (mA)
5
4
3
2
1
0
W_a = 0.5 W
V_g = 0 V
−0.5 V
−1 V
−1.5 V
−2 V
−2.5 V
−3 V
−3.5 V
−4 V
0
50
100
150
200
250
300
V_{a_T} (V)
350

SHUNT STABILIZER TRIODE

Shunt stabilizer triode intended for use as in colour TV receivers.

QUICK REFERENCE DATA				
Anode voltage	V_a		25	kV
Anode current	I_a	max.	1.6	mA

HEATING: Indirect by A.C. or D.C.; series supply

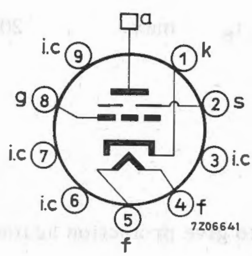
Heater current	I_f	300	mA
Heater voltage	V_f	7.3	V

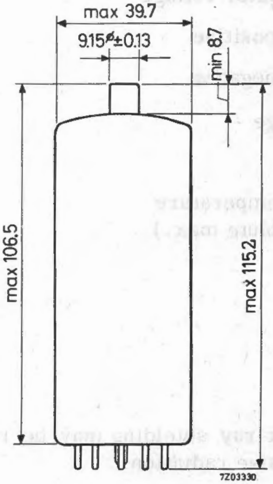
DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Magnoval

Top cap: Type 2





Mounting: Additional supporting of the tube at the top is required.
To prevent corona-effects any metal screening applied around the tube should be at least 5 cm from the nearest point of the bulb.
Adequate ventilation should be provided for.

TYPICAL CHARACTERISTICS

Anode voltage	V_a		25	kV
Screen voltage	V_s		0	V
Grid voltage change for an anode current change from 0.1 to 1.5 mA	ΔV_g	max.	10	V
Grid voltage at I_a = 1.5 mA	V_g		−7 to −30	V
at I_a = 0.1 mA	V_g	max.	−40	V

LIMITING VALUES (Design centre rating system unless otherwise specified)

Anode voltage	V_a	max.	25	kV
Anode voltage (absolute max.)	V_a	max.	27.5	kV 1)
Anode current	I_a	max.	1.6	mA
Anode dissipation	W_a	max.	30	W
Anode dissipation (absolute max.)	W_a	max.	40	W 2)
Negative grid voltage	$-V_g$	max.	150	V 3)
Grid resistor	R_g	max.	5	MΩ
Cathode to heater voltage				
cathode positive	V_{kf}	max.	400 V_{DC} +250	V_{AC}
cathode negative	$-V_{kf}$	max.	250	V
Screen voltage	V_s	max.	0	V
	$-V_s$	max.	400	V 4)
Anode seal temperature (absolute max.)	t_s	max.	200	°C

Precaution: x-ray shielding may be required to give protection against excessive radiation.

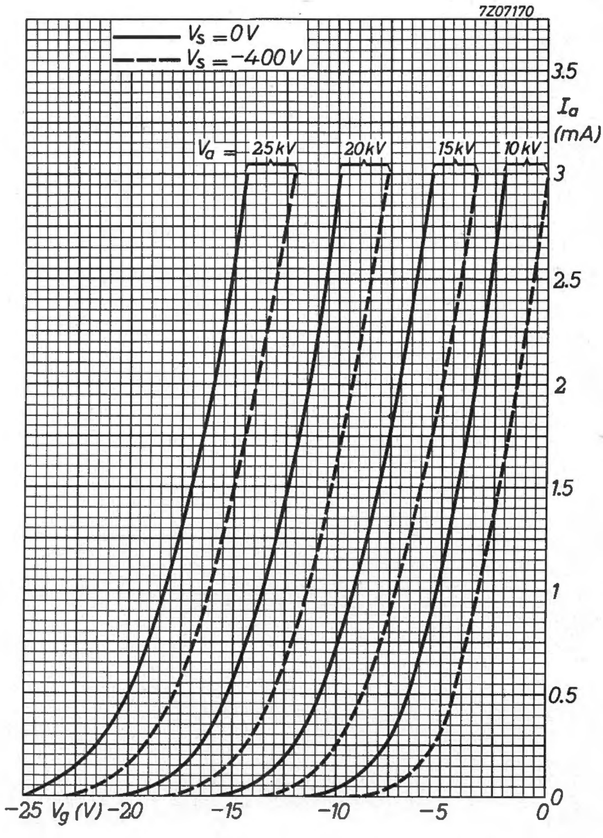
---

1) If due to a circuit failure the anode current becomes 0 mA the anode voltage should never exceed 45 kV (abs. max.)

2) Permissible only during short periods; in total up to a maximum of 10% of the operation time of the tube.

3) During equipment warm-up and for brief interval during receiver adjustment this voltage may rise to 440 V max.

4) The screen connected to pin 2 is provided to shield grid and cathode from the high anode voltage.
It is recommended to connect the screen directly to earth, with a minimum lead inductance.
The modulating influence of possible hum ripple of the screen to cathode voltage should be taken into account; the sensitivity for these variations in Vs/k is 2.5 μA/V max.


7Z07170
V_s = 0 V
V_s = −400 V
3.5
I_a (mA)
V_a = 25 kV
20 kV
15 kV
10 kV
3
2.5
2
1.5
1
0.5
0
−25 V_g (V) −20
−15
−10
−5
0

SHUNT STABILIZER TRIODE

Shunt stabilizer triode intended for use in colour TV receivers.

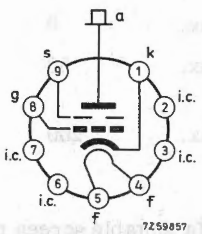
HEATING: Indirect by A.C. or D.C.; series supply

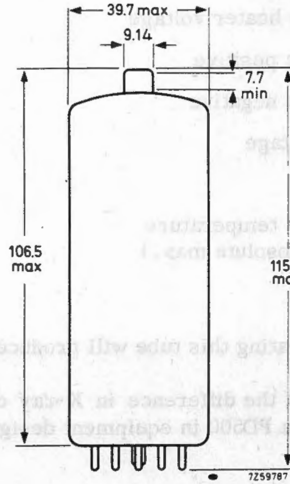
Heater current	I_f	300	mA
Heater voltage	V_f	7.3	V

DIMENSIONS AND CONNECTIONS

Dimensions in mm.

Base: Magnoval
Top cap: Type 2





Mounting: Additional supporting of the tube at the top is required. To prevent corona effects any metal screening applied around the tube should be at least 5 cm from the nearest point of the bulb. Adequate ventilation should be provided for.

TYPICAL CHARACTERISTICS

Anode voltage	V_a				25	kV
Screen voltage	V_s				0	V
Grid voltage change for an anode current change from 0.1 mA to 1.5 mA	ΔV_g	max.			10	V
Grid voltage at I_a = 1.5 mA	V_g	−9	to		−28	V
at I_a = 0.1 mA	V_g	max.			−38	V

Data based on pre-production tubes

LIMITING VALUES (Design centre rating system unless otherwise specified)

Anode voltage	V_a	max.	25	kV
Anode voltage (absolute max.)	V_a	max.	27.5	kV 1)
Anode current	I_a	max.	1.6	mA
Anode dissipation	W_a	max.	30	W
Anode dissipation (absolute max.)	W_a	max.	40	W 2)
Negative grid voltage	$-V_g$	max.	150	V 3)
Grid resistor	R_g	max.	5	MΩ
Cathode to heater voltage				
cathode positive	V_{kf}	max.	400 V_{DC} + 250	V_{AC}
cathode negative	$-V_{kf}$	max.	250	V
Screen voltage	V_s	max.	0	V
	$-V_s$	max.	50	V 4)
Anode seal temperature (absolute max.)	t_s	max.	200	°C

X-RAYS

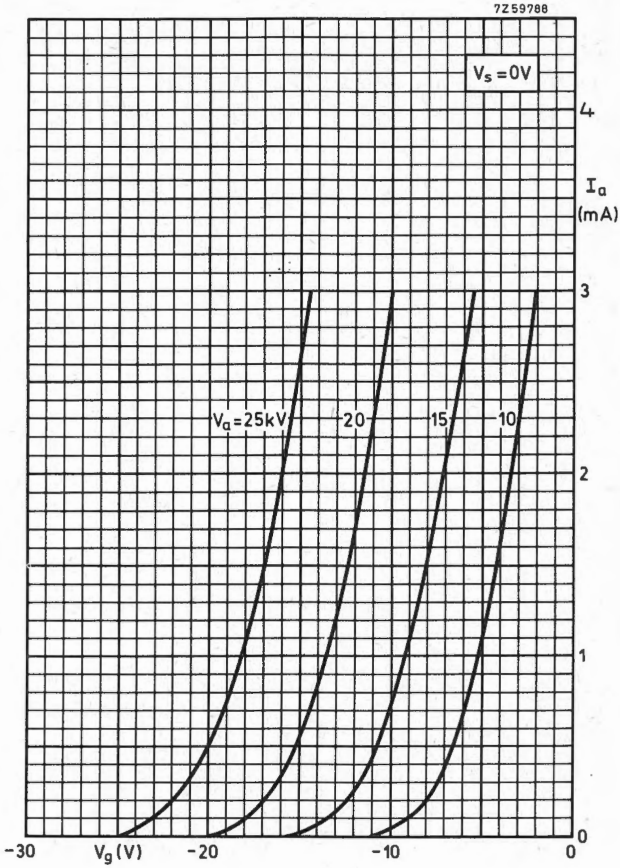
When operating this tube will produce X-radiation, and a suitable screen may be required.
Because of the difference in X-ray characteristics the PD510 should never be replaced by a PD500 in equipment designed for the PD510.

1) If due to a circuit failure the anode current becomes 0 mA the anode voltage should never exceed 45 kV (abs. max.)

2) Permissible only during short periods; in total up to a maximum of 10% of the operation time of the tube.

3) During equipment warm-up and for brief interval during receiver adjustment this voltage may rise to 440 V max.

4) The screen connected to pin 9 is provided to shield grid and cathode from the high anode voltage.
It is recommended to connect the screen directly to earth, with a minimum lead inductance.


7Z59788
$V_s = 0V$
4
I_a
(mA)
3
$V_a = 25kV$
20
15
10
2
1
0
-30
V_g (V)
-20
-10
0

PENTODE

Pentode intended for use in transitron circuits in television receivers.

QUICK REFERENCE DATA			
Anode current	I_a	3.0	mA
Transconductance	S	2.2	mA/V
Amplification factor	$\mu_{g_2g_1}$	38	-
Internal resistance	R_i	2.5	MΩ

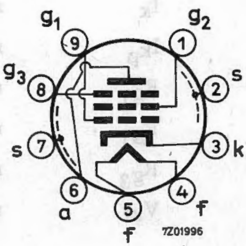
HEATING: Indirect by A.C. or D.C.; series supply

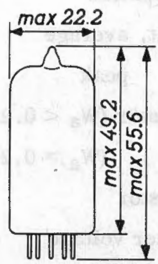
Heater current	I_f	300	mA
Heater voltage	V_f	4.5	V

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





CAPACITANCES

Anode to all except grid No.1	$C_{a(g_1)}$		5.1	pF
Grid No.1 except anode	$C_{g_1(a)}$		3.5	pF
Anode to grid No.1	C_{ag_1}	max.	0.07	pF
Grid No.1 to heater	C_{g_1f}	max.	0.03	pF

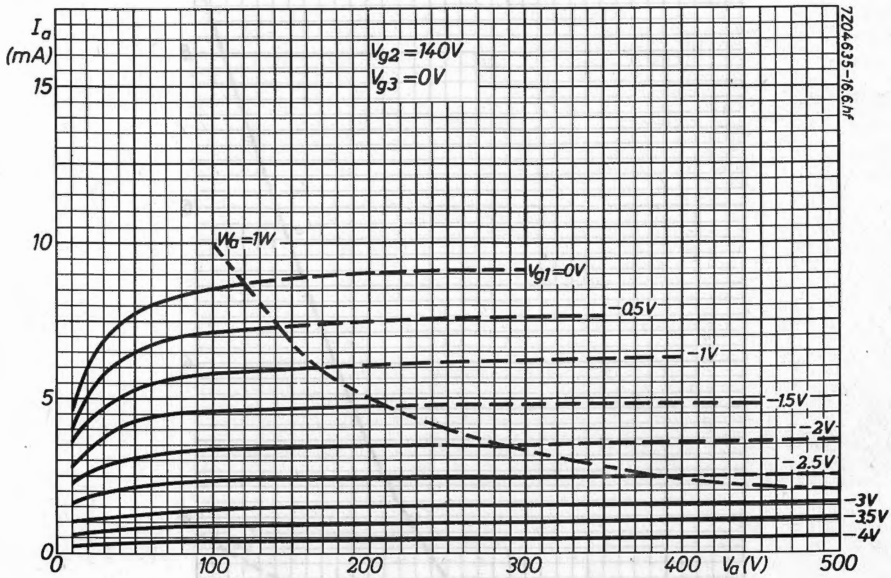
TYPICAL CHARACTERISTICS

Anode voltage	V_a	100	250	V
Grid No. 3 voltage	V_{g3}	-30	0	V
Grid No. 2 voltage	V_{g2}	35	140	V
Grid No. 1 voltage	V_{g1}	0	-2.2	V
Anode current	I_a	max. 0.01	3.0	mA
Grid No. 2 current	I_{g2}		0.6	mA
Transconductance	S		2.2	mA/V
Amplification factor	μ_{g2g1}		38	–
Internal resistance	R_i		2.5	MΩ

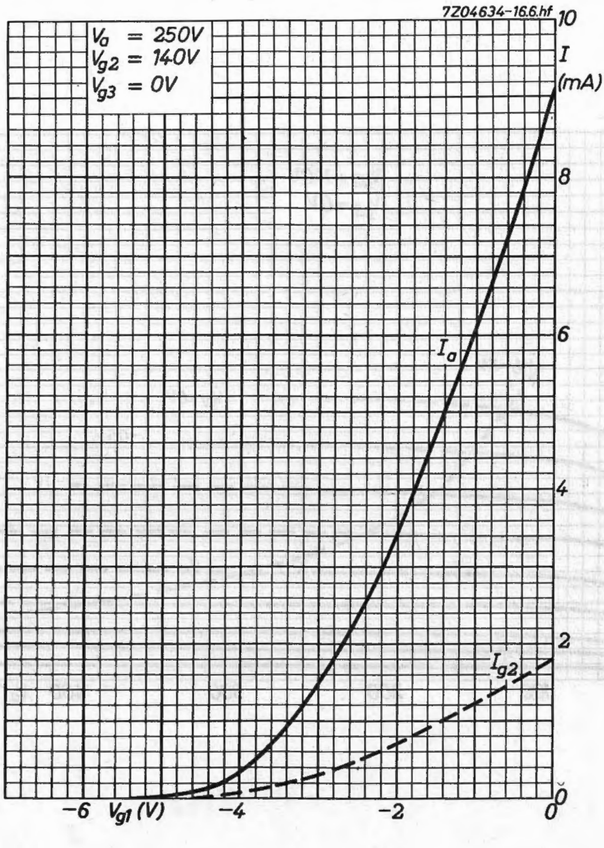
LIMITING VALUES (Design centre rating system)

Anode voltage	V_{ao}	max.	550	V
	V_a	max.	300	V
Anode dissipation	W_a	max.	1	W
Grid No. 2 voltage	V_{g2o}	max.	550	V
	V_{g2}	max.	200	V
Grid No. 2 dissipation	W_{g2}	max.	0.2	W
Cathode current, average	I_k	max.	4	mA
peak	I_{kp}	max.	25	mA [1])
Grid No. 1 resistor ($W_a < 0.2$ W)	R_{g1}	max.	10	MΩ
($W_a > 0.2$ W)	R_{g1}	max.	3	MΩ
Grid No. 3 resistor	R_{g3}	max.	0.1	MΩ
Cathode to heater voltage	V_{kf}	max.	100	V

[1]) Max. pulse duration 4% of a cycle but max. 0.8 ms.



I_a (mA)
15
10
5
0
V_{g2} = 140V
V_{g3} = 0V
W_a = 1W
V_{g1} = 0V
−0.5V
−1V
−1.5V
−2V
−2.5V
−3V
−3.5V
−4V
0
100
200
300
400
V_a (V)
500
7Z04635-16.6.hf


7Z04634-16.6.hf
V_a = 250V
V_{g2} = 140V
V_{g3} = 0V
I
(mA)
10
8
6
4
2
0
I_a
I_{g2}
−6
V_{g1} (V)
−4
−2
0

DOUBLE PENTODE

Double pentode intended for use as video output tube, sync. separator, A.G.C. amplifier or I.F. sound amplifier.

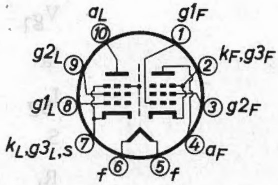
QUICK REFERENCE DATA			
F section			
Anode current	I_a	10	mA
Transconductance	S	8.5	mA/V
Amplification factor	$\mu_{g_2g_1}$	38	–
Internal resistance	R_i	150	kΩ
L section			
Anode current	I_a	30	mA
Transconductance	S	22	mA/V
Amplification factor	$\mu_{g_2g_1}$	38	–
Internal resistance	R_i	33	kΩ

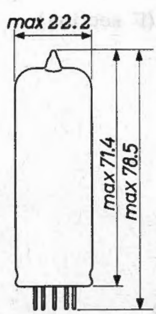
HEATING: Indirect by A.C. or D.C.; series supply

Heater current	I_f	300	mA
Heater voltage	V_f	17	V

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Decal





CAPACITANCES

		L section	F section	
Anode to all except grid No.1	$C_{a(g_1)}$	6.5	10.5	pF
Grid No.1 to all except anode	$C_{g_1(a)}$	12.5	10.5	pF
Anode to grid No.1	C_{ag_1}	0.100	0.15	pF
Grid No.1 to heater	C_{g_1f}		max. 0.15	pF

Between the two pentode sections

Anode L section to anode F section	$C_{a_La_F}$	max. 0.15	pF
Grid No.1 L section to grid No.1 F section	$C_{g_{1L}g_{1F}}$	max. 0.01	pF
Anode L section to grid No.1 F section	$C_{a_Lg_{1F}}$	max. 0.10	pF
Grid No.1 L section to anode F section	$C_{g_{1L}a_F}$	max. 0.005	pF

TYPICAL CHARACTERISTICS

Output pentode (L section)

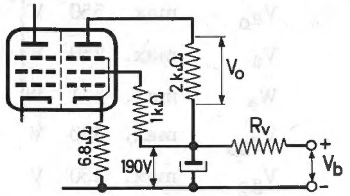
Anode voltage	V_a	170	V
Grid No.2 voltage	V_{g_2}	170	V
Grid No.1 voltage	V_{g_1}	-2.7	V
Anode current	I_a	30	mA
Grid No.2 current	I_{g_2}	7	mA
Transconductance	S	22	mA/V
Internal resistance	R_i	33	kΩ
Amplification factor	$\mu_{g_2g_1}$	38	-

Amplifier pentode (F section)

Anode voltage	V_a	150	V
Grid No.2 voltage	V_{g_2}	150	V
Grid No.1 voltage	V_{g_1}	-2.1	V
Anode current	I_a	10	mA
Grid No.2 current	I_{g_2}	3.0	mA
Transconductance	S	8.5	mA/V
Internal resistance	R_i	150	kΩ
Amplification factor	$\mu_{g_2g_1}$	38	-

OPERATING CHARACTERISTICS

Output pentode (L section) as video output tube



Supply voltage V_b = 210 230 V

Series resistor R_v = 390 820 Ω

R_v should be added to avoid excessive dissipation

Input voltage (peak to peak)	V_{ip-p}	= 3.6 V
Output voltage (peak to peak)	V_{op-p}	= 100 V

Amplifier pentode (F section)

		Sync Separator		A.G.C. amplifier		I.F. amplifier	
Supply voltage	V_b	200 to 250	V				
Anode resistor	R_a	50	kΩ				
Anode voltage	V_a			100 to 150	V	150	V
Grid No. 2 voltage	V_{g_2}	75	V	60	V	150	V
Grid No. 1 resistor	R_{g_1}	1	MΩ				
Grid No. 1 voltage	V_{g_1}	-2.7	V	-1.5	V	-2.1	V
Anode current	I_a	0.1	mA	1	mA	10	mA
Transconductance	S	0.2	mA/V	2.0	mA/V	8.5	mA/V

LIMITING VALUES (Design centre rating system)

Output pentode (L section)

Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	250	V
Anode dissipation	W_a	max.	5.1	W
Grid No. 2 voltage	$V_{g_{2o}}$	max.	550	V
	V_{g_2}	max.	250	V
Grid No. 2 dissipation	W_{g_2}	max.	2.5	W [1]
Grid No. 1 resistor	R_{g_1}	max.	1	MΩ
Cathode current	I_k	max.	60	mA [2]
Cathode to heater voltage	V_{kf}	max.	200	V

Amplifier pentode (F section)

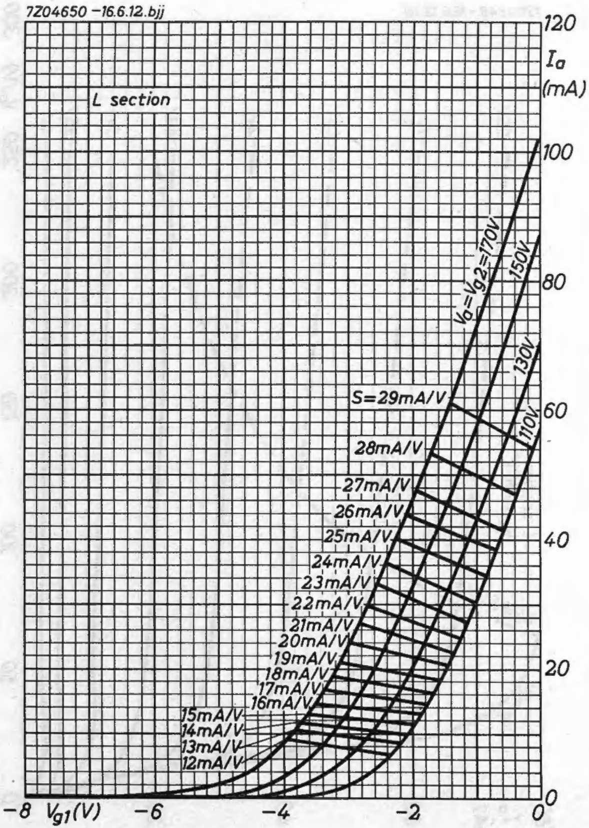
Anode voltage, peak ($I_a < 0.1$ mA)	V_{a_p}	max.	600	V [3]
	V_{a_o}	max.	550	V
	V_a	max.	250	V
Anode dissipation	W_a	max.	1.5	W
Grid No. 2 voltage	$V_{g_{2o}}$	max.	550	V
	V_{g_2}	max.	250	V
Grid No. 2 dissipation	W_{g_2}	max.	0.5	W
Grid No. 1 resistor	R_{g_1}	max.	1	MΩ
Cathode current	I_k	max.	15	mA
Cathode to heater voltage	V_{kf}	max.	200	V

---

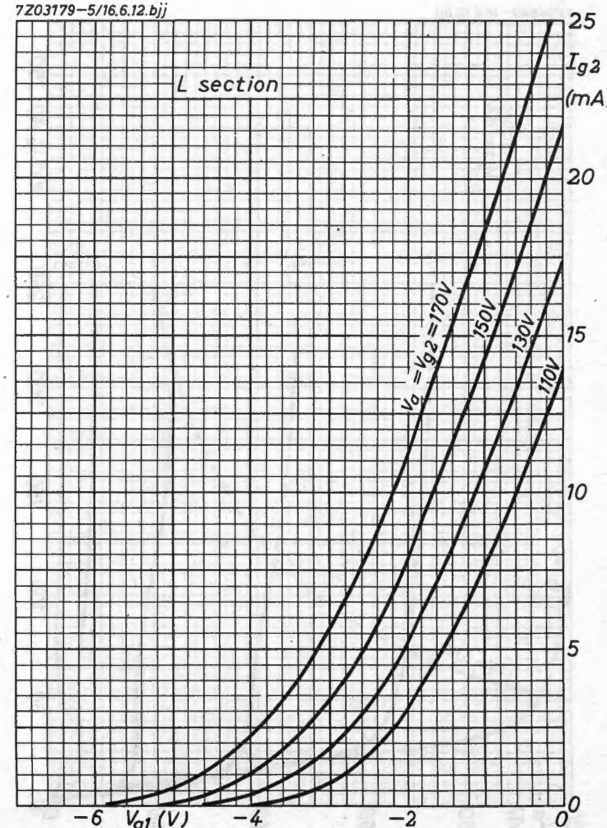
1) During short periods W_{g_2} = max. 3.2 W

2) During short periods I_k = max. 85 mA

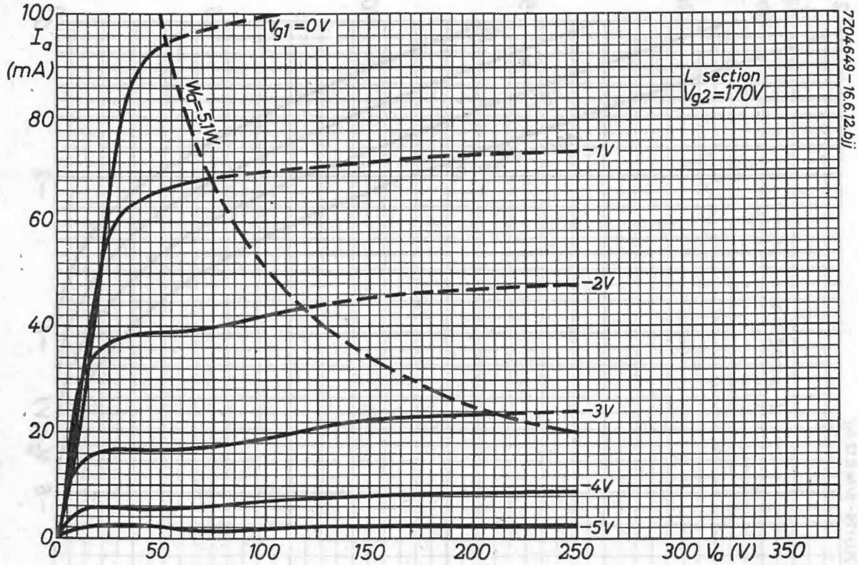
3) Max. pulse duration 18% of a cycle, with a max. of 18 μsec.

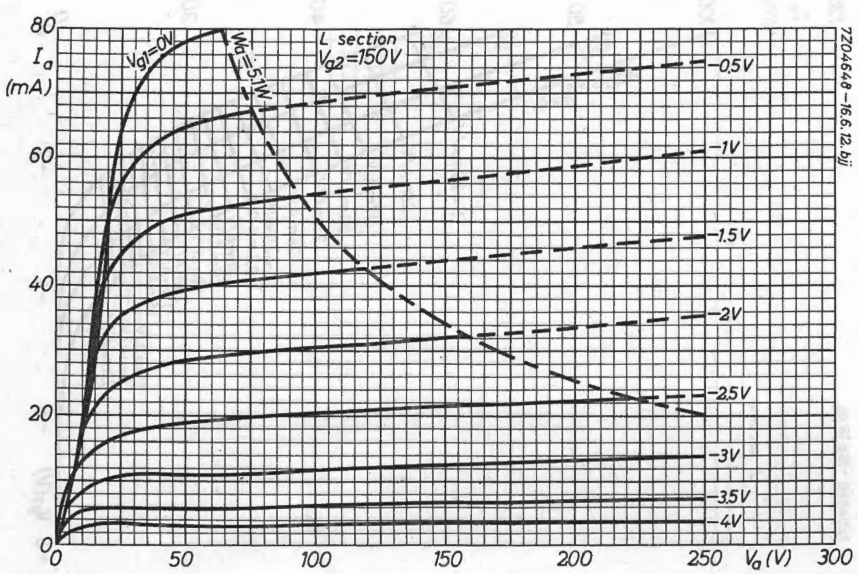


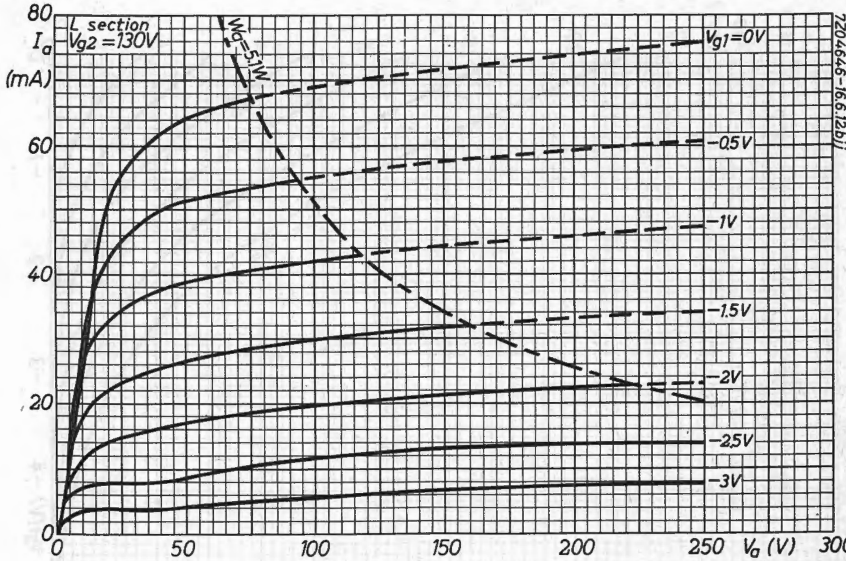
7Z04650 -16.6.12.bjj
L section
120
I_a
(mA)
100
80
60
40
20
0
$V_a = V_{g2} = 170V$
150V
130V
110V
S=29mA/V
28mA/V
27mA/V
26mA/V
25mA/V
24mA/V
23mA/V
22mA/V
21mA/V
20mA/V
19mA/V
18mA/V
17mA/V
16mA/V
15mA/V
14mA/V
13mA/V
12mA/V
−8
V_{g1}(V)
−6
−4
−2
0



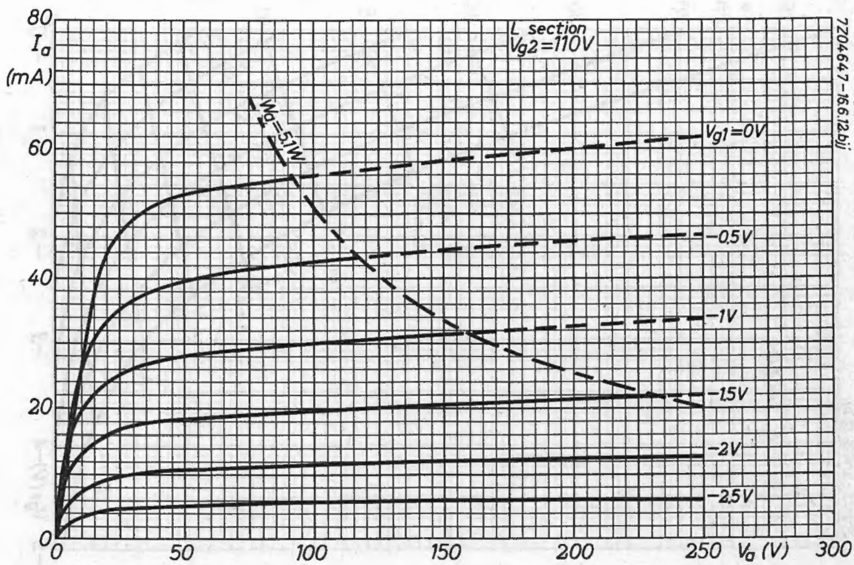
7Z03179−5/16.6.12.bjj
L section
25
I_{g2}
(mA)
20
15
10
5
0
$V_a = V_{g2} = 170V$
150V
130V
110V
−6
V_{g1} (V)
−4
−2
0


100
I_a
(mA)
80
60
40
20
0
0
50
100
150
200
250
300 V_a (V) 350
V_{g1} =0V
W_a=5.1W
L section
V_{g2}=170V
−1V
−2V
−3V
−4V
−5V
7Z04649−16.6.12.bjj

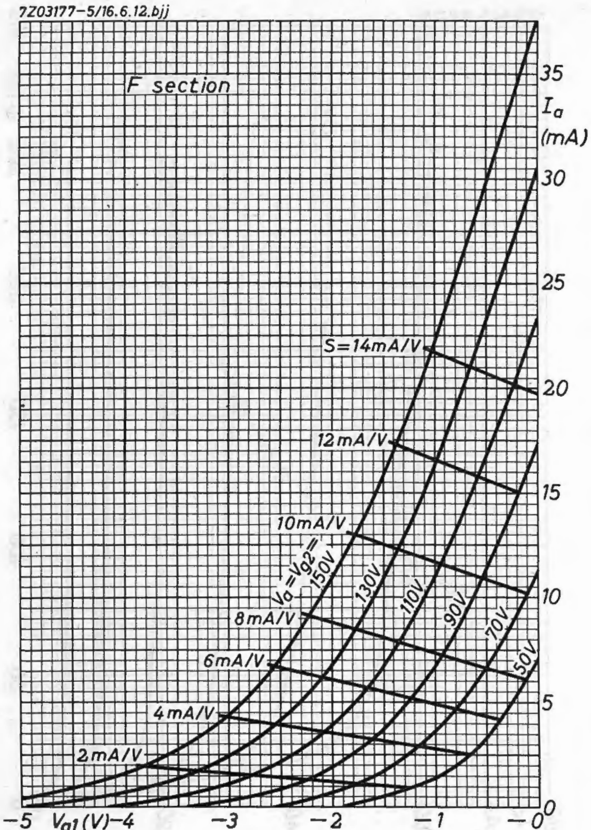

80
I_a
(mA)
60
40
20
0
0
50
100
150
200
250
V_a (V)
300
V_{g1}=0V
W_a=5.1W
L section
V_{g2}=150V
−0.5V
−1V
−1.5V
−2V
−2.5V
−3V
−3.5V
−4V
7Z04648−16.6.12.bjj

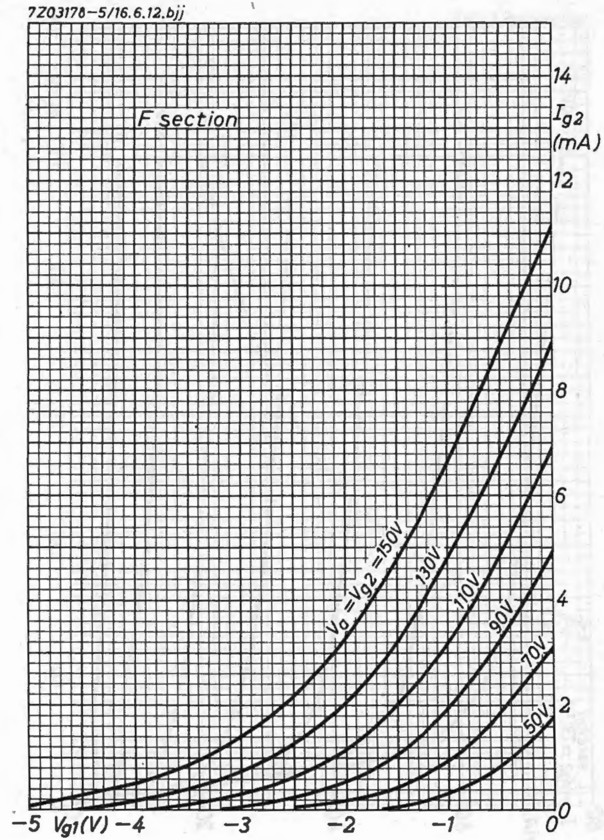


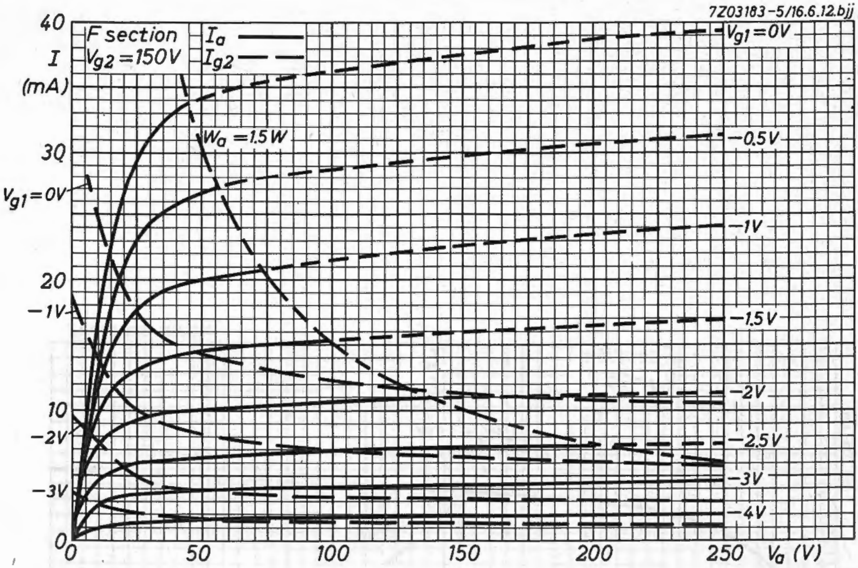
80
I_a
(mA)
60
40
20
0
L section
V_{g2} =130V
W_a=5.1W
V_{g1}=0V
−0.5V
−1V
−1.5V
−2V
−2.5V
−3V
0
50
100
150
200
250
V_a (V)
300
7Z04646−16.6.12b)

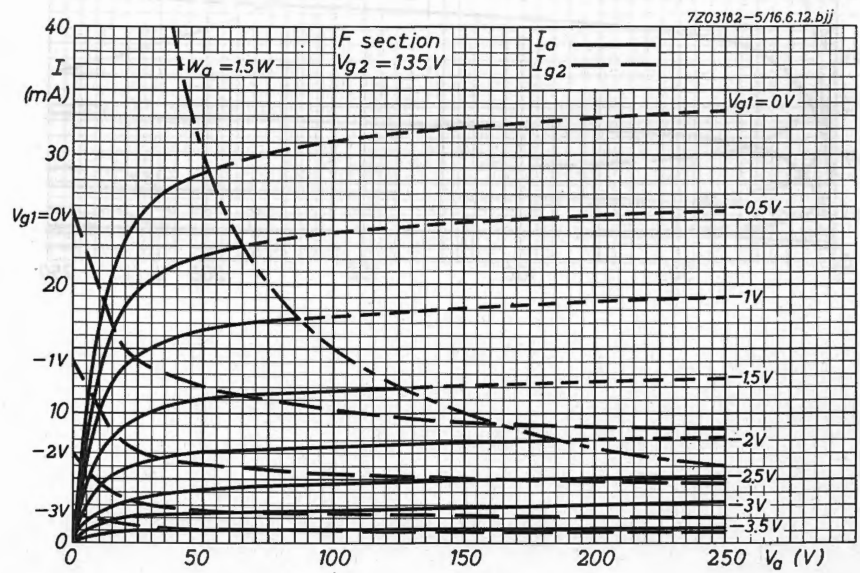


80
I_a
(mA)
60
40
20
0
L section
V_{g2}=110V
W_a=5.1W
V_{g1}=0V
−0.5V
−1V
−1.5V
−2V
−2.5V
0
50
100
150
200
250
V_a (V)
300
7Z04647−16.6.12b)

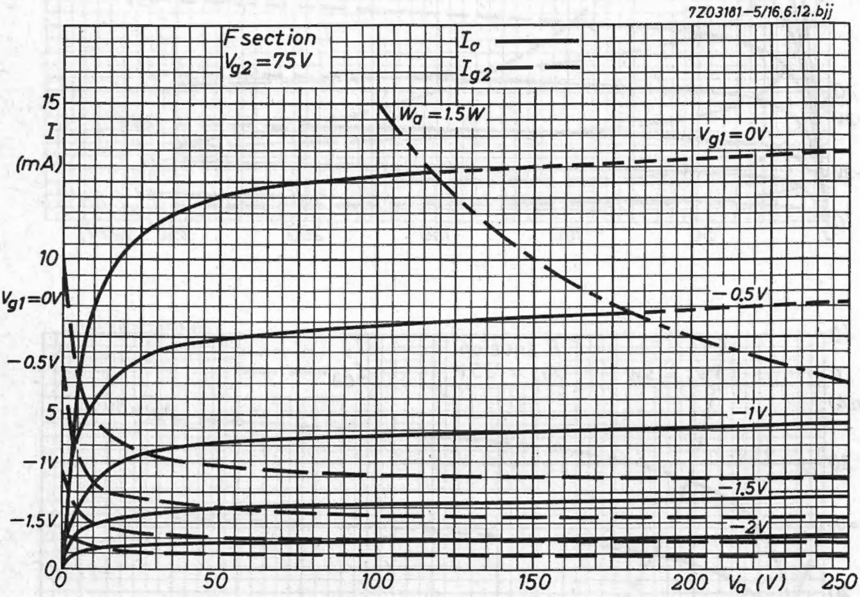

7Z03177-5/16.6.12.bjj
F section
I_a
(mA)
35
30
25
20
15
10
5
0
S=14mA/V
12mA/V
10mA/V
8mA/V
6mA/V
4mA/V
2mA/V
Va=Vg2=
150V
130V
110V
90V
70V
50V
-5
V_{g1}(V)
-4
-3
-2
-1
-0


7Z03178-5/16.6.12.bjj
F section
I_{g2}
(mA)
14
12
10
8
6
4
2
0
Va=Vg2=150V
130V
110V
90V
70V
50V
-5
V_{g1}(V)
-4
-3
-2
-1
0


7Z03183-5/16.6.12.bjj
F section
V_{g2} = 150V
I_a
I_{g2}
I (mA)
W_a = 1.5 W
V_{g1} = 0V
−0.5V
−1V
−1.5V
−2V
−2.5V
−3V
−4V
V_a (V)
40
30
20
10
0
50
100
150
200
250


7Z03182-5/16.6.12.bjj
F section
V_{g2} = 135 V
I_a
I_{g2}
I (mA)
W_a = 1.5 W
V_{g1} = 0V
−0.5V
−1V
−1.5V
−2V
−2.5V
−3V
−3.5V
V_a (V)
40
30
20
10
0
50
100
150
200
250

7Z03181–5/16.6.12.bjj



LINE OUTPUT PENTODE

Pentode intended for use as line output tube in television receivers.

QUICK REFERENCE DATA				
Anode peak voltage	V_{a_p}	max.	7	kV
Cathode current	I_k	max.	200	mA
Drive at V_{a_p} = 7 kV		min.	120	V

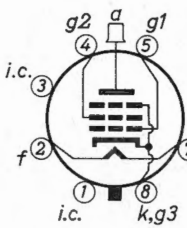
HEATING: Indirect by A.C. or D.C.; series supply

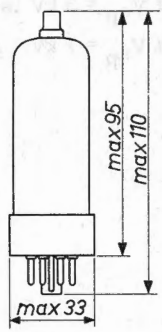
Heater current	I_f	300	mA
Heater voltage	V_f	25	V

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Octal

Top cap: Type 1





CAPACITANCES

Anode to all except grid No.1	$C_{a(g_1)}$		8	pF
Grid No.1 to all except anode	$C_{g_1(a)}$		17.5	pF
Anode to grid No.1	C_{ag_1}	max.	1.1	pF

TYPICAL CHARACTERISTICS

Anode voltage	V_a	100	V
Grid No. 2 voltage	V_{g_2}	100	V
Grid No. 1 voltage	V_{g_1}	-8.2	V
Anode current	I_a	100	mA
Grid No. 2 current	I_{g_2}	7	mA
Transconductance	S	14	mA/V
Amplification factor	$\mu_{g_2g_1}$	5.6	
Internal resistance	R_i	5	kΩ

REMARKS

On pages D to M curves are given for nominal new tubes. On designing a line output circuit it has to be taken into account that due to tube spread and deterioration during life the current may be reduced by 25%.

When the tube is operated below the knee of its I_a-V_a characteristic the screen grid series resistor must have a minimum value of 2.2 kΩ to avoid the occurrence of Barkhausen oscillations.

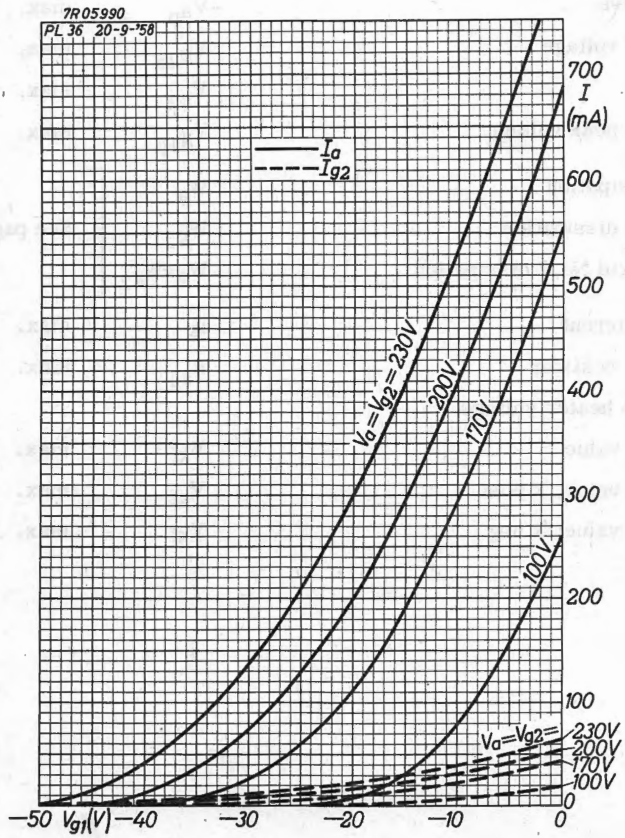
The min. drive at V_{ap} = 5 kV is 100 V
and at V_{ap} = 7 kV 120 V

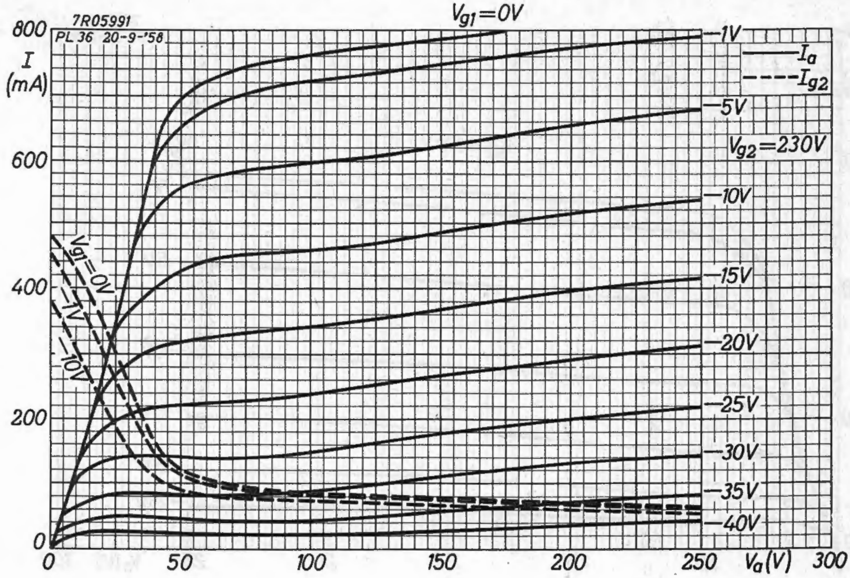
LIMITING VALUES (Design centre rating system)

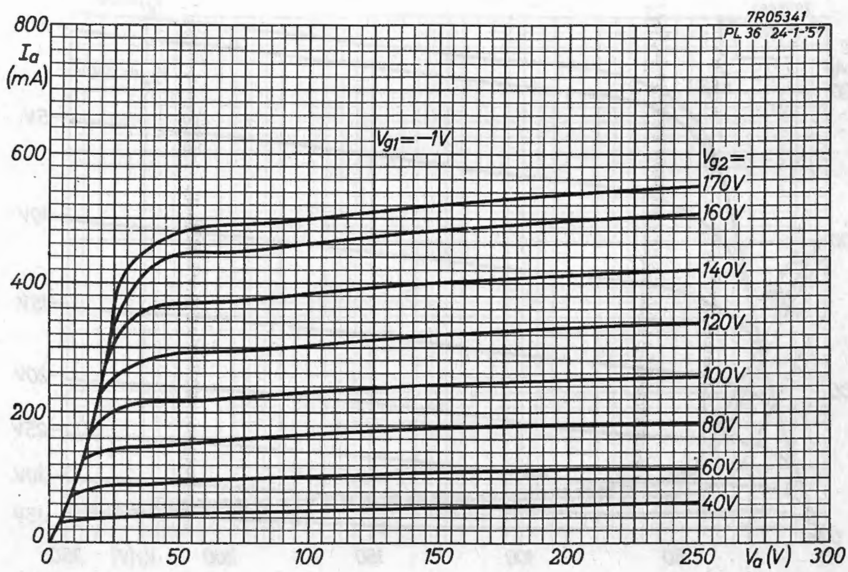
Anode voltage	V_{ao}	max.	550	V
	V_a	max.	250	V
Anode peak voltage				
positive	V_{ap}	max.	7	kV [1]
negative	$-V_{ap}$	max.	1.5	kV [1]
Grid No.2 voltage	$V_{g_{2o}}$	max.	550	V
	V_{g_2}	max.	250	V
Grid No.1 peak voltage	$V_{g_{1p}}$	max.	1	kV [1]
Anode dissipation	W_a	See page 7		
Grid No.2 dissipation	W_{g_2}	See page 7		
Anode + grid No.2 dissipation	$W_a+W_{g_2}$	See page 7		
Cathode current	I_k	max.	200	mA
Grid No.1 resistor	R_{g_1}	max.	0.5	MΩ [2]
Cathode to heater voltage				
A.C. value	V_{kf}	max.	250	V_{RMS}
D.C. value, k pos.	V_{kf}	max.	250	V
D.C. value, k neg.	V_{kf}	max.	200	V

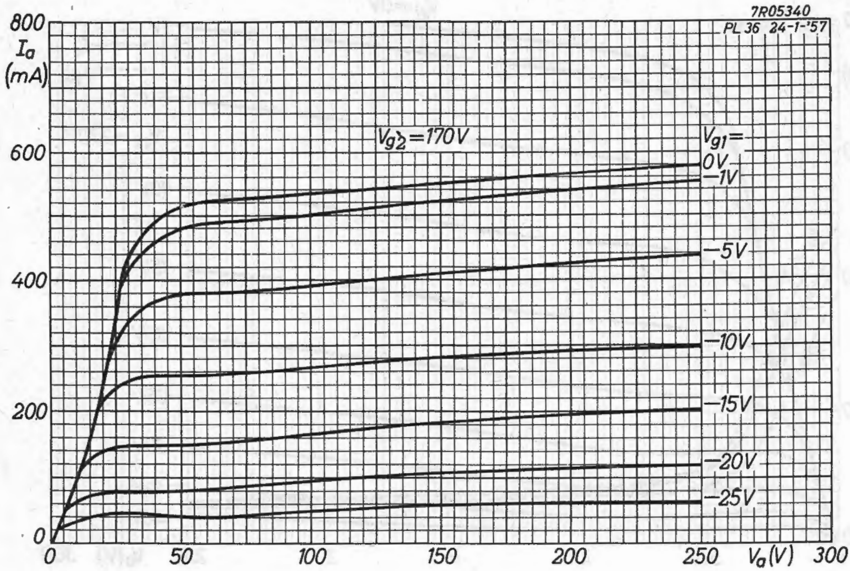
[1]) Valid for application in line output circuits where the max. pulse duration is 22% of a cycle with a max. of 18 μs.

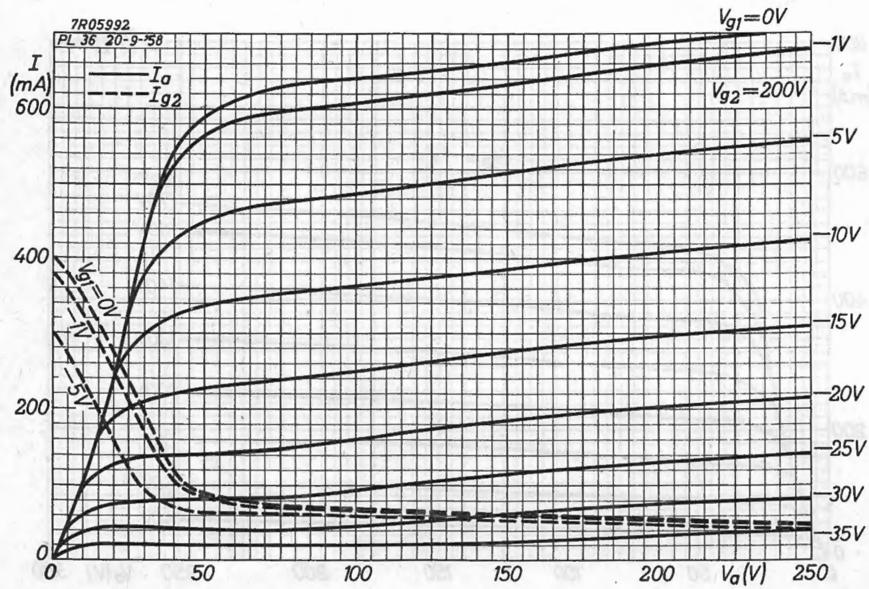
[2]) R_{g_1} = max. 2.2 MΩ for line output application only.

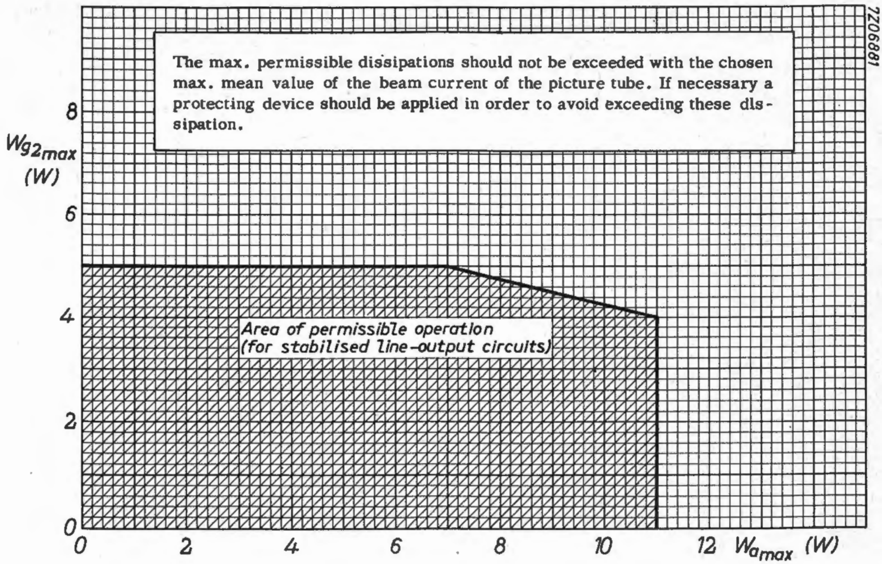

7R05990
PL 36 20-9-'58
700
I
(mA)
600
500
400
300
200
100
0
Ia
Ig2
Va=Vg2=230V
200V
170V
100V
Va=Vg2=
230V
200V
170V
100V
−50
Vg1(V)
−40
−30
−20
−10
0

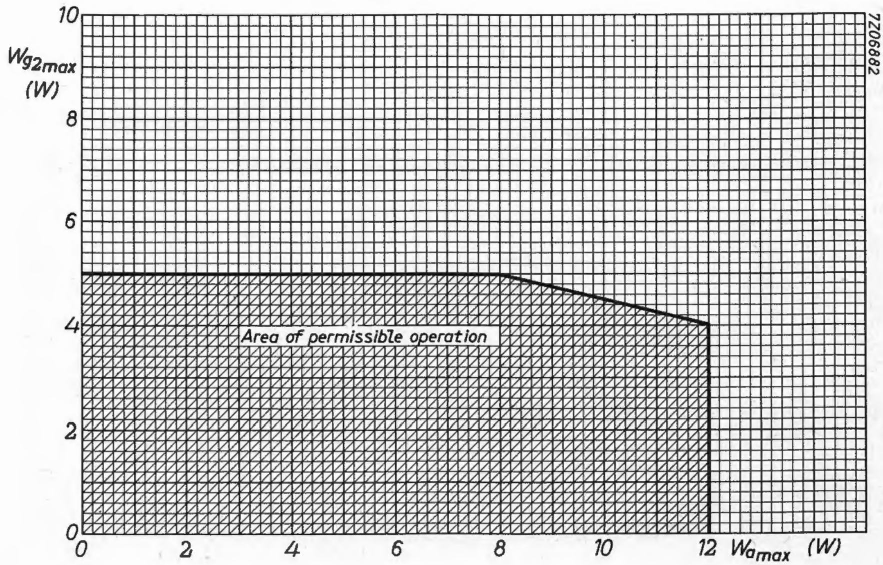

7R05991
PL 36 20-9-'58
800
I
(mA)
600
400
200
0
0
50
100
150
200
250
V_a(V)
300
V_{g1}=0V
-1V
-5V
-10V
-15V
-20V
-25V
-30V
-35V
-40V
I_a
I_{g2}
V_{g2}=230V
V_{g1}=0V
-1V
-10V


7R05341
PL 36 24-1-'57
800
I_a
(mA)
600
400
200
0
0
50
100
150
200
250
V_a(V)
300
V_{g1}=-1V
V_{g2}=
170V
160V
140V
120V
100V
80V
60V
40V


7R05340
PL 36 24-1-'57
800
I_a
(mA)
600
400
200
0
0
50
100
150
200
250
V_a(V)
300
V_{g2}=170V
V_{g1}=
0V
−1V
−5V
−10V
−15V
−20V
−25V


7R05992
PL 36 20-9-'58
I
(mA)
600
400
200
0
I_a
I_{g2}
V_{g1}=0V
−1V
V_{g2}=200V
−5V
−10V
−15V
−20V
−25V
−30V
−35V
V_{g1}=0V
−1V
−5V
0
50
100
150
200
V_a(V)
250


The max. permissible dissipations should not be exceeded with the chosen max. mean value of the beam current of the picture tube. If necessary a protecting device should be applied in order to avoid exceeding these dissipation.
7206881
Wg2max (W)
Area of permissible operation (for stabilised line-output circuits)
0
2
4
6
8
10
12
Wamax (W)


7206882
Wg2max (W)
Area of permissible operation
0
2
4
6
8
10
12
Wamax (W)

OUTPUT PENTODE FOR LINE DEFLECTION

Output pentode intended for use as horizontal deflection amplifier in small screen television receivers.

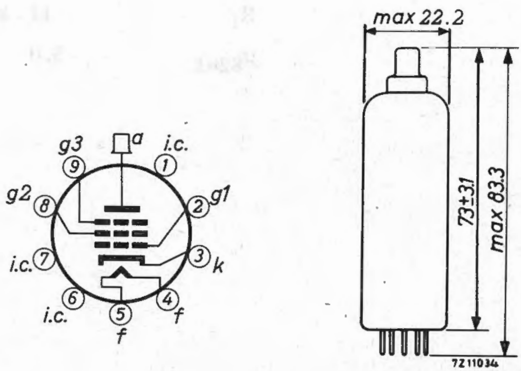
QUICK REFERENCE DATA				
Anode peak voltage	V_{a_p}	max.	7	kV
Cathode current	I_k	max.	180	mA

HEATING : Indirect by A.C. or D.C.; series supply

Heater current	I_f	300	mA
Heater voltage	V_f	21.5	V

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Noval



CAPACITANCES

Anode to all except grid No. 1	$C_{a(g1)}$		6	pF
→ Grid No. 1 to all except anode	$C_{g1(a)}$		14	pF
Anode to grid No. 1	C_{ag1}	max.	0.8	pF
Anode to cathode	C_{ak}	max.	0.1	pF
Grid No. 1 to heater	C_{g1f}	max.	0.2	pF

→ TYPICAL CHARACTERISTICS

A)

Anode voltage	V_a	170	V
Grid No. 3 voltage	V_{g3}	0	V
Grid No. 2 voltage	V_{g2}	170	V
Grid No. 1 voltage	V_{g1}	−24	V
Anode current	I_a	45	mA
Grid No. 2 current	I_{g2}	2.4	mA
Transconductance	S	6.3	mA/V
Internal resistance	R_i	11	kΩ
Amplification factor	μ_{g2g1}	5.0	

TYPICAL CHARACTERISTICS (continued)

B) (Measured under pulse conditions)

Anode voltage	V_a	40	V
Grid No. 3 voltage	V_{g3}	0	V
Grid No. 2 supply voltage	V_{bg2}	190	V
Grid No. 2 series resistor	R_{g2}	4.7	kΩ
Grid No. 1 voltage	V_{g1}	0	V
Anode current	I_a	180	mA
Grid No. 2 current	I_{g2}	18	mA

OPERATING CONDITIONS

Stabilized circuits (D.C. feedback)

Cut-off voltage

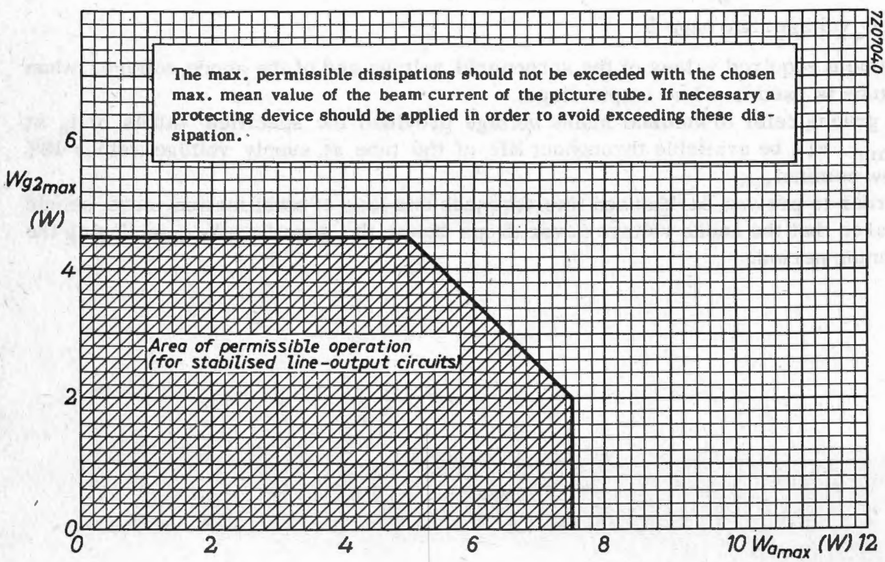
The minimum required cut-off voltage ($-V_{g1}$) during flyback is 120 V at V_a = 6000 V, V_{g2} = 190 V and Z_{g1} = 1 kΩ at line frequency.

Supply voltage: See page 5

Minimum required values of the screengrid voltage and of the anode voltage, when the tube is used in a line output stage.
The graphs refer to nominal mains voltage provided the specified values of I_a at $V_{a\ min}$, will be available throughout life of the tube at supply voltage values 10% below nominal.
In order to prevent Barkhausen interferences and less of stabilisation, care should be taken that the anode voltage never drops below the specified $V_{a\ min}$ during the scanning period.

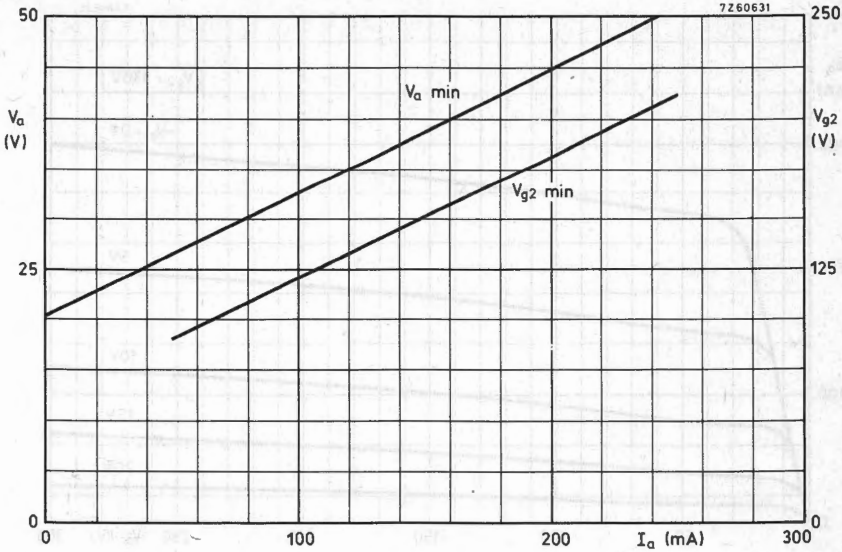
LIMITING VALUES (Design centre rating system)

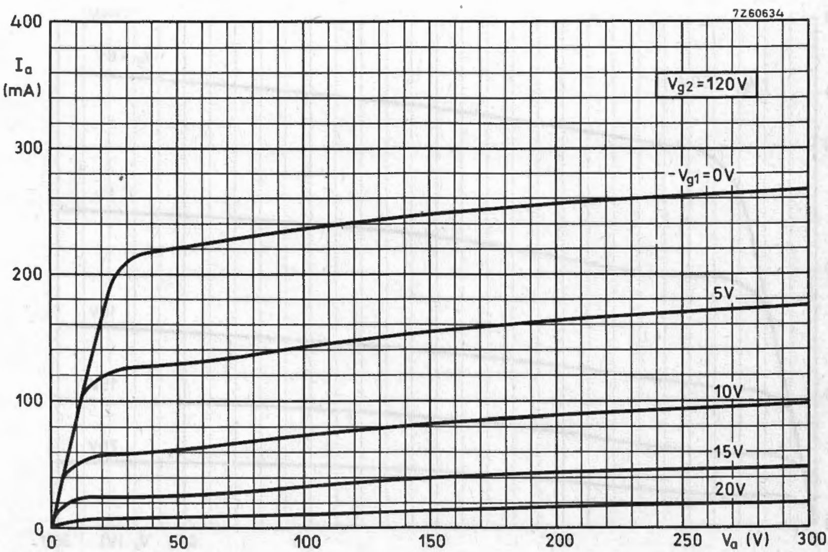
Anode voltage	V_{a_o}	max.	550 V
	V_a	max.	250 V
Anode voltage, peak	V_{a_p}	max.	7 kV [1]
negative peak	$-V_{a_p}$	max.	7 kV [1]
Anode dissipation	W_a	see figure below	
Grid No. 2 dissipation	W_{g2} [2]	see figure below	
Anode + grid No. 2 dissipation	$W_a + W_{g2}$	see figure below	
Grid No. 2 voltage	V_{g2_o}	max.	550 V
	V_{g2}	max.	250 V
Cathode current	I_k	max.	180 mA
Cathode to heater voltage	V_{kf}	max.	200 V
Grid No. 1 resistor	R_{g1}	max.	0.5 MΩ

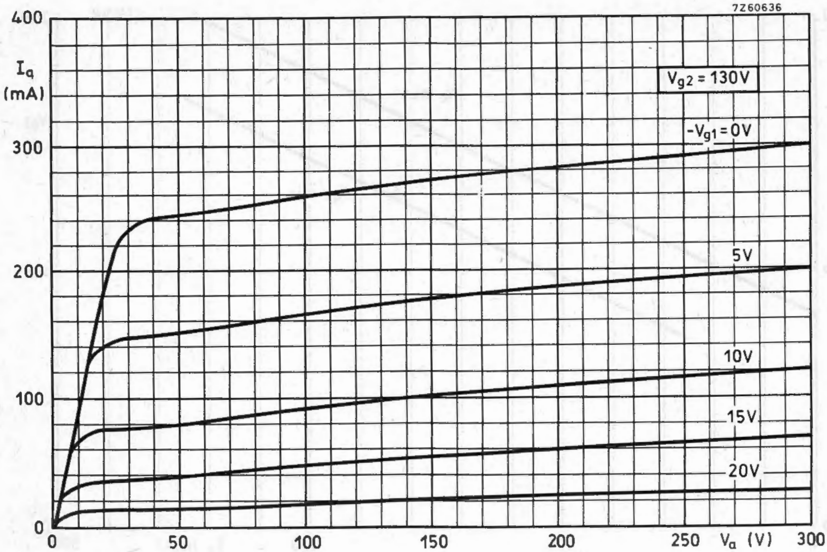


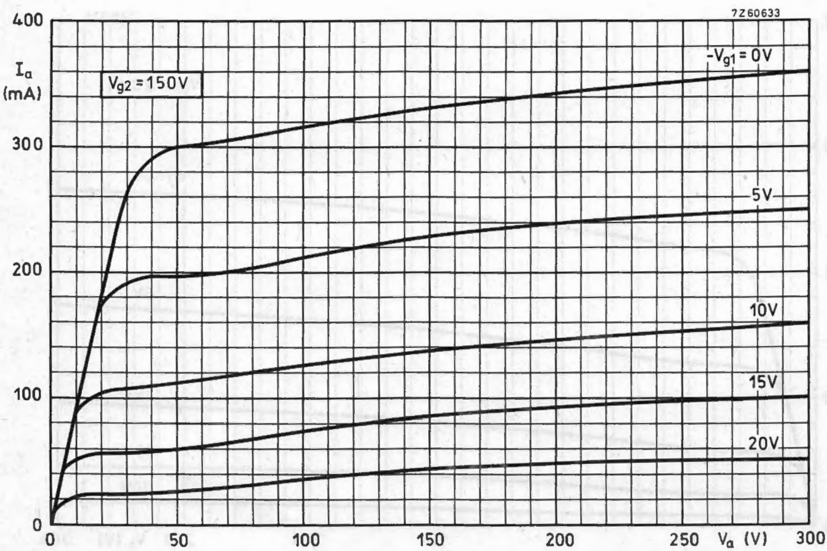
[1]) Maximum pulse duration 22 % of a cycle but maximum 18 μs.

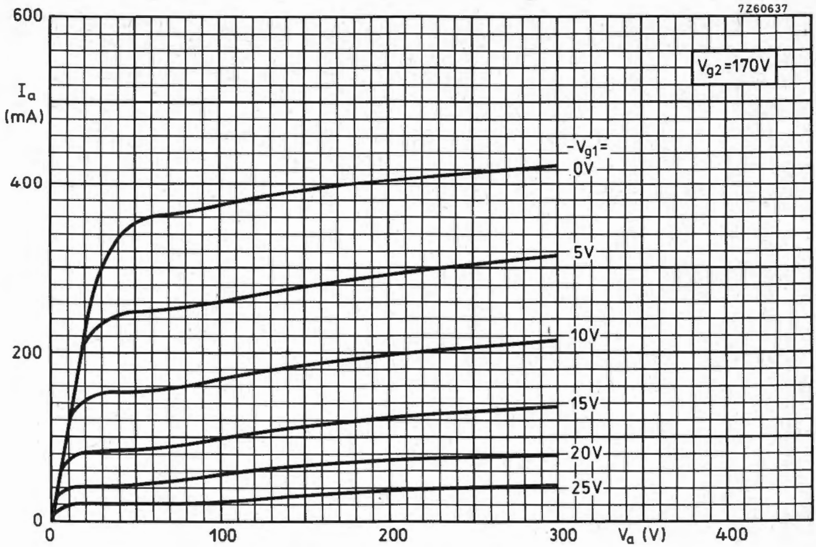
[2]) During the heating-up of the cathode W_{g2} = max. 6 W.

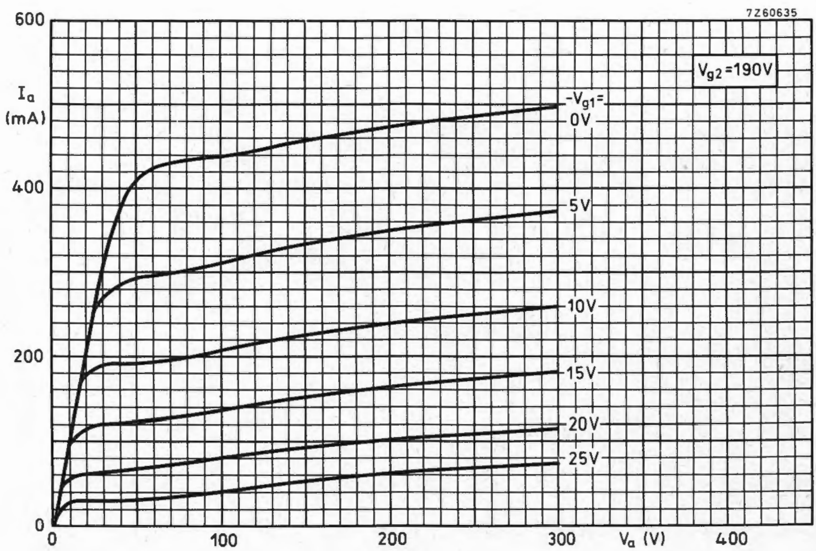

7Z60631
50
25
0
V_a
(V)
250
125
0
V_{g2}
(V)
V_a min
V_{g2} min
0
100
200
I_a (mA)
300


7Z60634
400
300
200
100
0
I_a
(mA)
V_{g2} = 120 V
$-V_{g1}$ = 0 V
5V
10V
15V
20V
0
50
100
150
200
250
V_a (V)
300


7Z60636
400
I_a
(mA)
300
200
100
0
$V_{g2} = 130V$
$-V_{g1} = 0V$
5V
10V
15V
20V
0
50
100
150
200
250
V_a (V)
300


7Z60633
400
I_a
(mA)
300
200
100
0
$V_{g2} = 150V$
$-V_{g1} = 0V$
5V
10V
15V
20V
0
50
100
150
200
250
V_a (V)
300


7Z60637
600
400
200
0
I_a
(mA)
V_{g2}=170V
$-V_{g1}$=
0V
5V
10V
15V
20V
25V
0
100
200
300
V_a (V)
400


7Z60635
600
400
200
0
I_a
(mA)
V_{g2}=190V
$-V_{g1}$=
0V
5V
10V
15V
20V
25V
0
100
200
300
V_a (V)
400

FRAME AND A.F. OUTPUT PENTODE

Pentode intended for use as frame output tube in television receivers and as A.F. power amplifier.

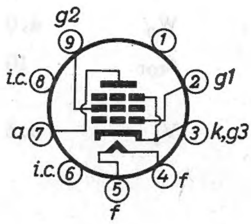
QUICK REFERENCE DATA			
Anode peak voltage	V_{a_p}	max.	2.5 kV
Cathode current	I_k	max.	75 mA
Output power	W_o		4.2 W

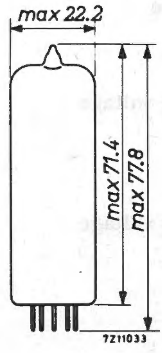
HEATING: Indirect by A.C. or D.C.; series supply

Heater current	I_f	300 mA
Heater voltage	V_f	16.5 V

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Noval





CAPACITANCES

Anode to all except grid No. 1	$C_{a(g_1)}$		5.9 pF
Grid No. 1 to all except anode	$C_{g_1(a)}$		11 pF
Anode to grid No. 1	C_{ag_1}	max.	1 pF
Grid No. 1 to heater	C_{g_1f}	max.	0.15 pF

OPTIMUM PEAK ANODE CURRENT IN FRAME OUTPUT OPERATION

To allow for tube spread and for deterioration during life in frame output application the circuit should be designed around a peak anode current not exceeding

90 mA at V_a = 50 V, V_{g2} = 170 V
120 mA at V_a = 60 V, V_{g2} = 200 V

OPERATING CHARACTERISTICS

A.F. power amplifier, class A

Supply voltage	V_b	170	200	V
Anode voltage	V_a	170	200	V
Grid No.2 voltage	V_{g2}	170		V
Grid No.2 series resistor	R_{g2}	0	680	Ω
Grid No.1 voltage	V_{g1}	-10.4	-13.9	V
Anode current	I_a	53	45	mA
Grid No.2 current	I_{g2}	10	8.5	mA
Transconductance	S	10.2	8.6	mA/V
Amplification factor	μ_{g2g1}	10	10	-
Internal resistance	R_i	20	24	kΩ
Load resistance	$R_{a\sim}$	3	4	kΩ
Grid No.1 driving voltage	V_i	6	7	V_{RMS}
Output power	W_o	4.0	4.2	W
Distortion	d_{tot}	10	10	%
Grid No.1 driving voltage for W_o = 50 mW	V_i	0.5	0.55	V_{RMS}

OPERATING CHARACTERISTICS (continued)

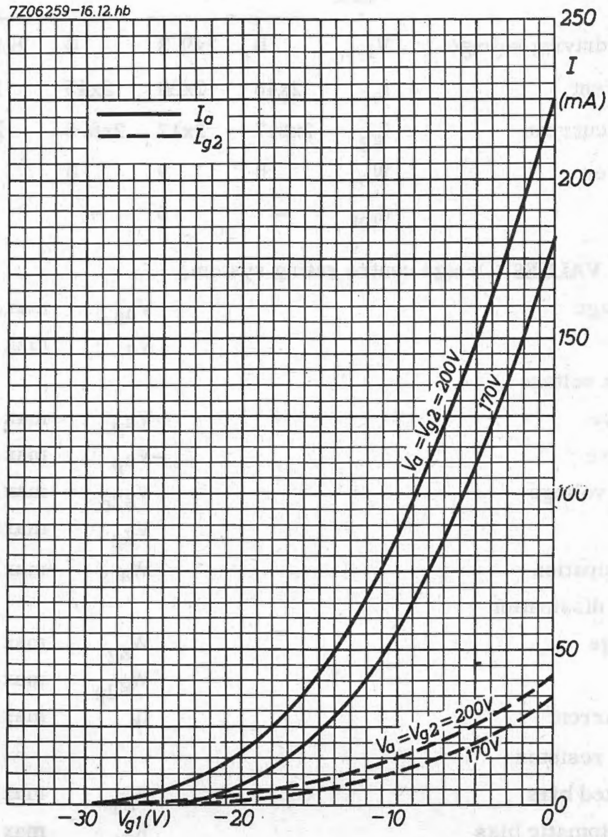
A.F. power amplifier, class A push-pull

Anode voltage	V_a	170		200		V
Grid No.2 voltage	V_{g2}	170		200		V
Common cathode resistor	R_k	100		135		Ω
Load resistance	$R_{aa\sim}$	4		4		kΩ
Grid No.1 driving voltage	V_i	0	2x9.3	0	2x13.5	V_{RMS}
Anode current	I_a	2x46	2x50	2x45	2x52	mA
Grid No.2 current	I_{g2}	2x8.7	2x17	2x8.5	2x19	mA
Output power	W_o	0	9	0	12	W
Distortion	d_{tot}	-	5	-	5	%

LIMITING VALUES (Design centre rating system)

Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	250	V [1]
Anode peak voltage				
positive	V_{ap}	max.	2500	V [2]
negative	$-V_{ap}$	max.	500	V
Grid No.2 voltage	V_{g2_o}	max.	550	V
	V_{g2}	max.	250	V
Anode dissipation	W_a	max.	9	W
Grid No.2 dissipation				
average	W_{g2}	max.	2.5	W
peak	W_{g2p}	max.	4	W
Cathode current	I_k	max.	75	mA
Grid No.1 resistor				
for fixed bias	R_{g1}	max.	0.4	MΩ
for automatic bias	R_{g1}	max.	1	MΩ
Cathode to heater voltage	V_{kf}	max.	200	V

[1]) When used as frame output tube with $W_a < 4.5$ W, V_a = max. 450 V is allowed.
[2]) Valid for application in frame output circuits where the max. pulse duration is 10% of a cycle with a max. of 2 ms.


7Z06259-16.12.hb
250
I
(mA)
200
150
100
50
0
I_a
I_{g2}
$V_a = V_{g2} = 200V$
170V
$V_a = V_{g2} = 200V$
170V
−30
V_{g1}(V)
−20
−10
0

VIDEO OUTPUT PENTODE

Pentode intended for use as video output tube.

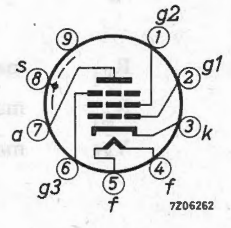
QUICK REFERENCE DATA			
Anode current	I_a	36	mA
Transconductance	S	10.5	mA/V
Amplification factor	$\mu_{g_2g_1}$	24	-

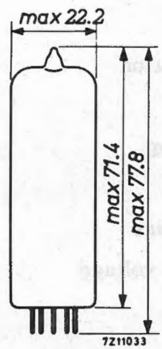
HEATING: Indirect by A.C. or D.C.; series supply

Heater current	I_f	300	mA
Heater voltage	V_f	15	V

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Noval





CAPACITANCES

Anode to all except grid No.1	$C_{a(g_1)}$		6.6	pF
Grid No.1 to all except anode	$C_{g_1(a)}$		10.8	pF
Anode to grid No.1	C_{ag_1}	max.	0.1	pF
Grid No.1 to grid No.2	$C_{g_1g_2}$		3.2	pF
Grid No.1 to heater	C_{g_1f}	max.	0.15	pF

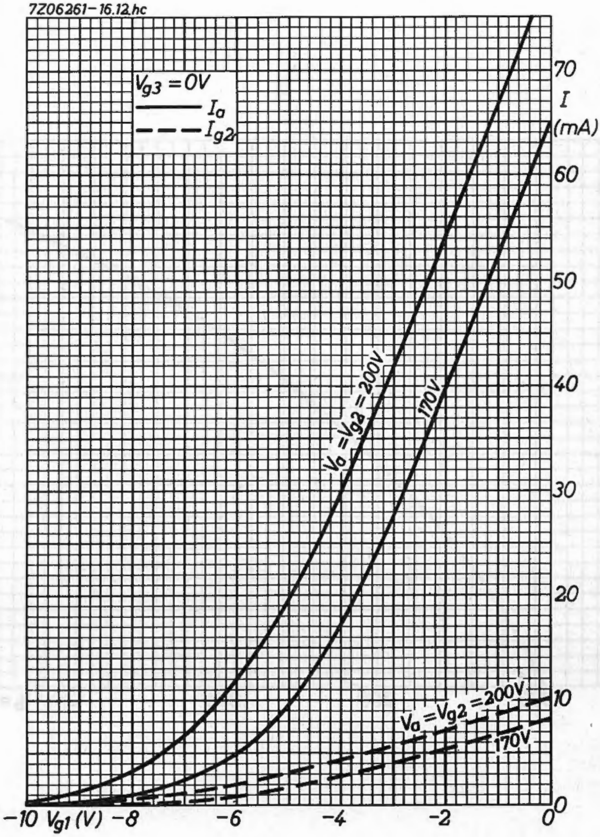
TYPICAL CHARACTERISTICS

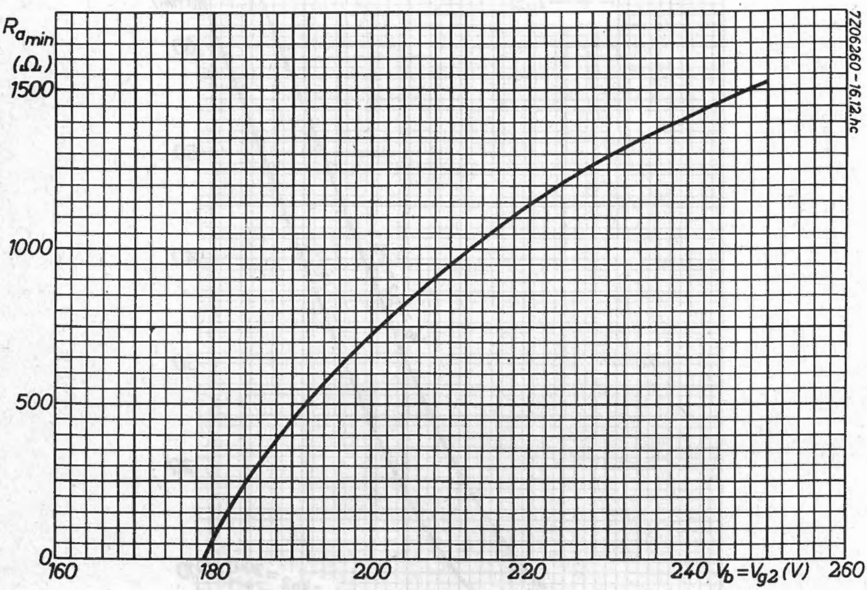
Anode voltage	V_a	170	200	V
Grid No.3 voltage	V_{g3}	0	0	V
Grid No.2 voltage	V_{g2}	170	200	V
Grid No.1 voltage	V_{g1}	-2.3	-3.5	V
Anode current	I_a	36	36	mA
Grid No.2 current	I_{g2}	5.0	5.0	mA
Transconductance	S	10.5	10.5	mA/V
Amplification factor	μ_{g2g1}	24	24	–
Internal resistance	R_i	0.1	0.1	MΩ

LIMITING VALUES (Design centre rating system)

Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	250	V
Grid No.2 voltage	V_{g2o}	max.	550	V
	V_{g2}	max.	250	V
Anode dissipation	W_a	max.	9	W
Grid No.2 dissipation	W_{g2}	max.	2	W
Cathode current	I_k	max.	70	mA
Grid No.1 resistor				
for fixed bias	R_{g1}	max.	0.5	MΩ
for automatic bias	R_{g1}	max.	1	MΩ
Cathode to heater voltage	V_{kf}	max.	200	V [1]

[1] D.C. component max. 150 V


7Z06261-16.12.hc
$V_{g3} = 0V$
I_a
I_{g2}
$V_a = V_{g2} = 200V$
170V
$V_a = V_{g2} = 200V$
170V
70
60
50
40
30
20
10
0
I
(mA)
−10 V_{g1} (V) −8
−6
−4
−2
0


$R_{a_{min}}$ (Ω)
1500
1000
500
0
160
180
200
220
240 $V_b = V_{g2}$ (V)
260
7Z06260-16.12.hc

FRAME AND A.F. OUTPUT PENTODE

Pentode intended for use as frame output tube in television receivers and as A.F. power amplifier.

QUICK REFERENCE DATA				
Anode peak voltage	V_{a_p}	max.	2	kV
Cathode current	I_k	max.	100	mA
Output power	W_o		5.3	W

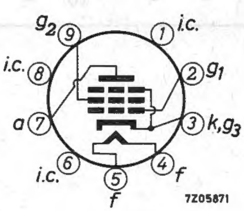
HEATING: Indirect by A.C. or D.C.; series supply

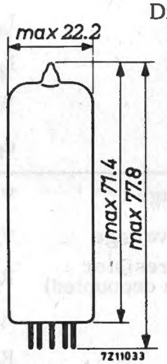
Heater current	I_f	300	mA
Heater voltage	V_f	15	V

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





CAPACITANCES

Anode to all except grid No.1	$C_{a(g_1)}$		6.8	pF
Grid No.1 to all except anode	$C_{g_1(a)}$		13	pF
Anode to grid No.1	C_{ag_1}	max.	0.6	pF
Grid No.1 to heater	C_{g_1f}	max.	0.25	pF

OPTIMUM PEAK ANODE CURRENT IN FRAME OUTPUT APPLICATION

The circuit should be designed so that the peak anode current does not exceed:

145 mA at $V_a = 60$ V, $V_{g2} = 170$ V, $I_f = 300$ mA
190 mA at $V_a = 70$ V, $V_{g2} = 200$ V, $I_f = 300$ mA
220 mA at $V_a = 80$ V, $V_{g2} = 220$ V, $I_f = 300$ mA

The minimum available value of the peak anode current at end of life and I_f = 285 mA is:

125 mA at $V_a = 60$ V, $V_{g2} = 170$ V
160 mA at $V_a = 70$ V, $V_{g2} = 200$ V
185 mA at $V_a = 80$ V, $V_{g2} = 220$ V

OPERATING CHARACTERISTICS

A.F. power amplifier, class A (measured with V_k constant)

Supply voltage	V_b		170			200		V
Grid No.2 series resistor (non decoupled)	R_{g2}		0			470		Ω
Cathode resistor	R_k		130			215		Ω
Load resistance	$R_{a\sim}$		2			2.5		kΩ
Grid No.1 driving voltage	V_i	0	0.47	6.1	0	0.52	7.0	V_{RMS}
Anode current	I_a	75	-	76	65	-	64	mA
Grid No.2 current	I_{g2}	4.0	-	16.5	3.2	-	11.4	mA
Output power	W_o	0	0.05	5.1	0	0.05	5.3	W
Distortion	d_{tot}	-	-	10	-	-	10	%

Anode supply voltage	V_{ba}		230		V
Grid No.2 supply voltage	V_{bg2}		200		V
Grid No.2 series resistor (non decoupled)	R_{g2}		220		Ω
Cathode resistor	R_k		270		Ω
Load resistance	$R_{a\sim}$		3.25		kΩ
Grid No.1 driving voltage	V_i	0	0.42	5.7	V_{RMS}
Anode current	I_a	56	-	54	mA
Grid No.2 current	I_{g2}	2.2	-	9.7	mA
Output power	W_o	0	0.05	5.4	W
Distortion	d_{tot}	-	-	10	%

OPERATING CHARACTERISTICS

A.F. power amplifier, class AB, two tubes in push-pull

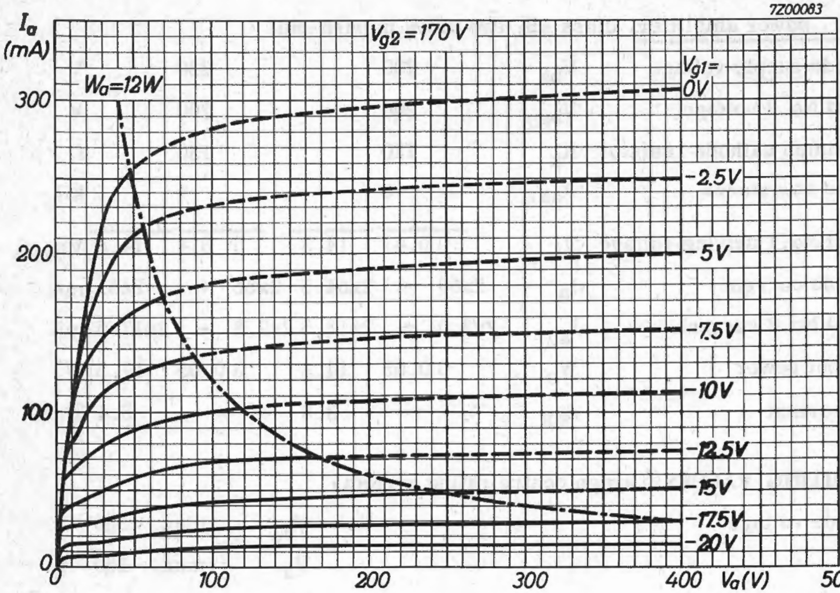
Anode supply voltage	V_{ba}	200			230			V
Grid No.2 voltage	V_{bg_2}	200			200			V
Common cathode resistor	R_k	120			130			Ω
Load resistance	$R_{aa\sim}$	3			4			kΩ
Grid No.1 driving voltage	V_i	0	0.47	14.3	0	0.4	14.6	V_{RMS}
Anode current	I_a	2x60	-	2x64.5	2x56	-	2x61	mA
Grid No.2 current	I_{g_2}	2x3.0	-	2x18.5	2x2.3	-	2x17.5	mA
Output power	W_o	0	0.05	14.3	0	0.05	17.5	W
Distortion	d_{tot}	-	-	3.8	-	-	5.4	%

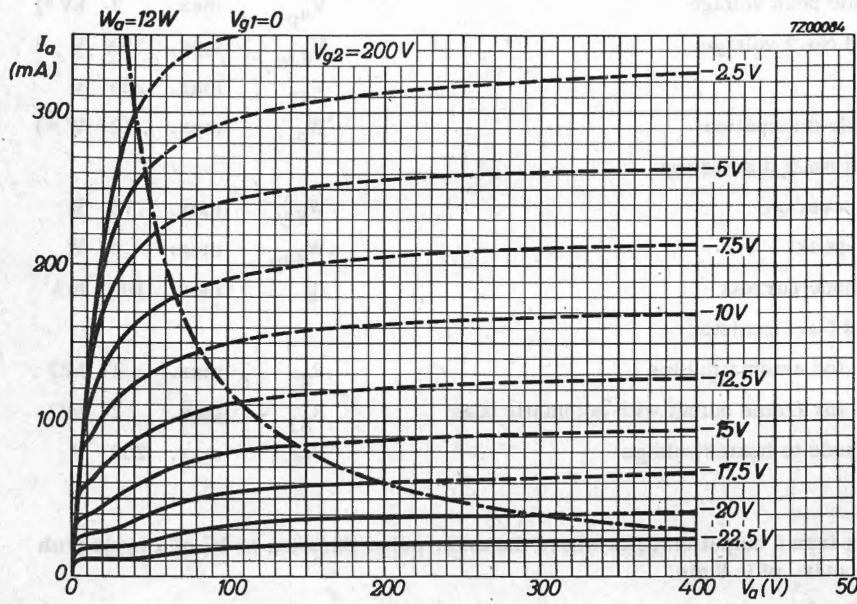
LIMITING VALUES (Design centre rating system)

Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	250	V
Anode peak voltage	V_{a_p}	max.	2	kV [1]
Grid No.2 voltage	$V_{g_{2o}}$	max.	550	V
	V_{g_2}	max.	250	V
Anode dissipation	W_a	max.	12	W [2]
Grid No.2 dissipation				
average	W_{g_2}	max.	1.75	W
peak	$W_{g_{2p}}$	max.	6	W
Cathode current	I_k	max.	100	mA
Grid No.1 resistor				
for automatic bias	R_{g_1}	max.	1	MΩ
for frame output with automatic bias	R_{g_1}	max.	2	MΩ
Cathode to heater voltage	V_{kf}	max.	200	V

[1]) In frame output circuits where the max. pulse duration is 4% of a cycle with a max. of 0.8 ms.

[2]) For frame output application W_a = max. 10 W.


7Z00083
I_a (mA)
V_{g2}=170 V
W_a=12W
V_{g1}= 0V
−2.5V
−5V
−7.5V
−10V
−12.5V
−15V
−17.5V
−20V
0
100
200
300
400
500
V_a(V)


7Z00084
I_a (mA)
W_a=12W
V_{g1}=0
V_{g2}=200 V
−2.5 V
−5V
−7.5V
−10V
−12.5V
−15V
−17.5V
−20V
−22.5V
0
100
200
300
400
500
V_a(V)

A.F. OUTPUT PENTODE

Pentode intended for use as A.F. power amplifier.

QUICK REFERENCE DATA			
Anode current	I_a	24	mA
Transconductance	S	5	mA/V
Amplification factor	μ_{g2g1}	17	
Output power	W_o	3	W

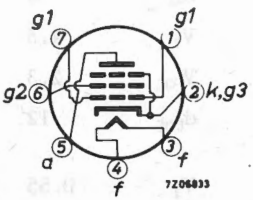
HEATING: Indirect by A.C. or D.C.; series supply

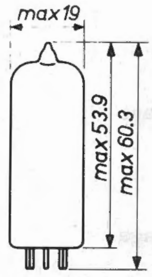
Heater current	I_f	300 mA
Heater voltage	V_f	4.5 V

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: miniature 7-pin





CAPACITANCES

Anode to all except grid No.1	$C_{a(g1)}$		3.5	pF
Grid No.1 to all except anode	$C_{g1(a)}$		5.3	pF
Anode to grid No.1	C_{ag1}	max.	0.4	pF
Grid No.1 to heater	C_{g1f}	max.	0.2	pF

TYPICAL CHARACTERISTICS

Anode voltage	V_a	250	V
Grid No.2 voltage	V_{g2}	250	V
Grid No.1 voltage	V_{g1}	-9.0	V
Anode current	I_a	24	mA
Grid No.2 current	I_{g2}	4.5	mA
Transconductance	S	5	mA/V
Amplification factor	μ_{g2g1}	17	
Internal resistance	R_i	80	kΩ

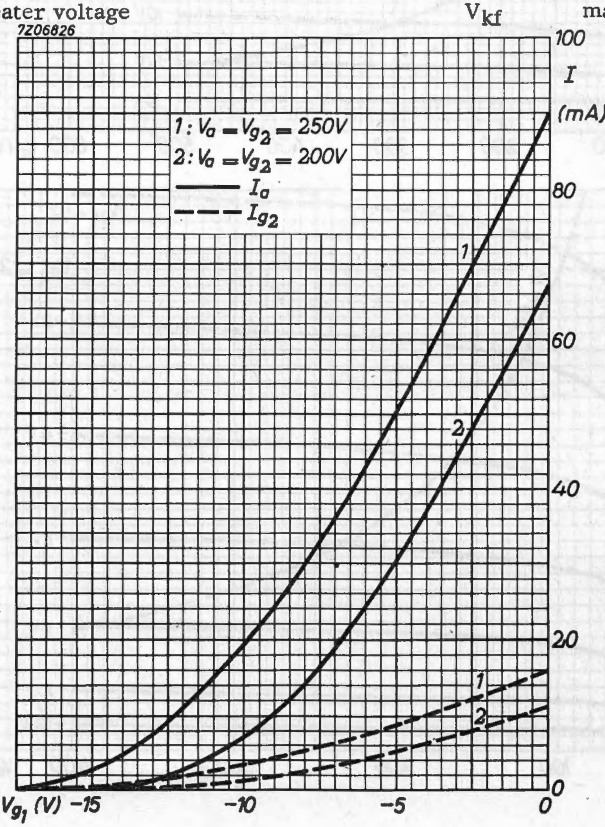
OPERATING CHARACTERISTICS

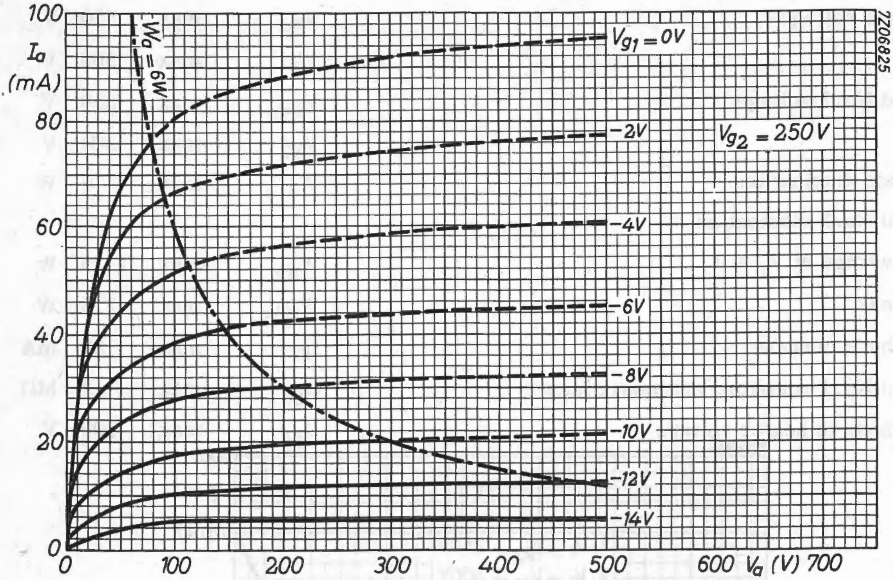
Class A

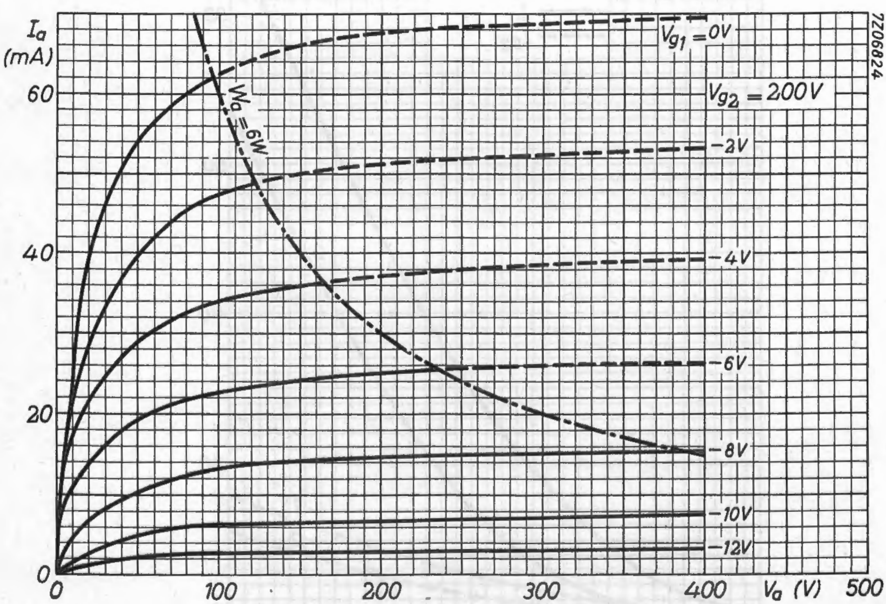
Anode voltage	V_a	200	250	V
Grid No.2 voltage	V_{g2}	200	250	V
Cathode resistor	R_k	230	320	Ω
Anode current	I_a	23	24	mA
Grid No.2 current	I_{g2}	4.2	4.5	mA
Load resistance	$R_{a\sim}$	8	10	kΩ
Grid No.1 driving voltage	V_i	4.5	5	V_{RMS}
Output power	W_o	2.3	3.0	W
Distortion	d_{tot}	12	12	%
Grid No.1 driving voltage for W_o = 50 mW	V_i	0.55	0.50	V_{RMS}

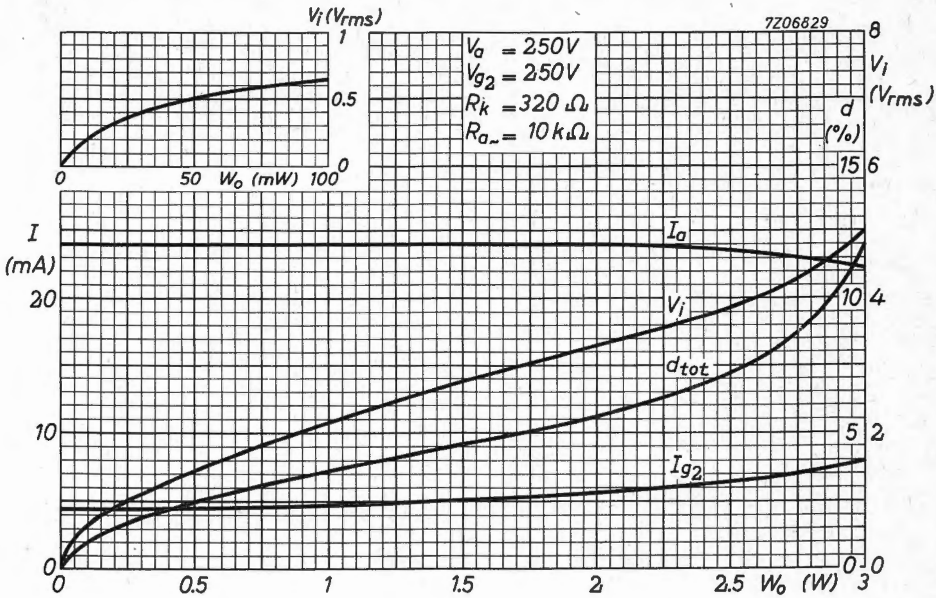
LIMITING VALUES (Design centre rating system)

Anode voltage	V_{ao}	max.	550	V
	V_a	max.	300	V
Grid No.2 voltage	V_{g2_o}	max.	550	V
	V_{g2}	max.	300	V
Anode dissipation	W_a	max.	6	W
Grid No.2 dissipation				
average at $V_i = 0$	W_{g2}	max.	1.25	W
peak	W_{g2_p}	max.	2.5	W
Cathode current	I_k	max.	35	mA
Grid No.1 resistor, automatic bias	R_{g1}	max.	2	MΩ
Cathode to heater voltage	V_{kf}	max.	200	V

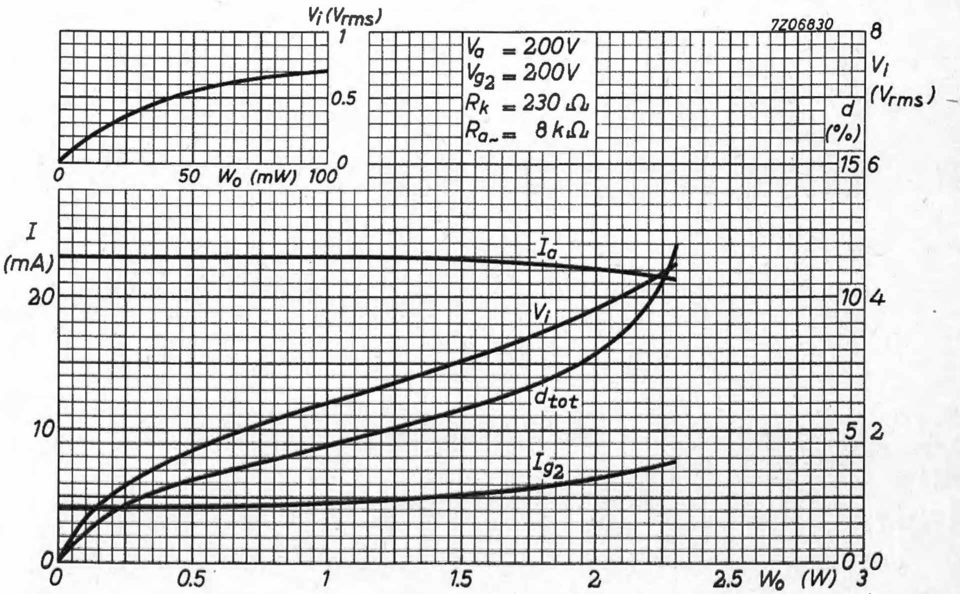



100
I_a
(mA)
80
60
40
20
0
0
100
200
300
400
500
600 V_a (V) 700
$W_a = 6W$
$V_{g1} = 0V$
−2V
−4V
−6V
−8V
−10V
−12V
−14V
$V_{g2} = 250V$
7Z06825


I_a
(mA)
60
40
20
0
0
100
200
300
400
V_a (V)
500
$W_a = 6W$
$V_{g1} = 0V$
$V_{g2} = 200V$
−2V
−4V
−6V
−8V
−10V
−12V
7Z06824



7Z06829
V_a = 250V
V_{g2} = 250V
R_k = 320 Ω
$R_{a\sim}$ = 10 kΩ
V_i (V_{rms})
W_o (mW)
I (mA)
d (%)
I_a
V_i
d_{tot}
I_{g2}
W_o (W)

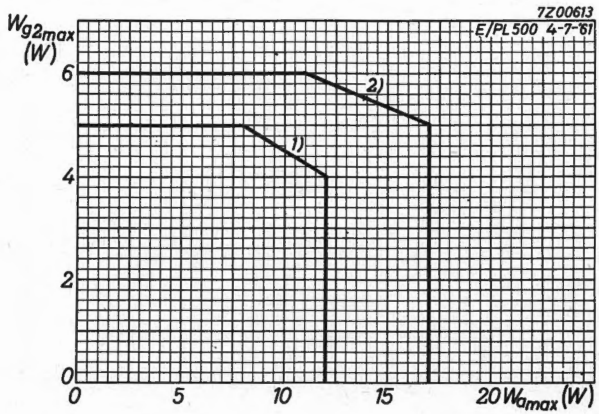


7Z06830
V_a = 200V
V_{g2} = 200V
R_k = 230 Ω
$R_{a\sim}$ = 8 kΩ
V_i (V_{rms})
W_o (mW)
I (mA)
d (%)
I_a
V_i
d_{tot}
I_{g2}
W_o (W)

LINE OUTPUT PENTODE

Beam pentode intended for use as line output tube in television receivers.

QUICK REFERENCE DATA				
Anode peak voltage	V_{a_p}	max.	7	kV
Cathode current	I_k	max.	250	mA
Anode dissipation	W_a	max.	12	W



1) Design centre limits for W_a and W_{g2}.

2) These limits for W_a and W_{g2} should not be exceeded with a nominal tube operating in a normal line deflection circuit under the worst probable conditions.

For further data and curves of this type please refer to PL504

LINE OUTPUT PENTODE

Beam pentode intended for use as line output tube in television receivers.

QUICK REFERENCE DATA				
Anode peak voltage	V_{ap}	max.	7	kV
Cathode current	I_k	max.	250	mA
Anode dissipation	W_a	max.	16	W

HEATING: Indirect by A.C. or D.C.; series supply

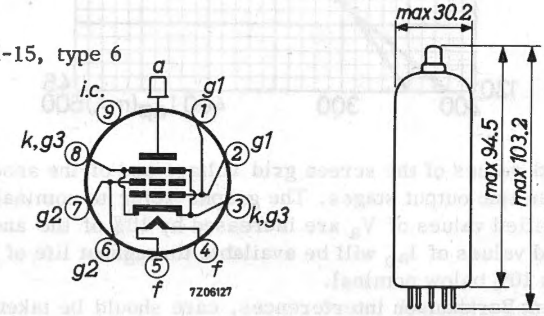
Heater current	I_f	300	mA
Heater voltage	V_f	27	V

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Magnoval; IEC 67-I-36a

Cap : Type 1

Outline: IEC67-II-15, type 6



CAPACITANCES

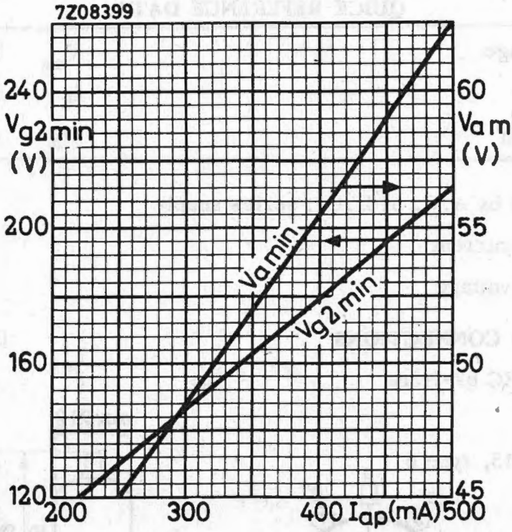
Anode to grid No. 1	C_{ag_1}		1.75	pF
Grid No. 1 to heater	C_{g_1f}	max.	0.2	pF

TYPICAL DYNAMIC CHARACTERISTICS (measured under pulse conditions)

Anode voltage	V_a	50	7000	V
Grid No. 2 voltage	V_{g2}	200	200	V
Grid No. 1 voltage	V_{g1}	-10	-120	V
Anode current	I_a	420	0.05	mA
Grid No. 2 current	I_{g2}	37		mA

OPERATING CHARACTERISTICS

Stabilized circuits (D.C. feedback)



Minimum required values of the screen grid voltage and of the anode voltage when the tube is used in line output stages. The graphs refer to nominal mains voltage provided the specified values of V_a are increased by 10% of the anode supply voltage. The specified values of I_{ap} will be available throughout life of the tube at supply voltage values 10% below nominal.
In order to prevent Barkhausen interferences, care should be taken that the anode voltage never drops below the specified V_a min. during the scanning period.

Non stabilized circuits

Supply voltage	V_b	190	230	V
Grid No. 2 series resistor	R_{g_2}	2.2	2.2	kΩ
Grid No. 1 voltage	V_{g_1}	+1	+1	V
Anode peak current	I_{a_p}	230	320	mA[1])

[1]) See page 3

HUM

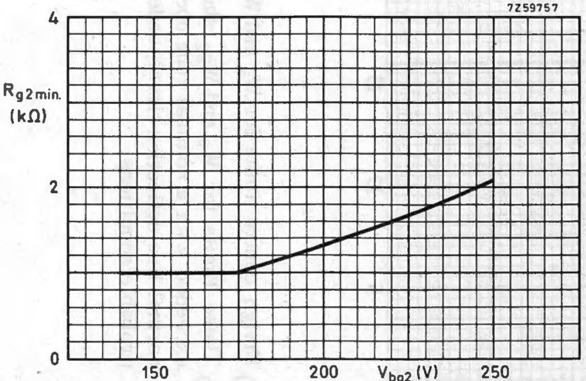
At Z_{g1} = 200 kΩ (f = 50 Hz), V_{kf} = 220 V_{RMS} and without wiring and socket capacitances, the equivalent grid hum voltage is < 5 mV.

LIMITING VALUES (Design centre rating system unless otherwise stated)

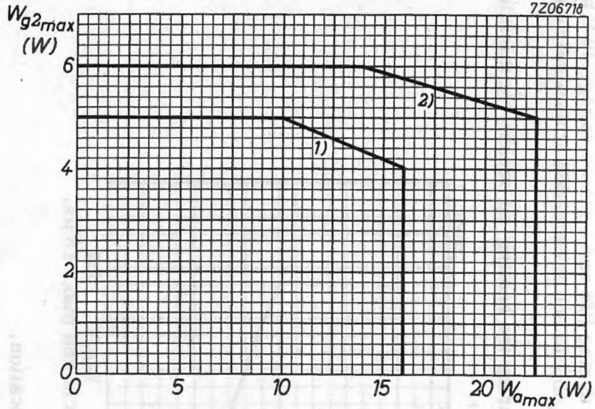
Anode voltage	V_{a_o}	max.	550	V	
Anode voltage	V_a	max.	250	V	
Anode voltage, peak	V_{a_p}	max.	7000	V	3)4)
Grid No.2 voltage	V_{g2o}	max.	550	V	
Grid No.2 voltage	V_{g2}	max.	250	V	
Anode dissipation	W_a	see page 4			
Grid No.2 dissipation	W_{g2}	see page 4			2)
Cathode current	I_k	max.	250	mA	
Grid No.1 resistor	R_{g1}	max.	0.5	MΩ	5)
Cathode to heater voltage	V_{kf}	max.	250	V	
Bulb temperature	t_{bulb}	max.	280	°C	6)

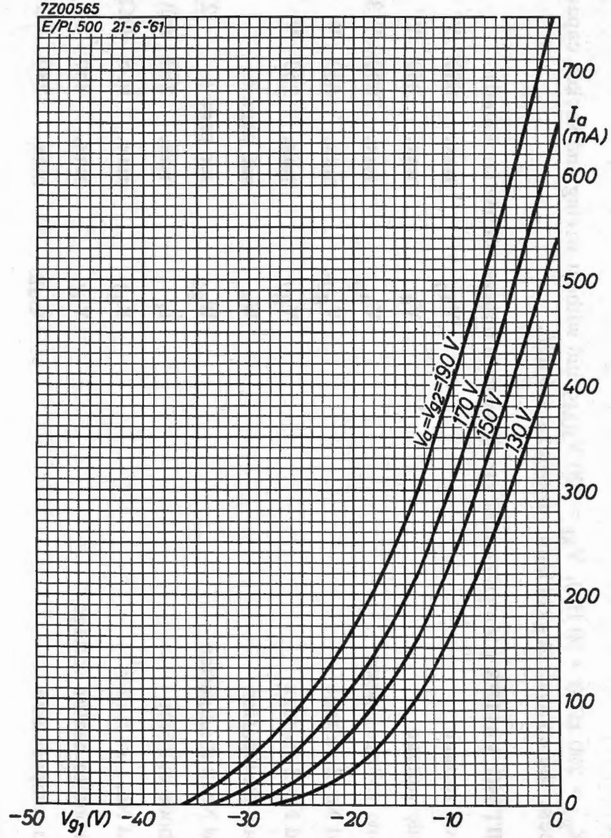
NOTES

1. To allow for tube spread, deterioration during life and a mains voltage 10 % below nominal, the specified values for I_{ap} should not be exceeded at nominal mains voltage and at the specified conditions.
2. To prevent an excessive value of W_{g2} during the heating-up period, the minimum R_{g2} values are given in the graph below.



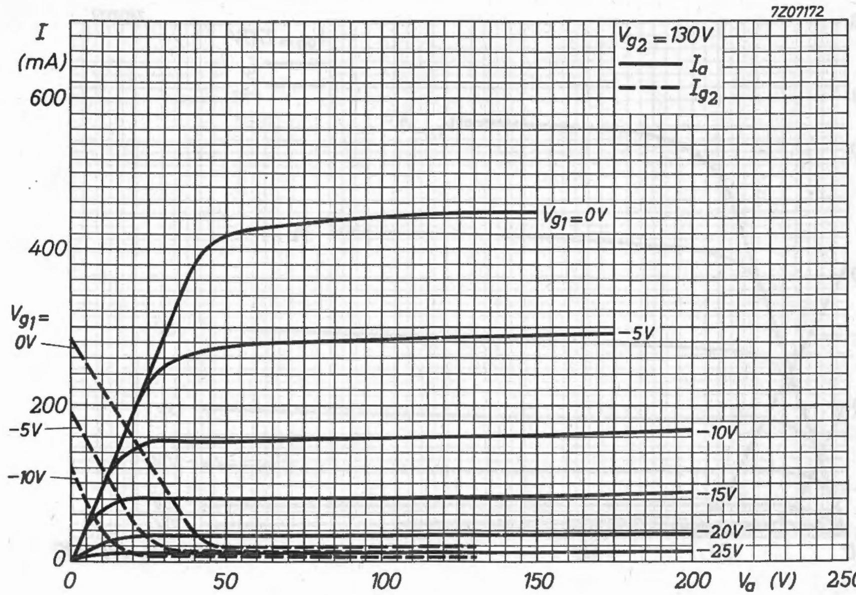
3. Maximum pulse duration is 22 % of a cycle and max. 18 μs.
4. V_{ap} design max. 8 kV
5. R_{g1} = max. 2.2 MΩ for line output application.
6. Absolute max. value.

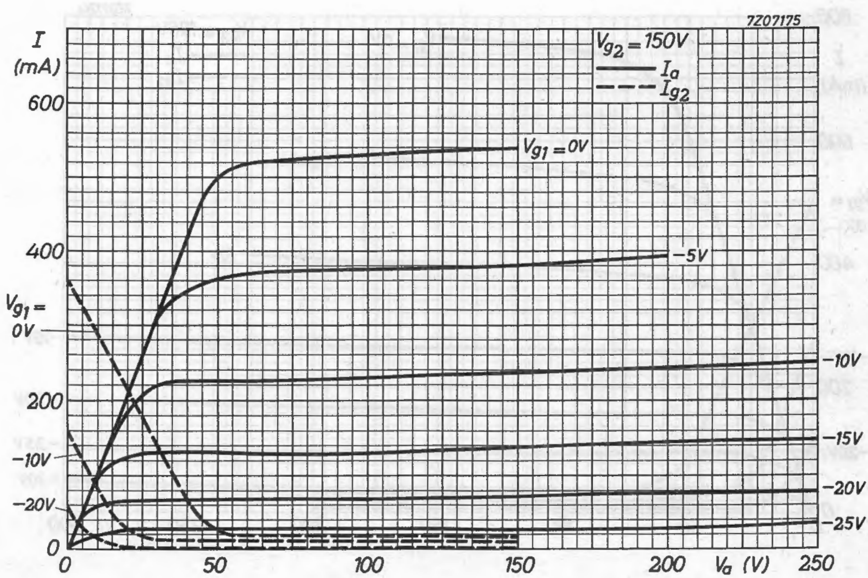


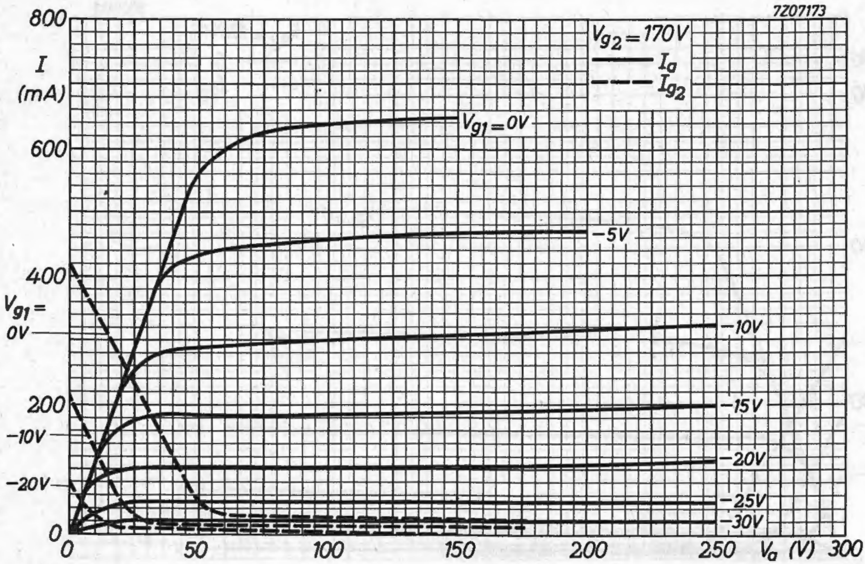


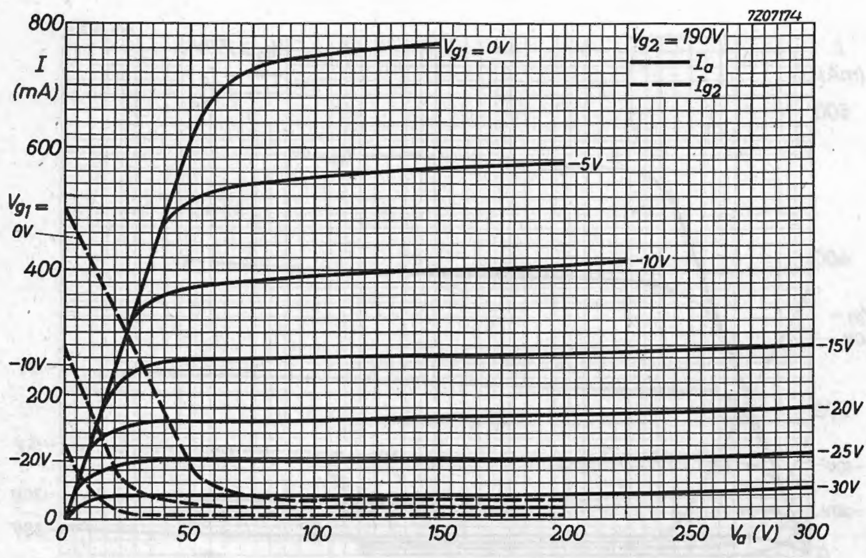
1) Disign centre limits for W_a and W_{g2}.

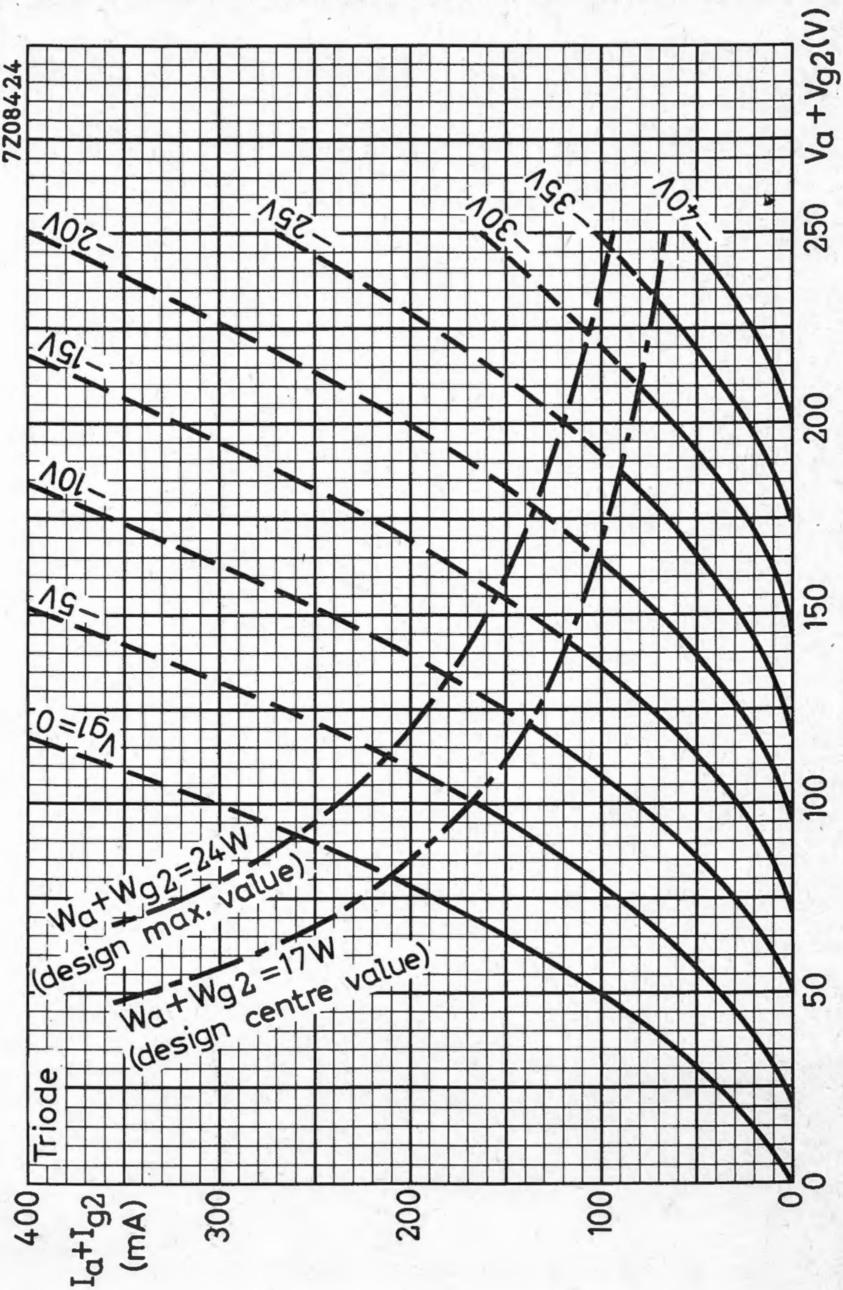
2) These limits for W_a and W_{g2} should not be exceeded with a nominal tube operating in a normal line deflection circuit under the worst probable conditions.


7Z07172
I
(mA)
600
400
200
0
$V_{g2}=130V$
I_a
I_{g2}
$V_{g1}=0V$
−5V
−10V
−15V
−20V
−25V
$V_{g1}=$
0V
−5V
−10V
0
50
100
150
200
250
V_a (V)


7Z07175
I
(mA)
600
400
200
0
$V_{g2}=150V$
I_a
I_{g2}
$V_{g1}=0V$
−5V
−10V
−15V
−20V
−25V
$V_{g1}=$
0V
−10V
−20V
0
50
100
150
200
250
V_a (V)


7Z07173
$V_{g2}=170V$
I_a
I_{g2}
I (mA)
800
600
400
200
0
$V_{g1}=$ 0V
-10V
-20V
$V_{g1}=0V$
-5V
-10V
-15V
-20V
-25V
-30V
0
50
100
150
200
250
V_a (V)
300


7Z07174
$V_{g2}=190V$
I_a
I_{g2}
I (mA)
800
600
400
200
0
$V_{g1}=$ 0V
-10V
-20V
$V_{g1}=0V$
-5V
-10V
-15V
-20V
-25V
-30V
0
50
100
150
200
250
V_a (V)
300


7Z08424
Triode
$I_a + I_{g2}$ (mA)
$V_a + V_{g2}$ (V)
400
300
200
100
0
0
50
100
150
200
250
$V_{g1} = 0$
−5V
−10V
−15V
−20V
−25V
−30V
−35V
−40V
$W_a + W_{g2} = 24W$
(design max. value)
$W_a + W_{g2} = 17W$
(design centre value)

LINE OUTPUT PENTODE

Output pentode intended for colour TV line deflection circuits.

QUICK REFERENCE DATA				
Anode peak voltage	V_{a_p}		7000	V
Cathode current	I_k	max.	500	mA
Anode dissipation	W_a	max.	25	W

LIMITING VALUES (Design centre rating system)

Anode dissipation	W_a	max.	25	W
Anode + grid No. 2 dissipation (triode connected)	$W_a+W_{g_2}$	max.	26	W

(Design max. rating system) [1])

Anode dissipation	W_a	max.	34	W
Anode + grid No. 2 dissipation (triode connected)	$W_a+W_{g_2}$	max.	35	W

For further data and curves of this type
please refer to type PL 509

[1]) The design maximum limits should not be exceeded with a nominal tube under the worst probable operating conditions at a normal picture width.

FRAME OUTPUT PENTODE

Pentode intended for use as frame output amplifier in colour television receivers.

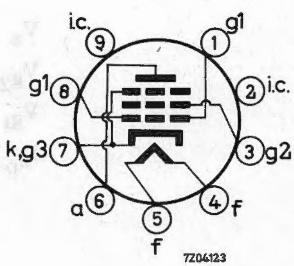
QUICK REFERENCE DATA				
Cathode current, average	I_k	max.	100	mA
Anode dissipation	W_a	max.	12	W

HEATING: Indirect by A.C. or D.C.; series supply

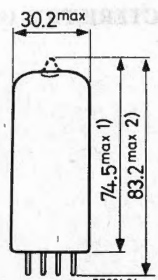
Heater current	I_f	300	mA
Heater voltage	V_f	17	V

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Magnoval



7Z04123



7Z09434

CAPACITANCES

Anode to grid No. 1	C_{ag1}	max.	1.6	pF
Grid No. 1 to heater	C_{g1f}	max.	0.2	pF

1) Max. 71.4
2) Max. 80.1 } for execution with pumping stem on base side.

TYPICAL CHARACTERISTICS

(Measured under pulse conditions)

Anode voltage	V_a		50	V_a	190	V
Grid No.2 voltage	V_{g2}		190	V_{g2}	190	V
Grid No.1 voltage	V_{g1}		-1	V_{g1}	-17	V
Anode current	I_{ap}		320	I_a	60	mA
Grid No.2 current	I_{g2}	approx.	60	I_{g2}	5	mA
Transconductance				S	9	mA/V
Amplification factor				μ_{g2g1}	8	-

Remarks.

The minimum I_a to be expected as a result of spread of the tube characteristics tube deterioration during life and decrease of the mains voltage to 10 % below the nominal value can be derived from the curves on page B by decreasing by 40 % the I_a values situated on the curve A-B at V_{g2} occuring at the decreased mains voltage.

In order not to exceed the maximum permissible value of W_{g2}, the circuit should be designed in such a way that the anode voltage should never be lower than the value determined by curve A-B at the relevant V_{g2} value.

OPERATING CHARACTERISTICS (end of scan values)

Anode voltage	V_a	70	V
Grid No.2 voltage	V_{g2}	200	V
Grid No.1 voltage	V_{g1}	-5	V
Anode peak current	I_{ap}	230	mA

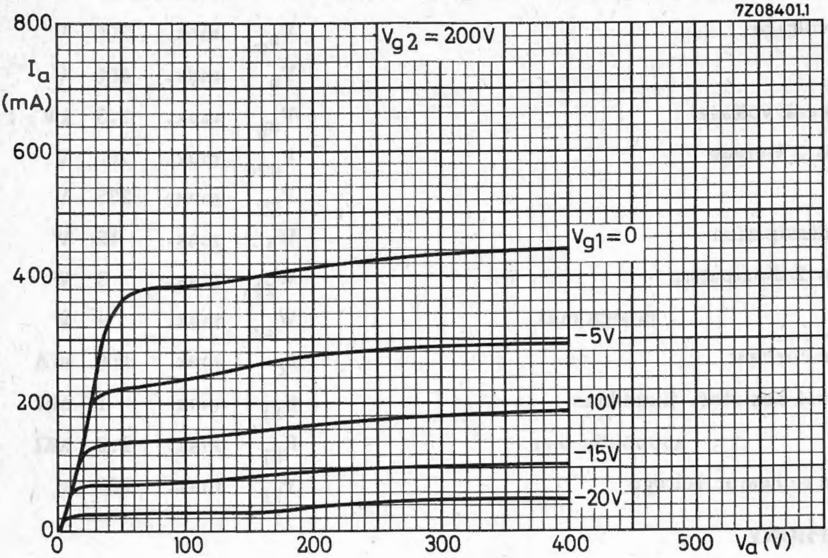
LIMITING VALUES (design centre rating system) unless otherwise stated

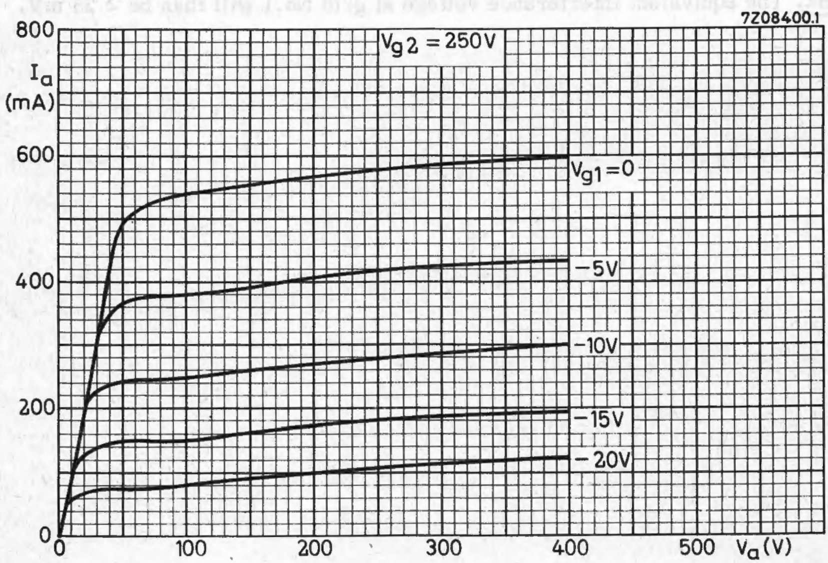
Anode voltage	V_{a_o}	max.	700	V	
	V_a	max.	400	V	
Anode peak voltage	V_{ap}	max.	2.5	kV	1)
Grid No.2 voltage	V_{g2o}	max.	700	V	
	V_{g2}	max.	275	V	
Anode dissipation	W_a	max.	12	W	
Grid No.2 dissipation	W_{g2}	max.	3	W	
design max.	W_{g2}	max.	4	W	
Cathode current	I_k	max.	100	mA	
Grid No.1 resistor, fixed bias	R_{g1}	max.	1	MΩ	
automatic bias	R_{g1}	max.	2.2	MΩ	
Cathode to heater voltage	V_{kf}	max.	220	V	

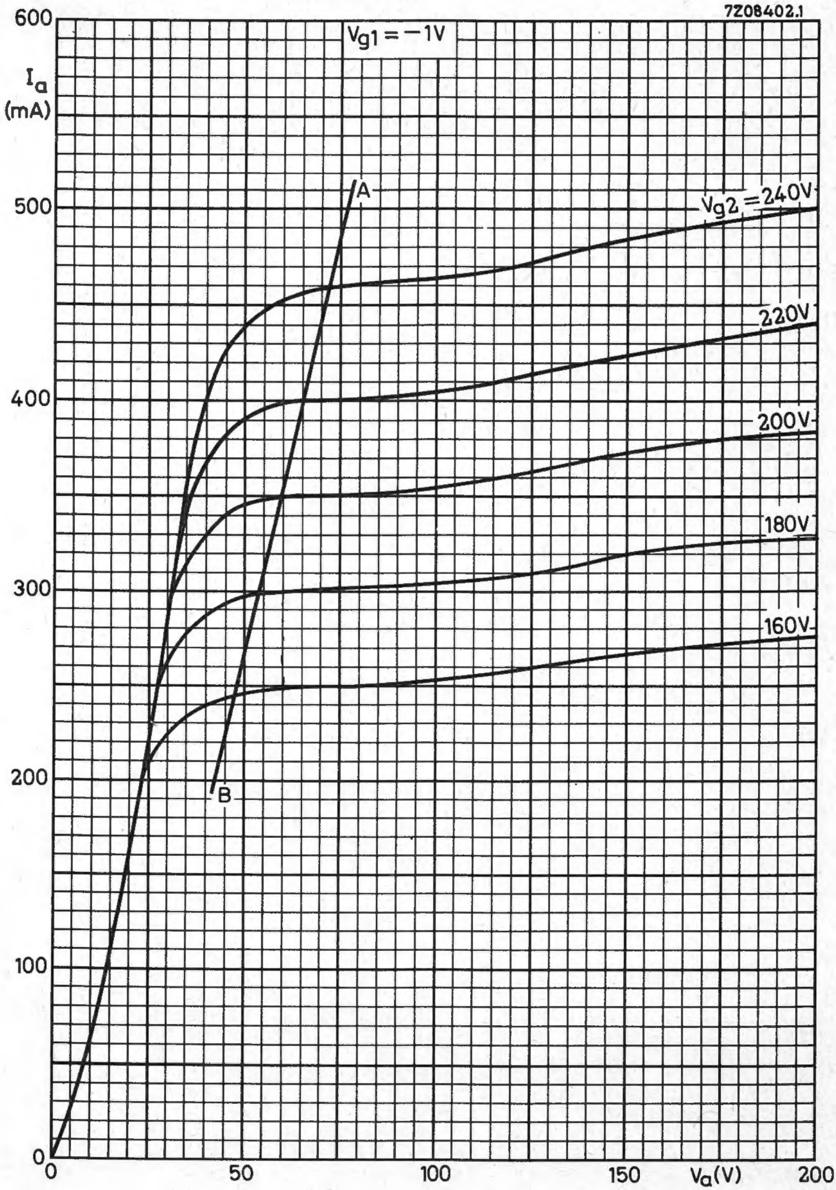
MICROPHONY

The maximum peak accelaration to which the tube may be subjected under the most unfavourable conditions is 1.5 g at frequencies < 600 Hz. and 0.2 g at frequencies > 600 Hz. The equivalent interferance voltage at grid No.1 will than be < 25 mV.

1) Max. pulse duration 5% of a cycle and max. 1 ms.


7Z08401.1
$V_{g2} = 200V$
I_a (mA)
800
600
400
200
0
0
100
200
300
400
500
V_a (V)
$V_{g1} = 0$
−5V
−10V
−15V
−20V


7Z08400.1
$V_{g2} = 250V$
I_a (mA)
800
600
400
200
0
0
100
200
300
400
500
V_a (V)
$V_{g1} = 0$
−5V
−10V
−15V
−20V


7Z08402.1
$V_{g1} = -1V$
I_a (mA)
600
500
400
300
200
100
0
A
B
$V_{g2} = 240V$
220V
200V
180V
160V
0
50
100
150
$V_a(V)$
200

LINE OUTPUT PENTODE

Output pentode intended for colour TV line deflection circuits.

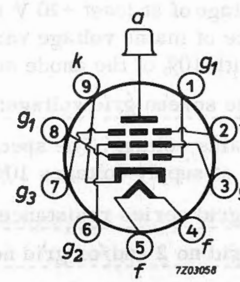
QUICK REFERENCE DATA				
Anode peak voltage	V_{a_p}		7000	V
Cathode current	I_k	max.	500	mA
Anode dissipation	W_a	max.	30	W

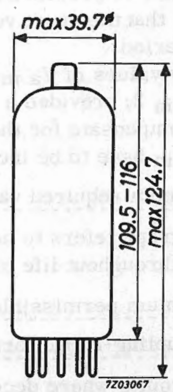
HEATING: Indirect by A.C. or D.C.; series supply

Heater current	I_f	300	mA
Heater voltage	V_f	40	V

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Magnoval
Top cap: Type 1
Mounting: Additional supporting of the tube at the top is required.





CAPACITANCES

Grid No. 1 to filament	C_{g_1f}	max.	0.2	pF
Anode to grid No. 1	C_{ag_1}	max.	3.0	pF
	C_{ag_1}		2.5	pF

TYPICAL CHARACTERISTICS (measured under pulse conditions)

Anode voltage	V_a	160	50	V
Grid No.3 voltage	V_{g_3}	0	0	V
Grid No.2 voltage	V_{g_2}	160	175	V
Grid No.1 voltage	V_{g_1}	0	-10	V
Anode current	I_a	1400	800	mA
Grid No.2 current	I_{g_2}	45	70	mA

OPERATING CONDITIONS (D.C. feedback)

Cut-off voltage

The minimum required cut-off voltage ($-V_{g_1}$) during flyback at V_a = 7000 V and Z_{g_1} = 1 kΩ at line frequency is at:

$$V_{g_2} = 150\text{ V} : V_{g_1} = -175\text{ V}$$
$$V_{g_2} = 200\text{ V} : V_{g_1} = -195\text{ V}$$
$$V_{g_2} = 250\text{ V} : V_{g_1} = -215\text{ V}$$

Supply voltages: See pages 4-5-6

Minimum required anode voltage: $V_{a\ min}$

In order to prevent Barkhausen interference and loss of stabilization, care should be taken that the anode voltage never drops below the specified $V_{a\ min}$ during the scanning period.
If low values of $V_{a\ min}$ are required, the $V_{a\ min}$ 1-line can be shifted over 10 V to $V_{a\ min}$ 2, provided a D.C. voltage of at least +20 V is applied to the beamplate (g3). To compensate for the influence of mains voltage variations, the specified values of $V_{a\ min}$ have to be increased with 10% of the anode supply voltage.

Minimum required values of the screen grid voltage: $V_{g2\ min}$

The graph refers to nominal mains voltage. The specified values of I_{ap} will be available throughout life of the tube at supply voltages 10% below nominal.

Maximum permissible screen grid series resistance: R_{g2} max. See pages 4-5-6

Decoupling-capacitors in the grid no 2 and/or grid no 3 circuit

In circuits where decoupling capacitors in the grid no 2 or the grid no 3 circuits are applied, incidental flashover in the tube may give rise to excessive dischargecurrents- and component or tube failure.
Therefore it is recommended to limit the dischargecurrents to these capacitors by means of an 100 Ohm resistance between g2 and the g2-bypass capacitance and an 1000 Ohms resistance between g3 and the g3-bypass capacitance.

Hum

At Z_{g_1} = 200 k (f = 50 Hz), $V_{k/f}$ = 220 V_{RMS} and without wiring and socket capacitance, the equivalent grid hum voltage is less than 5 mV.

LIMITING VALUES

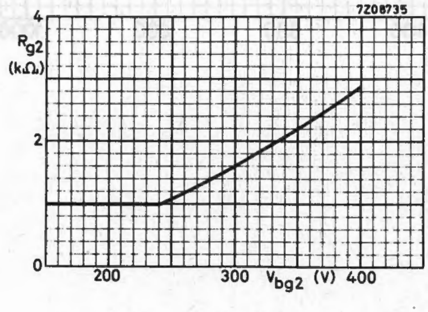
Design centre rating system

Anode voltage in cold condition	V_{ao}	max.	700	V	
Anode peak voltage	V_{ap}	max.	7000	V	1)
Anode dissipation	W_a	max.	30	W	
Anode + grid No.2 dissipation (triode-connected)	$W_a + W_{g_2}$	max.	31	W	
Grid No.3 voltage	V_{g_3}	max.	50	V	
Grid No.2 voltage in cold condition	$V_{g_{2o}}$	max.	700	V	
Grid No.2 voltage	V_{g_2}	max.	275	V	
Grid No.2 dissipation	W_{g_2}	max.	7	W	2)
Cathode current	I_k	max.	500	mA	
Cathode peak current	I_{k_p}	max.	1200	mA	
Cathode-to-heater voltage	V_{kf}	max.	250	V	
Grid No.1 resistor: fixed bias	R_{g_1}	max.	0.5	MΩ	3)
stabilized circuits	R_{g_1}	max.	2.2	MΩ	3)
Grid No.3 circuit resistance	R_{g_3}	max.	10	kΩ	4)
Bulb temperature	t_{bulb}	max.	300	°C	5)

Design max. rating system 6)

Anode dissipation	W_a	max.	40	W	
Anode + grid No.2 dissipation (triode connected)	$W_a + W_{g_2}$	max.	42	W	
Grid No.2 dissipation	W_{g_2}	max.	9	W	
Anode peak voltage	V_{ap}	max.	8000	V	1)
Neg. grid No.1 peak voltage	$-V_{g_1p}$	max.	550	V	1)

1. Max. pulse duration is 22% of a cycle and max. 18 μs.
2. To prevent an excessive value of W_{g_2} the minimum R_{g_2} values are given in the graph below.



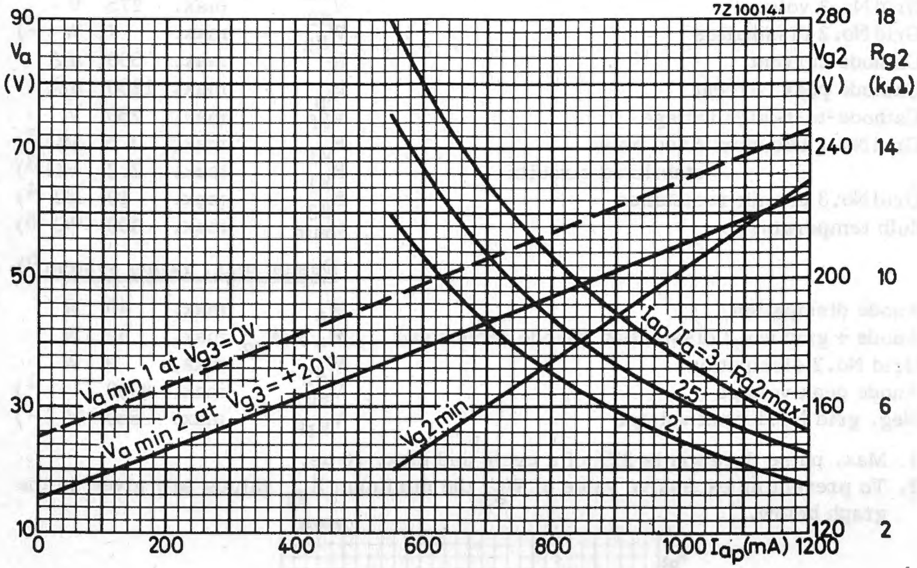
3. The circuit design has to be such that negative control grid currents up to 5 micro-amperes do not have any detrimental effect upon tube adjustment or circuit performance.
   Care should be taken that with 5 micro-amperes grid current the limiting values for I_k, W_a and W_{g_2} are not exceeded.
4. With $R_{g_3} \leq 10$ kΩ capacitive decoupling of g_3 is not required.
5. Absolute max. value.
6. The design maximum limits should not be exceeded with a nominal tube under the worst probable operating conditions at a normal picture width.

Min. required anode voltage.

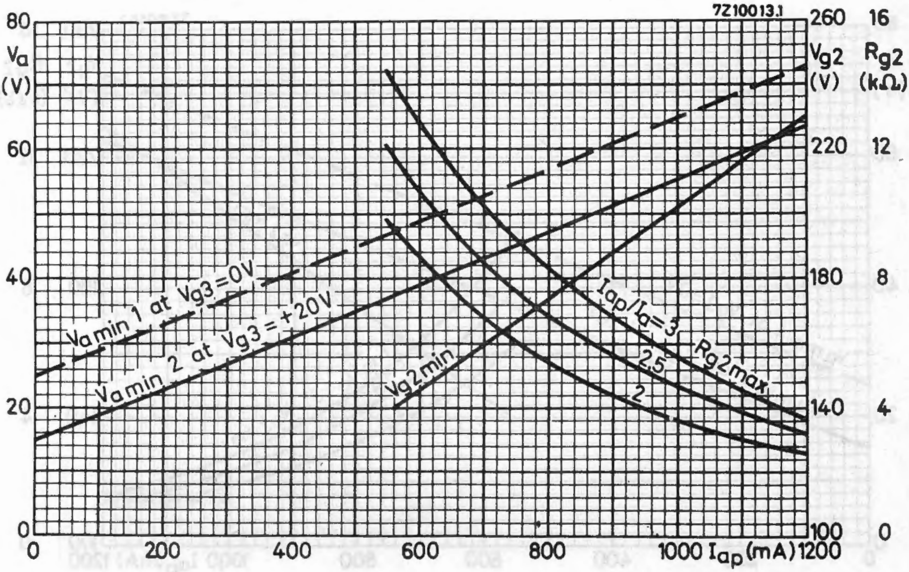
R_{g2} max : max. permissible screen grid series resistance for 400 V screen grid supply.

The specified values of I_{ap} are available at supply voltages 10% below nominal and throughout the tube life.

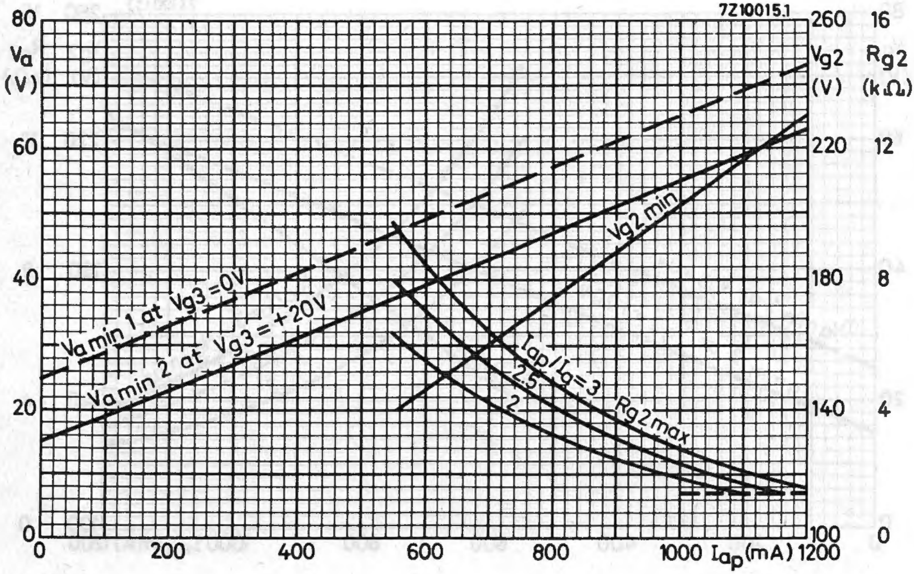
Remark: R_{g2} min for 400 V screen grid supply is 2.9 kΩ. (See page 3)

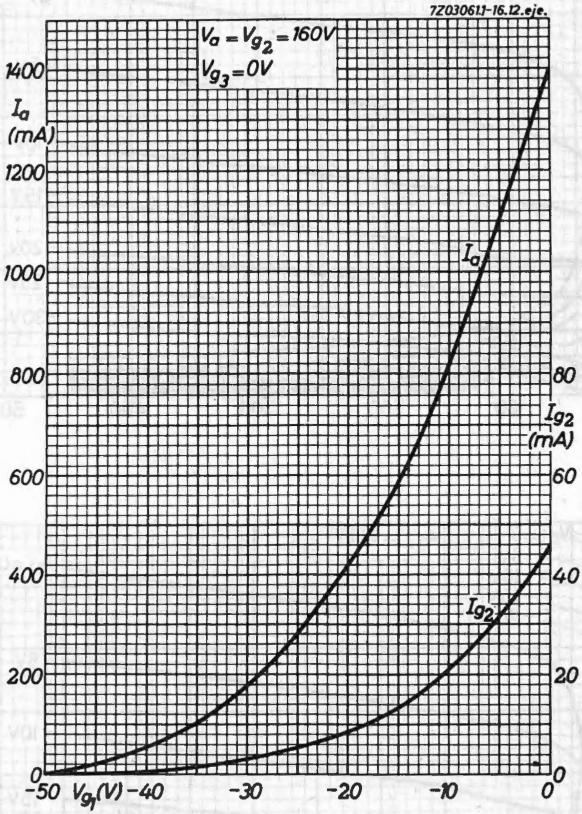


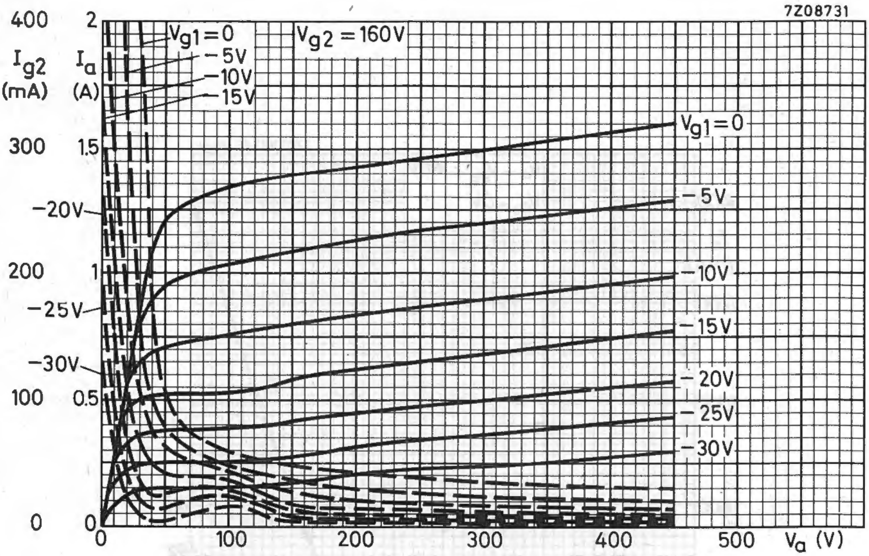
Min. required anode voltage.
$R_{g2\,max}$: max. permissible screen grid series resistance for 350 V screen grid supply.
The specified values of I_{ap} are available at supply voltages 10% below nominal and throughout the tube life.
Remark: $R_{g2\,min}$ for 350 V screen grid supply is 2.2 kΩ. (See page 3)

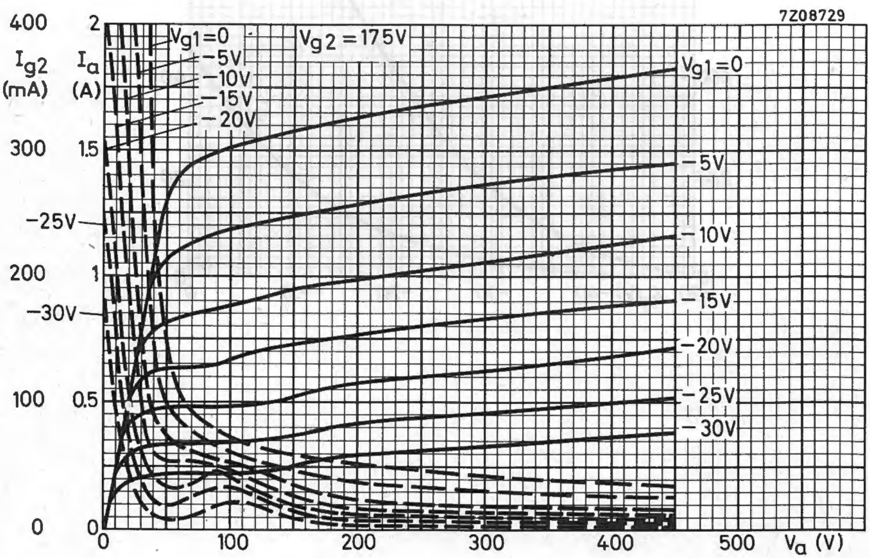


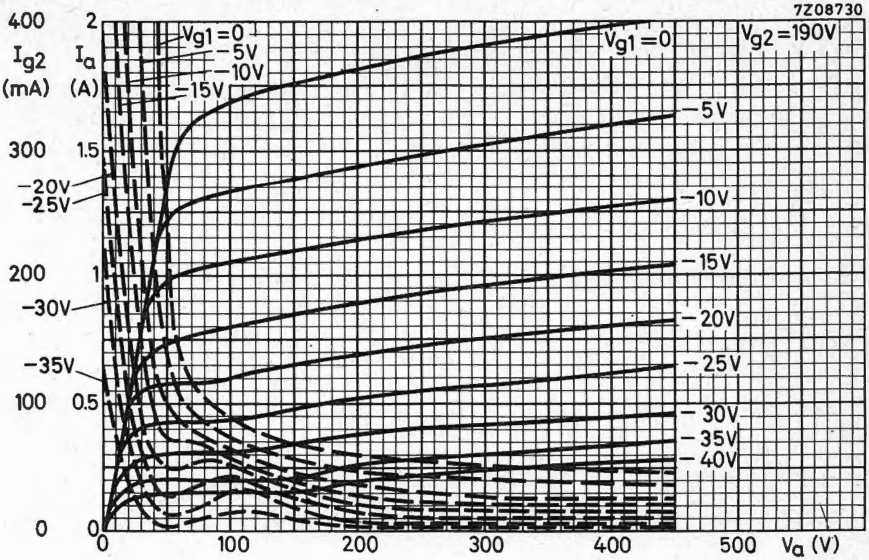
Min. required anode voltage.
R_{g2} max.: max. permissible screen grid series resistance for 280 V screen grid supply.
The specified values of I_{ap} are available at supply voltages 10% below nominal and throughout the tube life.
Remark: R_{g2} min for 280 V screen grid supply is 1.4 kΩ. (See page 3)




7Z03061.1-16.12.eje.
Va = Vg2 = 160V
Vg3 = 0V
Ia (mA)
1400
1200
1000
800
600
400
200
0
Ia
Ig2
Ig2 (mA)
80
60
40
20
0
-50
Vg1(V)
-40
-30
-20
-10
0


7Z08731
$V_{g2} = 160V$
$V_{g1} = 0$
−5V
−10V
−15V
−20V
−25V
−30V
400
300
200
100
0
I_{g2} (mA)
2
1.5
1
0.5
0
I_a (A)
0
100
200
300
400
500
V_a (V)


7Z08729
$V_{g2} = 175V$
$V_{g1} = 0$
−5V
−10V
−15V
−20V
−25V
−30V
400
300
200
100
0
I_{g2} (mA)
2
1.5
1
0.5
0
I_a (A)
0
100
200
300
400
500
V_a (V)


7Z08730
400
2
I_{g2}
(mA)
I_a
(A)
300
1.5
200
1
100
0.5
0
0
$V_{g1}=0$
−5V
−10V
−15V
−20V
−25V
−30V
−35V
$V_{g1}=0$
$V_{g2}=190V$
−5V
−10V
−15V
−20V
−25V
−30V
−35V
−40V
0
100
200
300
400
500
V_a (V)

LINE OUTPUT PENTODE

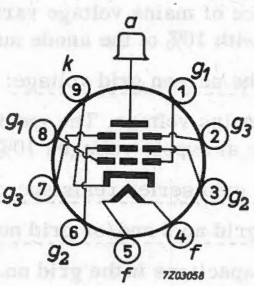
Output pentode intended for colour TV line deflection circuits.

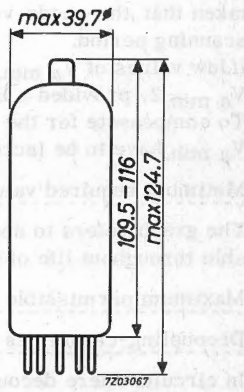
HEATING: Indirect by A.C. or D.C.; series supply

Heater current	I_f	300	mA
Heater voltage	V_f	40	V

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Magnoval
Top cap: Type 1
Mounting: Additional supporting of the tube at the top is required.





CAPACITANCES

Grid No. 1 to filament	C_{g1f}	max.	0.2	pF
Anode to grid No. 1	C_{ag1}	max.	3.0	pF
	C_{ag1}		2.5	pF

Data based on pre-production tubes.

TYPICAL CHARACTERISTICS (measured under pulse conditions)

Anode voltage	V_a	160	50	70	V
Grid No. 3 voltage	V_{g3}	0	0	0	V
Grid No. 2 voltage	V_{g2}	160	175	205	V
Grid No. 1 voltage	V_{g1}	0	−10	−11	V
Anode current	I_a	1400	800	1100	mA
Grid No. 2 current	I_{g2}	45	70	85	mA

OPERATING CONDITIONS (D.C. feedback)

Cut-off voltage

The minimum required cut-off voltage ($-V_{g1}$) during flyback at V_a = 7000 V and Z_{g1} = 1 kΩ at line frequency is at:

$$V_{g2} = 150\ V : V_{g1} = -175\ V$$
$$V_{g2} = 200\ V : V_{g1} = -195\ V$$
$$V_{g2} = 250\ V : V_{g1} = -215\ V$$

Supply voltage: See pages 4-5-6

Minimum required anode voltage: $V_{a\ min.}$

In order to prevent Barkhausen interference and loss of stabilization, care should be taken that the anode voltage never drops below the specified $V_{a\ min.}$ during the scanning period.
If low values of $V_{a\ min.}$ are required, the $V_{a\ min.}$ 1-line can be shifted over 10 V to $V_{a\ min.}$ 2, provided a D.C. voltage of at least +20 V is applied to the beamplate (g_3).
To compensate for the influence of mains voltage variations, the specified values of $V_{a\ min.}$ have to be increased with 10% of the anode supply voltage.

Minimum required values of the screen grid voltage: $V_{g2\ min.}$

The graph refers to nominal mains voltage. The specified values of I_{ap} will be available throughout life of the tube at supply voltages 10% below nominal.

Maximum permissible screen grid series resistance: R_{g2} max. See pages 4-5-6

Decoupling-capacitors in the grid no. 2 and/or grid no. 3 circuit

In circuits where decoupling capacitors in the grid no. 2 or the grid no. 3 circuits are applied, incidental flashover in the tube may give rise to excessive dischargecurrents - and component or tube failure.
Therefore it is recommended to limit the dischargecurrents to these capacitors by means of an 100 Ohm resistance between g2 and the g2-bypass capacitance and an 1000 Ohms resistance between g3 and the g3-bypass capacitance. The 1000 Ohms resistance should be protected by a spark-gap connected between g3 and earth.

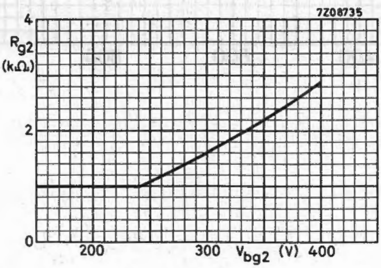
Hum

At Z_{g1} = 200 kΩ (f = 50 Hz), $V_{k/f}$ = 220 V_{RMS} and without wiring and socket capacitance, the equivalent grid hum voltage is less than 5 mV.

LIMITING VALUES

		Design centre rating system			
Anode voltage in cold condition	V_{ao}	max.	700	V	
Anode peak voltage	V_{ap}	max.	7000	V	
Anode dissipation	W_a	max.	35	W	
Grid No. 3 voltage	V_{g3}	max.	30	V	
Grid No. 2 voltage in cold condition	V_{g2o}	max.	700	V	
Grid No. 2 voltage	V_{g2}	max.	275	V	
Grid No. 2 dissipation	W_{g2}	max.	7	W	2)
Cathode current	I_k	max.	500	mA	
Cathode peak current	I_{kp}	max.	1500	mA	
Cathode-to-heater voltage	V_{kf}	max.	250	V	
Grid No. 1 resistor: fixed bias	R_{g1}	max.	0.5	MΩ	3)
stabilized circuits	R_{g1}	max.	2.2	MΩ	3)
Grid No. 3 circuit resistance	R_{g3}	max.	10	kΩ	4)
Bulb temperature	t_{bulb}	max.	300	°C	5)
		Design max. rating system			6)
Anode dissipation	W_a	max.	45	W	
Grid No. 2 dissipation	W_{g2}	max.	9	W	
Anode peak voltage	V_{ap}	max.	8000	V	1)
Neg. grid No. 1 peak voltage	$-V_{g1p}$	max.	550	V	1)

1. Max. pulse duration is 22% of a cycle and max. 18 μs.
2. To prevent an excessive value of W_{g2} the minimum R_{g2} values are given in the graph below.



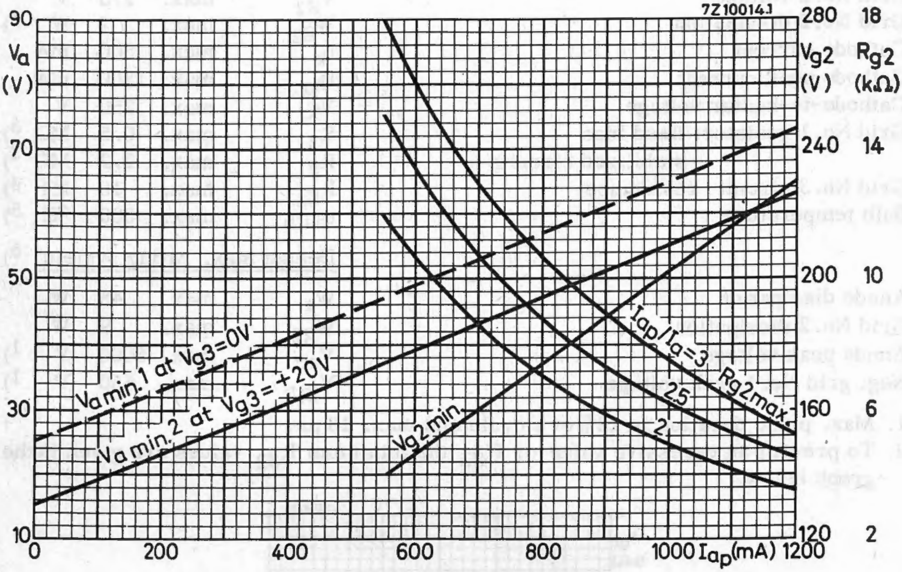
3. The circuit design has to be such that negative control grid currents up to 5 micro-amperes do not have any detrimental effect upon tube adjustment or circuit performance.
   Care should be taken that with 5 micro-amperes grid current the limiting values for I_k, W_a and W_{g2} are not exceeded.
4. With $R_{g3} \leq 10$ KΩ capacitive decoupling of g_3 is not required.
5. Absolute max. value.
6. The design maximum limits should not be exceeded with a nominal tube under the worst probable operating conditions at a normal picture width.

Min. required anode voltage.

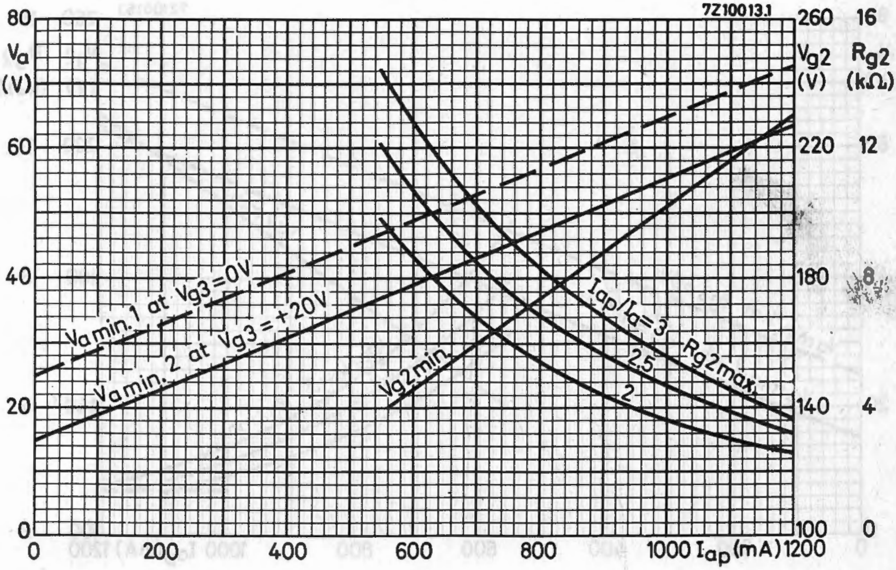
R_{g2} max.: max. permissible screen grid series resistance for 400 V screen grid supply.

The specified values of I_{ap} are available at supply voltages 10% below nominal and throughout the tube life.

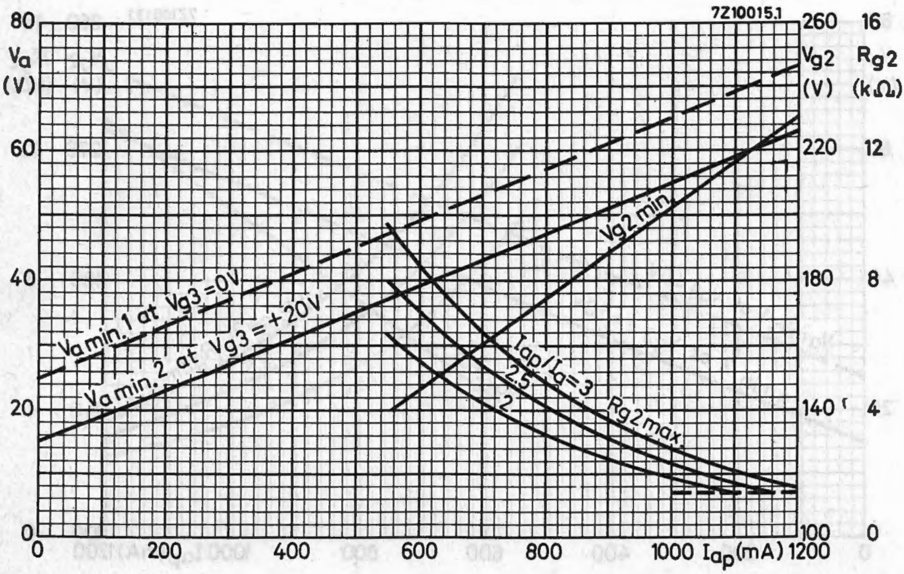
Remark: R_{g2} min. for 400 V screen grid supply is 2.9 kΩ. (See page 3)

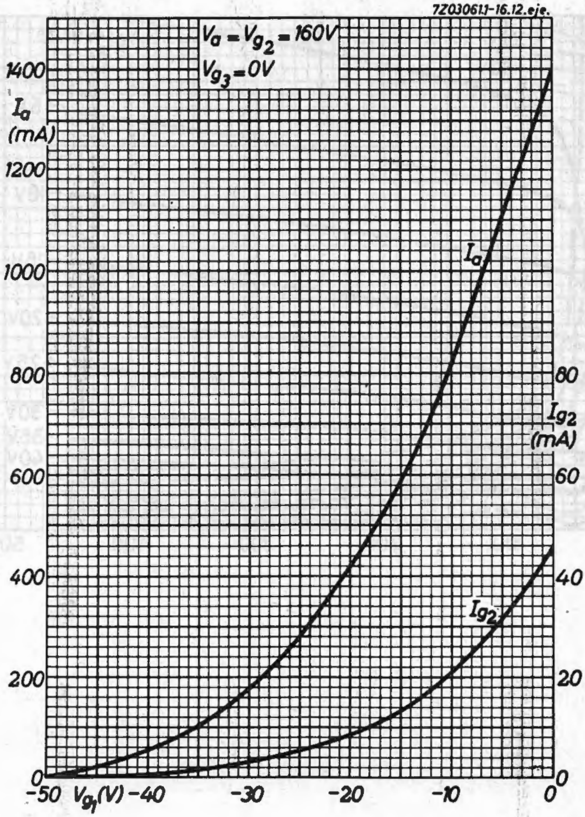


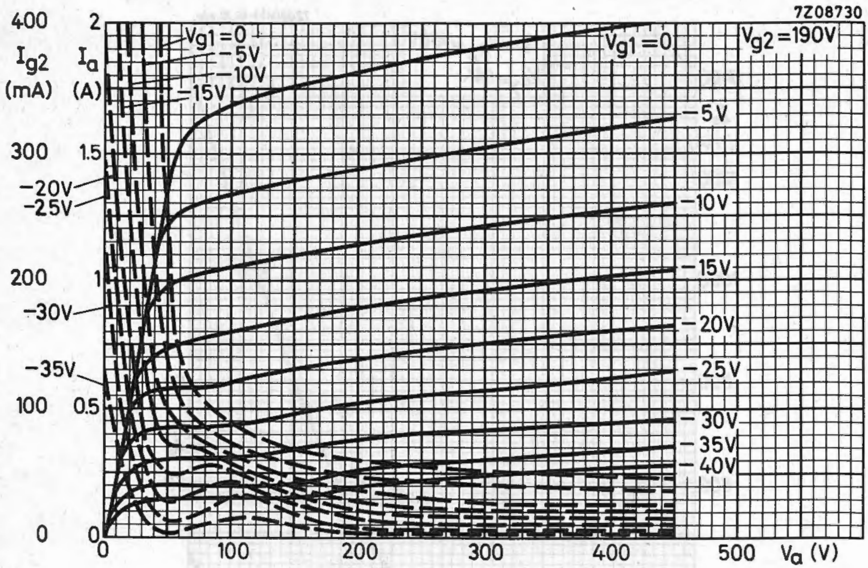
Min. required anode voltage.
$R_{g_2 max}$: max. permissible screen grid series resistance for 350 V screen grid supply.
The specified values of I_{ap} are available at supply voltages 10% below nominal and throughout the tube life.
Remark: $R_{g_2 min}$ for 350 V screen grid supply is 2.2 kΩ. (See page 3)



Min. required anode voltage.
$R_{g2\ max.}$: max. permissible screen grid series resistance for 280 V screen grid supply.
The specified values of I_{a_p} are available at supply voltages 10% below nominal and throughout the tube life.
Remark: $R_{g2\ min.}$ for 280 V screen grid supply is 1.4 kΩ. (See page 3)




7Z03061.1-16.12.eje.
$V_a = V_{g_2} = 160V$
$V_{g_3} = 0V$
1400
I_a
(mA)
1200
1000
800
600
400
200
0
I_a
80
I_{g2}
(mA)
60
40
I_{g2}
20
0
-50 V_{g_1}(V) -40
-30
-20
-10
0


7Z08730
400
2
I_{g2}
(mA)
I_a
(A)
300
1.5
200
1
100
0.5
0
0
$V_{g1}=0$
−5V
−10V
−15V
−20V
−25V
−30V
−35V
$V_{g1}=0$
$V_{g2}=190V$
−5 V
−10 V
−15 V
−20V
−25 V
− 30 V
− 35 V
− 40V
0
100
200
300
400
500
V_a (V)

VIDEO OUTPUT PENTODE

Luminance output tube in colour TV receivers.

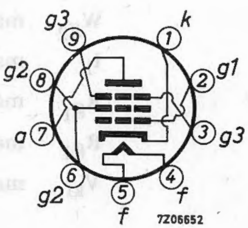
QUICK REFERENCE DATA				
Anode current	I_a		30	mA
Transconductance	S		40	mA/V
Anode dissipation	W_a	max.	6	W

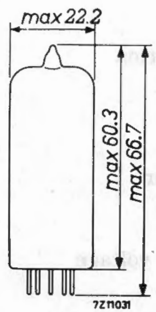
HEATING: Indirect by A.C. or D.C.; series supply

Heater current	I_f	300	mA
Heater voltage	V_f	16	V

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Noval





CAPACITANCES

Anode to all except grid No.1	$C_{a(g_1)}$		4	pF
Grid No.1 to all except anode	$C_{g_1(a)}$		20	pF
Anode to grid No.1	C_{ag_1}		0.075	pF
Anode to grid No.1	C_{ag_1}	max.	0.1	pF

TYPICAL CHARACTERISTICS

Anode voltage	V_a		170	V
Grid No.2 voltage	V_{g2}		170	V
Grid No.3 voltage	V_{g3}		0	V
Grid No.1 supply voltage	V_{bg1}		0	V
Cathode resistor (decoupled)	R_k		36	Ω
Anode current	I_a		30	mA
Grid No.2 current	I_{g2}		6.5	mA
Transconductance	S		40	mA/V
Amplification factor	μ_{g2g1}		70	-

LIMITING VALUES (Design centre rating system unless otherwise stated)

Anode supply voltage	V_{ba}	max.	400	V
Anode voltage,	V_{a_o}	max.	550	V
long term average	Va	max.	300	V
Grid No.2 voltage	V_{g2_o}	max.	550	V
	V_{g2}	max.	300	V
Anode dissipation	W_a	max.	6	W
Grid No.2 dissipation	W_{g2}	max.	2.5	W
	W_{g2}	max.	3.0	W 1)
Cathode current	I_k	max.	100	mA
Grid No.1 resistor	R_{g1}	max.	0.1	MΩ
at $R_k \geq 39\ \Omega$	R_{g1}	max.	0.5	MΩ
Cathode to heater voltage	V_{kf}	max.	200	V

[1]) Design maximum rating system including no signal condition.

OPERATING CONDITIONS (negative modulation)

V_b	=	250	V
R_b	=	330	Ω
R_{av}	=	560	Ω
R_a	=	2.7	kΩ
R_{g_2}	=	5.6	kΩ
R_k 1)	=	39	Ω
$+V_{bg_1}$	=	4	V

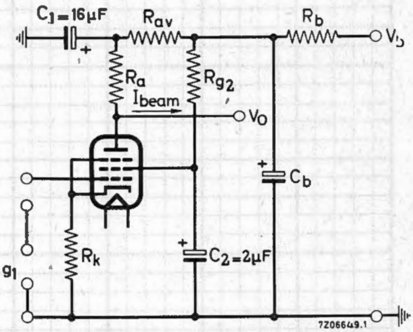


fig.1

V_{o_1}	=	100	V
V_{opp}	≧	140	V
Video-linearity	≧	0.8	–
V_{ipp}	ca.	5	V
I_{beam}	max.	7	mA

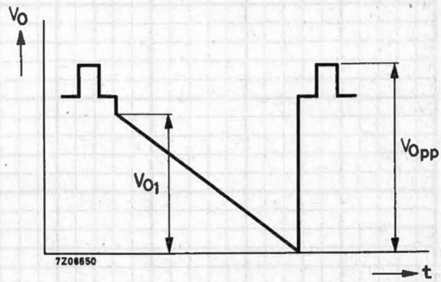
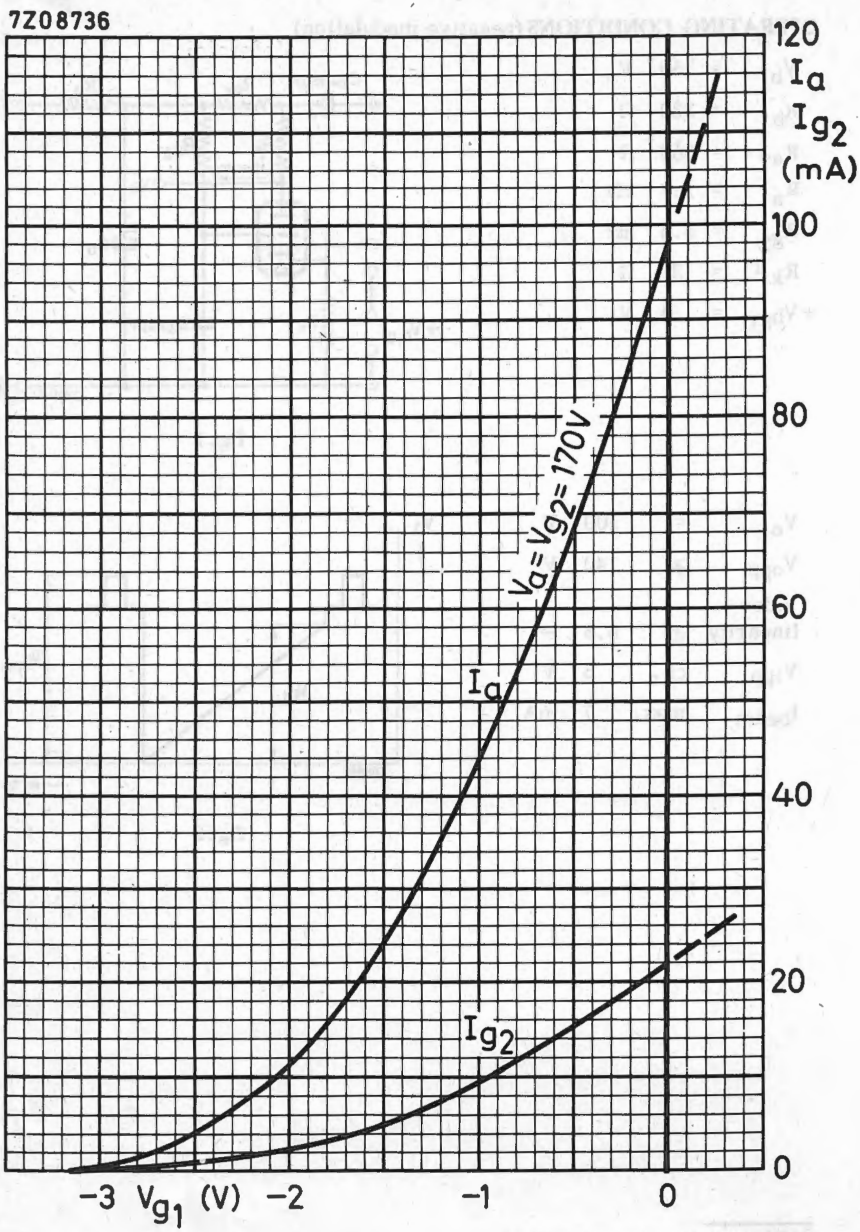
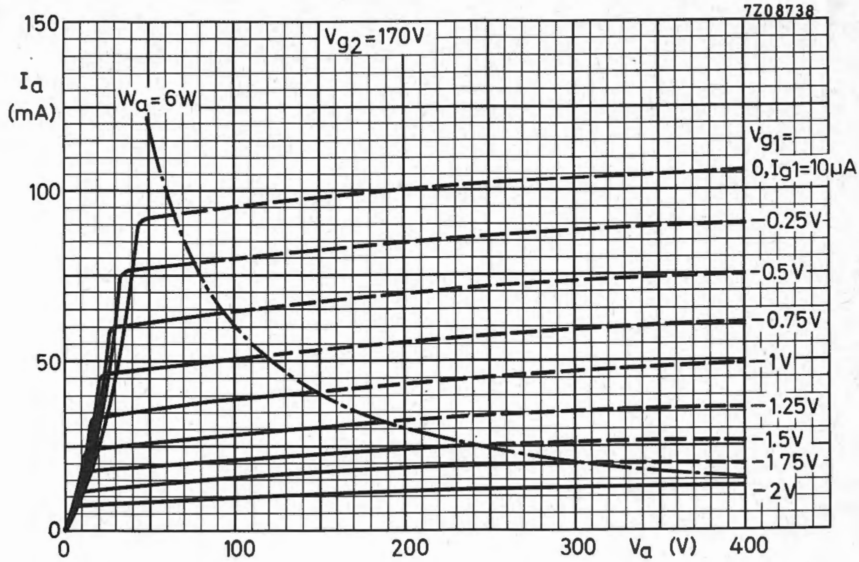
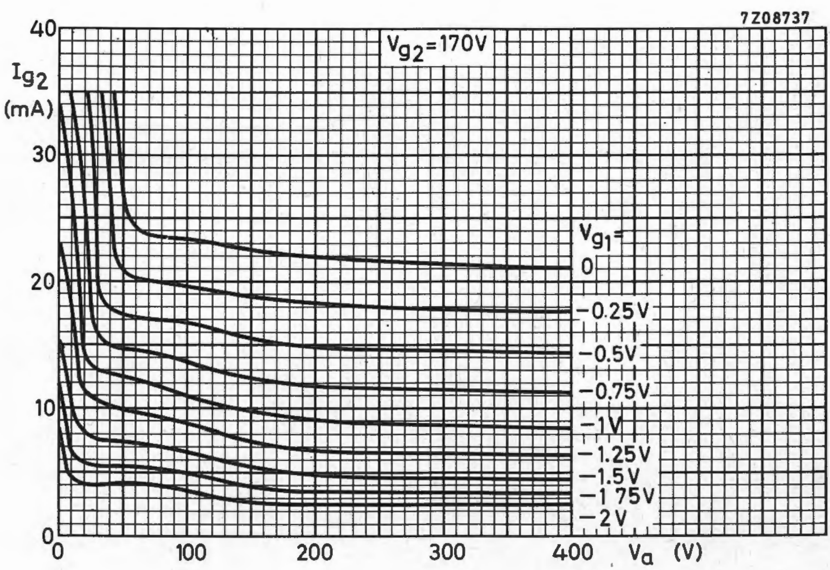


fig.2

1) Without by-pass capacitor.


7Z08736
120
I_a
I_{g2}
(mA)
100
80
60
40
20
0
$V_a = V_{g2} = 170V$
I_a
I_{g2}
−3
V_{g1} (V)
−2
−1
0


7Z08738
V_{g2}=170V
I_a (mA)
W_a=6W
V_{g1}=
0, I_{g1}=10μA
−0.25V
−0.5V
−0.75V
−1V
−1.25V
−1.5V
−1 75V
−2V
150
100
50
0
0
100
200
300
400
V_a (V)


7Z08737
V_{g2}=170V
I_{g2} (mA)
V_{g1}=
0
−0.25V
−0.5V
−0.75V
−1V
−1.25V
−1.5V
−1 75V
−2V
40
30
20
10
0
0
100
200
300
400
V_a (V)

BOOSTER DIODE

Booster diode intended for use in line time-base circuits of transformerless television receivers.

QUICK REFERENCE DATA				
Anode current, peak	I_{ap}	max.	450	mA
Anode voltage, peak	V_{ap}	max.	5000	V
Cathode to heater voltage, peak	V_{kf_p}	max.	5000	V

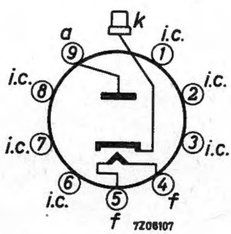
HEATING: Indirect by A.C. or D.C.; series supply

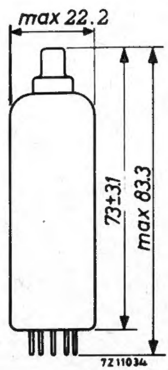
Heater current	I_f	300	mA
Heater voltage	V_f	17	V

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Noval

Top cap: Type 1





CAPACITANCES

Anode to all	C_a	6.4	pF
Cathode to heater	C_{kf}	2.8	pF

LIMITING VALUES (Design centre rating system, unless otherwise specified)

Supply voltage	V_{b_o}	max.	550	V
	V_b	max.	250	V
Anode dissipation	W_a	max.	3.5	W
Anode current, average	I_a	max	150	mA
peak	I_{a_p}	max.	450	mA
Anode voltage, peak	V_{a_p}	max	5000	V [1][2]
Absolute max.	V_{a_p}	max.	5600	V [1][2]
Cathode to heater voltage, peak	V_{kf_p}	max.	5000	V [1]
Series resistance heater chain	R_s	min.	80	Ω [3]
Heater to earth voltage	$V_{f/earth}$	max.	220	V_{RMS}

REMARK

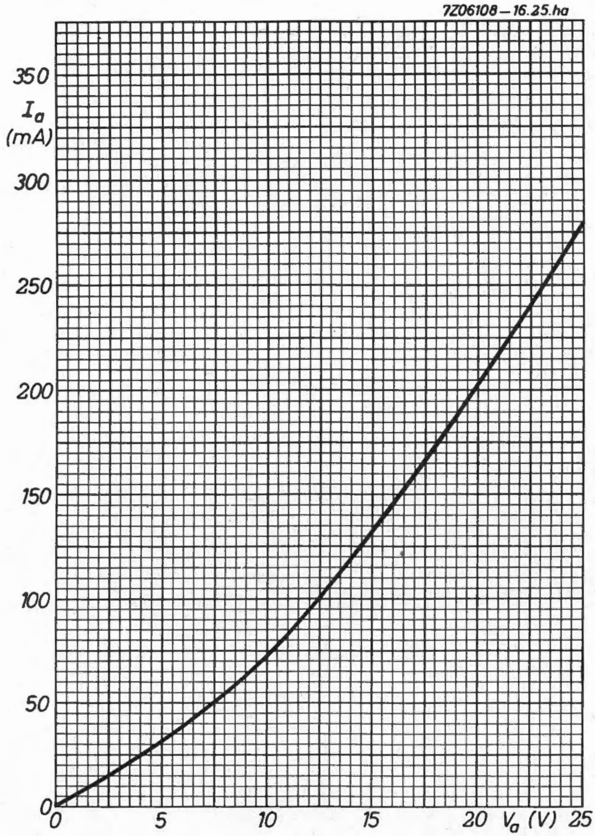
In general it will be necessary to take measures in order to prevent the maximum permissible screen grid dissipation of the tube that derive their anode voltage from this booster diode, from being exceeded during the heating-up time of the booster diode.

---

1) Max. pulse duration 22% of a cycle with a maximum of 18 μsec.

2) Cathode positive with respect to the anode.

3) R_S = minimum resistance of the heater chain between any heater pin and any mains terminal under working conditions (the heater of another tube can be used for this resistance).


7Z06108—16.25.ha
350
I_a
(mA)
300
250
200
150
100
50
0
0
5
10
15
20
V_a (V)
25

SINGLE ANODE RECTIFYING TUBE

Single anode high vacuum rectifying tube.

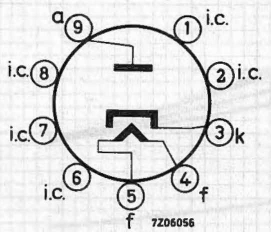
QUICK REFERENCE DATA			
Transformer voltage	V_{tr}	250	V_{RMS}
D.C. current	I_o	180	mA

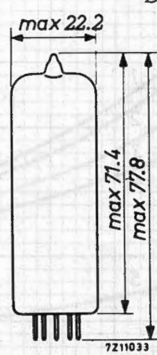
HEATING: Indirect by A.C. or D.C.; series supply

Heater current	I_f	300	mA
Heater voltage	V_f	19	V

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Noval





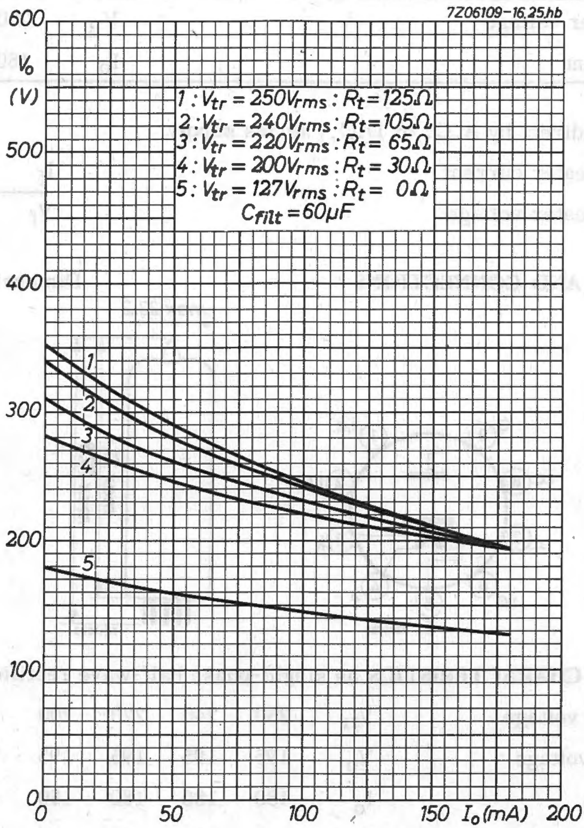
OPERATING CHARACTERISTICS as single-phase half-wave rectifier

Transformer voltage	V_{tr}	250	240	220	200	127	V_{RMS}
D.C. output voltage	V_o	195	195	195	195	127	V
D.C. current	I_o	180	180	180	180	180	mA
Protecting resistance	R_t	125	105	65	30	0	Ω
Input capacitance of smoothing filter	C_{filt}	60	60	60	60	60	μF

LIMITING VALUES (Design centre rating system)

Transformer voltage	V_{tr}	max.	250	V_{RMS}
Anode voltage, peak inverse	$V_{a_{inv_p}}$	max.	700	V
D.C. current	I_o	max.	180	mA
Cathode to heater voltage, peak	V_{kf_p}	max.	550	V 1)
Input capacitance of smoothing filter	C_{filt}	max.	60	μF 2)

Protecting resistance	R_t min.	100	80	40	30	0	Ω
at transformer voltage	V_{tr}	250	240	220	200	127	V



1) Max. 220 V_{RMS} A.C. voltage + max. 250 $V_{D.C.}$ voltage.
Cathode positive with respect to the heater.

2) When two tubes are placed in parallel, C_{filt} = max. 100 μF.
The resistor R_t must be inserted in the anode lead of each tube.

BOOSTER DIODE

Booster diode intended for use in line time-base circuits of transformerless television receivers.

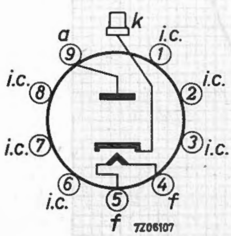
QUICK REFERENCE DATA			
Anode current, peak	I_{ap}	max. 550	mA
Anode voltage, negative peak	$-V_{ap}$	max. 6000	V
Cathode to heater voltage, peak	V_{kfp}	max. 6600	V

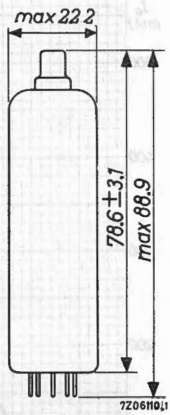
HEATING: Indirect by A.C. or D.C.; series supply

Heater current	I_f	300	mA
Heater voltage	V_f	30	V

DIMENSIONS AND CONNECTIONS Dimensions in.mm

Base: Noval
Top cap: Type 1





CAPACITANCES

Anode to all	C_a	8.6	pF
Cathode to heater	C_{kf}	2.7	pF

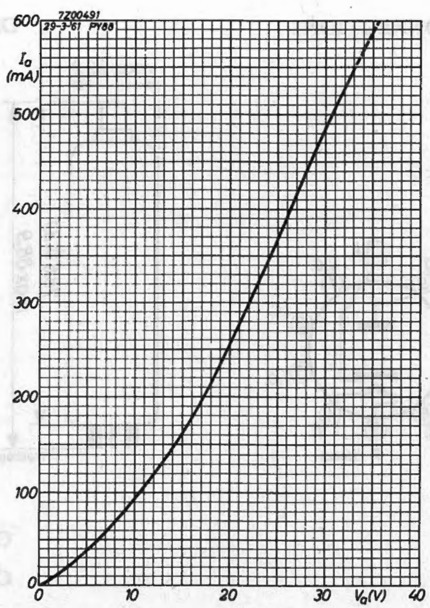
LIMITING VALUES (Design centre rating system unless otherwise specified)

Supply voltage	V_{bo}	max.	550	V
	V_b	max.	250	V
Anode dissipation	W_a	max.	5	W
Anode current, average	I_a	max.	220	mA
peak	I_{ap}	max.	550	mA
Anode voltage, negative peak	$-V_{ap}$	max.	6000	V [1])
negative peak (absolute max.)	$-V_{ap}$	max.	7500	V [1])
Cathode to heater voltage, peak	V_{kfp}	max.	6600	V [1])
Heater to earth voltage	$V_{f/earth}$	max.	220	V_{RMS}

→ Series resistance heater chain

During operation, the external resistance between either heater pin of the PY88 and either mains terminal should be at least 80 Ω when Vf/earth = 220 V_{RMS}
40 Ω when Vf/earth = 110 V_{RMS}

The hot heater resistances of other tubes in the heater chain can serve for this purpose.



[1]) Max. pulse duration 22% of a cycle but maximum 18 μs.

BOOSTER DIODE

Booster diode for timebase circuits of colour TV receivers.

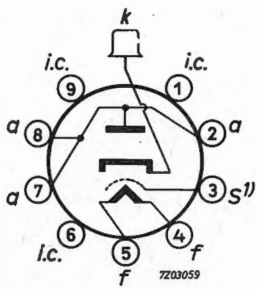
HEATING: Indirect by A.C. or D.C.; series supply

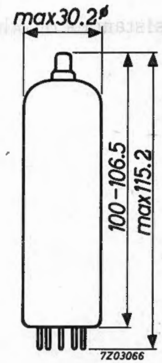
Heater current	I_f	300	mA
Heater voltage	V_f	42	V

MECHANICAL DATA — Dimensions in mm

Base: Magnoval

Cap: Type 1





CAPACITANCES

Anode to cathode	C_{ak}	13	pF
Cathode to heater	C_{kf}	3.7	pF

1) Insertion of a resistor of 300 Ω between pins 3 and 5 is recommended to improve the high-tension properties of the tube. If no resistor is used, pins 3 and 4 should be interconnected.

TYPICAL CHARACTERISTICS

Internal resistance (I_a = 440 mA)	R_i	45.5	Ω

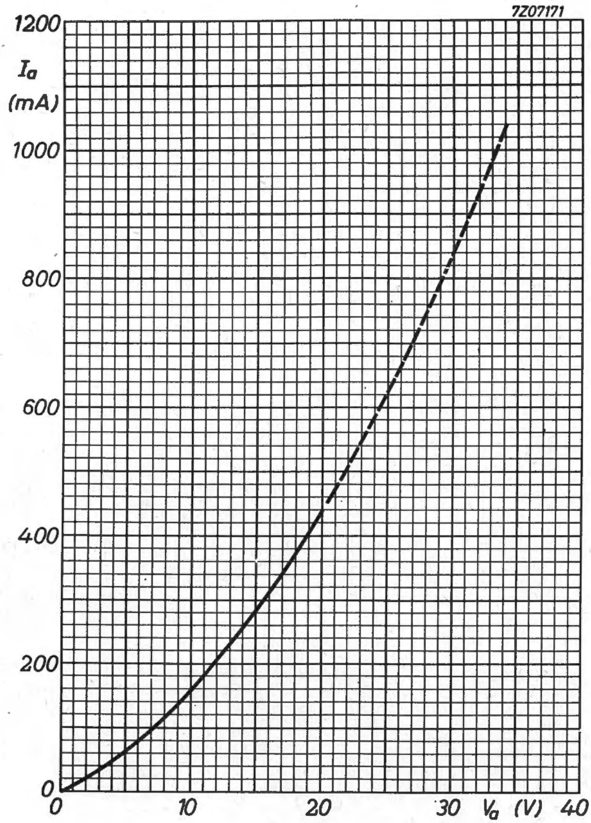
LIMITING VALUES (Design centre rating system)

Anode dissipation		W_a	max.	11	W
Anode current,	average	I_a	max.	440	mA
	peak	I_{a_p}	max.	800	mA
Anode voltage,	negative peak	$-V_{a_p}$	max.	5600	V [1]
	negative peak,(absolute max.)	$-V_{a_p}$	max.	7000	V [1]
Cathode to heater voltage, peak		V_{kf_p}	max.	6300	V [1]

→ Series resistance heater chain

During operation, the external resistance between either heater pin of the PY500 and either mains terminal should be at least 100 Ω when Vf/earth = 220 V_{RMS}
50 Ω when Vf/earth = 110 V_{RMS}
The hot heater resistances of other tubes in the heater chain can serve for this purpose.

[1]) Max. pulse duration 22% of a cycle, but max. 18 μs.


7Z07171
1200
I_a
(mA)
1000
800
600
400
200
0
0
10
20
30
V_a (V)
40

BOOSTER DIODE

Booster diode for timebase circuits of colour television receivers. The PY500A is unilaterally interchangeable with the PY500 in existing circuits. In new equipment designs the 300 Ω protection resistance between pins 3 and 5 can be deleted for the PY500A.

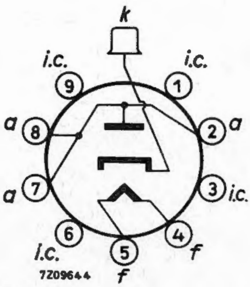
HEATING: Indirect by A.C. or D.C.; series supply

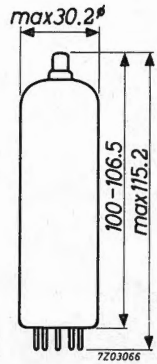
Heater current	I_f	300	mA
Heater voltage	V_f	42	V

MECHANICAL DATA Dimensions in mm

Base: Magnoval

Cap: Type 1





CAPACITANCES

Anode to cathode	C_{ak}	12.5	pF
Cathode to heater	C_{kf}	3.7	pF

TYPICAL CHARACTERISTICS

Internal resistance (I_a = 440 mA)	R_i		45.5	Ω

LIMITING VALUES (Design centre rating system)

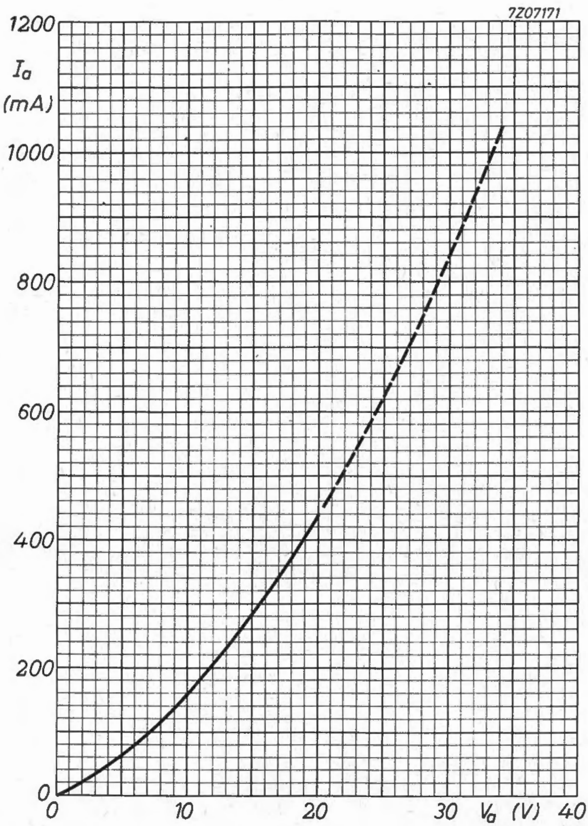
Anode dissipation	W_a	max.	11	W
Anode current, average	I_a	max.	440	mA
peak	I_{a_p}	max.	1000	mA
Anode voltage, negative peak	$-V_{a_p}$	max.	5600	V [1])
negative peak (absolute max.)	$-V_{a_p}$	max.	7000	V [1])
Cathode to heater voltage, peak	V_{kfp}	max.	6300	V [1])

→ Series resistance heater chain

During operation, the external resistance between either heater pin of the PY500A and either mains terminal should be at least 100 Ω when Vf/earth = 220 V_{RMS}
50 Ω when Vf/earth = 110 V_{RMS}

The hot heater resistances of other tubes in the heater chain can serve for this purpose.

[1]) Max. pulse duration 22% of a cycle, but max. 18 μs.


7Z07171
1200
I_a
(mA)
1000
800
600
400
200
0
0
10
20
30
V_a (V)
40

TRIPLE DIODE-TRIODE

Triple diode-triode intended for F.M. and A.M. signal detection and A.F. signal amplification.

QUICK REFERENCE DATA			
Triode section			
Anode current	I_a	1.0	mA
Transconductance	S	1.45	mA/V
Amplification factor	μ	70	-

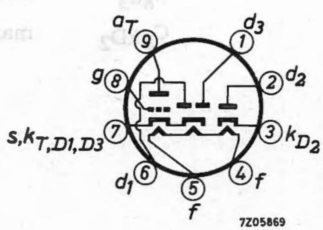
HEATING: Indirect by A.C. or D.C.; series supply

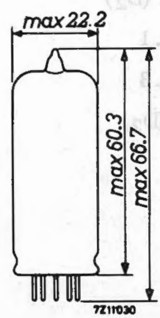
Heater current	I_f	100	mA
Heater voltage	V_f	28	V

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





It is recommended to connect pin 5 to earth.

CAPACITANCES

Triode section

Grid to all except anode	$C_{g(a)}$		1.9	pF
Anode to all except grid	$C_{a(g)}$		1.4	pF
Anode to grid	C_{ag}		2.0	pF
Grid to heater	C_{gf}	max.	0.04	pF

Diode sections

Diode No. 1 to all	C_{d_1}		0.8	pF
Diode No. 2 to all	C_{d_2}		4.8	pF
Diode No. 3 to all	C_{d_3}		4.8	pF
Cathode (D_2) to all	C_{kD_2}		5.0	pF
Diode No. 1 to heater	C_{d_1f}	max.	0.25	pF
Diode No. 3 to heater	C_{d_3f}	max.	0.2	pF
Cathode (D_2) to heater	C_{kD_2f}		2.5	pF

Between triode and diode sections

Anode to diode No. 1	C_{ad_1}	max.	0.12	pF
Anode to diode No. 3	C_{ad_3}	max.	0.1	pF
Anode to cathode (D_2)	C_{akD_2}	max.	0.01	pF
Grid to diode No. 1	C_{gd_1}	max.	0.07	pF
Grid to diode No. 3	C_{gd_3}	max.	0.02	pF
Grid to cathode (D_2)	C_{gkD_2}	max.	0.005	pF

TYPICAL CHARACTERISTICS

Triode section

Anode voltage	V_a	100	170	200	V
Grid voltage	V_g	-1	-1.85	-2.3	V
Anode current	I_a	0.8	1.0	1.0	mA
Transconductance	S	1.45	1.45	1.40	mA/V
Amplification factor	μ	70	70	70	-
Internal resistance	R_i	48	48	50	kΩ

OPERATING CHARACTERISTICS

Triode section as R.C. coupled A.F. amplifier

Grid resistor R_g = 10 MΩ

Supply voltage	V_b	200	200	200	170	170	170	V
Anode resistor	R_a	220	100	47	220	100	47	kΩ
Grid resistor next stage	R_g'	0.68	0.33	0.15	0.68	0.33	0.15	MΩ
Anode current	I_a	0.56	1.00	1.60	0.46	0.82	1.25	mA
Voltage gain	V_o/V_i	53	44	34	51	42	32	-
Distortion:								
at output voltage V_o = 3 V_{RMS}	d_{tot}	0.3	0.4	0.5	0.4	0.5	0.6	%
at output voltage V_o = 5 V_{RMS}	d_{tot}	0.4	0.6	0.9	0.5	0.8	1.1	%
at output voltage V_o = 8 V_{RMS}	d_{tot}	0.9	1.0	1.5	1.1	1.3	2.0	%

Supply voltage	V_b	100	100	100	V
Anode resistor	R_a	220	100	47	kΩ
Grid resistor next stage	R_g'	0.68	0.33	0.15	MΩ
Anode current	I_a	0.21	0.35	0.52	mA
Voltage gain	V_o/V_i	44	35	26	-
Distortion:					
at output voltage V_o = 3 V_{RMS}	d_{tot}	1.0	1.3	2.0	%
at output voltage V_o = 5 V_{RMS}	d_{tot}	1.7	2.3	4.3	%

TYPICAL CHARACTERISTICS

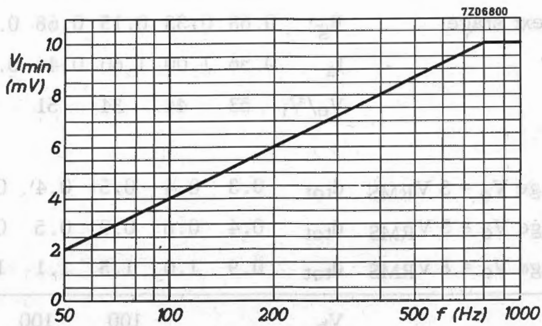
Diode section

Internal resistance diode No.1 at diode voltage V_{d_1} = +10 V	$R_i\,D_1$	5 kΩ
Internal resistance diode No.2 at diode voltage V_{d_2} = +5 V	$R_i\,D_2$	200 Ω
Internal resistance diode No.3 at diode voltage V_{d_3} = +5 V	$R_i\,D_3$	200 Ω
Ratio between R_i (D_2) and R_i (D_3)		min. 0.67 max. 1.5

Microphony Triode section

No special precautions against microphony are required in circuits where the input voltage is min. 10 mV for 50 mW output of the output tube at frequencies higher than 800 Hz.

At lower frequencies the sensitivity may be increased according to the figure below.



LIMITING VALUES (Design centre rating system)

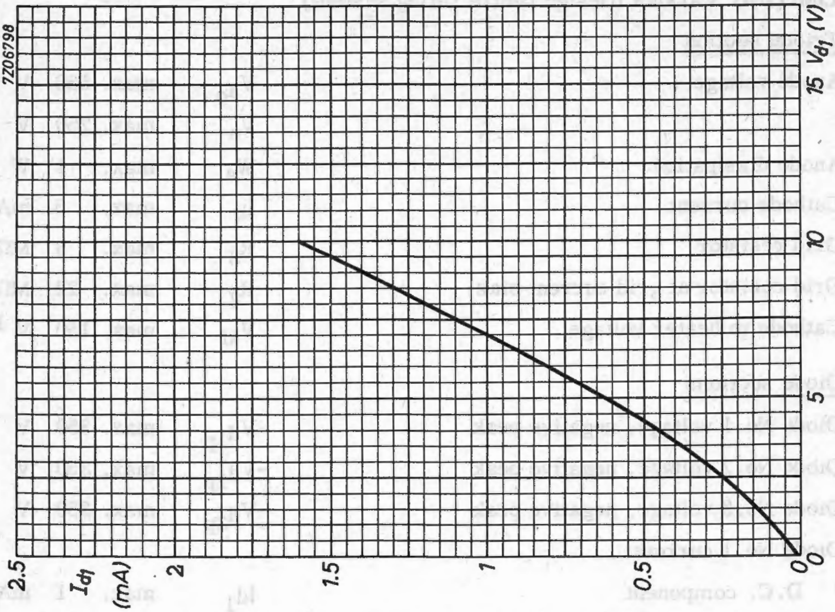
Triode section

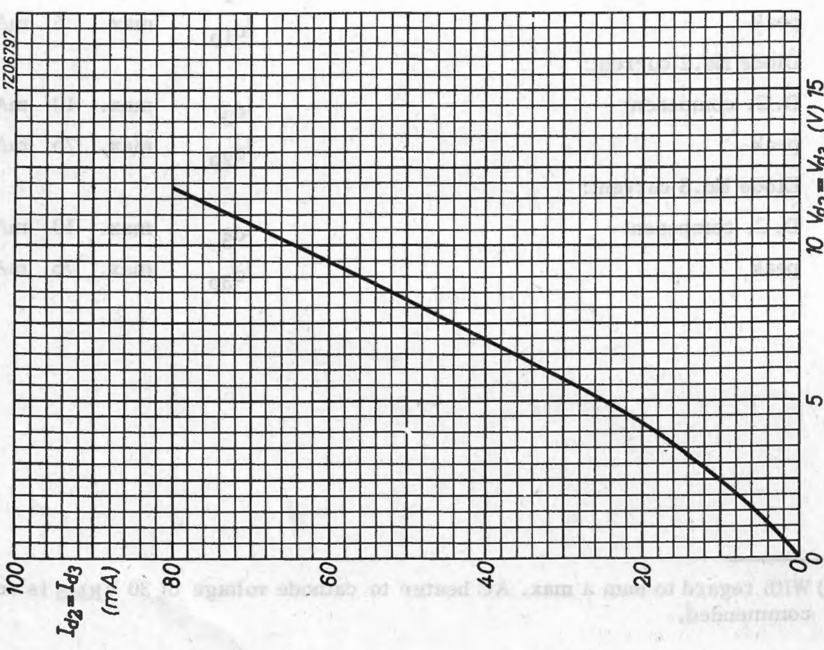
Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	250	V
Anode dissipation	W_a	max.	1	W
Cathode current	I_k	max.	5	mA
Grid resistor	R_g	max.	3	MΩ
Grid resistor at grid current bias	R_g	max.	22	MΩ
Cathode to heater voltage	V_{kf}	max.	150	V [1]

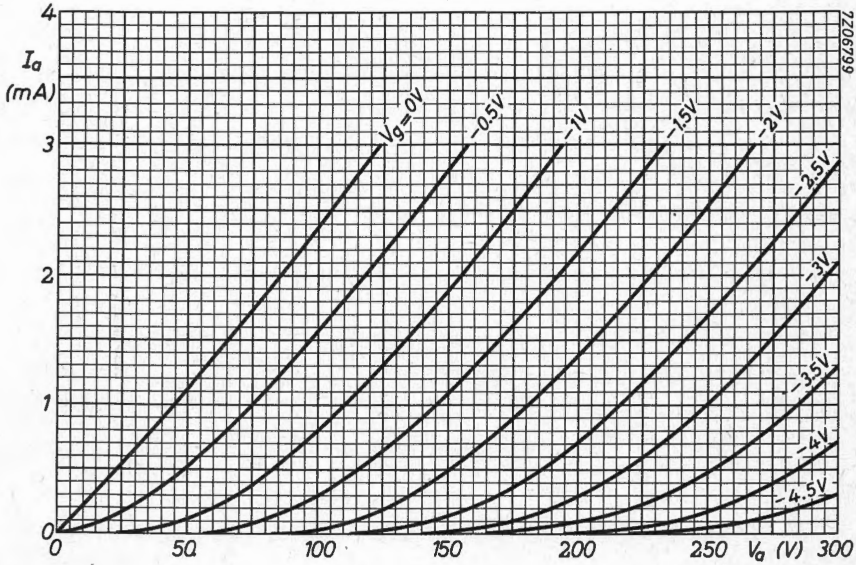
Diode sections

Diode No.1 voltage, negative peak	$-V_{d_{1p}}$	max.	350	V
Diode No.2 voltage, negative peak	$-V_{d_{2p}}$	max.	350	V
Diode No.3 voltage, negative peak	$-V_{d_{3p}}$	max.	350	V
Diode No.1 current:				
D.C. component	I_{d_1}	max.	1	mA
peak	$I_{d_{1p}}$	max.	6	mA
Diode No.2 current:				
D.C. component	I_{d_2}	max.	10	mA
peak	$I_{d_{2p}}$	max.	75	mA
Diode No.3 current:				
D.C. component	I_{d_3}	max.	10	mA
peak	$I_{d_{3p}}$	max.	75	mA

[1]) With regard to hum a max. AC heater to cathode voltage of 30 V_{RMS} is recommended.


7Z06798
I_{d1} (mA)
2.5
2
1.5
1
0.5
0
0
5
10
15 V_{d1} (V)


7Z06797
$I_{d2}=I_{d3}$ (mA)
100
80
60
40
20
0
0
5
10 $V_{d2}=V_{d3}$ (V) 15



I_a (mA)
4
3
2
1
0
0
50
100
150
200
250
V_a (V)
300
V_g=0V
−0.5V
−1V
−1.5V
−2V
−2.5V
−3V
−3.5V
−4V
−4.5V
7Z06799

DIODE-PENTODE

Diode-pentode. Pentode intended for use as R.F., I.F. or A.F. amplifier.

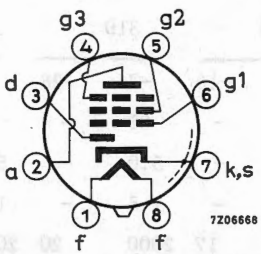
QUICK REFERENCE DATA			
Pentode section			
Variable transconductance			
Anode current	I_a	5	mA
Transconductance	S	2	mA/V
Amplification factor	μ_{g2g1}	16	-

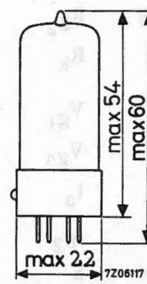
HEATING: Indirect by A.C. or D.C.; series supply

Heater current	I_f	100	mA
Heater voltage	V_f	12.6	V

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Rimlock





CAPACITANCES

Pentode section

Anode to all except grid No.1	$C_{a(g_1)}$		5.2	pF
Grid No.1 to all except anode	$C_{g_1(a)}$		4.1	pF
Anode to grid No.1	C_{ag_1}	max.	0.002	pF
Grid No.1 to heater	C_{g_1f}	max.	0.05	pF

Diode section

Diode to all	C_d		3.3	pF
Diode to heater	C_{df}	max.	0.02	pF

Between diode and pentode sections

Diode to grid No.1	C_{dg_1}	max.	0.0015	pF
Diode to anode	C_{da}	max.	0.15	pF

OPERATING CHARACTERISTICS

Pentode as R.F. or I.F. amplifier

Supply voltage	V_b	100		170		200		V
Anode resistor	R_a	0		0		0		Ω
Grid No.3 voltage	V_{g3}	0		0		0		V
Grid No.2 resistor	R_{g_2}	56		56		76		kΩ
Cathode resistor	R_k	310		310		310		Ω
Grid No 1 voltage	V_{g1}	−1.2	−16	−2	−28	−2	−34	V
Grid No 2 voltage	V_{g_2}	50	-	85	-	85	-	V
Anode current	I_a	2.8	-	5.0	-	5.0	-	mA
Grid No.2 current	I_{g_2}	0.9	-	1.5	-	1.5	-	mA
Transconductance	S	1700	17	2000	20	2000	20	μA/V
Internal resistance	R_i	0.85	min.10	0.9	min.10	1.0	min.10	MΩ
Amplification factor	$\mu_{g_2g_1}$	16	-	16	-	16	-	-
Equivalent noise resistance	R_{eq}	5.8	-	7.5	-	7.5	-	kΩ

OPERATING CHARACTERISTICS (continued)

Pentode as resistance coupled A.F. amplifier.

Supply voltage	V_b	170	170	V
Anode resistor	R_a	0.22	0.22	MΩ
Grid No.2 resistor	R_{g_2}	0.82	0.82	MΩ
Cathode resistor	R_k	2.7	2.7	kΩ
Grid No.1 supply voltage	V_R	0	−20	V
Anode current	I_a	0.50	0.14	mA
Grid No.2 current	I_{g_2}	0.17	0.04	mA
Voltage gain	V_o/V_i	80	6	-
Distortion:				
at output voltage V_o = 3 V_{RMS}	d_{tot}	0.8	3.6	%
at output voltage V_o = 5 V_{RMS}	d_{tot}	1.0	6.0	%
at output voltage V_o = 8 V_{RMS}	d_{tot}	1.2	9.0	%

Supply voltage	V_b	100	100	V
Anode resistor	R_a	0.22	0.22	MΩ
Grid No.2 resistor	R_{g_2}	0.82	0.82	MΩ
Cathode resistor	R_k	2.7	2.7	kΩ
Grid No.1 supply voltage	V_R	0	−10	V
Anode current	I_a	0.29	0.10	mA
Grid No.2 current	I_{g_2}	0.09	0.03	mA
Voltage gain	V_o/V_i	75	7	-
Distortion:				
at output voltage V_o = 3 V_{RMS}	d_{tot}	0.9	5.2	%
at output voltage V_o = 5 V_{RMS}	d_{tot}	1.1	8.0	%

LIMITING VALUES (Design centre rating system)

Pentode section

Anode voltage	V_{ao}	max. 550 V
	V_a	max. 250 V
Anode dissipation	W_a	max. 2 W
Grid No.2 voltage	V_{g2o}	max. 550 V
Grid No.2 voltage:		
at anode current max. 2.5 mA	V_{g_2}	max. 250 V
at anode current 5 mA	V_{g_2}	max. 125 V
Grid No.2 dissipation	W_{g_2}	max. 0.3 W
Cathode current	I_k	max. 10 mA
Grid No.1 resistor	R_{g_1}	max. 3 MΩ
Grid No.3 resistor	R_{g_3}	max. 3 MΩ
Cathode to heater voltage	V_{kf}	max. 150 V

Diode section

Diode voltage, negative peak	$-V_{dp}$	max. 350 V
Diode current	I_d	max. 0.8 mA
Diode current, peak	I_{dp}	max. 5 mA
Cathode to heater voltage	V_{kf}	max. 150 V

DOUBLE DIODE-TRIODE

Double diode-triode. Triode intended for use as A.F. amplifier.

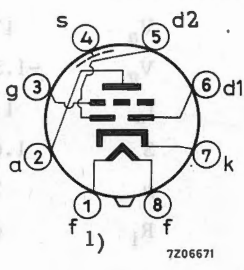
QUICK REFERENCE DATA			
Triode section			
Anode current	I_a	1.5	mA
Transconductance	S	1.65	mA/V
Amplification factor	μ	70	-

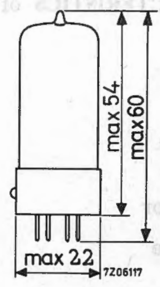
HEATING: Indirect by A.C. or D.C.; parallel supply

Heater current	I_f	100	mA
Heater voltage	V_f	14	V

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Rimlock





1) Earthed side of the filament circuit.

CAPACITANCES

Triode section

Grid to all except anode	$C_{g(a)}$		2.7	pF
Anode to all except grid	$C_{a(g)}$		1.7	pF
Anode to grid	C_{ag}		1.5	pF
Grid to heater	C_{gf}	max.	0.05	pF

Diode sections

Diode No.1 to all	C_{d_1}		0.8	pF
Diode No.2 to all	C_{d_2}		0.7	pF
Diode No.1 to diode No.2	$C_{d_1d_2}$	max.	0.3	pF
Diode No.1 to heater	C_{d_1f}	max.	0.1	pF
Diode No.2 to heater	C_{d_2f}	max.	0.05	pF

Between triode and diode sections

Diode No.1 to grid	C_{d_1g}	max.	0.007	pF
Diode No.2 to grid	C_{d_2g}	max.	0.03	pF
Diode No.1 to anode	C_{d_1a}	max.	0.01	pF
Diode No.2 to anode	C_{d_2a}	max.	0.01	pF

TYPICAL CHARACTERISTICS of the triode section

Anode voltage	V_a	170	100	V
Grid voltage	V_g	-1.55	-1.0	V
Anode current	I_a	1.5	0.8	mA
Transconductance	S	1.65	1.4	mA/V
Amplification factor	μ	70	70	-
Internal resistance	R_i	42	50	kΩ

OPERATING CHARACTERISTICS

Triode section as A.F. amplifier.

Supply voltage	V_b	170	100	170	100	V
Anode resistor	R_a	0.22	0.22	0.1	0.1	MΩ
Cathode resistor	R_k	5.6	5.6	3.9	3.9	kΩ
Grid resistor	R_g	1.0	1.0	1.0	1.0	MΩ
Grid resistor next stage	$R_{g'}$	0.68	0.68	0.33	0.33	MΩ
Anode current	I_a	0.28	0.18	0.45	0.28	mA
Voltage gain	V_o/V_i	44	41	37	34	-
Distortion at:						
output voltage V_o = 3 V_{RMS}	d_{tot}	1.1	1.4	1.1	2.0	%
output voltage V_o = 5 V_{RMS}	d_{tot}	1.3	1.9	1.7	3.5	%
output voltage V_o = 8 V_{RMS}	d_{tot}	1.85	–	2.6	–	%

Supply voltage	V_b	170	100	170	100	V
Anode resistor	R_a	0.22	0.22	0.1	0.1	MΩ
Cathode resistor	R_k	0	0	0	0	Ω
Grid resistor	R_g	22	22	22	22	MΩ
Grid resistor next stage	$R_{g'}$	0.68	0.68	0.33	0.33	MΩ
Anode current	I_a	0.46	0.21	0.82	0.35	mA
Voltage gain	V_o/V_i	48	41	42	35	-
Distortion at:						
output voltage V_o = 3 V_{RMS}	d_{tot}	0.95	1.45	0.75	1.6	%
output voltage V_o = 5 V_{RMS}	d_{tot}	1.1	2.0	1.0	2.8	%
output voltage V_o = 8 V_{RMS}	d_{tot}	1.3	–	1.2	–	%

LIMITING VALUES (Design centre rating system)

Triode section

Anode voltage	V_{a_o}	max. 550 V
	V_a	max. 250 V
Anode dissipation	W_a	max. 0.5 W
Cathode current	I_k	max. 5 mA
Grid resistor	R_g	max. 3 MΩ
Cathode to heater voltage	V_{kf}	max. 150 V

Diode sections (each diode)

Diode voltage, negative peak	$-V_{d_p}$	max. 350 V
Diode current		
average	I_d	max. 0.8 mA
peak	I_{dp}	max. 5 mA
Cathode to heater voltage	V_{kf}	max. 150 V

For curves refer to type UBC81.

DOUBLE DIODE-TRIODE

Double diode-triode. Triode intended for use as A.F. amplifier.

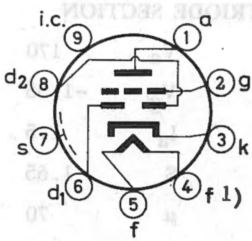
QUICK REFERENCE DATA			
Triode section			
Anode current	I_a	1.5	mA
Transconductance	S	1.65	mA/V
Amplification factor	μ	70	–

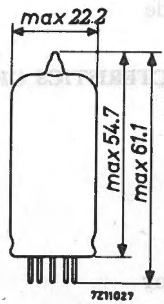
HEATING: Indirect by A.C. or D.C.; series supply

Heater current	I_f	100	mA
Heater voltage	V_f	14	V

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Noval





[1]) Earthed side of the heater circuit.

CAPACITANCES

Triode section

Grid to all except anode	$C_{g(a)}$		2.3	pF
Anode to all except grid	$C_{a(g)}$		2.3	pF
Anode to grid	C_{ag}		1.2	pF
Grid to heater	C_{gf}	max.	0.05	pF

Diode sections

Diode No.1 to all	C_{d_1}		0.9	pF
Diode No.2 to all	C_{d_2}		0.9	pF
Diode No.1 to diode No.2	$C_{d_1d_2}$	max.	0.2	pF
Diode No.1 to heater	C_{d_1f}	max.	0.25	pF
Diode No.2 to heater	C_{d_2f}	max.	0.05	pF

Between triode and diode sections

Diode No.1 to grid	C_{d_1g}	max.	0.007	pF
Diode No.2 to grid	C_{d_2g}	max.	0.007	pF
Diode No.1 to anode	C_{d_1a}	max.	0.005	pF
Diode No.2 to anode	C_{d_2a}	max.	0.01	pF

TYPICAL CHARACTERISTICS OF THE TRIODE SECTION

Anode voltage	V_a	170	100	V
Grid voltage	V_g	-1.55	-1.0	V
Anode current	I_a	1.5	0.8	mA
Transconductance	S	1.65	1.4	mA/V
Amplification factor	μ	70	70	-
Internal resistance	R_i	42	50	kΩ

OPERATING CHARACTERISTICS

Triode section as A.F. amplifier, circuit Fig.1

Supply voltage	V_b	170	100	170	100	V
Anode resistor	R_a	0.22	0.22	0.1	0.1	MΩ
Cathode resistor	R_k	5.6	5.6	3.9	3.9	kΩ
Grid resistor	R_g	1.0	1.0	1.0	1.0	MΩ
Grid resistor next stage	R_g	0.68	0.68	0.33	0.33	MΩ
Anode current	I_a	0.28	0.18	0.45	0.28	mA
Voltage gain	V_o/V_i	44	41	37	34	
Distortion at:						
output voltage $V_o = 3\ V_{RMS}$	d_t	1.1	1.4	1.1	2.0	%
output voltage $V_o = 5\ V_{RMS}$	d_t	1.3	1.9	1.7	3.5	%
output voltage $V_o = 8\ V_{RMS}$	d_t	1.85	-	2.6	-	%

Supply voltage	V_b	170	100	170	100	V
Anode resistor	R_a	0.22	0.22	0.1	0.1	MΩ
Cathode resistor	R_k	0	0	0	0	Ω
Grid resistor	R_g	22	22	22	22	MΩ
Grid resistor next stage	$R_{g'}$	0.68	0.68	0.33	0.33	MΩ
Anode current	I_a	0.46	0.21	0.82	0.35	mA
Voltage gain	V_o/V_i	48	41	42	35	
Distortion at						
output voltage $V_o = 3\ V_{RMS}$	d_t	0.95	1.45	0.75	1.6	%
output voltage $V_o = 5\ V_{RMS}$	d_t	1.1	2.0	1.0	2.8	%
output voltage $V_o = 8\ V_{RMS}$	d_t	1.3	-	1.2	-	%

OPERATING CHARACTERISTICS (continued)

Microphony

No special precautions against microphony are required in circuits where the input voltage is min. 10 mV for 50 mW output of the output tube.

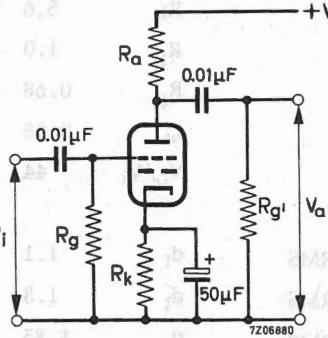


Fig. 1

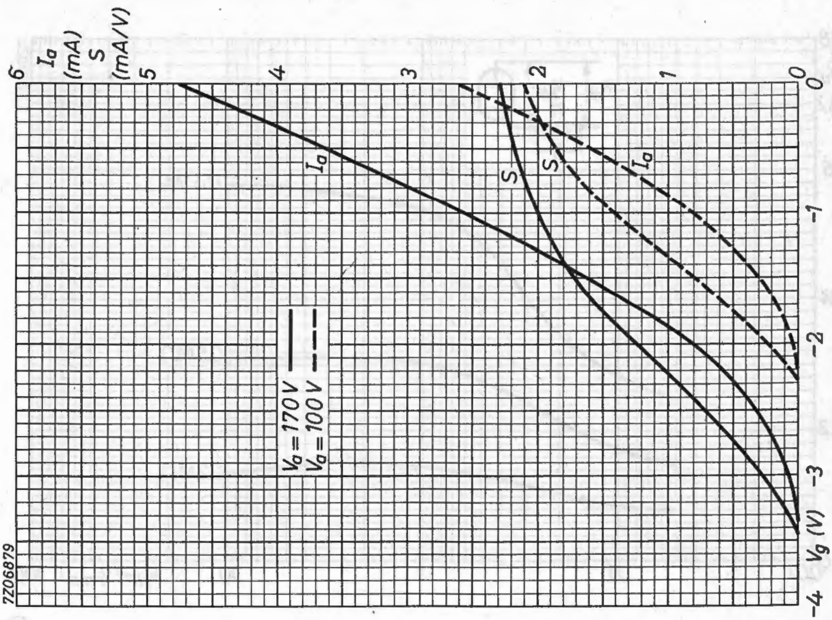
LIMITING VALUES (Design centre rating system)

Triode section

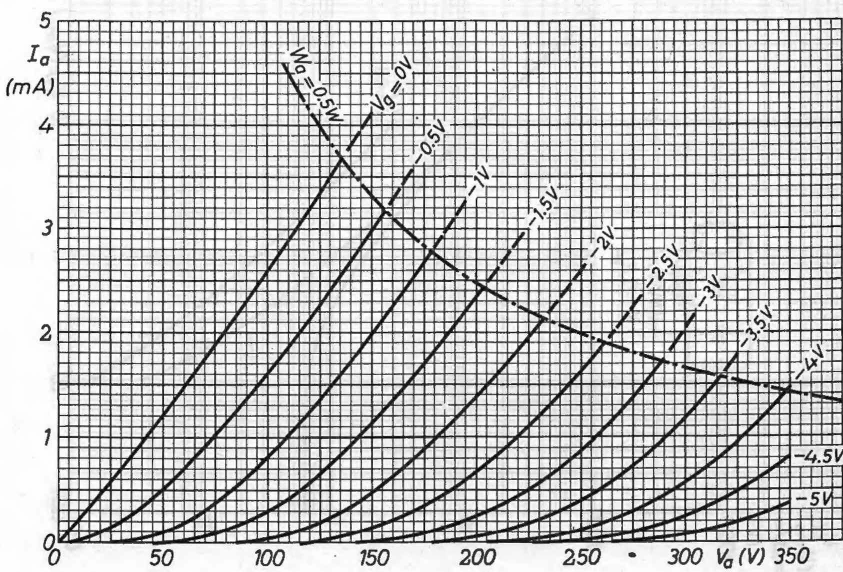
Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	250	V
Anode dissipation	W_a	max.	0.5	W
Cathode current	I_k	max.	5	mA
Grid resistor	R_g	max.	3	MΩ
Cathode to heater voltage	V_{kf}	max.	100	V

Diode sections (each diode)

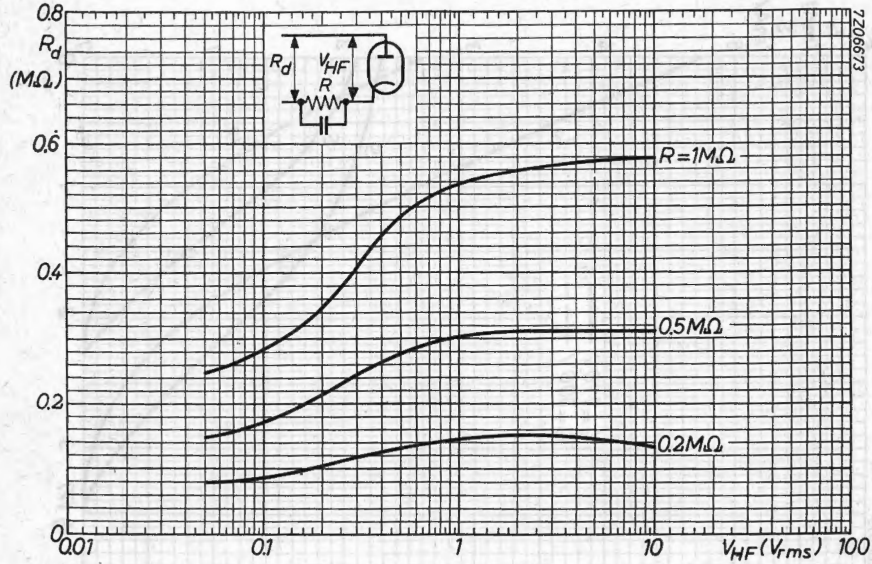
Diode voltage, negative peak	$-V_{dp}$	max.	350	V
Diode current:				
average	I_d	max.	0.8	mA
peak	I_{dp}	max.	5	mA
Cathode to heater voltage	V_{kf}	max.	100	V

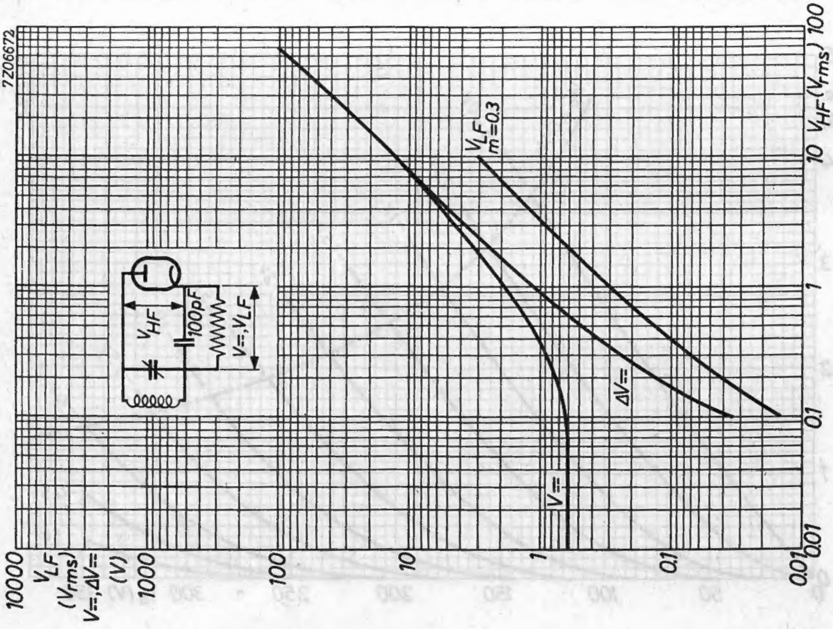


7Z06879
Ia (mA)
S (mA/V)
Ia
S
S
Ia
Va = 170 V
Va = 100 V
Vg (V)



7Z06940
Ia (mA)
Va (V)
Wa = 0.5W
Vg = 0V
−0.5V
−1V
−1.5V
−2V
−2.5V
−3V
−3.5V
−4V
−4.5V
−5V


7Z06673
R_d (MΩ)
R_d
V_{HF}
R
R=1MΩ
0.5MΩ
0.2MΩ
0.8
0.6
0.4
0.2
0
0.01
0.1
1
10
100
V_{HF} (V_{rms})


7Z06672
V_{LF} (V_{rms})
V=, ΔV= (V)
10000
1000
100
10
1
0.1
0.01
V_{HF} (V_{rms})
V_{HF}
100pF
V=, V_{LF}
V_{LF} m=0.3
ΔV=
V=

DOUBLE DIODE-PENTODE

Double diode-pentode. Pentode intended for use as R.F. or I.F. amplifier.

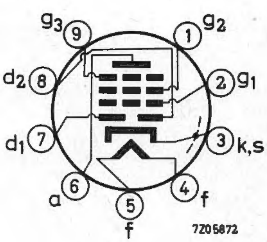
QUICK REFERENCE DATA			
Pentode section			
Variable transconductance			
Anode current	I_a	11	mA
Transconductance	S	4.5	mA/V
Amplification factor	$\mu_{g_2g_1}$	20	-

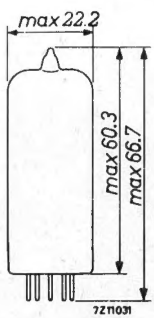
HEATING: Indirect by A.C. or D.C.; series supply

Heater current	I_f	100	mA
Heater voltage	V_f	19	V

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Noval





CAPACITANCES

Pentode section

Anode to all except grid No.1	$C_{a(g_1)}$	5.2	pF
Grid No.1 to all except anode	$C_{g_1(a)}$	5.0	pF
Anode to grid No.1	C_{ag_1}	max. 0.0025	pF
Grid No.1 to heater	C_{g_1f}	max. 0.05	pF

Diode sections

Diode No.1 to all	C_{d_1}	2.5	pF
Diode No.2 to all	C_{d_2}	2.5	pF
Diode No.1 to diode No.2	$C_{d_1d_2}$	max. 0.25	pF
Diode No.1 to heater	C_{d_1f}	max. 0.015	pF
Diode No.2 to heater	C_{d_2f}	max. 0.003	pF

Between pentode and diode sections

Diode No.1 to grid No.1	$C_{d_1g_1}$	max. 0.0008	pF
Diode No.2 to grid No.1	$C_{d_2g_1}$	max. 0.001	pF
Diode No.1 to anode	C_{d_1a}	max. 0.15	pF
Diode No.2 to anode	C_{d_2a}	max. 0.025	pF

TYPICAL CHARACTERISTICS

Pentode section

Anode voltage	V_a	200	170	100	V
Grid No.2 voltage	V_{g_2}	100	100	100	V
Grid No.3 voltage	V_{g_3}	0	0	0	V
Grid No.1 voltage	V_{g_1}	-1.5	-1 [1])	-2	V
Anode current	I_a	11	12	8.5	mA
Grid No.2 current	I_{g_2}	3.3	4	2.8	mA
Transconductance	S	4.5	5	3.5	mA/V
Amplification factor	$\mu_{g_2 g_1}$	20	20	20	–
Internal resistance	R_i	0.6	0.4	0.3	MΩ

OPERATING CHARACTERISTICS

Pentode section as R.F. or I.F. amplifier

Supply voltage	V_b	200		100		V
Anode resistor	R_a	0		0		Ω
Grid No.3 voltage	V_{g_3}	0		0		V
Grid No.2 resistor	R_{g_2}	30		0		kΩ
Grid No.1 voltage	V_{g_1}	-1.5	-20	-2	-10	V
Anode current	I_a	11	–	8.5	–	mA
Grid No.2 current	I_{g_2}	3.3	–	2.8	–	mA
Transconductance	S	4.5	0.12	3.5	0.11	mA/V
Internal resistance	R_i	0.6	–	0.3	–	MΩ

[1]) To avoid grid No.1 current the negative grid No.1 voltage should be min. 1.5 V

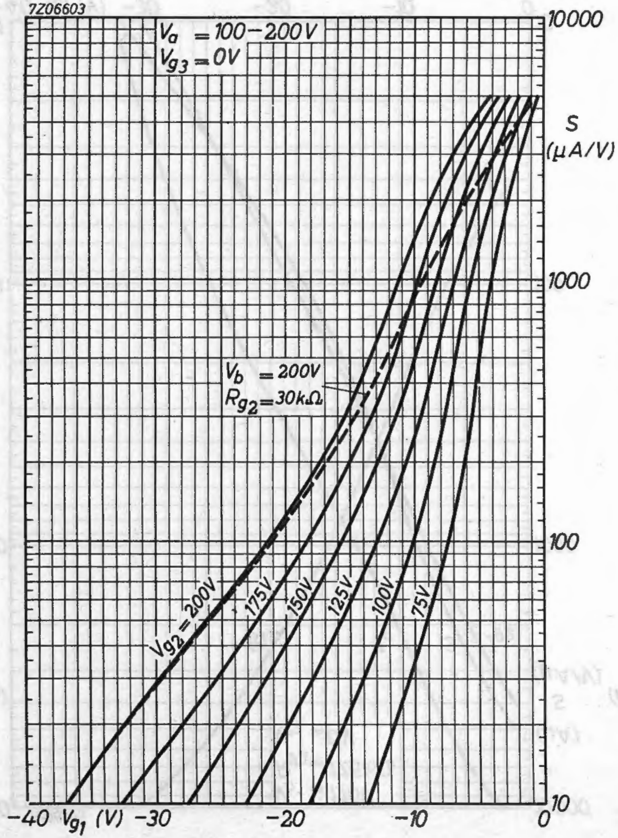
LIMITING VALUES (Design centre rating system)

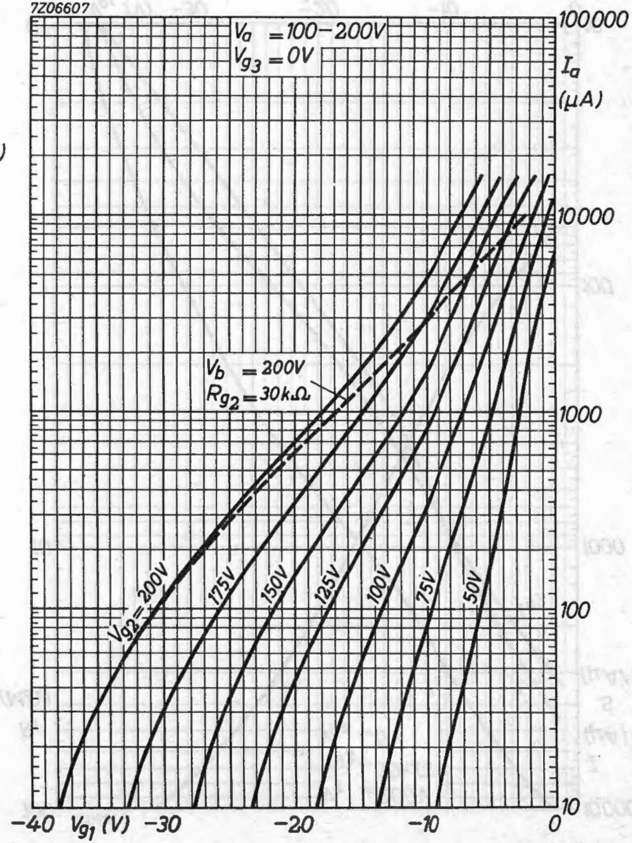
Pentode section

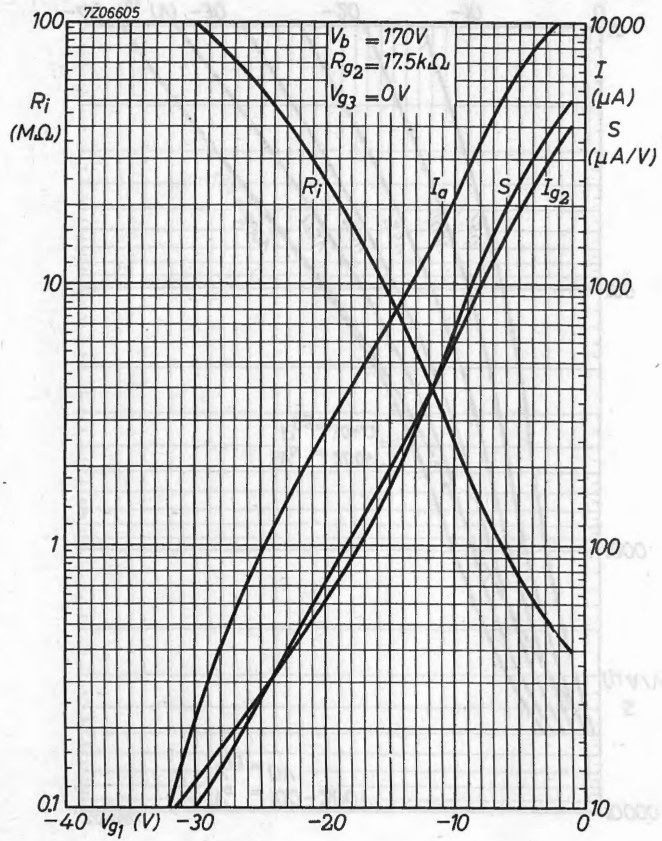
Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	250	V
Anode dissipation	W_a	max.	2.25	W
Grid No.2 voltage	$V_{g_{2o}}$	max.	550	V
Grid No.2 voltage				
at anode current I_a max. 4 mA	V_{g_2}	max.	250	V
at anode current I_a min. 8 mA	V_{g_2}	max.	125	V
Grid No.2 dissipation	W_{g_2}	max.	0.45	W
Cathode current	I_k	max.	16.5	mA
Grid No.1 resistor	R_{g_1}	max.	3	MΩ
Grid No.3 resistor	R_{g_3}	max.	10	kΩ
Cathode to heater voltage	V_{kf}	max.	100	V

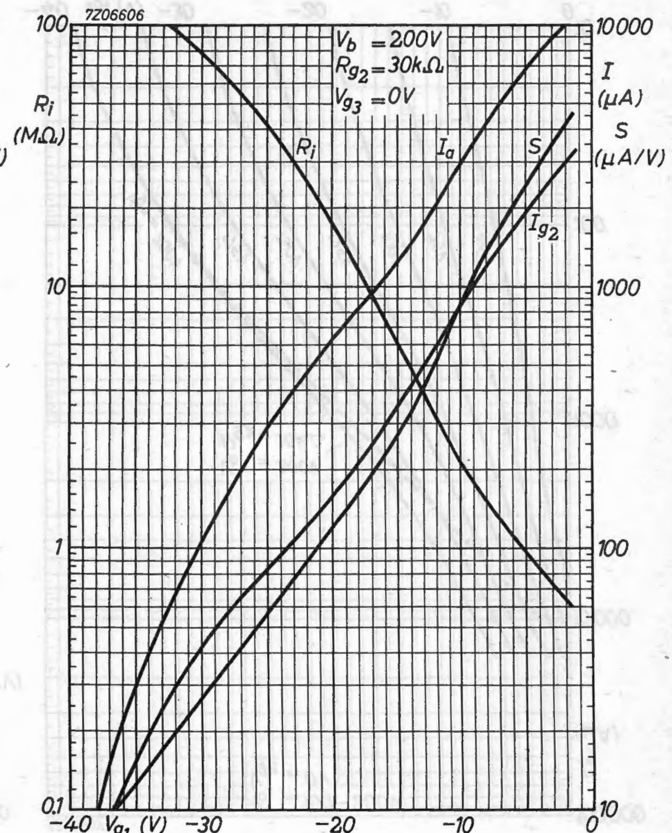
Diode sections (each diode)

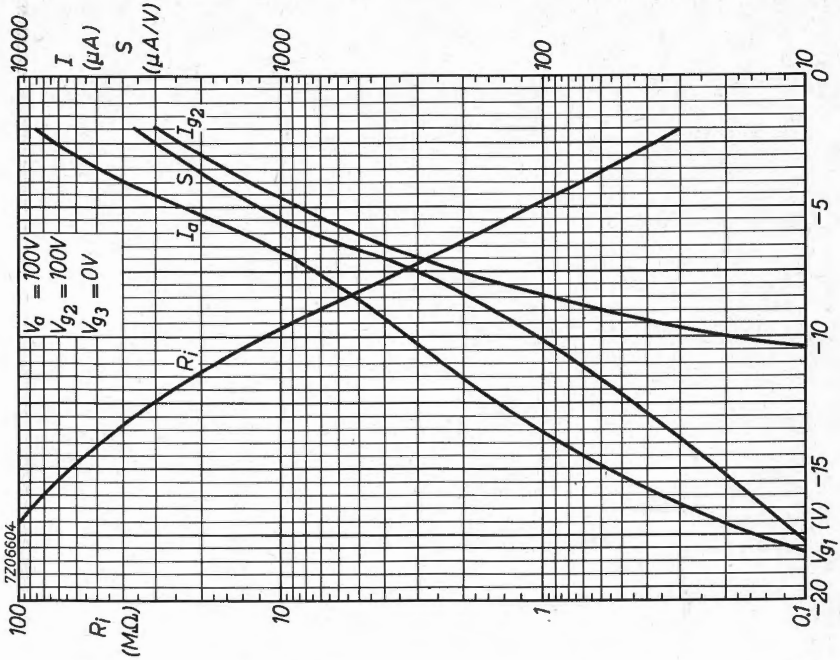
Diode voltage, negative peak	$-V_{dp}$	max.	200	V
Diode current; average	I_d	max.	0.8	mA
peak	I_{dp}	max.	5	mA
Cathode to heater voltage	V_{kf}	max.	100	V

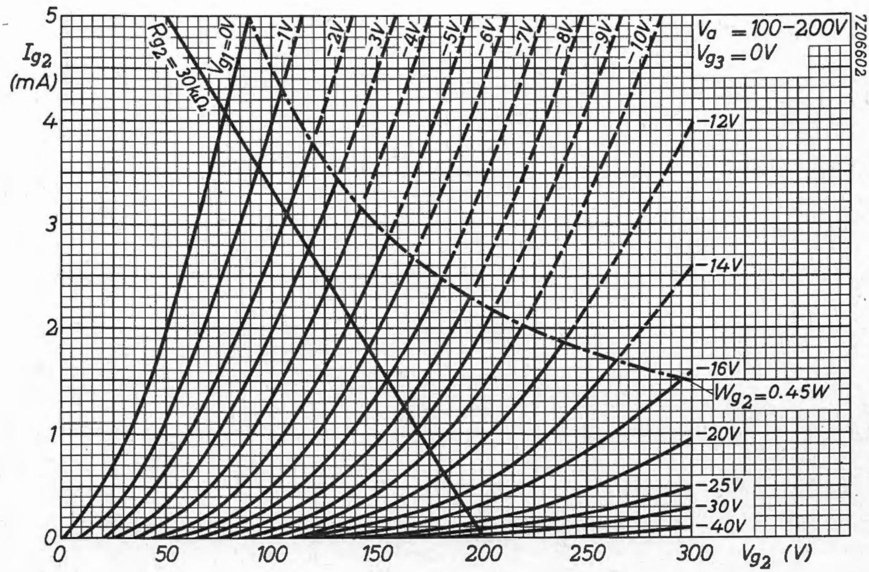

7Z06603
V_a = 100−200V
V_{g3} = 0V
V_b = 200V
R_{g2} = 30kΩ
V_{g2} = 200V
175V
150V
125V
100V
75V
S
(μA/V)
10000
1000
100
10
−40
V_{g1} (V)
−30
−20
−10
0


7Z06607
V_a = 100−200V
V_{g3} = 0V
V_b = 200V
R_{g2} = 30kΩ
V_{g2} = 200V
175V
150V
125V
100V
75V
50V
I_a
(μA)
100000
10000
1000
100
10
−40
V_{g1} (V)
−30
−20
−10
0


7Z06605
V_b = 170V
R_{g2} = 17.5kΩ
V_{g3} = 0V
R_i (MΩ)
I (μA)
S (μA/V)
R_i
I_a
S
I_{g2}
100
10
1
0.1
10000
1000
100
10
−40
V_{g1} (V)
−30
−20
−10
0


7Z06606
V_b = 200V
R_{g2} = 30kΩ
V_{g3} = 0V
R_i (MΩ)
I (μA)
S (μA/V)
R_i
I_a
S
I_{g2}
100
10
1
0.1
10000
1000
100
10
−40
V_{g1} (V)
−30
−20
−10
0


7Z06604
$V_a = 100V$
$V_{g2} = 100V$
$V_{g3} = 0V$
I (μA)
S (μA/V)
I_{g2}
S
I_a
R_i
R_i (MΩ)
V_{g1} (V)


7Z06602
$V_a = 100-200V$
$V_{g3} = 0V$
I_{g2} (mA)
V_{g2} (V)
$R_{g2} = 30k\Omega$
$V_{g1} = 0V$
$W_{g2} = 0.45W$

R.F. DOUBLE TRIODE

Double triode intended for use as R.F. amplifier and self oscillating mixer.

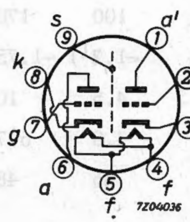
QUICK REFERENCE DATA			
Anode current	I_a	10	mA
Transconductance	S	6.7	mA/V
Amplification factor	μ	48	–

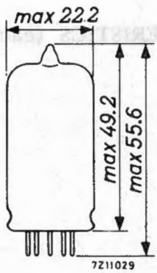
HEATING: Indirect by A.C. or D.C.; series supply

Heater current	I_f	100	mA
Heater voltage	V_f	26	V

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Noval





CAPACITANCES (each unit unless otherwise specified)

Anode to grid	C_{ag}		1.5	pF
Anode to cathode	C_{ak}		0.18	pF
Anode to cathode + heater + screen	$C_{a/kfs}$		1.2	pF
Grid to cathode + heater + screen	$C_{g/kfs}$		3.1	pF
Anode to cathode + heater + screen (measured with external screen of 22.5 mm diam.)	$C_{a/kfs}$		1.8	pF
Anode to anode other unit	$C_{aa'}$	max.	0.04	pF
Anode to anode other unit (measured with external screen of 22.5 mm diam.)	$C_{aa'}$	max.	0.008	pF
Grid to grid other unit	$C_{gg'}$	max.	0.003	pF
Anode to grid other unit	$C_{ag'}$	max.	0.008	pF
Anode to grid other unit	$C_{a'g}$	max.	0.008	pF
Anode to cathode other unit	$C_{ak'}$	max.	0.008	pF
Grid to cathode other unit	$C_{gk'}$	max.	0.003	pF
Anode to cathode other unit	$C_{a'k}$	max.	0.008	pF
Grid to cathode other unit	$C_{g'k}$	max.	0.003	pF

TYPICAL CHARACTERISTICS (each unit)

Anode voltage	V_a	100	170	200	V
Grid voltage	V_g	-1.2[1]	-1.75	-2.4	V
Anode current	I_a	4.5	10	10	mA
Transconductance	S	4.8	6.7	6	mA/V
Amplification factor	μ	46	48	46	-

[1]) In this case grid current may occur. If this is not permissible, a condition with a bias of −1.5 V should be chosen.

OPERATING CHARACTERISTICS

As R.F. amplifier (unit a, g, k)

Supply voltage	V_b	170	170	100	V
Anode resistor	R_a	1.3	1.5	1.5	kΩ
Anode voltage	V_a	161	155	91	V
Cathode resistor	R_k	330	150	138	Ω
Grid voltage	V_g	−2.2	−1.5	−0.8	V
Anode current	I_a	6.6	9.8	5.7	mA
Transconductance	S	5.1	6.7	5.9	mA/V
Internal resistance	R_i	8.5	7	8	kΩ
Grid input resistance (f = 100 MHz)	r_g	5.2	3.8	2.8	kΩ
Equivalent noise resistance	R_{eq}	0.82	0.55	0.61	kΩ

As self oscillating additive mixer (each unit)

Anode supply voltage	V_b	100	170	200	V
Anode resistor	R_a	4.7	4.7	8.2	kΩ
Grid resistor	R_g	1	1	1	MΩ
Oscillator voltage	$V_{osc.}$	1.8	2.8	2.8	V_{RMS}
Anode current	I_a	2.7	5.5	6	mA
Conversion conductance	S_c	2.2	2.8	2.9	mA/V
Internal resistance	R_i	19	15	14	kΩ
Grid input resistance (f = 100 MHz)	r_g		15		kΩ

LIMITING VALUES (each unit) (Design centre rating system)

Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	250	V
Anode dissipation	W_a	max.	2.5	W
Anode dissipation, total	W_a+W_a'	max.	4.5	W
Cathode current	I_k	max.	15	mA
Cathode to heater voltage	V_{kf}	max.	90	V
Grid voltage (negative)	$-V_g$	max.	100	V
Grid resistor	R_g	max.	1	MΩ

For curves please refer to type PCC85

TRIODE-HEXODE

Triode-hexode intended for use as frequency changer.

QUICK REFERENCE DATA			
Triode section			
Anode current	I_a	4.9	mA
Effective transconductance	S_{eff}	0.6	mA/V
Oscillator voltage	V_{osc}	7	V_{RMS}
Hexode section			
Anode current	I_a	2.2	mA
Conversion conductance	S_c	0.45	mA/V

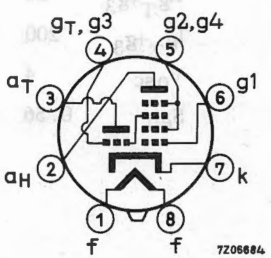
HEATING: Indirect by A.C. or D.C.; series supply

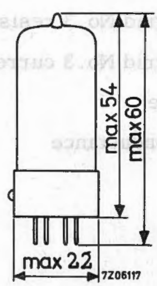
Heater current	I_f	100	mA
Heater voltage	V_f	14	V

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Rimlock





CAPACITANCES

Triode section

Anode to all except grid and grid No.3	$C_{a_T(g_Tg_3)}$	1.5 pF
Grid and grid No.3 to all except anode	$C_{g_Tg_3/(a_T)}$	4.9 pF
Grid and grid No.3 to anode	$C_{g_Tg_3/a_T}$	1.2 pF

Hexode section

Anode to all	C_a	6.0 pF
Grid No.1 to all	C_{g_1}	3.4 pF
Anode to grid No.1	C_{ag_1}	max. 0.1 pF
Grid No.1 to heater	C_{g_1f}	max. 0.15 pF

Between triode and hexode sections

Grid triode and grid No.3 to grid No.1 hexode	$C_{g_Tg_3/g_{1H}}$	max. 0.35 pF
Grid triode and grid No.3 to anode hexode	$C_{g_Tg_3/a_H}$	max. 0.2 pF

OPERATING CHARACTERISTICS

Triode as oscillator

Supply voltage	V_b	100	170	200	V
Anode resistor	R_a	10	10	10	kΩ
Anode current	I_a	2.8	4.9	4.6	mA
Grid triode and grid No.3 resistor	$R_{g_T+g_3}$	20	20	20	kΩ
Grid triode and grid No.3 current	$I_{g_T+g_3}$	200	320	360	μA
Oscillator voltage	V_{osc}	4	7	8	V_{RMS}
Effective transconductance	S_{eff}	0.56	0.6	0.5	mA/V

OPERATING CHARACTERISTICS (continued)

Hexode as frequency changer (grid No. 2+4 voltage through a potentiometer R_1, R_2).

Supply voltage	V_b	100		170		200		V
Anode resistor	R_a	0		0		0		Ω
Resistor 1	R_1	22		22		22		kΩ
Resistor 2	R_2	47		47		47		kΩ
Cathode resistor	R_k	200		200		225		Ω
Grid triode and grid No. 3 resistor	$R_{g_T+g_3}$	20		20		20		kΩ
Grid triode and grid No. 3 current	$I_{g_T+g_3}$	200		320		360		µA
Grid No. 1 voltage	V_{g_1}	−1.0	−14	−1.8	−22	−2.2	−27	V
Grid No. 2 and 4 voltage	$V_{g_{2+4}}$	53	68	87	116	105	136	V
Anode current	I_a	1.0	-	2.2	-	3.0	-	mA
Grid No. 2 and 4 current	$I_{g_{2+4}}$	1.0	-	1.9	-	2.1	-	mA
Conversion conductance	S_c	320	3.2	450	4.5	500	5	µA/V
Internal resistance	R_i	1.4	min. 5	1.2	min. 5	1.0	min. 5	MΩ
Equivalent noise resistance	R_{eq}	115	-	145	-	220	-	kΩ

LIMITING VALUES (Design centre rating system)

Triode section

Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	175	V
Anode dissipation	W_a	max.	0.75	W
Cathode current	I_k	max.	5.5	mA
Grid resistor	R_g	max.	3	MΩ
Cathode to heater voltage	V_{kf}	max.	150	V

LIMITING VALUES (Design centre rating system) (continued)

Hexode section

Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	250	V
Anode dissipation	W_a	max.	0.8	W
Grids No. 2 and 4 voltage	$V_{g(2+4)_o}$	max.	550	V
	$V_{g_{2+4}}$	max.	125	V
Grids No. 2 and 4 dissipation	$W_{g_{2+4}}$	max.	0.3	W
Cathode current	I_k	max.	7	mA
Grid No. 1 resistor	R_{g_1}	max.	3	MΩ
Grid No. 3 resistor	R_{g_3}	max.	3	MΩ
Cathode to heater voltage	V_{kf}	max.	150	V

TRIODE-HEXODE

Triode-hexode intended for use as frequency changer and phase inverter.

QUICK REFERENCE DATA			
Triode section			
Anode current	I_a	10	mA
Transconductance	S	2.8	mA/V
Hexode section			
Anode current	I_a	2.1	mA
Conversion conductance	S_c	0.67	mA/V

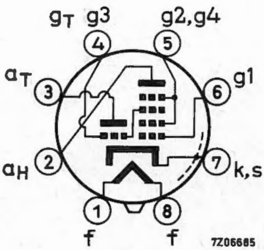
HEATING: Indirect by A.C. or D.C.; series supply

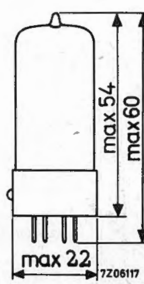
Heater current	I_f	100	mA
Heater voltage	V_f	14	V

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Rimlock





CAPACITANCES

Triode section

Anode to all except grid and grid No.3	$C_{a_T(g_Tg_3)}$	2.4	pF
Grid and grid No.3 to all except anode	$C_{g_Tg_3/(a_T)}$	5.9	pF
Grid and grid No.3 to anode	$C_{g_Tg_3/a_T}$	1.3	pF

Hexode section

Anode to all	C_a	9.4	pF
Grid No.1 to all	C_{g_1}	4.0	pF
Anode to grid No.1	C_{ag_1}	max. 0.1	pF
Grid No.1 to heater	C_{g_1f}	max. 0.15	pF

Between triode and hexode sections

Grid triode and grid No.3 to grid No.1 hexode	$C_{g_Tg_3/g_{1H}}$	max. 0.35	pF
Grid triode and grid No.3 to anode hexode	$C_{g_Tg_3/a_H}$	max. 0.2	pF

TYPICAL CHARACTERISTICS

Triode section

Anode voltage	V_a	100	V
Grid voltage	V_g	0	V
Anode current	I_a	10	mA
Transconductance	S	2.8	mA/V
Amplification factor	μ	16	-

OPERATING CHARACTERISTICS

Triode as oscillator

Supply voltage	V_b	100		170		200		V
Anode resistor	R_a	10		10		22		kΩ
Oscillator voltage	V_{osc}	4		8		8		V_{RMS}
Grid triode and grid No.3 resistor	$R_{g_T+g_3}$	22	47	22	47	22	47	kΩ
Grid triode and grid No.3 current	$I_{g_T+g_3}$	175	100	350	200	350	200	μA
Anode current	I_a	3.4	3.1	6.5	5.7	5.5	5.2	mA
Effective transconductance	S_{eff}	0.7	0.6	0.75	0.65	0.65	0.55	mA/V

Hexode as frequency changer, circuit fig.1.

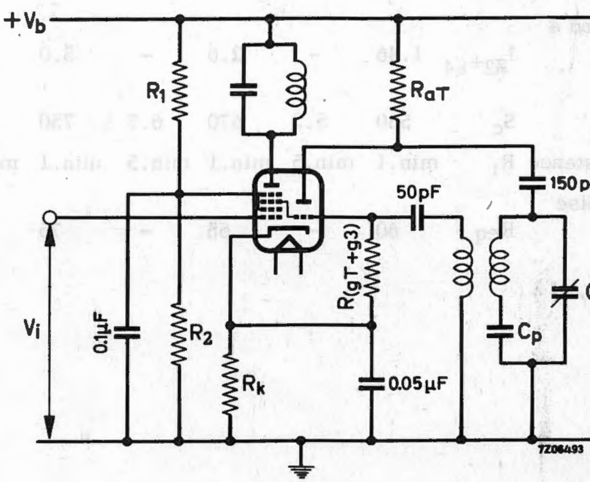


fig.1

OPERATING CHARACTERISTICS (continued)

Supply voltage	V_b	100		170		200		V
Anode resistor	R_a	0		0		0		Ω
Resistor 1	R_1	18		18		18		kΩ
Resistor 2	R_2	27		27		27		kΩ
Cathode resistor	R_k	180		180		180		Ω
Grid triode and grid No.3 resistor	$R_{g_T+g_3}$	22		22		22		kΩ
Grid triode and grid No.3 current	$I_{g_T+g_3}$	175		350		350		μA[1]
Grid No.1 voltage	V_{g_1}	-1.0	-13.5	-1.85	-25	-2	-27.5	V
Grids No.2 and 4 voltage	$V_{g_2+g_4}$	43	57	70	100	85	119	V
Anode current	I_a	1.2	-	2.1	-	3.0	-	mA
Grids No.2 and 4 current	$I_{g_2+g_4}$	1.46	-	2.6	-	3.0	-	mA
Conversion conductance	S_c	530	5.3	670	6.7	750	7.5	μA/V
Internal resistance	R_i	min.1	min.5	min.1	min.5	min.1	min.5	MΩ
Equivalent noise resistance	R_{eq}	60	-	65	-	75	-	kΩ

[1]) For $R_{g_T+g_3}$ = 47 kΩ, $I_{g_T+g_3}$ should be asjusted to 200 μA at V_a = 200 V or 170 V and to 100 μA at V_a = 100 V.

LIMITING VALUES

Triode section

Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	175	V
Anode dissipation	W_a	max.	0.8	W
Cathode current	I_k	max.	7	mA
Grid resistor	R_g	max.	3	MΩ
Cathode to heater voltage	V_{kf}	max.	150	V

Hexode section

Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	250	V
Anode dissipation	W_a	max.	1.5	W
Grids No.2 and 4 voltage	$V_{g(2+4)_o}$	max.	550	V
for anode current 3 mA	$V_{g_{2+4}}$	max.	125	V
for anode current max. 1 mA	$V_{g_{2+4}}$	max.	250	V
Grids No.2 and 4 dissipation	$W_{g_{2+4}}$	max.	0.3	W
Cathode current	I_k	max.	10	mA
Grid No.1 resistor	R_{g_1}	max.	3	MΩ
Grid No.3 resistor	R_{g_3}	max.	3	MΩ
Cathode to heater voltage	V_{kf}	max.	150	V

TRIODE-HEPTODE

Triode-heptode. Heptode section intended for use as mixer R.F.- or I.F. amplifier. Triode section intended for use as oscillator in A.M./F.M. receivers.

QUICK REFERENCE DATA			
Triode section			
Anode current	I_a	13.5	mA
Transconductance	S	3.7	mA/V
Amplification factor	μ	22	-
Heptode section			
Anode current	I_a	9.8	mA
Transconductance	S	4.3	mA/V
Amplification factor	$\mu_{g_2 g_1}$	25	-

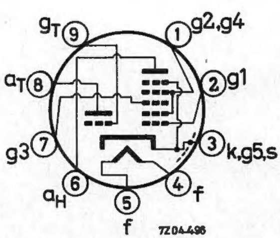
HEATING: Indirect by A.C. or D.C.; series supply

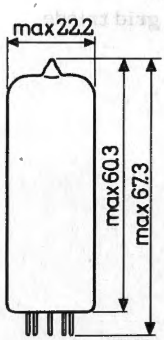
Heater current	I_f	100	mA
Heater voltage	V_f	19	V

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





CAPACITANCES

Triode section

Grid to all except anode	$C_{g(a)}$	2.6	pF
Anode to all except grid	$C_{a(g)}$	2.1	pF
Anode to grid	C_{ag}	1.0	pF
Grid to heater	C_{gf}	max. 0.02	pF

Heptode section

Grid No.1 to all except anode	$C_{g_1(a)}$	4.8	pF
Anode to all except grid No.1	$C_{a(g_1)}$	7.9	pF
Anode to grid No.1	C_{ag_1}	max.0.006	pF
Grid No.1 to heater	C_{g_1f}	max. 0.17	pF
Grid No.3 to all	C_{g_3}	6	pF
Grid No.1 to grid No.3	$C_{g_1g_3}$	max. 0.3	pF
Grid No.3 to heater	C_{g_3f}	max. 0.06	pF

Between heptode and triode sections

Anode heptode to anode triode	$C_{a_Ha_T}$	0.20	pF
Anode heptode to grid triode	$C_{a_Hg_T}$	max. 0.09	pF
Grid No.1 heptode to anode triode	$C_{g_{1H}a_T}$	max. 0.06	pF
Grid No.1 heptode to grid triode	$C_{g_{1H}g_T}$	max. 0.17	pF
Grid No.1 heptode to grid triode + grid No.3	C_{g_{1H}/g_Tg_3}	max. 0.45	pF
Anode heptode to grid triode + grid No.3	C_{a_H/g_Tg_3}	max. 0.35	pF

TYPICAL CHARACTERISTICS

Triode section

Anode voltage	V_a	100	V
Grid voltage	V_g	0	V
Anode current	I_a	13.5	mA
Transconductance	S	3.7	mA/V
Amplification factor	μ	22	-

Heptode section

Anode voltage	V_a	160	V
Grid No.3 voltage	V_{g_3}	0	V
Grids No.2 and 4 voltage	$V_{g_{2+4}}$	90	V
Grid No.1 current	I_{g_1}	0.5	μA
Grid No.1 voltage	V_{g_1}	-0.5	V
Anode current	I_a	9.8	mA
Grids No.2 and 4 current	$I_{g_{2+4}}$	6.1	mA
Transconductance	S	4.3	mA/V
Amplification factor	$\mu_{g_2g_1}$	25	-

OPERATING CHARACTERISTICS

Heptode section as mixer

Supply voltage	V_b	100		170		200		V
Anode resistor	R_a	0		0		0		Ω
Grids No.2 and 4 resistor	$R_{g_{2+4}}$	10		10		10		kΩ
Grid triode + grid No.3 resistor	$R_{g_T+g_3}$	47		47		47		kΩ
Grid triode + grid No.3 current	$I_{g_T+g_3}$	115		200		230		μA
Grid No.1 current	I_{g_1}	0.5	-	0.5	-	0.5	-	μA 1)
Grid No.1 voltage	V_{g_1}	-0.5	-12	-0.5	-19	-0.5	-22	V
Anode voltage	V_a	100	-	170	-	200	-	V
Grids No.2 and 4 voltage	$V_{g_{2+4}}$	56	-	88	-	100	-	V
Anode current	I_a	2.0	-	3.3	-	4.1	-	mA
Grids No.2 and 4 current	$I_{g_{2+4}}$	4.4	-	8.2	-	10	-	mA
Conversion conductance	S_c	850	8.5	1100	11	1200	12	μA/V
Internal resistance	R_i	0.75	min.3	0.8	min.3	0.85	min.3	MΩ
Equivalent noise resistance	R_{eq}	33	-	30	-	32	-	kΩ

1) Grid current bias obtained with R_{g_1} = 1 MΩ and with zero volts a.g.c. voltage; resulting grid No.1 voltage: -0.5 V.

OPERATING CHARACTERISTICS (continued)

Heptode section as R.F. or I.F. amplifier

Supply voltage	V_b	100		170		200		V
Anode resistor	R_a	0		0		3.9		kΩ
Grids No.2 and 4 resistor	R_{g2+4}	18		18		18		kΩ
Grid No.3 voltage	V_{g3}	0		0		0		V
Grid No.1 current	I_{g1}	0.5	–	0.5	–	0.5	–	µA [1]
Grid No.1 voltage	V_{g1}	–0.5	–15.7	–0.5	–26	–0.5	–30	V
Anode voltage	V_a	100	–	170	–	162	–	V
Grids No.2 and 4 voltage	V_{g2+4}	52	–	80	–	90	–	V
Anode current	I_a	4.1	–	8.0	–	9.8	–	mA
Grids No.2 and 4 current	I_{g2+4}	2.7	–	5.0	–	6.1	–	mA
Transconductance	S	2900	29	3900	39	4300	43	µA/V
Internal resistance	R_i	0.45	min.10	0.4	min.10	0.35	min.10	MΩ
Amplification factor	μ_{g2g1}	24	–	25	–	25	–	-
Equivalent noise resistance	R_{eq}	4.0	–	4.0	–	4.3	–	kΩ

Triode section as oscillator

Supply voltage	V_b	100	170	200	V
Anode resistor	R_a	15	15	15	kΩ
Grid triode + grid No.3 resistor	$R_{g_T+g_3}$	47	47	47	kΩ
Grid triode + grid No.3 current	$I_{g_T+g_3}$	115	200	230	µA
Anode current	I_a	2.5	4.5	5.4	mA
Effective transconductance	S_{eff}	0.58	0.65	0.65	mA/V

[1]) Grid current bias obtained with R_{g1} = 1 MΩ and with zero volts a.g.c. voltage; resulting grid No.1 voltage: –0.5 V.

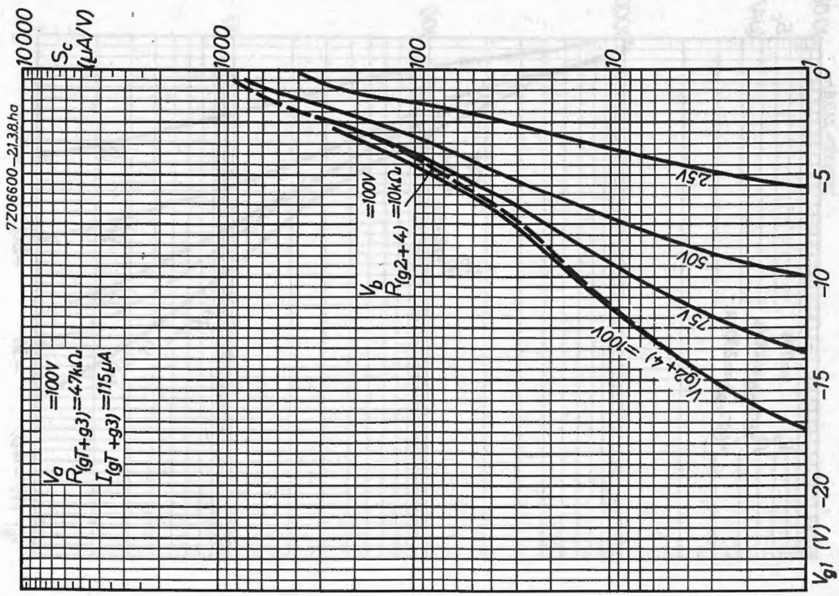
LIMITING VALUES (Design centre rating system)

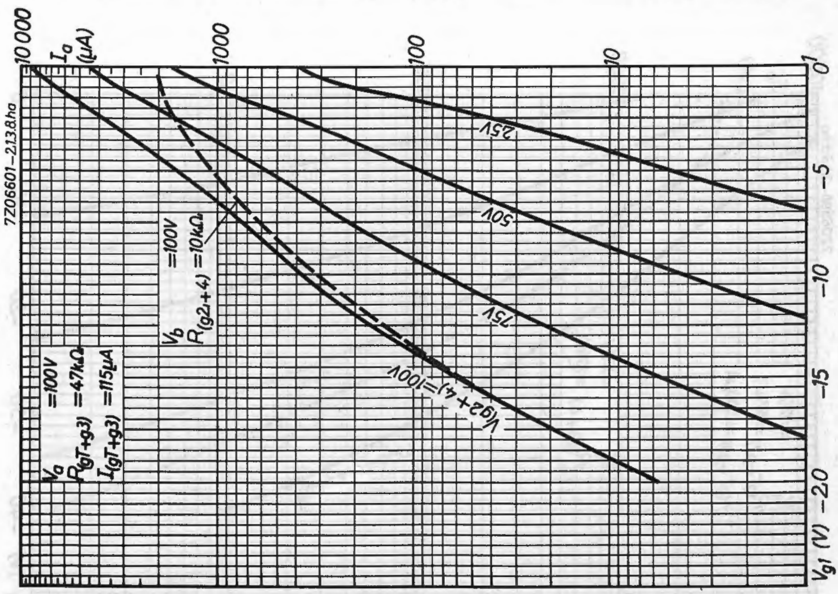
Heptode section

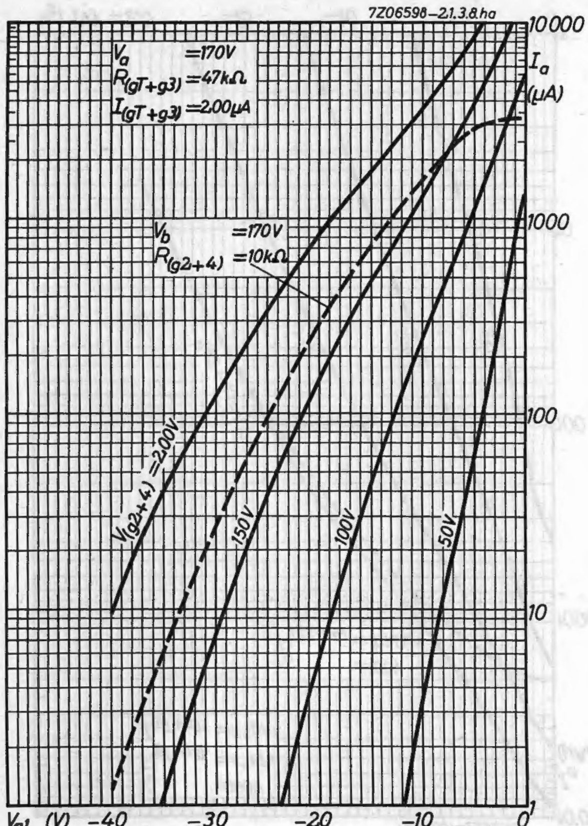
Anode voltage	V_{a_o}	max. 550 V
	V_a	max. 250 V
Anode dissipation	W_a	max. 1.8 W
Grids No.2 and 4 voltage	$V_{g_{2+4_o}}$	max. 550 V
	$V_{g_{2+4}}$	max. 125 V
Grids No.2 and 4 voltage (I_a max. 1 mA)	$V_{g_{2+4}}$	max. 250 V
Grids No.2 and 4 dissipation	$W_{g_{2+4}}$	max. 1 W
Cathode current	I_k	max. 18 mA
Grid No.1 resistor	R_{g_1}	max. 3 MΩ
Grid No.3 resistor	R_{g_3}	max. 20 kΩ
Grid No.3 resistor grid No.3 directly connected to grid triode	R_{g_3}	max. 3 MΩ
Cathode to heater voltage	V_{kf}	max. 100 V

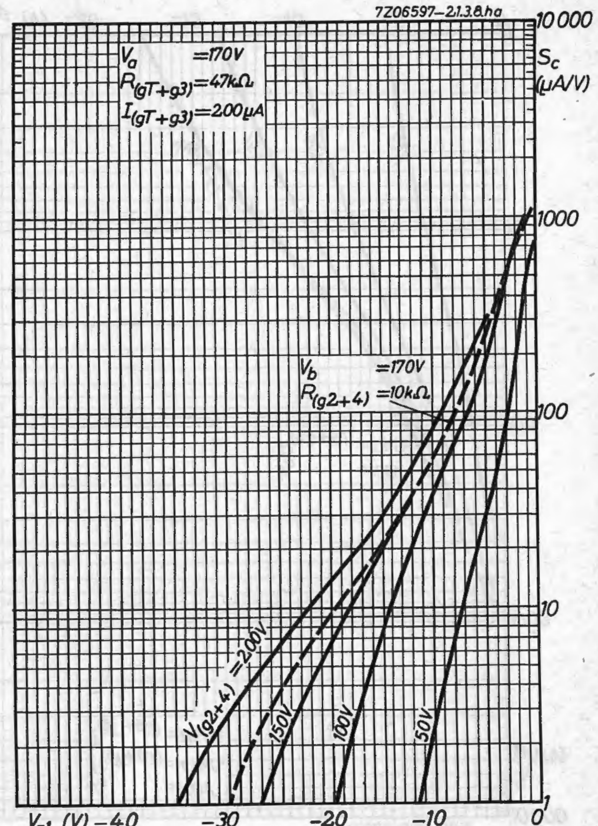
Triode section

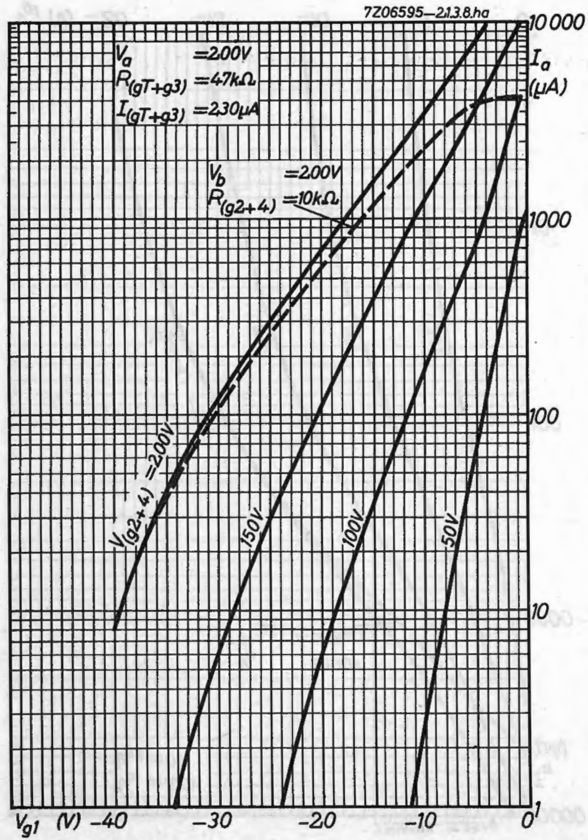
Anode voltage	V_{a_o}	max. 550 V
	V_a	max. 250 V
Anode dissipation	W_a	max. 0.8 W
Cathode current	I_k	max. 6.5 mA
Grid resistor	R_g	max. 3 MΩ
Cathode to heater voltage	V_{kf}	max. 100 V

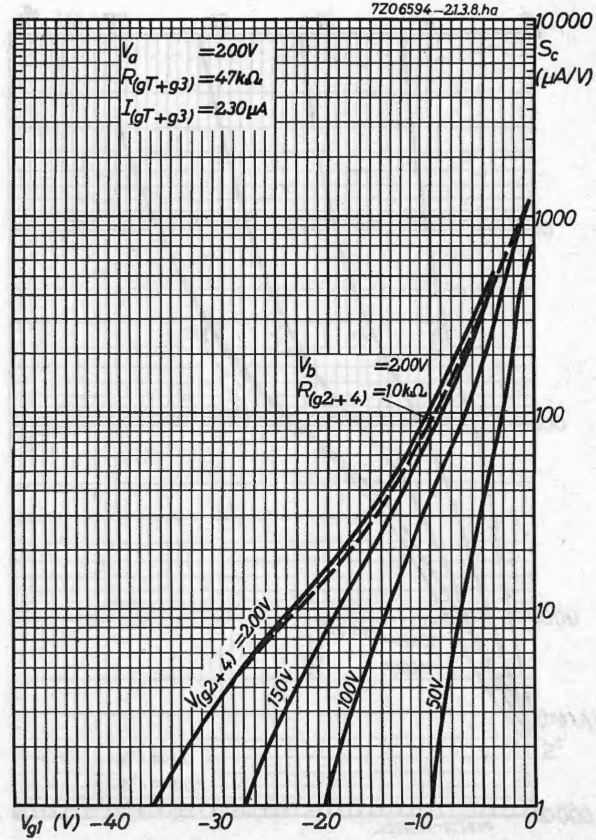

7Z06600–2.13.8.ha
10 000
S_c
(µA/V)
1000
100
10
0
–5
–10
–15
–20
V_{g1} (V)
V_a =100V
$R_{(gT+g3)}$ =47kΩ
$I_{(gT+g3)}$ =115µA
V_b =100V
$R_{(g2+4)}$ =10kΩ
25V
50V
75V
$V_{(g2+4)}$ =100V

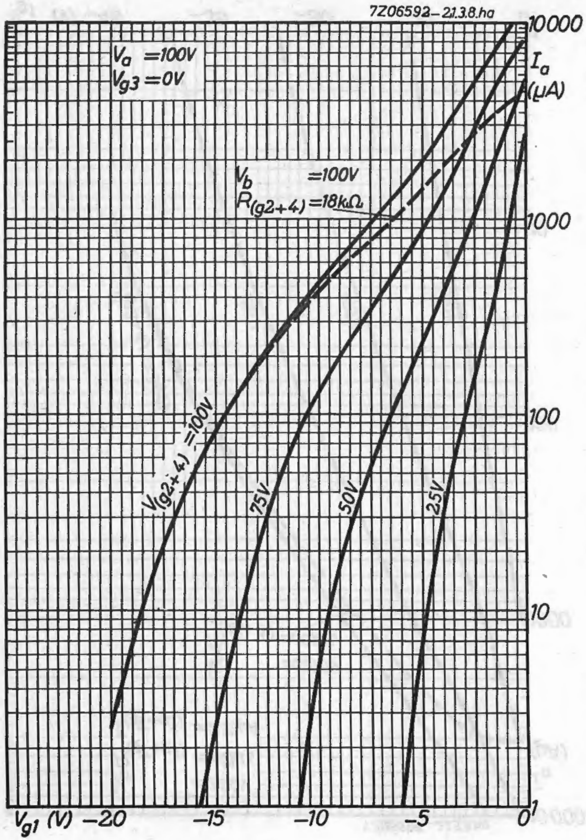

7Z06601–2.13.8.ha
10 000
I_a
(µA)
1000
100
10
0
–5
–10
–15
–20
V_{g1} (V)
V_a =100V
$R_{(gT+g3)}$ =47kΩ
$I_{(gT+g3)}$ =115µA
V_b =100V
$R_{(g2+4)}$ =10kΩ
25V
50V
75V
$V_{(g2+4)}$ =100V

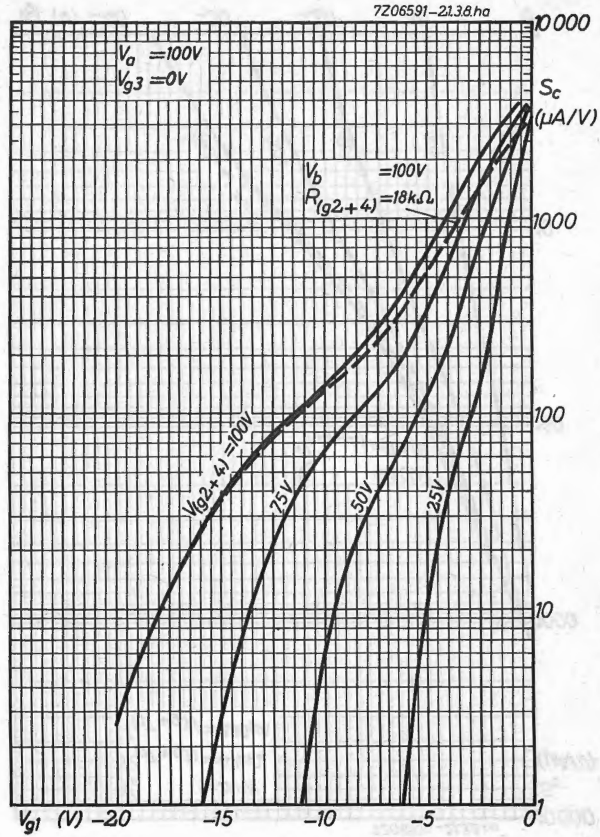

7Z06598–2.1.3.8.ha
V_a =170V
$R_{(gT+g3)}$ =47kΩ
$I_{(gT+g3)}$ =2.00μA
V_b =170V
$R_{(g2+4)}$ =10kΩ
$V_{(g2+4)}$ =200V
150V
100V
50V
I_a (μA)
10 000
1000
100
10
1
V_{g1} (V) −40 −30 −20 −10 0

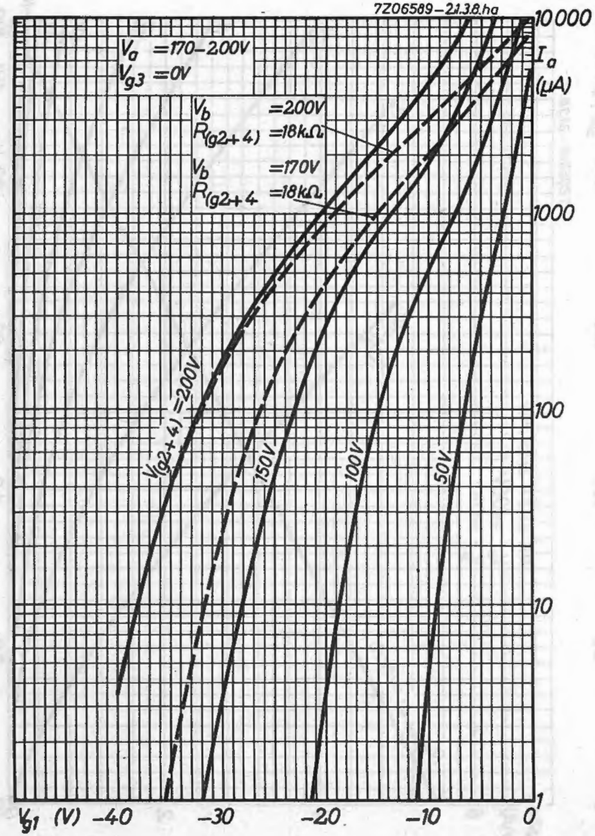

7Z06597–2.1.3.8.ha
V_a =170V
$R_{(gT+g3)}$ =47kΩ
$I_{(gT+g3)}$ =2.00μA
V_b =170V
$R_{(g2+4)}$ =10kΩ
$V_{(g2+4)}$ =200V
150V
100V
50V
S_c (μA/V)
10 000
1000
100
10
1
V_{g1} (V) −40 −30 −20 −10 0

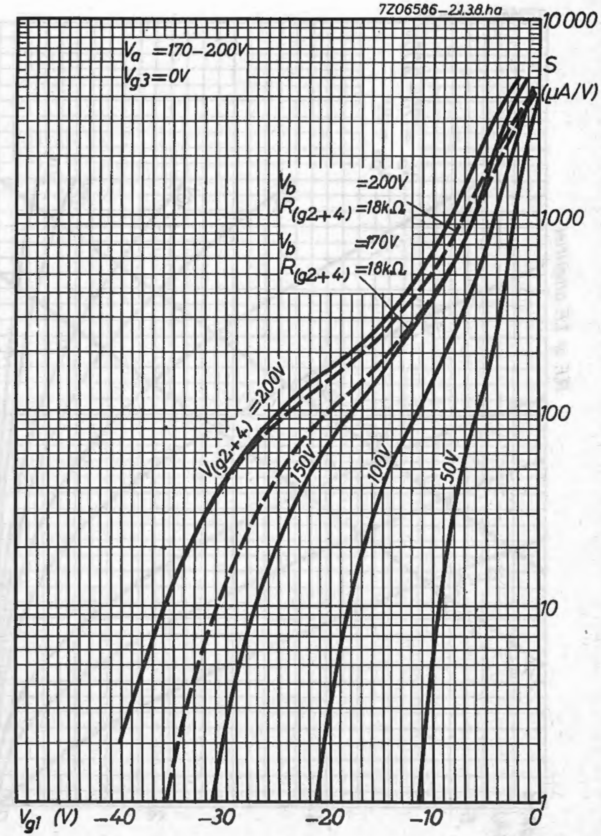

7Z06595–2.1.3.8.ha
V_a =200V
$R_{(gT+g3)}$ =47kΩ
$I_{(gT+g3)}$ =230μA
V_b =200V
$R_{(g2+4)}$ =10kΩ
$V_{(g2+4)}$ =200V
150V
100V
50V
10 000
I_a
(μA)
1000
100
10
1
V_{g1} (V) −40
−30
−20
−10
0

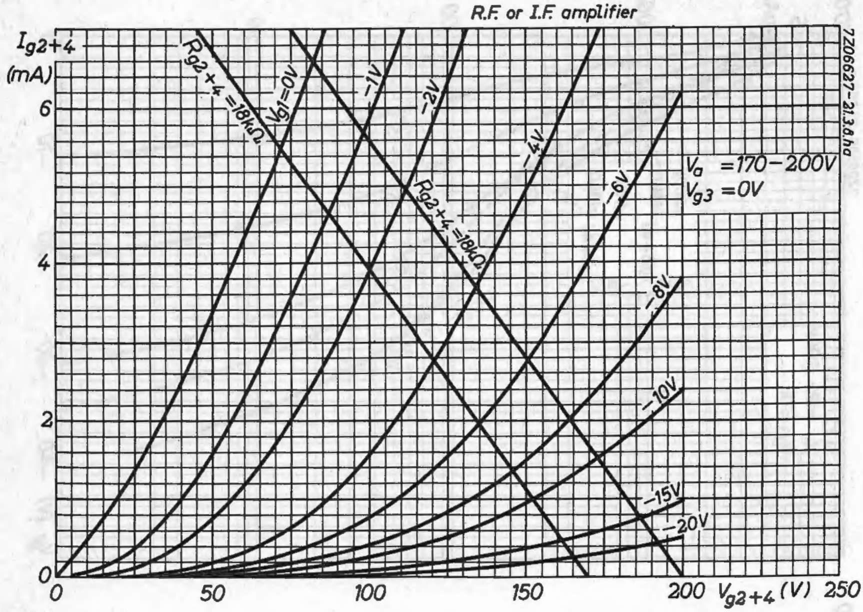

7Z06594–2.1.3.8.ha
V_a =200V
$R_{(gT+g3)}$ =47kΩ
$I_{(gT+g3)}$ =230μA
V_b =200V
$R_{(g2+4)}$ =10kΩ
$V_{(g2+4)}$ =200V
150V
100V
50V
10 000
S_c
(μA/V)
1000
100
10
1
V_{g1} (V) −40
−30
−20
−10
0

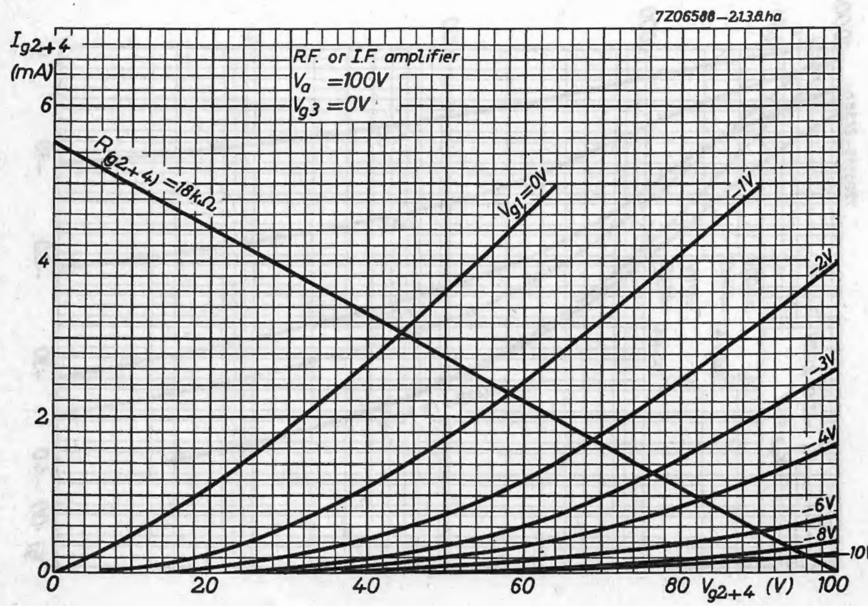

7Z06592-2.1.3.8.ha
V_a =100V
V_{g3} =0V
V_b =100V
$R_{(g2+4)}$ =18kΩ
$V_{(g2+4)}$ =100V
75V
50V
25V
I_a
(μA)
10000
1000
100
10
1
V_{g1} (V) −20
−15
−10
−5
0

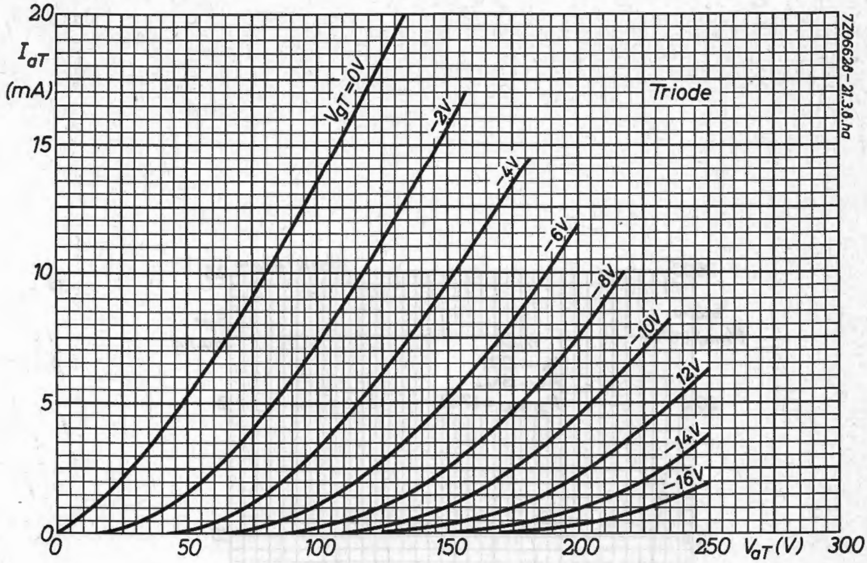

7Z06591-2.1.3.8.ha
V_a =100V
V_{g3} =0V
V_b =100V
$R_{(g2+4)}$ =18kΩ
$V_{(g2+4)}$ =100V
75V
50V
25V
S_c
(μA/V)
10000
1000
100
10
1
V_{g1} (V) −20
−15
−10
−5
0

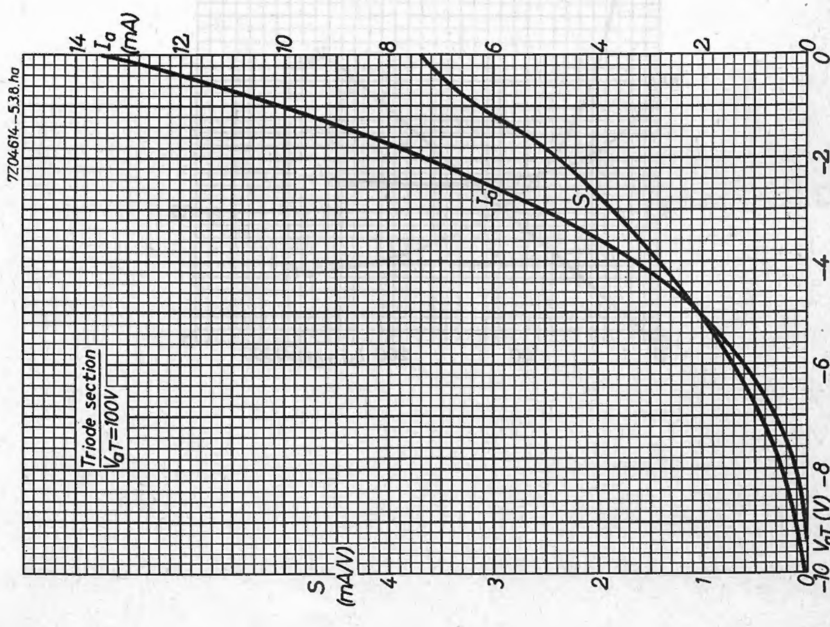

7Z06589-2.1.3.8.ha
V_a =170-200V
V_{g3} =0V
V_b =200V
$R_{(g2+4)}$ =18kΩ
V_b =170V
$R_{(g2+4}$ =18kΩ
$V_{(g2+4)}$ =200V
150V
100V
50V
10 000
I_a
(μA)
1000
100
10
1
V_{g1} (V) -40 -30 -20 -10 0

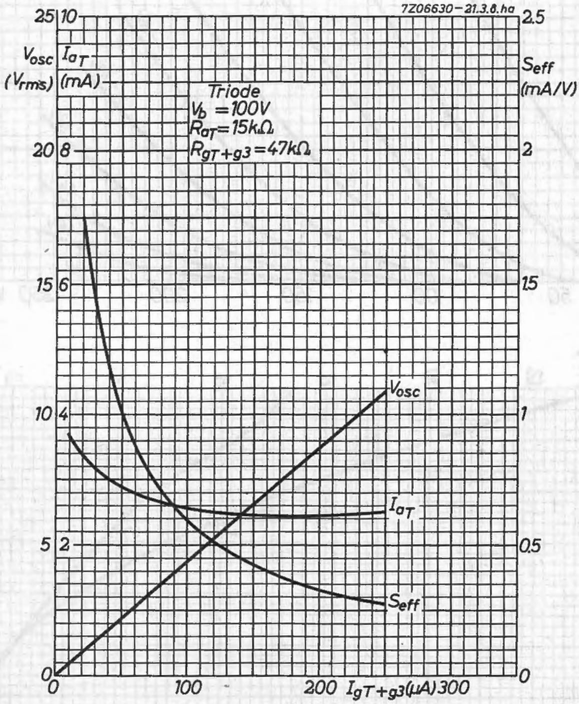

7Z06586-2.1.3.8.ha
V_a =170-200V
V_{g3}=0V
V_b =200V
$R_{(g2+4)}$ =18kΩ
V_b =170V
$R_{(g2+4)}$ =18kΩ
$V_{(g2+4)}$ =200V
150V
100V
50V
10 000
S
(μA/V)
1000
100
10
1
V_{g1} (V) -40 -30 -20 -10 0

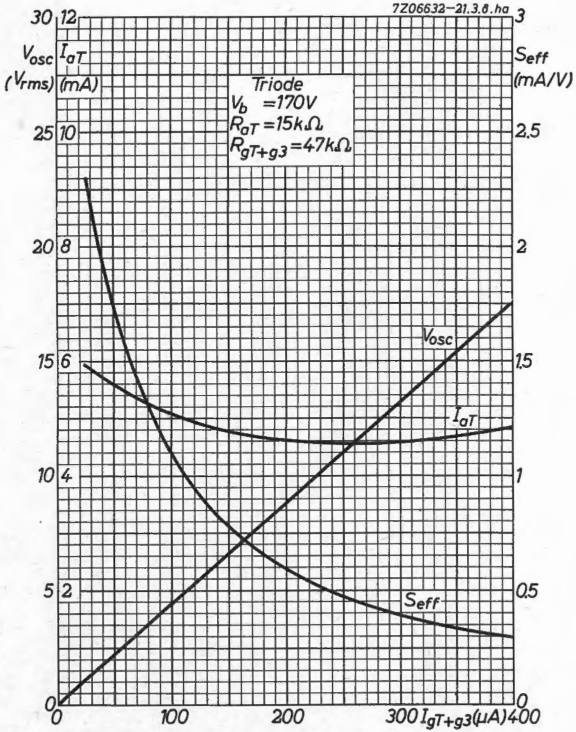

R.F. or I.F. amplifier
7Z06627-21.3.8.ha
I_{g2+4} (mA)
$R_{g2+4}=18k\Omega$
$V_{g1}=0V$
$-1V$
$-2V$
$-4V$
$-6V$
$-8V$
$-10V$
$-15V$
$-20V$
V_a =170−200V
V_{g3} =0V
V_{g2+4} (V)
0
2
4
6
0
50
100
150
200
250

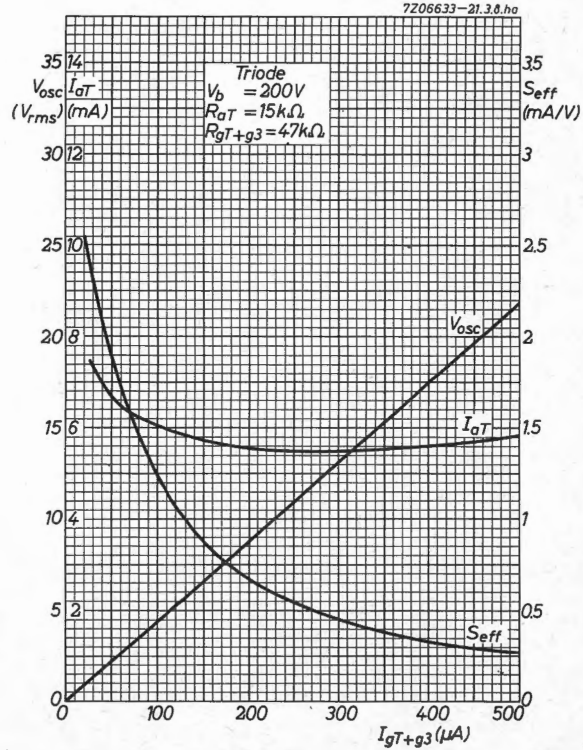

7Z06588-21.3.8.ha
I_{g2+4} (mA)
R.F. or I.F. amplifier
V_a =100V
V_{g3} =0V
$R_{(g2+4)}=18k\Omega$
$V_{g1}=0V$
$-1V$
$-2V$
$-3V$
$-4V$
$-6V$
$-8V$
$-10V$
V_{g2+4} (V)
0
2
4
6
0
20
40
60
80
100


20
I_{aT}
(mA)
15
10
5
0
Triode
V_{gT}=0V
−2V
−4V
−6V
−8V
−10V
12V
−14V
−16V
0
50
100
150
200
250
V_{aT} (V)
300
7Z06628-21.3.68.ha


7Z04614-5.3.68.ha
14
I_a
(mA)
12
10
8
6
4
2
0
I_a
S
Triode section
V_{aT}=100V
S
(mA/V)
4
3
2
1
0
0
−2
−4
−6
−8
V_{gT} (V)
−10


7Z06630-21.3.8.ha
Triode
V_b = 100V
R_{aT} = 15kΩ
R_{gT+g3} = 47kΩ
V_{osc} (V_{rms})
I_{aT} (mA)
S_{eff} (mA/V)
I_{gT+g3} (μA)
0
100
200
300
5
10
15
20
25
2
4
6
8
10
0.5
1
1.5
2
2.5


7Z06632-21.3.8.ha
V_{osc} (V_{rms})
I_{aT} (mA)
S_{eff} (mA/V)
Triode
V_b =170V
R_{aT} =15kΩ
R_{gT+g3} =47kΩ
V_{osc}
I_{aT}
S_{eff}
I_{gT+g3} (μA)
0
100
200
300
400
5
10
15
20
25
30
2
4
6
8
10
12
0.5
1
1.5
2
2.5
3


7Z06633-21.3.8.ha
V_{osc} (V_{rms})
I_{aT} (mA)
S_{eff} (mA/V)
Triode
V_b =200V
R_{aT} =15kΩ
R_{gT+g3} =47kΩ
V_{osc}
I_{aT}
S_{eff}
I_{gT+g3} (μA)
0
100
200
300
400
500
5
10
15
20
25
30
35
2
4
6
8
10
12
14
0.5
1
1.5
2
2.5
3
3.5

TRIODE-OUTPUT PENTODE

The triode section is intended for use as A.F. amplifier.
The pentode section is intended for use as A.F. power amplifier.

QUICK REFERENCE DATA			
Triode section			
Anode current	I_a	3.5	mA
Transconductance	S	2.2	mA/V
Amplification factor	μ	70	-
Pentode section			
Anode current	I_a	41	mA
Transconductance	S	7.5	mA/V
Amplification factor	$\mu_{g_2g_1}$	9.5	-
Output power	W_o	3.3	W

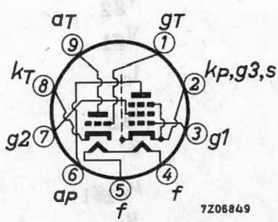
HEATING: Indirect by A.C. or D.C.; series supply

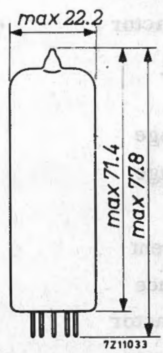
Heater current	I_f	100	mA
Heater voltage	V_f	50	V

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





CAPACITANCES

Triode section

Anode to all except grid	$C_{a(g)}$		4.3	pF
Grid to all except anode	$C_{g(a)}$		2.7	pF
Anode to grid	C_{ag}		4.4	pF
Grid to heater	C_{gf}	max.	0.02	pF

Pentode section

Anode to all except grid No. 1	$C_{a(g_1)}$		8.0	pF
Grid No. 1 to all except anode	$C_{g_1(a)}$		9.3	pF
Anode to grid No. 1	C_{ag_1}	max.	0.3	pF
Grid No. 1 to heater	C_{g_1f}	max.	0.3	pF

Between triode and pentode sections

Anode triode to grid No. 1 pentode	$C_{a_Tg_{1P}}$	max.	0.02	pF
Grid triode to anode pentode	$C_{g_Ta_P}$	max.	0.02	pF
Grid triode to grid No. 1 pentode	$C_{g_Tg_{1P}}$	max.	0.025	pF
Anode triode to anode pentode	$C_{a_Ta_P}$	max.	0.25	pF

TYPICAL CHARACTERISTICS

Triode section

Anode voltage	V_a	100	V
Grid voltage	V_g	0	V
Anode current	I_a	3.5	mA
Transconductance	S	2.2	mA/V
Amplification factor	μ	70	–

Pentode section

Anode voltage	V_a	170	V
Grid No. 2 voltage	V_{g2}	170	V
Grid No. 1 voltage	V_{g1}	-11.5	V
Anode current	I_a	41	mA
Grid No. 2 current	I_{g2}	9	mA
Transconductance	S	7.5	mA/V
Amplification factor	$\mu_{g_2g_1}$	9.5	–
Internal resistance	R_i	16	kΩ

OPERATING CHARACTERISTICS

Triode section as A.F. amplifier

A)	Signal source resistance	R_S	0.22		MΩ
	Grid resistor	R_g	3		MΩ
	Grid resistor of next stage	R_g'	0.68		MΩ
	Supply voltage	V_b	170	100	V
	Cathode resistor	R_k	2.7	2.7	kΩ
	Anode resistor	R_a	220	220	kΩ
	Anode current	I_a	0.43	0.23	mA
	Voltage gain	V_o/V_i 1)	51	47	-
	Max. output voltage	$V_{o\,max}$	25	15	V_{RMS}
	Distortion	d_{tot} 2)	2.3	4.0	%

B) Signal source resistance	R_S	0.22				MΩ
Grid resistor	R_g	22				MΩ
Grid resistor of next stage	R_g	0.68				MΩ
Supply voltage	V_b	170	170	100	100	V
Cathode resistor	R_k	0	0	0	0	Ω
Anode resistor	R_a	100	220	100	220	kΩ
Anode current	I_a	0.86	0.50	0.37	0.22	mA
Voltage gain	V_o/V_i 1)	49	53	42	46	-
Max. output voltage	$V_{o\,max}$	19	20	8	9	V_{RMS}
Distortion	d_{tot}	1.4 3)	1.4 3)	1.3 2)	1.5 2)	%

Microphony and hum

The triode section can be used without special precautions against microphony and hum in circuits in which an input voltage of minimum 10 mV_{RMS} is required for an output of 50 mW of the output stage, Z_g (f = 50 Hz) = 0.25 MΩ and without A.C. voltage between pin 4 and cathode.

1) Measured at small input voltage.
2) At lower output voltages the distortion is proportionally lower.
3) At lower output voltages down to 5 V_{RMS} the distortion is approximately constant. At values below 5 V_{RMS} the distortion is approximately proportional to V_o.

OPERATING CHARACTERISTICS

Pentode section

Class A (Measured with V_k constant)

Supply voltage	$V_{ba} = V_{bg_2}$		100			170		V
Cathode resistor	R_k		170			200		Ω
Load resistance	$R_{a\sim}$		3.0			3.25		kΩ
Grid No. 1 driving voltage	V_i	0	0.7	3.75	0	0.61	5.9	V_{RMS}
Anode current	I_a	26	–	27	42	–	44	mA
Grid No. 2 current	I_{g_2}	5.8	–	8.6	9.2	–	15.5	mA
Output power	W_o	0	0.05	1.0	0	0.05	3.2	W
Distortion	d_{tot}	–	–	10	–	–	10	%

Supply voltage	$V_{ba} = V_{bg_2}$		200		V
Grid No. 2 series resistor (non-decoupled)	R_{g_2}		470		Ω
Cathode resistor	R_k		330		Ω
Load resistance	$R_{a\sim}$		4.5		kΩ
Grid No. 1 driving voltage	V_i	0	0.66	6.7	V_{RMS}
Anode current	I_a	35	–	37	mA
Grid No. 2 current	I_{g_2}	7.8	–	13.3	mA
Output power	W_o	0	0.05	3.3	W
Distortion	d_{tot}	–	–	10	%

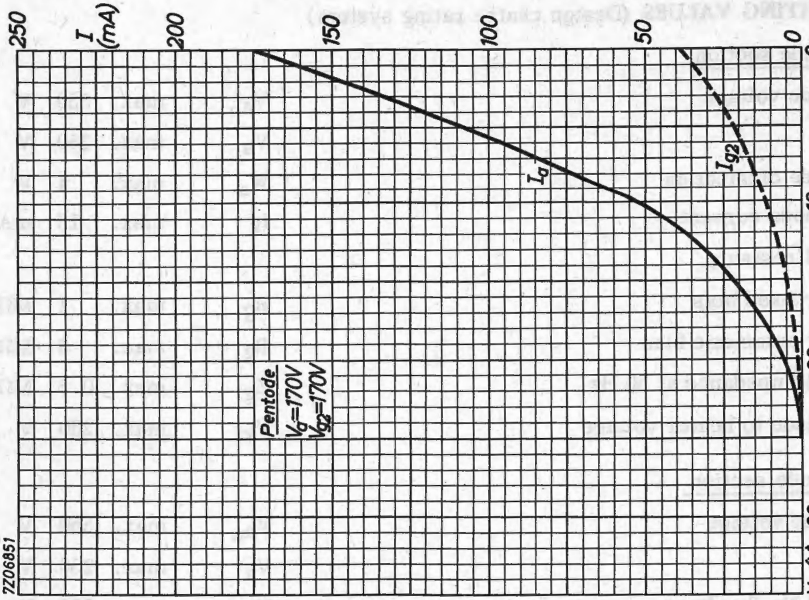
LIMITING VALUES (Design centre rating system)

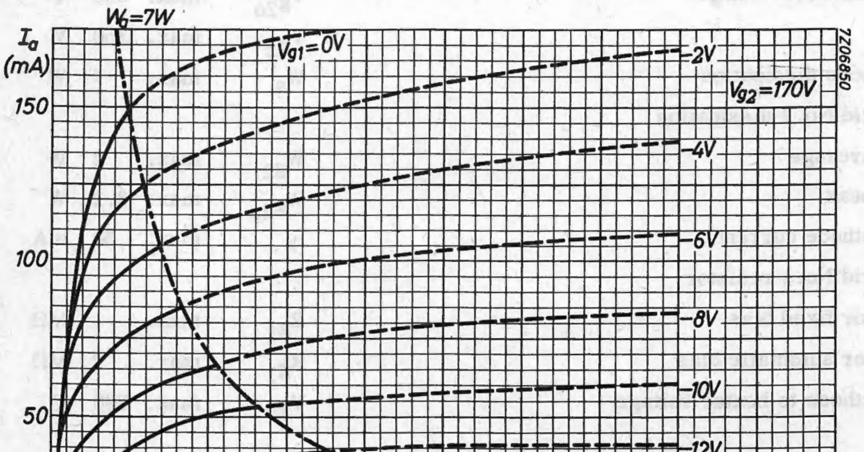
Triode section

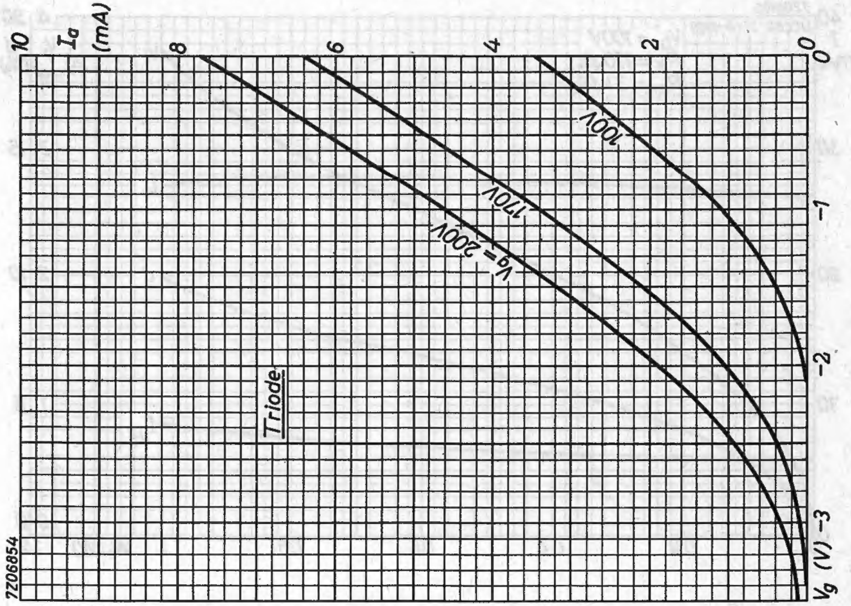
Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	250	V
Anode dissipation	W_a	max.	1	W
Cathode current	I_k	max.	15	mA
Grid resistor				
for fixed bias	R_g	max.	1	MΩ
for automatic bias	R_g	max.	3	MΩ
Grid impedance at 50 Hz	Z_g	max.	0.5	MΩ
Cathode to heater voltage	V_{kf}	max.	200	V

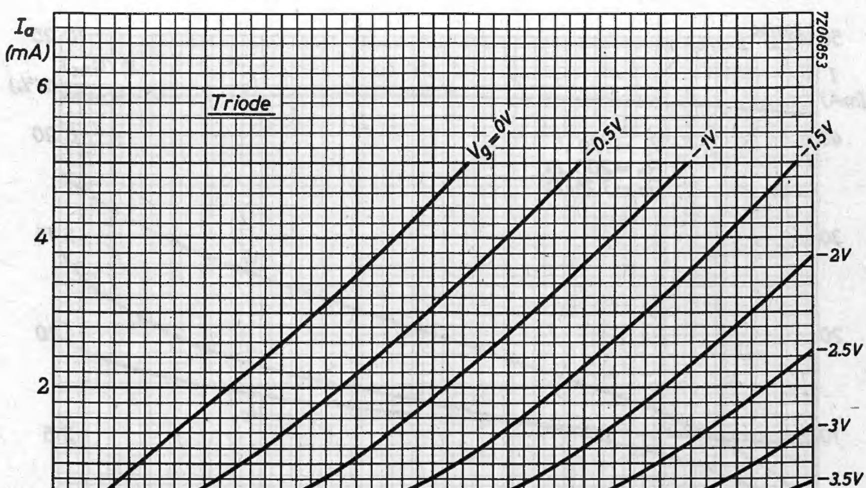
Pentode section

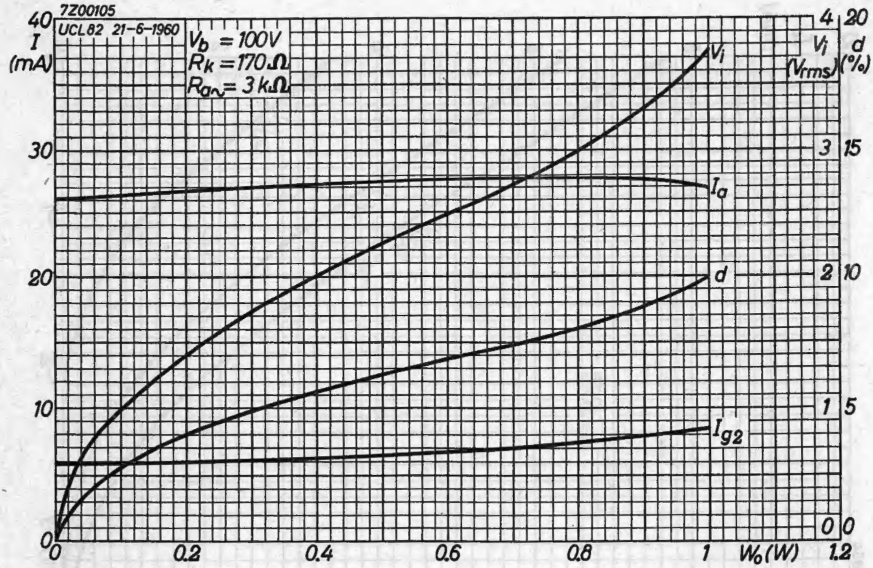
Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	250	V
Grid No.2 voltage	$V_{g_{2o}}$	max.	550	V
	V_{g_2}	max.	250	V
Anode dissipation	W_a	max.	7	W
Grid No.2 dissipation				
average	W_{g_2}	max.	2	W
peak	$W_{g_{2p}}$	max.	3.2	W
Cathode current	I_k	max.	50	mA
Grid No.1 resistor				
for fixed bias	R_{g_1}	max.	1	MΩ
for automatic bias	R_{g_1}	max.	2	MΩ
Cathode to heater voltage	V_{kf}	max.	200	V

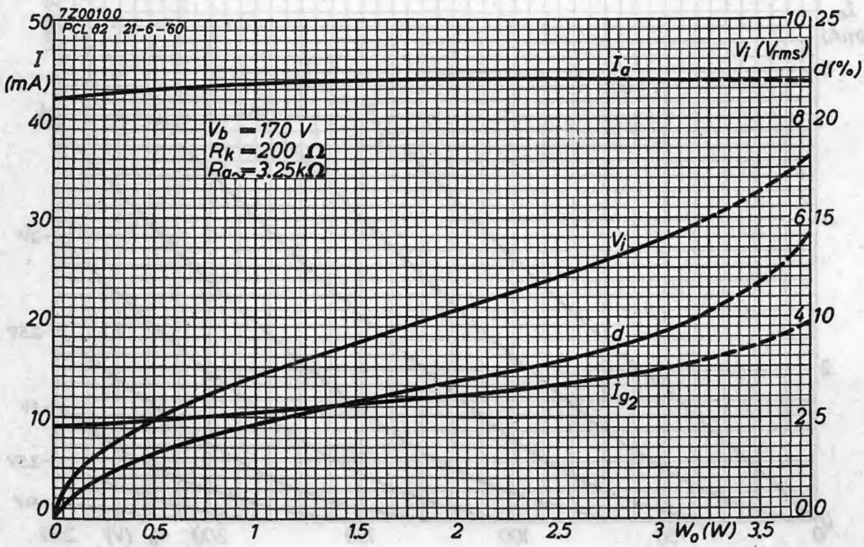

7Z06851
250
200
150
100
50
0
I (mA)
I_a
I_{g2}
Pentode
V_a=170V
V_{g2}=170V
0
-10
-20
-30
V_{g1}(V)

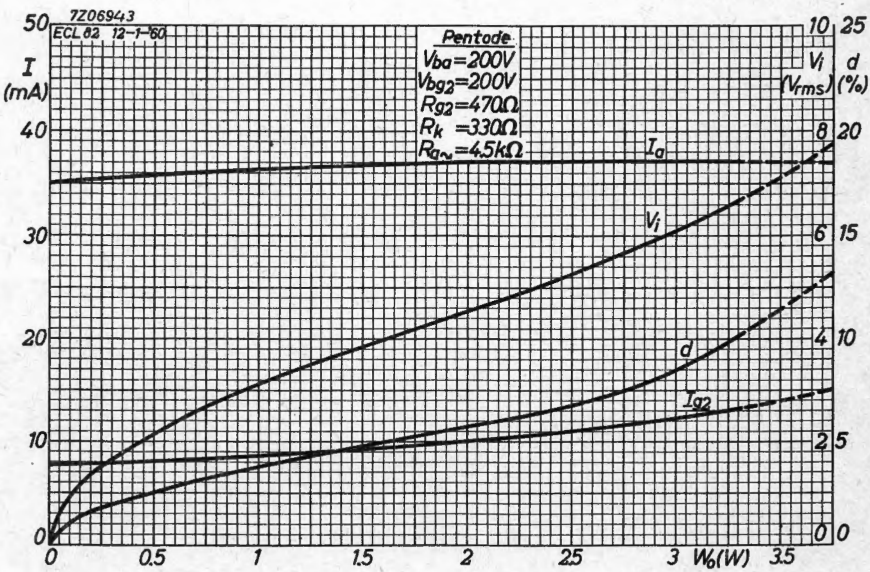

7Z06850
I_a (mA)
150
100
50
0
W_a=7W
V_{g1}=0V
-2V
V_{g2}=170V
-4V
-6V
-8V
-10V
-12V
-14V
-16V
-18V
-20V
0
100
200
300
400
V_a(V)
500


Triode
I_a (mA)
V_g (V)
V_a = 200V
170V
100V
7206854


Triode
I_a (mA)
V_a (V)
V_g=0V
−0.5V
−1V
−1.5V
−2V
−2.5V
−3V
−3.5V
−4V
7206853


7Z00105
UCL82 21-6-1960
V_b = 100V
R_k = 170 Ω
$R_{a\sim}$ = 3 kΩ
I (mA)
V_i (V_{rms})
d (%)
V_i
I_a
d
I_{g2}
W_o(W)


7Z00100
PCL 82 21-6-'60
V_b = 170 V
R_k = 200 Ω
$R_{a\sim}$ = 3.25kΩ
I (mA)
V_i (V_{rms})
d(%)
I_a
V_i
d
I_{g2}
W_o(W)


7Z06943
ECL 82 12-1-'60
Pentode
Vba=200V
Vbg2=200V
Rg2=470Ω
Rk =330Ω
Ra~=4.5kΩ
I
(mA)
Vi
(Vrms)
d
(%)
Ia
Vi
d
Ig2
Wo(W)
50
40
30
20
10
0
0.5
1
1.5
2
2.5
3
3.5
25
15
5

PENTODE

Pentode intended for use as R.F. or I.F. amplifier.

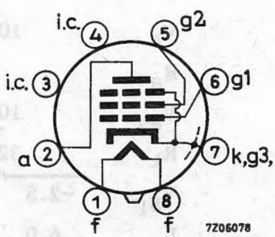
QUICK REFERENCE DATA			
Variable transconductance			
Anode current	I_a	6.0	mA
Transconductance	S	2.2	mA/V
Amplification factor	$\mu_{g_2 g_1}$	18	-

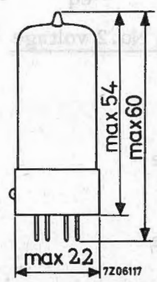
HEATING: Indirect by A.C. or D.C.; series supply

Heater current	I_f	100	mA
Heater voltage	V_f	12.6	V

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Rimlock





CAPACITANCES

Anode to all except grid No.1	$C_{a(g_1)}$	5.7	pF
Grid No.1 to all except anode	$C_{g_1(a)}$	4.9	pF
Anode to grid No.1	C_{ag_1}	max. 0.002	pF
Grid No.1 to heater	C_{g_1f}	max. 0.1	pF

OPERATING CHARACTERISTICS as R.F. or I.F. amplifier

a) With sliding grid No.2 voltage

Supply voltage	V_b	100		170		200		V
Anode resistor	R_a	0		0		0		Ω
Grid No.2 resistor	R_{g_2}	40		40		40		kΩ
Cathode resistor	R_k	325		325		325		Ω
Grid No.1 voltage	V_{g_1}	−1.4	−17	−2.5	−28	−3	−34	V
Anode current	I_a	3.3	−	6.0	−	7.2	−	mA
Grid No.2 current	I_{g_2}	1.0	−	1.75	−	2.1	−	mA
Transconductance	S	1900	19	2200	22	2300	23	µA/V
Amplification factor	$\mu_{g_2g_1}$	18	−	18	−	18	−	-
Internal resistance	R_i	0.8	min.10	1.0	min.10	1.0	min.10	MΩ
Equivalent noise resistance	R_{eq}	5.5	−	6.5	−	7.0	−	kΩ

b) With fixed grid No.2 voltage

Supply voltage	V_b	100		V
Anode resistor	R_a	0		Ω
Grid No.2 voltage	V_{g_2}	100		V
Cathode resistor	R_k	325		Ω
Grid No.1 voltage	V_{g_1}	−2.5	−16.5	V
Anode current	I_a	6.0	−	mA
Grid No.2 current	I_{g_2}	1.75	−	mA
Transconductance	S	2200	22	µA/V
Amplification factor	$\mu_{g_2g_1}$	18	−	-
Internal resistance	R_i	0.6	min. 10	MΩ
Equivalent noise resistance	R_{eq}	6.5	−	kΩ

LIMITING VALUES (Design centre rating system)

Anode voltage	V_{a_o}	max. 550	V
	V_a	max. 250	V
Anode dissipation	W_a	max. 2	W
Grid No.2 voltage	$V_{g_{2o}}$	max. 550	V
Grid No.2 voltage at anode current I_a = max. 4 mA	V_{g_2}	max. 250	V
Grid No.2 voltage at anode current I_a = 7.2 mA	V_{g_2}	max. 150	V
Grid No.2 dissipation	W_{g_2}	max. 0.3	W
Cathode current	I_k	max. 10	mA
Grid No.1 resistor	R_{g_1}	max. 3	MΩ
Cathode to heater voltage	V_{kf}	max. 150	V

R.F. PENTODE

Pentode intended for use as wide-band amplifier

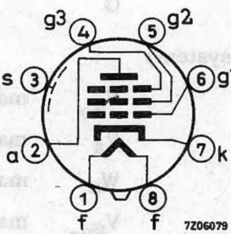
QUICK REFERENCE DATA			
Anode current	I_a	10	mA
Transconductance	S	8	mA/V
Amplification factor	$\mu_{g_2g_1}$	52	–
Internal resistance	R_i	300	kΩ

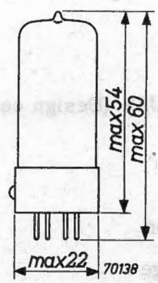
HEATING: Indirect by A.C. or D.C.; series supply

Heater current	I_f	100	mA
Heater voltage	V_f	21	V

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Rimlock





CAPACITANCES

Anode to all except grid No.1	$C_{a(g_1)}$	4.3	pF
Grid No.1 to all except anode	$C_{g_1(a)}$	8.6	pF
Anode to grid No.1	C_{ag_1}	max. 0.006	pF
Grid No.1 to heater	C_{g_1f}	max. 0.2	pF

TYPICAL CHARACTERISTICS

Anode voltage	V_a	170	V
Grid No.3 voltage	V_{g_3}	0	V
Grid No.2 voltage	V_{g_2}	170	V
Grid No.1 voltage	V_{g_1}	−2	V
Anode current	I_a	10	mA
Grid No.2 current	I_{g_2}	2.8	mA
Transconductance	S	8	mA/V
Internal resistance	R_i	300	kΩ
Amplification factor	$\mu_{g_2g_1}$	52	-
Equivalent noise resistance	R_{eq}	1060	Ω

OPERATING CHARACTERISTICS

Anode voltage	V_a	170	V
Grid No.3 voltage	V_{g_3}	0	V
Grid No.2 voltage	V_{g_2}	170	V
Anode current	I_a	10	mA
Frequency	f	100	MHz
Bandwidth	B	0.8	MHz
Gain	G	1000	-

LIMITING VALUES (Design centre rating system)

Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	250	V
Anode dissipation	W_a	max.	2	W
Grid No.2 voltage	$V_{g_{2o}}$	max.	550	V
	V_{g_2}	max.	250	V
Grid No.2 dissipation	W_{g_2}	max.	0.5	W
Grid No.1 voltage	$-V_{g_1}$	max.	100	V
Cathode current	I_k	max.	15	mA
Grid No.1 resistor (automatic bias)	R_{g_1}	max.	1	MΩ
Cathode to heater voltage	V_{kf}	max.	150	V

R.F. PENTODE

Pentode intended for use as R.F. and I.F. amplifier.

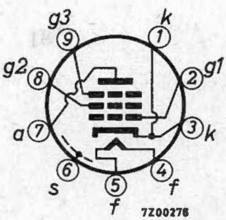
QUICK REFERENCE DATA			
Anode current	I_a	10	mA
Transconductance	S	7.4	mA/V
Amplification factor	$\mu_{g_2g_1}$	50	
Internal resistance	R_i	0.4	MΩ

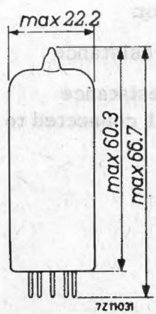
HEATING: Indirect by A.C. or D.C.; series supply

Heater voltage	V_f	19	V
Heater current	I_f	100	mA

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Noval





CAPACITANCES

Grid No.1 to all except anode	$C_{g_1(a)}$	7.5 pF
Anode to all except grid No.1	$C_{a(g_1)}$	3.3 pF
Anode to grid No.1	C_{ag_1}	max. 0.007 pF
Anode to cathode	C_{ak}	max. 0.012 pF
Grid No.2 to all	C_{g_2}	5.4 pF
Grid No.1 to grid No.2	$C_{g_1g_2}$	2.6 pF
Grid No.1 to heater	C_{g_1f}	max. 0.15 pF

TYPICAL CHARACTERISTICS AND OPERATING CHARACTERISTICS

Anode voltage	V_a	170	V
Grid No.3 voltage	V_{g3}	0	V
Grid No.2 voltage	V_{g2}	170	V
Grid No.1 voltage	V_{g1}	-2.0	V
Anode current	I_a	10	mA
Grid No.2 current	I_{g2}	2.5	mA
Transconductance	S	7.4	mA/V
Internal resistance	R_i	0.4	MΩ
Amplification factor	μ_{g2g1}	50	
Equivalent noise resistance	R_{eq}	1000	Ω
Grid No.1 input resistance f = 50 MHz, pin 1 connected to pin 3	r_{g1}	10	kΩ

LIMITING VALUES (Design centre rating system)

Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	250	V
Anode dissipation	W_a	max.	2.5	W
Grid No.2 voltage	V_{g2_o}	max.	550	V
	V_{g2}	max.	250	V
Grid No.2 dissipation	W_{g2}	max.	0.7	W
Cathode current	I_k	max.	15	mA
Grid No.1 resistor				
for automatic bias	R_{g1}	max.	1	MΩ
for fixed bias	R_{g1}	max.	0.5	MΩ
Heater to cathode voltage	V_{kf}	max.	150	V

R.F. PENTODE

Pentode with variable transconductance intended for use as R.F. or I.F. amplifier.

QUICK REFERENCE DATA			
Anode current	I_a	11.4	mA
Transconductance	S	6.1	mA/V
Internal resistance	R_i	350	kΩ

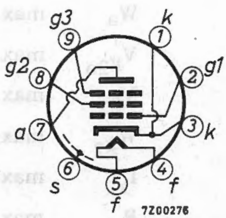
HEATING: Indirect by A.C. or D.C.; series supply

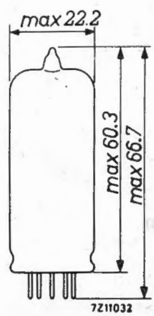
Heater current	I_f	100	mA
Heater voltage	V_f	19	V

DIMENSIONS AND CONNECTIONS

Dimensions in mm

Base: Noval





CAPACITANCES

Anode to all except grid No.1	$C_{a(g_1)}$	3.2	pF
Grid No.1 to all except anode	$C_{g_1(a)}$	6.9	pF
Anode to grid No.1	C_{ag_1}	max. 0.007	pF
Grid No.1 to heater	C_{g_1f}	max. 0.15	pF

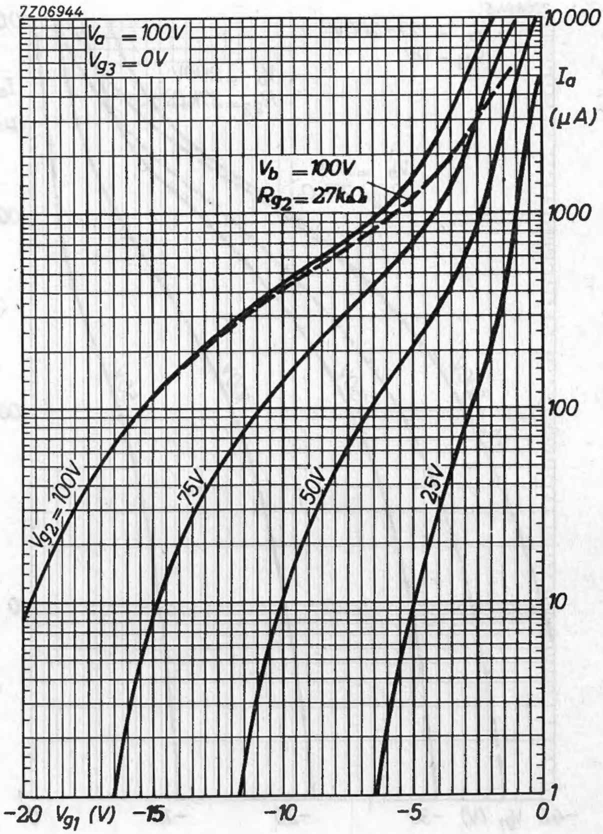
TYPICAL CHARACTERISTICS AND OPERATING CHARACTERISTICS

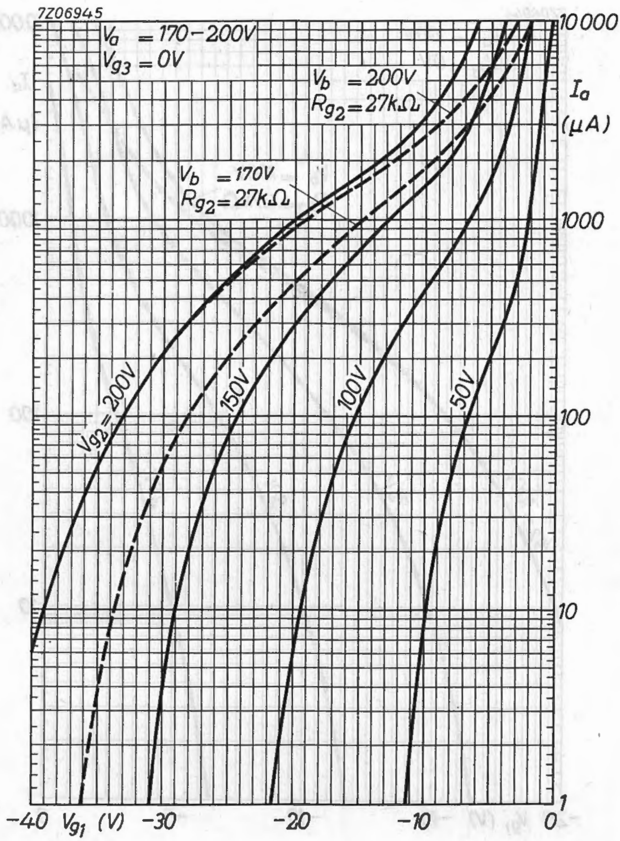
Anode voltage, supply voltage	$V_a=V_b$	100		170		200		V
Grid No.3 voltage	V_{g3}	0		0		0		V
Grid No.2 resistor	R_{g2}	27		27		27		kΩ
Grid No.1 voltage	V_{g1}	−1.1	−14	−2	−24	−2.3	−28	V
Grid No.2 voltage	V_{g2}	57	-	100	-	116	-	V
Anode current	I_a	5.5	-	9.7	-	11.4	-	mA
Grid No.2 current	I_{g2}	1.6	-	2.6	-	3.1	-	mA
Transconductance	S	5000	50	5900	59	6100	61	µA/V
Internal resistance	R_i	0.25	>5	0.3	>5	0.35	>5	MΩ
Equivalent noise resistance	R_{eq}	1.1	-	1.4	-	1.5	-	kΩ
Input resistance grid No.1 f = 50 MHz	r_{g1}	5.6	-	7.6	-	8	-	kΩ

LIMITING VALUES (Design centre rating system)

Anode voltage	V_{ao}	max.	550	V
	V_a	max.	250	V
Anode dissipation	W_a	max.	2.5	W
Grid No.2 voltage	V_{g2o}	max.	550	V
	V_{g2}	max.	250	V
Grid No.2 dissipation	W_{g2}	max.	0.65	W
Cathode current	I_k	max.	15	mA
Grid No.1 resistor	R_{g1}	max.	3	MΩ[1])
Cathode to heater voltage	V_{kf}	max.	150	V

[1]) When the tube is used at or near maximum ratings it is advisable to take the value of R_{g1} as low as possible.


7Z06944
$V_a = 100V$
$V_{g3} = 0V$
$V_b = 100V$
$R_{g2} = 27k\Omega$
$V_{g2} = 100V$
75V
50V
25V
10000
I_a
(μA)
1000
100
10
1
-20
V_{g1} (V)
-15
-10
-5
0



7Z06945
V_a = 170−200V
V_{g3} = 0V
V_b = 200V
R_{g2} = 27kΩ
V_b = 170V
R_{g2} = 27kΩ
V_{g2} = 200V
150V
100V
50V
10 000
1000
100
10
1
I_a
(μA)
−40
V_{g1} (V)
−30
−20
−10
0

R.F. PENTODE

Pentode with variable transconductance intended for use as R.F. or I.F. amplifier.

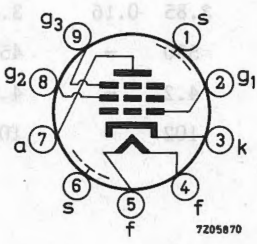
QUICK REFERENCE DATA			
Anode current	I_a	12	mA
Transconductance	S	4.4	mA/V
Amplification factor	$\mu_{g_2g_1}$	21	
Internal resistance	R_i	400	kΩ

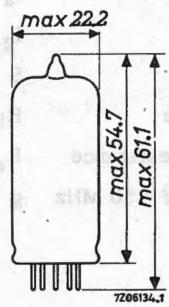
HEATING: Indirect by A.C. or D.C.; series supply

Heater current	I_f	100	mA
Heater voltage	V_f	12.6	V

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Noval





CAPACITANCES

Anode to all except grid No.1	$C_{a(g_1)}$	5.1	pF
Grid No.1 to all except anode	$C_{g_1(a)}$	5.5	pF
Anode to grid No.1	C_{ag_1}	max. 0.002	pF
Grid No.1 to heater	C_{g_1f}	0.05	pF

TYPICAL CHARACTERISTICS

Anode voltage	V_a	170	V
Grid No.2 voltage	V_{g_2}	100	V
Grid No.3 voltage	V_{g3}	0	V
Anode current	I_a	12	mA
Grid No.1 voltage	V_{g_1}	-1.2	V [1])
Grid No.2 current	I_{g_2}	4.4	mA
Transconductance	S	4.4	mA/V
Internal resistance	R_i	0.4	MΩ
Amplification factor	μ_{g2g1}	21	

OPERATING CHARACTERISTICS

Anode voltage, supply voltage	$V_a = V_b$	200		170		V
Grid No.3 voltage	V_{g3}	0		0		V
Grid No.2 resistor	R_{g_2}	24		15		kΩ
Cathode resistor	R_k	130		130		Ω
Grid No.1 voltage	V_{g_1}	-1.95	-20	-1.95	-20	V
Anode current	I_a	11.1	-	11.0	-	mA
Grid No.2 current	I_{g_2}	3.8	-	3.9	-	mA
Transconductance	S	3.85	0.16	3.8	0.11	mA/V
Internal resistance	R_i	550	-	450	-	kΩ
Equivalent noise resistance	R_{eq}	4.2	-	4.5	-	kΩ
Input conductance f = 50 MHz	g	102	-	102	-	μA/V

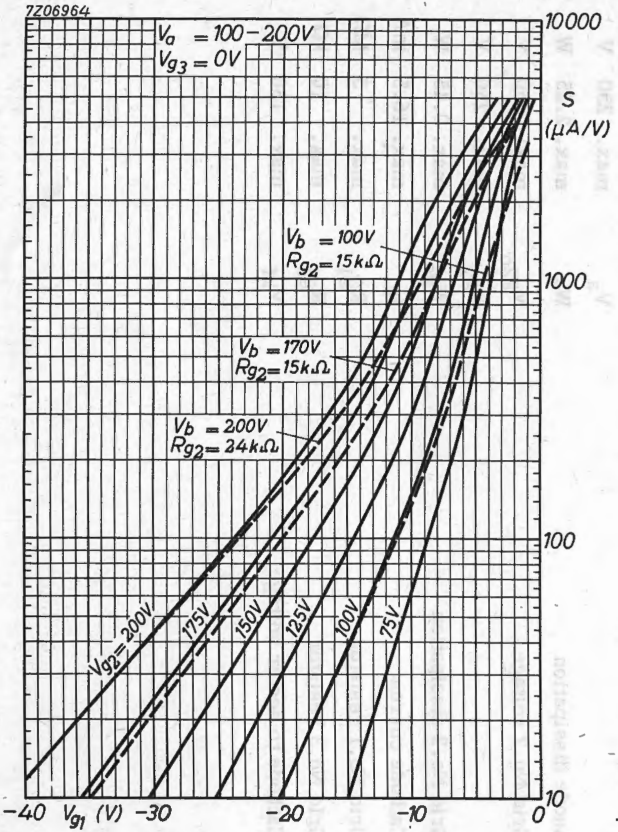
[1]) In this case control grid current may occur. If this is not permissible, the negative grid bias should be increased to a value of 1.5 V at least.

TYPICAL CHARACTERISTICS AND OPERATING CHARACTERISTICS
(continued)

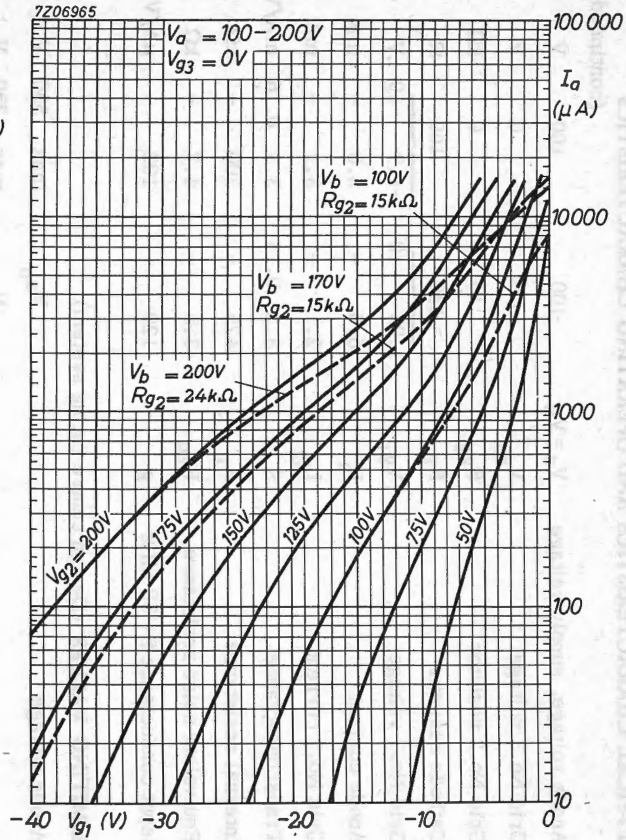
Anode voltage, supply voltage	$V_a = V_b$	100		100		V
Grid No.3 voltage	V_{g3}	0		0		V
Grid No.2 resistor	R_{g2}	15		0		kΩ
Cathode resistor	R_k	130		160		Ω
Grid No.1 voltage	V_{g1}	-1.05	-10	-1.9	-10	V
Anode current	I_a	6.0	-	8.6	-	mA
Grid No.2 current	I_{g2}	2.1	-	3.1	-	mA
Transconductance	S	3.2	0.15	3.3	0.16	mA/V
Internal resistance	R_i	475	-	300	-	kΩ
Equivalent noise resistance	R_{eq}	3.5	-	4.7	-	kΩ
Input conductance f = 50 MHz	g	120	-	102	-	µA/V

LIMITING VALUES (Design centre rating system)

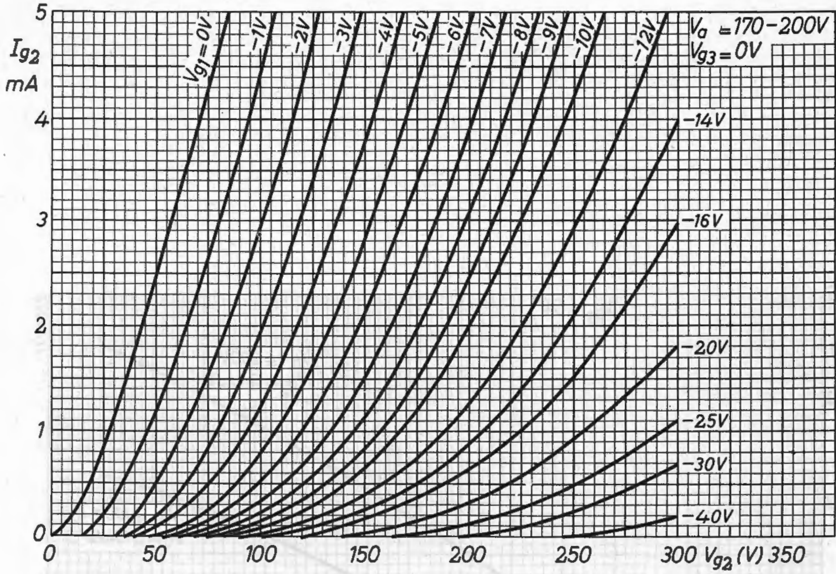
Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	250	V
Anode dissipation	W_a	max.	2.25	W
Grid No.2 voltage	V_{g2_o}	max.	550	V
	V_{g2}	max.	250	V
Grid No.2 dissipation	W_{g2}	max.	0.45	W
Cathode current	I_k	max.	16.5	mA
Grid No.1 resistor	R_{g1}	max.	3	MΩ
Grid No.3 resistor	R_{g3}	max.	10	kΩ
Cathode to heater voltage	V_{kf}	max.	150	V



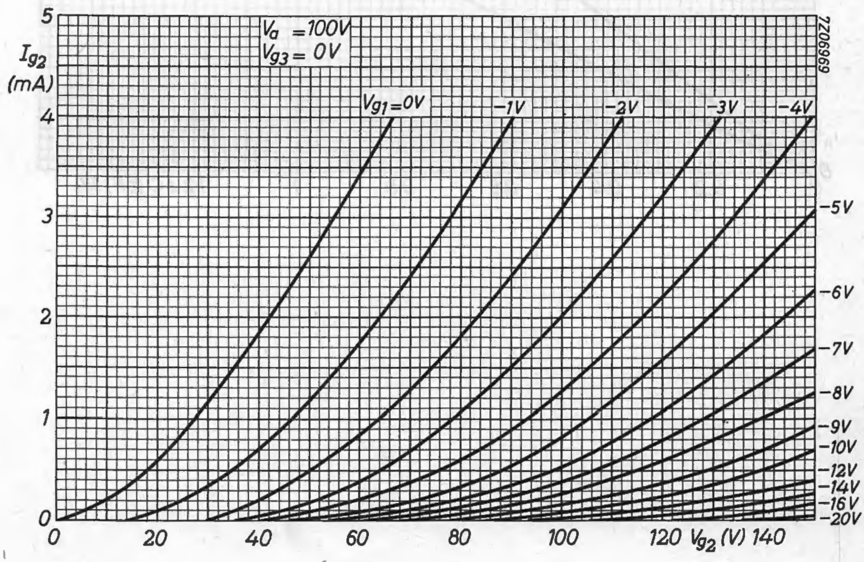
7Z06964
$V_a = 100-200V$
$V_{g3} = 0V$
S
(μA/V)
10000
1000
100
10
$V_b = 100V$
$R_{g2} = 15k\Omega$
$V_b = 170V$
$R_{g2} = 15k\Omega$
$V_b = 200V$
$R_{g2} = 24k\Omega$
$V_{g2} = 200V$
175V
150V
125V
100V
75V
−40
V_{g1} (V)
−30
−20
−10
0



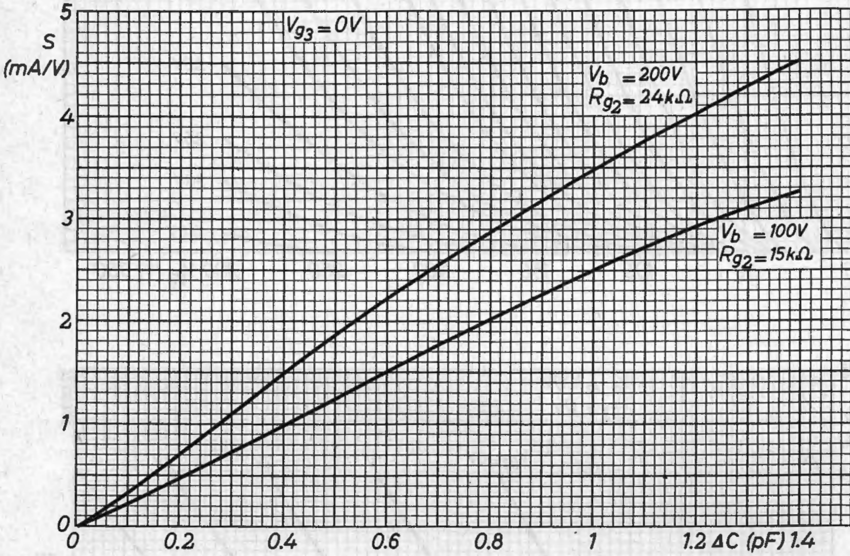
7Z06965
$V_a = 100-200V$
$V_{g3} = 0V$
I_a
(μA)
100 000
10000
1000
100
10
$V_b = 100V$
$R_{g2} = 15k\Omega$
$V_b = 170V$
$R_{g2} = 15k\Omega$
$V_b = 200V$
$R_{g2} = 24k\Omega$
$V_{g2} = 200V$
175V
150V
125V
100V
75V
50V
−40
V_{g1} (V)
−30
−20
−10
0



I_{g2} mA
V_a =170-200V
V_{g3}=0V
7Z06970
V_{g1}=0V
-1V
-2V
-3V
-4V
-5V
-6V
-7V
-8V
-9V
-10V
-12V
-14V
-16V
-20V
-25V
-30V
-40V
V_{g2} (V)



I_{g2} (mA)
V_a =100V
V_{g3}= 0V
7Z06969
V_{g1}=0V
-1V
-2V
-3V
-4V
-5V
-6V
-7V
-8V
-9V
-10V
-12V
-14V
-16V
-20V
V_{g2} (V)


5
S
(mA/V)
4
3
2
1
0
0
0.2
0.4
0.6
0.8
1
1.2 ΔC (pF) 1.4
$V_{g3} = 0V$
$V_b = 200V$
$R_{g2} = 24k\Omega$
$V_b = 100V$
$R_{g2} = 15k\Omega$
7Z06971

A.F. OUTPUT PENTODE

Pentode intended for use as A.F. power amplifier.

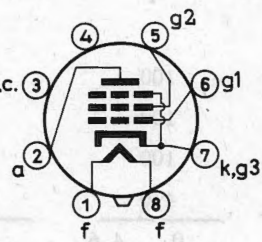
QUICK REFERENCE DATA			
Anode current	I_a	53	mA
Transconductance	S	9.5	mA/V
Amplification factor	$\mu_{g_2g_1}$	10	-
Output power	W_o	4.0	W

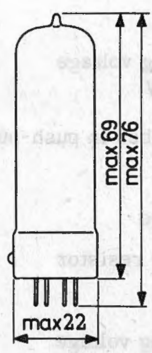
HEATING: Indirect by A.C. or D.C.; series supply

Heater current	I_f	100	mA
Heater voltage	V_f	45	V

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Rimlock





CAPACITANCES

Anode to all except grid No.1	$C_{a(g_1)}$		8.3	pF
Grid No.1 to all except anode	$C_{g_1(a)}$		11	pF
Anode to grid No.1	C_{ag_1}	max.	1	pF
Grid No.1 to heater.	C_{g_1f}	max.	0.1	pF

OPERATING CHARACTERISTICS

Class A

Anode voltage	V_a	100	170	V
Grid No.2 voltage	V_{g_2}	100	170	V
Grid No.1 voltage	V_{g_1}	-5.7	-10.4	V
Anode current	I_a	29	53	mA
Grid No.2 current	I_{g_2}	5.5	10	mA
Transconductance	S	8.0	9.5	mA/V
Amplification factor	$\mu_{g_2g_1}$	10	10	-
Internal resistance	R_i	18	20	kΩ
Load resistance	$R_{a\sim}$	3	3	kΩ
Grid No.1 driving voltage	V_i	3.8	6.0	V_{RMS}
Output power	W_o	1.25	4.0	W
Distortion	d_{tot}	10	10	%
Grid No.1 driving voltage for W_o = 50 mW	V_i	0.55	0.5	V_{RMS}

Class AB, two tubes in push-pull

Anode voltage	V_a	100		170		V
Grid No.2 voltage	V_{g_2}	100		170		V
Common cathode resistor	R_k	100		100		Ω
Load resistance	$R_{aa\sim}$	4.0		4.0		kΩ
Grid No.1 driving voltage	V_i	0	4.6	0	9.3	V_{RMS}
Anode current	I_a	2x25	2x27	2x46	2x49	mA
Grid No.2 current	I_{g_2}	2x5.0	2x6.8	2x9.0	2x16.5	mA
Output power	W_o	0	2.2	0	9	W
Distortion	d_{tot}	–	4.0	–	5.0	%

LIMITING VALUES (Design centre rating system)

Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	250	V
Grid No.2 voltage	V_{g2_o}	max.	550	V
	V_{g2}	max.	250	V
Anode dissipation	W_a	max.	9	W
Grid No.2 dissipation	W_{g_2}	max.	2.5	W
Cathode current	I_k	max.	75	mA
Grid No.1 resistor (automatic bias)	R_{g_1}	max.	1	MΩ
Cathode to heater voltage	V_{kf}	max.	150	V

A.F. OUTPUT PENTODE

Pentode intended for use as A.F. power amplifier.

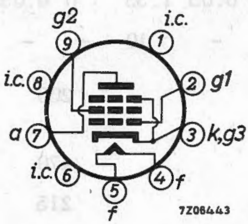
QUICK REFERENCE DATA			
Anode current	I_a	70	mA
Transconductance	S	11	mA/V
Amplification factor	$\mu_{g_2g_1}$	8	
Output power	W_o	5.3	W

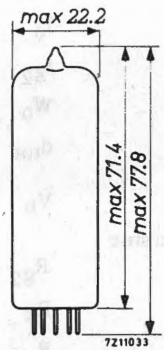
HEATING: Indirect by A.C. or D.C.; series supply

Heater current	I_f	100	mA
Heater voltage	V_f	45	V

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Noval





CAPACITANCES

Anode to all except grid No.1	$C_{a(g_1)}$		6.8	pF
Grid No.1 to all except anode	$C_{g_1(a)}$		13	pF
Anode to grid No.1	C_{ag_1}	max.	0.6	pF
Grid No.1 to heater	C_{g_1f}	max.	0.25	pF

TYPICAL CHARACTERISTICS

Anode voltage	V_a	170	V
Grid No. 2 voltage	V_{g2}	170	V
Grid No. 1 voltage	V_{g1}	-12.5	V
Anode current	I_a	70	mA
Grid No. 2 current	I_{g2}	3.5	mA
Transconductance	S	11	mA/V
Amplification factor	μ_{g2g1}	8	
Internal resistance	R_i	26	kΩ

OPERATING CHARACTERISTICS

Class A [1])

Supply voltage	V_b		100			170		V
Cathode resistor	R_k		130			130		Ω
Load resistance	$R_{a\sim}$		2.1			2.0		kΩ
Grid No. 1 driving voltage	V_i	0	0.55	3.8	0	0.47	6.1	V_{RMS}
Anode current	I_a	41	-	42	75	-	76	mA
Grid No. 2 current	I_{g2}	2.6	-	8.6	4.0	-	16.5	mA
Output power	W_o	0	0.05	1.55	0	0.05	5.1	W
Distortion	d_{tot}	-	-	10	-	-	10	%

Supply voltage	V_b		200		V
Grid No. 2 series resistor (non decoupled)	R_{g2}		470		Ω
Cathode resistor	R_k		215		Ω
Load resistance	$R_{a\sim}$		2.5		kΩ
Grid No. 1 driving voltage	V_i	0	0.52	7.0	V_{RMS}
Anode current	I_a	65	-	64	mA
Grid No. 2 current	I_{g2}	3.2	-	11.4	mA
Output power	W_o	0	0.05	5.3	W
Distortion	d_{tot}	-	-	10	%

[1]) Measured with V_k kept constant.

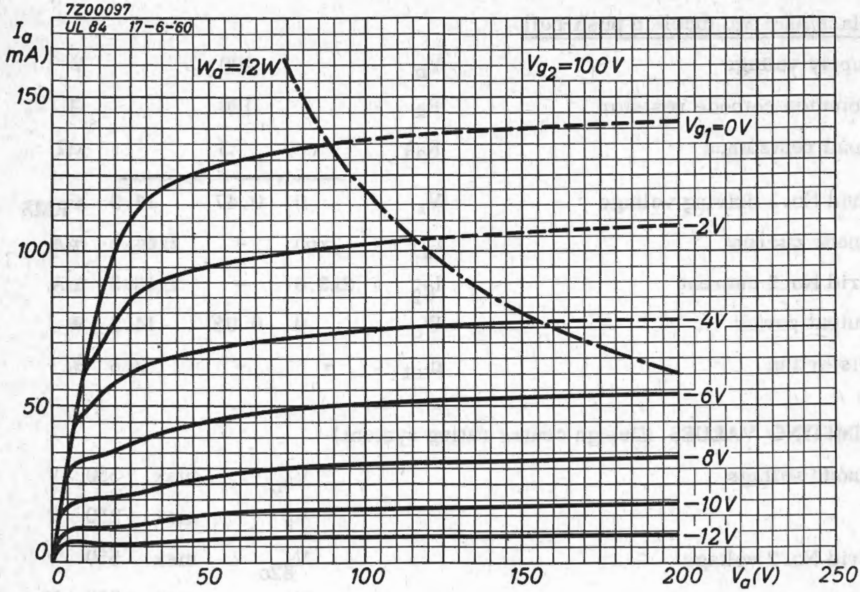
OPERATING CHARACTERISTICS (continued)

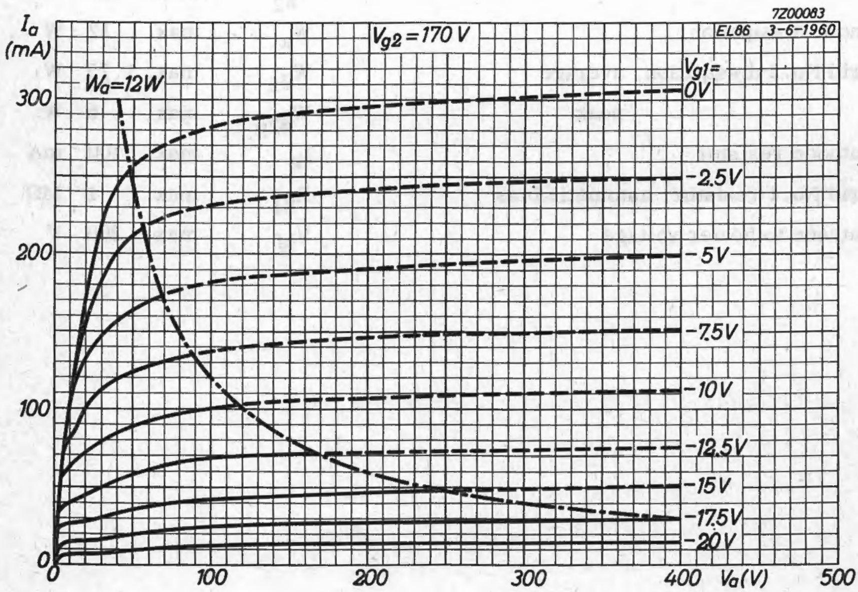
Class AB, two tubes in push-pull

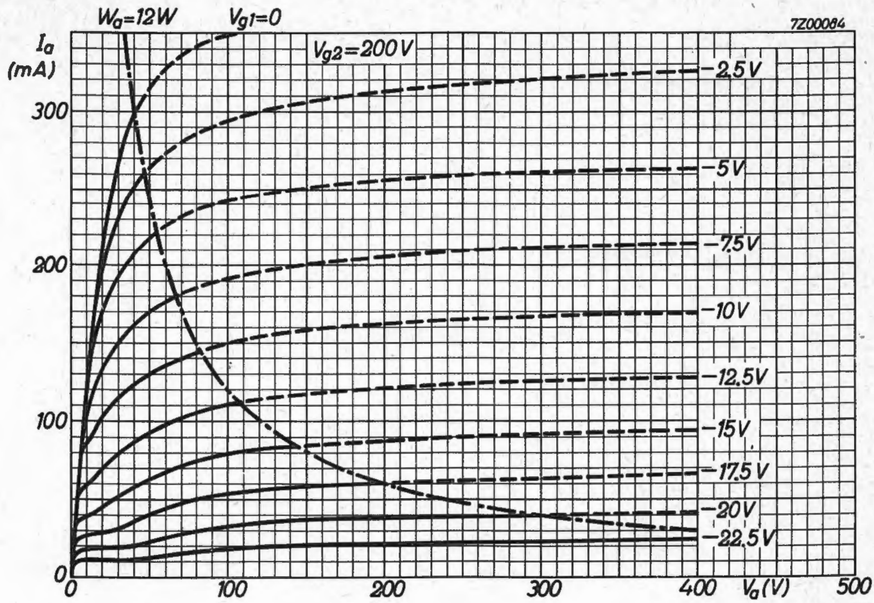
Supply voltage	V_b		200		V
Common cathode resistor	R_k		120		Ω
Load resistance	$R_{aa\sim}$		3		kΩ
Grid No. 1 driving voltage	V_i	0	0.47	14.3	V_{RMS}
Anode current	I_a	2x60	-	2x64.5	mA
Grid No. 2 current	I_{g_2}	2x3.0	-	2x18.5	mA
Output power	W_o	0	0.05	14.3	W
Distortion	d_{tot}	-	-	3.8	%

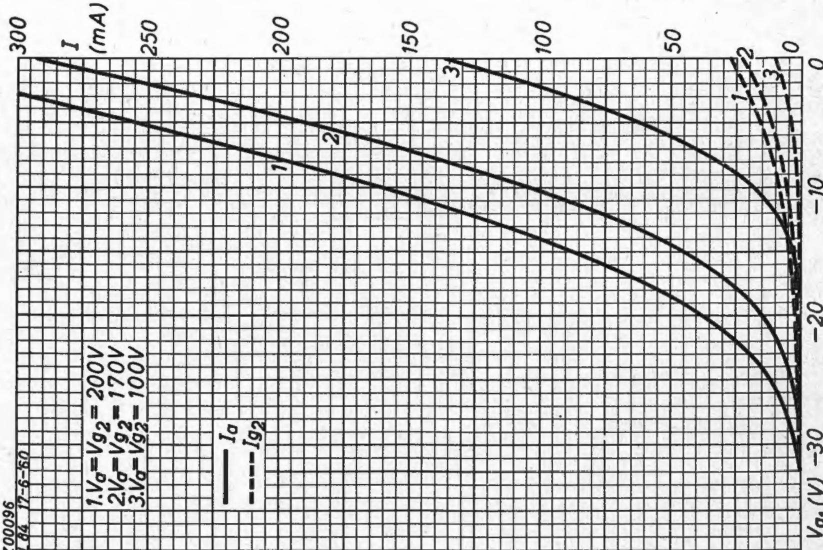
LIMITING VALUES (Design centre rating system)

Anode voltage	V_{a_o}	max.	550	V
	V_a	max.	250	V
Grid No. 2 voltage	$V_{g_{2o}}$	max.	550	V
	V_{g_2}	max.	200	V
Anode dissipation	W_a	max.	12	W
Grid No. 2 dissipation, average	W_{g_2}	max.	1.75	W
peak	$W_{g_{2p}}$	max.	6	W
Cathode resistor	I_k	max.	100	mA
Grid No. 1 resistor, automatic bias	R_{g_1}	max.	1	MΩ
Cathode to heater voltage	V_{kf}	max.	200	V


7Z00097
UL 84 17-6-'60
I_a mA)
W_a=12W
V_{g_2}=100V
V_{g_1}=0V
-2V
-4V
-6V
-8V
-10V
-12V
150
100
50
0
0
50
100
150
200
V_a(V)
250


7Z00083
EL86 3-6-1960
I_a (mA)
V_{g2}=170V
W_a=12W
V_{g1}= 0V
-2.5V
-5V
-7.5V
-10V
-12.5V
-15V
-17.5V
-20V
300
200
100
0
0
100
200
300
400
V_a(V)
500


7Z00084
W_a=12W
V_{g1}=0
V_{g2}=200V
I_a (mA)
300
200
100
0
−2.5V
−5V
−7.5V
−10V
−12.5V
−15V
−17.5V
−20V
−22.5V
0
100
200
300
400
V_a(V)
500


I (mA)
300
250
200
150
100
50
0
V_{g1} (V)
−10
−20
−30
−40
1. V_a = V_{g2} = 200V
2. V_a = V_{g2} = 170V
3. V_a = V_{g2} = 100V
I_a
I_{g2}
7Z00096
UL84 17-6-60

TUNING INDICATOR

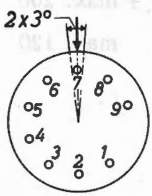
Indicator tube intended for use as tuning indicator or for modulation control.

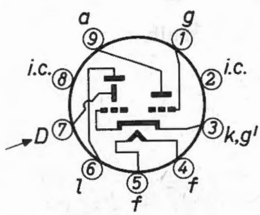
HEATING: Indirect by A.C. or D.C.; series supply

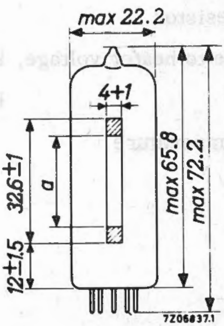
Heater current	I_f	100	mA
Heater voltage	V_f	12	V

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Noval







The arrow near pin 7 indicates the viewing direction.

OPERATING CHARACTERISTICS (D connected to a)

Supply voltage	V_b	170		V
Luminescent screen voltage	V_ℓ	170		V
Anode and deflection electrode resistance	$R_{a,D}$	470		kΩ
Grid resistor	R_g	3		MΩ
Grid supply voltage	V_{bg}	0	−15	V
Anode and deflection electrode current	I_{a+D}	0.3	0.04	mA
Luminescent screen current	I_ℓ	0.6	1.05	mA
Shadow length	a	20±5	0	mm

LIMITING VALUES (Design centre rating system)

Anode voltage		V_{a_o}		max. 550	V
		V_a		max. 250	V
Anode dissipation		W_a		max. 0.5	W
Deflection electrode voltage		V_{Do}		max. 550	V
		V_D		max. 250	V
Luminescent screen voltage		V_{ℓ_o}		max. 550	V
		V_ℓ		max. 250	V
		V_ℓ		min. 170	V
Cathode current		I_k		max. 3	mA
Grid resistor		R_g		max. 3	MΩ
Cathode to heater voltage,	k pos	V_{kf}		max. 250	V
	k neg	V_{kf}	max. 50 $V_{D.C.}$ +	max. 200	V_{RMS}
Bulb temperature		t_{bulb}		max. 120	°C

SINGLE ANODE RECTIFYING TUBE

Single anode high vacuum rectifying tube.

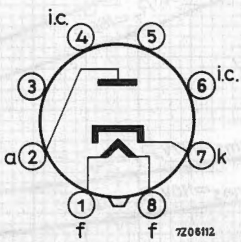
QUICK REFERENCE DATA			
Transformer voltage	V_{tr}	250	V_{RMS}
D.C. current	I_o	100	mA

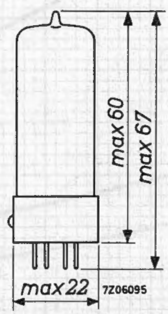
HEATING: Indirect by A.C. or D.C.; series supply

Heater current	I_f	100	mA
Heater voltage	V_f	31	V

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Rimlock



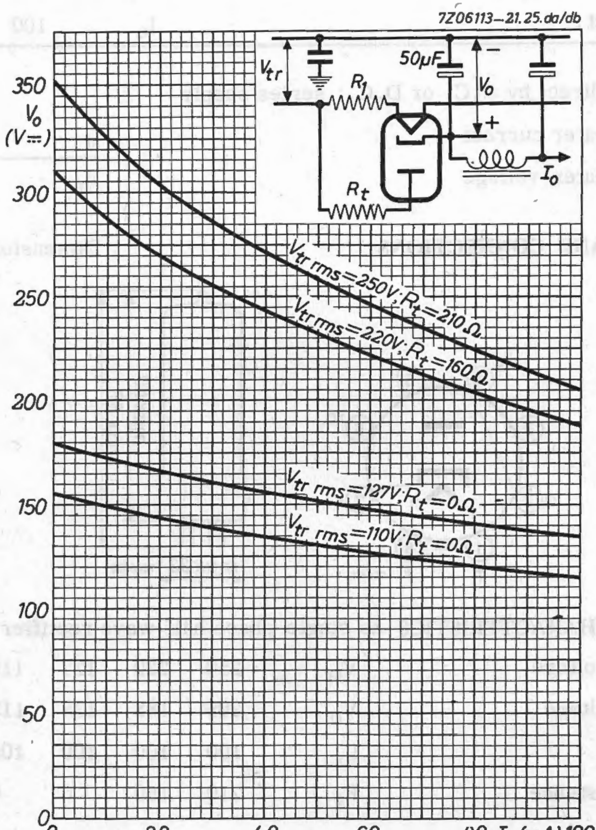


OPERATING CHARACTERISTICS as single-phase half-wave rectifier

Transformer voltage	V_{tr}	250	220	127	110	V_{RMS}
D.C. output voltage	V_o	205	188	135	113	V
D.C. current	I_o	100	100	100	100	mA
Protecting resistance	R_t	210	160	0	0	Ω
Input capacitor of smoothing filter	C_{filt}	50	50	50	50	μF

LIMITING VALUES (Design centre rating system)

Anode voltage, peak inverse	$V_{a\,inv_p}$		max.	700		V
D.C. current	I_o		max.	110		mA
Anode current, peak	I_{ap}		max.	660		mA
Heater to cathode voltage, peak, k pos	V_{kf_p}		max.	550		V
Protecting resistance	R_t	min. 100	90	0	0	Ω
at transformer voltage	V_{tr}	250	220	127	110	V_{RMS}



SINGLE ANODE RECTIFYING TUBE

Single anode high vacuum rectifying tube.

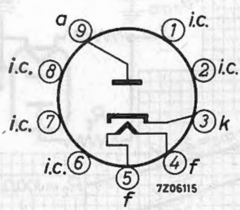
QUICK REFERENCE DATA			
Transformer voltage	V_{tr}	250	V_{RMS}
D.C. current	I_o	110	mA

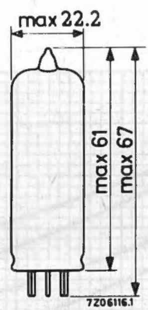
HEATING: Indirect by A.C. or D.C.; series supply

Heater current	I_f	100	mA
Heater voltage	V_f	38	V

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Noval



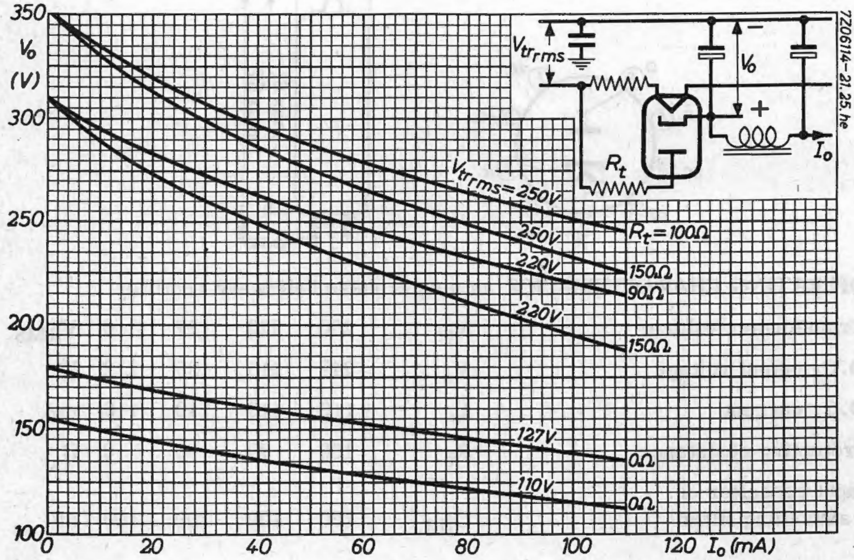


OPERATING CHARACTERISTICS as single-phase half-wave rectifier

Transformer voltage	V_{tr}	250	220	127	110	V_{RMS}
D.C. output voltage	V_o	245	215	135	112	V
D.C. current	I_o	110	110	110	110	mA
Protecting resistance	R_t	100	90	0	0	Ω
Input capacitor of smoothing filter	C_{filt}	100	100	100	100	μF

LIMITING VALUES (Design centre rating system)

Anode voltage, peak inverse	$V_{a\,inv_p}$			max.	700		V
D.C. current	I_o			max.	110		mA
Anode peak current	I_{ap}			max.	660		mA
Cathode to heater voltage, peak, k pos.	V_{kfp}			max.	550		V
Input capacitor of smoothing filter	C_{filt}			max.	100		μF
Protecting resistance	R_t	min.100	90	0	0		Ω
at transformer voltage	V_{tr}	250	220	127	110		V_{RMS}



SINGLE ANODE RECTIFYING TUBE

Single anode high vacuum rectifying tube.

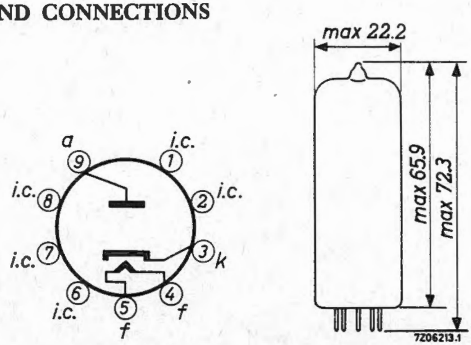
QUICK REFERENCE DATA			
Transformer voltage	V_{tr}	250	V
D.C. current	I_o	100	mA

HEATING: Indirect by A.C. or D.C.; series supply

Heater current	I_f	100	mA
Heater voltage	V_f	31	V

DIMENSIONS AND CONNECTIONS Dimensions in mm

Base: Noval

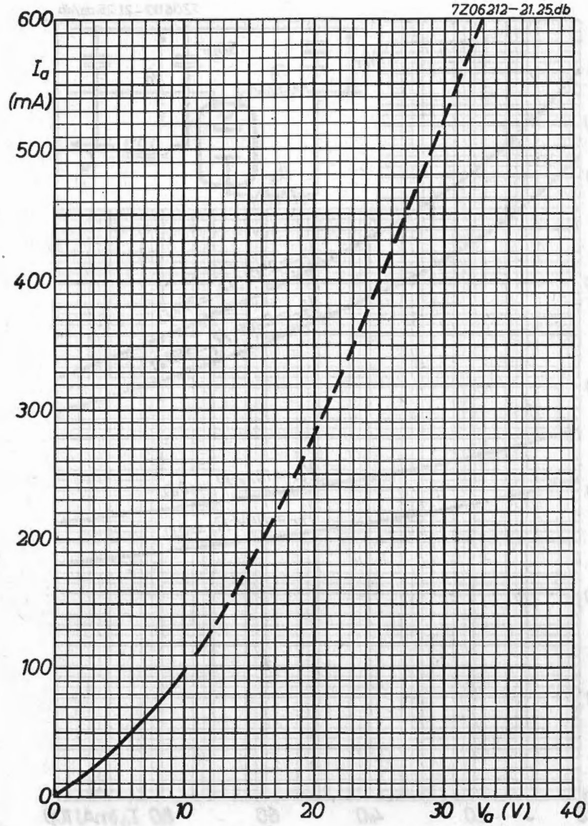


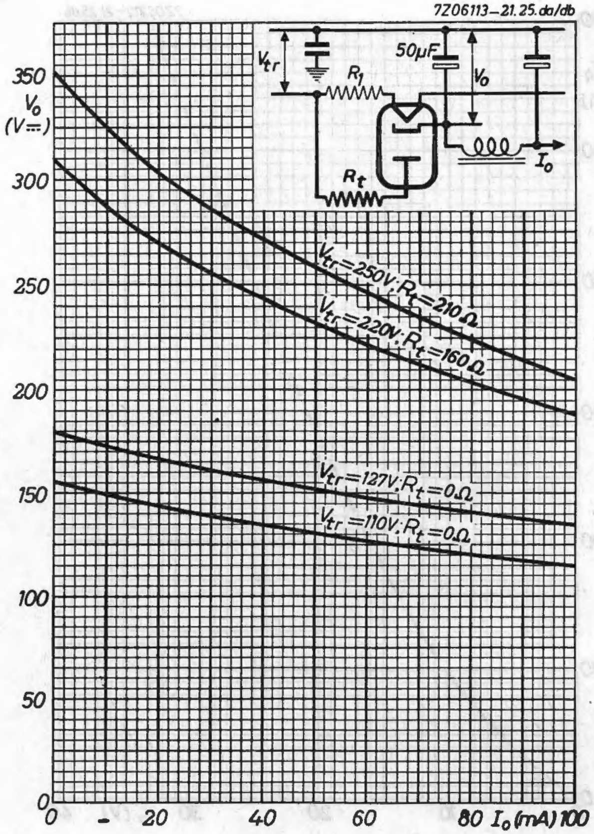
OPERATING CHARACTERISTICS as single-phase half-wave rectifier.

Transformer voltage	V_{tr}	250	220	127	110	V_{RMS}
D.C. output voltage	V_o	205	188	135	113	V
D.C. current	I_o	100	100	100	100	mA
Protecting resistance	R_t	210	160	0	0	Ω
Input capacitor of smoothing filter	C_{filt}	50	50	50	50	μF

LIMITING VALUES (Design centre rating system)

Anode voltage, peak inverse	$V_{a_{invp}}$	max.			700		V
D.C. current	I_o	max.			100		mA
Anode current, peak	I_{ap}	max.			600		mA
Heater to cathode voltage, peak, k pos.	V_{kf_p}	max.			550		V
Protecting resistance	R_t	min. 210	160		0	0	Ω
at transformer voltage	V_{tr}	250	220		127	110	V_{RMS}


7Z06212−21.25.db
600
I_a
(mA)
500
400
300
200
100
0
0
10
20
30
V_a (V)
40


7Z06113–21.25.da/db
350
300
250
200
150
100
50
0
V_o
(V⎓)
0
20
40
60
80
I_o (mA)
100
V_{tr}
50µF
R_1
R_t
V_o
I_o
V_{tr}=250V; R_t=210Ω
V_{tr}=220V; R_t=160Ω
V_{tr}=127V; R_t=0Ω
V_{tr}=110V; R_t=0Ω

INDEX OF TYPE NUMBERS

Type No.	Type No.	Type No.	Type No.	Type No.	type No.
AZ41	ECF801	EL41	EZ81	PL82	UF89
DM70	ECF802	EL42	GY501	PL83	UL41
DY51	ECH42	EL81	GZ34	PL84	UL84
DY86	ECH81	EL82	PABC80	PL95	UM84
DY87	ECH83	EL83	PC86	PL500	UY41
DY802	ECH84	EL84	PC88	PL504	UY42
EAA91	ECH200	EL86	PC92	PL505	UY85
EABC80	ECL80	EL95	PC97	PL508	UY89
EAF42	ECL82	EL500	PC900	PL509	
EB41	ECL84	EL503	PCC85	PL519	
EB91	ECL85	EL504	PCC88	PL802	
EBC41	ECL86	EL505	PCC189	PY81	
EBC81	ECL805	EL508	PCF80	PY82	
EBF80	ED500	EL509	PCF86	PY88	
EBF89	EF40	EL519	PCF200	PY500	
EC86	EF41	EL802	PCF201	PY500A	
EC88	EF42	EM80	PCF801	UABC80	
EC92	EF43	EM81	PCF802	UAF42	
EC900	EF80	EM84	PCH200	UBC41	
ECC40	EF85	EM87	PCL82	UBC81	
ECC81	EF86	EY81	PCL84	UBF89	
ECC82	EF89	EY82	PCL85	UCC85	
ECC83	EF91	EY86	PCL86	UCH41	
ECC85	EF92	EY87	PCL805	UCH42	
ECC88	EF95	EY88	PD500	UCH81	
ECC189	EF183	EY500	PD510	UCL82	
ECF80	EF184	EY500A	PF86	UF41	
ECF86	EFL200	EZ40	PFL200	UF42	
ECF200	EL34	EZ41	PL36	UF80	
ECF201	EL36	EZ80	PL81	UF85	

General section

Receiving tubes

Printed in The Netherlands

9399 131 16801